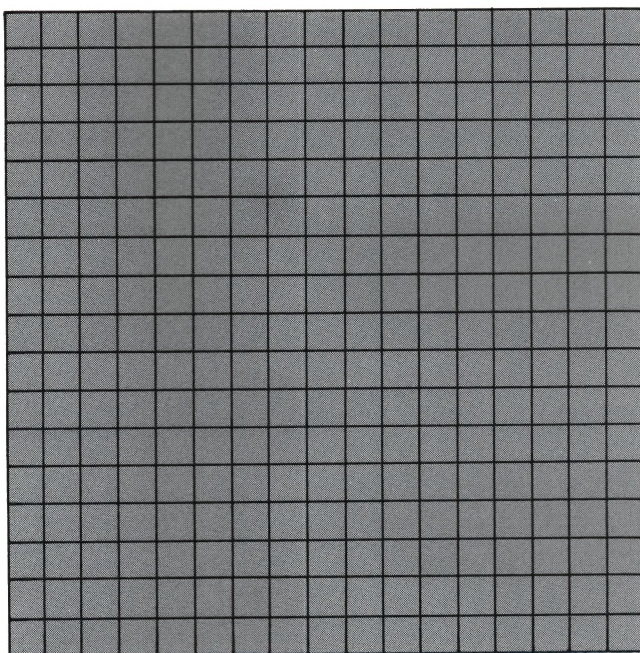


MICROSEMI DATA BOOK

micro

Microsemi Corp.
The diode experts



MICROSEMI DATA BOOK

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INTRODUCTION

DIODES

Microsemi Corp., with the addition of the Siemens Scottsdale semiconductor operation, is now one of the leading diode suppliers in the country. Product capability exceeds that of our major competitors. In fact, Microsemi can now provide over 90% of the most popular silicon diode types ever made. With manufacturing plants in Hong Kong; Bombay, India; Scottsdale, Arizona; and Santa Ana, California, Microsemi has a combined capacity of over 300 million devices per year.

Prior to the acquisition of Siemens' diode products, Microsemi purchased similar lines from Teledyne and Centralab. The combination of these product lines and facilities has enabled Microsemi to quickly assume a dominant position in the diode field.

Over the years, Microsemi has grown to be one of the leading suppliers of military hi-rel diodes and has expanded into the computer, commercial and consumer markets. The front end (dice manufacture) strength of the Siemens operation accelerated Microsemi's entry into these markets. Our overall company goal is to become the leading diode supplier in the country. Product expansion plans are already underway to add new diode products to accomplish our long term goal.

Here is a list of product areas where Microsemi Corp. is presently able to compete:

| Product Type | Military Hi-Rel | Computer/ Industrial | Commercial/ Consumer |
|------------------------------------|--------------------|-------------------------|-------------------------|
| 400mw/500mw Zeners | x | x | x |
| 1.0 watt Zeners | x | x | x |
| 1.5 - 2.5W Zeners | x | x | x |
| 5 watt Zeners | x | x | x |
| 10 watt Zeners | x | x | x |
| 50 watt Zeners | x | x | x |
| 250 - 500 mw Signal Diodes | x | x | x |
| Computer Switch Diodes | x | x | — |
| Low Leakage Pico Amp | x | x | — |
| Multi-junction Stabistors | x | x | — |
| 500ma Rectifier (no recovery) | x | x | — |
| 1.0A Rectifier (no recovery) | x | x | x |
| 3.0A Rectifier (no recovery) | x | x | x |
| 6.0A Rectifier (no recovery) | x | x | x |
| 500ma Rectifier (fast rec.) | x | x | — |
| 1.0A Rectifier (fast recovery) | x | x | x |
| 3.0A Rectifier (fast recovery) | x | x | x |
| 6.0A Rectifier (fast recovery) | x | x | x |
| 10.A Rectifier - Stud D04 | x | x | — |
| 20.A Rectifier - Stud D05 | x | x | — |
| 1.0A Ultra Fast (20 ns) Rectifier | x | x | — |
| 3.0A Ultra Fast (20 ns) Rectifier | x | x | — |
| 6.0A Ultra Fast (20 ns) Rectifier | x | x | — |
| 12.0A Ultra Fast (20 ns) Rectifier | x | x | — |
| 20.A Axial Lead | x | x | — |
| 500 watt Transient Supp. | x | x | — |
| 1500 watt Transient Supp. | x | — | — |
| High Voltage Diodes >1KV | x | x | — |
| High Voltage Fast Recovery >1KV | x | x | — |
| T.C. Zeners | x | x | x |
| T.C. Zener Assemblies | x | x | x |
| Rectifier Assemblies: | | | |
| Bridges | x | x | x |
| Doubblers | x | x | x |
| Dip Bridges | — | x | x |
| Diode Stacks ≤ 10KV | x | x | — |

NOTE 1: Types listed are also available in surface mount. Consult SMT Section or respective factory for specifications.

SPECIAL APPLICATION DIODES

| | |
|-------------------------------------|---|
| Avalanche Diodes | Controlled breakdown |
| Micro Diodes | Ultra-small package |
| Tunnel Diodes | Only manufacturer in the world |
| Backward Diodes | Only manufacturer in the world |
| Hi-Temp 250°C Diodes | Oil drilling, aircraft engine use |
| L.V.A. Zeners | Replaces TRW and Motorola |
| Log Diodes | Controlled conductance |
| Hi Voltage Zeners | > 300V |
| P.I.N. Diodes | Attenuators & Modulators |
| Leadless Inverted Carrier | Use in hybrid circuits |
| Surface Mount Diodes ⁽¹⁾ | Military, medical, and commercial for hybrid & printed circuits |

CHIPS

Microsemi is also the broadest chip supplier in the country and one of the only companies capable of supplying hi-rel and high quality glass passivated dice. The only diode types not in the Microsemi line are: Schottky, Varactor, F.E.T. current regulators, TRIAC's, SCR's and germanium products.

POWER RECTIFIERS and TRANSISTORS

In 1986, Microsemi Corp. strategically entered the power rectifier and transistor market by acquiring the Power Technology Components group of Rockwell International / Allen Bradley, located in a new facility in Torrance, California. The PTC product line currently includes: power rectifiers, HV NPN discrete transistors, and HV NPN Darlingtons and assemblies. These products have 200V to 1200V and 3 to 125 ampere ratings.

"THE DIODE EXPERTS"

Microsemi Corp. was the first diode manufacturer selected by the U.S. military services as a source to qualify product to the highest mil spec level — JANS. To locate them quickly, the JANS series in this data book are marked with a JANS "flag." Currently JANS qualification tests are being performed on many of our other product lines.

We are very proud of our accomplishments at Microsemi, especially from 1982-1986 with over 40% growth rate per year in a down market. Microsemi has an extremely strong engineering team with a total of over 180 years of diode product and process expertise. Our engineers are constantly called upon for unique or high performance devices and work closely with customers to satisfy their special requirements.

Microsemi is a company whose staff is dedicated to the highest performance and quality standards, and the ultimate satisfaction of our customers. While we are not perfect in the accomplishment of these goals, our corporate attitude of seeking constant improvements and corrective action of customer problems has earned us a respected position in the industry.

We are pleased with your interest in our company, and trust that this data will enable you to make a favorable decision to join our growing customer base.

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*For specifications, consult factory, or JEDEC registered data.

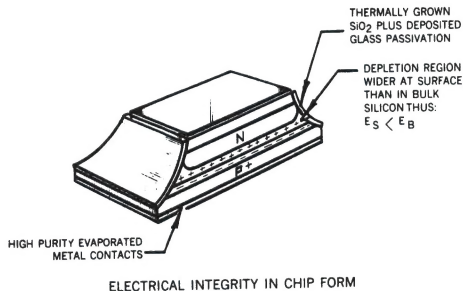
DIODE TECHNOLOGY

VOIDLESS BONDED DIODES

MICROSEMI CORP virtually eliminates all known device failure modes in silicon subminiature glass rectifiers with superior processes and new voidless glass packages.

Starting with the semiconductor die and continuing through final test and inspection, carefully evaluated processes and numerous quality control steps insure product homogeneity and ultimate reliability.

MICRO'S CHIP, a double-diffused mesa structure utilizing photo masking techniques and silicon wafers with 1-0-0 crystal alignment, provides excellent geometry and junction control with uniform contact area. The advantages of the mesa structure for high voltage rectifiers and transistors is well known. MICRO's geometry control and passivation solve the few remaining limitations of the mesa device.



The junction design concentrates breakdown in the bulk material for maximum breakdown voltage with minimum surface fields. Under reverse bias conditions the negative charges in the P-type silicon equalize the positive charges in the N-type. The sharp slope of the etched mesa junction stretches the depletion region at the surface — significantly reducing the surface field below that of the bulk. When breakdown occurs, therefore, it is not at the surface, but in the bulk silicon. With surface effects minimized, the maximum breakdown voltage is achieved with the lowest possible starting wafer resistivity which gives the optimum combination of high breakdown voltage and high conductivity.

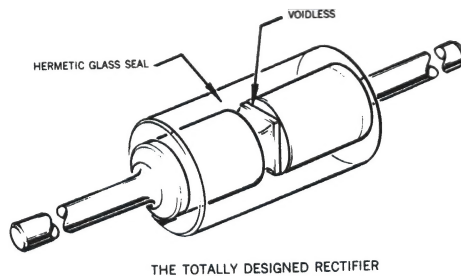
Carefully controlled junction base width insures maximum surge capability. A thermally grown oxide layer followed by a heavily deposited layer of high density alkali-free glass passivates the junction. The double passivation makes the die practically independent of outside ambients. Leakage measurements of less than ten nanoamperes at 200 V are typical and are carefully monitored to assure consistent process control. This combination of passivation and junction geometry provides stable junction breakdown voltages in excess of 1200 volts.

After passivation, high purity evaporated gold is alloyed to both the anode and cathode surfaces, followed by an additional 10KA of evaporated and fired silver. This results in a strong metallurgical contact to the silicon surface and provides extremely low contact resistance. The high temperature metallization system assures that subsequent processing of the dice, either as hybrid chips or in glass and epoxy assemblies, produces no degradation of surface of junction characteristics.

The rectifier final assembly is a three-stage process. The chip is first metallurgically bonded (875° C) to silver plated tungsten slugs. Metallurgical bonding insures structural integrity and the ultimate in reliability. After testing, the slug-die-slug assembly is then ready to be sealed in MICRO's voidless glass package.

MICRO'S VOIDLESS GLASS PACKAGE uses a thermal compression seal of chemically pure hard glass to the silver-plated tungsten slugs. An extremely alkaline-free glass sleeve is placed over the slug-die-slug assembly and heated to 800° C where the glass flows. During controlled cooling, the glass fills all voids and makes a strong thermal compression bond. The resultant package is a monolithic voidless structure of thermally matched material capable of withstanding virtually any environmental stress. Voltages of up to 1400 volts per single junction are sustained without any evidence of arcing.

Finally, copper or other leads as specified by the customer, are brazed to the assembled diode and the entire assembly is pressure tested at 500 PSI and inspected for absolute seal integrity.



GUIDE TO METALLURGICALLY-BONDED AXIAL LEAD DIODES JAN-JTX-JTXV TYPES

Military specifications require that all devices shown here be metallurgically bonded, not just "-1" parts as is generally believed. All devices listed on this chart are manufactured by Microsemi Corporation with the same hard glass voidless metallurgical constructions.

| POWER RATING — Zeners in watts/Rectifiers in I ₀ | | | | | |
|---|---|---|---|---|---|
| | 250mW | 400/500mW or 0.5A I ₀ | 1.5W or 1.0A I ₀ | 3A I ₀ | 5W or 6A I ₀ |
| ZENER | Use 400mW device | 1N 754-A thru 1N 759A-1 /127 1N 962B-1 thru 1N 973B-1 /117 | 1N 4460 thru 1N 4496 /406A | * | 1N4954 thru 1N4989 /356 |
| SMALL SIGNAL | 1N5194 thru 1N5196 /118 1N3595 /241 | See "RECTIFIER (NON-RECOVERY)" 1N 645-1 1N 649-1 | N.A. | N.A. | N.A. |
| COMPUTER CORE DRIVER | 1N 4148-1 /116 1N 4454-1 /144 | 1N 4150-1 /231 1N 4153-1 /337 | Use 1N 5802 Series | Use 1N 5807 Series | N.A |
| RECTIFIER (NON-RECOVERY) | See "SMALL SIGNAL" 1N 5194-6 | 1N 645-1 thru 1N 649-1 /240 | 1N 3611 thru 1N 3614 & 1N 3957 /228 1N 4245 thru 1N 4249 /286 1N 5614 thru 1N 5622 /427 | 1N5550 thru 1N5552 /420 | * |
| RECTIFIER (FAST RECOVERY) | 1N 4938-1 /169 | Use 1N 4938-1 /169 | 1N 4942 thru 1N 4948 /359 1N 5615 thru 1N 5623 /429 | 1N 5415 thru 1N 5420 /411 1N5186 thru 1N5190 /424 | * |
| RECTIFIER (ULTRA-FAST RECOVERY) | Use Computer Core Drive Types | * | 1N 5802 thru 1N 5806 /477 1N6073 thru 1N6075 /503 (EL) | 1N 5807 thru 1N 5811 /477 1N 6076 1N6078 /503 (EL) | 1N6079 1N 6080 1N 6081 /503 (EL) |

*Microsemi Corp. has metal-bonded voidless devices in these areas for non-standard parts.

/// Microsemi Corp. mil-qualification pending.

ZENER DIODE/RECTIFIER CROSS REFERENCE CHART

Containing all JEDEC registered Zener diodes.

This popular reference chart contains highlight information on all JEDEC registered Zener diode and rectifier types as well as Microsemi types. The following Codes are used:

Bold Face Type Only: Indicates devices manufactured by Microsemi

Light Face Type: Indicates devices not manufactured or offered by Microsemi. In most cases a "recommended substitute" is noted in column 8. It should be noted however that recommended substitutes are not direct replacements.

Case outlines are found on pages 37 thru 40.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|--|---------------------------|------------|--------------------------------------|--------------------------------|--------------|-----------------------|----------------------------------|
| 1N225 ⁽¹⁾ | 7.5 - 10.0 | 0.20 | — | Suffix A = 5% | 150mw | Case A ⁽⁸⁾ | |
| 1N226 ⁽¹⁾ | 9.0 - 12.0 | " | — | " " | " | " | |
| 1N227 ⁽¹⁾ | 11.0 - 14.5 | " | — | " " | " | " | |
| 1N228 ⁽¹⁾ | 13.5 - 18.0 | " | — | " " | " | " | |
| 1N229 ⁽¹⁾ | 17.0 - 21.0 | " | — | " " | " | " | |
| 1N230 ⁽¹⁾ | 20.0 - 27.0 | " | — | " " | " | " | |
| 1N231 ⁽¹⁾ | 25.0 - 32.0 | " | — | " " | " | " | |
| 1N232 ⁽¹⁾ | 30.0 - 39.0 | " | — | " " | " | " | |
| 1N233 ⁽¹⁾ | 37.0 - 45.0 | " | — | " " | " | " | |
| 1N234 ⁽¹⁾ | 43.0 - 54.0 | " | — | " " | " | " | |
| 1N235 ⁽¹⁾ | 52.0 - 64.0 | " | — | " " | " | " | |
| 1N236 thru 1N239 is an obsolete 150 mW Series. | | | | | | | |
| 1N429 ⁽²⁾ | 6.2 ± 5% | 7.5 | 20.0 | T.C. = .01%/°C ⁽⁴⁾ | 200mw | Case A ⁽⁸⁾ | |
| 1N430 ⁽²⁾ | 8.4 ± 5% | 10.0 | 15.0 | T.C. = .002%/°C ⁽⁴⁾ | 250mw | Case B | |
| 1N430A ⁽²⁾ | " " | " | " | T.C. = .001%/°C ⁽⁴⁾ | " | " | |
| 1N430B ⁽²⁾ | " " | " | " | T.C. = .001%/°C ⁽⁵⁾ | " | " | |
| 1N465 | 2.0 - 3.2 | 5.0 | 60.0 ⁽³⁾ | Suffix A = 5% | 200mw | Case A ⁽⁸⁾ | |
| 1N466 | 3.0 - 3.9 | " | 55.0 ⁽³⁾ | Suffix B = 1% | " | " | |
| 1N467 | 3.7 - 4.5 | " | 45.0 ⁽³⁾ | " " | " | " | |
| 1N468 | 4.3 - 5.4 | " | 35.0 ⁽³⁾ | " " | " | " | |
| 1N469 | 5.2 - 6.4 | " | 20.0 ⁽³⁾ | " " | " | " | |
| 1N470 | 6.2 - 8.0 | " | 10.0 ⁽³⁾ | " " | " | " | |
| 1N471 ⁽¹⁾ | 3.0 - 3.9 | " | 65.0 ⁽³⁾ | Suffix A = 5% | " | " | |
| 1N472 ⁽¹⁾ | 3.7 - 4.5 | " | 60.0 ⁽³⁾ | " " | " | " | |
| 1N473 ⁽¹⁾ | 4.3 - 5.4 | " | 50.0 ⁽³⁾ | " " | " | " | |
| 1N474 ⁽¹⁾ | 5.2 - 6.4 | " | 40.0 ⁽³⁾ | " " | " | " | |
| 1N475 ⁽¹⁾ | 6.2 - 8.0 | " | 25.0 ⁽³⁾ | " " | " | " | |
| Type No. | PIV | I_o 25°C | VF | IR | T_{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| 1N483B | 80 | .2 | 1.0 | .025 | | D07 | |
| 1N485B | 200 | .2 | 1.0 | .025 | | D07 | |
| 1N486B | 250 | .2 | 1.0 | .025 | | D07 | |
| 1N645-1 | 260 | .4 | 1.0 | .05 | | DO35 | |
| 1N647-1 | 480 | .4 | 1.0 | .05 | | DO35 | |
| 1N649-1 | 720 | .4 | 1.0 | .05 | | DO35 | |
| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| 1N664 | 8.2 | 10.0 | 7.0 | 5% | 400mw | — | |
| 1N665 | 12.0 | 10.0 | 10.0 | " | " | — | |
| 1N666 | 15.0 | 5.0 | 24.0 | " | " | — | |
| 1N667 | 18.0 | " | 26.0 | " | " | — | |
| 1N668 | 22.0 | " | 30.0 | " | " | — | |
| 1N669 | 27.0 | " | 35.0 | " | " | — | |
| 1N670 | 68.0 | 1.0 | 290.0 | " | " | — | |
| 1N671 | 100.0 | " | 350.0 | " | " | — | |
| 1N672 | 150.0 | " | 1000.0 | " | " | — | |
| 1N674 | 4.7 | 20.0 | 16.0 | 5% | 400mw | — | 1N750 |
| 1N675 | 6.2 | 20.0 | 3.0 | 5% | 400mw | — | 1N753 |
| 1N701 | 10.0 | 10.0 | 9.0 | 5% | 400mw | — | 1N758 |
| 1N702 | 2.0 - 3.2 | 5.0 | 60.0 ⁽³⁾ | Suffix A = 5% | 250mw | DO-7/DO-35 | |
| 1N703 | 3.0 - 3.9 | " | 55.0 ⁽³⁾ | " " | " | " | |
| 1N704 | 3.7 - 4.5 | " | 45.0 ⁽³⁾ | " " | " | " | |
| 1N705 | 4.3 - 5.4 | " | 35.0 ⁽³⁾ | " " | " | " | |
| 1N706 | 5.2 - 6.4 | " | 20.0 ⁽³⁾ | " " | " | " | |
| 1N707 | 6.2 - 8.0 | " | 10.0 ⁽³⁾ | " " | " | " | |
| 1N708 | 5.6 | 25.0 | 3.6 | No Suffix = 10% | 250mw | " | |
| 1N709 | 6.2 | " | 4.1 | Suffix A = 5% | " | " | |
| 1N710 | 6.8 | " | 4.7 | " " | " | " | |
| 1N711 | 7.5 | " | 5.3 | " " | " | " | |
| 1N712 | 8.2 | " | 6.0 | " " | " | " | |
| 1N713 | 9.1 | 12.0 | 7.0 | " " | " | " | |
| 1N714 | 10.0 | " | 8.0 | " " | " | " | |
| 1N715 | 11.0 | " | 9.0 | " " | " | " | |
| 1N716 | 12.0 | " | 10.0 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

- (1) Double anode type
- (2) Temperature compensated zener diode
- (3) $I_{ZT} = 10mA$
- (4) Temperature range -55°C to +100°C
- (5) Temperature range -55°C to +150°C
- (8) Microsemi utilizes glass sub potted in epoxy.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|------------------------|------------------------------|------|--|-----------------------------------|-----------------|-------------------|--|
| 1N717 | 13.0 | 12.0 | 11.0 | No Suffix = 10% | 250 mw | DO-7/DO-35 | |
| 1N718 | 15.0 | " | 13.0 | Suffix A = 5% | " | " | |
| 1N719 | 16.0 | " | 15.0 | " | " | " | |
| 1N720 | 18.0 | " | 17.0 | " | " | " | |
| 1N721 | 20.0 | 4.0 | 20.0 | " | " | " | |
| 1N722 | 22.0 | " | 24.0 | " | " | " | |
| 1N723 | 24.0 | " | 28.0 | " | " | " | |
| 1N724 | 27.0 | " | 35.0 | " | " | " | |
| 1N725 | 30.0 | " | 42.0 | " | " | " | |
| 1N726 | 33.0 | " | 50.0 | " | " | " | |
| 1N727 | 36.0 | " | 60.0 | " | " | " | |
| 1N728 | 39.0 | " | 70.0 | " | " | " | |
| 1N729 | 43.0 | " | 84.0 | " | " | " | |
| 1N730 | 47.0 | " | 98.0 | " | " | " | |
| 1N731 | 51.0 | " | 115.0 | " | " | " | |
| 1N732 | 56.0 | " | 140.0 | " | " | " | |
| 1N733 | 62.0 | 2.0 | 170.0 | No Suffix = 10% | 250 mw | DO-7/DO-35 | |
| 1N734 | 68.0 | 2.0 | 200.0 | Suffix A = 5% | " | " | |
| 1N735 | 75.0 | 2.0 | 240.0 | " | " | " | |
| 1N736 | 82.0 | 2.0 | 280.0 | " | " | " | |
| 1N737 | 91.0 | 1.0 | 340.0 | " | " | " | |
| 1N738 | 100.0 | 1.0 | 400.0 | " | " | " | |
| 1N739 | 110.0 | 1.0 | 490.0 | " | " | " | |
| 1N740 | 120.0 | 1.0 | 570.0 | " | " | " | |
| 1N741 | 130.0 | 1.0 | 650.0 | " | " | " | |
| 1N742 | 150.0 | 1.0 | 860.0 | " | " | " | |
| 1N743 | 160.0 | 1.0 | 970.0 | " | " | " | |
| 1N744 | 180.0 | 1.0 | 1200.0 | " | " | " | |
| 1N745 | 200.0 | 1.0 | 1400.0 | " | " | " | |
| 1N746 | 3.3 | 20.0 | 28.0 | No Suffix = 10% | 400 mw | DO-7/DO-35 | |
| 1N747 | 3.6 | 20.0 | 24.0 | Suffix A = 5% | " | " | |
| 1N748 | 3.9 | 20.0 | 23.0 | " | " | " | |
| 1N749 | 4.3 | 20.0 | 22.0 | " | " | " | |
| 1N750 | 4.7 | 20.0 | 19.0 | " | " | " | |
| 1N751 | 5.1 | 20.0 | 17.0 | " | " | " | |
| 1N752 | 5.6 | 20.0 | 11.0 | " | " | " | |
| 1N753 | 6.2 | 20.0 | 7.0 | " | " | " | |
| 1N754 | 6.8 | 20.0 | 5.0 | " | " | " | |
| 1N755 | 7.5 | 20.0 | 6.0 | " | " | " | |
| 1N756 | 8.2 | 20.0 | 8.0 | " | " | " | |
| 1N757 | 9.1 | 20.0 | 10.0 | " | " | " | |
| 1N758 | 10.0 | 20.0 | 17.0 | " | " | " | |
| 1N759 | 12.0 | 20.0 | 30.0 | " | " | " | |
| 1N761 | 4.3 - 5.4 | 10.0 | 40.0 | | 250 mw | " | |
| 1N762 | 5.2 - 6.4 | " | 18.0 | | " | " | |
| 1N763 | 6.2 - 8.0 | " | 7.0 | | " | " | |
| 1N764 | 7.5 - 10.0 | " | 12.0 | | " | " | |
| 1N765 | 9.0 - 12.0 | 5.0 | 45.0 | | " | " | |
| 1N766 | 11.0 - 14.5 | 5.0 | 55.0 | | " | " | |
| 1N767 | 13.5 - 18.0 | 5.0 | 70.0 | | " | " | |
| 1N768 | 17.0 - 21.0 | 5.0 | 100.0 | | " | " | |
| 1N769 | 20.0 - 27.0 | 5.0 | 150.0 | | " | " | |
| 1N821 ⁽²⁾ | 6.2 ± 5% | 7.5 | 15.0 | T.C. = .01% / °C ⁽⁴⁾ | 400 mw | DO-7/DO-35 | |
| 1N821A ⁽²⁾ | 6.2 ± 5% | " | 10.0 | T.C. = .01% / °C ⁽⁴⁾ | " | " | |
| 1N822 ^(1,2) | 6.2 ± 5% | " | 15.0 | T.C. = .01% / °C ⁽⁴⁾ | " | " | |
| 1N823 ⁽²⁾ | 6.2 ± 5% | " | 15.0 | T.C. = .005% / °C ⁽⁴⁾ | " | " | |
| 1N823A ⁽²⁾ | 6.2 ± 5% | " | 10.0 | T.C. = .005% / °C ⁽⁴⁾ | " | " | |
| 1N824 ^(1,2) | 6.2 ± 5% | " | 15.0 | T.C. = .005% / °C ⁽⁴⁾ | " | " | |
| 1N825 ⁽²⁾ | 6.2 ± 5% | " | 15.0 | T.C. = .002% / °C ⁽⁴⁾ | " | " | |
| 1N825A ⁽²⁾ | 6.2 ± 5% | " | 10.0 | T.C. = .002% / °C ⁽⁴⁾ | " | " | |
| 1N826 ⁽²⁾ | 6.2 - 6.9 | " | 15.0 | T.C. = .002% / °C ⁽⁴⁾ | " | " | |
| 1N827 ⁽²⁾ | 6.2 ± 5% | " | 15.0 | T.C. = .001% / °C ⁽⁴⁾ | " | " | |
| 1N827A ⁽²⁾ | 6.2 ± 5% | " | 10.0 | T.C. = .001% / °C ⁽⁴⁾ | " | " | |
| 1N828 ⁽²⁾ | 6.2 - 6.9 | " | 15.0 | T.C. = .001% / °C ⁽⁴⁾ | " | " | |
| 1N829A | 6.2 ± 5% | " | 15.0 | T.C. = .0005% / °C ⁽⁴⁾ | " | " | |
| 1N935 ⁽²⁾ | 9.0 ± 5% | 7.5 | 20.0 | T.C. = .01% / °C ⁽⁷⁾ | 500 mw | DO-7 | |
| 1N936 ⁽²⁾ | 9.0 ± 5% | " | 20.0 | T.C. = .005% / °C ⁽⁷⁾ | " | " | |
| 1N937 ⁽²⁾ | 9.0 ± 5% | " | 20.0 | T.C. = .002% / °C ⁽⁷⁾ | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(1) Double anode type (4) Temperature range —55°C to +100°C (7) No suffix denotes temp. range 0°C to +75°C
 (2) Temperature compensated zener diode Suffix A denotes temp. range —55°C to +100°C
 Suffix B denotes temp. range —55°C to +150°C

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------|------------------------------|--------------|--|-------------------------------|-----------------|-------------------|--|
| 1N938(2) | 9.0 ± 5% | 7.5 | 20.0 | T.C. = .001% / °C(7) | " | " | |
| 1N939(2) | 9.0 ± 5% | " | 20.0 | T.C. = .0005% / °C(7) | " | " | |
| 1N940(2) | 9.0 ± 5% | " | 20.0 | T.C. = .0002% / °C(7) | " | " | |
| 1N941(2) | 11.7 ± 5% | 7.5 | 30.0 | T.C. = .01% / °C(7) | " | " | |
| 1N942(2) | 11.7 ± 5% | " | 30.0 | T.C. = .005% / °C(7) | " | " | |
| 1N943(2) | 11.7 ± 5% | " | 30.0 | T.C. = .002% / °C(7) | " | " | |
| 1N944(2) | 11.7 ± 5% | " | 30.0 | T.C. = .001% / °C(7) | " | " | |
| 1N945(2) | 11.7 ± 5% | " | 30.0 | T.C. = .0005% / °C(7) | " | " | |
| 1N946(2) | 11.7 ± 5% | " | 30.0 | T.C. = .0002% / °C(7) | " | " | |
| 1N957 | 6.8 | 18.5 | 4.5 | No Suffix = 20% | 400mw | DO-7/DO-35 | |
| 1N958 | 7.5 | 16.5 | 5.5 | Suffix A = 10% | " | " | |
| 1N959 | 8.2 | 15.0 | 6.5 | Suffix B = 5% | " | " | |
| 1N960 | 9.1 | 14.0 | 7.5 | " | " | " | |
| 1N961 | 10.0 | 12.5 | 8.5 | " | " | " | |
| 1N962 | 11.0 | 11.5 | 9.5 | " | " | " | |
| 1N963 | 12.0 | 10.5 | 11.5 | " | " | " | |
| 1N964 | 13.0 | 9.5 | 13.0 | " | " | " | |
| 1N965 | 15.0 | 8.5 | 16.0 | " | " | " | |
| 1N966 | 16.0 | 7.8 | 17.0 | No Suffix = 20% | 400mw | DO-7/DO-35 | |
| 1N967 | 18.0 | 7.0 | 21.0 | Suffix A = 10% | " | " | |
| 1N968 | 20.0 | 6.2 | 25.0 | Suffix B = 5% | " | " | |
| 1N969 | 22.0 | 5.6 | 29.0 | " | " | " | |
| 1N970 | 24.0 | 5.2 | 33.0 | " | " | " | |
| 1N971 | 27.0 | 4.6 | 41.0 | " | " | " | |
| 1N972 | 30.0 | 4.2 | 49.0 | " | " | " | |
| 1N973 | 33.0 | 3.8 | 58.0 | " | " | " | |
| 1N974 | 36.0 | 3.4 | 70.0 | " | " | " | |
| 1N975 | 39.0 | 3.2 | 80.0 | " | " | " | |
| 1N976 | 43.0 | 3.0 | 93.0 | " | " | " | |
| 1N977 | 47.0 | 2.7 | 105.0 | " | " | " | |
| 1N978 | 51.0 | 2.5 | 125.0 | " | " | " | |
| 1N979 | 56.0 | 2.2 | 150.0 | " | " | " | |
| 1N980 | 62.0 | 2.0 | 185.0 | " | " | " | |
| 1N981 | 68.0 | 1.8 | 230.0 | " | " | " | |
| 1N982 | 75.0 | 1.7 | 270.0 | " | " | " | |
| 1N983 | 82.0 | 1.5 | 330.0 | " | " | " | |
| 1N984 | 91.0 | 1.4 | 400.0 | " | " | " | |
| 1N985 | 100.0 | 1.3 | 500.0 | " | " | " | |
| 1N986 | 110.0 | 1.1 | 750.0 | " | " | " | |
| 1N987 | 120.0 | 1.0 | 900.0 | " | " | " | |
| 1N988 | 130.0 | 0.95 | 1100.0 | " | " | " | |
| 1N989 | 150.0 | 0.85 | 1500.0 | " | " | " | |
| 1N990 | 160.0 | 0.80 | 1700.0 | " | " | " | |
| 1N991 | 180.0 | 0.68 | 2200.0 | " | " | " | |
| 1N992 | 200.0 | 0.65 | 2500.0 | " | " | " | |
| 1N1313 | 7.5 - 10.0 | 0.20 | — | Suffix A = 5% | 150mw | Case A(8) | |
| 1N1314 | 9.0 - 12.0 | " | — | " | " | " | |
| 1N1315 | 11.0 - 14.5 | " | — | " | " | " | |
| 1N1316 | 13.5 - 18.0 | " | — | " | " | " | |
| 1N1317 | 17.0 - 21.0 | " | — | " | " | " | |
| 1N1318 | 20.0 - 27.0 | " | — | " | " | " | |
| 1N1319 | 25.0 - 32.0 | " | — | " | " | " | |
| 1N1320 | 30.0 - 39.0 | " | — | " | " | " | |
| 1N1321 | 37.0 - 45.0 | " | — | " | " | " | |
| 1N1322 | 43.0 - 54.0 | " | — | " | " | " | |
| 1N1323 | 52.0 - 64.0 | " | — | " | " | " | |
| 1N1324 | 62.0 - 80.0 | " | — | " | " | " | |
| 1N1325 | 75.0 - 100 | " | — | " | " | " | |
| 1N1326 | 90.0 - 120 | " | — | " | " | " | |
| 1N1327 | 110 - 145 | " | — | " | " | " | |
| 1N1351 | 10.0 | 500.0 | 2.0 | No Suffix = 10% | 10 watt | DO-4 | |
| 1N1352 | 11.0 | 500.0 | 2.0 | Suffix A = 5% | " | " | |
| 1N1353 | 12.0 | 500.0 | 2.0 | Suffix R = Rev. Polarity | " | " | |
| 1N1354 | 13.0 | 500.0 | 2.0 | " | " | " | |
| 1N1355 | 15.0 | 500.0 | 2.0 | " | " | " | |
| 1N1356 | 16.0 | 500.0 | 3.0 | " | " | " | |
| 1N1357 | 18.0 | 150.0 | 3.0 | " | " | " | |
| 1N1358 | 20.0 | 150.0 | 3.0 | " | " | " | |
| 1N1359 | 22.0 | 150.0 | 3.0 | " | " | " | |
| 1N1360 | 24.0 | 150.0 | 3.0 | " | " | " | |
| 1N1361 | 27.0 | 150.0 | 3.0 | " | " | " | |
| 1N1362 | 30.0 | 150.0 | 4.0 | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type. (8) Microsemi device utilizes glass sub potted in epoxy.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|------------------------|-------------------------------------|-------|---|----------------------------------|-----------------|----------------------|--|
| | Volts | @ mA | | | | | |
| 1N1363 | 33.0 | 150.0 | 4.0 | No Suffix = 10% | 10 watt | DO-4 | |
| 1N1364 | 36.0 | 150.0 | 5.0 | Suffix A = 5% | " | " | |
| 1N1365 | 39.0 | 150.0 | 5.0 | Suffix R = Rev. Polarity | " | " | |
| 1N1366 | 43.0 | 150.0 | 6.0 | " " | " | " | |
| 1N1367 | 47.0 | 150.0 | 7.0 | " " | " | " | |
| 1N1368 | 51.0 | 150.0 | 8.0 | " " | " | " | |
| 1N1369 | 56.0 | 150.0 | 9.0 | " " | " | " | |
| 1N1370 | 62.0 | 50.0 | 12.0 | " " | " | " | |
| 1N1371 | 68.0 | 50.0 | 14.0 | " " | " | " | |
| 1N1372 | 75.0 | 50.0 | 20.0 | " " | " | " | |
| 1N1373 | 82.0 | 50.0 | 22.0 | " " | " | " | |
| 1N1374 | 91.0 | 50.0 | 35.0 | " " | " | " | |
| 1N1375 | 100.0 | 50.0 | 40.0 | " " | " | " | |
| 1N1416 | 8.2 | 200.0 | 3.0 | 5% | 10 watt | — | 1N2972 |
| 1N1417 | 12.0 | 200.0 | 3.5 | " | " | — | 1N2976 |
| 1N1418 | 15.0 | 100.0 | 4.0 | " | " | — | 1N2979 |
| 1N1419 | 18.0 | 100.0 | 5.0 | " | " | — | 1N2982 |
| 1N1420 | 22.0 | 100.0 | 5.0 | " | " | — | 1N2985 |
| 1N1421 | 27.0 | 50.0 | 8.0 | " | " | — | 1N2988 |
| 1N1422 | 68.0 | 20.0 | 15.0 | 5% | 10 watt | — | 1N3001 |
| 1N1423 | 100.0 | 20.0 | 30.0 | " | " | — | 1N3005 |
| 1N1424 | 150.0 | 10.0 | 105.0 | " | " | — | 1N3011 |
| 1N1425 | 8.2 | 20.0 | 5.0 | 5% | 1 watt | — | 1N3018 |
| 1N1426 | 12.0 | 20.0 | 7.0 | " | " | — | 1N3022 |
| 1N1427 | 15.0 | 10.0 | 17.0 | " | " | — | 1N3024 |
| 1N1428 | 18.0 | 10.0 | 20.0 | " | " | — | 1N3026 |
| 1N1429 | 22.0 | 10.0 | 23.0 | " | " | — | 1N3028 |
| 1N1430 | 27.0 | 5.0 | 50.0 | " | " | — | 1N3030 |
| 1N1431 | 68.0 | 2.0 | 150.0 | " | " | — | 1N3040 |
| 1N1432 | 100.0 | 2.0 | 350.0 | " | " | — | 1N3044 |
| 1N1433 | 150.0 | 1.0 | 1200.0 | " | " | — | 1N3048 |
| 1N1482 | 4.7 | 200.0 | 3.0 | 5% | 10 watt | — | 1N3995 |
| 1N1483 | 6.2 | 200.0 | 2.0 | " | " | — | 1N3998 |
| 1N1484 | 4.7 | 50.0 | 5.0 | 5% | 1 watt | — | 1N3825 |
| 1N1485 | 6.2 | 20.0 | 5.0 | " | " | — | 1N3828 |
| 1N1507 | 3.9 | 35.0 | 15.0 | No Suffix = 10% | 750mw | DO-12 ⁽⁹⁾ | 1N3823 |
| 1N1508 | 4.7 | 30.0 | 13.0 | Suffix A = 5% | " | " | 1N3825 |
| 1N1509 | 5.6 | 26.0 | 11.0 | " " | " | " | 1N3827 |
| 1N1510 | 6.8 | 22.0 | 3.0 | " " | " | " | 1N3016 |
| 1N1511 | 8.2 | 18.0 | 3.0 | " " | " | " | 1N3018 |
| 1N1512 | 10.0 | 15.0 | 3.2 | " " | " | " | 1N3020 |
| 1N1513 | 12.0 | 12.0 | 6.5 | " " | " | " | 1N3022 |
| 1N1514 | 15.0 | 10.0 | 10.5 | " " | " | " | 1N3024 |
| 1N1515 | 18.0 | 8.0 | 16.0 | " " | " | " | 1N3026 |
| 1N1516 | 22.0 | 6.0 | 40.0 | " " | " | " | 1N3028 |
| 1N1517 | 27.0 | 5.0 | 82.0 | " " | " | " | 1N3030 |
| 1N1518 | 3.9 | 50.0 | 10.0 | No Suffix = 10% | 1 watt | DO-3 ⁽⁹⁾ | 1N3823 |
| 1N1519 | 4.7 | 40.0 | 13.0 | Suffix A = 5% | " | " | 1N3825 |
| 1N1520 | 5.6 | 35.0 | 10.2 | " " | " | " | 1N3827 |
| 1N1521 | 6.8 | 30.0 | 4.2 | " " | " | " | 1N3016 |
| 1N1522 | 8.2 | 25.0 | 3.0 | " " | " | " | 1N3018 |
| 1N1523 | 10.0 | 20.0 | 4.0 | " " | " | " | 1N3020 |
| 1N1524 | 12.0 | 15.0 | 6.0 | " " | " | " | 1N3022 |
| 1N1525 | 15.0 | 13.0 | 13.0 | " " | " | " | 1N3024 |
| 1N1526 | 18.0 | 10.0 | 25.0 | " " | " | " | 1N3026 |
| 1N1527 | 22.0 | 9.0 | 32.0 | " " | " | " | 1N3028 |
| 1N1528 | 27.0 | 7.0 | 45.0 | " " | " | " | 1N3030 |
| 1N1530 ⁽²⁾ | 8.4 ± 5% | 10.0 | 15.0 | T.C. = .002% / °C ⁽⁴⁾ | 250mw | Case Q | 1N3156 ⁽²⁷⁾ |
| 1N1530A ⁽²⁾ | 8.4 ± 5% | 10.0 | 15.0 | T.C. = .001% / °C ⁽⁴⁾ | " | " | 1N3157 ⁽²⁷⁾ |
| 1N1588 | 3.9 | 150.0 | 4.5 | No Suffix = 10% | 3.5 watt | DO-4 | |
| 1N1589 | 4.7 | 125.0 | 4.0 | Suffix A = 5% | " | " | |
| 1N1590 | 5.6 | 110.0 | 3.0 | " " | " | " | |
| 1N1591 | 6.8 | 100.0 | 0.9 | " " | " | " | |
| 1N1592 | 8.2 | 80.0 | 1.5 | " " | " | " | |
| 1N1593 | 10.0 | 70.0 | 2.5 | " " | " | " | |
| 1N1594 | 12.0 | 50.0 | 3.0 | " " | " | " | |
| 1N1595 | 15.0 | 40.0 | 5.5 | " " | " | " | |
| 1N1596 | 18.0 | 35.0 | 9.0 | " " | " | " | |
| 1N1597 | 22.0 | 30.0 | 14.0 | " " | " | " | |
| 1N1598 | 27.0 | 25.0 | 24.0 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(2) Temperature compensated zener diode
(4) Temperature range —55°C to +100°C

(9) Supplied by Microsemi in DO-13 Case

(27) Supplied by Microsemi in DO-7 package.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-----------------------------|-------------------------------------|--------|---|--|-----------------|----------------------|--|
| | Volts | @ mA | | | | | |
| 1N1599 | 3.9 | 500.0 | 1.5 | No Suffix = 10% Suffix A = 5% " " | 10 watt | DO-4 | |
| 1N1600 | 4.7 | 400.0 | 0.9 | | " | " | |
| 1N1601 | 5.6 | 350.0 | 0.6 | | " | " | |
| 1N1602 | 6.8 | 300.0 | 0.4 | " " | " | " | |
| 1N1603 | 8.2 | 250.0 | 0.6 | | " | " | |
| 1N1604 | 10.0 | 200.0 | 1.0 | | " | " | |
| 1N1605 | 12.0 | 170.0 | 2.0 | " " | " | " | |
| 1N1606 | 15.0 | 140.0 | 1.9 | | " | " | |
| 1N1607 | 18.0 | 110.0 | 4.0 | | " | " | |
| 1N1608 | 22.0 | 90.0 | 6.0 | " " | " | " | |
| 1N1609 | 27.0 | 70.0 | 10.0 | | " | " | |
| 1N1735⁽²⁾ | 6.2 ± 5% | 7.5 | 20.0 | No Suffix, T.C. = .01% / °C(4) Suffix A, T.C. = .005% / °C(4) " " " " | 200mw | Case 1 | 1N821⁽²⁷⁾ |
| 1N1736⁽²⁾ | 12.4 ± 5% | " | 40.0 | | 400mw | Case 2 | |
| 1N1737⁽²⁾ | 18.6 ± 5% | " | 60.0 | | 600mw | Case 3 | |
| 1N1738⁽²⁾ | 24.8 ± 5% | " | 80.0 | | 800mw | Case 3 | |
| 1N1739⁽²⁾ | 31.0 ± 5% | " | 100.0 | " " | 1000mw | Case 4 | |
| 1N1740⁽²⁾ | 37.2 ± 5% | " | 120.0 | | 1200mw | " | |
| 1N1741⁽²⁾ | 43.4 ± 5% | " | 140.0 | | 1400mw | " | |
| 1N1742⁽²⁾ | 49.6 ± 5% | " | 160.0 | | 1600mw | " | |
| 1N1743 | 10.0 | 200.0 | 3.0 | 5% | 10 watt | — | 1N2974 |
| 1N1744 | 10.0 | 20.0 | 6.0 | 5% | 1 watt | — | 1N3020 |
| 1N1765 | 5.6 | 100.0 | 1.2 | No Suffix = 10% Suffix A = 5% " " | 1 watt | DO-12 ⁽⁹⁾ | 1N3827 |
| 1N1766 | 6.2 | " | 1.5 | | " | " | 1N3828 |
| 1N1767 | 6.8 | " | 1.7 | | " | " | 1N3016 |
| 1N1768 | 7.5 | " | 2.1 | " " | " | " | 1N3017 |
| 1N1769 | 8.2 | " | 2.4 | | " | " | 1N3018 |
| 1N1770 | 9.1 | 50.0 | 3.0 | | " | " | 1N3019 |
| 1N1771 | 10.0 | " | 3.5 | " " | " | " | 1N3020 |
| 1N1772 | 11.0 | " | 4.2 | | " | " | 1N3021 |
| 1N1773 | 12.0 | " | 5.0 | | " | " | 1N3022 |
| 1N1774 | 13.0 | " | 5.8 | " " | " | " | 1N3023 |
| 1N1775 | 15.0 | " | 7.6 | | " | " | 1N3024 |
| 1N1776 | 16.0 | " | 8.6 | | " | " | 1N3025 |
| 1N1777 | 18.0 | " | 11.0 | " " | " | " | 1N3026 |
| 1N1778 | 20.0 | 15.0 | 13.0 | | " | " | 1N3027 |
| 1N1779 | 22.0 | " | 16.0 | | " | " | 1N3028 |
| 1N1780 | 24.0 | " | 18.0 | " " | " | " | 1N3029 |
| 1N1781 | 27.0 | " | 23.0 | | " | " | 1N3030 |
| 1N1782 | 30.0 | " | 28.0 | | " | " | 1N3031 |
| 1N1783 | 33.0 | " | 33.0 | " " | " | " | 1N3032 |
| 1N1784 | 36.0 | " | 39.0 | | " | " | 1N3033 |
| 1N1785 | 39.0 | " | 45.0 | | " | " | 1N3034 |
| 1N1786 | 43.0 | " | 54.0 | " " | " | " | 1N3035 |
| 1N1787 | 47.0 | " | 64.0 | | " | " | 1N3036 |
| 1N1788 | 51.0 | " | 74.0 | | " | " | 1N3037 |
| 1N1789 | 56.0 | " | 88.0 | " " | " | " | 1N3038 |
| 1N1790 | 62.0 | 5.0 | 105.0 | | " | " | 1N3039 |
| 1N1791 | 68.0 | " | 125.0 | | " | " | 1N3040 |
| 1N1792 | 75.0 | " | 150.0 | " " | " | " | 1N3041 |
| 1N1793 | 82.0 | " | 175.0 | | " | " | 1N3042 |
| 1N1794 | 91.0 | " | 220.0 | | " | " | 1N3043 |
| 1N1795 | 100.0 | " | 260.0 | " " | " | " | 1N3044 |
| 1N1796 | 110.0 | " | 320.0 | | " | " | 1N3045 |
| 1N1797 | 120.0 | " | 390.0 | | " | " | 1N3046 |
| 1N1798 | 130.0 | " | 450.0 | " " | " | " | 1N3047 |
| 1N1799 | 150.0 | " | 600.0 | | " | " | 1N3048 |
| 1N1800 | 160.0 | " | 700.0 | | " | " | 1N3049 |
| 1N1801 | 180.0 | " | 900.0 | " " | " | " | 1N3050 |
| 1N1802 | 200.0 | " | 1100.0 | | " | " | 1N3051 |
| 1N1803 | 5.6 | 1000.0 | 1.0 | No Suffix = 10% Suffix A = 5% Suffix R = Rev. Polarity | 10 watt | DO-4 | |
| 1N1804 | 6.2 | " | " | | " | " | |
| 1N1805 | 6.8 | " | " | | " | " | |
| 1N1806 | 7.5 | " | " | " " | " | " | |
| 1N1807 | 8.2 | " | " | | " | " | |
| 1N1808 | 9.1 | 500.0 | " | | " | " | |
| 1N1809 | 110.0 | 50.0 | 47.0 | " " | " | " | |
| 1N1810 | 120.0 | " | 56.0 | | " | " | |
| 1N1811 | 130.0 | " | 65.0 | | " | " | |
| 1N1812 | 150.0 | " | 82.0 | " " | " | " | |
| 1N1813 | 160.0 | " | 93.0 | | " | " | |
| 1N1814 | 180.0 | " | 115.0 | | " | " | |
| 1N1815 | 200.0 | " | 140.0 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

⁽⁹⁾ Supplied by Microsemi in DO-13 case.

⁽²⁷⁾ Supplied by Microsemi in DO-7 package.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------------------------|-------------------------------------|-------|---|---|-----------------|-----------------------|--|
| | Volts | @ mA | | | | | |
| 1N1816 | 13.0 | 500.0 | 2.0 | No Suffix = 10% Suffix A = 5% Suffix C = Double Anode (10%) | 10 watt | DO-4 | |
| 1N1817 | 15.0 | " | " | | " | " | |
| 1N1818 | 16.0 | " | 3.0 | | " | " | |
| 1N1819 | 18.0 | " | " | " " | " | " | |
| 1N1820 | 20.0 | 250.0 | " | " " | " | " | |
| 1N1821 | 22.0 | " | " | " " | " | " | |
| 1N1822 | 24.0 | " | " | " " | " | " | |
| 1N1823 | 27.0 | " | " | " " | " | " | |
| 1N1824 | 30.0 | " | 4.0 | " " | " | " | |
| 1N1825 | 33.0 | 150.0 | " | " " | " | " | |
| 1N1826 | 36.0 | " | 5.0 | " " | " | " | |
| 1N1827 | 39.0 | " | " | " " | " | " | |
| 1N1828 | 43.0 | " | 6.0 | " " | " | " | |
| 1N1829 | 47.0 | " | 7.0 | " " | " | " | |
| 1N1830 | 51.0 | " | 8.0 | " " | " | " | |
| 1N1831 | 56.0 | " | 9.0 | " " | " | " | |
| 1N1832 | 62.0 | 50.0 | 12.0 | " " | " | " | |
| 1N1833 | 68.0 | " | 14.0 | " " | " | " | |
| 1N1834 | 75.0 | " | 20.0 | " " | " | " | |
| 1N1835 | 82.0 | 50.0 | 22.0 | No Suffix = 10%, Suffix A = 5% Suffix C = Double Anode (10%) | 10 watt | DO-4 | |
| 1N1836 | 91.0 | " | 35.0 | | " | " | |
| 1N1875 | 8.2 | 25.0 | 5.0 | No Suffix = 10% Suffix A = 5% | 1 watt | Case R ⁽⁹⁾ | 1N3018 |
| 1N1876 | 10.0 | " | 6.0 | | " | " | 1N3020 |
| 1N1877 | 12.0 | " | 7.0 | | " | " | 1N3022 |
| 1N1878 | 15.0 | " | 8.0 | " " | " | " | 1N3024 |
| 1N1879 | 18.0 | " | 9.0 | " " | " | " | 1N3026 |
| 1N1880 | 22.0 | 8.0 | 24.0 | " " | " | " | 1N3028 |
| 1N1881 | 27.0 | " | 27.0 | " " | " | " | 1N3030 |
| 1N1882 | 33.0 | " | 30.0 | " " | " | " | 1N3032 |
| 1N1883 | 39.0 | " | 35.0 | " " | " | " | 1N3034 |
| 1N1884 | 47.0 | " | 50.0 | " " | " | " | 1N3036 |
| 1N1885 | 56.0 | " | 75.0 | " " | " | " | 1N3038 |
| 1N1886 | 68.0 | 3.0 | 250.0 | " " | " | " | 1N3040 |
| 1N1887 | 82.0 | " | 325.0 | " " | " | " | 1N3042 |
| 1N1888 | 100.0 | " | 400.0 | " " | " | " | 1N3044 |
| 1N1889-1N1890 is an obsolete series | | | | | | | |
| 1N1891 | 8.2 | 25.0 | 5.0 | No Suffix = 10% Suffix A = 5% | 10 watt | Case K | 1N2972 |
| 1N1892 | 10.0 | " | 6.0 | | " | " | 1N2974 |
| 1N1893 | 12.0 | " | 7.0 | | " | " | 1N2976 |
| 1N1894 | 15.0 | " | 8.0 | " " | " | " | 1N2979 |
| 1N1895 | 18.0 | " | 9.0 | " " | " | " | 1N2982 |
| 1N1896 | 22.0 | 8.0 | 24.0 | " " | " | " | 1N2985 |
| 1N1897 | 27.0 | " | 27.0 | " " | " | " | 1N2988 |
| 1N1898 | 33.0 | " | 30.0 | " " | " | " | 1N2990 |
| 1N1899 | 39.0 | " | 35.0 | " " | " | " | 1N2992 |
| 1N1900 | 47.0 | " | 50.0 | " " | " | " | 1N2995 |
| 1N1901 | 56.0 | " | 75.0 | " " | " | " | 1N2999 |
| 1N1902 | 68.0 | 3.0 | 250.0 | " " | " | " | 1N3001 |
| 1N1903 | 82.0 | " | 325.0 | " " | " | " | 1N3003 |
| 1N1904 | 100.0 | " | 400.0 | " " | " | " | 1N3005 |
| 1N1927 | 3.9 | 5.0 | 11.0 ⁽¹⁰⁾ | No Suffix = 10% Suffix A = 5% | 250mw | Case L | 1N748 |
| 1N1928 | 4.7 | " | 10.0 ⁽¹⁰⁾ | | " | " | 1N750 |
| 1N1929 | 5.6 | " | 8.0 ⁽¹⁰⁾ | | " | " | 1N752 |
| 1N1930 | 6.8 | " | 7.0 ⁽¹⁰⁾ | " " | " | " | 1N754 |
| 1N1931 | 8.2 | " | 15.0 ⁽¹⁰⁾ | " " | " | " | 1N756 |
| 1N1932 | 10.0 | " | 22.0 ⁽¹⁰⁾ | " " | " | " | 1N758 |
| 1N1933 | 12.0 | 1.0 | 30.0 ⁽¹⁰⁾ | " " | " | " | 1N759 |
| 1N1934 | 15.0 | " | 50.0 ⁽¹⁰⁾ | " " | " | " | 1N965 |
| 1N1935 | 18.0 | " | 70.0 ⁽¹⁰⁾ | " " | " | " | 1N967 |
| 1N1936 | 22.0 | " | 100.0 ⁽¹⁰⁾ | " " | " | " | 1N969 |
| 1N1937 | 27.0 | " | 200.0 ⁽¹⁰⁾ | " " | " | " | 1N971 |
| 1N1938 | 33.0 | 0.2 | 300.0 ⁽¹⁰⁾ | " " | " | " | 1N973 |
| 1N1939 | 39.0 | " | 400.0 ⁽¹⁰⁾ | " " | " | " | 1N975 |
| 1N1940 | 47.0 | " | 500.0 ⁽¹⁰⁾ | " " | " | " | 1N977 |
| 1N1941 | 56.0 | " | 700.0 ⁽¹⁰⁾ | " " | " | " | 1N979 |
| 1N1942 | 68.0 | " | 900.0 ⁽¹⁰⁾ | " " | " | " | 1N981 |
| 1N1943 | 82.0 | " | 1200.0 ⁽¹⁰⁾ | " " | " | " | 1N983 |
| 1N1944 | 100.0 | " | 1700.0 ⁽¹⁰⁾ | " " | " | " | 1N985 |
| 1N1945 | 120.0 | " | 2800.0 ⁽¹⁰⁾ | " " | " | " | 1N987 |
| 1N1946 | 150.0 | 0.1 | — | " " | " | " | 1N989 |
| 1N1947 | 180.0 | " | — | " " | " | " | 1N991 |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(8) Microsemi device utilizes glass subassembly potted in epoxy.
(9) Supplied by Microsemi in DO-13 Case.

(10) Typical Zener Impedance. 1N1927-32 and 1N1981-86
I_Z @ 10mA. 1N1933-36 and 1N1987-90 @ 5mA. 1N1937-39 and 1N1991-3 @ 3mA. 1N1940-41 and 1N1994-5 @ 2mA. 1N1942-45 and 1N1996-99 @ 1mA.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|--|---------------------------|--------|--------------------------------------|-------------------------------|--------------|----------------|----------------------------------|
| 1N1948 | 220.0 | 0.2 | — | No Suffix = 10% | 250 mw | Case L | |
| 1N1949 | 270.0 | 0.1 | — | Suffix A = 5% | " | " | |
| 1N1950 | 330.0 | " | — | " | " | " | |
| 1N1951 | 395.0 | " | — | " | " | " | |
| 1N1952 | 470.0 | " | — | " | " | " | |
| 1N1953 | 565.0 | " | — | " | " | " | |
| 1N1954 thru 1N1980 is an obsolete 200mw series | | | | | | | |
| 1N1981 | 3.9 | 5.0 | 11.0(10) | No Suffix = 10% | 150mw | Case A(8) | |
| 1N1982 | 4.7 | " | 10.0(10) | Suffix A = 5% | " | " | |
| 1N1983 | 5.6 | " | 8.0(10) | " | " | " | |
| 1N1984 | 6.8 | " | 7.0(10) | " | " | " | |
| 1N1985 | 8.2 | " | 15.0(10) | " | " | " | |
| 1N1986 | 10.0 | " | 22.0(10) | " | " | " | |
| 1N1987 | 12.0 | 1.0 | 30.0(10) | " | " | " | |
| 1N1988 | 15.0 | " | 50.0(10) | " | " | " | |
| 1N1989 | 18.0 | " | 70.0(10) | " | " | " | |
| 1N1990 | 22.0 | " | 100.0(10) | " | " | " | |
| 1N1991 | 27.0 | 1.0 | 200.0(10) | No Suffix = 10% | 150mw | Case A(8) | |
| 1N1992 | 33.0 | 0.2 | 300.0(10) | Suffix A = 5% | " | " | |
| 1N1993 | 39.0 | " | 400.0(10) | " | " | " | |
| 1N1994 | 47.0 | " | 500.0(10) | " | " | " | |
| 1N1995 | 56.0 | " | 700.0(10) | " | " | " | |
| 1N1996 | 68.0 | " | 900.0(10) | " | " | " | |
| 1N1997 | 82.0 | " | 1200.0(10) | " | " | " | |
| 1N1998 | 100.0 | " | 1700.0(10) | " | " | " | |
| 1N1999 | 120.0 | " | 2800.0(10) | " | " | " | |
| 1N2000 | 145.0 | 0.1 | — | " | " | " | |
| 1N2001 | 180.0 | " | — | " | " | " | |
| 1N2002 | 220.0 | " | — | " | " | " | |
| 1N2003 | 270.0 | " | — | " | " | " | |
| 1N2004 | 330.0 | " | — | " | " | " | |
| 1N2005 | 390.0 | " | — | " | " | " | |
| 1N2006 | 470.0 | " | — | " | " | " | |
| 1N2007 | 560.0 | " | — | " | " | " | |
| 1N2008 | 100.0 | 50.0 | 40.0 | No Suffix = 10% | 10 watt | DO-4 | |
| 1N2009 | 110.0 | " | 47.0 | Suffix A = 5% | " | " | |
| 1N2010 | 120.0 | " | 56.0 | Suffix R = Rev. Polarity | " | " | |
| 1N2011 | 130.0 | " | 65.0 | Suffix C = Double Anode (10%) | " | " | |
| 1N2012 | 150.0 | " | 82.0 | " | " | " | |
| 1N2032 | 4.3 - 5.4 | 10.0 | 55.0 | | 750 mw | DO-12(9) | 1N3825 |
| 1N2033 | 5.2 - 6.4 | " | 20.0 | | " | " | 1N3827 |
| 1N2034 | 6.2 - 8.0 | " | 8.0 | | " | " | 1N3829 |
| 1N2035 | 7.5 - 10.0 | " | 15.0 | | " | " | 1N3019 |
| 1N2036 | 9.0 - 12.0 | 5.0 | 50.0 | | " | " | 1N3021 |
| 1N2037 | 11.0 - 14.5 | " | 70.0 | | " | " | 1N3023 |
| 1N2038 | 13.5 - 18.0 | " | 120.0 | | " | " | 1N3025 |
| 1N2039 | 17.0 - 21.0 | " | 200.0 | | " | " | 1N3027 |
| 1N2040 | 20.0 - 27.0 | " | 300.0 | | " | " | 1N3029 |
| 1N2041 | 4.3 - 5.4 | 1000.0 | 0.5 | | 10 watt | DO-4 | |
| 1N2042 | 5.2 - 6.4 | " | 0.7 | | " | " | |
| 1N2043 | 6.2 - 8.0 | " | 0.8 | | " | " | |
| 1N2044 | 7.5 - 10.0 | " | 0.8 | | " | " | |
| 1N2045 | 9.0 - 12.0 | 500.0 | 1.5 | | " | " | |
| 1N2046 | 11.0 - 14.5 | " | 2.0 | | " | " | |
| 1N2047 | 13.5 - 18.0 | " | 3.0 | | " | " | |
| 1N2048 | 17.0 - 21.0 | " | " | | " | " | |
| 1N2049 | 20.0 - 27.0 | 150.0 | 8.0 | | " | " | |
| 1N2163(2) | 9.4 ± 5% Suffix | 10.0 | 15.0 | T.C. = .005% / °C(11) | 750mw | DO-13 | 1N936(27) |
| 1N2164(2) | " | " | " | " | " | " | 1N936A(27) |
| 1N2165(2) | A = 2.0% | " | " | " | " | " | 1N936B(27) |
| 1N2166(2) | " | " | " | T.C. = .001% / °C(11) | " | " | 1N938(27) |
| 1N2167(2) | " | " | " | " | " | " | 1N938A(27) |
| 1N2168(2) | " | " | " | " | " | " | 1N938B(27) |
| 1N2169(2) | " | " | " | T.C. = .0005% / °C(11) | " | " | 1N939(27) |
| 1N2170(2) | " | " | " | " | " | " | 1N939A(27) |
| 1N2171(2) | " | " | " | " | " | " | 1N939B(27) |
| 1N2214(2) | 5.4 - 5.6 | 35.0 | 5.6 | T.C. = .03% / °C | 1 watt | DO-1 (9) | 1N3827 |
| 1N2387 is an obsolete 1 watt device | | | | | | | |
| 1N2498 | 10.0 | 500.0 | 2.0 | No Suffix = 10% | 10 watt | DO-4 | |
| 1N2499 | 11.0 | " | " | Suffix A = 5% | " | " | |
| 1N2500 | 12.0 | " | " | Suffix C = Double Anode (10%) | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(9) Supplied by Microsemi in DO-13.
 (27) Supplied by Microsemi in DO-7 package.
 (33) Supplied by Microsemi in Case Size CC.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|--|---------------------------|--------|--------------------------------------|---------------------------------------|--------------|----------------|----------------------------------|
| Volts | @ mA | | | | | | |
| 1N2620 ⁽²⁾ | 9.3 ± 5% | 10.0 | 15.0 | Temp. .01% / °C ⁽⁷⁾ | 750 mw | DO-13 | 1N935 ⁽²⁷⁾ |
| 1N2621 ⁽²⁾ | 9.3 ± 5% | " | " | Coeff. .005% / °C ⁽⁷⁾ | " | " | 1N936 ⁽²⁷⁾ |
| 1N2622 ⁽²⁾ | 9.3 ± 5% | " | " | .002% / °C ⁽⁷⁾ | " | " | 1N937 ⁽²⁷⁾ |
| 1N2623 ⁽²⁾ | 9.3 ± 5% | " | " | .001% / °C ⁽⁷⁾ | " | " | 1N938 ⁽²⁷⁾ |
| 1N2624 ⁽²⁾ | 9.3 ± 5% | " | " | .0005% / °C ⁽⁷⁾ | " | " | 1N939 ⁽²⁷⁾ |
| 1N2625-1N2626 is an obsolete series | | | | | | | |
| 1N2765 ⁽²⁾ | 6.8 ± 5% | 7.5 | 20.0 | T.C. = .005% / °C ⁽⁴⁾ | — | Case S | 1N825 ⁽²⁷⁾ |
| 1N2766 ⁽²⁾ | 13.6 ± 5% | " | 40.0 | Suffix A = .0025% / °C ⁽⁴⁾ | — | " | 1N4058 ⁽³³⁾ |
| 1N2767 ⁽²⁾ | 20.4 ± 5% | " | 60.0 | " " | — | Case T | 1N4061 ⁽³³⁾ |
| 1N2768 ⁽²⁾ | 27.2 ± 5% | " | 80.0 | " " | — | " | 1N4063 ⁽³³⁾ |
| 1N2769 ⁽²⁾ | 34.0 ± 5% | " | 100.0 | " " | — | Case L | 1N4065 ⁽³³⁾ |
| 1N2770 ⁽²⁾ | 40.8 ± 5% | " | 120.0 | " " | — | " | 1N4067 ⁽³³⁾ |
| 1N2783 is an obsolete device | | | | | | | |
| 1N2790 | 8.5 ± 5% | 10.0 | 15.0 | T.C. = .002% / °C | 1 watt | — | 1N3156 |
| 1N2804 | 6.8 | 1850.0 | 0.2 | No Suffix = 20% | 50 watt | TO-3 | |
| 1N2805 | 7.5 | 1700.0 | 0.3 | Suffix A = 10%, Suffix B = 5% | " | " | |
| 1N2806 | 8.2 | 1500.0 | 0.4 | Suffix R = Rev. Polarity | " | " | |
| 1N2807 | 9.1 | 1370.0 | 0.5 | No Suffix = 20% | 50 watt | TO-3 | |
| 1N2808 | 10.0 | 1200.0 | 0.6 | Suffix A = 10%, Suffix B = 5% | " | " | |
| 1N2809 | 11.0 | 1100.0 | 0.8 | Suffix R = Rev. Polarity | " | " | |
| 1N2810 | 12.0 | 1000.0 | 1.0 | " " | " | " | |
| 1N2811 | 13.0 | 960.0 | 1.1 | " " | " | " | |
| 1N2812 | 14.0 | 890.0 | 1.2 | " " | " | " | |
| 1N2813 | 15.0 | 830.0 | 1.4 | " " | " | " | |
| 1N2814 | 16.0 | 780.0 | 1.6 | " " | " | " | |
| 1N2815 | 17.0 | 740.0 | 1.8 | " " | " | " | |
| 1N2816 | 18.0 | 700.0 | 2.0 | " " | " | " | |
| 1N2817 | 19.0 | 660.0 | 2.2 | " " | " | " | |
| 1N2818 | 20.0 | 630.0 | 2.4 | " " | " | " | |
| 1N2819 | 22.0 | 570.0 | 2.5 | " " | " | " | |
| 1N2820 | 24.0 | 520.0 | 2.6 | " " | " | " | |
| 1N2821 | 25.0 | 500.0 | 2.7 | " " | " | " | |
| 1N2822 | 27.0 | 460.0 | 2.8 | " " | " | " | |
| 1N2823 | 30.0 | 420.0 | 3.0 | " " | " | " | |
| 1N2824 | 33.0 | 380.0 | 3.2 | " " | " | " | |
| 1N2825 | 36.0 | 350.0 | 3.5 | " " | " | " | |
| 1N2826 | 39.0 | 320.0 | 4.0 | " " | " | " | |
| 1N2827 | 43.0 | 290.0 | 4.5 | " " | " | " | |
| 1N2828 | 45.0 | 280.0 | " | " " | " | " | |
| 1N2829 | 47.0 | 270.0 | 5.0 | " " | " | " | |
| 1N2830 | 50.0 | 250.0 | " | " " | " | " | |
| 1N2831 | 51.0 | 245.0 | 5.2 | " " | " | " | |
| 1N2832 | 56.0 | 220.0 | 6.0 | " " | " | " | |
| 1N2833 | 62.0 | 200.0 | 7.0 | " " | " | " | |
| 1N2834 | 68.0 | 180.0 | 8.0 | " " | " | " | |
| 1N2835 | 75.0 | 170.0 | 9.0 | " " | " | " | |
| 1N2836 | 82.0 | 150.0 | 11.0 | " " | " | " | |
| 1N2837 | 91.0 | 140.0 | 15.0 | " " | " | " | |
| 1N2838 | 100.0 | 120.0 | 20.0 | " " | " | " | |
| 1N2839 | 105.0 | " | 25.0 | " " | " | " | |
| 1N2840 | 110.0 | 110.0 | 30.0 | " " | " | " | |
| 1N2841 | 120.0 | 100.0 | 40.0 | " " | " | " | |
| 1N2842 | 130.0 | 95.0 | 50.0 | " " | " | " | |
| 1N2843 | 150.0 | 85.0 | 75.0 | " " | " | " | |
| 1N2844 | 160.0 | 80.0 | 80.0 | " " | " | " | |
| 1N2845 | 180.0 | 68.0 | 90.0 | " " | " | " | |
| 1N2846 | 200.0 | 65.0 | 100.0 | " " | " | " | |
| 1N2865-1N2868 is an obsolete series | | | | | | | |
| 1N2937 | 50.0 | 25.0 | 75.0 | 15% | 10 watt | DO-4 | |
| 1N2942 thru 1N2968 is an obsolete 50 watt series | | | | | | | |
| 1N2970 | 6.8 | 370.0 | 1.2 | No Suffix = 20% | 10 watt | DO-4 | |
| 1N2971 | 7.5 | 335.0 | 1.3 | Suffix A = 10%, Suffix B = 5% | " | " | |
| 1N2972 | 8.2 | 305.0 | 1.5 | Suffix R = Rev. Polarity | " | " | |
| 1N2973 | 9.1 | 275.0 | 2.0 | " " | " | " | |
| 1N2974 | 10.0 | 250.0 | 3.0 | " " | " | " | |
| 1N2975 | 11.0 | 230.0 | " | " " | " | " | |
| 1N2976 | 12.0 | 210.0 | " | " " | " | " | |
| 1N2977 | 13.0 | 190.0 | " | " " | " | " | |
| 1N2978 | 14.0 | 180.0 | " | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(2) Temperature compensated zener diode

(4) Temperature range -55°C to +100°C

(7) No suffix denotes temp. range 0°C to +75°C

Suffix A denotes temp. range -55°C to +100°C

Suffix B denotes temp. range -55°C to +150°C

(9) Supplied by Microsemi in DO-13 Case

(10) See footnote (10) on page 9

(11) Temperature range 0°C to +70°C 1N2163, 66.69

-55°C to +125°C 1N2164, 67.70

-55°C to +185°C 1N2165, 68.71

(27) Supplied by Microsemi in DO-7 package.

(33) Supplied by Microsemi in Case Size CC.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------|-------------------------------------|-------|---|-------------------------------|-----------------|-------------------|--|
| | Volts | @ mA | | | | | |
| 1N2979 | 15.0 | 170.0 | 3.0 | No Suffix = 20% | 10 watt | DO-4 | |
| 1N2980 | 16.0 | 155.0 | 4.0 | Suffix A = 10%, Suffix B = 5% | " | " | |
| 1N2981 | 17.0 | 145.0 | " | Suffix R = Rev. Polarity | " | " | |
| 1N2982 | 18.0 | 140.0 | " | " " | " | " | |
| 1N2983 | 19.0 | 130.0 | " | " " | " | " | |
| 1N2984 | 20.0 | 125.0 | " | " " | " | " | |
| 1N2985 | 22.0 | 115.0 | 5.0 | " " | " | " | |
| 1N2986 | 24.0 | 105.0 | " | " " | " | " | |
| 1N2987 | 25.0 | 100.0 | 6.0 | " " | " | " | |
| 1N2988 | 27.0 | 95.0 | 7.0 | " " | " | " | |
| 1N2989 | 30.0 | 85.0 | 8.0 | " " | " | " | |
| 1N2990 | 33.0 | 75.0 | 9.0 | " " | " | " | |
| 1N2991 | 36.0 | 70.0 | 10.0 | " " | " | " | |
| 1N2992 | 39.0 | 65.0 | 11.0 | " " | " | " | |
| 1N2993 | 43.0 | 60.0 | 12.0 | " " | " | " | |
| 1N2994 | 45.0 | 55.0 | 13.0 | No Suffix = 20% | 10 watt | DO-4 | |
| 1N2995 | 47.0 | " | 14.0 | Suffix A = 10%, Suffix B = 5% | " | " | |
| 1N2996 | 50.0 | 50.0 | 15.0 | Suffix R = Rev. Polarity | " | " | |
| 1N2997 | 51.0 | " | " | " " | " | " | |
| 1N2998 | 52.0 | " | " | " " | " | " | |
| 1N2999 | 56.0 | 45.0 | 16.0 | " " | " | " | |
| 1N3000 | 62.0 | 40.0 | 17.0 | " " | " | " | |
| 1N3001 | 68.0 | 37.0 | 18.0 | " " | " | " | |
| 1N3002 | 75.0 | 33.0 | 22.0 | " " | " | " | |
| 1N3003 | 82.0 | 30.0 | 25.0 | " " | " | " | |
| 1N3004 | 91.0 | 28.0 | 35.0 | " " | " | " | |
| 1N3005 | 100.0 | 25.0 | 40.0 | " " | " | " | |
| 1N3006 | 105.0 | " | 45.0 | " " | " | " | |
| 1N3007 | 110.0 | 23.0 | 55.0 | " " | " | " | |
| 1N3008 | 120.0 | 20.0 | 75.0 | " " | " | " | |
| 1N3009 | 130.0 | 19.0 | 100.0 | " " | " | " | |
| 1N3010 | 140.0 | 18.0 | 125.0 | " " | " | " | |
| 1N3011 | 150.0 | 17.0 | 175.0 | " " | " | " | |
| 1N3012 | 160.0 | 16.0 | 200.0 | " " | " | " | |
| 1N3013 | 175.0 | 14.0 | 250.0 | " " | " | " | |
| 1N3014 | 180.0 | " | 260.0 | " " | " | " | |
| 1N3015 | 200.0 | 12.0 | 300.0 | " " | " | " | |
| 1N3016 | 6.8 | 37.0 | 3.5 | No Suffix = 20% | 1 watt | DO-13 | |
| 1N3017 | 7.5 | 34.0 | 4.0 | Suffix A = 10% | " | " | |
| 1N3018 | 8.2 | 31.0 | 4.5 | Suffix B = 5% | " | " | |
| 1N3019 | 9.1 | 28.0 | 5.0 | " " | " | " | |
| 1N3020 | 10.0 | 25.0 | 7.0 | " " | " | " | |
| 1N3021 | 11.0 | 23.0 | 8.0 | " " | " | " | |
| 1N3022 | 12.0 | 21.0 | 9.0 | " " | " | " | |
| 1N3023 | 13.0 | 19.0 | 10.0 | " " | " | " | |
| 1N3024 | 15.0 | 17.0 | 14.0 | " " | " | " | |
| 1N3025 | 16.0 | 15.5 | 16.0 | " " | " | " | |
| 1N3026 | 18.0 | 14.0 | 20.0 | " " | " | " | |
| 1N3027 | 20.0 | 12.5 | 22.0 | " " | " | " | |
| 1N3028 | 22.0 | 11.5 | 23.0 | " " | " | " | |
| 1N3029 | 24.0 | 10.5 | 25.0 | " " | " | " | |
| 1N3030 | 27.0 | 9.5 | 35.0 | " " | " | " | |
| 1N3031 | 30.0 | 8.5 | 40.0 | " " | " | " | |
| 1N3032 | 33.0 | 7.5 | 45.0 | " " | " | " | |
| 1N3033 | 36.0 | 7.0 | 50.0 | " " | " | " | |
| 1N3034 | 39.0 | 6.5 | 60.0 | " " | " | " | |
| 1N3035 | 43.0 | 6.0 | 70.0 | " " | " | " | |
| 1N3036 | 47.0 | 5.5 | 80.0 | " " | " | " | |
| 1N3037 | 51.0 | 5.0 | 95.0 | " " | " | " | |
| 1N3038 | 56.0 | 4.5 | 110.0 | " " | " | " | |
| 1N3039 | 62.0 | 4.0 | 125.0 | " " | " | " | |
| 1N3040 | 68.0 | 3.7 | 150.0 | " " | " | " | |
| 1N3041 | 75.0 | 3.3 | 175.0 | " " | " | " | |
| 1N3042 | 82.0 | 3.0 | 200.0 | " " | " | " | |
| 1N3043 | 91.0 | 2.8 | 250.0 | " " | " | " | |
| 1N3044 | 100.0 | 2.5 | 350.0 | " " | " | " | |
| 1N3045 | 110.0 | 2.3 | 450.0 | " " | " | " | |
| 1N3046 | 120.0 | 2.0 | 550.0 | " " | " | " | |
| 1N3047 | 130.0 | 1.9 | 700.0 | " " | " | " | |
| 1N3048 | 150.0 | 1.7 | 1000.0 | " " | " | " | |

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|---|---------------------------|------------|--------------------------------------|-------------------------------|--------------|----------------|----------------------------------|
| 1N3049 | 160.0 | 1.6 | 1100.0 | No Suffix = 20% | 1 watt | DO-13 | |
| 1N3050 | 180.0 | 1.4 | 1200.0 | Suffix A = 10% | " | " | |
| 1N3051 | 200.0 | 1.2 | 1500.0 | Suffix B = 5% | " | " | |
| 1N3098-1N3101, 1N3102-1N3105, 1N3106-1N3109 are obsolete series | | | | | | | |
| 1N3112 | 7.5 | 30.0 | 2.0 | 5% | 1 watt | DO-3 (9) | 1N3017 |
| 1N3148(2) | 8.5 ± 5% | 10.0 | 15.0 | T.C. = .005% / °C | 400mw | — | 1N3155 |
| 1N3154(2) | 8.4 ± 5% | 10.0 | 15.0 | T.C. = .01% / °C(12) | 400mw | DO-7 | |
| 1N3155(2) | 8.4 ± 5% | " | " | T.C. = .005% / °C(12) | " | " | |
| 1N3156(2) | 8.4 ± 5% | " | " | T.C. = .002% / °C(12) | " | " | |
| 1N3157(2) | 8.4 ± 5% | " | " | T.C. = .001% / °C(12) | " | " | |
| 1N3181(1) | 8.2 | 14.0 | 10.0 | 10% | 600mw | Case Z | N/A |
| 1N3199(2) | 8.0 - 8.8 | 10.0 | 15.0 | T.C. = .005% / °C(6) | 270mw | Case GG(27) | 1N3155 |
| 1N3200(2) | 8.0 - 8.8 | " | " | T.C. = .003% / °C(6) | " | " | 1N3156 |
| 1N3201(2) | 8.0 - 8.8 | " | " | T.C. = .002% / °C(6) | " | " | 1N3156 |
| 1N3202(2) | 8.0 - 8.8 | " | " | T.C. = .001% / °C(6) | " | " | 1N3157 |
| Type No. | PIV | I_o 25°C | VF | IR | T_{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| 1N3206 | 100 | .040 | 1.0 | .025 | (n sec.) 4.0 | H | |
| 1N3207 | 60 | .075 | 1.0 | .05 | 6.0 | H | |
| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N3305 | 6.8 | 1850.0 | 0.2 | No Suffix = 20% | 50 watt | DO-5 | |
| 1N3306 | 7.5 | 1700.0 | 0.3 | Suffix A = 10%, Suffix B = 5% | " | " | |
| 1N3307 | 8.2 | 1500.0 | 0.4 | Suffix R = Rev. Polarity | " | " | |
| 1N3308 | 9.1 | 1370.0 | 0.5 | " " | " | " | |
| 1N3309 | 10.0 | 1200.0 | 0.6 | " " | " | " | |
| 1N3310 | 11.0 | 1100.0 | 0.8 | " " | " | " | |
| 1N3311 | 12.0 | 1000.0 | 1.0 | " " | " | " | |
| 1N3312 | 13.0 | 960.0 | 1.1 | " " | " | " | |
| 1N3313 | 14.0 | 890.0 | 1.2 | " " | " | " | |
| 1N3314 | 15.0 | 830.0 | 1.4 | " " | " | " | |
| 1N3315 | 16.0 | 780.0 | 1.6 | " " | " | " | |
| 1N3316 | 17.0 | 740.0 | 1.8 | " " | " | " | |
| 1N3317 | 18.0 | 700.0 | 2.0 | " " | " | " | |
| 1N3318 | 19.0 | 660.0 | 2.2 | " " | " | " | |
| 1N3319 | 20.0 | 630.0 | 2.4 | " " | " | " | |
| 1N3320 | 22.0 | 570.0 | 2.5 | " " | " | " | |
| 1N3321 | 24.0 | 520.0 | 2.6 | " " | " | " | |
| 1N3322 | 25.0 | 500.0 | 2.7 | " " | " | " | |
| 1N3323 | 27.0 | 460.0 | 2.8 | " " | " | " | |
| 1N3324 | 30.0 | 420.0 | 3.0 | " " | " | " | |
| 1N3325 | 33.0 | 380.0 | 3.2 | " " | " | " | |
| 1N3326 | 36.0 | 350.0 | 3.5 | " " | " | " | |
| 1N3327 | 39.0 | 320.0 | 4.0 | " " | " | " | |
| 1N3328 | 43.0 | 290.0 | 4.5 | " " | " | " | |
| 1N3329 | 45.0 | 280.0 | 4.5 | " " | " | " | |
| 1N3330 | 47.0 | 270.0 | 5.0 | " " | " | " | |
| 1N3331 | 50.0 | 250.0 | 5.0 | " " | " | " | |
| 1N3332 | 51.0 | 245.0 | 5.2 | " " | " | " | |
| 1N3333 | 52.0 | 240.0 | 5.5 | " " | " | " | |
| 1N3334 | 56.0 | 220.0 | 6.0 | " " | " | " | |
| 1N3335 | 62.0 | 200.0 | 7.0 | " " | " | " | |
| 1N3336 | 68.0 | 180.0 | 8.0 | " " | " | " | |
| 1N3337 | 75.0 | 170.0 | 9.0 | " " | " | " | |
| 1N3338 | 82.0 | 150.0 | 11.0 | " " | " | " | |
| 1N3339 | 91.0 | 140.0 | 15.0 | " " | " | " | |
| 1N3340 | 100.0 | 120.0 | 20.0 | " " | " | " | |
| 1N3341 | 105.0 | 120.0 | 25.0 | " " | " | " | |
| 1N3342 | 110.0 | 110.0 | 30.0 | " " | " | " | |
| 1N3343 | 120.0 | 100.0 | 40.0 | " " | " | " | |
| 1N3344 | 130.0 | 95.0 | 50.0 | " " | " | " | |
| 1N3345 | 140.0 | 90.0 | 60.0 | " " | " | " | |
| 1N3346 | 150.0 | 85.0 | 75.0 | " " | " | " | |
| 1N3347 | 160.0 | 80.0 | 80.0 | " " | " | " | |
| 1N3348 | 175.0 | 70.0 | 85.0 | " " | " | " | |
| 1N3349 | 180.0 | 68.0 | 90.0 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

- (1) Double anode type
 (2) Temperature compensated zener diode
 (6) Temperature range -50°C to +100°C
 (7) Temperature range 0°C to +75°C

- (9) Supplied by Microsemi in DO-13 Case
 (12) No suffix denotes temp. range -55°C to +100°C. Suffix A denotes -55°C to +150°C
 (13) Temperature range +25°C to +100°C

- (18) Certified voltage time stability
 (19) Low-reverse leakage diode
 (27) Supplied by Microsemi in DO-7 Case

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|---|------------------------------|--------------|--|------------------------------------|-----------------|------------------------|--|
| | Volts | @ mA | | | | | |
| 1N3350 | 200.0 | 65.0 | 100.0 | " " | " | " | |
| 1N3392 thru 1N3432 is an obsolete 500mw series | | | | | | | |
| 1N3433 thru 1N3463 is an obsolete 2 watt series | | | | | | | |
| 1N3477 | 2.2 | 5.0 | 60 @ 10mA | No Suffix = 10% Suffix A = 5% | 250mw | DO-7 | |
| 1N3496 ⁽²⁾ | 5.9 - 6.5 | 7.5 | 15.0 | T.C. = .005% / °C ⁽⁷⁾ | " | DO-7 | |
| 1N3497 ⁽²⁾ | 5.9 - 6.5 | " | " | T.C. = .002% / °C ⁽⁷⁾ | " | " | |
| 1N3498 ⁽²⁾ | 5.9 - 6.5 | " | " | T.C. = .001% / °C ⁽⁷⁾ | " | " | |
| 1N3499 ⁽²⁾ | 5.9 - 6.5 | " | " | T.C. = .0005% / °C ⁽⁷⁾ | " | " | |
| 1N3500 ⁽²⁾ | 5.9 - 6.5 | " | " | T.C. = .01% / °C ⁽⁷⁾ | " | " | |
| 1N3501 ^(2,18) | 6.2 - 6.5 | " | 12.0 | T.C. = .0013% / °C ⁽¹³⁾ | 250mw | DO-7 | |
| 1N3502 ^(2,18) | 6.2 - 6.5 | " | " | T.C. = .0006% / °C ⁽¹³⁾ | " | " | |
| 1N3503 ^(2,18) | 6.2 - 6.5 | " | " | T.C. = .0013% / °C ⁽¹³⁾ | " | " | |
| 1N3504 ^(2,18) | 6.2 - 6.5 | " | " | T.C. = .0013% / °C ⁽¹³⁾ | " | " | |
| 1N3506 ⁽¹⁹⁾ | 3.3 | 20.0 | 24.0 | 5% | 400mw | DO-7/DO-35 | |
| 1N3507 ⁽¹⁹⁾ | 3.6 | " | 22.0 | " | " | " | |
| 1N3508 ⁽¹⁹⁾ | 3.9 | " | 20.0 | " | " | " | |
| 1N3509 ⁽¹⁹⁾ | 4.3 | " | 18.0 | " | " | " | |
| 1N3510 ⁽¹⁹⁾ | 4.7 | " | 16.0 | " | " | " | |
| 1N3511 ⁽¹⁹⁾ | 5.1 | " | 14.0 | " | " | " | |
| 1N3512 ⁽¹⁹⁾ | 5.6 | " | 8.0 | " | " | " | |
| 1N3513 ⁽¹⁹⁾ | 6.2 | " | 3.0 | " | " | " | |
| 1N3514 ⁽¹⁹⁾ | 6.8 | " | " | " | " | " | |
| 1N3515 ⁽¹⁹⁾ | 7.5 | 10.0 | 4.0 | " | " | " | |
| 1N3516 ⁽¹⁹⁾ | 8.2 | " | 5.0 | " | " | " | |
| 1N3517 ⁽¹⁹⁾ | 9.1 | " | 6.0 | " | " | " | |
| 1N3518 ⁽¹⁹⁾ | 10.0 | 10.0 | 7.0 | 5% | 400mw | " | |
| 1N3519 ⁽¹⁹⁾ | 11.0 | " | 8.0 | " | " | " | |
| 1N3520 ⁽¹⁹⁾ | 12.0 | " | 10.0 | " | " | " | |
| 1N3521 ⁽¹⁹⁾ | 13.0 | 5.0 | 12.0 | " | " | " | |
| 1N3522 ⁽¹⁹⁾ | 15.0 | " | 14.0 | " | " | " | |
| 1N3523 ⁽¹⁹⁾ | 16.0 | " | 16.0 | " | " | " | |
| 1N3524 ⁽¹⁹⁾ | 18.0 | " | 18.0 | " | " | " | |
| 1N3525 ⁽¹⁹⁾ | 20.0 | " | 20.0 | " | " | " | |
| 1N3526 ⁽¹⁹⁾ | 22.0 | " | 35.0 | " | " | " | |
| 1N3527 ⁽¹⁹⁾ | 24.0 | " | 38.0 | " | " | " | |
| 1N3528 ⁽¹⁹⁾ | 27.0 | 4.0 | 40.0 | " | " | " | |
| 1N3529 ⁽¹⁹⁾ | 30.0 | " | 48.0 | " | " | " | |
| 1N3530 ⁽¹⁹⁾ | 33.0 | 3.0 | 50.0 | " | " | " | |
| 1N3531 ⁽¹⁹⁾ | 36.0 | " | 75.0 | " | " | " | |
| 1N3532 ⁽¹⁹⁾ | 39.0 | " | 100.0 | " | " | " | |
| 1N3533 ⁽¹⁹⁾ | 43.0 | 2.0 | 130.0 | " | " | " | |
| 1N3534 ⁽¹⁹⁾ | 47.0 | " | 150.0 | " | " | " | |
| 1N3537 ⁽¹⁾ | 11.0 - 13.0 | 25.0 | 7.0 | 8% | 1 watt | Case R ⁽⁹⁾ | 1N3022 |
| 1N3553 ⁽²⁾ | 6.3 ± 3.2% | 7.5 | 15.0 | T.C. = .01% / °C ⁽⁴⁾ | 250mw | DO-7 | |
| 1N3580 ⁽²⁾ | 11.7 ± 5% | " | 25.0 | T.C. = .01% / °C ⁽⁷⁾ | 750mw | DO-13 | 1N941 ⁽²⁷⁾ |
| 1N3581 ⁽²⁾ | 11.7 ± 5% | " | " | T.C. = .005% / °C ⁽⁷⁾ | " | " | 1N942 ⁽²⁷⁾ |
| 1N3582 ⁽²⁾ | 11.7 ± 5% | " | " | T.C. = .002% / °C ⁽⁷⁾ | " | " | 1N943 ⁽²⁷⁾ |
| 1N3583 ⁽²⁾ | 11.7 ± 5% | " | " | T.C. = .001% / °C ⁽⁷⁾ | " | " | 1N944 ⁽²⁷⁾ |
| 1N3584 ⁽²⁾ | 11.7 ± 5% | " | " | T.C. = .0005% / °C ⁽⁷⁾ | " | " | 1N945 ⁽²⁷⁾ |
| Type No. | PIV | I_o 25°C | VF | IR | T_{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| 1N3595 | 150 | — | .83 min. 1.00 max. | 1.0(nA) | (μsec.) 3.0 | DO35 | |
| 1N3611 | 200 | (100°C)A | 1.1 | 1.0 | | A | |
| 1N3612 | 400 | 1.0 | 1.1 | 1.0 | | A | |
| 1N3613 | 600 | 1.0 | 1.1 | 1.0 | | A | |
| 1N3614 | 800 | 1.0 | 1.1 | 1.0 | | A | |
| 1N3644 | 1500 | (55°) .25 | 5.0 | 5 | | S | |
| 1N3645 | 2000 | .25 | 5.0 | 5 | | S | |
| 1N3646 | 2500 | .25 | 5.0 | 5 | | S | |
| 1N3647 | 3000 | .25 | 5.0 | 5 | | S | |
| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N3675 | 6.8 | 18.5 | 4.5 | No Suffix = 20% | 750mw | Case X ⁽²⁸⁾ | |
| 1N3676 | 7.5 | 16.5 | 5.5 | Suffix A = 10% | " | " | |
| 1N3677 | 8.2 | 15.0 | 6.5 | Suffix B = 5% | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------|-------------------------------------|------|---|-------------------------------|-----------------|-------------------|--|
| | Volts | @ mA | | | | | |
| 1N3678 | 9.1 | 14.0 | 7.5 | No Suffix = 20% | 750mw | Case X (28) | |
| 1N3679 | 10.0 | 12.5 | 8.5 | Suffix A = 10% | " | " | |
| 1N3680 | 11.0 | 11.5 | 9.5 | Suffix B = 5% | " | " | |
| 1N3681 | 12.0 | 10.5 | 11.5 | " " | " | " | |
| 1N3682 | 13.0 | 9.5 | 13.0 | " " | " | " | |
| 1N3683 | 15.0 | 8.5 | 16.0 | " " | " | " | |
| 1N3684 | 16.0 | 7.8 | 17.0 | " " | " | " | |
| 1N3685 | 18.0 | 7.0 | 21.0 | " " | " | " | |
| 1N3686 | 20.0 | 6.2 | 25.0 | " " | " | " | |
| 1N3687 | 22.0 | 5.6 | 29.0 | " " | " | " | |
| 1N3688 | 24.0 | 5.2 | 33.0 | " " | " | " | |
| 1N3689 | 27.0 | 4.6 | 41.0 | " " | " | " | |
| 1N3690 | 30.0 | 4.2 | 49.0 | " " | " | " | |
| 1N3691 | 33.0 | 3.8 | 58.0 | " " | " | " | |
| 1N3692 | 36.0 | 3.4 | 70.0 | " " | " | " | |
| 1N3693 | 39.0 | 3.2 | 80.0 | " " | " | " | |
| 1N3694 | 43.0 | 3.0 | 93.0 | " " | " | " | |
| 1N3695 | 47.0 | 2.7 | 105.0 | " " | " | " | |
| 1N3696 | 51.0 | 2.5 | 125.0 | " " | " | " | |
| 1N3697 | 56.0 | 2.2 | 150.0 | " " | " | " | |
| 1N3698 | 62.0 | 2.0 | 185.0 | " " | " | " | |
| 1N3699 | 68.0 | 1.8 | 230.0 | " " | " | " | |
| 1N3700 | 75.0 | 1.7 | 270.0 | " " | " | " | |
| 1N3701 | 82.0 | 1.5 | 330.0 | " " | " | " | |
| 1N3702 | 91.0 | 1.4 | 400.0 | " " | " | " | |
| 1N3703 | 100.0 | 1.3 | 500.0 | " " | " | " | |
| 1N3704 | 110.0 | 1.1 | 750.0 | " " | " | " | |
| 1N3705 | 120.0 | 1.0 | 900.0 | " " | " | " | |
| 1N3706 | 130.0 | 0.95 | 1100.0 | " " | " | " | |
| 1N3707 | 150.0 | 0.85 | 1500.0 | " " | " | " | |
| 1N3708 | 160.0 | 0.80 | 1700.0 | " " | " | " | |
| 1N3709 | 180.0 | 0.68 | 2200.0 | " " | " | " | |
| 1N3710 | 200.0 | 0.65 | 2500.0 | " " | " | " | |
| 1N3732 | 5.1 | 40.0 | 8.5 | 5% | 1 watt | DO-3 (9) | |
| 1N3763(2) | 20 ± 5% | 10.0 | 35.0 | T.C. = .002% / °C | 1.5 watt | Case CC | |
| 1N3776(1) | 10.0 | 25.0 | 6.0 | 10% | 6 watt | DO-4 | |
| 1N3779(2) | 6.3 - 6.7 | 7.5 | 10.0 | T.C. = .015% / °C(4) | 400mw | DO-7 | |
| 1N3780(2) | 6.3 - 6.7 | " | " | T.C. = .01% / °C(4) | " | " | |
| 1N3781(2) | 6.3 - 6.7 | " | " | T.C. = .005% / °C(4) | " | " | |
| 1N3782(2) | 6.3 - 6.7 | " | " | T.C. = .002% / °C(4) | " | " | |
| 1N3783(2) | 6.3 - 6.7 | " | " | T.C. = .001% / °C(4) | " | " | |
| 1N3784(2) | 6.3 - 6.7 | " | " | T.C. = .0005% / °C(4) | " | " | |
| 1N3785 | 6.8 | 55.0 | 2.7 | No Suffix = 20% | 1.5 watt | Case AA(28) | 2EZ6,8D |
| 1N3786 | 7.5 | 50.0 | 3.0 | Suffix A = 10% | " | " | 2EZ7,5D |
| 1N3787 | 8.2 | 46.0 | 3.5 | Suffix B = 5% | " | " | 2EZ8,2D |
| 1N3788 | 9.1 | 41.0 | 4.0 | No Suffix = 20% | 1.5 watt | Case AA(28) | 2EZ9,1D |
| 1N3789 | 10.0 | 37.0 | 5.0 | Suffix A = 10% | " | " | 2EZ10D |
| 1N3790 | 11.0 | 34.0 | 6.0 | Suffix B = 5% | " | " | 2EZ11D |
| 1N3791 | 12.0 | 31.0 | 7.0 | " " | " | " | 2EZ12D |
| 1N3792 | 13.0 | 29.0 | 9.0 | " " | " | " | 2EZ13D |
| 1N3793 | 15.0 | 25.0 | 10.0 | " " | " | " | 2EZ15D |
| 1N3794 | 16.0 | 23.0 | 11.0 | " " | " | " | 2EZ16D |
| 1N3795 | 18.0 | 21.0 | 13.0 | " " | " | " | 2EZ18D |
| 1N3796 | 20.0 | 19.0 | 15.0 | " " | " | " | 2EZ20D |
| 1N3797 | 22.0 | 17.0 | 16.0 | " " | " | " | 2EZ22D |
| 1N3798 | 24.0 | 16.0 | 17.0 | " " | " | " | 2EZ24D |
| 1N3799 | 27.0 | 14.0 | 20.0 | " " | " | " | 2EZ27D |
| 1N3800 | 30.0 | 12.0 | 25.0 | " " | " | " | 2EZ30D |
| 1N3801 | 33.0 | 11.0 | 30.0 | " " | " | " | 2EZ33D |
| 1N3802 | 36.0 | 10.0 | 35.0 | " " | " | " | 2EZ36D |
| 1N3803 | 39.0 | 10.0 | 40.0 | " " | " | " | 2EZ39D |
| 1N3804 | 43.0 | 9.0 | 45.0 | " " | " | " | 2EZ43D |
| 1N3805 | 47.0 | 8.0 | 55.0 | " " | " | " | 2EZ47D |
| 1N3806 | 51.0 | 7.4 | 65.0 | " " | " | " | 2EZ51D |
| 1N3807 | 56.0 | 6.7 | 75.0 | " " | " | " | 2EZ56D |
| 1N3808 | 62.0 | 6.0 | 85.0 | " " | " | " | 2EZ62D |
| 1N3809 | 68.0 | 5.5 | 95.0 | " " | " | " | 2EZ68D |
| 1N3810 | 75.0 | 5.0 | 110.0 | " " | " | " | 2EZ75D |
| 1N3811 | 82.0 | 4.5 | 130.0 | " " | " | " | 2EZ82D |
| 1N3812 | 91.0 | 4.1 | 150.0 | " " | " | " | 2EZ91D |
| 1N3813 | 100.0 | 3.7 | 200.0 | " " | " | " | 2EZ100D |
| 1N3814 | 110.0 | 3.4 | 300.0 | " " | " | " | 2EZ110D |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(1) Double anode type

(2) Temperature compensated zener diode

(4) Temperature range -55°C to +100°C

(7) No suffix denotes temp. range 0°C to +75°C

Suffix A denotes -55°C to +100°C

Suffix B denotes temp. range -55°C to +150°C

(9) Supplied by Microsemi in DO-13 Case

(14) TC = .005V/°C @ +25°C to +100°C or
0.25V/°C @ -55°C to +25°C

(19) Low reverse leakage diode

(28) Supplied by Microsemi in Case J (DO-41)

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-----------------------|---------------------------|-----------------|--------------------------------------|--------------------------|-----------------|-------------------------|----------------------------------|
| 1N3815 | 120.0 | 3.1 | 350.0 | No Suffix = 20% | 1.5 watt | Case AA ⁽²⁸⁾ | 2EZ120D |
| 1N3816 | 130.0 | 2.9 | 400.0 | Suffix A = 10% | " | " | 2EZ130D |
| 1N3817 | 150.0 | 2.5 | 700.0 | Suffix B = 5% | " | " | 2EZ150D |
| 1N3818 | 160.0 | 2.3 | 750.0 | " " | " | " | 2EZ160D |
| 1N3819 | 180.0 | 2.1 | 800.0 | " " | " | " | 2EZ180D |
| 1N3820 | 200.0 | 1.9 | 1000.0 | " " | " | " | 2EZ200D |
| 1N3821 | 3.3 | 76.0 | 10.0 | No Suffix = 10% | 1 watt | DO-13 | |
| 1N3822 | 3.6 | 69.0 | 10.0 | Suffix A = 5% | " | " | |
| 1N3823 | 3.9 | 64.0 | 9.0 | " " | " | " | |
| 1N3824 | 4.3 | 58.0 | 9.0 | " " | " | " | |
| 1N3825 | 4.7 | 53.0 | 8.0 | " " | " | " | |
| 1N3826 | 5.1 | 49.0 | 7.0 | " " | " | " | |
| 1N3827 | 5.6 | 45.0 | 5.0 | " " | " | " | |
| 1N3828 | 6.2 | 41.0 | 2.0 | " " | " | " | |
| 1N3829 | 6.8 | 37.0 | 1.5 | " " | " | " | |
| 1N3830 | 7.5 | 34.0 | 1.5 | " " | " | " | |
| Type No | PIV | Io 25°C | VF | IR | T _{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| 1N3879 | 50 | 6 | 1.4 | 15 | 200 (n sec) | DO4 | |
| 1N3880 | 100 | 6 | 1.4 | 15 | 200 | DO4 | |
| 1N3881 | 200 | 6 | 1.4 | 15 | 200 | DO4 | |
| 1N3882 | 300 | 6 | 1.4 | 15 | 200 | DO4 | |
| 1N3883 | 400 | 6 | 1.4 | 15 | 200 | DO4 | |
| 1N3889 | 50 | 12 | 1.4 | 25 | 200 (n sec) | DO4 | |
| 1N3890 | 100 | 12 | 1.4 | 25 | 200 | DO4 | |
| 1N3891 | 200 | 12 | 1.4 | 25 | 200 | DO4 | |
| 1N3892 | 300 | 12 | 1.4 | 25 | 200 | DO4 | |
| 1N3893 | 400 | 12 | 1.4 | 25 | 200 | DO4 | |
| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N3949 | 20.0 | 250.0 | 3.0 | 5% | 10 watt | DO-4 | |
| 1N3950 | 20.0 | 19.0 | 15.0 | 5% | 1.5 watt | Case AA ⁽²⁸⁾ | |
| 1N3951 | 25.0 | 15.0 | 18.0 | " | " | " | |
| Type No. | PIV | Io 25°C | VF | IR | T _{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| 1N3957 | 1150 | (100°C)A 1.0 | 1.1 | 1.0 | | A | |
| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N3984 | 5.5 | 1000.0 | 0.7 | 5% | 10 watt | DO-4 | |
| 1N3985 | 6.0 | 1000.0 | 0.7 | " | " | " | |
| 1N3986 | 6.2 | 805.0 | 1.5 | 5% | 10 watt | DO-4 | |
| 1N3993 | 3.9 | 640.0 | 2.0 | No Suffix = 10% | 10 watt | DO-4 | |
| 1N3994 | 4.3 | 580.0 | 1.5 | Suffix A = 5% | " | " | |
| 1N3995 | 4.7 | 530.0 | 1.2 | Suffix R = Rev. Polarity | " | " | |
| 1N3996 | 5.1 | 490.0 | 1.1 | " " | " | " | |
| 1N3997 | 5.6 | 445.0 | 1.0 | " " | " | " | |
| 1N3998 | 6.2 | 405.0 | 1.1 | " " | " | " | |
| 1N3999 | 6.8 | 370.0 | 1.2 | " " | " | " | |
| 1N4000 | 7.5 | 335.0 | 1.3 | " " | " | " | |
| 1N4010 ⁽²⁾ | 6.2 ± 5% | 7.5 | 15.0 | T.C. ⁽¹⁴⁾ | 400mw | DO-7 | |
| 1N4016 | 8.2 | 150.0 | 1.5 | No Suffix = 20% | 5 watt | DO-4 | |
| 1N4017 | 9.1 | 135.0 | 2.0 | Suffix A = 10% | " | " | |
| 1N4018 | 10.0 | 125.0 | 2.0 | Suffix B = 5% | " | " | |
| 1N4019 | 11.0 | 115.0 | 2.5 | " " | " | " | |
| 1N4020 | 12.0 | 105.0 | 2.5 | " " | " | " | |
| 1N4021 | 13.0 | 95.0 | 3.0 | " " | " | " | |
| 1N4022 | 15.0 | 85.0 | " | " " | " | " | |
| 1N4023 | 16.0 | 80.0 | " | " " | " | " | |
| 1N4024 | 18.0 | 70.0 | 4.0 | " " | " | " | |
| 1N4025 | 20.0 | 65.0 | 4.0 | " " | " | " | |
| 1N4026 | 22.0 | 55.0 | 5.0 | " " | " | " | |
| 1N4027 | 24.0 | 50.0 | 6.0 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|------------------------------|------------------------------|------|--|---|-----------------|-------------------|--|
| | Volts | @ mA | | | | | |
| 1N4028 | 27.0 | 45.0 | 6.0 | No Suffix = 20% Suffix A = 10% Suffix B = 5% | 5 watt | Case K (32) | |
| 1N4029 | 30.0 | 42.0 | 8.0 | | " | " | |
| 1N4030 | 33.0 | 38.0 | 10.0 | | " | " | |
| 1N4031 | 36.0 | 35.0 | 12.0 | " " | " | " | |
| 1N4032 | 39.0 | 32.0 | 15.0 | " " | " | " | |
| 1N4033 | 43.0 | 29.0 | 20.0 | " " | " | " | |
| 1N4034 | 47.0 | 27.0 | 20.0 | " " | " | " | |
| 1N4035 | 51.0 | 24.5 | 25.0 | " " | " | " | |
| 1N4036 | 56.0 | 22.0 | 30.0 | " " | " | " | |
| 1N4037 | 62.0 | 20.0 | 50.0 | " " | " | " | |
| 1N4038 | 68.0 | 18.5 | 75.0 | " " | " | " | |
| 1N4039 | 75.0 | 16.5 | 100.0 | " " | " | " | |
| 1N4040 | 82.0 | 15.0 | 100.0 | " " | " | " | |
| 1N4041 | 91.0 | 13.5 | 125.0 | " " | " | " | |
| 1N4042 | 100.0 | 12.5 | 150.0 | " " | " | " | |
| 1N4057(2) | 12.4 ± 5% | 10.0 | 25.0 | No Suffix T.C. = .005%/°C(4) Suffix A T.C. = .002%/°C(4) | 1.5 watt | Case CC | |
| 1N4058(2) | 14.6 ± 5% | " | 30.0 | | " | " | |
| 1N4059(2) | 16.8 ± 5% | " | " | | " | " | |
| 1N4060(2) | 18.5 ± 5% | " | " | " " | " | " | |
| 1N4061(2) | 21.0 ± 5% | " | 35.0 | " " | " | " | |
| 1N4062(2) | 23.0 ± 5% | " | 40.0 | " " | " | " | |
| 1N4063(2) | 27.0 ± 5% | " | 45.0 | " " | " | " | |
| 1N4064(2) | 30.0 ± 5% | " | 50.0 | " " | " | " | |
| 1N4065(2) | 33.0 ± 5% | " | 55.0 | " " | " | " | |
| 1N4066(2) | 37.0 ± 5% | 7.5 | 80.0 | " " | " | " | |
| 1N4067(2) | 43.0 ± 5% | " | 90.0 | " " | " | " | |
| 1N4068(2) | 47.0 ± 5% | " | 100.0 | " " | " | " | |
| 1N4069(2) | 51.0 ± 5% | " | 110.0 | " " | 2.0 watt | Case DD | |
| 1N4070(2) | 56.0 ± 5% | " | 120.0 | " " | | | |
| 1N4071(2) | 62.0 ± 5% | " | 135.0 | " " | | | |
| 1N4072(2) | 68.0 ± 5% | 5.0 | 230.0 | " " | " | " | |
| 1N4073(2) | 75.0 ± 5% | " | 250.0 | " " | " | " | |
| 1N4074(2) | 82.0 ± 5% | " | 270.0 | " " | " | " | |
| 1N4075(2) | 87.0 ± 5% | " | 290.0 | " " | " | " | |
| 1N4076(2) | 91.0 ± 5% | " | 310.0 | " " | " | " | |
| 1N4077(2) | 100 ± 5% | " | 340.0 | " " | " | " | |
| 1N4078(2) | 105 ± 5% | 2.5 | 700.0 | " " | " | " | |
| 1N4079(2) | 110 ± 5% | " | 740.0 | " " | " | " | |
| 1N4080(2) | 120 ± 5% | " | 800.0 | " " | " | " | |
| 1N4081(2) | 130 ± 5% | " | 840.0 | " " | 2.5 watt | Case EE | |
| 1N4082(2) | 140 ± 5% | " | 960.0 | " " | | | |
| 1N4083(2) | 150 ± 5% | " | 1020.0 | " " | | | |
| 1N4084(2) | 175 ± 5% | " | 1150.0 | " " | " | " | |
| 1N4085(2) | 200 ± 5% | " | 1350.0 | " " | " | " | |
| 1N4094 is an obsolete device | | | | | | | |
| 1N4095 | 5.0 | 40.0 | 15.0 | 10% | 275 mw | DO-7/DO-35 | |
| 1N4096 | 90.0 | 8.0 | 150.0 | 5% | 3 watt | Case JJ (28) | |
| 1N4097 | 100.0 | 5.0 | 175.0 | " | " | | |
| 1N4098 | 150.0 | 5.0 | 650.0 | " | " | | |
| 1N4099 (19,20) | 6.8 | 0.25 | 200.0 | 5% | 250mw | DO-7/DO-35 | |
| 1N4100 (19,20) | 7.5 | " | " | " | " | " | |
| 1N4101 (19,20) | 8.2 | " | " | " | " | " | |
| 1N4102 (19,20) | 8.7 | " | " | " | " | " | |
| 1N4103 (19,20) | 9.1 | " | " | " | " | " | |
| 1N4104 (19,20) | 10.0 | " | " | " | " | " | |
| 1N4105 (19,20) | 11.0 | " | " | " | " | " | |
| 1N4106 (19,20) | 12.0 | " | " | " | " | " | |
| 1N4107 (19,20) | 13.0 | " | " | " | " | " | |
| 1N4108 (19,20) | 14.0 | " | " | " | " | " | |
| 1N4109 (19,20) | 15.0 | " | 100.0 | " | " | " | |
| 1N4110 (19,20) | 16.0 | " | " | " | " | " | |
| 1N4111 (19,20) | 17.0 | " | " | " | " | " | |
| 1N4112 (19,20) | 18.0 | " | " | " | " | " | |
| 1N4113 (19,20) | 19.0 | " | 150.0 | " | " | " | |
| 1N4114 (19,20) | 20.0 | " | " | " | " | " | |
| 1N4115 (19,20) | 22.0 | " | " | " | " | " | |
| 1N4116 (19,20) | 24.0 | " | " | " | " | " | |
| 1N4117 (19,20) | 25.0 | " | " | " | " | " | |
| 1N4118 (19,20) | 27.0 | " | " | " | " | " | |
| 1N4119 (19,20) | 28.0 | " | 200.0 | " | " | " | |
| 1N4120 (19,20) | 30.0 | " | " | " | " | " | |
| 1N4121 (19,20) | 33.0 | " | " | " | " | " | |
| 1N4122 (19,20) | 36.0 | " | " | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(2) Temperature compensated zener diode
(4) Temperature range -55°C to +100°C

(19) Low reverse leakage diode
(20) Low noise diode

(28) Supplied by Microsemi in Case J (DO-41)
(32) Supplied by Microsemi in DO-4 Case

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|---------------------------|-------------------------------------|-------|---|--|-----------------|----------------------------|--|
| 1N4123 ^(19,20) | 39.0 | 0.25 | 200.0 | 5% | 250mw | DO-7/DO-35 | |
| 1N4124 ^(19,20) | 43.0 | " | 250.0 | " | " | " | |
| 1N4125 ^(19,20) | 47.0 | " | " | " | " | " | |
| 1N4126 ^(19,20) | 51.0 | " | 300.0 | " | " | " | |
| 1N4127 ^(19,20) | 56.0 | " | " | " | " | " | |
| 1N4128 ^(19,20) | 60.0 | " | 400.0 | " | " | " | |
| 1N4129 ^(19,20) | 62.0 | " | 500.0 | " | " | " | |
| 1N4130 ^(19,20) | 68.0 | " | 700.0 | " | " | " | |
| 1N4131 ^(19,20) | 75.0 | " | " | " | " | " | |
| 1N4132 ^(19,20) | 82.0 | " | 800.0 | " | " | " | |
| 1N4133 ^(19,20) | 87.0 | " | 1000.0 | " | " | " | |
| 1N4134 ^(19,20) | 91.0 | " | 1200.0 | " | " | " | |
| 1N4135 ^(19,20) | 100.0 | " | 1500.0 | " | " | " | |
| 1N4158 | 6.8 | 37.0 | 3.5 | No Suffix = 20% Suffix A = 10% Suffix B = 5% | 1 watt | Case DO-29 ⁽²⁸⁾ | |
| 1N4159 | 7.5 | 34.0 | 4.0 | | " | " | |
| 1N4160 | 8.2 | 31.0 | 4.5 | | " | " | |
| 1N4161 | 9.1 | 28.0 | 5.0 | " " | " | " | |
| 1N4162 | 10.0 | 25.0 | 7.0 | " " | " | " | |
| 1N4163 | 11.0 | 23.0 | 8.0 | " " | " | " | |
| 1N4164 | 12.0 | 21.0 | 9.0 | " " | " | " | |
| 1N4165 | 13.0 | 19.0 | 10.0 | " " | " | " | |
| 1N4166 | 15.0 | 17.0 | 14.0 | " " | " | " | |
| 1N4167 | 16.0 | 15.5 | 16.0 | " " | " | " | |
| 1N4168 | 18.0 | 14.0 | 20.0 | " " | " | " | |
| 1N4169 | 20.0 | 12.5 | 22.0 | " " | " | " | |
| 1N4170 | 22.0 | 11.5 | 23.0 | " " | " | " | |
| 1N4171 | 24.0 | 10.5 | 25.0 | " " | " | " | |
| 1N4172 | 27.0 | 9.5 | 35.0 | " " | " | " | |
| 1N4173 | 30.0 | 8.5 | 40.0 | " " | " | " | |
| 1N4174 | 33.0 | 7.5 | 45.0 | " " | " | " | |
| 1N4175 | 36.0 | 7.0 | 50.0 | " " | " | " | |
| 1N4176 | 39.0 | 6.5 | 60.0 | " " | " | " | |
| 1N4177 | 43.0 | 6.0 | 70.0 | " " | " | " | |
| 1N4178 | 47.0 | 5.5 | 80.0 | " " | " | " | |
| 1N4179 | 51.0 | 5.0 | 95.0 | " " | " | " | |
| 1N4180 | 56.0 | 4.5 | 110.0 | " " | " | " | |
| 1N4181 | 62.0 | 4.0 | 125.0 | " " | " | " | |
| 1N4182 | 68.0 | 3.7 | 150.0 | " " | " | " | |
| 1N4183 | 75.0 | 3.3 | 175.0 | " " | " | " | |
| 1N4184 | 82.0 | 3.0 | 200.0 | " " | " | " | |
| 1N4185 | 91.0 | 2.8 | 250.0 | " " | " | " | |
| 1N4186 | 100.0 | 2.5 | 350.0 | " " | " | " | |
| 1N4187 | 110.0 | 2.3 | 450.0 | " " | " | " | |
| 1N4188 | 120.0 | 2.0 | 550.0 | " " | " | " | |
| 1N4189 | 130.0 | 1.9 | 700.0 | " " | " | " | |
| 1N4190 | 150.0 | 1.7 | 1000.0 | " " | " | " | |
| 1N4191 | 160.0 | 1.6 | 1100.0 | " " | " | " | |
| 1N4192 | 180.0 | 1.4 | 1200.0 | " " | " | " | |
| 1N4193 | 200.0 | 1.2 | 1500.0 | " " | " | " | |
| 1N4194 | 6.8 | 370.0 | 1.2 | No Suffix = 20% Suffix A = 10% Suffix B = 5% | 10 watt | Case HH ⁽³²⁾ | 1N2970 |
| 1N4195 | 7.5 | 335.0 | 1.3 | | " | " | 1N2971 |
| 1N4196 | 8.2 | 305.0 | 1.5 | | " | " | 1N2972 |
| 1N4197 | 9.1 | 275.0 | 2.0 | " " | " | " | 1N2973 |
| 1N4198 | 10.0 | 250.0 | 3.0 | " " | " | " | 1N2974 |
| 1N4199 | 11.0 | 230.0 | " | " " | " | " | 1N2975 |
| 1N4200 | 12.0 | 210.0 | " | " " | " | " | 1N2976 |
| 1N4201 | 13.0 | 190.0 | " | " " | " | " | 1N2977 |
| 1N4202 | 14.0 | 180.0 | " | " " | " | " | 1N2978 |
| 1N4203 | 15.0 | 170.0 | " | " " | " | " | 1N2979 |
| 1N4204 | 16.0 | 155.0 | 4.0 | " " | " | " | 1N2980 |
| 1N4205 | 17.0 | 145.0 | " | " " | " | " | 1N2981 |
| 1N4206 | 18.0 | 140.0 | " | " " | " | " | 1N2982 |
| 1N4207 | 19.0 | 130.0 | " | " " | " | " | 1N2983 |
| 1N4208 | 20.0 | 125.0 | " | " " | " | " | 1N2984 |
| 1N4209 | 22.0 | 115.0 | 5.0 | " " | " | " | 1N2985 |
| 1N4210 | 24.0 | 105.0 | " | " " | " | " | 1N2986 |
| 1N4211 | 25.0 | 100.0 | 6.0 | " " | " | " | 1N2987 |
| 1N4212 | 27.0 | 95.0 | 7.0 | " " | " | " | 1N2988 |
| 1N4213 | 30.0 | 85.0 | 8.0 | " " | " | " | 1N2989 |
| 1N4214 | 33.0 | 75.0 | 9.0 | " " | " | " | 1N2990 |
| 1N4215 | 36.0 | 70.0 | 10.0 | " " | " | " | 1N2991 |
| 1N4216 | 39.0 | 65.0 | 11.0 | " " | " | " | 1N2992 |
| 1N4217 | 43.0 | 60.0 | 12.0 | " " | " | " | 1N2993 |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(28) Supplied by Microsemi in Case DO-29.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|----------------|----------------------------------|---------------------|---|-------------------------|-----------------|-------------------------|----------------------------------|
| | Volts | @ mA | | | | | |
| 1N4218 | 45.0 | 55.0 | 13.0 | No Suffix = 20% | 10 watt | Case HH ⁽³²⁾ | 1N2994 |
| 1N4219 | 47.0 | 55.0 | 14.0 | Suffix A = 10% | " | " | 1N2995 |
| 1N4220 | 50.0 | 50.0 | 15.0 | Suffix B = 5% | " | " | 1N2996 |
| 1N4221 | 51.0 | " | " | " | " | " | 1N2997 |
| 1N4222 | 52.0 | " | " | " | " | " | 1N2998 |
| 1N4223 | 56.0 | 45.0 | 16.0 | " | " | " | 1N2999 |
| 1N4224 | 62.0 | 40.0 | 17.0 | " | " | " | 1N3000 |
| 1N4225 | 68.0 | 37.0 | 18.0 | " | " | " | 1N3001 |
| 1N4226 | 75.0 | 33.0 | 22.0 | " | " | " | 1N3002 |
| 1N4227 | 82.0 | 30.0 | 25.0 | " | " | " | 1N3003 |
| 1N4228 | 91.0 | 38.0 | 35.0 | " | " | " | 1N3004 |
| 1N4229 | 100.0 | 25.0 | 40.0 | " | " | " | 1N3005 |
| 1N4230 | 105.0 | 25.0 | 45.0 | " | " | " | 1N3006 |
| 1N4231 | 110.0 | 23.0 | 55.0 | " | " | " | 1N3007 |
| 1N4232 | 120.0 | 20.0 | 75.0 | " | " | " | 1N3008 |
| 1N4233 | 130.0 | 19.0 | 100.0 | " | " | " | 1N3009 |
| 1N4234 | 140.0 | 18.0 | 125.0 | " | " | " | 1N3010 |
| 1N4235 | 150.0 | 17.0 | 175.0 | " | " | " | 1N3011 |
| 1N4236 | 160.0 | 16.0 | 200.0 | " | " | " | 1N3012 |
| 1N4237 | 175.0 | 14.0 | 250.0 | " | " | " | 1N3013 |
| 1N4238 | 180.0 | 14.0 | 260.0 | " | " | " | 1N3014 |
| 1N4239 | 200.0 | 12.0 | 300.0 | " | " | " | 1N3015 |
| 1N4240 | 5 ± .1 | 400.0 | 0.68 | — | 10 watt | DO-4 | |
| 1N4241 | 6 ± .1 | 350.0 | 0.50 | — | " | " | |
| Type No. | PIV | I _o 25°C | VF | IR | T _{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| | | (100°C)A | | | (n sec.) | | |
| 1N4245 | 200 | 1.00 | 1.3 | 1.0 | 5.0 | A | |
| 1N4246 | 400 | 1.00 | 1.3 | 1.0 | 5.0 | A | |
| 1N4247 | 600 | 1.00 | 1.3 | 1.0 | 5.0 | A | |
| 1N4248 | 800 | 1.00 | 1.3 | 1.0 | 5.0 | A | |
| 1N4249 | 1000 | 1.00 | 1.3 | 1.0 | 5.0 | A | |
| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N4258 | 6.8 | 370.0 | 1.2 | No Suffix = 20% | 10 watt | Case KK | 1N2970 |
| 1N4259 | 7.5 | 335.0 | 1.3 | Suffix A = 10% | " | " | 1N2971 |
| 1N4260 | 8.2 | 305.0 | 1.5 | Suffix B = 5% | " | " | 1N2972 |
| 1N4261 | 9.1 | 275.0 | 2.0 | " | " | " | 1N2973 |
| 1N4262 | 10.0 | 250.0 | 3.0 | " | " | " | 1N2974 |
| 1N4263 | 11.0 | 230.0 | " | " | " | " | 1N2975 |
| 1N4264 | 12.0 | 210.0 | " | " | " | " | 1N2976 |
| 1N4265 | 13.0 | 190.0 | " | " | " | " | 1N2977 |
| 1N4266 | 15.0 | 170.0 | " | " | " | " | 1N2979 |
| 1N4267 | 16.0 | 155.0 | 4.0 | " | " | " | 1N2980 |
| 1N4268 | 18.0 | 140.0 | " | " | " | " | 1N2982 |
| 1N4269 | 20.0 | 125.0 | " | " | " | " | 1N2984 |
| 1N4270 | 22.0 | 115.0 | 5.0 | " | " | " | 1N2985 |
| 1N4271 | 24.0 | 105.0 | " | " | " | " | 1N2986 |
| 1N4272 | 27.0 | 95.0 | 7.0 | " | " | " | 1N2988 |
| 1N4273 | 30.0 | 85.0 | 8.0 | " | " | " | 1N2989 |
| 1N4274 | 33.0 | 75.0 | 9.0 | " | " | " | 1N2990 |
| 1N4275 | 36.0 | 70.0 | 10.0 | " | " | " | 1N2991 |
| 1N4276 | 39.0 | 65.0 | 11.0 | " | " | " | 1N2992 |
| 1N4277 | 43.0 | 60.0 | 12.0 | " | " | " | 1N2993 |
| 1N4278 | 47.0 | 55.0 | 14.0 | " | " | " | 1N2995 |
| 1N4279 | 51.0 | 50.0 | 15.0 | " | " | " | 1N2997 |
| 1N4280 | 56.0 | 45.0 | 16.0 | " | " | " | 1N2999 |
| 1N4281 | 62.0 | 40.0 | 17.0 | " | " | " | 1N3000 |
| 1N4282 | 68.0 | 37.0 | 18.0 | " | " | " | 1N3001 |
| 1N4283 | 75.0 | 33.0 | 22.0 | " | " | " | 1N3002 |
| 1N4284 | 82.0 | 30.0 | 25.0 | " | " | " | 1N3003 |
| 1N4285 | 91.0 | 28.0 | 35.0 | " | " | " | 1N3004 |
| 1N4286 | 100.0 | 25.0 | 40.0 | " | " | " | 1N3005 |
| 1N4287 | 110.0 | 23.0 | 55.0 | " | " | " | 1N3007 |
| 1N4288 | 120.0 | 20.0 | 75.0 | " | " | " | 1N3008 |
| 1N4289 | 130.0 | 19.0 | 100.0 | " | " | " | 1N3009 |
| 1N4290 | 150.0 | 17.0 | 175.0 | " | " | " | 1N3011 |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(2) Temperature compensated zener diode

(7) No suffix denotes temp. range 0°C

Suffix A denotes temp range -55°C to +100°C

(15) T.C. = 0 to +.01%/°C

Temp. range = -55°C to +150°C

(16) I_Z (nom.) is shown. T.C. is guaranteed over current ranges:

150-250mA for 1N4297, 8; 110-190 mA for 1N4299, 300;

750-1250 for 1N4301, 2; 550-950 mA for 1N4303, 4

(28) Can be supplied by Microsemi in Case J (DO-41)

(32) Can be supplied by Microsemi in DO-4 Case

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} , Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-----------------------|-------------------------------------|------------------------|---|--|-----------------|-------------------------|--|
| 1N4291 | 160.0 | 16.0 | 200.0 | No Suffix = 20% | 10 watt | Case KK | 1N3012 |
| 1N4292 | 180.0 | 14.0 | 260.0 | Suffix A = 10% | " | " | 1N3014 |
| 1N4293 | 200.0 | 12.0 | 300.0 | Suffix B = 5% | " | " | 1N3015 |
| 1N4295 ⁽²⁾ | 10.0 | 10.0 | 20.0 | No Suf. = 2% Suf. A = 1% ⁽¹⁵⁾ | 400mw | DO-7 | |
| 1N4296 ⁽²⁾ | 10.0 | 20.0 | 10.0 | No Suf. = 2% Suf. A = 1% ⁽¹⁵⁾ | 1 watt | DO-13 | |
| 1N4297 ⁽²⁾ | 8.36 - 9.24 | 200.0 ⁽¹⁶⁾ | 1.4 | T.C. = .01% / °C ⁽⁷⁾ | 10 watt | DO-4 | |
| 1N4298 ⁽²⁾ | 8.36 - 9.24 | 200.0 ⁽¹⁶⁾ | " | T.C. = .005% / °C ⁽⁷⁾ | " | " | |
| 1N4299 ⁽²⁾ | 10.74 - 11.86 | 150.0 ⁽¹⁶⁾ | " | T.C. = .01% / °C ⁽⁷⁾ | " | " | |
| 1N4300 ⁽²⁾ | 10.74 - 11.86 | 150.0 ⁽¹⁶⁾ | " | T.C. = .005% / °C ⁽⁷⁾ | " | " | |
| 1N4301 ⁽²⁾ | 8.36 - 9.24 | 1000.0 ⁽¹⁶⁾ | 4.9 | T.C. = .01% / °C ⁽⁷⁾ | 50 watt | DO-5 | |
| 1N4302 ⁽²⁾ | 8.36 - 9.24 | 1000.0 ⁽¹⁶⁾ | " | T.C. = .005% / °C ⁽⁷⁾ | " | " | |
| 1N4303 ⁽²⁾ | 10.74 - 11.86 | 750.0 ⁽¹⁶⁾ | 3.8 | T.C. = .01% / °C ⁽⁷⁾ | " | " | |
| 1N4304 ⁽²⁾ | 10.74 - 11.86 | 750.0 ⁽¹⁶⁾ | " | T.C. = .005% / °C ⁽⁷⁾ | " | " | |
| 1N4321 | 50.0 | 15.0 | 50.0 | 10% | 3 watt | Case LL | |
| 1N4323 | 6.8 | 37.0 | 3.5 | No Suffix = 20% | 1 watt | DO-7 ⁽²⁸⁾ | |
| 1N4324 | 7.5 | 34.0 | 4.0 | Suffix A = 10% | " | " | |
| 1N4325 | 8.2 | 31.0 | 4.5 | Suffix B = 5% | " | " | |
| 1N4326 | 9.1 | 28.0 | 5.0 | " " | " | " | |
| 1N4327 | 10.0 | 25.0 | 7.0 | " " | " | " | |
| 1N4328 | 11.0 | 23.0 | 8.0 | " " | " | " | |
| 1N4329 | 12.0 | 21.0 | 9.0 | " " | " | " | |
| 1N4330 | 13.0 | 19.0 | 10.0 | " " | " | " | |
| 1N4331 | 15.0 | 17.0 | 14.0 | " " | " | " | |
| 1N4332 | 16.0 | 15.5 | 16.0 | " " | " | " | |
| 1N4333 | 18.0 | 14.0 | 20.0 | " " | " | " | |
| 1N4334 | 20.0 | 12.5 | 22.0 | " " | " | " | |
| 1N4335 | 22.0 | 11.5 | 23.0 | " " | " | " | |
| 1N4336 | 24.0 | 10.5 | 25.0 | " " | " | " | |
| 1N4337 | 27.0 | 9.5 | 35.0 | " " | " | " | |
| 1N4338 | 30.0 | 8.5 | 40.0 | " " | " | " | |
| 1N4339 | 33.0 | 7.5 | 45.0 | " " | " | " | |
| 1N4340 | 36.0 | 7.0 | 55.0 | " " | " | " | |
| 1N4341 | 39.0 | 6.5 | 60.0 | " " | " | " | |
| 1N4342 | 43.0 | 6.0 | 70.0 | " " | " | " | |
| 1N4343 | 47.0 | 5.5 | 80.0 | " " | " | " | |
| 1N4344 | 51.0 | 5.0 | 95.0 | " " | " | " | |
| 1N4345 | 56.0 | 4.5 | 110.0 | " " | " | " | |
| 1N4346 | 62.0 | 4.0 | 125.0 | " " | " | " | |
| 1N4347 | 68.0 | 3.7 | 150.0 | " " | " | " | |
| 1N4348 | 75.0 | 3.3 | 175.0 | " " | " | " | |
| 1N4349 | 82.0 | 3.0 | 200.0 | " " | " | " | |
| 1N4350 | 91.0 | 2.8 | 250.0 | " " | " | " | |
| 1N4351 | 100.0 | 2.5 | 350.0 | " " | " | " | |
| 1N4352 | 110.0 | 2.3 | 450.0 | " " | " | " | |
| 1N4353 | 120.0 | 2.0 | 550.0 | " " | " | " | |
| 1N4354 | 130.0 | 1.9 | 700.0 | " " | " | " | |
| 1N4355 | 150.0 | 1.7 | 1000.0 | " " | " | " | |
| 1N4356 | 160.0 | 1.6 | 1100.0 | " " | " | " | |
| 1N4357 | 180.0 | 1.4 | 1200.0 | " " | " | " | |
| 1N4358 | 200.0 | 1.2 | 1500.0 | " " | " | " | |
| 1N4360 | 2.4 | 10.0 | 60.0 | 5% | 250mw | DO-7 | |
| 1N4370 | 2.4 | 20.0 | 30.0 | No Suffix = 10% | 400mw | DO-7 | |
| 1N4371 | 2.7 | " | " | Suffix A = 5% | " | " | |
| 1N4372 | 3.0 | " | 29.0 | " " | " | " | |
| 1N4400 | 6.8 | 37.0 | 2.0 | 20% | 1 watt | Case NN ⁽²⁹⁾ | |
| 1N4401 | 7.5 | 34.0 | 2.0 | " | " | " | |
| 1N4402 | 8.2 | 31.0 | 2.0 | " | " | " | |
| 1N4403 | 9.1 | 28.0 | 2.5 | " | " | " | |
| 1N4404 | 10.0 | 25.0 | 3.0 | " | " | " | |
| 1N4405 | 11.0 | 23.0 | 3.5 | " | " | " | |
| 1N4406 | 12.0 | 21.0 | 4.0 | " | " | " | |
| 1N4407 | 13.0 | 19.0 | 5.0 | " | " | " | |
| 1N4408 | 15.0 | 17.0 | 6.0 | " | " | " | |
| 1N4409 | 16.0 | 15.5 | 8.0 | " | " | " | |
| 1N4410 | 18.0 | 14.0 | 10.0 | " | " | " | |
| 1N4411 | 20.0 | 12.5 | 11.0 | " | " | " | |
| 1N4412 | 22.0 | 11.5 | 12.0 | " | " | " | |
| 1N4413 | 24.0 | 10.5 | 13.0 | " | " | " | |
| 1N4414 | 27.0 | 9.5 | 14.0 | " | " | " | |
| 1N4415 | 30.0 | 8.5 | 15.0 | " | " | " | |
| 1N4416 | 33.0 | 7.5 | 17.0 | " | " | " | |
| 1N4417 | 36.0 | 7.0 | 19.0 | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|--------------------------|------------------------------|------------|--|-------------------------------|-----------------|-------------------------|--|
| | Volts | @ mA | | | | | |
| 1N4418 | 39.0 | 6.5 | 21.0 | 20% | 1 watt | Case NN ⁽²⁴⁾ | |
| 1N4419 | 43.0 | 6.0 | 23.0 | " | " | " | |
| 1N4420 | 47.0 | 5.5 | 26.0 | " | " | " | |
| 1N4421 | 51.0 | 5.0 | 30.0 | " | " | " | |
| 1N4422 | 56.0 | 4.5 | 33.0 | " | " | " | |
| 1N4423 | 62.0 | 4.0 | 40.0 | " | " | " | |
| 1N4424 | 68.0 | 3.7 | 44.0 | " | " | " | |
| 1N4425 | 75.0 | 3.3 | 60.0 | " | " | " | |
| 1N4426 | 82.0 | 3.0 | 85.0 | " | " | " | |
| 1N4427 | 91.0 | 2.8 | 115.0 | 20% | 1 watt | Case NN ⁽²⁶⁾ | |
| 1N4428 | 100.0 | 2.5 | 165.0 | " | " | " | |
| 1N4429 | 110.0 | 2.3 | 250.0 | " | " | " | |
| 1N4430 | 120.0 | 2.0 | 350.0 | " | " | " | |
| 1N4431 | 130.0 | 1.9 | 500.0 | " | " | " | |
| 1N4432 | 150.0 | 1.7 | 800.0 | " | " | " | |
| 1N4433 | 160.0 | 1.6 | 1000.0 | " | " | " | |
| 1N4434 | 180.0 | 1.4 | 1100.0 | " | " | " | |
| 1N4435 | 200.0 | 1.2 | 1400.0 | " | " | " | |
| Type No. | PIV | I_o 25°C | VF | IR | T_{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| 1N4449 ^{500 mw} | 75 | — | 1.0 | .025 | 4 (n sec.) | DO35 | |
| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N4460 | 6.2 | 40.0 | 4.0 | 5% | 1.5 watt | Case MM ⁽²⁸⁾ | |
| 1N4461 | 6.8 | 37.0 | 2.5 | " | " | " | |
| 1N4462 | 7.5 | 34.0 | " | " | " | " | |
| 1N4463 | 8.2 | 31.0 | 3.0 | " | " | " | |
| 1N4464 | 9.1 | 28.0 | 4.0 | " | " | " | |
| 1N4465 | 10.0 | 25.0 | 5.0 | " | " | " | |
| 1N4466 | 11.0 | 23.0 | 6.0 | " | " | " | |
| 1N4467 | 12.0 | 21.0 | 7.0 | " | " | " | |
| 1N4468 | 13.0 | 19.0 | 8.0 | " | " | " | |
| 1N4469 | 15.0 | 17.0 | 9.0 | " | " | " | |
| 1N4470 | 16.0 | 15.5 | 10.0 | " | " | " | |
| 1N4471 | 18.0 | 14.0 | 11.0 | " | " | " | |
| 1N4472 | 20.0 | 12.5 | 12.0 | " | " | " | |
| 1N4473 | 22.0 | 11.5 | 14.0 | " | " | " | |
| 1N4474 | 24.0 | 10.5 | 16.0 | " | " | " | |
| 1N4475 | 27.0 | 9.5 | 18.0 | " | " | " | |
| 1N4476 | 30.0 | 8.5 | 20.0 | " | " | " | |
| 1N4477 | 33.0 | 7.5 | 25.0 | " | " | " | |
| 1N4478 | 36.0 | 7.0 | 27.0 | " | " | " | |
| 1N4479 | 39.0 | 6.5 | 30.0 | " | " | " | |
| 1N4480 | 43.0 | 6.0 | 40.0 | " | " | " | |
| 1N4481 | 47.0 | 5.5 | 50.0 | " | " | " | |
| 1N4482 | 51.0 | 5.0 | 60.0 | " | " | " | |
| 1N4483 | 56.0 | 4.5 | 70.0 | " | " | " | |
| 1N4484 | 62.0 | 4.0 | 80.0 | " | " | " | |
| 1N4485 | 68.0 | 3.7 | 100.0 | " | " | " | |
| 1N4486 | 75.0 | 3.3 | 130.0 | " | " | " | |
| 1N4487 | 82.0 | 3.0 | 160.0 | " | " | " | |
| 1N4488 | 91.0 | 2.8 | 200.0 | " | " | " | |
| 1N4489 | 100.0 | 2.5 | 250.0 | 5% | 1.5 watt | Case MM ⁽²⁸⁾ | |
| 1N4490 | 110.0 | 2.3 | 300.0 | " | " | " | |
| 1N4491 | 120.0 | 2.0 | 400.0 | " | " | " | |
| 1N4492 | 130.0 | 1.9 | 500.0 | " | " | " | |
| 1N4493 | 150.0 | 1.7 | 700.0 | " | " | " | |
| 1N4494 | 160.0 | 1.6 | 1000.0 | " | " | " | |
| 1N4495 | 180.0 | 1.4 | 1300.0 | " | " | " | |
| 1N4496 | 200.0 | 1.2 | 1500.0 | " | " | " | |
| 1N4499 | 6.2 | 7.5 | 20.0 | 5% | 1 watt | DO-7 ⁽²⁸⁾ | 1N4735 |
| 1N4501 ⁽²⁾ | 6.7-7.4 | 10.0 | 10.0 | T.C. = .01%/°C ⁽⁴⁾ | 210 mw | Case GG ⁽²⁷⁾ | |
| 1N4503 | 33.0 | 20.0 | 21.0 | 10% | 3 watt | Case OO | |
| 1N4504 | 200.0 | 4.0 | 1000.0 | " | " | " | |
| 1N4535 | 3.45 ⁽¹⁾ | 10.0 | 65.0 ⁽²²⁾ | 5% | 500 mw | DO-7 | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(1) Double anode type

(2) Temperature compensated zener diode

(6) Temperature range -55°C to +100°C

(7) No suffix denotes temp. range 0°C to +75°C

Suffix A denotes temp. range -55°C to +100°C

(19) Low reverse leakage diode

(20) Low noise diode

(22) Extended current range devices

1N4611, 1.0-3.0 mA; 1N4612, 3.0-7.0 mA;

1N4613, 7.0-15 mA

(23) Special low current series

(27) Supplied by Microsemi in DO-7 Case

(28) Supplied by Microsemi in Case J (DO-41)

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------|------------------------------|---------------|--|--|-----------------|-------------------|--|
| | Volts | @ mA | | | | | |
| 1N4549 | 3.9 | 3200 | 0.16 | No Suffix = 20% Suffix A = 10%, Suffix B = 5% Suffix R = Rev. Polarity | 50 watt | DO-5 | |
| 1N4550 | 4.3 | 2900 | 0.16 | | " | " | |
| 1N4551 | 4.7 | 2650 | 0.12 | | " | " | |
| 1N4552 | 5.1 | 2450 | 0.12 | " " | " | " | |
| 1N4553 | 5.6 | 2250 | 0.12 | " " | " | " | |
| 1N4554 | 6.2 | 2000 | 0.14 | " " | " | " | |
| 1N4555 | 6.8 | 1850 | 0.16 | " " | " | " | |
| 1N4556 | 7.5 | 1650 | 0.24 | " " | " | " | |
| 1N4557 | 3.9 | 3200 | 0.16 | No Suffix = 20% Suffix A = 10%, Suffix B = 5% Suffix R = Rev. Polarity | 50 watt | TO-3 | |
| 1N4558 | 4.3 | 2900 | 0.16 | | " | " | |
| 1N4559 | 4.7 | 2650 | 0.12 | | " | " | |
| 1N4560 | 5.1 | 2450 | 0.12 | " " | " | " | |
| 1N4561 | 5.6 | 2250 | 0.12 | " " | " | " | |
| 1N4562 | 6.2 | 2000 | 0.14 | " " | " | " | |
| 1N4563 | 6.8 | 1850 | 0.16 | " " | " | " | |
| 1N4564 | 7.5 | 1650 | 0.24 | " " | " | " | |
| 1N4565(2,23) | 6.4 ± 5% | 0.5 | 200.0 | T.C. = .01% / °C(7) | 400 mw | DO-7 | |
| 1N4566(2,23) | 6.4 ± 5% | " | " | T.C. = .005% / °C(7) | " | " | |
| 1N4567(2,23) | 6.4 ± 5% | " | " | T.C. = .002% / °C(7) | " | " | |
| 1N4568(2,23) | 6.4 ± 5% | " | " | T.C. = .001% / °C(7) | " | " | |
| 1N4569(2,23) | 6.4 ± 5% | " | " | T.C. = .0005% / °C(7) | " | " | |
| 1N4570(2,23) | 6.4 ± 5% | 1.0 | 100.0 | T.C. = .01% / °C(7) | " | " | |
| 1N4571(2,23) | 6.4 ± 5% | " | " | T.C. = .005% / °C(7) | " | " | |
| 1N4572(2,23) | 6.4 ± 5% | " | " | T.C. = .002% / °C(7) | " | " | |
| 1N4573(2,23) | 6.4 ± 5% | " | " | T.C. = .001% / °C(7) | " | " | |
| 1N4574(2,23) | 6.4 ± 5% | " | " | T.C. = .0005% / °C(7) | " | " | |
| 1N4575(2,23) | 6.4 ± 5% | 2.0 | 50.0 | T.C. = .01% / °C(7) | " | " | |
| 1N4576(2,23) | 6.4 ± 5% | " | " | T.C. = .005% / °C(7) | " | " | |
| 1N4577(2,23) | 6.4 ± 5% | " | " | T.C. = .002% / °C(7) | " | " | |
| 1N4578(2,23) | 6.4 ± 5% | " | " | T.C. = .001% / °C(7) | " | " | |
| 1N4579(2,23) | 6.4 ± 5% | " | " | T.C. = .0005% / °C(7) | " | " | |
| 1N4580(2,23) | 6.4 ± 5% | 4.0 | 25.0 | T.C. = .01% / °C(7) | " | " | |
| 1N4581(2,23) | 6.4 ± 5% | " | " | T.C. = .005% / °C(7) | " | " | |
| 1N4582(2,23) | 6.4 ± 5% | " | " | T.C. = .002% / °C(7) | " | " | |
| 1N4583(2,23) | 6.4 ± 5% | " | " | T.C. = .001% / °C(7) | " | " | |
| 1N4584(2,23) | 6.4 ± 5% | " | " | T.C. = .0005% / °C(7) | " | " | |
| 1N4611(2) | 6.6 ± 5% | 2.0(22) | 75.0 | Suffix A = .0005% / °C | 250mw | DO-7 | |
| 1N4612(2) | 6.6 ± 5% | 5.0(22) | 25.0 | Suffix B = .001% / °C | " | " | |
| 1N4613(2) | 6.6 ± 5% | 10.0(22) | 15.0 | Suffix C = .002% / °C | " | " | |
| 1N4614(19,20) | 1.8 | 250.0 μ A | 1200.0 | ±5% | 250 mw | DO-7/DO-35 | |
| 1N4615(19,20) | 2.0 | " | 1250.0 | " | " | " | |
| 1N4616(19,20) | 2.2 | " | 1300.0 | " | " | " | |
| 1N4617(19,20) | 2.4 | " | 1400.0 | " | " | " | |
| 1N4618(19,20) | 2.7 | " | 1500.0 | " | " | " | |
| 1N4619(19,20) | 3.0 | " | 1600.0 | " | " | " | |
| 1N4620(19,20) | 3.3 | " | 1650.0 | " | " | " | |
| 1N4621(19,20) | 3.6 | " | 1700.0 | " | " | " | |
| 1N4622(19,20) | 3.9 | " | 1650.0 | " | " | " | |
| 1N4623(19,20) | 4.3 | " | 1600.0 | " | " | " | |
| 1N4624(19,20) | 4.7 | " | 1550.0 | " | " | " | |
| 1N4625(19,20) | 5.1 | " | 1500.0 | " | " | " | |
| 1N4626(19,20) | 5.6 | " | 1400.0 | " | " | " | |
| 1N4627(19,20) | 6.2 | " | 1200.0 | " | " | " | |
| 1N4628 | 6.8 | 18.5 | 4.5 | No Suffix = 5% | 600 mw | DO-7 | |
| 1N4629 | 7.5 | 16.5 | 5.5 | | " | " | |
| 1N4630 | 8.2 | 15.0 | 6.5 | | " | " | |
| 1N4631 | 9.1 | 14.0 | 7.5 | " | " | " | |
| 1N4632 | 10.0 | 12.5 | 8.5 | " | " | " | |
| 1N4633 | 11.0 | 11.5 | 9.5 | " | " | " | |
| 1N4634 | 12.0 | 10.5 | 11.5 | " | " | " | |
| 1N4635 | 13.0 | 9.5 | 13.0 | " | " | " | |
| 1N4636 | 15.0 | 8.5 | 16.0 | " | " | " | |
| 1N4637 | 16.0 | 7.8 | 17.0 | " | " | " | |
| 1N4638 | 18.0 | 7.0 | 21.0 | " | " | " | |
| 1N4639 | 20.0 | 6.2 | 25.0 | " | " | " | |
| 1N4640 | 22.0 | 5.6 | 29.0 | " | " | " | |
| 1N4641 | 24.0 | 5.2 | 33.0 | " | " | " | |
| 1N4642 | 27.0 | 4.6 | 41.0 | " | " | " | |
| 1N4643 | 30.0 | 4.2 | 49.0 | " | " | " | |
| 1N4644 | 33.0 | 3.8 | 58.0 | " | " | " | |
| 1N4645 | 36.0 | 3.4 | 70.0 | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------------------|-------------------------------------|------|---|-------------------------------|-----------------|-------------------------|--|
| | Volts | @ mA | | | | | |
| 1N4646 | 39.0 | 3.2 | 80.0 | No Suffix = 5% | 600 mw | DO-7 | |
| 1N4647 | 43.0 | 3.0 | 93.0 | " | " | " | |
| 1N4648 | 47.0 | 2.7 | 105.0 | " | " | " | |
| 1N4649 ⁽¹⁹⁾ | 3.3 | 76.0 | 10.0 | " | 1 watt | Case QQ ⁽²⁸⁾ | |
| 1N4650 ⁽¹⁹⁾ | 3.6 | 69.0 | 10.0 | " | " | " | |
| 1N4651 ⁽¹⁹⁾ | 3.9 | 64.0 | 9.0 | " | " | " | |
| 1N4652 ⁽¹⁹⁾ | 4.3 | 58.0 | 9.0 | " | " | " | |
| 1N4653 ⁽¹⁹⁾ | 4.7 | 53.0 | 8.0 | " | " | " | |
| 1N4654 ⁽¹⁹⁾ | 5.1 | 49.0 | 7.0 | " | " | " | |
| 1N4655 ⁽¹⁹⁾ | 5.6 | 45.0 | 5.0 | " | " | " | |
| 1N4656 ⁽¹⁹⁾ | 6.2 | 41.0 | 2.0 | " | " | " | |
| 1N4657 ⁽¹⁹⁾ | 6.8 | 37.0 | 3.5 | " | " | " | |
| 1N4658 ⁽¹⁹⁾ | 7.5 | 34.0 | 4.0 | No Suffix = 5% | 1 watt | Case QQ ⁽²⁸⁾ | |
| 1N4659 ⁽¹⁹⁾ | 8.2 | 31.0 | 4.5 | " | " | " | |
| 1N4660 ⁽¹⁹⁾ | 9.1 | 28.0 | 5.0 | " | " | " | |
| 1N4661 ⁽¹⁹⁾ | 10.0 | 25.0 | 7.0 | " | " | " | |
| 1N4662 ⁽¹⁹⁾ | 11.0 | 23.0 | 8.0 | " | " | " | |
| 1N4663 ⁽¹⁹⁾ | 12.0 | 21.0 | 9.0 | " | " | " | |
| 1N4664 ⁽¹⁹⁾ | 13.0 | 19.0 | 10.0 | " | " | " | |
| 1N4665 ⁽¹⁹⁾ | 15.0 | 17.0 | 14.0 | " | " | " | |
| 1N4666 ⁽¹⁹⁾ | 16.0 | 15.5 | 16.0 | " | " | " | |
| 1N4667 ⁽¹⁹⁾ | 18.0 | 14.0 | 20.0 | " | " | " | |
| 1N4668 ⁽¹⁹⁾ | 20.0 | 12.5 | 22.0 | " | " | " | |
| 1N4669 ⁽¹⁹⁾ | 22.0 | 11.5 | 23.0 | " | " | " | |
| 1N4670 ⁽¹⁹⁾ | 24.0 | 10.5 | 25.0 | " | " | " | |
| 1N4671 ⁽¹⁹⁾ | 27.0 | 9.5 | 35.0 | " | " | " | |
| 1N4672 ⁽¹⁹⁾ | 30.0 | 8.5 | 40.0 | " | " | " | |
| 1N4673 ⁽¹⁹⁾ | 33.0 | 7.5 | 45.0 | " | " | " | |
| 1N4674 ⁽¹⁹⁾ | 36.0 | 7.0 | 50.0 | " | " | " | |
| 1N4675 ⁽¹⁹⁾ | 39.0 | 6.5 | 60.0 | " | " | " | |
| 1N4676 ⁽¹⁹⁾ | 43.0 | 6.0 | 70.0 | " | " | " | |
| 1N4677 ⁽¹⁹⁾ | 47.0 | 5.5 | 80.0 | " | " | " | |
| 1N4678 ⁽²³⁾ | 1.8 | 0.05 | ⁽²⁴⁾ | No Suffix = 5% | 250 mw | DO-7/DO-35 | |
| 1N4679 ⁽²³⁾ | 2.0 | " | " | " | " | " | |
| 1N4680 ⁽²³⁾ | 2.2 | " | " | " | " | " | |
| 1N4681 ⁽²³⁾ | 2.4 | " | " | " | " | " | |
| 1N4682 ⁽²³⁾ | 2.7 | " | " | " | " | " | |
| 1N4683 ⁽²³⁾ | 3.0 | " | " | " | " | " | |
| 1N4684 ⁽²³⁾ | 3.3 | " | " | " | " | " | |
| 1N4685 ⁽²³⁾ | 3.6 | " | " | " | " | " | |
| 1N4686 ⁽²³⁾ | 3.9 | " | " | " | " | " | |
| 1N4687 ⁽²³⁾ | 4.3 | " | " | " | " | " | |
| 1N4688 ⁽²³⁾ | 4.7 | " | " | " | " | " | |
| 1N4689 ⁽²³⁾ | 5.1 | " | " | " | " | " | |
| 1N4690 ⁽²³⁾ | 5.6 | " | " | " | " | " | |
| 1N4691 ⁽²³⁾ | 6.2 | " | " | " | " | " | |
| 1N4692 ⁽²³⁾ | 6.8 | " | " | " | " | " | |
| 1N4693 ⁽²³⁾ | 7.5 | " | " | " | " | " | |
| 1N4694 ⁽²³⁾ | 8.2 | " | " | " | " | " | |
| 1N4695 ⁽²³⁾ | 8.7 | " | " | " | " | " | |
| 1N4696 ⁽²³⁾ | 9.1 | " | " | " | " | " | |
| 1N4697 ⁽²³⁾ | 10.0 | " | " | " | " | " | |
| 1N4698 ⁽²³⁾ | 11.0 | " | " | " | " | " | |
| 1N4699 ⁽²³⁾ | 12.0 | " | " | " | " | " | |
| 1N4700 ⁽²³⁾ | 13.0 | " | " | " | " | " | |
| 1N4701 ⁽²³⁾ | 14.0 | " | " | " | " | " | |
| 1N4702 ⁽²³⁾ | 15.0 | " | " | " | " | " | |
| 1N4703 ⁽²³⁾ | 16.0 | " | " | " | " | " | |
| 1N4704 ⁽²³⁾ | 17.0 | " | " | " | " | " | |
| 1N4705 ⁽²³⁾ | 18.0 | " | " | " | " | " | |
| 1N4706 ⁽²³⁾ | 19.0 | " | " | " | " | " | |
| 1N4707 ⁽²³⁾ | 20.0 | " | " | " | " | " | |
| 1N4708 ⁽²³⁾ | 22.0 | " | " | " | " | " | |
| 1N4709 ⁽²³⁾ | 24.0 | " | " | " | " | " | |
| 1N4710 ⁽²³⁾ | 25.0 | " | " | " | " | " | |
| 1N4711 ⁽²³⁾ | 27.0 | " | " | " | " | " | |
| 1N4712 ⁽²³⁾ | 28.0 | " | " | " | " | " | |
| 1N4713 ⁽²³⁾ | 30.0 | " | " | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(1) Double anode type

(2) Temperature compensated zener diode

(7) No suffix denotes temp. range 0°C to +75°C

Suffix A denotes temp. range -55°C to +100°C

(19) Low reverse leakage diode

(23) Special low current series

(24) Z_z specified in terms of voltage regulation

(28) Can be supplied by Microsemi in Case J (DO-41)

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|------------------------|------------------------------|------|--|-------------------------------|-----------------|-------------------------|--|
| 1N4714 ⁽²³⁾ | 33.0 | 0.05 | (24) | No Suffix = 5% | 250 mw | DO-7/DO-35 | |
| 1N4715 ⁽²³⁾ | 36.0 | " | " | " | " | " | |
| 1N4716 ⁽²³⁾ | 39.0 | " | " | " | " | " | |
| 1N4717 ⁽²³⁾ | 43.0 | " | " | " | " | " | |
| 1N4728 | 3.3 | 76.0 | 10.0 | No Suffix = 10% | 1 watt | Case J | |
| 1N4729 | 3.6 | 69.0 | 10.0 | Suffix A = 5% | " | or DO-41 | |
| 1N4730 | 3.9 | 64.0 | 9.0 | " | " | glass | |
| 1N4731 | 4.3 | 58.0 | 9.0 | " | " | " | |
| 1N4732 | 4.7 | 53.0 | 8.0 | " | " | " | |
| 1N4733 | 5.1 | 49.0 | 7.0 | " | " | " | |
| 1N4734 | 5.6 | 45.0 | 5.0 | " | " | " | |
| 1N4735 | 6.2 | 41.0 | 2.0 | " | " | " | |
| 1N4736 | 6.8 | 37.0 | 3.5 | " | " | " | |
| 1N4737 | 7.5 | 34.0 | 4.0 | No Suffix = 10% | 1 watt | Case J | |
| 1N4738 | 8.2 | 31.0 | 4.5 | Suffix A = 5% | " | or DO-41 | |
| 1N4739 | 9.1 | 28.0 | 5.0 | " | " | glass | |
| 1N4740 | 10.0 | 25.0 | 7.0 | " | " | " | |
| 1N4741 | 11.0 | 23.0 | 8.0 | " | " | " | |
| 1N4742 | 12.0 | 21.0 | 9.0 | " | " | " | |
| 1N4743 | 13.0 | 19.0 | 10.0 | " | " | " | |
| 1N4744 | 15.0 | 17.0 | 14.0 | " | " | " | |
| 1N4745 | 16.0 | 15.5 | 16.0 | " | " | " | |
| 1N4746 | 18.0 | 14.0 | 20.0 | " | " | " | |
| 1N4747 | 20.0 | 12.5 | 22.0 | " | " | " | |
| 1N4748 | 22.0 | 11.5 | 23.0 | " | " | " | |
| 1N4749 | 24.0 | 10.5 | 25.0 | " | " | " | |
| 1N4750 | 27.0 | 9.5 | 35.0 | " | " | " | |
| 1N4751 | 30.0 | 8.5 | 40.0 | " | " | " | |
| 1N4752 | 33.0 | 7.5 | 45.0 | " | " | " | |
| 1N4753 | 36.0 | 7.0 | 50.0 | " | " | " | |
| 1N4754 | 39.0 | 6.5 | 60.0 | " | " | " | |
| 1N4755 | 43.0 | 6.0 | 70.0 | " | " | " | |
| 1N4756 | 47.0 | 5.5 | 80.0 | " | " | " | |
| 1N4757 | 51.0 | 5.0 | 95.0 | " | " | " | |
| 1N4758 | 56.0 | 4.5 | 110.0 | " | " | " | |
| 1N4759 | 62.0 | 4.0 | 125.0 | " | " | " | |
| 1N4760 | 68.0 | 3.7 | 150.0 | " | " | " | |
| 1N4761 | 75.0 | 3.3 | 175.0 | " | " | " | |
| 1N4762 | 82.0 | 3.0 | 200.0 | " | " | " | |
| 1N4763 | 91.0 | 2.8 | 250.0 | " | " | " | |
| 1N4764 | 100.0 | 2.5 | 350.0 | " | " | " | |
| 1N4765 ⁽²⁾ | 9.1 ± 5% | 0.5 | 350.0 | .01% / °C ⁽⁷⁾ | 250 mw | DO-7 | |
| 1N4766 ⁽²⁾ | 9.1 ± 5% | " | " | .005% / °C ⁽⁷⁾ | " | " | |
| 1N4767 ⁽²⁾ | 9.1 ± 5% | " | " | .002% / °C ⁽⁷⁾ | " | " | |
| 1N4768 ⁽²⁾ | 9.1 ± 5% | " | " | .001% / °C ⁽⁷⁾ | " | " | |
| 1N4769 ⁽²⁾ | 9.1 ± 5% | " | " | .0005% / °C ⁽⁷⁾ | " | " | |
| 1N4770 ⁽²⁾ | 9.1 ± 5% | 1.0 | 200.0 | .01% / °C ⁽⁷⁾ | " | " | |
| 1N4771 ⁽²⁾ | 9.1 ± 5% | " | " | .005% / °C ⁽⁷⁾ | " | " | |
| 1N4772 ⁽²⁾ | 9.1 ± 5% | " | " | .002% / °C ⁽⁷⁾ | " | " | |
| 1N4773 ⁽²⁾ | 9.1 ± 5% | " | " | .001% / °C ⁽⁷⁾ | " | " | |
| 1N4774 ⁽²⁾ | 9.1 ± 5% | " | " | .0005% / °C ⁽⁷⁾ | " | " | |
| 1N4775 ⁽²⁾ | 8.5 ± 5% | 0.5 | 200.0 | .01% / °C ⁽⁷⁾ | 250 mw | DO-7 | |
| 1N4776 ⁽²⁾ | 8.5 ± 5% | " | " | .005% / °C ⁽⁷⁾ | " | " | |
| 1N4777 ⁽²⁾ | 8.5 ± 5% | " | " | .002% / °C ⁽⁷⁾ | " | " | |
| 1N4778 ⁽²⁾ | 8.5 ± 5% | " | " | .001% / °C ⁽⁷⁾ | " | " | |
| 1N4779 ⁽²⁾ | 8.5 ± 5% | " | " | .0005% / °C ⁽⁷⁾ | " | " | |
| 1N4780 ⁽²⁾ | 8.5 ± 5% | 1.0 | 100.0 | .01% / °C ⁽⁷⁾ | " | " | |
| 1N4781 ⁽²⁾ | 8.5 ± 5% | " | " | .005% / °C ⁽⁷⁾ | " | " | |
| 1N4782 ⁽²⁾ | 8.5 ± 5% | " | " | .002% / °C ⁽⁷⁾ | " | " | |
| 1N4783 ⁽²⁾ | 8.5 ± 5% | " | " | .001% / °C ⁽⁷⁾ | " | " | |
| 1N4784 ⁽²⁾ | 8.5 ± 5% | " | " | .0005% / °C ⁽⁷⁾ | " | " | |
| 1N4831 | 9.1 | 28.0 | 8.0 | No Suffix = 20% | 1.2 watt | Case FF ⁽²⁸⁾ | |
| 1N4832 | 10.0 | 25.0 | 9.0 | Suffix A = 10% | " | " | |
| 1N4833 | 11.0 | 23.0 | 10.0 | Suffix B = 5% | " | " | |
| 1N4834 | 12.0 | 21.0 | 12.0 | Double Anode | " | " | |
| 1N4835 | 13.0 | 19.0 | 15.0 | " | " | " | |
| 1N4836 | 15.0 | 17.0 | 17.0 | " | " | " | |
| 1N4837 | 16.0 | 16.0 | 19.0 | " | " | " | |
| 1N4838 | 18.0 | 14.0 | 20.0 | " | " | " | |
| 1N4839 | 20.0 | 12.5 | 22.0 | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------|-------------------------------------|--------|---|-------------------------------|-----------------|-------------------|--|
| 1N4840 | 22.0 | 11.3 | 23.0 | Double Anode | 1.2 watt | Case FF (28) | |
| 1N4841 | 24.0 | 10.5 | 25.0 | " " | " | " | |
| 1N4842 | 27.0 | 9.3 | 35.0 | " " | " | " | |
| 1N4843 | 30.0 | 8.3 | 40.0 | " " | " | " | |
| 1N4844 | 33.0 | 7.5 | 45.0 | " " | " | " | |
| 1N4845 | 36.0 | 7.0 | 50.0 | " " | " | " | |
| 1N4846 | 39.0 | 6.5 | 60.0 | " " | " | " | |
| 1N4847 | 43.0 | 5.8 | 70.0 | " " | " | " | |
| 1N4848 | 47.0 | 5.3 | 80.0 | " " | " | " | |
| 1N4849 | 51.0 | 5.0 | 95.0 | " " | " | " | |
| 1N4850 | 56.0 | 4.5 | 110.0 | " " | " | " | |
| 1N4851 | 62.0 | 4.0 | 125.0 | No Suffix = 20% | 1.2 watt | Case FF (28) | |
| 1N4852 | 68.0 | 3.7 | 150.0 | Suffix A = 10% | " | " | |
| 1N4853 | 75.0 | 3.3 | 175.0 | Suffix B = 5% | " | " | |
| 1N4854 | 82.0 | 3.0 | 200.0 | Double Anode | " | " | |
| 1N4855 | 91.0 | 2.8 | 250.0 | " " | " | " | |
| 1N4856 | 100.0 | 2.5 | 350.0 | " " | " | " | |
| 1N4857 | 110.0 | 2.3 | 450.0 | " " | " | " | |
| 1N4858 | 120.0 | 2.1 | 550.0 | " " | " | " | |
| 1N4859 | 130.0 | 1.9 | 700.0 | " " | " | " | |
| 1N4860 | 150.0 | 1.7 | 100.0 | " " | " | " | |
| 1N4881 | 20.0 | 40.0 | 9.0 | ±10% | 3 watt | Case LL (28) | |
| 1N4882 | 36.0 | 20.0 | 21.0 | ±10% | " | " | |
| 1N4883 | 12.0 | 65.0 | 5.0 | ±5% | " | " | |
| 1N4884 | 20.0 | 40.0 | 9.0 | ±5% | " | " | |
| 1N4889 | 62.0 | 20.0 | 42.5 | ±5% | 5 watt | Case RR | 1N5372 |
| 1N4890 (2,18) | 6.35v ± 5% | 7.5 mA | 10.0 | .001% / °C (13,26) | 400 mw | DO-7 | |
| 1N4891 (2,18) | " | " | " | .0005% / °C (13,26) | " | " | |
| 1N4892 (2,18) | " | " | " | .001% / °C (13,26) | " | " | |
| 1N4893 (2,18) | " | " | " | .0005% / °C (13,26) | " | " | |
| 1N4894 (2,18) | " | " | " | .001% / °C (13,26) | " | " | |
| 1N4895 (2,18) | " | " | " | .0005% / °C (13,26) | " | " | |
| 1N4896 (2,20) | 12.8v ± 5% | 0.5 | 400.0 | .01% / °C (13) | 400mw | DO-7 | |
| 1N4897 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4898 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4899 (2,20) | " | " | " | .001% / °C (13) | " | " | |
| 1N4900 (2,20) | " | 1.0 | 200.0 | .01% / °C (13) | " | " | |
| 1N4901 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4902 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4903 (2,20) | " | " | " | .001% / °C (13) | " | " | |
| 1N4904 (2,20) | " | 2.0 | 100.0 | .01% / °C (13) | " | " | |
| 1N4905 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4906 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4907 (2,20) | " | " | " | .001% / °C (13) | " | " | |
| 1N4908 (2,20) | " | 4.0 | 50.0 | .01% / °C (13) | " | " | |
| 1N4909 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4910 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4911 (2,20) | " | " | " | .001% / °C (13) | " | " | |
| 1N4912 (2,20) | " | 7.5 | 25.0 | .01% / °C (13) | " | " | |
| 1N4913 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4914 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4915 (2,20) | " | " | " | .001% / °C (13) | " | " | |
| 1N4916 (2,20) | 19.2v ± 5% | 0.5 | 600.0 | .01% / °C (13) | " | " | |
| 1N4917 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4918 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4919 (2,20) | " | 1.0 | 300.0 | .01% / °C (13) | " | " | |
| 1N4920 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4921 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4922 (2,20) | " | 2.0 | 150.0 | .01% / °C (13) | " | " | |
| 1N4923 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4924 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4925 (2,20) | " | 4.0 | 75.0 | .01% / °C (13) | " | " | |
| 1N4926 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4927 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4928 (2,20) | " | " | " | .001% / °C (13) | " | " | |
| 1N4929 (2,20) | " | 7.5 | 36.0 | .01% / °C (13) | " | " | |
| 1N4930 (2,20) | " | " | " | .005% / °C (13) | " | " | |
| 1N4931 (2,20) | " | " | " | .002% / °C (13) | " | " | |
| 1N4932 (2,20) | " | " | " | .001% / °C (13) | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(1) Double anode type

(2) Temperature compensated zener diode

(13) No suffix denotes temp. range 25 to 100°C

"A" Suffix denotes temp. range -55° to +100°C

(18) Certified voltage time stability

(20) Low noise diode

(26) 1N4890 & 91 have a certified voltage time stability of 50ppm

1N4892 & 93 have a certified voltage time stability of 20ppm

1N4894 & 95 have a certified voltage time stability of 10ppm

(28) Can be supplied by Microsemi in Case J (DO-41)

| Type No. | PIV | Io 25°C | VF | IR | T _{RR} | Device Package | MICROSEMI Recommended Substitute |
|-----------------|----------------------------------|---------|---|-------------------------|-----------------|----------------|----------------------------------|
| | Volts | Amps | Volts | μA | | | |
| 1N4938-1 | 200 | .1 | 1.0 | .10 | | B | |
| | | (55°C)A | | | (n sec.) | | |
| 1N4942 | 200 | 1.0 | 1.3 | 1.0 | 150 | A | |
| 1N4944 | 400 | 1.0 | 1.3 | 1.0 | 150 | A | |
| 1N4946 | 600 | 1.0 | 1.3 | 1.0 | 250 | A | |
| 1N4947 | 800 | 1.0 | 1.3 | 1.0 | 250 | A | |
| 1N4948 | 1000 | 1.0 | 1.3 | 1.0 | 500 | A | |
| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N4954 | 6.8 | 175.0 | 1.0 | ± 5% | 5 watt | Case VV | |
| 1N4955 | 7.5 | " | 1.5 | " | " | " | |
| 1N4956 | 8.2 | 150.0 | " | " | " | " | |
| 1N4957 | 9.1 | " | 2.0 | " | " | " | |
| 1N4958 | 10.0 | 125.0 | " | " | " | " | |
| 1N4959 | 11.0 | " | 2.5 | " | " | " | |
| 1N4960 | 12.0 | 100.0 | " | " | " | " | |
| 1N4961 | 13.0 | " | 3.0 | " | " | " | |
| 1N4962 | 15.0 | 75.0 | 3.5 | " | " | " | |
| 1N4963 | 16.0 | " | " | " | " | " | |
| 1N4964 | 18.0 | 65.0 | 4.0 | " | " | " | |
| 1N4965 | 20.0 | " | 4.5 | " | " | " | |
| 1N4966 | 22.0 | 50.0 | 5.0 | " | " | " | |
| 1N4967 | 24.0 | " | " | " | " | " | |
| 1N4968 | 27.0 | " | 6.0 | " | " | " | |
| 1N4969 | 30.0 | 40.0 | 8.0 | " | " | " | |
| 1N4970 | 33.0 | " | 10.0 | " | " | " | |
| 1N4971 | 36.0 | 30.0 | 11.0 | " | " | " | |
| 1N4972 | 39.0 | " | 14.0 | " | " | " | |
| 1N4973 | 43.0 | " | 20.0 | " | " | " | |
| 1N4974 | 47.0 | 25.0 | 25.0 | " | " | " | |
| 1N4975 | 51.0 | " | 27.0 | " | " | " | |
| 1N4976 | 56.0 | 20.0 | 35.0 | " | " | " | |
| 1N4977 | 62.0 | " | 42.0 | " | " | " | |
| 1N4978 | 68.0 | " | 44.0 | " | " | " | |
| 1N4979 | 75.0 | " | 45.0 | " | " | " | |
| 1N4980 | 82.0 | 15.0 | 65.0 | " | " | " | |
| 1N4981 | 91.0 | " | 75.0 | " | " | " | |
| 1N4982 | 100.0 | 12.0 | 90.0 | " | " | " | |
| 1N4983 | 110.0 | " | 125.0 | " | " | " | |
| 1N4984 | 120.0 | 10.0 | 170.0 | " | " | " | |
| 1N4985 | 130.0 | " | 190.0 | " | " | " | |
| 1N4986 | 150.0 | 8.0 | 330.0 | " | " | " | |
| 1N4987 | 160.0 | " | 350.0 | " | " | " | |
| 1N4988 | 180.0 | 5.0 | 430.0 | " | " | " | |
| 1N4989 | 200.0 | " | 480.0 | " | " | " | |
| 1N4990 | 220.0 | " | 550.0 | " | " | " | |
| 1N4991 | 240.0 | " | 650.0 | " | " | " | |
| 1N4992 | 270.0 | " | 800.0 | " | " | " | |
| 1N4993 | 300.0 | 4.0 | 950.0 | " | " | " | |
| 1N4994 | 330.0 | " | 1175.0 | " | " | " | |
| 1N4995 | 360.0 | 3.0 | 1400.0 | " | " | " | |
| 1N4996 | 390.0 | " | 1800.0 | " | " | " | |
| 1N5008 | 3.3 | 189.0 | 6.0 | No Suffix = 10% | 2.5 watt | Case SS | |
| 1N5009 | 3.6 | 173.0 | 5.5 | A Suffix = 5% | " | " | |
| 1N5010 | 3.9 | 160.0 | 5.0 | " | " | " | |
| 1N5011 | 4.3 | 145.0 | 4.0 | " " | " | " | |
| 1N5012 | 4.7 | 133.0 | 3.5 | " " | " | " | |
| 1N5013 | 5.1 | 122.0 | 3.0 | " " | " | " | |
| 1N5014 | 5.6 | 111.0 | 2.5 | " " | " | " | |
| 1N5015 | 6.2 | 101.0 | 3.0 | " " | " | " | |
| 1N5016 | 6.8 | 92.0 | 1.6 | " " | " | " | |
| 1N5017 | 7.5 | 83.0 | 1.8 | " " | " | " | |
| 1N5018 | 8.2 | 76.0 | 2.1 | " " | " | " | |
| 1N5019 | 9.1 | 69.0 | 2.4 | " " | " | " | |
| 1N5020 | 10.0 | 62.0 | 3.0 | " " | " | " | |
| 1N5021 | 11.0 | 57.0 | 3.6 | " " | " | " | |
| 1N5022 | 12.0 | 52.0 | 4.2 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------|-------------------------------------|------|---|-------------------------------|-----------------|-------------------------|--|
| | Volts | @ mA | | | | | |
| 1N5023 | 13.0 | 48.0 | 4.8 | No Suffix = 10% | 2.5 watt | Case SS | |
| 1N5024 | 14.0 | 45.0 | 5.4 | A Suffix = 5% | " | " | |
| 1N5025 | 15.0 | 42.0 | 6.0 | " " | " | " | |
| 1N5026 | 16.0 | 39.0 | 6.6 | " " | " | " | |
| 1N5027 | 17.0 | 37.0 | 7.2 | " " | " | " | |
| 1N5028 | 18.0 | 35.0 | 7.8 | " " | " | " | |
| 1N5029 | 19.0 | 33.0 | 8.4 | No Suffix = 10% | 2.5 watt | Case SS | |
| 1N5030 | 20.0 | 31.0 | 9.0 | A Suffix = 5% | " | " | |
| 1N5031 | 22.0 | 28.0 | 9.6 | " " | " | " | |
| 1N5032 | 24.0 | 26.0 | 10.0 | " " | " | " | |
| 1N5033 | 25.0 | 25.0 | 11.0 | " " | " | " | |
| 1N5034 | 27.0 | 23.0 | 12.0 | " " | " | " | |
| 1N5035 | 30.0 | 21.0 | 15.0 | " " | " | " | |
| 1N5036 | 33.0 | 19.0 | 18.0 | " " | " | " | |
| 1N5037 | 36.0 | 17.0 | 21.0 | " " | " | " | |
| 1N5038 | 39.0 | 16.0 | 24.0 | " " | " | " | |
| 1N5039 | 43.0 | 15.0 | 27.0 | " " | " | " | |
| 1N5040 | 45.0 | 14.0 | 30.0 | " " | " | " | |
| 1N5041 | 47.0 | 13.0 | 33.0 | " " | " | " | |
| 1N5042 | 50.0 | 12.0 | 36.0 | " " | " | " | |
| 1N5043 | 51.0 | 12.0 | 36.0 | " " | " | " | |
| 1N5044 | 52.0 | 12.0 | 39.0 | " " | " | " | |
| 1N5045 | 56.0 | 11.0 | 45.0 | " " | " | " | |
| 1N5046 | 62.0 | 10.0 | 51.0 | " " | " | " | |
| 1N5047 | 68.0 | 9.2 | 57.0 | " " | " | " | |
| 1N5048 | 75.0 | 8.3 | 66.0 | " " | " | " | |
| 1N5049 | 82.0 | 7.6 | 78.0 | " " | " | " | |
| 1N5050 | 91.0 | 6.9 | 90.0 | " " | " | " | |
| 1N5051 | 100.0 | 6.2 | 120.0 | " " | " | " | |
| 1N5063 | 6.8 | 75.0 | 2.0 | ±5% | 3 watt | Case UU ⁽²⁸⁾ | |
| 1N5064 | 7.5 | " | " | " | " | " | |
| 1N5065 | 8.2 | " | 3.0 | " | " | " | |
| 1N5066 | 9.1 | " | " | " | " | " | |
| 1N5067 | 10.0 | " | 4.0 | " | " | " | |
| 1N5068 | 11.0 | 70.0 | 5.0 | " | " | " | |
| 1N5069 | 13.0 | 50.0 | 6.0 | " | " | " | |
| 1N5070 | 14.0 | " | " | " | " | " | |
| 1N5071 | 15.0 | " | " | " | " | " | |
| 1N5072 | 16.0 | " | 7.0 | " | " | " | |
| 1N5073 | 18.0 | 40.0 | 8.0 | " | " | " | |
| 1N5074 | 22.0 | 30.0 | 10.0 | " | " | " | |
| 1N5075 | 24.0 | " | " | " | " | " | |
| 1N5076 | 27.0 | 25.0 | 12.0 | " | " | " | |
| 1N5077 | 30.0 | " | 15.0 | " | " | " | |
| 1N5078 | 33.0 | 20.0 | 21.0 | " | " | " | |
| 1N5079 | 36.0 | " | " | " | " | " | |
| 1N5080 | 39.0 | " | 27.0 | " | " | " | |
| 1N5081 | 40.0 | " | " | " | " | " | |
| 1N5082 | 43.0 | 15.0 | 35.0 | " | " | " | |
| 1N5083 | 45.0 | " | 37.0 | " | " | " | |
| 1N5084 | 47.0 | " | 43.0 | " | " | " | |
| 1N5085 | 50.0 | " | 50.0 | " | " | " | |
| 1N5086 | 51.0 | " | " | " | " | " | |
| 1N5087 | 56.0 | 10.0 | 70.0 | " | " | " | |
| 1N5088 | 60.0 | " | " | " | " | " | |
| 1N5089 | 62.0 | " | 75.0 | " | " | " | |
| 1N5090 | 68.0 | " | 85.0 | " | " | " | |
| 1N5091 | 70.0 | " | 90.0 | " | " | " | |
| 1N5092 | 75.0 | " | 100.0 | " | " | " | |
| 1N5093 | 80.0 | " | 115.0 | " | " | " | |
| 1N5094 | 82.0 | " | 120.0 | " | " | " | |
| 1N5095 | 91.0 | 8.0 | 155.0 | " | " | " | |
| 1N5096 | 110.0 | 5.0 | 250.0 | " | " | " | |
| 1N5097 | 120.0 | " | 325.0 | " | " | " | |
| 1N5098 | 130.0 | " | 375.0 | " | " | " | |
| 1N5099 | 140.0 | " | 550.0 | " | " | " | |
| 1N5100 | 160.0 | 4.0 | 700.0 | " | " | " | |
| 1N5101 | 170.0 | " | 750.0 | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low reverse leakage diode

(28) Supplied by Microsemi in Case J (DO-41)

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|------------------------|------------------------------|------------|--|-------------------------------|-----------------|-------------------------|--|
| 1N5102 | 180.0 | 4.0 | 850.0 | ±5% | 3 watt | Case UU ⁽²⁸⁾ | |
| 1N5103 | 190.0 | " | 900.0 | " | " | " | |
| 1N5104 | 200.0 | " | 950.0 | " | " | " | |
| 1N5105 | 220.0 | 3.0 | 1100.0 | ±5% | 3 watt | Case UU | |
| 1N5106 | 240.0 | " | 1300.0 | " | " | " | |
| 1N5107 | 260.0 | " | 1500.0 | " | " | " | |
| 1N5108 | 270.0 | " | 1600.0 | " | " | " | |
| 1N5109 | 280.0 | " | 1700.0 | " | " | " | |
| 1N5110 | 300.0 | " | 1900.0 | " | " | " | |
| 1N5111 | 320.0 | 2.0 | 2100.0 | " | " | " | |
| 1N5112 | 330.0 | " | 2250.0 | " | " | " | |
| 1N5113 | 340.0 | " | 2400.0 | " | " | " | |
| 1N5114 | 360.0 | " | 2700.0 | " | " | " | |
| 1N5115 | 380.0 | " | 3000.0 | " | " | " | |
| 1N5116 | 390.0 | " | 3250.0 | " | " | " | |
| 1N5117 | 400.0 | " | 3500.0 | " | " | " | |
| 1N5118 | 14.0 | 100.0 | 3.0 | " | 5 watt | Case VV | |
| 1N5119 | 40.0 | 30.0 | 14.0 | " | " | " | |
| 1N5120 | 45.0 | " | 20.0 | " | " | " | |
| 1N5121 | 50.0 | 25.0 | 25.0 | " | " | " | |
| 1N5122 | 60.0 | 20.0 | 40.0 | " | " | " | |
| 1N5123 | 70.0 | " | 45.0 | " | " | " | |
| 1N5124 | 80.0 | 15.0 | 60.0 | " | " | " | |
| 1N5125 | 90.0 | " | 75.0 | " | " | " | |
| 1N5126 | 140.0 | 8.0 | 230.0 | " | " | " | |
| 1N5127 | 170.0 | " | 380.0 | " | " | " | |
| 1N5128 | 190.0 | 5.0 | 450.0 | " | " | " | |
| 1N5129 | 260.0 | " | 650.0 | " | " | " | |
| 1N5130 | 280.0 | 4.0 | 850.0 | " | " | " | |
| 1N5131 | 320.0 | " | 1100.0 | " | " | " | |
| 1N5132 | 340.0 | " | 1200.0 | " | " | " | |
| 1N5133 | 380.0 | 3.0 | 1500.0 | " | " | " | |
| 1N5134 | 400.0 | " | 1800.0 | " | " | " | |
| Type No. | PIV | I_o 25°C | VF | IR | T_{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| 1N5194 | 80 | .2 | 1.0 | .025 | | D035 | |
| 1N5195 | 200 | .2 | 1.0 | .025 | | D035 | |
| 1N5196 | 250 | .2 | 1.0 | .025 | | D035 | |
| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| 1N5221 ⁽¹⁹⁾ | 2.4 | 20.0 | 30.0 | No Suffix = 20% | 500mw | DO-7/DO-35 | |
| 1N5222 ⁽¹⁹⁾ | 2.5 | " | " | Suffix A = 10% | " | " | |
| 1N5223 ⁽¹⁹⁾ | 2.7 | " | " | Suffix B = 5% | " | " | |
| 1N5224 ⁽¹⁹⁾ | 2.8 | " | " | " | " | " | |
| 1N5225 ⁽¹⁹⁾ | 3.0 | " | 29.0 | " | " | " | |
| 1N5226 ⁽¹⁹⁾ | 3.3 | " | 28.0 | " | " | " | |
| 1N5227 ⁽¹⁹⁾ | 3.6 | " | 24.0 | " | " | " | |
| 1N5228 ⁽¹⁹⁾ | 3.9 | " | 23.0 | " | " | " | |
| 1N5229 ⁽¹⁹⁾ | 4.3 | " | 22.0 | " | " | " | |
| 1N5230 ⁽¹⁹⁾ | 4.7 | " | 19.0 | " | " | " | |
| 1N5231 ⁽¹⁹⁾ | 5.1 | " | 17.0 | " | " | " | |
| 1N5232 ⁽¹⁹⁾ | 5.6 | " | 11.0 | " | " | " | |
| 1N5233 ⁽¹⁹⁾ | 6.0 | " | 7.0 | " | " | " | |
| 1N5234 ⁽¹⁹⁾ | 6.2 | " | " | " | " | " | |
| 1N5235 ⁽¹⁹⁾ | 6.8 | " | 5.0 | " | " | " | |
| 1N5236 ⁽¹⁹⁾ | 7.5 | " | 6.0 | " | " | " | |
| 1N5237 ⁽¹⁹⁾ | 8.2 | " | 8.0 | " | " | " | |
| 1N5238 ⁽¹⁹⁾ | 8.7 | " | " | " | " | " | |
| 1N5239 ⁽¹⁹⁾ | 9.1 | " | 10.0 | " | " | " | |
| 1N5240 ⁽¹⁹⁾ | 10.0 | " | 17.0 | " | " | " | |
| 1N5241 ⁽¹⁹⁾ | 11.0 | " | 22.0 | " | " | " | |
| 1N5242 ⁽¹⁹⁾ | 12.0 | " | 30.0 | " | " | " | |
| 1N5243 ⁽¹⁹⁾ | 13.0 | 9.5 | 13.0 | " | " | " | |
| 1N5244 ⁽¹⁹⁾ | 14.0 | 9.0 | 15.0 | " | " | " | |
| 1N5245 ⁽¹⁹⁾ | 15.0 | 8.5 | 16.0 | " | " | " | |
| 1N5246 ⁽¹⁹⁾ | 16.0 | 7.8 | 17.0 | " | " | " | |
| 1N5247 ⁽¹⁹⁾ | 17.0 | 7.4 | 19.0 | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------------------|-------------------------------------|------|---|-------------------------------|-----------------|---------------------------|--|
| | Volts | @ mA | | | | | |
| 1N5248 ⁽¹⁹⁾ | 18.0 | 7.0 | 21.0 | No Suffix = 20% | 500mw | DO-7/DO-35 | |
| 1N5249 ⁽¹⁹⁾ | 19.0 | 6.6 | 23.0 | Suffix A = 10% | " | " | |
| 1N5250 ⁽¹⁹⁾ | 20.0 | 6.2 | 25.0 | Suffix B = 5% | " | " | |
| 1N5251 ⁽¹⁹⁾ | 22.0 | 5.6 | 29.0 | " " | " | " | |
| 1N5252 ⁽¹⁹⁾ | 24.0 | 5.2 | 33.0 | " " | " | " | |
| 1N5253 ⁽¹⁹⁾ | 25.0 | 5.0 | 35.0 | " " | " | " | |
| 1N5254 ⁽¹⁹⁾ | 27.0 | 4.6 | 41.0 | " " | " | " | |
| 1N5255 ⁽¹⁹⁾ | 28.0 | 4.5 | 44.0 | " " | " | " | |
| 1N5256 ⁽¹⁹⁾ | 30.0 | 4.2 | 49.0 | " " | " | " | |
| 1N5257 ⁽¹⁹⁾ | 33.0 | 3.8 | 58.0 | No Suffix = 20% | 500mw | DO-7/DO-35 | |
| 1N5258 ⁽¹⁹⁾ | 36.0 | 3.4 | 70.0 | Suffix A = 10% | " | " | |
| 1N5259 ⁽¹⁹⁾ | 39.0 | 3.2 | 80.0 | Suffix B = 5% | " | " | |
| 1N5260 ⁽¹⁹⁾ | 43.0 | 3.0 | 93.0 | " " | " | " | |
| 1N5261 ⁽¹⁹⁾ | 47.0 | 2.7 | 105.0 | " " | " | " | |
| 1N5262 ⁽¹⁹⁾ | 51.0 | 2.5 | 125.0 | " " | " | " | |
| 1N5263 ⁽¹⁹⁾ | 56.0 | 2.2 | 150.0 | " " | " | " | |
| 1N5264 ⁽¹⁹⁾ | 60.0 | 2.1 | 170.0 | " " | " | " | |
| 1N5265 ⁽¹⁹⁾ | 62.0 | 2.0 | 185.0 | " " | " | " | |
| 1N5266 ⁽¹⁹⁾ | 68.0 | 1.8 | 230.0 | " " | " | " | |
| 1N5267 ⁽¹⁹⁾ | 75.0 | 1.7 | 270.0 | " " | " | " | |
| 1N5268 ⁽¹⁹⁾ | 82.0 | 1.5 | 330.0 | " " | " | " | |
| 1N5269 ⁽¹⁹⁾ | 87.0 | 1.4 | 370.0 | " " | " | " | |
| 1N5270 ⁽¹⁹⁾ | 91.0 | " | 400.0 | " " | " | " | |
| 1N5271 ⁽¹⁹⁾ | 100.0 | 1.3 | 500.0 | " " | " | " | |
| 1N5272 ⁽¹⁹⁾ | 110.0 | 1.1 | 750.0 | " " | " | " | |
| 1N5273 ⁽¹⁹⁾ | 120.0 | 1.0 | 900.0 | " " | " | " | |
| 1N5274 ⁽¹⁹⁾ | 130.0 | 0.95 | 1100.0 | " " | " | " | |
| 1N5275 ⁽¹⁹⁾ | 140.0 | 0.90 | 1300.0 | " " | " | " | |
| 1N5276 ⁽¹⁹⁾ | 150.0 | 0.85 | 1500.0 | " " | " | " | |
| 1N5277 ⁽¹⁹⁾ | 160.0 | 0.80 | 1700.0 | " " | " | " | |
| 1N5278 ⁽¹⁹⁾ | 170.0 | 0.74 | 1900.0 | " " | " | " | |
| 1N5279 ⁽¹⁹⁾ | 180.0 | 0.68 | 2200.0 | " " | " | " | |
| 1N5280 ⁽¹⁹⁾ | 190.0 | 0.66 | 2400.0 | " " | " | " | |
| 1N5281 ⁽¹⁹⁾ | 200.0 | 0.65 | 2500.0 | " " | " | " | |
| 1N5333 | 3.3 | 380 | 3.0 | No Suffix = 20% | 5 watt | A1ee ^{(30) (31)} | |
| 1N5334 | 3.6 | 350 | 2.5 | Suffix A = 10% | " | " | |
| 1N5335 | 3.9 | 320 | 2.0 | Suffix B = 5% | " | " | |
| 1N5336 | 4.3 | 290 | 2.0 | " " | " | " | |
| 1N5337 | 4.7 | 260 | 2.0 | " " | " | " | |
| 1N5338 | 5.1 | 240 | 1.5 | " " | " | " | |
| 1N5339 | 5.6 | 220 | 1.0 | " " | " | " | |
| 1N5340 | 6.0 | 200 | 1.0 | " " | " | " | |
| 1N5341 | 6.2 | 200 | 1.0 | " " | " | " | |
| 1N5342 | 6.8 | 175 | 1.0 | " " | " | " | |
| 1N5343 | 7.5 | 175 | 1.5 | " " | " | " | |
| 1N5344 | 8.2 | 150 | 1.5 | " " | " | " | |
| 1N5345 | 8.7 | 150 | 2.0 | " " | " | " | |
| 1N5346 | 9.1 | 150 | 2.0 | " " | " | " | |
| 1N5347 | 10 | 125 | 2.0 | " " | " | " | |
| 1N5348 | 11 | 125 | 2.5 | " " | " | " | |
| 1N5349 | 12 | 100 | 2.5 | " " | " | " | |
| 1N5350 | 13 | 100 | 2.5 | " " | " | " | |
| 1N5351 | 14 | 100 | 2.5 | " " | " | " | |
| 1N5352 | 15 | 75 | 2.5 | " " | " | " | |
| 1N5353 | 16 | 75 | 2.5 | " " | " | " | |
| 1N5354 | 17 | 70 | 2.5 | " " | " | " | |
| 1N5355 | 18 | 65 | 2.5 | " " | " | " | |
| 1N5356 | 19 | 65 | 3.0 | " " | " | " | |
| 1N5357 | 20 | 65 | 3.0 | " " | " | " | |
| 1N5358 | 22 | 50 | 3.5 | " " | " | " | |
| 1N5359 | 24 | 50 | 3.5 | " " | " | " | |
| 1N5360 | 25 | 50 | 4.0 | " " | " | " | |
| 1N5361 | 27 | 50 | 5.0 | " " | " | " | |
| 1N5362 | 28 | 50 | 6.0 | " " | " | " | |
| 1N5363 | 30 | 40 | 8.0 | " " | " | " | |
| 1N5364 | 33 | 40 | 10 | " " | " | " | |
| 1N5365 | 36 | 30 | 11 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low leakage series.

(20) Low noise series.

(28) Supplied by Microsemi in Case J (DO-41).

(30) This is the package referenced in the Autumn 1972 Semiconductor Diode & SCR D.A.T.A. book.

(31) Supplied by Microsemi in Case T-18 which is identical to A1ee.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|------------------------------------|------------------------------|------------|--|--|-----------------|---------------------------|--|
| | Volts | @ mA | | | | | |
| 1N5366 | 39 | 30 | 14 | No Suffix = 20% Suffix A = 10% Suffix B = 5% | 5 watt | A1ee ^{(30) (31)} | |
| 1N5367 | 43 | 30 | 20 | | " | " | |
| 1N5368 | 47 | 25 | 25 | | " | " | |
| 1N5369 | 51 | 25 | 27 | " " | " | " | |
| 1N5370 | 56 | 20 | 35 | " " | " | " | |
| 1N5371 | 60 | 20 | 40 | " " | " | " | |
| 1N5372 | 62 | 20 | 42 | No Suffix = 20% Suffix A = 10% Suffix B = 5% | 5 watts | A1ee ^{(30) (31)} | |
| 1N5373 | 68 | 20 | 44 | | " | " | |
| 1N5374 | 75 | 20 | 45 | | " | " | |
| 1N5375 | 82 | 15 | 65 | " " | " | " | |
| 1N5376 | 87 | 15 | 75 | " " | " | " | |
| 1N5377 | 91 | 15 | 75 | " " | " | " | |
| 1N5378 | 100 | 12 | 90 | " " | " | " | |
| 1N5379 | 110 | 12 | 125 | " " | " | " | |
| 1N5380 | 120 | 10 | 170 | " " | " | " | |
| 1N5381 | 130 | 10 | 190 | " " | " | " | |
| 1N5382 | 140 | 8 | 230 | " " | " | " | |
| 1N5383 | 150 | 8 | 330 | " " | " | " | |
| 1N5384 | 160 | 8 | 350 | " " | " | " | |
| 1N5385 | 170 | 8 | 380 | " " | " | " | |
| 1N5386 | 180 | 5 | 430 | " " | " | " | |
| 1N5387 | 190 | 5 | 450 | " " | " | " | |
| 1N5388 | 200 | 5 | 480 | " " | " | " | |
| Type No. | PIV | I_o 25°C | VF | IR | T_{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| | | (55°C) | | | (n sec.) | | |
| 1N5415 | 50 | 3.0 | 1.1 | 1.0 | 150 | E | |
| 1N5416 | 100 | 3.0 | 1.1 | 1.0 | 150 | E | |
| 1N5417 | 200 | 3.0 | 1.1 | 1.0 | 150 | E | |
| 1N5418 | 400 | 3.0 | 1.1 | 1.0 | 150 | E | |
| 1N5419 | 500 | 3.0 | 1.1 | 1.0 | 250 | E | |
| 1N5420 | 600 | 3.0 | 1.1 | 1.0 | 400 | E | |
| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N5518 ^{(19) (20)} | 3.3 | 20 | 26 | No Suffix = \pm 20% A Suffix = \pm 10% B Suffix = \pm 5% | 400 mw | DO-7/DO-35 | |
| 1N5519 ^{(19) (20)} | 3.6 | 20 | 24 | | " | " | |
| 1N5520 ^{(19) (20)} | 3.9 | 20 | 22 | | " | " | |
| 1N5521 ^{(19) (20)} | 4.3 | 20 | 18 | C Suffix = \pm 2% D Suffix = \pm 1% | " | " | |
| 1N5522 ^{(19) (20)} | 4.7 | 10 | 22 | | " | " | |
| 1N5523 ^{(19) (20)} | 5.1 | 5 | 26 | | " | " | |
| 1N5524 ^{(19) (20)} | 5.6 | 3 | 30 | " " | " | " | |
| 1N5525 ^{(19) (20)} | 6.2 | 1 | 30 | " " | " | " | |
| 1N5526 ^{(19) (20)} | 6.8 | 1 | 30 | " " | " | " | |
| 1N5527 ^{(19) (20)} | 7.5 | 1 | 35 | " " | " | " | |
| 1N5528 ^{(19) (20)} | 8.2 | 1 | 40 | " " | " | " | |
| 1N5529 ^{(19) (20)} | 9.1 | 1 | 45 | " " | " | " | |
| 1N5530 ^{(19) (20)} | 10.0 | 1 | 60 | " " | " | " | |
| 1N5531 ^{(19) (20)} | 11.0 | 1 | 80 | " " | " | " | |
| 1N5532 ^{(19) (20)} | 12.0 | 1 | 90 | " " | " | " | |
| 1N5533 ^{(19) (20)} | 13.0 | 1 | 90 | " " | " | " | |
| 1N5534 ^{(19) (20)} | 14.0 | 1 | 100 | " " | " | " | |
| 1N5535 ^{(19) (20)} | 15.0 | 1 | 100 | " " | " | " | |
| 1N5536 ^{(19) (20)} | 16.0 | 1 | 100 | " " | " | " | |
| 1N5537 ^{(19) (20)} | 17.0 | 1 | 100 | " " | " | " | |
| 1N5538 ^{(19) (20)} | 18.0 | 1 | 100 | " " | " | " | |
| 1N5539 ^{(19) (20)} | 19.0 | 1 | 100 | " " | " | " | |
| 1N5540 ^{(19) (20)} | 20.0 | 1 | 100 | " " | " | " | |
| 1N5541 ^{(19) (20)} | 22.0 | 1 | 100 | " " | " | " | |
| 1N5542 ^{(19) (20)} | 24.0 | 1 | 100 | " " | " | " | |
| 1N5543 ^{(19) (20)} | 25.0 | 1 | 100 | " " | " | " | |
| 1N5544 ^{(19) (20)} | 28.0 | 1 | 100 | " " | " | " | |
| 1N5545 ^{(19) (20)} | 30.0 | 1 | 100 | " " | " | " | |
| 1N5546 ^{(19) (20)} | 33.0 | 1 | 100 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low reverse leakage diode

(27) Supplied by Microsemi in DO-7 Case

(28) Supplied by Microsemi in Case J (DO-41)

(30) This is the package referenced in the Autumn

1972 Semiconductor Diode & SCR D.A.T.A. book.

| Type No. | PIV | Io 25°C | VF | IR | T _{RR} | Device Package | MICROSEMI Recommended Substitute |
|----------------|----------------------------------|---------|---|-------------------------|---------------------|----------------------------|----------------------------------|
| | Volts | Amps | Volts | μA | | | |
| | | (55°C) | | | | | |
| 1N5550 | 200 | 5.0 | 1.0 | 1.0 | | E M M E | |
| 1N5551 | 400 | 5.0 | 1.0 | 1.0 | | | |
| 1N5552 | 600 | 5.0 | 1.0 | 1.0 | | | |
| 1N5553 | 800 | 5.0 | 1.1 | 1.0 | | | |
| 1N5554 | 1000 | 5.0 | 1.1 | 1.0 | | | |
| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N5555 | 33.0 | 1 | No Impedance Specified | No Tolerance Specified | 1,500 watts for ims | DO-13 | |
| 1N5556 | 43.7 | 1 | " | " | " | " | |
| 1N5557 | 54.0 | 1 | " | " | " | " | |
| 1N5558 | 191.0 | 1 | " | " | " | " | |
| 1N5559 | 6.8 | 37 | No Impedance Specified | No Suffix = ± 20% | 1.0 watt | A196d ^{(28) (30)} | |
| 1N5560 | 7.5 | 34 | " | " " | " | " | |
| 1N5561 | 8.2 | 31 | " | " " | " | " | |
| 1N5562 | 9.1 | 28 | " | " " | " | " | |
| 1N5563 | 10 | 25 | " | " " | " | " | |
| 1N5564 | 11 | 23 | " | " " | " | " | |
| 1N5565 | 12 | 21 | " | " " | " | " | |
| 1N5566 | 13 | 19 | " | " " | " | " | |
| 1N5567 | 15 | 17 | " | " " | " | " | |
| 1N5568 | 16 | 15.5 | " | " " | " | " | |
| 1N5569 | 18 | 14 | " | " " | " | " | |
| 1N5570 | 20 | 12.5 | " | " " | " | " | |
| 1N5571 | 22 | 11.5 | " | " " | " | " | |
| 1N5572 | 24 | 10.5 | " | " " | " | " | |
| 1N5573 | 27 | 9.5 | " | " " | " | " | |
| 1N5574 | 30 | 8.5 | " | " " | " | " | |
| 1N5575 | 33 | 7.5 | " | " " | " | " | |
| 1N5576 | 36 | 7.0 | " | " " | " | " | |
| 1N5577 | 39 | 6.5 | " | " " | " | " | |
| 1N5578 | 43 | 6.0 | " | " " | " | " | |
| 1N5579 | 47 | 5.5 | " | " " | " | " | |
| 1N5580 | 51 | 5.0 | No Impedance Specified | No Suffix = ± 20% | 1.0 watt | A196d ^{(28) (30)} | |
| 1N5581 | 56 | 4.5 | " | " " | " | " | |
| 1N5582 | 62 | 4.0 | " | " " | " | " | |
| 1N5583 | 68 | 3.7 | " | " " | " | " | |
| 1N5584 | 75 | 3.3 | " | " " | " | " | |
| 1N5585 | 82 | 3.0 | " | " " | " | " | |
| 1N5586 | 91 | 2.8 | " | " " | " | " | |
| 1N5587 | 100 | 2.5 | " | " " | " | " | |
| 1N5588 | 110 | 2.3 | " | " " | " | " | |
| 1N5589 | 120 | 2.0 | " | " " | " | " | |
| 1N5590 | 130 | 1.9 | " | " " | " | " | |
| 1N5591 | 150 | 1.7 | " | " " | " | " | |
| 1N5592 | 160 | 1.6 | " | " " | " | " | |
| 1N5593 | 180 | 1.4 | " | " " | " | " | |
| 1N5594 | 200 | 1.2 | " | " " | " | " | |
| Type No. | PIV | Io 25°C | VF | IR | T _{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | | | |
| | | (55°C) | | | (n sec.) | | |
| 1N5614 | 200 | 1.00 | | 1.0 | 2.0 | A | |
| 1N5616 | 400 | 1.00 | .8 min. | 1.0 | 2.0 | A | |
| 1N5618 | 600 | 1.00 | to | 1.0 | 2.0 | A | |
| 1N5620 | 800 | 1.00 | 1.3 max. | 1.0 | 2.0 | A | |
| 1N5622 | 1000 | 1.00 | | 1.0 | 2.0 | A | |
| 1N5615 | 200 | 1.0 | | .5 | 150 | A | |
| 1N5617 | 400 | 1.0 | .8 min. | .5 | 150 | A | |
| 1N5619 | 600 | 1.0 | to | .5 | 250 | A | |
| 1N5621 | 800 | 1.0 | 1.6 max. | .5 | 300 | A | |
| 1N5623 | 1000 | 1.0 | | .5 | 500 | A | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low reverse leakage diode

(27) Supplied by Microsemi in DO-7 Case

(28) Supplied by Microsemi in Case J (DO-41)

(30) This is the package referenced in the Autumn 1972 Semiconductor Diode & SCR D.A.T.A. book.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------|------------------------------|------|--|-------------------------------|------------------------|-------------------|--|
| | Volts | @ mA | | | | | |
| 1N5629 | 6.8 | 10 | No Impedance Specified | No Suffix = 10% | 1500 watts for 1 ms | DO-13 | |
| 1N5629A | 6.8 | 10 | | Suffix A = 5% | | " | |
| 1N5630 | 7.5 | 10 | | " " | " | " | |
| 1N5630A | 7.5 | 10 | | " " | " | " | |
| 1N5631 | 8.2 | 10 | " | " " | " | " | |
| 1N5631A | 8.2 | 10 | | " " | " | " | |
| 1N5632 | 9.1 | 1 | | " " | " | " | |
| 1N5632A | 9.1 | 1 | | " " | " | " | |
| 1N5633 | 10.0 | 1 | " | " " | " | " | |
| 1N5633A | 10.0 | 1 | | " " | " | " | |
| 1N5634 | 11.0 | 1 | | " " | " | " | |
| 1N5634A | 11.0 | 1 | | " " | " | " | |
| 1N5635 | 12.0 | 1 | " | " " | " | " | |
| 1N5635A | 12.0 | 1 | | " " | " | " | |
| 1N5636 | 13.0 | 1 | | " " | " | " | |
| 1N5636A | 13.0 | 1 | | " " | " | " | |
| 1N5637 | 15.0 | 1 | " | " " | " | " | |
| 1N5637A | 15.0 | 1 | | " " | " | " | |
| 1N5638 | 16.0 | 1 | | " " | " | " | |
| 1N5638A | 16.0 | 1 | | " " | " | " | |
| 1N5639 | 18.0 | 1 | " | " " | " | " | |
| 1N5639A | 18.0 | 1 | | " " | " | " | |
| 1N5640 | 20.0 | 1 | | " " | " | " | |
| 1N5640A | 20.0 | 1 | | " " | " | " | |
| 1N5641 | 22.0 | 1 | " | " " | " | " | |
| 1N5641A | 22.0 | 1 | | " " | " | " | |
| 1N5642 | 24.0 | 1 | | " " | " | " | |
| 1N5642A | 24.0 | 1 | | " " | " | " | |
| 1N5643 | 27.0 | 1 | " | " " | " | " | |
| 1N5643A | 27.0 | 1 | | " " | " | " | |
| 1N5644 | 30.0 | 1 | | " " | " | " | |
| 1N5644A | 30.0 | 1 | | " " | " | " | |
| 1N5645 | 33.0 | 1 | " | " " | " | " | |
| 1N5645A | 33.0 | 1 | | " " | " | " | |
| 1N5646 | 36.0 | 1 | | " " | " | " | |
| 1N5646A | 36.0 | 1 | | " " | " | " | |
| 1N5647 | 39.0 | 1 | " | " " | " | " | |
| 1N5647A | 39.0 | 1 | | " " | " | " | |
| 1N5648 | 43.0 | 1 | | " " | " | " | |
| 1N5648A | 43.0 | 1 | | " " | " | " | |
| 1N5649 | 47.0 | 1 | " | " " | " | " | |
| 1N5649A | 47.0 | 1 | | " " | " | " | |
| 1N5650 | 51.0 | 1 | | " " | " | " | |
| 1N5650A | 51.0 | 1 | | " " | " | " | |
| 1N5651 | 56.0 | 1 | " | " " | " | " | |
| 1N5651A | 56.0 | 1 | | " " | " | " | |
| 1N5652 | 62.0 | 1 | | " " | " | " | |
| 1N5652A | 62.0 | 1 | | " " | " | " | |
| 1N5653 | 68.0 | 1 | " | " " | " | " | |
| 1N5653A | 68.0 | 1 | | " " | " | " | |
| 1N5654 | 75.0 | 1 | | " " | " | " | |
| 1N5654A | 75.0 | 1 | | " " | " | " | |
| 1N5655 | 82.0 | 1 | " | " " | " | " | |
| 1N5655A | 82.0 | 1 | | " " | " | " | |
| 1N5656 | 91.0 | 1 | | " " | " | " | |
| 1N5656A | 91.0 | 1 | | " " | " | " | |
| 1N5657 | 100.0 | 1 | " | " " | " | " | |
| 1N5657A | 100.0 | 1 | | " " | " | " | |
| 1N5658 | 110.0 | 1 | | " " | " | " | |
| 1N5658A | 110.0 | 1 | | " " | " | " | |
| 1N5659 | 120.0 | 1 | " | " " | " | " | |
| 1N5659A | 120.0 | 1 | | " " | " | " | |
| 1N5660 | 130.0 | 1 | | " " | " | " | |
| 1N5660A | 130.0 | 1 | | " " | " | " | |
| 1N5661 | 150.0 | 1 | " | " " | " | " | |
| 1N5661A | 150.0 | 1 | | " " | " | " | |
| 1N5662 | 160.0 | 1 | | " " | " | " | |
| 1N5662A | 160.0 | 1 | | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low reverse leakage diode

(27) Supplied by Microsemi in DO-7 Case

(28) Supplied by Microsemi in Case J (DO-41)

(30) This is the package referenced in the Autumn
1972 Semiconductor Diode & SCR D.A.T.A. book.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------------------|------------------------------|------------|--|----------------------------------|------------------------|----------------------|--|
| | Volts | @ mA | | | | | |
| 1N5663 | 170.0 | 1 | No Impedance Specified | No Suffix = 10% Suffix A = 5% | 1,500 watts for ims | DO-13 | |
| 1N5663A | 170.0 | 1 | " | " " | " | " | |
| 1N5664 | 180.0 | 1 | " | " " | " | " | |
| 1N5664A | 180.0 | 1 | " | " " | " | " | |
| 1N5665 | 200.0 | 1 | " | " " | " | " | |
| 1N5665A | 200.0 | 1 | " | " " | " | " | |
| 1N5666 | 1.8 | 1 | 65 ⁽²⁷⁾ | No Suffix = $\pm 10\%$ | 250 mw | C29N ⁽¹⁹⁾ | |
| 1N5667 | 2.0 | 1 | 65 | " " | " | " | |
| 1N5668 | 2.2 | 1 | 65 | " " | " | " | |
| 1N5669 | 2.4 | 1 | 65 | " " | " | " | |
| 1N5670 | 2.7 | 1 | 65 | " " | " | " | |
| 1N5671 | 3.0 | 1 | 65 | " " | " | " | |
| 1N5672 | 3.3 | 1 | 65 | " " | " | " | |
| 1N5673 | 3.6 | 1 | 65 | " " | " | " | |
| 1N5674 | 3.9 | 1 | 65 | " " | " | " | |
| 1N5675 | 4.3 | 1 | 65 | " " | " | " | |
| 1N5676 | 4.7 | 1 | 65 | " " | " | " | |
| 1N5677 | 5.1 | 1 | 65 | " " | " | " | |
| 1N5678 | 5.6 | 1 | 65 | " " | " | " | |
| 1N5728 ⁽¹⁹⁾ | 4.7 | 10 | 70 | B Suffix = $\pm 5\%$ | 400mw | DO-35 | |
| 1N5729 ⁽¹⁹⁾ | 5.1 | 10 | 50 | C Suffix = $\pm 2\%$ | " | " | |
| 1N5730 ⁽¹⁹⁾ | 5.6 | 10 | 25 | D Suffix = $\pm 1\%$ | " | " | |
| 1N5731 ⁽¹⁹⁾ | 6.2 | 10 | 10 | " | " | " | |
| 1N5732 ⁽¹⁹⁾ | 6.8 | 10 | 10 | B Suffix = $\pm 5\%$ | 400 mw | DO-35 | |
| 1N5733 ⁽¹⁹⁾ | 7.5 | 10 | 10 | C Suffix = $\pm 2\%$ | " | " | |
| 1N5734 ⁽¹⁹⁾ | 8.2 | 10 | 15 | D Suffix = $\pm 1\%$ | " | " | |
| 1N5735 ⁽¹⁹⁾ | 9.1 | 10 | 15 | " | " | " | |
| 1N5736 ⁽¹⁹⁾ | 10 | 10 | 20 | " | " | " | |
| 1N5737 ⁽¹⁹⁾ | 11 | 5 | 20 | " | " | " | |
| 1N5738 ⁽¹⁹⁾ | 12 | 5 | 30 | " | " | " | |
| 1N5739 ⁽¹⁹⁾ | 13 | 5 | 30 | " | " | " | |
| 1N5740 ⁽¹⁹⁾ | 15 | 5 | 30 | " | " | " | |
| 1N5741 ⁽¹⁹⁾ | 16 | 5 | 40 | " | " | " | |
| 1N5742 ⁽¹⁹⁾ | 18 | 5 | 45 | " | " | " | |
| 1N5743 ⁽¹⁹⁾ | 20 | 5 | 55 | " | " | " | |
| 1N5744 ⁽¹⁹⁾ | 22 | 5 | 55 | " | " | " | |
| 1N5745 ⁽¹⁹⁾ | 24 | 5 | 70 | " | " | " | |
| 1N5746 ⁽¹⁹⁾ | 27 | 2 | 80 | " | " | " | |
| 1N5747 ⁽¹⁹⁾ | 30 | 2 | 80 | " | " | " | |
| 1N5748 ⁽¹⁹⁾ | 33 | 2 | 90 | " | " | " | |
| 1N5749 ⁽¹⁹⁾ | 36.0 | 2 | 90 | " | " | " | |
| 1N5750 ⁽¹⁹⁾ | 39.0 | 2 | 130 | " | " | " | |
| 1N5751 ⁽¹⁹⁾ | 43.0 | 2 | 150 | " | " | " | |
| 1N5752 ⁽¹⁹⁾ | 47.0 | 2 | 170 | " | " | " | |
| 1N5753 ⁽¹⁹⁾ | 51.0 | 2 | 180 | " | " | " | |
| 1N5754 ⁽¹⁹⁾ | 56.0 | 2 | 200 | " | " | " | |
| 1N5755 ⁽¹⁹⁾ | 62.0 | 2 | 215 | " | " | " | |
| 1N5756 ⁽¹⁹⁾ | 68.0 | 2 | 240 | " | " | " | |
| 1N5757 ⁽¹⁹⁾ | 75.0 | 2 | 255 | " | " | " | |
| Type No. | PIV | I_o 25°C | VF | IR | T_{RR} | Device Package | MICROSEMI Recommended Substitute |
| | Volts | Amps | Volts | μA | (n sec.) | | |
| 1N5802 | 50 | 2.5 | .875 | 1.0 | 25 | A | |
| 1N5803 | 75 | @ | @ | 1.0 | 25 | A | |
| 1N5804 | 100 | TL=75°C | 1.0Adc | 1.0 | 25 | A | |
| 1N5805 | 125 | (L=3/4") | 250 msec | 1.0 | 25 | A | |
| 1N5806 | 150 | | pulse width | 1.0 | 25 | A | |
| 1N5807 | 50 | 6.0 | .875 | 5.0 | 30 | E | |
| 1N5808 | 75 | @ | @ | 5.0 | 30 | E | |
| 1N5809 | 100 | TL=75°C | 4Adc | 5.0 | 30 | E | |
| 1N5810 | 125 | (L=3/4") | 250 msec | 5.0 | 30 | E | |
| 1N5811 | 150 | | pulse width | 5.0 | 30 | E | |
| 1N5812 | 50 | 20 | .9 | 1.0 | 35 | DO4 | |
| 1N5813 | 75 | 20 | .9 | 1.0 | 35 | DO4 | |
| 1N5814 | 100 | 20 | .9 | 1.0 | 35 | DO4 | |
| 1N5815 | 125 | 20 | .9 | 1.0 | 35 | DO4 | |
| 1N5816 | 150 | 20 | .9 | 1.0 | 35 | DO4 | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low reverse leakage diode

(27) Supplied by Microsemi in DO-7 Case

(28) Supplied by Microsemi in Case J (DO-41)

(30) This is the package referenced in the Autumn

1972 Semiconductor Diode & SCR D.A.T.A. book.

| Zener Type No. | Zener Voltage at I_{ZT} | | Max. Zener Impedance @ I_{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|-------------------|------------------------------|-------|--|-------------------------------|-----------------|-------------------|--|
| | Volts | @ mA | | | | | |
| 1N5837 | 2.40 | 20.0 | 50.0 | Suffix A = 10% | 500 mW | | 1N5221 |
| 1N5838 | 2.50 | 20.0 | 50.0 | Suffix B = 5% | " | | 1N5222 |
| 1N5839 | 2.70 | 20.0 | 50.0 | " | " | | 1N5223 |
| 1N5840 | 2.80 | 20.0 | 50.0 | " | " | | 1N5224 |
| 1N5841 | 3.00 | 20.0 | 50.0 | " | " | | 1N5225 |
| 1N5842 | 3.30 | 20.0 | 50.0 | " | " | | 1N5226 |
| 1N5843 | 3.60 | 20.0 | 48.0 | " | " | | 1N5227 |
| 1N5844 | 3.90 | 20.0 | 40.0 | " | " | | 1N5228 |
| 1N5845 | 4.30 | 20.0 | 25.0 | " | " | | 1N5229 |
| 1N5846 | 4.70 | 20.0 | 19.0 | " | " | | 1N5230 |
| 1N5847 | 5.10 | 20.0 | 17.0 | " | " | | 1N5231 |
| 1N5848 | 5.60 | 20.0 | 15.0 | " | " | | 1N5232 |
| 1N5849 | 6.00 | 20.0 | 13.0 | " | " | | 1N5233 |
| 1N5850 | 6.20 | 20.0 | 14.0 | " | " | | 1N5234 |
| 1N5851 | 6.80 | 20.0 | 17.0 | " | " | | 1N5235 |
| 1N5852 | 7.50 | 20.0 | 23.0 | " | " | | 1N5236 |
| 1N5853 | 8.20 | 20.0 | 34.0 | " | " | | 1N5237 |
| 1N5854 | 8.70 | 20.0 | 44.0 | " | " | | 1N5238 |
| 1N5855 | 9.10 | 20.0 | 50.0 | " | " | | 1N5239 |
| 1N5856 | 10.00 | 20.0 | 62.0 | " | " | | 1N5240 |
| 1N5857 | 11.00 | 20.0 | 68.0 | " | " | | 1N5241 |
| 1N5858 | 12.00 | 20.0 | 70.0 | " | " | | 1N5242 |
| 1N5859 | 13.00 | 9.5 | 70.0 | " | " | | 1N5243 |
| 1N5860 | 14.00 | 9.0 | 70.0 | " | " | | 1N5244 |
| 1N5861 | 15.0 | 8.5 | 34.0 | " | " | | 1N5245 |
| 1N5862 | 16.0 | 7.8 | 38.0 | " | " | | 1N5246 |
| 1N5863 | 17.0 | 7.4 | 42.0 | " | " | | 1N5247 |
| 1N5864 | 18.0 | 7.0 | 48.0 | " | " | | 1N5248 |
| 1N5865 | 19.0 | 6.6 | 52.0 | " | " | | 1N5249 |
| 1N5866 | 20.0 | 6.2 | 57.0 | " | " | | 1N5250 |
| 1N5867 | 22.0 | 5.6 | 68.0 | " | " | | 1N5251 |
| 1N5868 | 24.0 | 5.2 | 78.0 | " | " | | 1N5252 |
| 1N5869 | 25.0 | 5.0 | 85.0 | " | " | | 1N5253 |
| 1N5870 | 27.0 | 4.6 | 98.0 | " | " | | 1N5254 |
| 1N5871 | 28.0 | 4.5 | 105.0 | " | " | | 1N5255 |
| 1N5872 | 30.0 | 4.2 | 117.0 | " | " | | 1N5256 |
| 1N5873 | 33.0 | 3.8 | 140.0 | " | " | | 1N5257 |
| 1N5874 | 36.0 | 3.4 | 160.0 | " | " | | 1N5258 |
| 1N5875 | 39.0 | 3.2 | 190.0 | " | " | | 1N5259 |
| 1N5876 | 43.0 | 3.0 | 225.0 | " | " | | 1N5260 |
| 1N5877 | 47.0 | 2.7 | 260.0 | " | " | | 1N5261 |
| 1N5878 | 51.0 | 2.5 | 300.0 | " | " | | 1N5262 |
| 1N5879 | 56.0 | 2.2 | 360.0 | " | " | | 1N5263 |
| 1N5880 | 60.0 | 2.1 | 410.0 | " | " | | 1N5264 |
| 1N5881 | 62.0 | 2.0 | 430.0 | " | " | | 1N5265 |
| 1N5882 | 68.0 | 1.8 | 520.0 | " | " | | 1N5266 |
| 1N5883 | 75.0 | 1.7 | 600.0 | " | " | | 1N5267 |
| 1N5884 | 82.0 | 1.5 | 700.0 | " | " | | 1N5268 |
| 1N5913 | 3.3 | 113.6 | 10.0 | No Suffix = 20% | 1.5 Watt | Case J | |
| 1N5914 | 3.6 | 104.2 | 9.0 | Suffix A = 10% | " | or DO-41 | |
| 1N5915 | 3.9 | 96.1 | 7.5 | Suffix B = 5% | " | glass | |
| 1N5916 | 4.3 | 87.2 | 6.0 | Suffix C = 2% | " | " | |
| 1N5917 | 4.7 | 79.8 | 5.0 | Suffix D = 1% | " | " | |
| 1N5918 | 5.1 | 73.5 | 4.0 | " | " | " | |
| 1N5919 | 5.6 | 66.9 | 2.0 | " | " | " | |
| 1N5920 | 6.2 | 60.5 | 2.0 | " | " | " | |
| 1N5921 | 6.8 | 55.1 | 2.5 | " | " | " | |
| 1N5922 | 7.5 | 50.0 | 3.0 | " | " | " | |
| 1N5923 | 8.2 | 45.7 | 3.5 | " | " | " | |
| 1N5924 | 9.1 | 41.2 | 4.0 | " | " | " | |
| 1N5925 | 10.0 | 37.5 | 4.5 | " | " | " | |
| 1N5926 | 11.0 | 34.1 | 5.5 | " | " | " | |
| 1N5927 | 12.0 | 31.2 | 6.5 | " | " | " | |
| 1N5928 | 13.0 | 28.8 | 7.0 | " | " | " | |
| 1N5929 | 15.0 | 25.0 | 9.0 | " | " | " | |
| 1N5930 | 16.0 | 23.4 | 10.0 | " | " | " | |
| 1N5931 | 18.0 | 20.8 | 12.0 | " | " | " | |
| 1N5932 | 20.0 | 18.7 | 14.0 | " | " | " | |
| 1N5933 | 22.0 | 17.0 | 17.5 | " | " | " | |
| 1N5934 | 24.0 | 15.6 | 19.0 | " | " | " | |
| 1N5935 | 27.0 | 13.9 | 23.0 | " | " | " | |
| 1N5936 | 30.0 | 12.5 | 28.0 | " | " | " | |
| 1N5937 | 33.0 | 11.4 | 33.0 | " | " | " | |
| 1N5938 | 36.0 | 10.4 | 38.0 | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low reverse leakage diode

(27) Supplied by Microsemi in DO-7 Case

(28) Supplied by Microsemi in Case J (DO-41)

(30) This is the package referenced in the Autumn

1972 Semiconductor Diode & SCR D.A.T.A. book.

| Zener Type No. | Zener Voltage at I_{Z1} | | Max. Zener Impedance @ I_{Z1} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
|------------------------------|------------------------------|------|--|-------------------------------|-----------------|-------------------|--|
| | Volts | @ mA | | | | | |
| 1N5939 | 39.0 | 9.6 | 45.0 | No Suffix = 20% | 1.5 Watt | Case J | |
| 1N5940 | 43.0 | 8.7 | 53.0 | Suffix A = 10% | " | or DO-41 | |
| 1N5941 | 47.0 | 8.0 | 67.0 | Suffix B = 5% | " | glass | |
| 1N5942 | 51.0 | 7.3 | 70.0 | Suffix C = 2% | " | " | |
| 1N5943 | 56.0 | 6.7 | 86.0 | Suffix D = 1% | " | " | |
| 1N5944 | 62.0 | 6.0 | 100.0 | " | " | " | |
| 1N5945 | 68.0 | 5.5 | 120.0 | " | " | " | |
| 1N5946 | 75.0 | 5.0 | 140.0 | " | " | " | |
| 1N5947 | 82.0 | 4.6 | 160.0 | " | " | " | |
| 1N5948 | 91.0 | 4.1 | 200.0 | " | " | " | |
| 1N5949 | 100.0 | 3.7 | 250.0 | " | " | " | |
| 1N5950 | 110.0 | 3.4 | 300.0 | " | " | " | |
| 1N5951 | 120.0 | 3.1 | 380.0 | " | " | " | |
| 1N5952 | 130.0 | 2.9 | 450.0 | " | " | " | |
| 1N5953 | 150.0 | 2.5 | 600.0 | " | " | " | |
| 1N5954 | 160.0 | 2.3 | 700.0 | " | " | " | |
| 1N5955 | 180.0 | 2.1 | 900.0 | " | " | " | |
| 1N5956 | 200.0 | 1.9 | 1200.0 | " | " | " | |
| 1N5985 | 2.4 | 5.0 | 110 | A Suffix = $\pm 10\%$ | 500mw | DO-35 | |
| 1N5986 | 2.7 | 5.0 | 110 | B Suffix = $\pm 5\%$ | " | " | |
| 1N5987 | 3.0 | 5.0 | 100 | " | " | " | |
| 1N5988 | 3.3 | 5.0 | 100 | " | " | " | |
| 1N5989 | 3.6 | 5.0 | 95 | " | " | " | |
| 1N5990 | 3.9 | 5.0 | 95 | " | " | " | |
| 1N5991 | 4.3 | 5.0 | 90 | " | " | " | |
| 1N5992 | 4.7 | 5.0 | 90 | " | " | " | |
| 1N5993 | 5.1 | 5.0 | 88 | " | " | " | |
| 1N5994 | 5.6 | 5.0 | 70 | " | " | " | |
| 1N5995 | 6.2 | 5.0 | 50 | " | " | " | |
| 1N5996 | 6.8 | 5 | 25 | A suffix = $\pm 10\%$ | 500 mw | DO-35 | |
| 1N5997 | 7.5 | 5 | 10 | B suffix = $\pm 5\%$ | " | " | |
| 1N5998 | 8.2 | 5 | 15 | " | " | " | |
| 1N5999 | 9.1 | 5 | 18 | " | " | " | |
| 1N6000 | 10 | 5 | 22 | " | " | " | |
| 1N6001 | 11 | 5 | 25 | " | " | " | |
| 1N6002 | 12 | 5 | 32 | " | " | " | |
| 1N6003 | 13 | 5 | 36 | " | " | " | |
| 1N6004 | 15 | 5 | 42 | " | " | " | |
| 1N6005 | 16 | 5 | 48 | " | " | " | |
| 1N6006 | 18 | 5 | 55 | " | " | " | |
| 1N6007 | 20 | 5 | 62 | " | " | " | |
| 1N6008 | 22 | 5 | 70 | " | " | " | |
| 1N6009 | 24 | 5 | 78 | " | " | " | |
| 1N6010 | 27 | 5 | 88 | " | " | " | |
| 1N6011 | 30 | 5 | 95 | " | " | " | |
| 1N6012 | 33 | 5 | 110 | " | " | " | |
| 1N6013 | 36 | 5.0 | 130 | " | " | " | |
| 1N6014 | 39 | 2.0 | 170 | " | " | " | |
| 1N6015 | 43 | 2.0 | 180 | " | " | " | |
| 1N6016 | 47 | 2.0 | 200 | " | " | " | |
| 1N6017 | 51 | 2.0 | 225 | " | " | " | |
| 1N6018⁽²⁷⁾ | 56 | 2.0 | 240 | " | " | " | |
| 1N6019⁽²⁷⁾ | 62 | 2.0 | 265 | " | " | " | |
| 1N6020⁽²⁷⁾ | 68 | 2.0 | 280 | " | " | " | |
| 1N6021⁽²⁷⁾ | 75 | 2.0 | 300 | " | " | " | |
| 1N6022⁽²⁷⁾ | 82 | 2.0 | 350 | " | " | " | |
| 1N6023⁽²⁷⁾ | 91 | 2.0 | 400 | " | " | " | |
| 1N6024⁽²⁷⁾ | 100 | 1.0 | 800 | " | " | " | |
| 1N6025⁽²⁷⁾ | 110 | 1.0 | 950 | " | " | " | |
| 1N6026⁽²⁷⁾ | 120 | 1.0 | 1250 | " | " | " | |
| 1N6027⁽²⁷⁾ | 130 | 1.0 | 1400 | " | " | " | |
| 1N6028⁽²⁷⁾ | 150 | 1.0 | 1700 | " | " | " | |
| 1N6029⁽²⁷⁾ | 160 | 1.0 | 2000 | " | " | " | |
| 1N6030⁽²⁷⁾ | 180 | 1.0 | 2350 | " | " | " | |
| 1N6031⁽²⁷⁾ | 200 | 1.0 | 2700 | " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low reverse leakage diode

(20) Low noise series

(27) Supplied by Microsemi in DO-7 Case

(28) Supplied by Microsemi in Case J (DO-41)

(30) This is the package referenced in the Autumn

1972 Semiconductor Diode & SCR D.A.T.A. book.

| Type No. | PIV | Io 25°C | VF | IR | T _{RR} | Device Package | MICROSEMI Recommended Substitute |
|----------------------------------|----------------------------------|---------|---|-------------------------|-----------------|----------------|----------------------------------|
| | Volts | Amps | Volts | μA | | | |
| 1N6073 | 50 | 3.0 | 2.04 | 1.0 | (n sec.) | A | |
| 1N6074 | 100 | 3.0 | 2.04 | 1.0 | 30 | A | |
| 1N6075 | 150 | 3.0 | 2.04 | 1.0 | 30 | A | |
| 1N6076 | 50 | 6.0 | 1.76 | 5.0 | 30 | E | |
| 1N6077 | 100 | 6.0 | 1.76 | 5.0 | 30 | E | |
| 1N6078 | 150 | 6.0 | 1.76 | 5.0 | 30 | E | |
| 1N6079 | 50 | 12.0 | 1.50 | 10.0 | 30 | G | |
| 1N6080 | 100 | 12.0 | 1.50 | 10.0 | (n sec.) | G | |
| 1N6081 | 150 | 12.0 | 1.50 | 10.0 | 30 | G | |
| Zener Type No. | Zener Voltage at I _{ZT} | | Max. Zener Impedance @ I _{ZT} Ohms | Zener Voltage Tolerance | Power Rating | Device Package | MICROSEMI Recommended Substitute |
| | Volts | @ mA | | | | | |
| 1N6082 ^(19,20) | 4.3 | 20.0 | 18.0 | No Suffix = 20% | 400 mW | DO-7/DO-35 | |
| 1N6083 ^(19,20) | 4.7 | 10.0 | 10.0 | Suffix A = 10% | " | " | |
| 1N6084 ^(19,20) | 5.1 | 5.0 | 10.0 | Suffix B = 5% | " | " | |
| 1N6085 ^(19,20) | 5.6 | 1.0 | 40.0 | Suffix C = 2% | " | " | |
| 1N6086 ^(19,20) | 6.2 | 1.0 | 45.0 | Suffix D = 1% | " | " | |
| 1N6087 ^(19,20) | 6.8 | 1.0 | 50.0 | " " | " | " | |
| 1N6088 ^(19,20) | 7.5 | 1.0 | 50.0 | " " | " | " | |
| 1N6089 ^(19,20) | 8.2 | 1.0 | 60.0 | " " | " | " | |
| 1N6090 ^(19,20) | 9.1 | 1.0 | 60.0 | " " | " | " | |
| 1N6091 ^(19,20) | 10.0 | 1.0 | 60.0 | " " | " | " | |

NOTE — Diode types presently available from Microsemi Corporation are shown in bold type.

(19) Low reverse leakage diode

(20) Low noise series

(27) Supplied by Microsemi in DO-7 Case

(28) Supplied by Microsemi in Case J (DO-41)

(30) This is the package referenced in the Autumn 1972 Semiconductor Diode & SCR D.A.T.A. book.

In addition to the JEDEC registered zener devices listed previously in this section, Microsemi Corp. supplies the following Pro Electron zener device types frequently used outside of the United States. The numerical digits following "C" in each type number indicates the zener voltage. If further specific information is required on defined parameters of these device types, contact the factory.

| Zener Series No. | Power Rating | Device Package |
|--------------------|--------------|----------------------|
| BZX83 COV8 to C51 | 500mW | DO-35 |
| BZX97 COV8 to C51 | 500mW | DO-35 |
| BZX98 C3V9 to C200 | 10W | DO-4 (metric thread) |
| BZY97 C3V3 to C200 | 1.32W | J case (plastic) |
| BZD10 C3V3 to C200 | 1.32W | DO-13 |
| BZW22 C3V3 to C200 | 1.30W | DO-41 (glass) |
| BZV40 C3V3 to C200 | 5.00W | T-18 (plastic) |

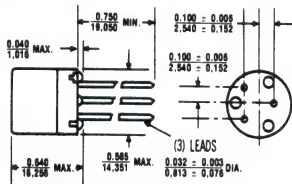
CASE CONFIGURATION CHART

| | | | | | |
|--------------------------------------|--------------------------------------|--|--------------------------------------|---|--------------------------------------|
| <div>DO-1</div> <div></div> | <div>DO-3</div> <div></div> | <div>DO-4</div> <div></div> | <div>DO-5</div> <div></div> | <div>DO-7</div> <div></div> | |
| <div>DO-12</div> <div></div> | <div>DO-13</div> <div></div> | <div>DO-27</div> <div></div> | <div>DO-35</div> <div></div> | <div>TO-3 (Modified)</div> <div></div> | <div>Case 1</div> <div></div> |
| <div>Case 2</div> <div></div> | <div>Case 3</div> <div></div> | <div>Case 4</div> <div></div> | <div>Case A</div> <div></div> | <div>A196d</div> <div></div> | |
| <div>Case B</div> <div></div> | <div>C29N</div> <div></div> | <div>Case J (DO-41)</div> <div></div> | <div>Case K</div> <div></div> | <div>Case L</div> <div></div> | |

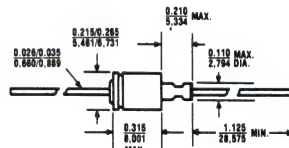
All dimensions in INCH
m.m.

CASE CONFIGURATION CHART

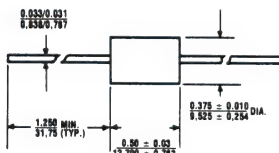
Case Q



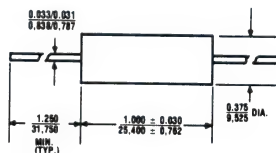
Case R



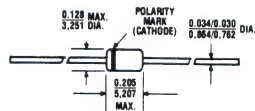
Case S



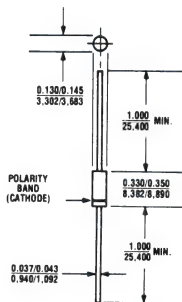
Case T



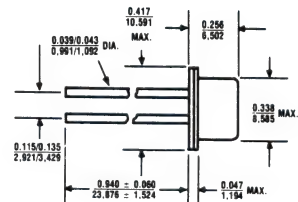
Case X



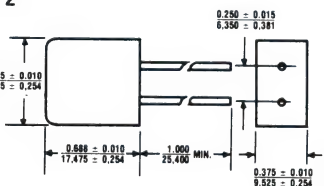
T-18



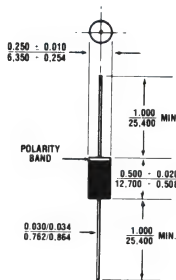
Case AA



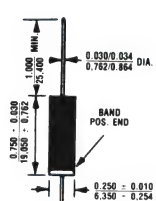
Case Z



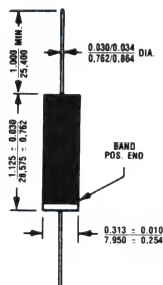
Case CC



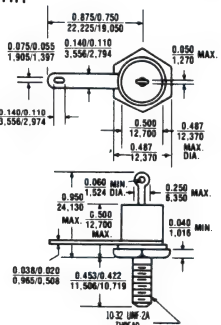
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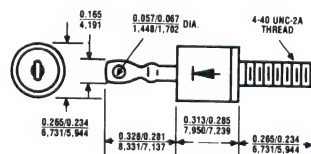
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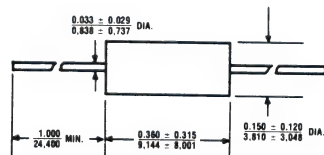
Case HH



Case FF

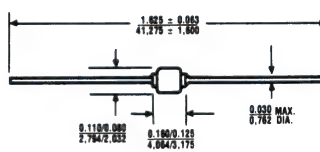


Case GG

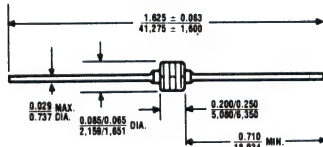


CASE CONFIGURATION CHART

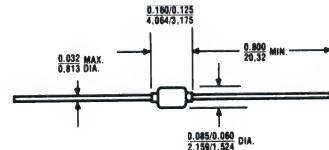
Case JJ



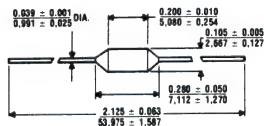
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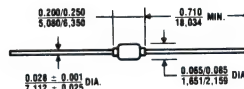
Case MM



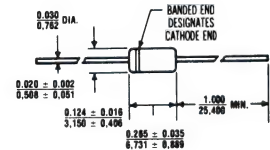
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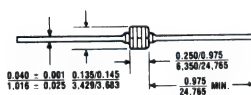
Case OO



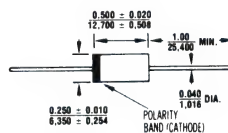
Case QQ



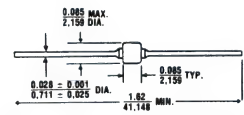
Case RR



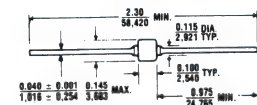
Case SS



Case UU



Case VV

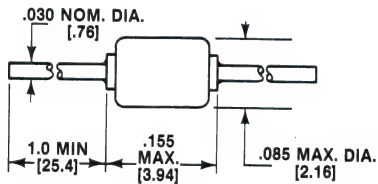


CASE CONFIGURATION CHART

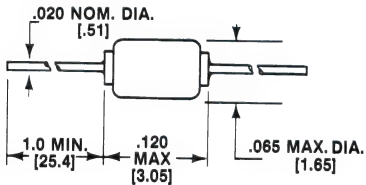
MECHANICAL CONFIGURATIONS PHYSICAL DIMENSIONS

DIMENSIONS IN INCHES (MM)

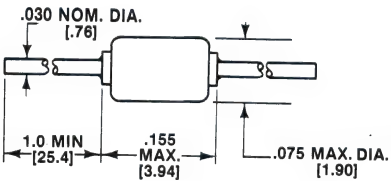
PACKAGE A



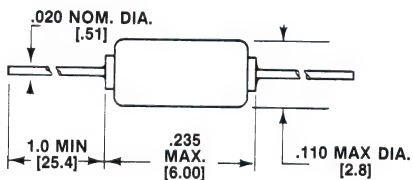
PACKAGE B [D034]



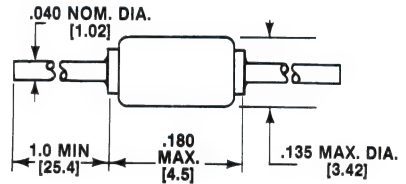
PACKAGE C



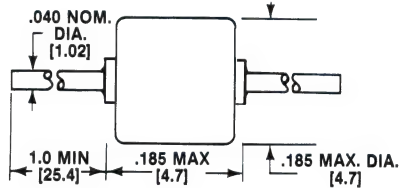
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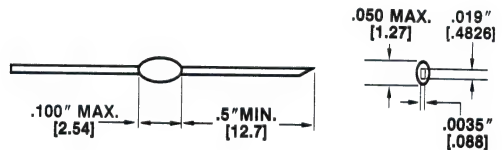
PACKAGE E



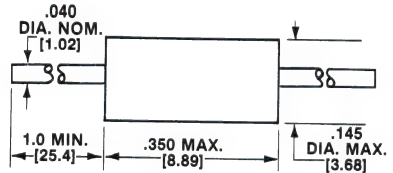
PACKAGE G



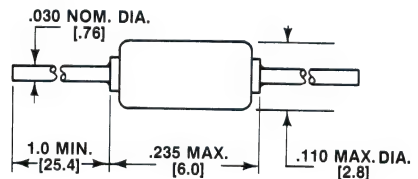
PACKAGE H



PACKAGE R

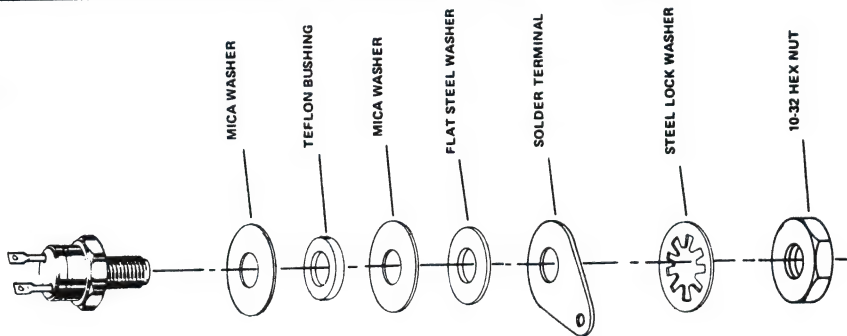


PACKAGE S

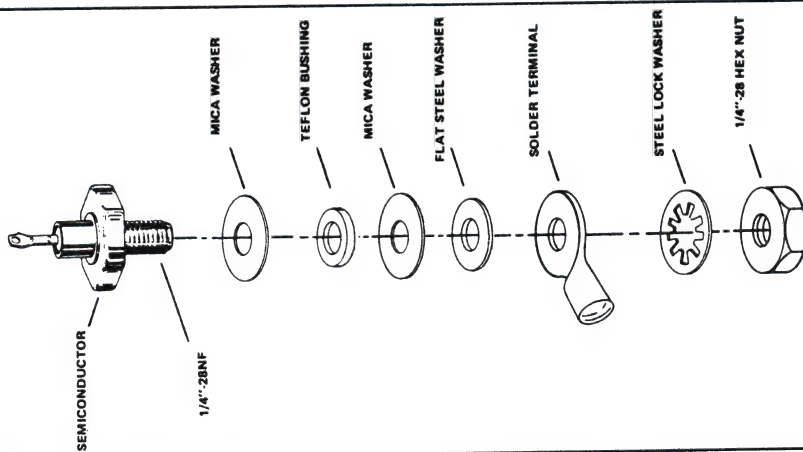


MOUNTING HARDWARE

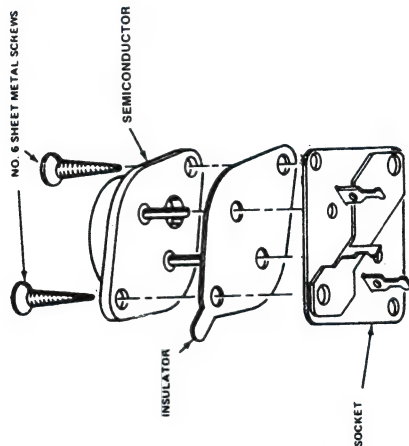
10-32 STUD
DO-4



1/4" STUD
DO-5



TO-3



GUIDE TO AVAILABLE AXIAL LEADED ZENER DIODES

| | Early Industry Standard | Early Industry Standard | Low Noise Low Current Mil - Spec | Low Current (50 uA) Low Leakage | Low Noise Low Current Mil - Spec | Industry Standard Mil - Spec | Industry Standard Mil - Spec | High Performance | Low Voltage Avalanche | Low Noise Low Z Mil - Spec |
|-----------------|-------------------------------|-------------------------------|--|---------------------------------------|--|------------------------------------|------------------------------------|---------------------|-----------------------------|----------------------------------|
| Power | 250 mw | 250 mw | 250mw | 250mw | 250mw | 400mw | 400mw | 400 mw | 400 mw | 400 mw |
| | DO-35 | DO-35 | DO-35 | DO-35 | DO-35 | DO-35 | DO-35 | DO-35 | DO-7 | DO-35 |
| | DO-7 | DO-7 | DO-7 | DO-7 | DO-7 | DO-7 | DO-7 | DO-7 | DO-35 | DO-7 |
| Vz Volts | | | | | | | | | | |
| 1.8 | | | | 1N4678 | 1N4614 | | | | | |
| 2.0 | | | | 1N4679 | 1N4615 | | | | | |
| 2.2 | | | [Mil-S- 19500/435] | 1N4680 | 1N4616 | | | | | [Mil-S- 19500/437] |
| 2.4 | | | | 1N4681 | 1N4617 | 1N4370 | | | | |
| 2.7 | 1N702 | | | 1N4682 | 1N4618 | 1N4371 | | | | |
| 2.8 | | | | | | | | | | |
| 3.0 | | | | 1N4683 | 1N4619 | 1N4372 | [Mil-S- 19500/117] | | | |
| 3.3 | | | | 1N4684 | 1N4620 | 1N746 | | 1N3506 | | 1N5518 |
| 3.6 | 1N703 | | | 1N4685 | 1N4621 | 1N747 | | 1N3507 | | 1N5519 |
| 3.9 | | | | 1N4686 | 1N4622 | 1N748 | | 1N3508 | | 1N5520 |
| 4.3 | 1N704 | | | 1N4687 | 1N4623 | 1N749 | | 1N3509 | 1N6082 | 1N5521 |
| 4.7 | | 1N761 | | 1N4688 | 1N4624 | 1N750 | | 1N3510 | 1N6083 | 1N5522 |
| 5.1 | 1N705 | | | 1N4689 | 1N4625 | 1N751 | | 1N3511 | 1N6084 | 1N5523 |
| 5.6 | 1N708 | 1N762 | | 1N4690 | 1N4626 | 1N752 | | 1N3512 | 1N6085 | 1N5524 |
| 6.2 | 1N709 | | | 1N4691 | 1N4627 | 1N753 | | 1N3513 | 1N6086 | 1N5525 |
| 6.8 | 1N710 | | 1N4099 | 1N4692 | | 1N754 | 1N957 | 1N3514 | 1N6087 | 1N5526 |
| 7.1 | 1N707 | 1N763 | | | [Mil-S- 19500/435] | | | | | |
| 7.5 | 1N711 | | 1N4100 | 1N4693 | | 1N755 | 1N958 | 1N3515 | 1N6088 | 1N5527 |
| 8.2 | 1N712 | | 1N4101 | 1N4694 | | 1N756 | 1N959 | 1N3516 | 1N6089 | 1N5528 |
| 8.8 | | 1N764 | 1N4102 | 1N4695 | | | | | | |
| 9.1 | 1N713 | | 1N4103 | 1N4696 | | 1N757 | 1N960 | 1N3517 | 1N6090 | 1N5529 |
| 10 | 1N714 | | 1N4104 | 1N4697 | | 1N758 | 1N961 | 1N3518 | 1N6091 | 1N5530 |
| 10.5 | | 1N765 | | | | | | | | |
| 11 | 1N715 | | 1N4105 | 1N4698 | | | 1N962 | 1N3519 | | 1N5531 |
| 12 | 1N716 | | 1N4106 | 1N4699 | | 1N759 | 1N963 | 1N3520 | | 1N5532 |
| 12.8 | | 1N766 | | | | | | | | |
| 13 | 1N717 | | 1N4107 | 1N4700 | | | 1N964 | 1N3521 | | 1N5533 |
| 14 | | | 1N4108 | 1N4701 | | | | | | 1N5534 |
| 15 | 1N718 | | 1N4109 | 1N4702 | | | 1N965 | 1N3522 | | 1N5535 |
| 15.8 | | 1N767 | | | | | | | | |
| 16 | 1N719 | | 1N4110 | 1N4703 | | | 1N966 | 1N3523 | | 1N5536 |
| 17 | | | 1N4111 | 1N4704 | | [Mil-S- 19500/127] | | | | |
| 18 | 1N720 | | 1N4112 | 1N4705 | | | 1N967 | 1N3524 | | 1N5537 |
| 19 | | 1N768 | 1N4113 | 1N4706 | | | | | | 1N5538 |
| 20 | 1N721 | | 1N4114 | 1N4707 | | | 1N968 | 1N3525 | | 1N5539 |
| 22 | 1N722 | | 1N4115 | 1N4708 | | | 1N969 | 1N3526 | | 1N5540 |
| 23.5 | | 1N769 | | | | | | | | 1N5541 |
| 24 | 1N723 | | 1N4116 | 1N4709 | | | 1N970 | 1N3527 | | 1N5542 |
| 25 | | | 1N4117 | 1N4710 | | | | | | 1N5543 |
| 27 | 1N724 | | 1N4118 | 1N4711 | | | 1N971 | 1N3528 | | |
| 28 | | | 1N4119 | 1N4712 | | | | | | 1N5544 |
| 30 | 1N725 | | 1N4120 | 1N4713 | | | 1N972 | 1N3529 | | 1N5545 |
| 33 | 1N726 | | 1N4121 | 1N4714 | | | 1N973 | 1N3530 | | 1N5546 |
| 36 | 1N727 | | 1N4122 | 1N4715 | | | 1N974 | 1N3531 | | |
| 39 | 1N728 | | 1N4123 | 1N4716 | | | 1N975 | 1N3532 | | |
| 40 | | | | | | | | | | |
| 43 | 1N729 | | 1N4124 | 1N4717 | | | 1N976 | 1N3533 | | |
| 45 | | | | | | | | | | |
| 47 | 1N730 | | 1N4125 | | | | 1N977 | 1N3534 | | |
| 50 | | | | | | | | | | |
| 51 | 1N731 | | 1N4126 | | | | 1N978 | | | |
| 52 | | | | | | | | | | |
| 56 | 1N732 | | 1N4127 | | | | 1N979 | | | |
| 60 | | | 1N4128 | | | | | | | |
| 62 | 1N733 | | 1N4129 | | | | 1N980 | | | |
| 68 | 1N734 | | 1N4130 | | | | 1N981 | | | |
| 70 | | | | | | | | | | |
| 75 | 1N735 | | 1N4131 | | | | 1N982 | | | |
| 80 | | | | | | | | | | |
| 82 | 1N736 | | 1N4132 | | | | 1N983 | | | |
| 87 | | | 1N4133 | | | | | | | |
| 90 | | | | | | | | | | |
| 91 | 1N737 | | 1N4134 | | | | 1N984 | | | |
| 100 | 1N738 | | 1N4135 | | | | 1N985 | | | |
| 110 | 1N739 | | | | | | 1N986 | | | |
| 120 | 1N740 | | | | | | 1N987 | | | |
| 130 | 1N741 | | | | | | 1N988 | | | |
| 140 | | | | | | | | | | |
| 150 | 1N742 | | | | | | 1N989 | | | |
| 160 | 1N743 | | | | | | 1N990 | | | |
| 170 | | | | | | | | | | |
| 180 | 1N744 | | | | | | 1N991 | | | |
| 190 | | | | | | | | | | |
| 200 | 1N745 | | | | | | 1N992 | | | |

GUIDE TO AVAILABLE AXIAL LEADED ZENER DIODES

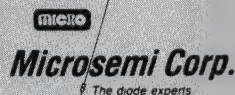
| | Popular Industrial Commercial | Double Stud 1/2" 5 MA | Double Stud | Replaced By 1N4728A Series | Obsolete Metal Can MIL - Spec | Obsolete Use 1N4728 Series | Obsolete Use 1N4728 Series | Obsolete Use 1N4728 Series | Very Popular Industrial Commercial | 1 Watt Epoxy Case J Commercial and Industrial Applications |
|-----------------|-------------------------------------|--------------------------|----------------|----------------------------------|-------------------------------------|----------------------------------|----------------------------------|----------------------------------|--|--|
| Power | 500 mw | 500 mw | 500mw | 1 watt | 1 watt | 1 watt | 1 watt | 1 watt | 1 watt | |
| | DO-35 | DO-35 | DO-35 | DO-41 | DO-41 | DO-41 | DO-41 | DO-41 | DO-41 | |
| | DO-7 | DO-35 | DO-35 | DO-41 | DO-13 | DO-29 | DO-7 | DO-14 | DO-41 | |
| Vz Volts | | | | | | | | | | |
| 1.6 | | | | | | | | | | |
| 2.0 | | | | | | | | | | |
| 2.2 | | | | | | | | | | |
| 2.4 | 1N5221 | 1N5985 | | | | | | | | |
| 2.7 | 1N5223 | 1N5986 | | | | | | | | |
| 2.8 | 1N5224 | | | | | | | | | |
| 3.0 | 1N5225 | 1N5987 | | | | | | | | |
| 3.3 | 1N5226 | 1N5988 | | | | | | | | |
| 3.6 | 1N5227 | 1N5989 | | | | | | | | |
| 3.9 | 1N5228 | 1N5990 | | | | | | | | |
| 4.3 | 1N5229 | 1N5991 | | | | | | | | |
| 4.7 | 1N5230 | 1N5992 | 1N5728 | | | | | | | |
| 5.1 | 1N5231 | 1N5993 | 1N5729 | | | | | | | |
| 5.6 | 1N5232 | 1N5994 | 1N5730 | | | | | | | |
| 6.2 | 1N5234 | 1N5995 | 1N5739 | | | | | | | |
| 6.8 | 1N5235 | 1N5996 | 1N5732 | 1N3675 | 1N3016 | 1N4158 | 1N4323 | 1N4657 | 1N4736 | |
| 7.1 | | | | | | | | | | |
| 7.5 | 1N5236 | 1N5997 | 1N5733 | 1N3676 | 1N3017 | 1N4159 | 1N4324 | 1N4658 | 1N4737 | |
| 8.2 | 1N5237 | 1N5998 | 1N5734 | 1N3677 | 1N3018 | 1N4160 | 1N4325 | 1N4659 | 1N4738 | |
| 8.8 | 1N5238 | | | | | | | | | |
| 9.1 | 1N5239 | 1N5999 | 1N5735 | 1N3678 | 1N3019 | 1N4161 | 1N4326 | 1N4660 | 1N4739 | |
| 10 | 1N5240 | 1N6000 | 1N5736 | 1N3679 | 1N3020 | 1N4162 | 1N4327 | 1N4661 | 1N4740 | |
| 10.5 | | | | | | | | | | |
| 11 | 1N5241 | 1N6001 | 1N5737 | 1N3680 | 1N3021 | 1N4163 | 1N4328 | 1N4662 | 1N4741 | |
| 12 | 1N5242 | 1N6002 | 1N5738 | 1N3681 | 1N3022 | 1N4164 | 1N4329 | 1N4663 | 1N4742 | |
| 12.8 | | | | | | | | | | |
| 13 | 1N5243 | 1N6003 | 1N5739 | 1N3682 | 1N3023 | 1N4165 | 1N4330 | 1N4664 | 1N4743 | |
| 14 | 1N5244 | | | | | | | | | |
| 15 | 1N5245 | 1N6004 | 1N5740 | 1N3683 | 1N3024 | 1N4166 | 1N4331 | 1N4665 | 1N4744 | |
| 15.8 | | | | | | | | | | |
| 16 | 1N5246 | 1N6005 | 1N5741 | 1N3684 | 1N3025 | 1N4167 | 1N4332 | 1N4666 | 1N4745 | |
| 17 | 1N5247 | | | | | | | | | |
| 18 | 1N5248 | 1N6006 | 1N5742 | 1N3685 | 1N3026 | 1N4168 | 1N4333 | 1N4667 | 1N4746 | |
| 19 | 1N5249 | | | | | | | | | |
| 20 | 1N5250 | 1N6007 | 1N5743 | 1N3686 | 1N3027 | 1N4169 | 1N4334 | 1N4668 | 1N4747 | |
| 22 | 1N5251 | 1N6008 | 1N5744 | 1N3687 | 1N3028 | 1N4170 | 1N4335 | 1N4669 | 1N4748 | |
| 23.5 | | | | | | | | | | |
| 24 | 1N5252 | 1N6009 | 1N5745 | 1N3688 | 1N3029 | 1N4171 | 1N4336 | 1N4670 | 1N4749 | |
| 25 | 1N5253 | | | | | | | | | |
| 27 | 1N5254 | 1N6010 | 1N5746 | 1N3689 | 1N3030 | 1N4172 | 1N4337 | 1N4671 | 1N4750 | |
| 28 | 1N5255 | | | | | | | | | |
| 30 | 1N5256 | 1N6011 | 1N5747 | 1N3690 | 1N3031 | 1N4173 | 1N4338 | 1N4672 | 1N4751 | |
| 33 | 1N5257 | 1N6012 | 1N5748 | 1N3691 | 1N3032 | 1N4174 | 1N4339 | 1N4673 | 1N4752 | |
| 36 | 1N5258 | 1N6013 | 1N5749 | 1N3692 | 1N3033 | 1N4175 | 1N4340 | 1N4674 | 1N4753 | |
| 39 | 1N5259 | 1N6014 | 1N5750 | 1N3693 | 1N3034 | 1N4176 | 1N4341 | 1N4675 | 1N4754 | |
| 40 | | | | | | | | | | |
| 43 | 1N5260 | 1N6015 | 1N5751 | 1N3694 | 1N3035 | 1N4177 | 1N4342 | 1N4676 | 1N4755 | |
| 45 | | | | | | | | | | |
| 47 | 1N5261 | 1N6016 | 1N5752 | 1N3695 | 1N3036 | 1N4178 | 1N4343 | 1N4677 | 1N4756 | |
| 50 | | | | | | | | | | |
| 51 | 1N5262 | 1N6017 | 1N5753 | 1N3696 | 1N3037 | 1N4179 | 1N4344 | | 1N4757 | |
| 52 | | | | | | | | | | |
| 56 | 1N5263 | 1N6018 | 1N5754 | 1N3697 | 1N3038 | 1N4180 | 1N4345 | | 1N4758 | |
| 60 | 1N5264 | | | | | | | | | |
| 62 | 1N5265 | 1N6019 | 1N5755 | 1N3698 | 1N3039 | 1N4181 | 1N4346 | | 1N4759 | |
| 68 | 1N5266 | 1N6020 | 1N5756 | 1N3699 | 1N3040 | 1N4182 | 1N4347 | | 1N4760 | |
| 70 | | | | | | | | | | |
| 75 | 1N5267 | 1N6021 | 1N5757 | 1N3700 | 1N3041 | 1N4183 | 1N4348 | | 1N4761 | |
| 80 | | | | | | | | | | |
| 82 | 1N5268 | 1N6022 | | 1N3701 | 1N3042 | 1N4184 | 1N4349 | | 1N4762 | |
| 87 | 1N5269 | | | | | | | | | |
| 90 | | | | | | | | | | |
| 91 | 1N5270 | 1N6023 | | 1N3702 | 1N3043 | 1N4185 | 1N4350 | | 1N4763 | |
| 100 | 1N5271 | 1N6024 | | 1N3703 | 1N3044 | 1N4186 | 1N4351 | | 1N4764 | |
| 110 | 1N5272 | 1N6025 | | 1N3704 | 1N3045 | 1N4187 | 1N4352 | | | 1E2110D5 |
| 120 | 1N5273 | 1N6026 | | 1N3705 | 1N3046 | 1N4188 | 1N4353 | | | 1E2120D5 |
| 130 | 1N5274 | 1N6027 | | 1N3706 | 1N3047 | 1N4189 | 1N4354 | | | 1E2130D5 |
| 140 | 1N5275 | | | | | | | | | 1E2140D5 |
| 150 | 1N5276 | 1N6028 | | 1N3707 | 1N3048 | 1N4190 | 1N4355 | | | 1E2150D5 |
| 160 | 1N5277 | 1N6029 | | 1N3708 | 1N3049 | 1N4191 | 1N4356 | | | 1E2160D5 |
| 170 | 1N5278 | | | | | | | | | 1E2170D5 |
| 180 | 1N5279 | 1N6030 | | 1N3709 | 1N3050 | 1N4192 | 1N4357 | | | 1E2180D5 |
| 190 | 1N5280 | | | | | | | | | 1E2190D5 |
| 200 | 1N5281 | 1N6031 | | 1N3710 | 1N3051 | 1N4193 | 1N4358 | | | 1E2200D5 |

GUIDE TO AVAILABLE AXIAL LEADED ZENER DIODES

| | Metal Can Mil-Spec | Double Stud Glass | Double Anode | Commercial Plastic | Mil-Std-701 Preferred Mil-Spec | 2 Watt Epoxy Case J Commercial and Industrial Applications | Commercial Plastic | Industry Standard | 3 Watt Epoxy Case J Commercial and Industrial Applications |
|-----------------|-----------------------|----------------------|-----------------|-----------------------|--------------------------------------|--|-----------------------|----------------------|--|
| Power | 1 Watt | 1 Watt | 1.2 Watt | 1.5 Watt | 1.5 Watt | | 2.5 Watt | 3.0 Watt | |
| | DO-41 | "A" | "A" | "A" | "A" | | "A" | "A" | |
| | DO-13 | DO-41 | DO-29 | DO-41 | "A" | | | "A" | |
| Vz Volts | | | | | | | | | |
| 1.8 | | | | | | | | | |
| 2.0 | | | | | | | | | |
| 2.2 | | | | | | | | | |
| 2.4 | | | | | | | | | |
| 2.7 | [Mil-S- 19500/115] | | | | [Mil-S- 19500/406] | | | | |
| 2.8 | | | | | | | | | |
| 3.0 | | | | | | | | | |
| 3.3 | 1N3821 | | | 1N5913 | 1N6485 | | 1N5008 | | |
| 3.6 | 1N3822 | | | 1N5914 | 1N6486 | 2EZ3.6D5 | 1N5009 | | |
| 3.9 | 1N3823 | | | 1N5915 | 1N6487 | 2EZ3.9D5 | 1N5010 | | 3EZ3.9D5 |
| 4.3 | 1N3824 | | | 1N5916 | 1N6488 | 2EZ4.3D5 | 1N5011 | | 3EZ4.3D5 |
| 4.7 | 1N3825 | | | 1N5917 | 1N6489 | 2EZ4.7D5 | 1N5012 | | 3EZ4.7D5 |
| 5.1 | 1N3826 | | | 1N5918 | 1N6490 | 2EZ5.1D5 | 1N5013 | | 3EZ5.1D5 |
| 5.6 | 1N3827 | | | 1N5919 | 1N6491 | 2EZ5.6D5 | 1N5014 | | 3EZ5.6D5 |
| 6.2 | 1N3828 | | | 1N5920 | 1N4460 | 2EZ6.2D5 | 1N5015 | | 3EZ6.2D5 |
| 6.8 | 1N3829 | 1N5559 | | 1N5921 | 1N4461 | 2EZ6.8D5 | 1N5016 | 1N5063 | 3EZ6.8D5 |
| 7.1 | | | | | | | | | |
| 7.5 | 1N3830 | 1N5560 | | 1N5922 | 1N4462 | 2EZ7.5D5 | 1N5017 | 1N5064 | 3EZ7.5D5 |
| 8.2 | | 1N5561 | | 1N5923 | 1N4463 | 2EZ8.2D5 | 1N5018 | 1N5065 | 3EZ8.2D5 |
| 8.8 | | | | | | | | | |
| 9.1 | | 1N5562 | 1N4831 | 1N5924 | 1N4464 | 2EZ9.1D5 | 1N5019 | 1N5066 | 3EZ9.1D5 |
| 10 | | 1N5563 | 1N4832 | 1N5925 | 1N4465 | 2EZ10D5 | 1N5020 | 1N5067 | 3EZ10D5 |
| 10.5 | | | | | | | | | |
| 11 | | 1N5564 | 1N4833 | 1N5926 | 1N4466 | 2EZ11D5 | 1N5021 | 1N5068 | 3EZ11D5 |
| 12 | | 1N5565 | 1N4834 | 1N5927 | 1N4467 | 2EZ12D5 | 1N5022 | 1N4883 | 3EZ12D5 |
| 12.8 | | | | | | | | | |
| 13 | | 1N5566 | 1N4835 | 1N5928 | 1N4468 | 2EZ13D5 | 1N5023 | 1N5069 | 3EZ13D5 |
| 14 | | | | | | 2EZ14D5 | 1N5024 | 1N5070 | 3EZ14D5 |
| 15 | | 1N5567 | 1N4836 | 1N5929 | 1N4469 | 2EZ15D5 | 1N5025 | 1N5071 | 3EZ15D5 |
| 15.8 | | | | | | | | | |
| 16 | | 1N5568 | 1N4837 | 1N5930 | 1N4470 | 2EZ16D5 | 1N5026 | 1N5072 | 3EZ16D5 |
| 17 | | | | | | 2EZ17D5 | 1N5027 | | 3EZ17D5 |
| 18 | | 1N5569 | 1N4838 | 1N5931 | 1N4471 | 2EZ18D5 | 1N5028 | 1N5073 | 3EZ18D5 |
| 19 | | | | | | 2EZ19D5 | 1N5029 | | 3EZ19D5 |
| 20 | | 1N5570 | 1N4839 | 1N5932 | 1N4472 | 2EZ20D5 | 1N5030 | 1N4884 | 3EZ20D5 |
| 22 | | 1N5571 | 1N4840 | 1N5933 | 1N4473 | 2EZ22D5 | 1N5031 | 1N5074 | 3EZ22D5 |
| 23.5 | | | | | | | | | |
| 24 | | 1N5572 | 1N4841 | 1N5934 | 1N4474 | 2EZ24D5 | 1N5032 | 1N5075 | 3EZ24D5 |
| 25 | | | | | | | 1N5033 | | |
| 27 | | 1N5573 | 1N4842 | 1N5935 | 1N4475 | 2EZ27D5 | 1N5034 | 1N5076 | 3EZ27D5 |
| 28 | | | | | | | | | |
| 30 | | 1N5574 | 1N4843 | 1N5936 | 1N4476 | 2EZ30D5 | 1N5035 | 1N5077 | 3EZ30D5 |
| 33 | | 1N5575 | 1N4844 | 1N5937 | 1N4477 | 2EZ33D5 | 1N5036 | 1N5078 | 3EZ33D5 |
| 36 | | 1N5576 | 1N4845 | 1N5938 | 1N4478 | 2EZ36D5 | 1N5037 | 1N5079 | 3EZ36D5 |
| 39 | | 1N5577 | 1N4846 | 1N5939 | 1N4479 | 2EZ39D5 | 1N5038 | 1N5080 | 3EZ39D5 |
| 40 | | | | | | | | | |
| 43 | | 1N5578 | 1N4847 | 1N5940 | 1N4480 | 2EZ43D5 | 1N5039 | 1N5081 | |
| 45 | | | | | | | 1N5040 | 1N5082 | 3EZ43D5 |
| 47 | | 1N5579 | 1N4848 | 1N5941 | 1N4481 | 2EZ47D5 | 1N5041 | 1N5084 | 3EZ47D5 |
| 50 | | | | | | | 1N5042 | 1N5085 | |
| 51 | | 1N5580 | 1N4849 | 1N5942 | 1N4482 | 2EZ51D5 | 1N5043 | 1N5086 | 3EZ51D5 |
| 52 | | | | | | | 1N5044 | | |
| 56 | | 1N5581 | 1N4850 | 1N5943 | 1N4483 | 2EZ56D5 | 1N5045 | 1N5087 | 3EZ56D5 |
| 60 | | | | | | | | 1N5088 | 3EZ60D5 |
| 62 | | 1N5582 | 1N4851 | 1N5944 | 1N4484 | 2EZ62D5 | 1N5046 | 1N5089 | 3EZ62D5 |
| 68 | | 1N5583 | 1N4852 | 1N5945 | 1N4485 | 2EZ68D5 | 1N5047 | 1N5090 | 3EZ68D5 |
| 70 | | | | | | | | 1N5091 | |
| 75 | | 1N5584 | 1N4853 | 1N5946 | 1N4486 | 2EZ75D5 | 1N5048 | 1N5092 | 3EZ75D5 |
| 80 | | | | | | | | 1N5093 | |
| 82 | | 1N5585 | 1N4854 | 1N5947 | 1N4487 | 2EZ82D5 | 1N5049 | 1N5094 | 3EZ82D5 |
| 87 | | | | | | | | | |
| 90 | | | | | | | | 1N4096 | |
| 91 | | 1N5586 | 1N4855 | 1N5948 | 1N4488 | 2EZ91D5 | 1N5050 | 1N5095 | 3EZ91D5 |
| 100 | | 1N5587 | 1N4856 | 1N5949 | 1N4489 | 2EZ100D5 | 1N5051 | 1N4097 | 3EZ100D5 |
| 110 | | 1N5588 | 1N4857 | 1N5950 | 1N4490 | 2EZ110D5 | | 1N5096 | 3EZ110D5 |
| 120 | | 1N5589 | 1N4858 | 1N5951 | 1N4491 | 2EZ120D5 | | 1N5097 | 3EZ120D5 |
| 130 | | 1N5590 | 1N4859 | 1N5952 | 1N4492 | 2EZ130D5 | | 1N5098 | 3EZ130D5 |
| 140 | | | | | | 2EZ140D5 | | 1N5099 | 3EZ140D5 |
| 150 | | 1N5591 | 1N4860 | 1N5953 | 1N4493 | 2EZ150D5 | | 1N4098 | 3EZ150D5 |
| 160 | | 1N5592 | | 1N5954 | 1N4494 | 2EZ160D5 | | 1N5100 | 3EZ160D5 |
| 170 | | | | | | 2EZ170D5 | | 1N5101 | 3EZ170D5 |
| 180 | | 1N5593 | | 1N5955 | 1N4495 | 2EZ180D5 | | 1N5102 | 3EZ180D5 |
| 190 | | | | | | 2EZ190D5 | | 1N5103 | 3EZ190D5 |
| 200 | | 1N5594 | | 1N5956 | 1N4496 | 2EZ200D5 | | 1N5104 | 3EZ200D5 |

GUIDE TO AVAILABLE AXIAL LEADED ZENER DIODES

| | Mil-Std-701 Preferred Mil - Spec | Popular Plastic Package | 10 Watt Stud Package DO-4 Industrial & Military Applications | 50 Watt Stud Package DO-5 Industrial & Military Applications | 50 Watt Diamond Package TO-3 Industrial & Military Applications |
|-----------------|--|-------------------------------|--|--|---|
| Power | 5.0 Watt | 5.0 Watt | | | |
| | "E" | "R" | | | |
| | "E" | | | | |
| Vz Volts | | | | | |
| 1.8 | | | | | |
| 2.0 | | | | | |
| 2.2 | | | | | |
| 2.4 | | | | | |
| 2.7 | | | | | |
| 2.8 | | | | | |
| 3.0 | | | | | |
| 3.3 | | 1N5333 | | | |
| 3.6 | | 1N5334 | | | |
| 3.9 | | 1N5335 | 1N3993 | 1N4549 | 1N4557 |
| 4.3 | | 1N5336 | 1N3994 | 1N4550 | 1N4558 |
| 4.7 | | 1N5337 | 1N3995 | 1N4551 | 1N4559 |
| 5.1 | | 1N5338 | 1N3996 | 1N4552 | 1N4560 |
| 5.6 | 1N5968 | 1N5339 | 1N3997 | 1N4553 | 1N4561 |
| 6.2 | 1N5969 | 1N5341 | 1N3998 | 1N4554 | 1N4562 |
| 6.8 | 1N4954 | 1N5342 | 1N2970 1N3999 | 1N4555 1N3305 | 1N4563 1N2804 |
| 7.1 | | | | | |
| 7.5 | 1N4955 | 1N5343 | 1N2971 1N4000 | 1N4556 1N3306 | 1N4564 1N2805 |
| 8.2 | 1N4956 | 1N5344 | 1N2972 | 1N3307 | 1N2806 |
| 8.6 | | 1N5345 | | | |
| 9.1 | 1N4957 | 1N5346 | 1N2973 | 1N3308 | 1N2807 |
| 10 | 1N4958 | 1N5347 | 1N2974 | 1N3309 | 1N2808 |
| 10.5 | | | | | |
| 11 | 1N4959 | 1N5348 | 1N2975 | 1N3310 | 1N2809 |
| 12 | 1N4960 | 1N5349 | 1N2976 | 1N3311 | 1N2810 |
| 12.8 | | | | | |
| 13 | 1N4961 | 1N5350 | 1N2977 | 1N3312 | 1N2811 |
| 14 | 1N5118 | 1N5351 | 1N2978 | 1N3313 | 1N2812 |
| 15 | 1N4962 | 1N5352 | 1N2979 | 1N3314 | 1N2813 |
| 15.8 | | | | | |
| 16 | 1N4963 | 1N5353 | 1N2980 | 1N3315 | 1N2814 |
| 17 | | 1N5354 | 1N2981 | 1N3316 | 1N2815 |
| 18 | 1N4964 | 1N5355 | 1N2982 | 1N3317 | 1N2816 |
| 19 | | 1N5356 | 1N2983 | 1N3318 | 1N2817 |
| 20 | 1N4965 | 1N5357 | 1N2984 | 1N3319 | 1N2818 |
| 22 | 1N4966 | 1N5358 | 1N2985 | 1N3320 | 1N2819 |
| 23.5 | | | | | |
| 24 | 1N4967 | 1N5359 | 1N2986 | 1N3321 | 1N2820 |
| 25 | | 1N5360 | 1N2987 | 1N3322 | 1N2821 |
| 27 | 1N4968 | 1N5361 | 1N2988 | 1N3323 | 1N2822 |
| 28 | | 1N5362 | | | |
| 30 | 1N4969 | 1N5363 | 1N2989 | 1N3324 | 1N2823 |
| 33 | 1N4970 | 1N5364 | 1N2990 | 1N3325 | 1N2824 |
| 36 | 1N4971 | 1N5365 | 1N2991 | 1N3326 | 1N2825 |
| 39 | 1N4972 | 1N5366 | 1N2992 | 1N3327 | 1N2826 |
| 40 | 1N5119 | | | | |
| 43 | 1N4973 | 1N5367 | 1N2993 | 1N3328 | 1N2827 |
| 43.7 | | | | | |
| 45 | 1N5120 | | 1N2994 | 1N3329 | 1N2828 |
| 47 | 1N4974 | 1N5368 | 1N2995 | 1N3330 | 1N2829 |
| 50 | 1N5121 | | 1N2996 | 1N3331 | 1N2830 |
| 51 | 1N4975 | 1N5369 | 1N2997 | 1N3332 | 1N2831 |
| 52 | | | 1N2998 | 1N3333 | |
| 54.0 | | | | | |
| 56 | 1N4976 | 1N5370 | 1N2999 | 1N3334 | 1N2832 |
| 60 | 1N5122 | 1N5371 | | | |
| 62 | 1N4977 | 1N5372 | 1N3000 | 1N3335 | 1N2833 |
| 68 | 1N4978 | 1N5373 | 1N3001 | 1N3336 | 1N2834 |
| 70 | 1N5123 | | | | |
| 75 | 1N4979 | 1N5374 | 1N3002 | 1N3337 | 1N2835 |
| 80 | 1N5124 | | | | |
| 82 | 1N4980 | 1N5375 | 1N3003 | 1N3338 | 1N2836 |
| 87 | | 1N5376 | | | |
| 90 | 1N5125 | | | | |
| 91 | 1N4981 | 1N5377 | 1N3004 | 1N3339 | 1N2837 |
| 100 | 1N4982 | 1N5378 | 1N3005 | 1N3340 | 1N2838 |
| 105 | | | 1N3006 | 1N3341 | 1N2839 |
| 110 | 1N4983 | 1N5379 | 1N3007 | 1N3342 | 1N2840 |
| 120 | 1N4984 | 1N5380 | 1N3008 | 1N3343 | 1N2841 |
| 130 | 1N4985 | 1N5381 | 1N3009 | 1N3344 | 1N2842 |
| 140 | 1N5126 | 1N5382 | 1N3010 | 1N3345 | |
| 150 | 1N4986 | 1N5383 | 1N3011 | 1N3346 | 1N2843 |
| 160 | 1N4987 | 1N5384 | 1N3012 | 1N3347 | 1N2844 |
| 170 | 1N5127 | 1N5385 | | | |
| 175 | | | 1N3013 | 1N3348 | |
| 180 | 1N4988 | 1N5386 | 1N3014 | 1N3349 | 1N2845 |
| 190 | 1N5128 | 1N5387 | | | |
| 200 | 1N4989 | 1N5388 | 1N3015 | 1N3350 | 1N2846 |



SANTA ANA, CA

SCOTTSDALE, AZ
For more information call:
(602) 941-6300

1N746 thru 1N759A and 1N4370 thru 1N4372A DO-7

1% and 2% VERSIONS
"C" and "D" AVAILABLE

FEATURES

- ZENER VOLTAGE 2.4V to 12.0V
- AVAILABLE IN JAN, JANTX and JANTXV QUALIFICATIONS TO MIL-S-19500/127
- 1N746A THRU 1N759A HAVE S1N QUALIFICATION

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to $+175^{\circ}\text{C}$
DC Power Dissipation: 400 mW
Power Derating: 3.2 mW/ $^{\circ}\text{C}$ above 50°C
Forward Voltage @ 200 mA: 1.5 Volts

ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NO. (NOTE 1) | NOMINAL ZENER VOLTAGE V_Z @ I_{ZT} (NOTE 2) | ZENER TEST CURRENT I_{ZT} | MAXIMUM ZENER IMPEDANCE Z_{ZT} @ I_{ZT} (NOTE 3) | MAXIMUM REVERSE CURRENT @ $V_R = 1$ VOLT | | MAXIMUM ZENER CURRENT I_{ZM} (NOTE 4) | TYPICAL TEMP COEFF. OF ZENER VOLTAGE α_{VZ} |
|----------------------------------|---|--------------------------------------|--|--|--------------------------|---|---|
| | | | | @ 25°C | @ $+150^{\circ}\text{C}$ | | |
| | VOLTS | mA | OHMS | μA | μA | mA | %/ $^{\circ}\text{C}$ |
| 1N4370 | 2.4 | 20 | 30 | 100 | 200 | 150 | -.085 |
| 1N4371 | 2.7 | 20 | 30 | 75 | 150 | 135 | -.080 |
| 1N4372 | 3.0 | 20 | 29 | 50 | 100 | 120 | -.075 |
| 1N746 | 3.3 | 20 | 28 | 10 | 30 | 110 | -.066 |
| 1N747 | 3.6 | 20 | 24 | 10 | 30 | 100 | -.058 |
| 1N748 | 3.9 | 20 | 23 | 10 | 30 | 95 | -.046 |
| 1N749 | 4.3 | 20 | 22 | 2 | 30 | 85 | -.033 |
| 1N750 | 4.7 | 20 | 19 | 2 | 30 | 75 | -.015 |
| 1N751 | 5.1 | 20 | 17 | 1 | 20 | 70 | $\pm .010$ |
| 1N752 | 5.6 | 20 | 11 | 1 | 20 | 65 | $+ .030$ |
| 1N753 | 6.2 | 20 | 7 | .1 | 20 | 60 | $+ .049$ |
| 1N754 | 6.8 | 20 | 5 | .1 | 20 | 55 | $+ .053$ |
| 1N755 | 7.5 | 20 | 6 | .1 | 20 | 50 | $+ .057$ |
| 1N756 | 8.2 | 20 | 8 | .1 | 20 | 45 | $+ .060$ |
| 1N757 | 9.1 | 20 | 10 | .1 | 20 | 40 | $+ .061$ |
| 1N758 | 10.0 | 20 | 17 | .1 | 20 | 35 | $+ .062$ |
| 1N759 | 12.0 | 20 | 30 | .1 | 20 | 30 | $+ .062$ |

*JEDEC Registered Data

NOTE 1 Standard tolerance on JEDEC types shown is $\pm 10\%$. Suffix letter A denotes $\pm 5\%$ tolerance; suffix letter C denotes $\pm 2\%$; and suffix letter D denotes $\pm 1\%$ tolerance.

NOTE 2 Voltage measurements to be performed 20 sec. after application of D.C. test current.

NOTE 3 Zener impedance derived by superimposing on I_{ZT} , a 60 cps, rms ac current equal to $10\% I_{ZT}$ (2 mA ac).

NOTE 4 Allowance has been made for the increase in V_Z due to Z_Z and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 400 mW.

SILICON
400 mW
ZENER DIODES

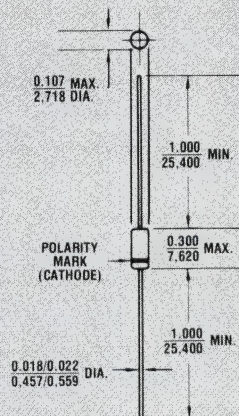


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $300^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N746 thru 1N759A, 1N4370 thru 1N4372A DO-7

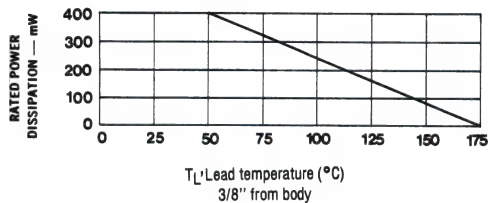


FIGURE 2 POWER DERATING CURVE

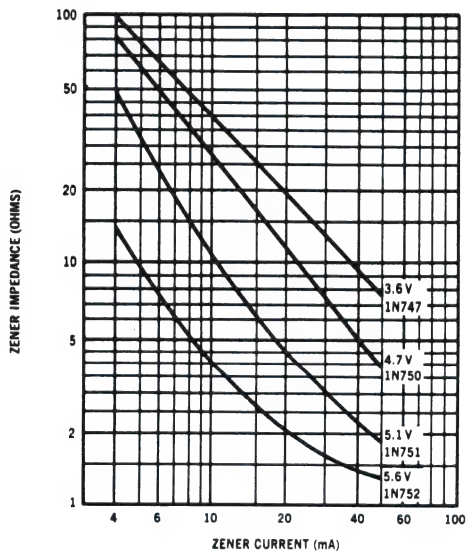


FIGURE 3

ZENER IMPEDANCE VS ZENER CURRENT
(TYPICAL)

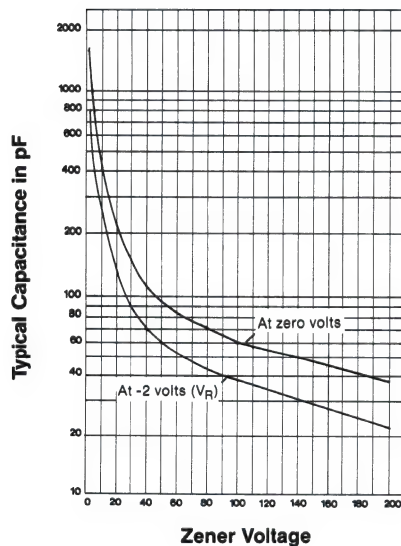


FIGURE 4

CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)



SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

1N746 thru 1N759A and 1N4370 thru 1N4372A DO-35

1% and 2% VERSIONS
"C" and "D" AVAILABLE

FEATURES

- ZENER VOLTAGE 2.4 V to 12.0 V
- AVAILABLE IN JAN, JANTX AND JANTXV-1 QUALIFICATIONS TO MIL-S-19500/127
- METALLURGICALLY BONDED DEVICE TYPES

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +175°C

DC Power Dissipation: 400 mW

Power Derating: 4.0 mW/°C above 75°C

Forward Voltage @ 200 mA: 1.5 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NO. (NOTE 1) | NOMINAL ZENER VOLTAGE V_Z @ I_{ZT} (NOTE 2) | ZENER TEST CURRENT I_{ZT} | MAXIMUM ZENER IMPEDANCE Z_Z @ I_{ZT} (NOTE 3) | MAXIMUM REVERSE CURRENT @ $V_R = 1$ VOLT | | MAXIMUM ZENER CURRENT I_{ZW} (NOTE 4) | TYPICAL TEMP COEFF. OF ZENER VOLTAGE α_{VZ} |
|----------------------------------|---|--------------------------------------|---|--|----------|---|---|
| | | | | @ 25°C | @ +150°C | | |
| | | | | μA | μA | | %/°C |
| 1N4370 | 2.4 | 20 | 30 | 100 | 200 | 150 | -.085 |
| 1N4371 | 2.7 | 20 | 30 | 75 | 150 | 135 | -.080 |
| 1N4372 | 3.0 | 20 | 29 | 50 | 100 | 120 | -.075 |
| 1N746 | 3.3 | 20 | 28 | 10 | 30 | 110 | -.066 |
| 1N747 | 3.6 | 20 | 24 | 10 | 30 | 100 | -.058 |
| 1N748 | 3.9 | 20 | 23 | 10 | 30 | 95 | -.046 |
| 1N749 | 4.3 | 20 | 22 | 2 | 30 | 85 | -.033 |
| 1N750 | 4.7 | 20 | 19 | 2 | 30 | 75 | -.015 |
| 1N751 | 5.1 | 20 | 17 | 1 | 20 | 70 | $\pm .010$ |
| 1N752 | 5.6 | 20 | 11 | 1 | 20 | 65 | + .030 |
| 1N753 | 6.2 | 20 | 7 | .1 | 20 | 60 | + .049 |
| 1N754 | 6.8 | 20 | 5 | .1 | 20 | 55 | + .053 |
| 1N755 | 7.5 | 20 | 6 | .1 | 20 | 50 | + .057 |
| 1N756 | 8.2 | 20 | 8 | .1 | 20 | 45 | + .060 |
| 1N757 | 9.1 | 20 | 10 | .1 | 20 | 40 | + .061 |
| 1N758 | 10.0 | 20 | 17 | .1 | 20 | 35 | + .062 |
| 1N759 | 12.0 | 20 | 30 | .1 | 20 | 30 | + .062 |

*JEDEC Registered Data

NOTE 1 Standard tolerance on JEDEC types shown is $\pm 10\%$. Suffix letter A denotes $\pm 5\%$ tolerance; suffix letter C denotes $\pm 2\%$; and suffix letter D denotes $\pm 1\%$ tolerance.

NOTE 2 Voltage measurements to be performed 20 sec. after application of D.C. test current.

NOTE 3 Zener impedance derived by superimposing on I_{ZT} , a 60 cps, rms ac current equal to $10\% I_{ZT}$ (2 mA ac).

NOTE 4 Allowance has been made for the increase in V_Z due to Z_Z and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 400 mW.

SILICON 400 mW ZENER DIODES

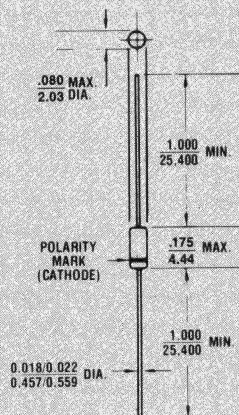


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body. Metallurgically bonded DO-35's exhibit less than 100 °C/W at zero distance from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITIONS: Any.

1N746 thru 1N759A DO-35 1N4370 thru 1N4372A

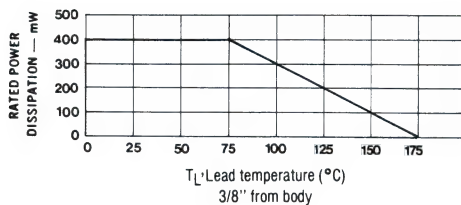


FIGURE 2 POWER DERATING CURVE

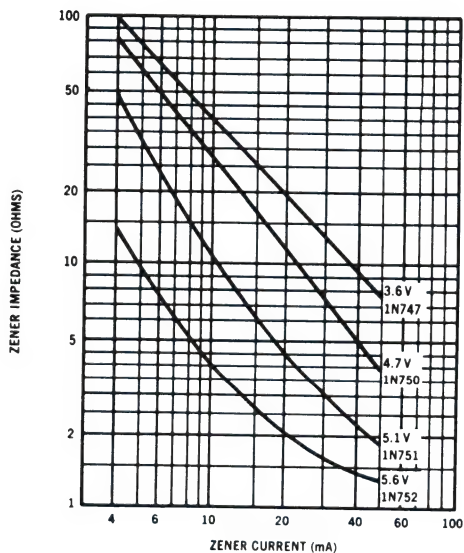


FIGURE 3

ZENER IMPEDANCE VS ZENER CURRENT
(TYPICAL)

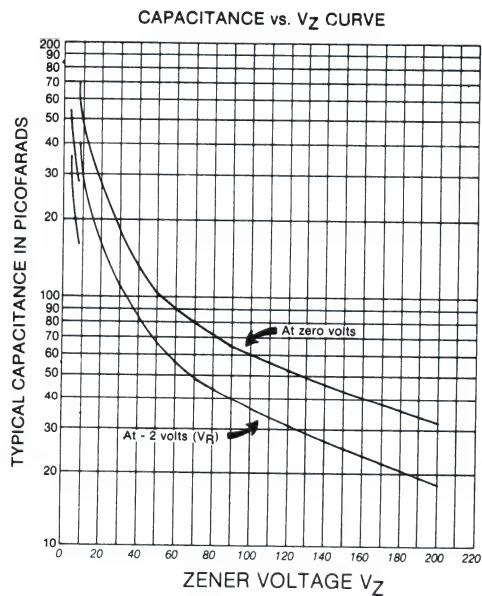


FIGURE 4

CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)

1N754A-1 thru 1N759A-1 DO-35

FEATURES

- ZENER VOLTAGE 6.8 V to 12.0 V
- AVAILABLE IN JAN, JANTX, JANTXV-1 AND JANS QUALIFICATIONS TO MIL-S-19500/127
- METALLURGICALLY BONDED VOIDLESS DEVICE TYPES

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +175°C
DC Power Dissipation: 400 mW
Power Derating: 4.0 mW/°C above 75°C
Forward Voltage @ 200 mA: 1.5 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NO. (NOTE 1) | NOMINAL ZENER VOLTAGE V_Z @ I_{ZT} (NOTE 2) | ZENER TEST CURRENT I_{ZT} | MAXIMUM ZENER IMPEDANCE Z_{ZT} @ I_{ZT} (NOTE 3) | MAXIMUM REVERSE CURRENT @ $V_R = 1$ VOLT | | MAXIMUM ZENER CURRENT I_{ZM} (NOTE 4) | TYPICAL TEMP COEFF. OF ZENER VOLTAGE α_{VZ} |
|----------------------------------|---|--------------------------------------|--|--|----------|---|---|
| | | | | @ 25°C | @ +150°C | | |
| | | | | μA | μA | | % / °C |
| 1N754A | 6.8 | 20 | 5 | .1 | 20 | 55 | + .053 |
| 1N755A | 7.5 | 20 | 6 | .1 | 20 | 50 | + .057 |
| 1N756A | 8.2 | 20 | 8 | .1 | 20 | 45 | + .060 |
| 1N757A | 9.1 | 20 | 10 | .1 | 20 | 40 | + .061 |
| 1N758A | 10.0 | 20 | 17 | .1 | 20 | 35 | + .062 |
| 1N759A | 12.0 | 20 | 30 | .1 | 20 | 30 | + .062 |

* JEDEC Registered Data

NOTE 1 Standard tolerance on JEDEC types shown is $\pm 5\%$.

NOTE 2 Voltage measurements to be performed 20 sec. after application of D.C. test current.

NOTE 3 Zener impedance derived by superimposing on I_{ZT} , a 60 cps, rms ac current equal to 10% I_{ZT} (2 mA ac).

NOTE 4 Allowance has been made for the increase in V_Z due to Z_Z and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 400 mW.

SILICON 400 mW ZENER DIODES

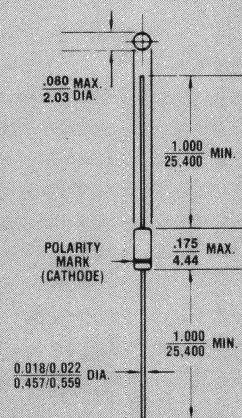


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body. Metallurgically bonded DO-35's exhibit less than 100 °C/W at zero distance from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITIONS: Any.

1N754A-1 thru 1N759A-1 DO-35

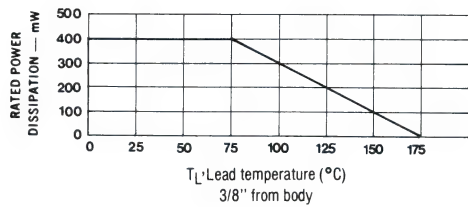


FIGURE 2 POWER DERATING CURVE

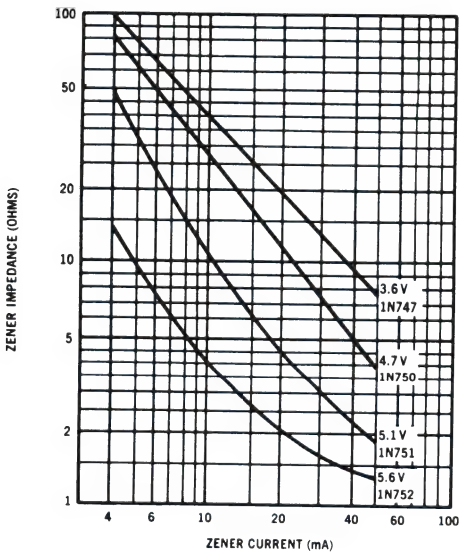


FIGURE 3 ZENER IMPEDANCE VS ZENER CURRENT (TYPICAL)

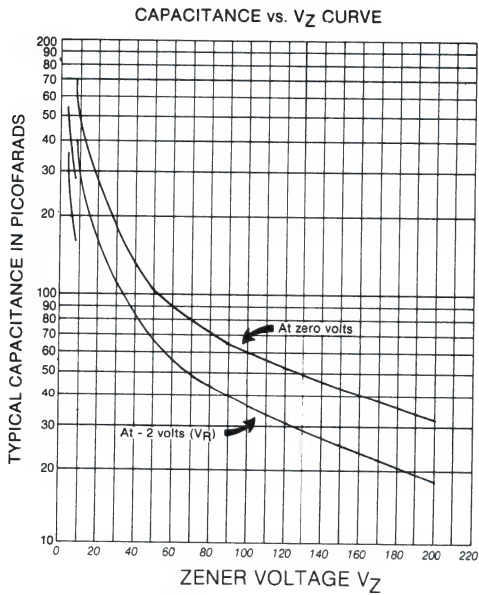


FIGURE 4 CAPACITANCE VS. ZENER VOLTAGE (TYPICAL)

1N957B thru 1N992B DO-7

FEATURES

- 6.8 TO 200V ZENER VOLTAGE RANGE
- 1N962B THRU 1N992B HAVE JAN, JANTX AND JANTXV QUALIFICATIONS TO MIL-S-19500/117
- 1N962B THRU 1N973B HAVE S1N QUALIFICATION

MAXIMUM RATINGS

Steady State Power Dissipation: 400 mW
Operating and Storage Temperatures: -65°C to +175°C
Derating Factor Above 50°C: 3.2 mW/°C
Forward Voltage @ 200 mA: 1.5 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NUMBER (Note 1) | NOMINAL ZENER VOLTAGE (Note 2) V _Z | ZENER TEST CURRENT I _{ZT} | MAX. ZENER IMPEDANCE (Note 3) | | | MAX. DC ZENER CURRENT (Note 4) I _{ZM} | MAX. SURGE CURRENT (RECURRENT) (Note 5) I _Z (SURGE) | MAX. REVERSE LEAKAGE CURRENT | | MAX. TEMP. COEFFICIENT |
|-------------------------------------|---|---|----------------------------------|------|-----|--|--|------------------------------------|-------|---------------------------|
| | VOLTS | mA | OHMS | OHMS | mA | mA | mA | μA | VOLTS | %/°C |
| 1N957B | 6.8 | 18.5 | 4.5 | 700 | 1.0 | 55 | 300 | 150 | 5.2 | +0.05 |
| 1N958B | 7.5 | 16.5 | 5.5 | 700 | .5 | 50 | 275 | 75 | 5.7 | +0.058 |
| 1N959B | 8.2 | 15.0 | 6.5 | 700 | .5 | 45 | 250 | 50 | 6.2 | +0.065 |
| 1N960B | 9.1 | 14.0 | 7.5 | 700 | .5 | 41 | 225 | 25 | 6.9 | +0.068 |
| 1N961B | 10 | 12.5 | 8.5 | 700 | .25 | 38 | 200 | 10 | 7.6 | +0.075 |
| 1N962B | 11 | 11.5 | 9.5 | 700 | .25 | 32 | 175 | 5 | 8.4 | +0.076 |
| 1N963B | 12 | 10.5 | 11.5 | 700 | .25 | 31 | 160 | 5 | 9.1 | +0.077 |
| 1N964B | 13 | 9.5 | 13.0 | 700 | .25 | 28 | 150 | 5 | 9.9 | +0.079 |
| 1N965B | 15 | 8.5 | 16 | 700 | .25 | 25 | 130 | 5 | 11.4 | +0.082 |
| 1N966B | 16 | 7.8 | 17 | 700 | .25 | 24 | 120 | 5 | 12.2 | +0.083 |
| 1N967B | 18 | 7.0 | 21 | 750 | .25 | 20 | 110 | 5 | 13.7 | +0.085 |
| 1N968B | 20 | 6.2 | 25 | 750 | .25 | 18 | 100 | 5 | 15.2 | +0.086 |
| 1N969B | 22 | 5.6 | 29 | 750 | .25 | 16 | 90 | 5 | 16.7 | +0.087 |
| 1N970B | 24 | 5.2 | 33 | 750 | .25 | 15 | 80 | 5 | 18.2 | +0.088 |
| 1N971B | 27 | 4.6 | 41 | 750 | .25 | 13 | 70 | 5 | 20.6 | +0.090 |
| 1N972B | 30 | 4.2 | 49 | 1000 | .25 | 12 | 65 | 5 | 22.8 | +0.091 |
| 1N973B | 33 | 3.8 | 58 | 1000 | .25 | 11 | 60 | 5 | 25.1 | +0.092 |
| 1N974B | 36 | 3.4 | 70 | 1000 | .25 | 10 | 55 | 5 | 27.4 | +0.093 |
| 1N975B | 39 | 3.2 | 80 | 1000 | .25 | 9.5 | 46 | 5 | 29.7 | +0.094 |
| 1N976B | 43 | 3.0 | 93 | 1500 | .25 | 8.8 | 44 | 5 | 32.7 | +0.095 |
| 1N977B | 47 | 2.7 | 105 | 1500 | .25 | 7.9 | 40 | 5 | 35.8 | +0.095 |
| 1N978B | 51 | 2.5 | 125 | 1500 | .25 | 7.4 | 37 | 5 | 38.8 | +0.096 |
| 1N979B | 56 | 2.2 | 150 | 2000 | .25 | 6.8 | 35 | 5 | 42.6 | +0.096 |
| 1N980B | 62 | 2.0 | 185 | 2000 | .25 | 6.0 | 30 | 5 | 47.1 | +0.097 |
| 1N981B | 68 | 1.8 | 230 | 2000 | .25 | 5.5 | 28 | 5 | 51.7 | +0.097 |
| 1N982B | 75 | 1.7 | 270 | 2000 | .25 | 5.0 | 26 | 5 | 56.0 | +0.098 |
| 1N983B | 82 | 1.5 | 330 | 3000 | .25 | 4.6 | 23 | 5 | 62.2 | +0.098 |
| 1N984B | 91 | 1.4 | 400 | 3000 | .25 | 4.1 | 21 | 5 | 69.2 | +0.099 |
| 1N985B | 100 | 1.3 | 500 | 3000 | .25 | 3.7 | 18 | 5 | 76.0 | +0.11 |
| 1N986B | 110 | 1.1 | 750 | 4000 | .25 | 3.3 | 16 | 5 | 83.6 | +0.11 |
| 1N987B | 120 | 1.0 | 900 | 4500 | .25 | 3.1 | 15 | 5 | 91.2 | +0.11 |
| 1N988B | 130 | 0.95 | 1100 | 5000 | .25 | 2.7 | 13 | 5 | 98.8 | +0.11 |
| 1N989B | 150 | 0.85 | 1500 | 6000 | .25 | 2.4 | 12 | 5 | 114.0 | +0.11 |
| 1N990B | 160 | 0.80 | 1700 | 6500 | .25 | 2.2 | 11 | 5 | 121.6 | +0.11 |
| 1N991B | 180 | 0.68 | 2200 | 7100 | .25 | 2.0 | 10 | 5 | 136.8 | +0.11 |
| 1N992B | 200 | 0.65 | 2500 | 8000 | .25 | 1.8 | 9 | 5 | 152.0 | +0.11 |

*JEDEC Registered Data

SILICON 400 mW ZENER DIODES

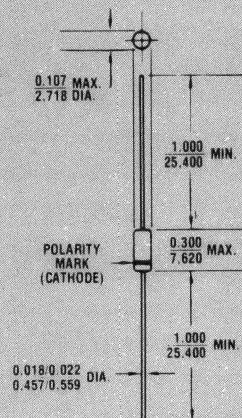


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N957B thru 1N992B DO-7

NOTE 1 The JEDEC type numbers shown (B suffix) have a $\pm 5\%$ tolerance on nominal zener voltage. The suffix A is used to identify $\pm 10\%$ tolerance; suffix C is used to identify $\pm 2\%$; and suffix D is used to identify $\pm 1\%$ tolerance; no suffix indicates $\pm 20\%$ tolerance.

NOTE 2 Zener voltage (V_Z) is measured after the test current has been applied for 20 ± 5 seconds. The device shall be suspended by its leads with the inside edge of the mounting clips between .375" and .500" from the body. Mounting clips shall be maintained at a temperature of $25 \pm 8/-2^\circ\text{C}$.

NOTE 3 The zener impedance is derived from the 60 cycle A.C. voltage, which results when an A.C. current

having an R.M.S. value equal to 10% of the D.C. zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at 2 points to insure a sharp knee on the breakdown curve and to eliminate unstable units.

NOTE 4 The values of I_{ZM} are calculated for a $\pm 5\%$ tolerance on nominal zener voltage. Allowance has been made for the rise in zener voltage above V_{ZT} which results from zener impedance and the increase in junction temperature as power dissipation approaches 400 mW. In the case of individual diodes I_{ZM} is that value of current which results in a dissipation of 400 mW at 50°C lead temperature at 3/8" from body.

NOTE 5 Surge is 1/2 square wave or equivalent sine wave pulse of 1/120 sec. duration.

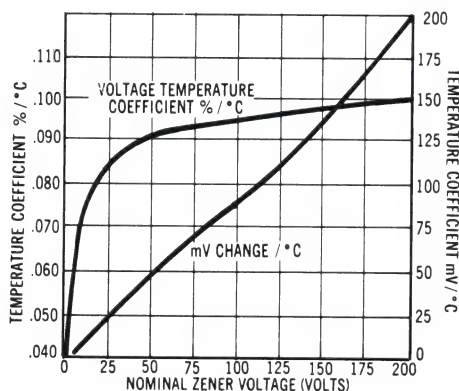


FIGURE 2

ZENER VOLTAGE TEMPERATURE
COEFF. vs. ZENER VOLTAGE

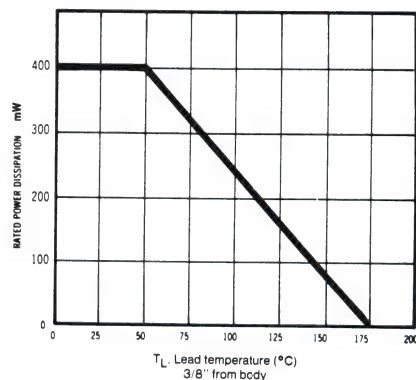


FIGURE 3

POWER DERATING CURVE

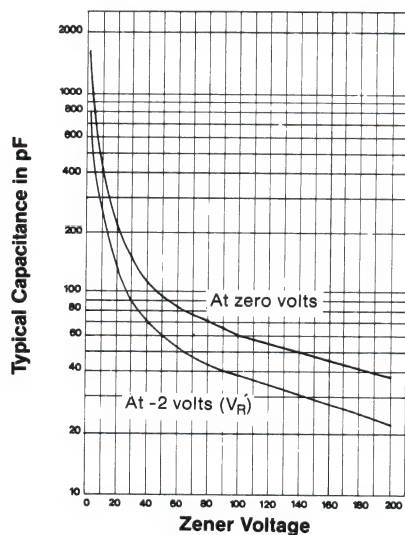


FIGURE 4

CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)

1N957B thru 1N992B DO-35

FEATURES

- 6.8 TO 200V ZENER VOLTAGE RANGE
- 1N962B-1 THRU 1N992B-1 AVAILABLE IN JAN, JANTX AND JANTXV QUALIFICATIONS TO MIL-S-19500/117
- METALLURGICALLY BONDED DEVICE TYPES
- CONSULT FACTORY FOR VOLTAGES ABOVE 200 V

MAXIMUM RATINGS

Steady State Power Dissipation: 400 mW
Operating and Storage Temperature: -65°C to +175°C
Derating Factor Above 75°C: 4.0 mW/°C
Forward Voltage @ 200 mA: 1.5 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NUMBER (Note 1) | NOMINAL ZENER VOLTAGE (Note 2) V _Z | ZENER TEST CURRENT I _{ZT} | MAX. ZENER IMPEDANCE (Note 3) | | MAX. DC ZENER CURRENT (Note 4) I _{ZW} | MAX. SURGE CURRENT (RECURRENT) (Note 5) I _Z (SURGE) | MAX. REVERSE LEAKAGE CURRENT | | MAX. TEMP. COEFFICIENT C _{VZ} | |
|-------------------------------------|---|---|-----------------------------------|-----------------------------------|--|--|------------------------------------|----------------|--|--------|
| | | | Z _{2T} @ I _{ZT} | Z _{2K} @ I _{ZK} | | | μA | V _A | | |
| | VOLTS | mA | OHMS | OHMS | mA | mA | μA | VOLTS | %/°C | |
| 1N957B | 6.8 | 18.5 | 4.5 | 700 | 1.0 | 55 | 300 | 150 | 5.2 | +0.05 |
| 1N958B | 7.5 | 16.5 | 5.5 | 700 | .5 | 50 | 275 | 75 | 5.7 | +0.058 |
| 1N959B | 8.2 | 15.0 | 6.5 | 700 | .5 | 45 | 250 | 50 | 6.2 | +0.065 |
| 1N960B | 9.1 | 14.0 | 7.5 | 700 | .5 | 41 | 225 | 25 | 6.9 | +0.068 |
| 1N961B | 10 | 12.5 | 8.5 | 700 | .25 | 38 | 200 | 10 | 7.6 | +0.075 |
| 1N962B | 11 | 11.5 | 9.5 | 700 | .25 | 32 | 175 | 5 | 8.4 | +0.076 |
| 1N963B | 12 | 10.5 | 11.5 | 700 | .25 | 31 | 160 | 5 | 9.1 | +0.077 |
| 1N964B | 13 | 9.5 | 13.0 | 700 | .25 | 28 | 150 | 5 | 9.9 | +0.079 |
| 1N965B | 15 | 8.5 | 16 | 700 | .25 | 25 | 130 | 5 | 11.4 | +0.082 |
| 1N966B | 16 | 7.8 | 17 | 700 | .25 | 24 | 120 | 5 | 12.2 | +0.083 |
| 1N967B | 18 | 7.0 | 21 | 750 | .25 | 20 | 110 | 5 | 13.7 | +0.085 |
| 1N968B | 20 | 6.2 | 25 | 750 | .25 | 18 | 100 | 5 | 15.2 | +0.086 |
| 1N969B | 22 | 5.6 | 29 | 750 | .25 | 16 | 90 | 5 | 16.7 | +0.087 |
| 1N970B | 24 | 5.2 | 33 | 750 | .25 | 15 | 80 | 5 | 18.2 | +0.088 |
| 1N971B | 27 | 4.6 | 41 | 750 | .25 | 13 | 70 | 5 | 20.6 | +0.090 |
| 1N972B | 30 | 4.2 | 49 | 1000 | .25 | 12 | 65 | 5 | 22.8 | +0.091 |
| 1N973B | 33 | 3.8 | 58 | 1000 | .25 | 11 | 60 | 5 | 25.1 | +0.092 |
| 1N974B | 36 | 3.4 | 70 | 1000 | .25 | 10 | 55 | 5 | 27.4 | +0.093 |
| 1N975B | 39 | 3.2 | 80 | 1000 | .25 | 9.5 | 46 | 5 | 29.7 | +0.094 |
| 1N976B | 43 | 3.0 | 93 | 1500 | .25 | 8.8 | 44 | 5 | 32.7 | +0.095 |
| 1N977B | 47 | 2.7 | 105 | 1500 | .25 | 7.9 | 40 | 5 | 35.8 | +0.095 |
| 1N978B | 51 | 2.5 | 125 | 1500 | .25 | 7.4 | 37 | 5 | 38.8 | +0.096 |
| 1N979B | 56 | 2.2 | 150 | 2000 | .25 | 6.8 | 35 | 5 | 42.6 | +0.096 |
| 1N980B | 62 | 2.0 | 185 | 2000 | .25 | 6.0 | 30 | 5 | 47.1 | +0.097 |
| 1N981B | 68 | 1.8 | 230 | 2000 | .25 | 5.5 | 28 | 5 | 51.7 | +0.097 |
| 1N982B | 75 | 1.7 | 270 | 2000 | .25 | 5.0 | 26 | 5 | 56.0 | +0.098 |
| 1N983B | 82 | 1.5 | 330 | 3000 | .25 | 4.6 | 23 | 5 | 62.2 | +0.098 |
| 1N984B | 91 | 1.4 | 400 | 3000 | .25 | 4.1 | 21 | 5 | 69.2 | +0.099 |
| 1N985B | 100 | 1.3 | 500 | 3000 | .25 | 3.7 | 18 | 5 | 76.0 | +0.11 |
| 1N986B | 110 | 1.1 | 750 | 4000 | .25 | 3.3 | 16 | 5 | 83.6 | +0.11 |
| 1N987B | 120 | 1.0 | 900 | 4500 | .25 | 3.1 | 15 | 5 | 91.2 | +0.11 |
| 1N988B | 130 | 0.95 | 1100 | 5000 | .25 | 2.7 | 13 | 5 | 98.8 | +0.11 |
| 1N989B | 150 | 0.85 | 1500 | 6000 | .25 | 2.4 | 12 | 5 | 114.0 | +0.11 |
| 1N990B | 160 | 0.80 | 1700 | 6500 | .25 | 2.2 | 11 | 5 | 121.6 | +0.11 |
| 1N991B | 180 | 0.68 | 2200 | 7100 | .25 | 2.0 | 10 | 5 | 136.8 | +0.11 |
| 1N992B | 200 | 0.65 | 2500 | 8000 | .25 | 1.8 | 9 | 5 | 152.0 | +0.11 |

*JEDEC Registered Data

SILICON 400 mW ZENER DIODES

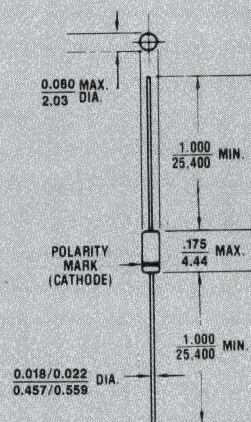


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body. Metallurgically bonded DO-35's exhibit less than 100°C/W at zero distance from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N957B thru 1N992B DO-35

NOTE 1 The JEDEC type numbers shown (B suffix) have a $\pm 5\%$ tolerance on nominal zener voltage. The suffix A is used to identify $\pm 10\%$ tolerance; suffix C is used to identify $\pm 2\%$; and suffix D is used to identify $\pm 1\%$ tolerance; no suffix indicates $\pm 20\%$ tolerance.

NOTE 2 Zener voltage (V_Z) is measured after the test current has been applied for 20 ± 5 seconds. The device shall be suspended by its leads with the inside edge of the mounting clips between .375" and .500" from the body. Mounting clips shall be maintained at a temperature of $25 \pm 8/-2^\circ\text{C}$.

NOTE 3 The zener impedance is derived from the 60 cycle A.C. voltage, which results when an A.C. current

having an R.M.S. value equal to 10% of the D.C. zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at 2 points to insure a sharp knee on the breakdown curve and to eliminate unstable units.

NOTE 4 The values of I_{ZM} are calculated for a $\pm 5\%$ tolerance on nominal zener voltage. Allowance has been made for the rise in zener voltage above V_{ZT} which results from zener impedance and the increase in junction temperature as power dissipation approaches 400 mW. In the case of individual diodes I_{ZM} is that value of current which results in a dissipation of 400 mW at 75°C lead temperature at 3/8" from body.

NOTE 5 Surge is 1/2 square wave or equivalent sine wave pulse of 1/120 sec. duration.

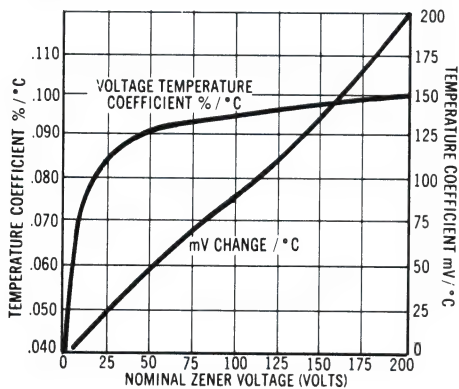


FIGURE 2

ZENER VOLTAGE TEMPERATURE
COEFF. vs. ZENER VOLTAGE

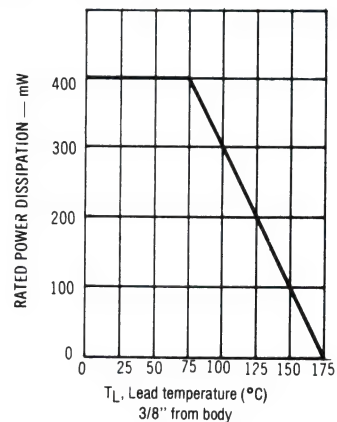


FIGURE 3

POWER DERATING CURVE

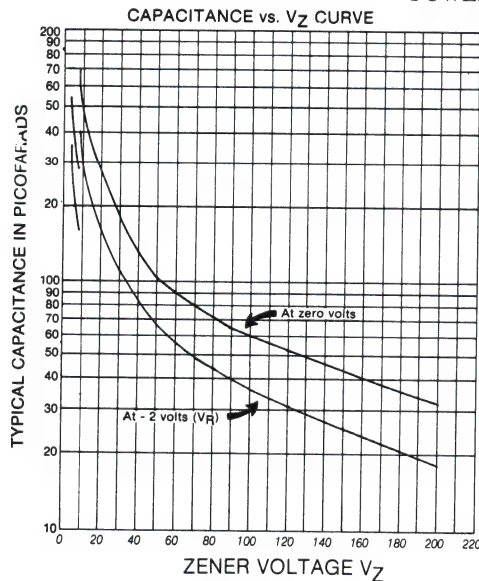


FIGURE 4

CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)



SANTA ANA, CA
For more information call:
(714) 979-8220

SCOTTSDALE, AZ

**1N962B
thru
1N973B
DO-35**

☆ JANS ☆

FEATURES

- 6.8 TO 200V ZENER VOLTAGE RANGE
- AVAILABLE IN JAN, JANTX AND JANTXV, AND JANS QUALIFICATIONS TO MIL-S-19500/117
- METALLURGICALLY BONDED VOIDLESS DEVICE TYPES
- CONSULT FACTORY FOR VOLTAGES ABOVE 200 V

MAXIMUM RATINGS

Steady State Power Dissipation: 400 mW
Operating and Storage Temperature: - 65°C to + 175°C
Derating Factor Above 75°C: 4.0 mW/°C
Forward Voltage @ 200 mA: 1.5 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NUMBER (Note 1) | NOMINAL ZENER VOLTAGE (Note 2) V _Z | ZENER TEST CURRENT I _{ZT} | MAX. ZENER IMPEDANCE (Note 3) | | | MAX. DC ZENER CURRENT (Note 4) I _{ZM} | MAX. SURGE CURRENT (RECURRENT) (Note 5) I _Z (SURGE) | MAX. REVERSE LEAKAGE CURRENT | | MAX. TEMP. COEFFICIENT α _{VZ} |
|-------------------------------------|---|---|-----------------------------------|-----------------------------------|-----------------------------------|--|--|------------------------------------|----------------|--|
| | | | Z _{1T} @ I _{ZT} | Z _{2K} @ I _{ZK} | Z _{3K} @ I _{ZK} | | | I _L | V _L | |
| | VOLTS | mA | OHMS | OHMS | mA | mA | mA | μA | VOLTS | %/°C |
| 1N962B | 11 | 11.5 | 9.5 | 700 | .25 | 32 | 175 | 5 | 8.4 | +0.076 |
| 1N963B | 12 | 10.5 | 11.5 | 700 | .25 | 31 | 160 | 5 | 9.1 | +0.077 |
| 1N964B | 13 | 9.5 | 13.0 | 700 | .25 | 28 | 150 | 5 | 9.9 | +0.078 |
| 1N965B | 15 | 8.5 | 16 | 700 | .25 | 25 | 130 | 5 | 11.4 | +0.082 |
| 1N966B | 16 | 7.8 | 17 | 700 | .25 | 24 | 120 | 5 | 12.2 | +0.083 |
| 1N967B | 18 | 7.0 | 21 | 750 | .25 | 20 | 110 | 5 | 13.7 | +0.085 |
| 1N968B | 20 | 6.2 | 25 | 750 | .25 | 18 | 100 | 5 | 15.2 | +0.086 |
| 1N969B | 22 | 5.6 | 29 | 750 | .25 | 16 | 90 | 5 | 16.7 | +0.087 |
| 1N970B | 24 | 5.2 | 33 | 750 | .25 | 15 | 80 | 5 | 18.2 | +0.088 |
| 1N971B | 27 | 4.6 | 41 | 750 | .25 | 13 | 70 | 5 | 20.6 | +0.090 |
| 1N972B | 30 | 4.2 | 49 | 1000 | .25 | 12 | 65 | 5 | 22.8 | +0.091 |
| 1N973B | 33 | 3.8 | 58 | 1000 | .25 | 11 | 60 | 5 | 25.1 | +0.092 |

* JEDEC Registered Data

**SILICON
400 mW
ZENER DIODES**

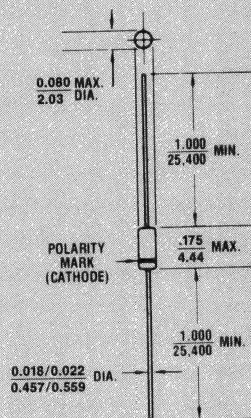


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case, DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body. Metallurgically bonded DO-35's exhibit less than 100°C/W at zero distance from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N962B thru 1N973B DO-35

NOTE 1 The JEDEC type numbers shown (B suffix) have a $\pm 5\%$ tolerance on nominal zener voltage. The suffix A is used to identify $\pm 10\%$ tolerance; suffix C is used to identify $\pm 2\%$; and suffix D is used to identify $\pm 1\%$ tolerance; no suffix indicates $\pm 20\%$ tolerance.

NOTE 2 Zener voltage (V_Z) is measured after the test current has been applied for 20 ± 5 seconds. The device shall be suspended by its leads with the inside edge of the mounting clips between .375" and .500" from the body. Mounting clips shall be maintained at a temperature of $25 \pm 8/-2^\circ\text{C}$.

NOTE 3 The zener impedance is derived from the 60 cycle A.C. voltage, which results when an A.C. current

having an R.M.S. value equal to 10% of the D.C. zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at 2 points to insure a sharp knee on the breakdown curve and to eliminate unstable units.

NOTE 4 The values of I_{ZM} are calculated for a $\pm 5\%$ tolerance on nominal zener voltage. Allowance has been made for the rise in zener voltage above V_{ZT} which results from zener impedance and the increase in junction temperature as power dissipation approaches 400 mW. In the case of individual diodes I_{ZM} is that value of current which results in a dissipation of 400 mW at 50°C lead temperature at 3/8" from body.

NOTE 5 Surge is 1/2 square wave or equivalent sine wave pulse of 1/120 sec. duration.

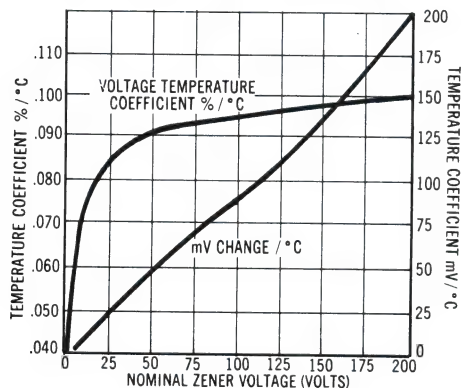


FIGURE 2
ZENER VOLTAGE TEMPERATURE
COEFF. vs. ZENER VOLTAGE

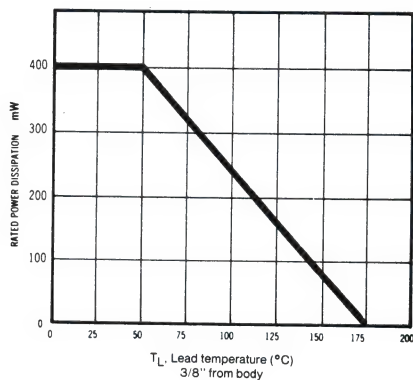


FIGURE 3
POWER DERATING CURVE

SANTA ANA, CA

SCOTTSDALE, AZ
For more information call:
(602) 941-6300

1N2804 thru 1N2846B and 1N4557B thru 1N4564B

FEATURES

- ZENER VOLTAGE 3.9V to 200V
- AVAILABLE IN TOLERANCES OF $\pm 5\%$, $\pm 10\%$ and $\pm 20\%$
- DESIGNED FOR MILITARY ENVIRONMENTS (See Below)

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to $+175^{\circ}\text{C}$

DC Power Dissipation: 50 watts

Power Derating: $0.5\text{W}/^{\circ}\text{C}$ above 75°C

Forward Voltage @ 10 A: 1.5 Volts

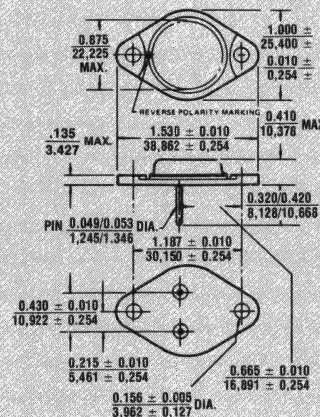
* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NO. (Note 1) | NOMINAL ZENER VOLTAGE V_z @ I_z (Note 2) | ZENER TEST CURRENT I_z mA | MAX. ZENER IMPEDANCE (Note 3) | | MAX. DC ZENER CURRENT (I_{zm}) @ 75°C Case Temp. (Note 4) mA | TYPICAL ZENER VOLTAGE Temp. Coeff. C_{Vz} %/°C | MAXIMUM LEAKAGE CURRENT ** $I_{L@V_R}$ | |
|-------------------------------|--|--------------------------------------|----------------------------------|---------------------------|--|---|--|-------|
| | | | $Z_{0.1}$ @ I_z OHMS | $Z_{0.5}$ @ I_z OHMS | | | μA | V |
| †1N4557B | 3.9 | 3200 | 0.16 | 400 | 11,900 | -0.046 | 150 | 0.5 |
| †1N4558B | 4.3 | 2900 | 0.16 | 500 | 10,650 | -0.033 | 150 | 0.5 |
| †1N4559B | 4.7 | 2650 | 0.12 | 600 | 9,700 | -0.015 | 100 | 1 |
| †1N4560B | 5.1 | 2450 | 0.12 | 650 | 8,900 | ± 0.010 | 20 | 1 |
| †1N4561B | 5.6 | 2250 | 0.12 | 900 | 8,100 | +0.03 | 20 | 1 |
| †1N4562B | 6.2 | 2000 | 0.14 | 1000 | 7,300 | +0.049 | 20 | 2 |
| †1N4563B | 6.8 | 1850 | 0.16 | 200 | 6,650 | +0.053 | 10 | 2 |
| †1N4564B | 7.5 | 1650 | 0.24 | 100 | 6,050 | +0.057 | 10 | 3 |
| †1N2804B | 6.8 | 1850 | 0.2 | 70 | 7,400 | .040 | 150 | 4.5 |
| †1N2805B | 7.5 | 1700 | 0.3 | 70 | 6,600 | .045 | 100 | 5 |
| †1N2806B | 8.2 | 1500 | 0.4 | 70 | 5,800 | .048 | 50 | 5.4 |
| †1N2807B | 9.1 | 1370 | 0.5 | 70 | 5,300 | .050 | 25 | 6.1 |
| †1N2808B | 10 | 1200 | 0.6 | 80 | 4,800 | .055 | 25 | 6.7 |
| †1N2809B | 11 | 1100 | 0.8 | 80 | 4,300 | .060 | 10 | 8.4 |
| †1N2810B | 12 | 1000 | 1.0 | 80 | 4,000 | .065 | 10 | 9.1 |
| †1N2811B | 13 | 960 | 1.1 | 80 | 3,700 | .065 | 10 | 9.9 |
| 1N2812B | 14 | 890 | 1.2 | 80 | 3,400 | .070 | 10 | 10.6 |
| †1N2813B | 15 | 830 | 1.4 | 80 | 3,100 | .070 | 10 | 11.4 |
| †1N2814B | 16 | 780 | 1.6 | 80 | 2,950 | .070 | 10 | 12.2 |
| 1N2815B | 17 | 740 | 1.8 | 80 | 2,750 | .075 | 10 | 13.0 |
| †1N2816B | 18 | 700 | 2.0 | 80 | 2,550 | .075 | 10 | 13.7 |
| 1N2817B | 19 | 660 | 2.2 | 80 | 2,450 | .075 | 10 | 14.4 |
| †1N2818B | 20 | 630 | 2.4 | 80 | 2,350 | .075 | 10 | 15.2 |
| †1N2819B | 22 | 570 | 2.5 | 80 | 2,100 | .080 | 10 | 16.7 |
| †1N2820B | 24 | 520 | 2.6 | 80 | 1,950 | .080 | 10 | 18.2 |
| 1N2821B | 25 | 500 | 2.7 | 90 | 1,850 | .080 | 10 | 19 |
| 1N2822B | 27 | 460 | 2.8 | 90 | 1,650 | .085 | 10 | 20.6 |
| †1N2823B | 30 | 420 | 3.0 | 90 | 1,550 | .085 | 10 | 22.8 |
| †1N2824B | 33 | 380 | 3.2 | 90 | 1,450 | .085 | 10 | 25.1 |
| †1N2825B | 36 | 350 | 3.5 | 90 | 1,300 | .085 | 10 | 27.4 |
| †1N2826B | 39 | 320 | 4.0 | 90 | 1,175 | .090 | 10 | 29.7 |
| †1N2827B | 43 | 290 | 4.5 | 90 | 1,075 | .090 | 10 | 32.7 |
| 1N2828B | 45 | 280 | 4.5 | 100 | 1,030 | .090 | 10 | 34.2 |
| †1N2829B | 47 | 270 | 5.0 | 100 | 980 | .090 | 10 | 35.8 |
| 1N2830B | 50 | 250 | 5.0 | 100 | 935 | .090 | 10 | 38 |
| †1N2831B | 51 | 245 | 5.2 | 100 | 925 | .090 | 10 | 38.8 |
| †1N2832B | 56 | 220 | 6 | 110 | 825 | .090 | 10 | 42.6 |
| †1N2833B | 62 | 200 | 7 | 120 | 735 | .090 | 10 | 47.1 |
| †1N2834B | 68 | 180 | 8 | 140 | 670 | .090 | 10 | 51.7 |
| †1N2835B | 75 | 170 | 9 | 150 | 600 | .090 | 10 | 56 |
| †1N2836B | 82 | 150 | 11 | 160 | 550 | .090 | 10 | 62.2 |
| †1N2837B | 91 | 140 | 15 | 180 | 470 | .090 | 10 | 69.2 |
| †1N2838B | 100 | 120 | 20 | 200 | 450 | .090 | 10 | 76 |
| 1N2839B | 105 | 120 | 25 | 210 | 430 | .095 | 10 | 79.8 |
| †1N2840B | 110 | 110 | 30 | 220 | 410 | .095 | 10 | 83.6 |
| †1N2841B | 120 | 100 | 40 | 240 | 375 | .095 | 10 | 91.2 |
| †1N2842B | 130 | 95 | 50 | 275 | 345 | .095 | 10 | 98.8 |
| †1N2843B | 150 | 85 | 75 | 400 | 300 | .095 | 10 | 114.0 |
| †1N2844B | 160 | 80 | 80 | 450 | 285 | .095 | 10 | 121.6 |
| †1N2845B | 180 | 68 | 90 | 525 | 250 | .095 | 10 | 136.8 |
| †1N2846B | 200 | 65 | 100 | 600 | 220 | .100 | 10 | 152.0 |

*JEDEC Registered Data. **Not JEDEC Data.

†Have JAN, JANTX and JANTXV Qualifications to MIL-S-19500/114.

SILICON 50 WATT ZENER DIODES



All dimensions in $\frac{\text{INCH}}{\text{m.m.}}$ **FIGURE 1**

MECHANICAL CHARACTERISTICS

CASE: Industry Standard TO-3, (modified), hermetically sealed, 0.052 inch diameter pins.

FINISH: All external surfaces are corrosion resistant and terminal solderable.

THERMAL RESISTANCE: $1.5^{\circ}\text{C}/\text{W}$ (Typical) junction to base.

POLARITY: Standard Polarity units are connected anode to case. Reverse polarity (cathode to case is indicated by a red dot on the base plate. (Suffix R)

WEIGHT: 15 grams.

MOUNTING HARDWARE: See page 41.

1N2804 thru 1N2846B, 1N457B thru 1N4564B

NOTE 1 The JEDEC type numbers shown (B suffix) have a $\pm 5\%$ tolerance on nominal zener voltage. The suffix A is used to identify $\pm 10\%$ tolerance; no suffix indicates $\pm 20\%$ tolerance. If tighter tolerance is required, consult factory. Standard polarity units have the anode connected to the case. Reverse polarity (cathode-to-case) units are available and are indicated by suffixing an R to the part number.

NOTE 2 Zener Voltage (V_Z) is measured with junction in thermal equilibrium with 30°C base temperature. The test currents (I_{ZT}) have been selected so that at nominal voltages the dissipation is a constant 12.5 watts. This results in a nominal junction temperature rise of 18.75°C .

NOTE 3 The zener impedance is derived from the 60 cycle A.C. voltage, which results when an A.C. current having an R.M.S. value equal to 10% of the D.C. zener current (I_{zt} or I_{zk}) is superimposed on I_{zt} or I_{zk} . Zener impedance is measured at 2 points to insure a sharp knee on the breakdown curve and to eliminate unstable units. A curve showing the variation of zener impedance vs. zener current for six representative types is shown in Figure 3. A 100% cathode ray tube curve trace test is used to insure that each zener diode breakdown region begins at a current lower than I_{zk} and continues at nearly constant voltage to a current level in excess of I_{zm} .

NOTE 4 The values of I_{zm} are calculated for a $\pm 5\%$ tolerance on nominal zener voltage. Allowance has been made for the rise in zener voltage above V_{zt} which results from zener impedance and the increase in junction temperature as power dissipation approaches 50 watts. In the case of individual diodes I_{zm} is that value of current which results in a dissipation of 50 watts.

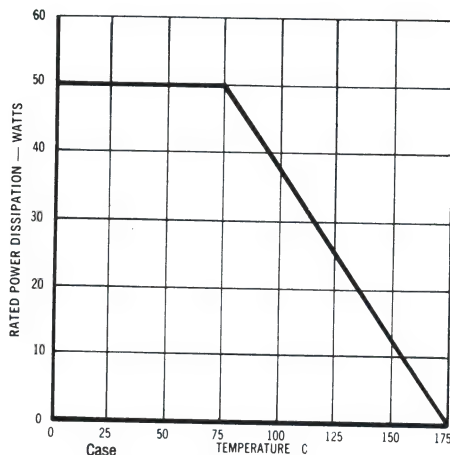
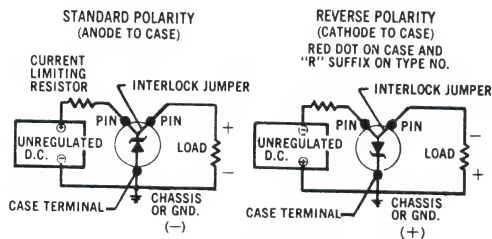


FIGURE 2
POWER DERATING CURVE



Typical circuit connections for anode-to-case and cathode-to-case polarities (standard and reverse polarities, respectively).

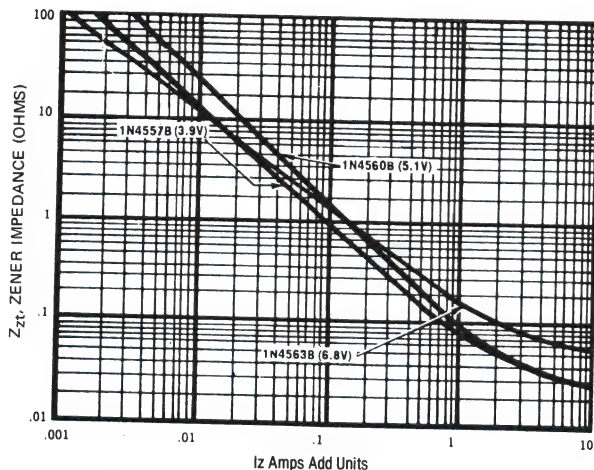
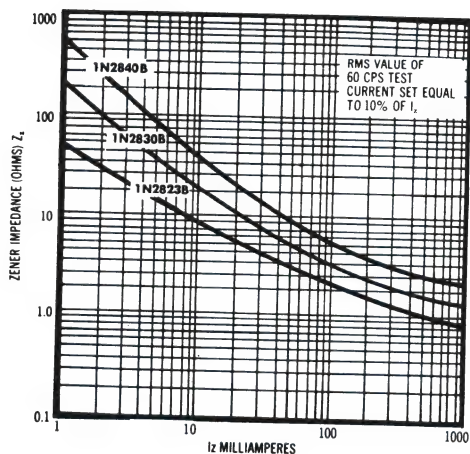


FIGURE 3

TYPICAL ZENER IMPEDANCE vs. ZENER CURRENT
FOR TYPES SHOWN

1N2970 thru 1N3015B and 1N3993 thru 1N4000A

FEATURES

- ZENER VOLTAGE 3.9 to 200V
- VOLTAGE TOLERANCES; $\pm 5\%$, $\pm 10\%$ and $\pm 20\%$ (See Note 1)
- MAXIMUM RELIABILITY FOR MILITARY ENVIRONMENTS (See † Below)

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to $+175^{\circ}\text{C}$

DC Power Dissipation: 10 Watts

Power Derating: 80 mW/ $^{\circ}\text{C}$ above 50°C

Forward Voltage @ 2.0 A: 1.5 Volts

*ELECTRICAL CHARACTERISTICS @ 30°C Case Temperature

| JEDEC TYPE NO. (Note 1) | NOMINAL ZENER VOLTAGE V_Z @ I_{ZT} (Note 2) | ZENER TEST CURRENT I_{ZT} mA | MAX. DYNAMIC IMPEDANCE (Note 3) | | MAX. DC ZENER CURRENT I_{ZM} @ 75°C Stud Temp. (Note 4) mA | TYPICAL TEMP. COEFF. α_{VZ} %/C | MAX** LEAKAGE CURRENT I_R @ V_R Volts | | POLARITY |
|-------------------------------|---|--|---------------------------------------|-----------------------------|--|--|---|-------|---|
| | | | Z_{01} @ I_{ZT} OHMS | Z_{0k} @ I_{mk} OHMS | | | | | |
| †1N3993A | 3.9 | 640 | 2.0 | 400 | 2390 | -0.046 | 100 | 0.5 | STD. POLARITY CATHODE TO STUD |
| †1N3994A | 4.3 | 580 | 1.5 | 400 | 2130 | -0.033 | 100 | 0.5 | |
| †1N3995A | 4.7 | 530 | 1.2 | 500 | 1940 | -0.015 | 50 | 1.0 | |
| †1N3996A | 5.1 | 490 | 1.1 | 550 | 1780 | ± 0.010 | 10 | 1.0 | |
| †1N3997A | 5.6 | 445 | 1.0 | 600 | 1620 | +0.030 | 10 | 1.0 | |
| †1N3998A | 6.2 | 405 | 1.1 | 750 | 1460 | +0.049 | 10 | 2.0 | |
| †1N3999A | 6.8 | 370 | 1.2 | 500 | 1330 | +0.040 | 10 | 2.0 | STD. POLARITY ANODE TO STUD |
| †1N4000A | 7.5 | 335 | 1.3 | 250 | 1210 | +0.045 | 10 | 3.0 | |
| †1N2970B | 6.8 | 370 | 1.2 | 500 | 1320 | .040 | 150 | 5.2 | |
| †1N2971B | 7.5 | 335 | 1.3 | 250 | 1180 | .045 | 100 | 5.7 | |
| †1N2972B | 8.2 | 305 | 1.5 | 250 | 1040 | .048 | 50 | 6.2 | |
| †1N2973B | 9.1 | 275 | 2.0 | 250 | 960 | .051 | 25 | 6.9 | |
| †1N2974B | 10 | 250 | 3 | 250 | 860 | .055 | 25 | 7.6 | |
| †1N2975B | 11 | 230 | 3 | 250 | 780 | .060 | 10 | 8.4 | |
| †1N2976B | 12 | 210 | 3 | 250 | 720 | .065 | 10 | 9.1 | STD. POLARITY CATHODE TO STUD |
| †1N2977B | 13 | 190 | 3 | 250 | 660 | .065 | 10 | 9.9 | |
| †1N2978B | 14 | 180 | 3 | 250 | 600 | .070 | 10 | 10.5 | |
| †1N2979B | 15 | 170 | 3 | 250 | 560 | .070 | 10 | 11.4 | |
| †1N2980B | 16 | 155 | 4 | 250 | 530 | .070 | 10 | 12.2 | |
| †1N2981B | 17 | 145 | 4 | 250 | 500 | .075 | 10 | 13.0 | |
| †1N2982B | 18 | 140 | 4 | 250 | 460 | .075 | 10 | 13.7 | STD. POLARITY ANODE TO STUD |
| †1N2983B | 19 | 130 | 4 | 250 | 440 | .075 | 10 | 14.0 | |
| †1N2984B | 20 | 125 | 4 | 250 | 420 | .075 | 10 | 15.2 | |
| †1N2985B | 22 | 115 | 5 | 250 | 380 | .080 | 10 | 16.7 | |
| †1N2986B | 24 | 105 | 5 | 250 | 350 | .080 | 10 | 18.2 | |
| †1N2987B | 25 | 100 | 5 | 250 | 310 | .080 | 10 | 18.2 | |
| †1N2988B | 27 | 95 | 7 | 250 | 300 | .085 | 10 | 20.8 | STD. POLARITY CATHODE TO STUD |
| †1N2989B | 30 | 85 | 8 | 300 | 280 | .085 | 10 | 22.8 | |
| †1N2990B | 33 | 75 | 9 | 300 | 260 | .085 | 10 | 25.1 | |
| †1N2991B | 36 | 70 | 10 | 300 | 230 | .085 | 10 | 27.4 | |
| †1N2992B | 39 | 65 | 11 | 300 | 210 | .090 | 10 | 29.7 | |
| †1N2993B | 43 | 60 | 12 | 400 | 195 | .090 | 10 | 32.7 | |
| †1N2994B | 45 | 55 | 13 | 400 | 185 | .090 | 10 | 33.0 | STD. POLARITY ANODE TO STUD |
| †1N2995B | 47 | 55 | 14 | 400 | 175 | .090 | 10 | 35.8 | |
| †1N2996B | 50 | 50 | 15 | 500 | 165 | .090 | 10 | 36.0 | |
| †1N2997B | 51 | 50 | 15 | 500 | 160 | .090 | 10 | 38.8 | |
| †1N2998B | 52 | 50 | 15 | 500 | 160 | .090 | 10 | 39.0 | |
| †1N2999B | 56 | 45 | 16 | 500 | 150 | .090 | 10 | 42.8 | |
| †1N3000B | 62 | 40 | 17 | 600 | 130 | .090 | 10 | 47.1 | STD. POLARITY CATHODE TO STUD |
| †1N3001B | 68 | 37 | 18 | 600 | 120 | .090 | 10 | 51.7 | |
| †1N3002B | 75 | 33 | 22 | 600 | 110 | .090 | 10 | 56.0 | |
| †1N3003B | 82 | 30 | 25 | 700 | 100 | .090 | 10 | 62.2 | |
| †1N3004B | 91 | 28 | 35 | 800 | 85 | .090 | 10 | 69.2 | |
| †1N3005B | 100 | 25 | 40 | 900 | 80 | .090 | 10 | 76.0 | |
| †1N3006B | 106 | 25 | 45 | 1000 | 75 | .095 | 10 | 76.0 | STD. POLARITY ANODE TO STUD |
| †1N3007B | 110 | 23 | 55 | 1100 | 72 | .095 | 10 | 83.6 | |
| †1N3008B | 120 | 20 | 75 | 1200 | 67 | .095 | 10 | 91.2 | |
| †1N3009B | 130 | 19 | 100 | 1300 | 62 | .095 | 10 | 98.8 | |
| †1N3010B | 140 | 18 | 125 | 1400 | 58 | .095 | 10 | 100.0 | |
| †1N3011B | 150 | 17 | 175 | 1500 | 54 | .095 | 10 | 114.0 | |
| †1N3012B | 160 | 16 | 200 | 1600 | 50 | .095 | 10 | 121.6 | STD. POLARITY CATHODE TO STUD |
| †1N3013B | 175 | 14 | 250 | 1750 | 46 | .095 | 10 | 135.0 | |
| †1N3014B | 180 | 14 | 250 | 1850 | 45 | .095 | 10 | 136.8 | |
| †1N3015B | 200 | 12 | 300 | 2000 | 40 | .100 | 10 | 152.0 | |

*JEDEC Registered Data. **Not JEDEC Data.

†Have JAN and JANTX Qualifications to MIL-S-19500/272.

††Have JAN, JANTX and JANTXV Qualifications to MIL-S-19500/124.

SILICON 10 WATT ZENER DIODES

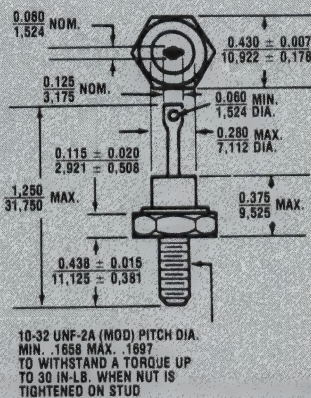


FIGURE 1

All dimensions in INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Industry Standard DO-4, 7/16" Hex. stud with 10-32 threads, welded, hermetically sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and terminal solderable.

WEIGHT: 7.5 grams.

MOUNTING POSITION: Any

THERMAL RESISTANCE: $10^{\circ}\text{C}/\text{W}$ (Typical) junction to stud.

POLARITY

1N3993 - 1N4000: Std. Polarity is cathode to stud. Reverse polarity (anode to stud) indicated by suffix "R."

1N2970 - 1N3015: Std. Polarity is anode to stud. Reverse polarity indicated by suffix "R."

MOUNTING HARDWARE: See page 41.

1N2970 thru 1N3015B, 1N3993 thru 1N4000A

NOTE 1 1N3993-1N4000 series: suffix A indicates $\pm 5\%$ tolerance, no suffix indicates $\pm 10\%$ tolerance. 1N2970-1N3015 series: suffix B indicates $\pm 5\%$ tolerance, suffix A indicates $\pm 10\%$, no suffix indicates $\pm 20\%$ tolerance. If tighter tolerance is required, consult factory.

NOTE 2 The electrical characteristics are measured after allowing the device to stabilize for 90 seconds with 30°C Base temperature.

NOTE 3 The zener impedance (Z_{ZT}) is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is

superimposed on I_{ZT} or I_{ZK} . When making zener impedance measurements at the I_{ZK} test point, it may be necessary to insert a 60 Hz band pass filter between the diode and voltmeter to avoid errors resulting from low level noise signals. A curve showing the variation of zener impedance vs. zener current for three representative types is shown in Figures 3 and 4.

NOTE 4 These values of I_{ZM} may be exceeded in the case of individual diodes. The values shown are calculated for the worst case which is a unit of $\pm 5\%$ tolerance at the high voltage end of its tolerance range. Allowance has also been made for the rise in zener voltage above V_{ZT} , which results from zener impedance and the increase in junction temperature as power dissipation approaches 10 watts.

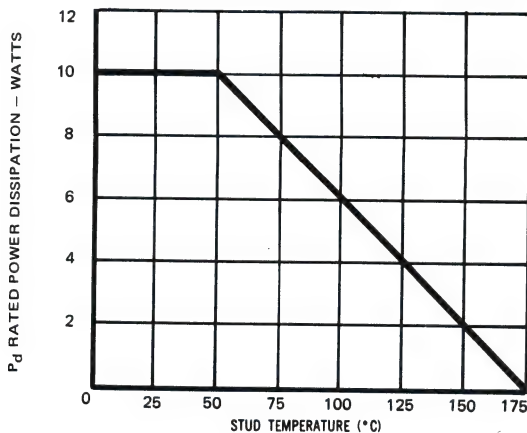


FIGURE 2
POWER DERATING CURVE

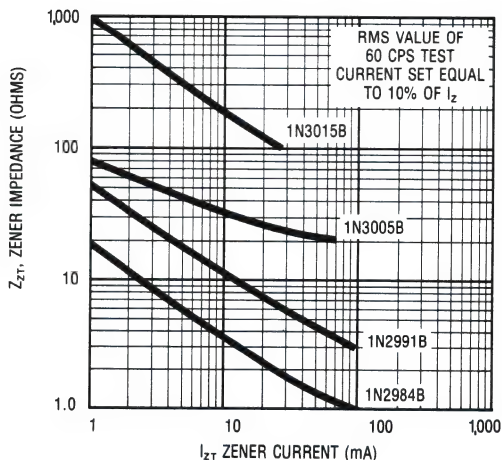


FIGURE 3

TYPICAL ZENER IMPEDANCE vs. ZENER CURRENT
FOR TYPES SHOWN

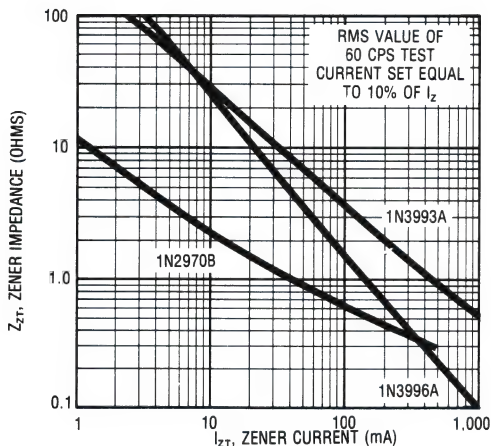


FIGURE 4

TYPICAL ZENER IMPEDANCE vs. ZENER CURRENT
FOR TYPES SHOWN

1N3016B thru 1N3051B

FEATURES

- ZENER VOLTAGE RANGE: 6.8V TO 200V
- 1N3016B THROUGH 1N3051B HAVE JAN, JANTX, and JANTXV QUALIFICATIONS TO MIL-S-19500/115
- S1N3016B THROUGH S1N3051B ALSO AVAILABLE

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to $+175^{\circ}\text{C}$

DC Power Dissipation: 1 Watt

Derating: 6.67 mW/ $^{\circ}\text{C}$ above 25°C

Forward Voltage @ 200 mA: 1.5 Volts

*ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NUMBER (Note 1) | NOMINAL ZENER VOLTAGE V_z @ I_z (Note 2) | ZENER TEST CURRENT I_z | MAXIMUM ZENER IMPEDANCE (Note 3) | | | MAXIMUM ZENER CURRENT I_{zW} (Note 4) | MAXIMUM REVERSE LEAKAGE CURRENT† I_R @ V_R | | TYPICAL TEMP. COEFF. OF ZENER VOLTAGE α_{Vz} |
|-------------------------------------|--|-----------------------------------|-------------------------------------|---------------------|-----|---|--|-------|---|
| | | | Z_{ZT} @ I_z | Z_{ZK} @ I_{ZK} | | | μA | Volts | |
| 1N3016B | 6.8 | 37 | 3.5 | 700 | 1.0 | 140 | 150 | 5.2 | .040 |
| 1N3017B | 7.5 | 34 | 4.0 | 700 | .5 | 125 | 100 | 5.7 | .045 |
| 1N3018B | 8.2 | 31 | 4.5 | 700 | .5 | 115 | 50 | 6.2 | .048 |
| 1N3019B | 9.1 | 28 | 5 | 700 | .5 | 105 | 25 | 6.9 | .050 |
| 1N3020B | 10 | 25 | 7 | 700 | .25 | 95 | 25 | 7.6 | .055 |
| 1N3021B | 11 | 23 | 8 | 700 | .25 | 85 | 10 | 8.4 | .060 |
| 1N3022B | 12 | 21 | 9 | 700 | .25 | 80 | 10 | 9.1 | .065 |
| 1N3023B | 13 | 19 | 10 | 700 | .25 | 74 | 10 | 9.9 | .065 |
| 1N3024B | 15 | 17 | 14 | 700 | .25 | 63 | 10 | 11.4 | .070 |
| 1N3025B | 16 | 15.5 | 16 | 700 | .25 | 60 | 10 | 12.2 | .070 |
| 1N3026B | 18 | 14 | 20 | 750 | .25 | 52 | 10 | 13.7 | .075 |
| 1N3027B | 20 | 12.5 | 22 | 750 | .25 | 47 | 10 | 15.2 | .075 |
| 1N3028B | 22 | 11.5 | 23 | 750 | .25 | 43 | 10 | 16.7 | .080 |
| 1N3029B | 24 | 10.5 | 25 | 750 | .25 | 40 | 10 | 18.2 | .080 |
| 1N3030B | 27 | 9.5 | 35 | 750 | .25 | 34 | 10 | 20.6 | .085 |
| 1N3031B | 30 | 8.5 | 40 | 1000 | .25 | 31 | 10 | 22.8 | .085 |
| 1N3032B | 33 | 7.5 | 45 | 1000 | .25 | 28 | 10 | 25.1 | .085 |
| 1N3033B | 36 | 7.0 | 50 | 1000 | .25 | 26 | 10 | 27.4 | .085 |
| 1N3034B | 39 | 6.5 | 60 | 1000 | .25 | 23 | 10 | 29.7 | .090 |
| 1N3035B | 43 | 6.0 | 70 | 1500 | .25 | 21 | 10 | 32.7 | .090 |
| 1N3036B | 47 | 5.5 | 80 | 1500 | .25 | 19 | 10 | 35.8 | .090 |
| 1N3037B | 51 | 5.0 | 95 | 1500 | .25 | 18 | 10 | 38.8 | .090 |
| 1N3038B | 56 | 4.5 | 110 | 2000 | .25 | 17 | 10 | 42.6 | .090 |
| 1N3039B | 62 | 4.0 | 125 | 2000 | .25 | 15 | 10 | 47.1 | .090 |
| 1N3040B | 68 | 3.7 | 150 | 2000 | .25 | 14 | 10 | 51.7 | .090 |
| 1N3041B | 75 | 3.3 | 175 | 2000 | .25 | 12 | 10 | 56.0 | .090 |
| 1N3042B | 82 | 3.0 | 200 | 3000 | .25 | 11 | 10 | 62.2 | .090 |
| 1N3043B | 91 | 2.8 | 250 | 3000 | .25 | 10 | 10 | 69.2 | .090 |
| 1N3044B | 100 | 2.5 | 350 | 3000 | .25 | 9.0 | 10 | 76.0 | .090 |
| 1N3045B | 110 | 2.3 | 450 | 4000 | .25 | 8.3 | 10 | 83.6 | .095 |
| 1N3046B | 120 | 2.0 | 550 | 4500 | .25 | 8.0 | 10 | 91.2 | .095 |
| 1N3047B | 130 | 1.9 | 700 | 5000 | .25 | 6.9 | 10 | 98.8 | .095 |
| 1N3048B | 150 | 1.7 | 1000 | 6000 | .25 | 5.7 | 10 | 114.0 | .095 |
| 1N3049B | 160 | 1.6 | 1100 | 6500 | .25 | 5.4 | 10 | 121.6 | .095 |
| 1N3050B | 180 | 1.4 | 1200 | 7000 | .25 | 4.9 | 10 | 136.8 | .095 |
| 1N3051B | 200 | 1.2 | 1500 | 8000 | .25 | 4.6 | 10 | 152.0 | .100 |

*JEDEC Registered Data. †Not JEDEC Data.

SILICON 1 WATT ZENER DIODES

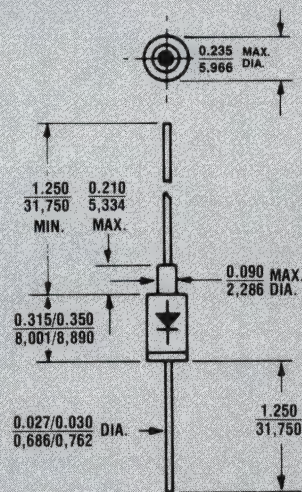


FIGURE 1

All dimensions in
INCH
m.m

MECHANICAL CHARACTERISTICS

CASE: DO-13, welded, hermetical-ly sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $100^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at at 0.375-inches from body.

POLARITY: Cathode connected case.

WEIGHT: 1.4 grams.

MOUNTING POSITION: Any.

1N3016B thru 1N3051B

NOTE 1 When using JEDEC Numbers B suffix signifies a $\pm 5\%$ tolerance on nominal zener voltage. The suffix A is used to identify $\pm 10\%$ tolerance; no suffix indicates $\pm 20\%$ tolerance. If tighter tolerance is required, consult factory.

NOTE 2 Zener Voltage (V_Z) is measured with junction in thermal equilibrium with still air at a temperature of 25°C . The test currents (I_{ZT}) have been selected so that at nominal voltages the dissipation is a constant 0.25 watts. This results in a nominal junction temperature rise of 25°C .

NOTE 3 The zener impedance is derived from the 60 cycle ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at 2 points to insure a sharp knee on the breakdown curve

and to eliminate unstable units. A curve showing the variation of zener impedance vs. zener current for four representative types is shown in Figure 2.

NOTE 4 These values of I_{ZM} may often be exceeded in the case of individual diodes. The values shown are calculated for a unit at the high voltage end of its tolerance range. Allowance has also been made for the rise in zener voltage above V_{ZT} which results from zener impedance and the increase in junction temperature as a unit approaches thermal equilibrium at a dissipation of 1 watt. The I_{ZM} values shown for $\pm 5\%$ tolerance units may be used with little error for $\pm 10\%$ tolerance units, but should be reduced by 7% to include a $\pm 20\%$ tolerance unit near the high voltage end of its tolerance range.

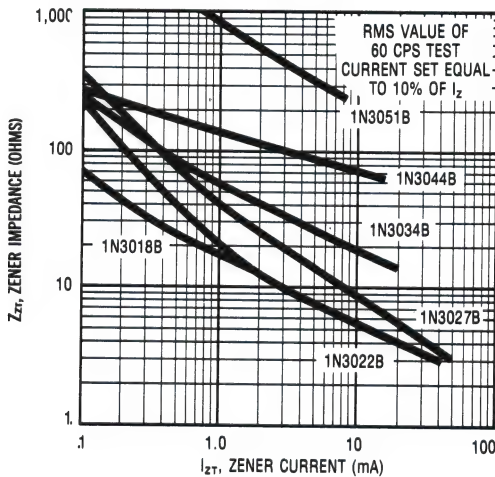


FIGURE 2

TYPICAL ZENER IMPEDANCE vs. ZENER CURRENT FOR TYPES SHOWN

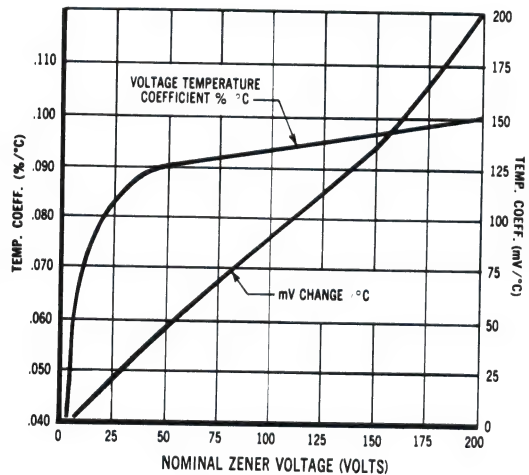


FIGURE 3

TYPICAL ZENER VOLTAGE TEMPERATURE COEFF. vs. ZENER VOLTAGE

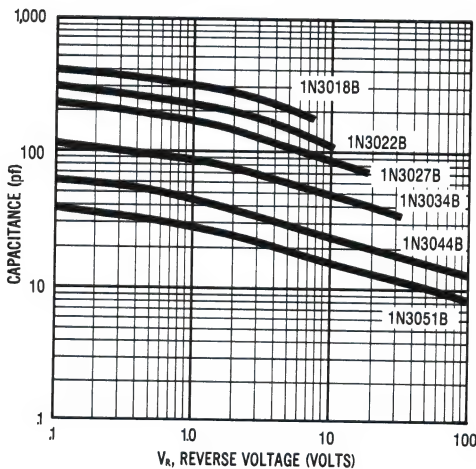


FIGURE 4

TYPICAL CAPACITANCE vs. REVERSE VOLTAGE FOR 1-WATT ZENERS

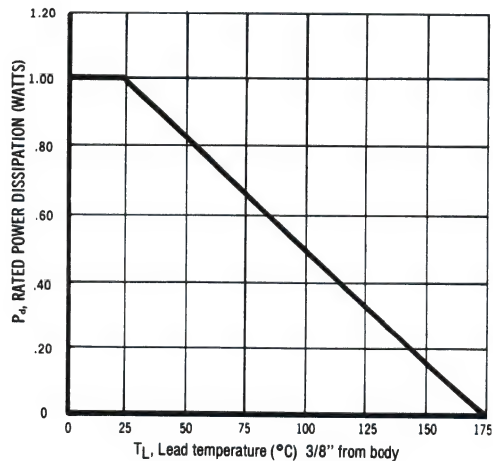


FIGURE 5

POWER DERATING CURVE

1N3305 thru 1N3350B and 1N4549B thru 1N4556B

FEATURES

- ZENER VOLTAGE 3.9 TO 200V
- LOW ZENER IMPEDANCE
- HIGHLY RELIABLE AND RUGGED
- FOR MILITARY AND OTHER DEMANDING APPLICATIONS (See Below)

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to $+175^{\circ}\text{C}$

DC Power Dissipation: 50 Watts

Power Derating: 0.5 W/ $^{\circ}$ above 75°C

Forward Voltage @ 10 A: 1.5 Volts

*ELECTRICAL CHARACTERISTICS @ 30°C Case Temperature

| JEDEC TYPE NO. (Note 1) | NOMINAL ZENER VOLTAGE V _Z @ I _Z (Note 2) | ZENER TEST CURRENT I _{ZT} mA (Note 3) | MAX. DYNAMIC IMPEDANCE (Note 3) Z ₀₁ @ I _{ZT} OHMS | | MAX. DC ZENER CURRENT I _{ZM} mA | MAX. REVERSE LEAKAGE** CURRENT I _R (max) @ V _R μA VOLTS | | TYPICAL TEMP. COEFF. α _{VZ} %/°C |
|-------------------------------|--|--|---|-----------------------------------|---|---|---------------------------------|---|
| | | | Z ₀₁ @ I _{ZT} | Z ₀₁ @ I _{ZT} | | I _R @ V _R | I _R @ V _R | |
| †1N4549B | 3.9 | 3,200 | 0.16 | 400 | 11,900 | 150 | 0.5 | -0.046 |
| †1N4550B | 4.3 | 2,900 | 0.16 | 500 | 10,650 | 150 | 0.5 | -0.033 |
| †1N4551B | 4.7 | 2,650 | 0.12 | 600 | 9,700 | 100 | 1.0 | -0.015 |
| †1N4552B | 5.1 | 2,450 | 0.12 | 650 | 8,900 | 20 | 1.0 | +0.010 |
| †1N4553B | 5.6 | 2,250 | 0.12 | 900 | 8,100 | 20 | 1.0 | +0.030 |
| †1N4554B | 6.2 | 2,000 | 0.14 | 1,000 | 7,300 | 20 | 2.0 | +0.049 |
| 1N4555B | 6.8 | 1,850 | 0.16 | 200 | 6,650 | 10 | 2.0 | +0.053 |
| 1N4556B | 7.5 | 1,650 | 0.24 | 100 | 6,060 | 10 | 3.0 | +0.057 |
| †1N3305B | 6.8 | 1,850 | 0.20 | 70 | 6,600 | 300 | 4.5 | 0.040 |
| †1N3306B | 7.5 | 1,700 | 0.30 | 70 | 5,900 | 125 | 5.0 | 0.045 |
| †1N3307B | 8.2 | 1,500 | 0.40 | 70 | 5,200 | 50 | 5.4 | 0.048 |
| †1N3308B | 9.1 | 1,370 | 0.50 | 70 | 4,800 | 25 | 6.1 | 0.050 |
| †1N3309B | 10.0 | 1,200 | 0.60 | 80 | 4,300 | 25 | 6.7 | 0.055 |
| †1N3310B | 11.0 | 1,100 | 0.80 | 80 | 3,900 | 10 | 8.4 | 0.060 |
| †1N3311B | 12.0 | 1,000 | 1.00 | 80 | 3,800 | 10 | 9.1 | 0.065 |
| †1N3312B | 13.0 | 960 | 1.10 | 80 | 3,300 | 10 | 9.9 | 0.065 |
| †1N3313B | 14.0 | 890 | 1.20 | 80 | 3,000 | 10 | 11.4 | 0.070 |
| †1N3314B | 15.0 | 830 | 1.40 | 80 | 2,800 | 10 | 11.4 | 0.070 |
| †1N3315B | 16.0 | 780 | 1.60 | 80 | 2,650 | 10 | 12.2 | 0.070 |
| 1N3316B | 17.0 | 740 | 1.80 | 80 | 2,500 | 10 | 13.0 | 0.075 |
| †1N3317B | 18.0 | 700 | 2.00 | 80 | 2,300 | 10 | 13.7 | 0.075 |
| 1N3318B | 19.0 | 660 | 2.20 | 80 | 2,200 | 10 | 13.7 | 0.075 |
| †1N3319B | 20.0 | 630 | 2.40 | 80 | 2,100 | 10 | 15.2 | 0.075 |
| †1N3320B | 22.0 | 570 | 2.50 | 80 | 1,900 | 10 | 16.7 | 0.080 |
| †1N3321B | 24.0 | 520 | 2.60 | 80 | 1,750 | 10 | 18.2 | 0.080 |
| 1N3322B | 25.0 | 500 | 2.70 | 90 | 1,650 | 10 | 18.2 | 0.080 |
| †1N3323B | 27.0 | 460 | 2.80 | 90 | 1,500 | 10 | 20.6 | 0.085 |
| †1N3324B | 30.0 | 420 | 3.00 | 90 | 1,400 | 10 | 22.8 | 0.085 |
| †1N3325B | 33.0 | 380 | 3.20 | 90 | 1,300 | 10 | 25.1 | 0.085 |
| †1N3326B | 36.0 | 350 | 3.50 | 90 | 1,150 | 10 | 27.4 | 0.085 |
| †1N3327B | 38.0 | 320 | 4.00 | 90 | 1,050 | 10 | 29.7 | 0.090 |
| †1N3328B | 43.0 | 290 | 4.50 | 90 | 975 | 10 | 32.7 | 0.090 |
| †1N3329B | 45.0 | 280 | 4.50 | 100 | 930 | 10 | 32.7 | 0.090 |
| †1N3330B | 47.0 | 270 | 5.00 | 100 | 880 | 10 | 36.8 | 0.090 |
| †1N3331B | 50.0 | 250 | 5.00 | 100 | 830 | 10 | 36.8 | 0.090 |
| †1N3332B | 51.0 | 245 | 5.20 | 100 | 810 | 10 | 36.8 | 0.090 |
| 1N3333B | 52.0 | 240 | 5.50 | 100 | 790 | 10 | 42.6 | 0.090 |
| †1N3334B | 56.0 | 220 | 6.00 | 110 | 740 | 10 | 42.6 | 0.090 |
| †1N3335B | 62.0 | 200 | 7.00 | 120 | 660 | 10 | 47.1 | 0.090 |
| †1N3336B | 68.0 | 180 | 8.00 | 140 | 600 | 10 | 51.7 | 0.090 |
| †1N3337B | 75.0 | 170 | 9.00 | 150 | 540 | 10 | 56.0 | 0.090 |
| †1N3338B | 82.0 | 150 | 11.00 | 160 | 490 | 10 | 62.2 | 0.090 |
| †1N3339B | 91.0 | 140 | 15.00 | 180 | 420 | 10 | 69.2 | 0.090 |
| †1N3340B | 100.0 | 120 | 20.00 | 200 | 400 | 10 | 76.0 | 0.090 |
| †1N3341B | 106.0 | 120 | 25.00 | 210 | 380 | 10 | 83.0 | 0.095 |
| †1N3342B | 110.0 | 110 | 30.00 | 220 | 365 | 10 | 83.0 | 0.095 |
| †1N3343B | 120.0 | 100 | 40.00 | 240 | 336 | 10 | 91.2 | 0.095 |
| †1N3344B | 130.0 | 95 | 50.00 | 275 | 310 | 10 | 99.8 | 0.095 |
| †1N3345B | 140.0 | 90 | 60.00 | 325 | 290 | 10 | 114.0 | 0.095 |
| †1N3346B | 150.0 | 85 | 75.00 | 400 | 270 | 10 | 114.0 | 0.095 |
| †1N3347B | 160.0 | 80 | 80.00 | 450 | 250 | 10 | 121.6 | 0.095 |
| †1N3348B | 175.0 | 70 | 85.00 | 500 | 230 | 10 | 121.6 | 0.095 |
| †1N3349B | 180.0 | 68 | 90.00 | 525 | 220 | 10 | 136.8 | 0.095 |
| †1N3350B | 200.0 | 66 | 100.00 | 600 | 200 | 10 | 152.0 | 0.100 |

*JEDEC Registered Data. **Not JEDEC Data.

† Have JAN and JANTX Qualifications to MIL-S-19500/358.

SILICON 50 WATT ZENER DIODES

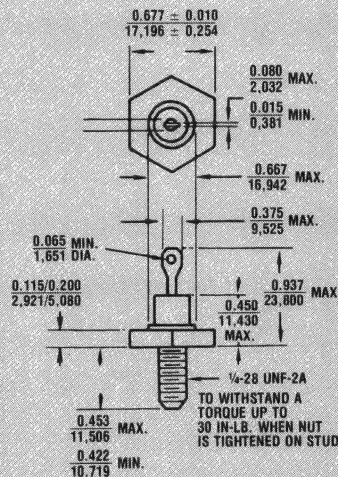


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Industry Standard DO-5, 11/16" Hex. stud with 1/4-28 threads, welded, hermetically sealed metal and glass.

DIMENSIONS: See outline drawing Fig. 1.

FINISH: All external surfaces are corrosion resistant and terminal solderable.

THERMAL RESISTANCE: $1.5^{\circ}\text{C}/\text{W}$ (Typical) junction to stud.

POLARITY: Standard polarity anode to case. Reverse polarity (cathode to case) indicated by suffix R.

MOUNTING HARDWARE: See page 41.

1N3305 thru 1N3350B, 1N4549B thru 1N4556B

NOTE 1

When using JEDEC numbers an R suffix should be used to signify reversed polarity. The suffixes A and B indicate tolerances of 10% and 5% respectively. No suffix or just R denotes $\pm 20\%$ tolerance. Example: 1N3319RB is a REVERSED polarity, 20 volt unit having a $\pm 5\%$ tolerance on Zener Voltage.

NOTE 2

Zener Voltage (V_Z) is measured with junction in thermal equilibrium with 30°C stud temperature.

NOTE 3

The zener impedance is derived from the 60 cycle A.C. voltage, which results when an A.C. current having an R.M.S. value equal to 10% of the D.C. zener current (I_{zt} or I_{zk}) is superimposed on I_{zt} or I_{zk} . Zener impedance is measured at 2 points to insure a sharp knee on the breakdown curve and to eliminate unstable units. A curve showing the variation of zener impedance vs. zener current for three representative types is shown in Figure 3.

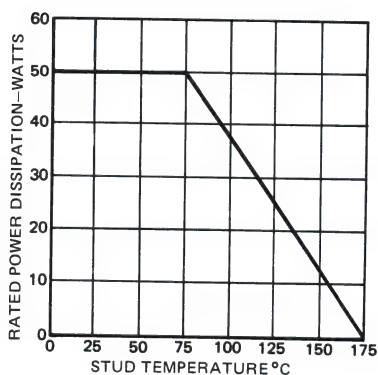


FIGURE 2
POWER DERATING CURVE

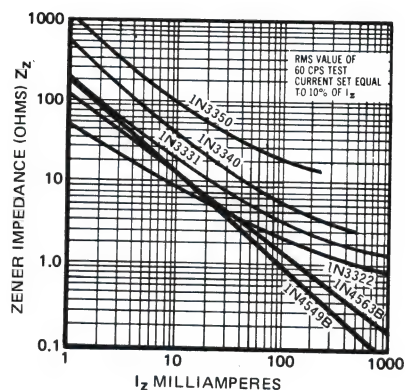


FIGURE 3
TYPICAL ZENER IMPEDANCE
vs. ZENER CURRENT

Microsemi Corp.
The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

1N3821 thru 1N3830A

FEATURES

- ZENER VOLTAGE RANGE: 3.3V to 7.5V
- 1N3821A-1N3828A HAVE JAN, JANTX and JANTXV QUALIFICATIONS TO MIL-S-19500/115

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to $+175^{\circ}\text{C}$

DC Power Dissipation: 1 Watt

Derating: 6.67 mW/ $^{\circ}\text{C}$ above 25°C

Forward Voltage @ 200 mA: 1.5 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NO. | NOMINAL ZENER VOLTAGE V _Z @ I _{ZT} (Note 1) | ZENER TEST CURRENT I _{ZT} | MAX. ZENER IMPEDANCE (Note 2) | | MAXIMUM ZENER CURRENT I _{ZM} (Note 3) | MAXIMUM REVERSE CURRENT I _R @ V _R | | TYPICAL TEMP. COEFF. of ZENER VOLTAGE α _{VZ} |
|-------------------|---|---|-----------------------------------|--|--|--|-------|---|
| | | | Z _{ZT} @ I _{ZT} | Z _{ZK} @ I _{ZK} = 1mA | | μA | VOLTS | |
| | | | | | | | | |
| | VOLTS | mA | OHMS | OHMS | mA | | | %/°C |
| 1N3821 | 3.3 | 76 | 10 | 400 | 276 | 100 | 1 | — .066 |
| 1N3821A | 3.3 | 76 | 10 | 400 | 276 | 100 | 1 | — .066 |
| 1N3822 | 3.6 | 69 | 10 | 400 | 252 | 100 | 1 | — .058 |
| 1N3822A | 3.6 | 69 | 10 | 400 | 252 | 100 | 1 | — .058 |
| 1N3823 | 3.9 | 64 | 9 | 400 | 238 | 50 | 1 | — .046 |
| 1N3823A | 3.9 | 64 | 9 | 400 | 238 | 50 | 1 | — .046 |
| 1N3824 | 4.3 | 58 | 9 | 400 | 213 | 10 | 1 | — .033 |
| 1N3824A | 4.3 | 58 | 9 | 400 | 213 | 10 | 1 | — .033 |
| 1N3825 | 4.7 | 53 | 8 | 500 | 194 | 10 | 1 | — .015 |
| 1N3825A | 4.7 | 53 | 8 | 500 | 194 | 10 | 1 | — .015 |
| 1N3826 | 5.1 | 49 | 7 | 550 | 178 | 10 | 1 | ± .010 |
| 1N3826A | 5.1 | 49 | 7 | 550 | 178 | 10 | 1 | ± .010 |
| 1N3827 | 5.6 | 45 | 5 | 600 | 162 | 10 | 2 | + .030 |
| 1N3827A | 5.6 | 45 | 5 | 600 | 162 | 10 | 2 | + .030 |
| 1N3828 | 6.2 | 41 | 2 | 700 | 146 | 10 | 3 | + .049 |
| 1N3828A | 6.2 | 41 | 2 | 700 | 146 | 10 | 3 | + .049 |
| 1N3829 | 6.8 | 37 | 1.5 | 500 | 133 | 10 | 3 | + .053 |
| 1N3829A | 6.8 | 37 | 1.5 | 500 | 133 | 10 | 3 | + .053 |
| 1N3830 | 7.5 | 34 | 1.5 | 250 | 121 | 10 | 3 | + .057 |
| 1N3830A | 7.5 | 34 | 1.5 | 250 | 121 | 10 | 3 | + .057 |

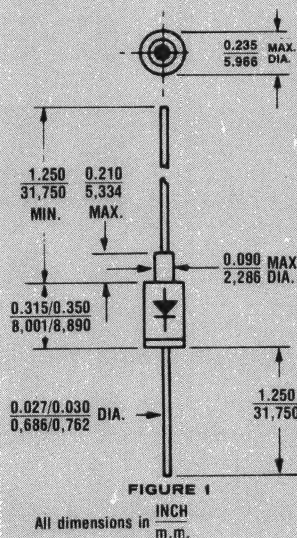
* JEDEC Registered Data

NOTE 1 The JEDEC type numbers shown with suffix A have a standard tolerance of $\pm 5\%$ on the nominal zener voltage. V_Z measured with device in thermal equilibrium in 25°C still air and mounted in test clips, $3/4"$ from unit body. If tighter tolerance on V_Z is required, consult factory.

NOTE 2 ZENER Impedance derived by superimposing on I_{ZT} - I_{ZK} a 60 cps, rms. a.c. current equal to $10\% I_{ZT}$ or I_{ZK} .

NOTE 3 Allowance has been made for the increase in V_Z due to Z_Z and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 1 watt.

SILICON 1 WATT ZENER DIODES



MECHANICAL CHARACTERISTICS

CASE: DO-13, welded, hermetically sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $100^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375 -inches from body.

POLARITY: Cathode connected case.

WEIGHT: 1.4 grams.

MOUNTING POSITION: Any.

1N3821 thru 1N3830A

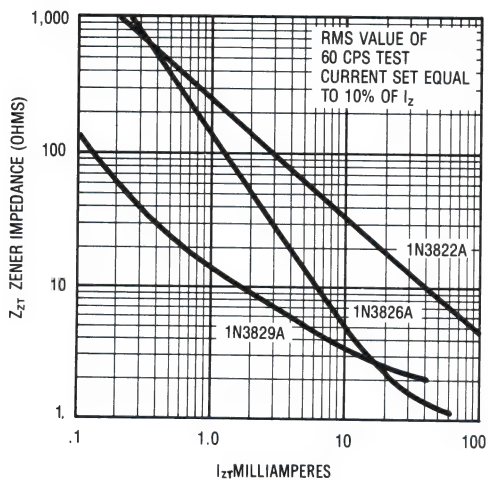


FIGURE 2
TYPICAL ZENER IMPEDANCE vs.
ZENER CURRENT FOR TYPES SHOWN

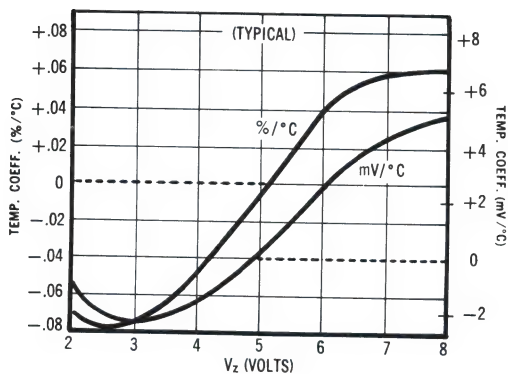


FIGURE 3
TEMP. COEFF. vs. ZENER VOLTAGE

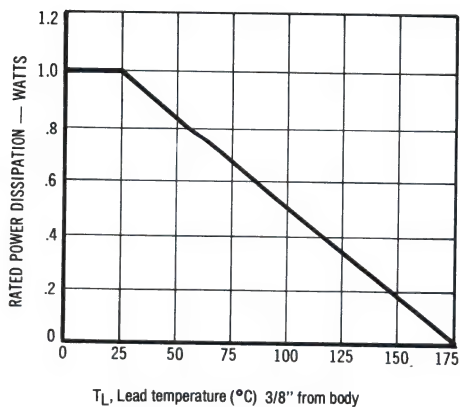


FIGURE 4
POWER DERATING CURVE

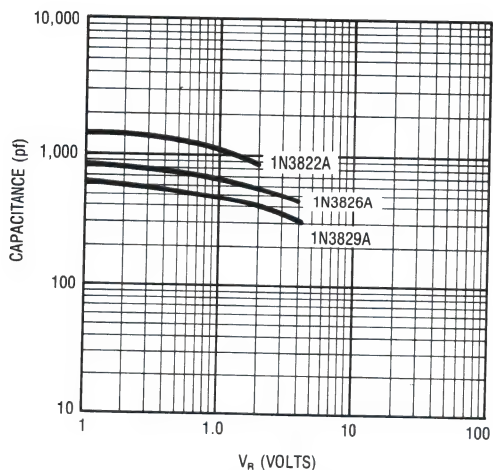
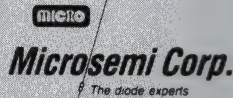


FIGURE 5
TYPICAL CAPACITANCE vs. REVERSE
VOLTAGE FOR 1-WATT ZENERS



SANTA ANA, CA

SCOTTSDALE, AZ
For more information call:
(602) 941-6300

1N4099 thru 1N4135 and 1N4614 thru 1N4627 DO-7

FEATURES

- ZENER VOLTAGE 1.8V to 100V
- ALL HAVE JAN, JANTX and JANTXV QUALIFICATIONS TO MIL-S-19500/435
- LOW NOISE
- LOW REVERSE LEAKAGE

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +200°C

DC Power Dissipation: 400 mW

Power Derating: 2.66 mW/°C above 50°C in DO-7

Forward Voltage @ 200 mA: 1.0 Volts 1N4099-1N4135
@ 100 mA: 1.0 Volts 1N4614-1N4627

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NO. | NOMINAL ZENER VOLTAGE V _Z @ I _{ZT} (Note 1) | ZENER TEST CURRENT I _{ZT} | MAXIMUM ZENER IMPEDANCE Z _{VT} (Note 2) | MAXIMUM REVERSE CURRENT I _Z @ V _R | | MAXIMUM NOISE DENSITY N _p @ I _{ZT} (Figure 2) | MAXIMUM ZENER CURRENT I _{ZM} (Note 3) | TYPICAL TEMP. COEFF. OF ZENER VOLTAGE α _{VZ} |
|----------------------|---|---|--|--|-------|---|--|--|
| | VOLTS | μA | OHMS | μA | VOLTS | μV/√Hz | mA | %/°C |
| 1N4614 | 1.8 | 250 | 1200 | 7.5 | 1 | 1 | 120 | -0.075 |
| 1N4615 | 2.0 | 250 | 1250 | 5.0 | 1 | 1 | 110 | -0.075 |
| 1N4616 | 2.2 | 250 | 1300 | 4.0 | 1 | 1 | 100 | -0.075 |
| 1N4617 | 2.4 | 250 | 1400 | 2.0 | 1 | 1 | 95 | -0.075 |
| 1N4618 | 2.7 | 250 | 1500 | 1.0 | 1 | 1 | 90 | -0.075 |
| 1N4619 | 3.0 | 250 | 1600 | 0.8 | 1 | 1 | 87 | -0.075 |
| 1N4620 | 3.3 | 250 | 1650 | 7.5 | 1.5 | 1 | 85 | -0.075 |
| 1N4621 | 3.6 | 250 | 1700 | 7.5 | 2 | 1 | 83 | -0.065 |
| 1N4622 | 3.9 | 250 | 1650 | 5.0 | 2 | 1 | 80 | -0.060 |
| 1N4623 | 4.3 | 250 | 1600 | 4.0 | 2 | 1 | 77 | -0.050 |
| 1N4624 | 4.7 | 250 | 1550 | 10.0 | 3 | 1 | 75 | -0.040, +0.020 |
| 1N4625 | 5.1 | 250 | 1500 | 10.0 | 3 | 2 | 70 | -0.045, +0.030 |
| 1N4626 | 5.6 | 250 | 1400 | 10.0 | 4 | 4 | 65 | -0.020, +0.040 |
| 1N4627 | 6.2 | 250 | 1200 | 10.0 | 5 | 5 | 61 | -0.010, +0.050 |
| 1N4099 | 6.8 | 250 | 200 | 10.0 | 5.17 | 40 | 56 | 0.040 |
| 1N4100 | 7.5 | 250 | 200 | 10.0 | 5.70 | 40 | 51 | 0.048 |
| 1N4101 | 8.2 | 250 | 200 | 1.0 | 6.24 | 40 | 46 | 0.048 |
| 1N4102 | 8.7 | 250 | 200 | 1.0 | 6.61 | 40 | 44 | 0.049 |
| 1N4103 | 9.1 | 250 | 200 | 1.0 | 6.92 | 40 | 42 | 0.050 |
| 1N4104 | 10 | 250 | 200 | 1.0 | 7.60 | 40 | 38 | 0.055 |
| 1N4105 | 11 | 250 | 200 | .05 | 8.44 | 40 | 35 | 0.060 |
| 1N4106 | 12 | 250 | 200 | .05 | 9.12 | 40 | 32 | 0.065 |
| 1N4107 | 13 | 250 | 200 | .05 | 9.87 | 40 | 29 | 0.065 |
| 1N4108 | 14 | 250 | 200 | .05 | 10.65 | 40 | 27 | 0.070 |
| 1N4109 | 15 | 250 | 100 | .05 | 11.40 | 40 | 25 | 0.070 |
| 1N4110 | 16 | 250 | 100 | .05 | 12.15 | 40 | 24 | 0.070 |
| 1N4111 | 17 | 250 | 100 | .05 | 12.92 | 40 | 22 | 0.075 |
| 1N4112 | 18 | 250 | 100 | .05 | 13.67 | 40 | 21 | 0.075 |
| 1N4113 | 19 | 250 | 150 | .05 | 14.44 | 40 | 20 | 0.075 |
| 1N4114 | 20 | 250 | 150 | .01 | 15.20 | 40 | 19 | 0.075 |
| 1N4115 | 22 | 250 | 150 | .01 | 16.72 | 40 | 17 | 0.080 |
| 1N4116 | 24 | 250 | 150 | .01 | 18.25 | 40 | 16 | 0.080 |
| 1N4117 | 25 | 250 | 150 | .01 | 19.00 | 40 | 15 | 0.080 |
| 1N4118 | 27 | 250 | 150 | .01 | 20.45 | 40 | 14 | 0.085 |
| 1N4119 | 28 | 250 | 200 | .01 | 21.28 | 40 | 14 | 0.085 |
| 1N4120 | 30 | 250 | 200 | .01 | 22.80 | 40 | 13 | 0.085 |
| 1N4121 | 33 | 250 | 200 | .01 | 25.08 | 40 | 12 | 0.09 |
| 1N4122 | 36 | 250 | 200 | .01 | 27.38 | 40 | 11 | 0.09 |
| 1N4123 | 39 | 250 | 200 | .01 | 29.65 | 40 | 9.8 | 0.09 |
| 1N4124 | 43 | 250 | 250 | .01 | 32.65 | 40 | 8.9 | 0.09 |
| 1N4125 | 47 | 250 | 250 | .01 | 35.75 | 40 | 8.1 | 0.09 |
| 1N4126 | 51 | 250 | 300 | .01 | 38.76 | 40 | 7.5 | 0.09 |
| 1N4127 | 56 | 250 | 300 | .01 | 42.60 | 40 | 6.7 | 0.09 |
| 1N4128 | 60 | 250 | 400 | .01 | 45.60 | 40 | 6.4 | 0.09 |
| 1N4129 | 62 | 250 | 500 | .01 | 47.10 | 40 | 6.1 | 0.09 |
| 1N4130 | 68 | 250 | 700 | .01 | 51.68 | 40 | 5.6 | 0.095 |
| 1N4131 | 75 | 250 | 700 | .01 | 57.00 | 40 | 5.1 | 0.095 |
| 1N4132 | 82 | 250 | 800 | .01 | 62.32 | 40 | 4.6 | 0.095 |
| 1N4133 | 87 | 250 | 1000 | .01 | 66.12 | 40 | 4.4 | 0.095 |
| 1N4134 | 91 | 250 | 1200 | .01 | 69.16 | 40 | 4.2 | 0.095 |
| 1N4135 | 100 | 250 | 1500 | .01 | 76.00 | 40 | 3.8 | 0.095 |

*JEDEC Registered Data.

SILICON
400 mW
LOW NOISE
ZENER DIODES

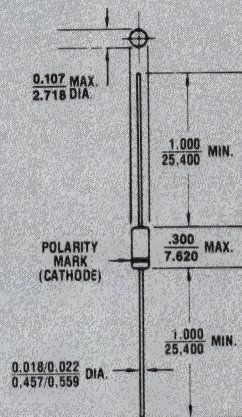


FIGURE 1

All dimensions in
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass
case. DO-7.

FINISH: All external surfaces are
corrosion resistant and leads sol-
derable.

THERMAL RESISTANCE: 300°C/
W (Typical) junction to lead a
0.375-inches from body on DO-7

POLARITY: Diode to be operated
with the banded end positiv
with respect to the opposite end

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N4099 thru 1N4135, 1N4614 thru 1N4627 DO-7

Noise density, (N_D) is specified in microvolts-rms per square-root-hertz. Actual measurement is performed using a 1 KHz to 3 KHz frequency bandpass filter at a constant Zener test current (I_{ZT}) at 25°C ambient temperature. N_D is calculated from the formula.

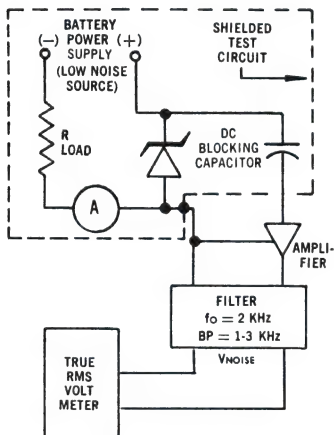


FIGURE 2 NOISE DENSITY MEASUREMENT CIRCUIT

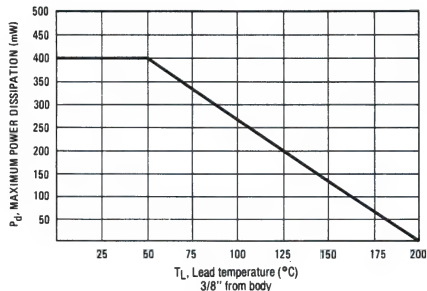


FIGURE 3 POWER DERATING CURVE

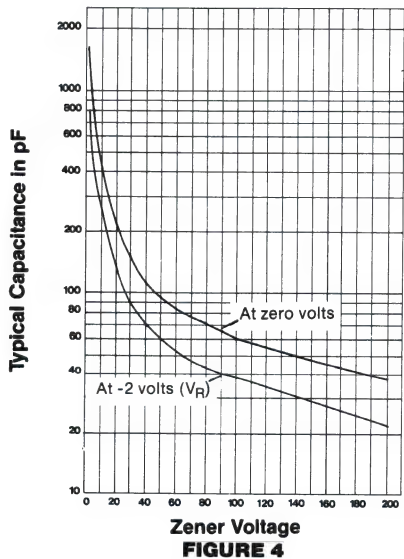


FIGURE 4
CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)

NOTE 1 The JEDEC type numbers shown with no suffix have a standard tolerance of $\pm 5\%$ on the nominal Zener voltage: suffix C is used to identify $\pm 2\%$; and suffix D is used to identify $\pm 1\%$ tolerance. V_Z is measured with the diode in thermal equilibrium in 25°C still air.

NOTE 2 Zener impedance is derived by superimposing on I_{ZT} , a 60 Hz rms a.c. current equal to 10% of I_{ZT} (25 μ A a.c.).

NOTE 3 Based upon 400 mW maximum power dissipation at 25°C ambient temperature, allowance has been made for the higher voltage associated with operation at higher currents.

1N4099 thru 1N4135 and 1N4614 thru 1N4627 DO-35

FEATURES

- ZENER VOLTAGE 1.8 TO 100 V
- ALL HAVE JAN, JANTX AND JANTXV-1 QUALIFICATIONS TO MIL-S-19500/435
- LOW NOISE
- LOW REVERSE LEAKAGE

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +200°C

DC Power Dissipation: 400 mW

Power Derating: 3.2 mW/°C above 75°C in DO-35

Forward Voltage @ 200 mA: 1.1 Volts 1N4099 - 1N4135

@ 100 mA: 1.0 Volts 1N4614 - 1N4627

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NO. | NOMINAL ZENER VOLTAGE V _Z @ I _{ZT} (Note 1) | ZENER TEST CURRENT I _{ZT} | MAXIMUM ZENER IMPEDANCE Z _{VT} (Note 2) | MAXIMUM REVERSE CURRENT I _Z @ V _R | MAXIMUM NOISE DENSITY N _D @ I _{ZT} (Note 4) | MAXIMUM ZENER CURRENT I _{ZM} (Note 3) | TYPICAL TEMP. COEFF. OF ZENER VOLTAGE α _{VZ} |
|----------------------|---|---|--|--|---|--|--|
| | VOLTS | μA | OHMS | μA | VOLTS | μV/√R _Z | %/°C |
| 1N4614 | 1.8 | 250 | 1200 | 7.5 | 1 | 1 | -0.075 |
| 1N4615 | 2.0 | 250 | 1250 | 5.0 | 1 | 1 | -0.075 |
| 1N4616 | 2.2 | 250 | 1300 | 4.0 | 1 | 1 | -0.075 |
| 1N4617 | 2.4 | 250 | 1400 | 2.0 | 1 | 1 | -0.075 |
| 1N4618 | 2.7 | 250 | 1500 | 1.0 | 1 | 1 | -0.075 |
| 1N4619 | 3.0 | 250 | 1600 | 0.8 | 1 | 1 | -0.075 |
| 1N4620 | 3.3 | 250 | 1650 | 7.5 | 1.5 | 1 | -0.075 |
| 1N4621 | 3.6 | 250 | 1700 | 7.5 | 2 | 1 | -0.065 |
| 1N4622 | 3.9 | 250 | 1650 | 5.0 | 2 | 1 | -0.060 |
| 1N4623 | 4.3 | 250 | 1600 | 4.0 | 2 | 1 | -0.050 |
| 1N4624 | 4.7 | 250 | 1550 | 10.0 | 3 | 1 | -0.040, +0.020 |
| 1N4625 | 5.1 | 250 | 1500 | 10.0 | 3 | 2 | -0.045, +0.030 |
| 1N4626 | 5.6 | 250 | 1400 | 10.0 | 4 | 4 | -0.020, +0.040 |
| 1N4627 | 6.2 | 250 | 1200 | 10.0 | 5 | 5 | -0.010, +0.050 |
| 1N4099 | 6.8 | 250 | 200 | 10.0 | 5.17 | 40 | 0.040 |
| 1N4100 | 7.5 | 250 | 200 | 10.0 | 5.70 | 40 | 0.045 |
| 1N4101 | 8.2 | 250 | 200 | 1.0 | 6.24 | 40 | 0.048 |
| 1N4102 | 8.7 | 250 | 200 | 1.0 | 6.61 | 40 | 0.049 |
| 1N4103 | 9.1 | 250 | 200 | 1.0 | 6.92 | 40 | 0.050 |
| 1N4104 | 10 | 250 | 200 | 1.0 | 7.60 | 40 | 0.055 |
| 1N4105 | 11 | 250 | 200 | .05 | 8.44 | 40 | 0.060 |
| 1N4106 | 12 | 250 | 200 | .05 | 9.12 | 40 | 0.065 |
| 1N4107 | 13 | 250 | 200 | .05 | 9.87 | 40 | 0.065 |
| 1N4108 | 14 | 250 | 200 | .05 | 10.65 | 40 | 0.070 |
| 1N4109 | 15 | 250 | 100 | .05 | 11.40 | 40 | 0.070 |
| 1N4110 | 16 | 250 | 100 | .05 | 12.15 | 40 | 0.070 |
| 1N4111 | 17 | 250 | 100 | .05 | 12.92 | 40 | 0.075 |
| 1N4112 | 18 | 250 | 100 | .05 | 13.67 | 40 | 0.075 |
| 1N4113 | 19 | 250 | 150 | .05 | 14.44 | 40 | 0.075 |
| 1N4114 | 20 | 250 | 150 | .01 | 15.20 | 40 | 0.075 |
| 1N4115 | 22 | 250 | 150 | .01 | 16.72 | 40 | 0.080 |
| 1N4116 | 24 | 250 | 150 | .01 | 18.25 | 40 | 0.080 |
| 1N4117 | 25 | 250 | 150 | .01 | 19.00 | 40 | 0.080 |
| 1N4118 | 27 | 250 | 150 | .01 | 20.45 | 40 | 0.085 |
| 1N4119 | 28 | 250 | 200 | .01 | 21.28 | 40 | 0.085 |
| 1N4120 | 30 | 250 | 200 | .01 | 22.80 | 40 | 0.085 |
| 1N4121 | 33 | 250 | 200 | .01 | 25.08 | 40 | 0.085 |
| 1N4122 | 36 | 250 | 200 | .01 | 27.38 | 40 | 0.09 |
| 1N4123 | 39 | 250 | 200 | .01 | 29.65 | 40 | 0.09 |
| 1N4124 | 43 | 250 | 250 | .01 | 32.65 | 40 | 0.09 |
| 1N4125 | 47 | 250 | 250 | .01 | 35.75 | 40 | 0.09 |
| 1N4126 | 51 | 250 | 300 | .01 | 38.76 | 40 | 0.09 |
| 1N4127 | 56 | 250 | 300 | .01 | 42.60 | 40 | 0.09 |
| 1N4128 | 60 | 250 | 400 | .01 | 45.60 | 40 | 0.09 |
| 1N4129 | 62 | 250 | 500 | .01 | 47.10 | 40 | 0.09 |
| 1N4130 | 68 | 250 | 700 | .01 | 51.68 | 40 | 0.095 |
| 1N4131 | 75 | 250 | 700 | .01 | 57.00 | 40 | 0.095 |
| 1N4132 | 82 | 250 | 800 | .01 | 62.32 | 40 | 0.095 |
| 1N4133 | 87 | 250 | 1000 | .01 | 66.12 | 40 | 0.095 |
| 1N4134 | 91 | 250 | 1200 | .01 | 69.16 | 40 | 0.095 |
| 1N4135 | 100 | 250 | 1500 | .01 | 76.00 | 40 | 0.095 |

*JEDEC Registered Data.

**SILICON
400 mW
LOW NOISE
ZENER DIODES**

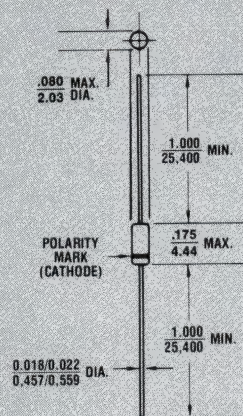


FIGURE 1

All dimensions in INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body in DO-35. Metallurgically bonded DO-35's exhibit less than 100°C/W at zero distance from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N4099 thru 1N4135, 1N4614 thru 1N4627 DO-35

Noise density, (N_D) is specified in microvolts-rms per square-root-hertz. Actual measurement is performed using a 1 KHz to 3 KHz frequency bandpass filter at a constant Zener test current (I_{ZT}) at 25°C ambient temperature. N_D is calculated from the formula.

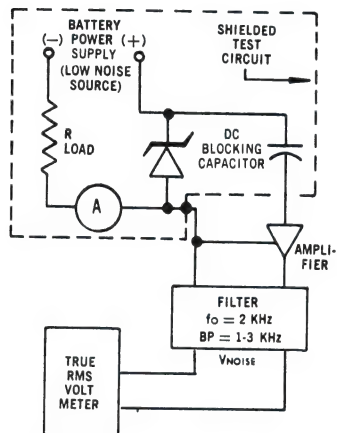


FIGURE 2 NOISE DENSITY MEASUREMENT CIRCUIT

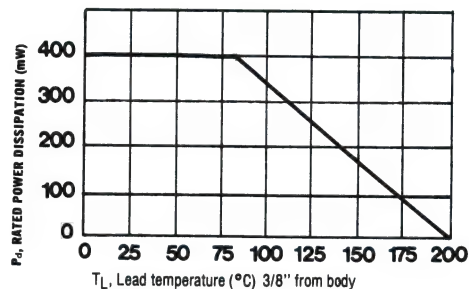


FIGURE 3 POWER DERATING CURVE

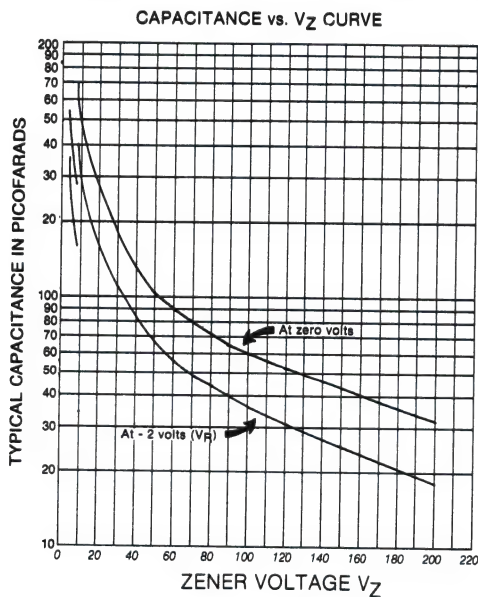


FIGURE 4
CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)

NOTE 1 The JEDEC type numbers shown above have a standard tolerance of $\pm 5\%$ on the nominal Zener voltage. Also available in 2% and 1% tolerance, suffix C and D respectively. V_Z is measured with the diode in thermal equilibrium in 25°C still air.

NOTE 2 Zener impedance is derived by superimposing on I_{ZT} , a 60 Hz rms a.c. current equal to 10% of I_{ZT} (25 μ A a.c.).

NOTE 3 Based upon 400 mW maximum power dissipation at 75°C lead temperature, allowance has been made for the higher voltage associated with operation at higher currents.

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

1N4460 thru 1N4496 and 1N6485 thru 1N6491

FEATURES

- Microminiature package.
- High performance characteristics.
- Stable operation at temperatures to 200°C.
- Voidless hermetically sealed glass package.
- Triple layer passivation.
- Very low thermal impedance.
- Metallurgically bonded.
- TX/TXV Types available per MIL-S-19500/406.

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C.
Storage Temperature: -65°C to +200°C.
Power Dissipation: 1.5 Watts @ 30°C Air Ambient.

ELECTRICAL CHARACTERISTICS

| TYPE | ZENER VOLTAGE (NOM.) V _Z | TEST CURRENT I _{zt} | DYNAMIC IMPEDANCE (MAX.) Z _{zt} @ I _{zt} | KNEE IMPEDANCE (MAX.) Z _{zk} @ I _{zk} | TEST CURRENT I _{zk} | REVERSE CURRENT (MAX.) I _R @ V _R | TEST VOLTAGE V _R | MAXIMUM CONT. I _{zm} | RATINGS MAXIMUM SURGE I _s | T _a = 100°C |
|--------|--|---------------------------------|---|--|---------------------------------|---|--------------------------------|-------------------------------|--------------------------------------|------------------------|
| | VOLTS | mA | OHMS | OHMS | mA | μA | VOLTS | mA | Amps | |
| 1N6485 | 3.3 | 76.0 | 10 | 400 | 1.0 | 50 | 1.0 | 433 | - | 4.2 |
| 1N6486 | 3.6 | 69.0 | 10 | 400 | 1.0 | 50 | 1.0 | 397 | - | 3.9 |
| 1N6487 | 3.9 | 64.0 | 9 | 400 | 1.0 | 35 | 1.0 | 366 | - | 3.6 |
| 1N6488 | 4.3 | 58.0 | 9 | 400 | 1.0 | 5.0 | 1.0 | 332 | - | 3.3 |
| 1N6489 | 4.7 | 53.0 | 8 | 500 | 1.0 | 4.0 | 1.0 | 304 | - | 3.0 |
| 1N6490 | 5.1 | 49.0 | 7 | 500 | 1.0 | 1.0 | 1.0 | 280 | - | 2.7 |
| 1N6491 | 5.6 | 45.0 | 5 | 600 | 1.0 | 0.5 | 2.0 | 255 | - | 2.5 |
| 1N4460 | 6.2 | 40.0 | 4 | 200 | 1.0 | 10.0 | 3.72 | 230 | - | 2.3 |
| 1N4461 | 6.8 | 37.0 | 2.5 | 200 | 1.0 | 5.0 | 4.08 | 210 | 5.0 | 2.1 |
| 1N4462 | 7.5 | 34.0 | 2.5 | 400 | .5 | 1.0 | 4.50 | 191 | 4.5 | 1.9 |
| 1N4463 | 8.2 | 31.0 | 3 | 400 | .5 | .50 | 4.92 | 174 | 3.9 | 1.7 |
| 1N4464 | 9.1 | 28.0 | 4 | 500 | .5 | .30 | 5.46 | 157 | 3.4 | 1.6 |
| 1N4465 | 10.0 | 25.0 | 5 | 500 | .25 | .30 | 8.00 | 143 | 3.0 | 1.4 |
| 1N4466 | 11.0 | 23.0 | 6 | 550 | .25 | .30 | 8.80 | 130 | 2.6 | 1.3 |
| 1N4467 | 12.0 | 21.0 | 7 | 550 | .25 | .20 | 9.60 | 119 | 2.4 | 1.2 |
| 1N4468 | 13.0 | 19.0 | 8 | 550 | .25 | .05 | 10.40 | 110 | 2.2 | 1.1 |
| 1N4469 | 15.0 | 17.0 | 9 | 600 | .25 | .05 | 12.00 | 95 | 1.8 | .95 |
| 1N4470 | 16.0 | 15.5 | 10 | 600 | .25 | .05 | 12.80 | 90 | 1.6 | .80 |
| 1N4471 | 18.0 | 14.0 | 11 | 650 | .25 | .05 | 14.40 | 79 | 1.4 | .79 |
| 1N4472 | 20.0 | 12.5 | 12 | 650 | .25 | .05 | 16.00 | 71 | 1.2 | .71 |
| 1N4473 | 22.0 | 11.5 | 14 | 650 | .25 | .05 | 17.60 | 65 | 1.1 | .65 |
| 1N4474 | 24.0 | 10.5 | 16 | 700 | .25 | .05 | 19.20 | 60 | .90 | .60 |
| 1N4475 | 27.0 | 9.5 | 18 | 700 | .25 | .05 | 21.60 | 53 | .80 | .53 |
| 1N4476 | 30.0 | 8.5 | 20 | 750 | .25 | .05 | 24.00 | 48 | .75 | .48 |
| 1N4477 | 33.0 | 7.5 | 25 | 800 | .25 | .05 | 26.40 | 43 | .66 | .43 |
| 1N4478 | 36.0 | 7.0 | 27 | 850 | .25 | .05 | 28.80 | 40 | .60 | .40 |
| 1N4479 | 39.0 | 6.5 | 30 | 900 | .25 | .05 | 31.2 | 37 | .54 | .37 |
| 1N4480 | 43.0 | 6.0 | 40 | 950 | .25 | .05 | 34.4 | 33 | .48 | .33 |
| 1N4481 | 47.0 | 5.5 | 50 | 1000 | .25 | .05 | 37.6 | 30 | .45 | .30 |
| 1N4482 | 51.0 | 5.0 | 60 | 1100 | .25 | .05 | 40.8 | 28 | .42 | .28 |
| 1N4483 | 56.0 | 4.5 | 70 | 1300 | .25 | .25 | 44.8 | 26 | .39 | .26 |
| 1N4484 | 62.0 | 4.0 | 80 | 1500 | .25 | .25 | 49.6 | 23 | .35 | .23 |
| 1N4485 | 68.0 | 3.7 | 100 | 1700 | .25 | .25 | 54.4 | 21 | .32 | .21 |
| 1N4486 | 75.0 | 3.3 | 130 | 2000 | .25 | .25 | 60.4 | 19 | .29 | .19 |
| 1N4487 | 82.0 | 3.0 | 160 | 2500 | .25 | .25 | 65.6 | 17 | .26 | .17 |
| 1N4488 | 91.0 | 2.8 | 200 | 3000 | .25 | .25 | 72.8 | 16 | .23 | .16 |
| 1N4489 | 100.0 | 2.5 | 250 | 3100 | .25 | .25 | 80.0 | 14 | .20 | .14 |
| 1N4490 | 110.0 | 2.0 | 300 | 4000 | .25 | .25 | 88.0 | 13 | .19 | .13 |
| 1N4491 | 120.0 | 2.0 | 400 | 4500 | .25 | .25 | 96.0 | 12 | .18 | .12 |
| 1N4492 | 130.0 | 1.9 | 500 | 5000 | .25 | .25 | 104.0 | 11 | .16 | .11 |
| 1N4493 | 150.0 | 1.7 | 700 | 6000 | .25 | .25 | 120.0 | 9.5 | .14 | .095 |
| 1N4494 | 160.0 | 1.6 | 1000 | 6500 | .25 | .25 | 128.0 | 8.9 | .12 | .089 |
| 1N4495 | 180.0 | 1.4 | 1300 | 7000 | .25 | .25 | 144.0 | 7.9 | .10 | .079 |
| 1N4496 | 200.0 | 1.2 | 1500 | 8000 | .25 | .25 | 160.0 | 7.2 | .08 | .072 |

1.5 WATT GLASS ZENER DIODES

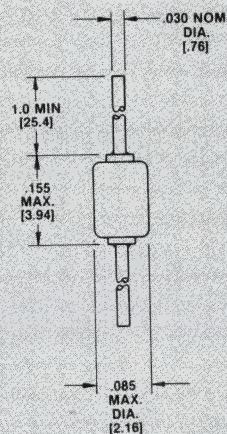
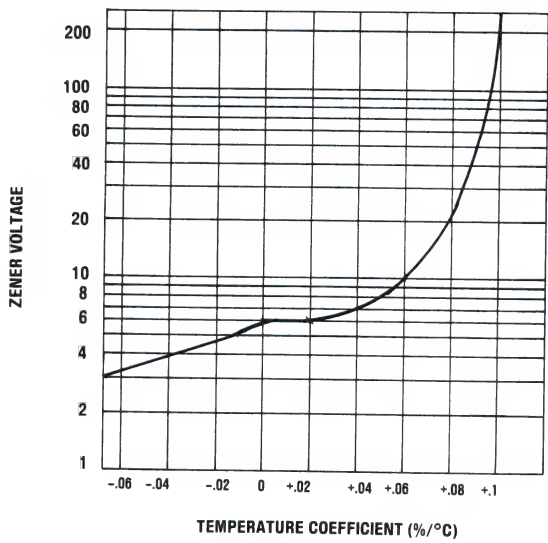


FIGURE 1

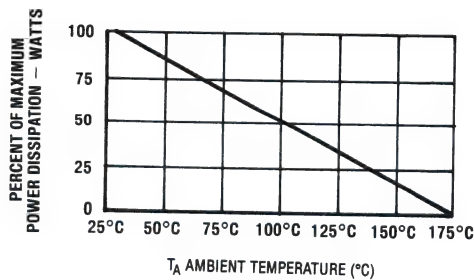
MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass case.
Lead Material: Tinned copper.
Marking: Body painted, alpha
numeric with JEDEC number.
Polarity: Cathode band.

1N4460 thru 1N4496 and 1N6485 thru 1N6491



**FIGURE 2
TYPICAL TEMPERATURE
COEFFICIENT CHARACTERISTICS**



**FIGURE 3
POWER TEMPERATURE DERATING CURVE**

1N4678 thru 1N4717

FEATURES

- LOW OPERATING CURRENT AT 50 μ A
- STANDARD $\pm 5\%$ VOLTAGE TOLERANCE
- GUARANTEED VOLTAGE REGULATION
- ALSO AVAILABLE IN DO-35 PACKAGE

MAXIMUM RATINGS

Junction and Storage Temperature: -65°C to $+200^{\circ}\text{C}$

DC Power Dissipation: 250mW (Capable of 400mW in DO-7 package supplied)

Power Derating: 1.66mW/ $^{\circ}\text{C}$ above 50°C Ambient (2.28mW/ $^{\circ}\text{C}$ above 25°C in DO-7)

Forward Voltage @ 100mA: 1.5 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NUMBER | NOMINAL ZENER VOLTAGE (NOTE 3) | ZENER TEST CURRENT | MAXIMUM VOLTAGE REGULATION (NOTE 2 & 3) | MAXIMUM REVERSE LEAKAGE CURRENT | MAXIMUM DC ZENER CURRENT |
|-------------------|--------------------------------|--------------------|---|---------------------------------|--------------------------|
| (NOTE 1) | V_Z | I_{ZT} | ΔV_Z | I_R @ V_R | I_{ZM} |
| | VOLTS * | μA | VOLTS | μA VOLTS | mA |
| 1N4678 | 1.8 | 50 | 0.70 | 7.5 | 1.0 |
| 1N4679 | 2.0 | 50 | 0.70 | 5.0 | 1.0 |
| 1N4680 | 2.2 | 50 | 0.75 | 4.0 | 1.0 |
| 1N4681 | 2.4 | 50 | 0.80 | 2.0 | 1.0 |
| 1N4682 | 2.7 | 50 | 0.85 | 1.0 | 1.0 |
| 1N4683 | 3.0 | 50 | 0.90 | 0.8 | 1.0 |
| 1N4684 | 3.3 | 50 | 0.95 | 7.5 | 1.5 |
| 1N4685 | 3.6 | 50 | 0.95 | 7.5 | 2.0 |
| 1N4686 | 3.9 | 50 | 0.97 | 5.0 | 2.0 |
| 1N4687 | 4.3 | 50 | 0.99 | 4.0 | 2.0 |
| 1N4688 | 4.7 | 50 | 0.99 | 10.0 | 3.0 |
| 1N4689 | 5.1 | 50 | 0.97 | 10.0 | 3.0 |
| 1N4690 | 5.6 | 50 | 0.96 | 10.0 | 4.0 |
| 1N4691 | 6.2 | 50 | 0.95 | 10.0 | 5.0 |
| 1N4692 | 6.8 | 50 | 0.90 | 10.0 | 5.1 |
| 1N4693 | 7.5 | 50 | 0.75 | 10.0 | 5.7 |
| 1N4694 | 8.2 | 50 | 0.50 | 1.0 | 6.2 |
| 1N4695 | 8.7 | 50 | 0.10 | 1.0 | 6.6 |
| 1N4696 | 9.1 | 50 | 0.08 | 1.0 | 6.9 |
| 1N4697 | 10.0 | 50 | 0.10 | 1.0 | 7.6 |
| 1N4698 | 11.0 | 50 | 0.11 | 0.05 | 8.4 |
| 1N4699 | 12.0 | 50 | 0.12 | 0.05 | 9.1 |
| 1N4700 | 13.0 | 50 | 0.13 | 0.05 | 9.8 |
| 1N4701 | 14.0 | 50 | 0.14 | 0.05 | 10.6 |
| 1N4702 | 15.0 | 50 | 0.15 | 0.05 | 11.4 |
| 1N4703 | 16.0 | 50 | 0.16 | 0.05 | 12.1 |
| 1N4704 | 17.0 | 50 | 0.17 | 0.05 | 12.9 |
| 1N4705 | 18.0 | 50 | 0.18 | 0.05 | 13.6 |
| 1N4706 | 19.0 | 50 | 0.19 | 0.05 | 14.4 |
| 1N4707 | 20.0 | 50 | 0.20 | 0.01 | 15.2 |
| 1N4708 | 22.0 | 50 | 0.22 | 0.01 | 16.7 |
| 1N4709 | 24.0 | 50 | 0.24 | 0.01 | 18.2 |
| 1N4710 | 25.0 | 50 | 0.25 | 0.01 | 19.0 |
| 1N4711 | 27.0 | 50 | 0.27 | 0.01 | 20.4 |
| 1N4712 | 28.0 | 50 | 0.28 | 0.01 | 21.2 |
| 1N4713 | 30.0 | 50 | 0.30 | 0.01 | 22.8 |
| 1N4714 | 33.0 | 50 | 0.33 | 0.01 | 25.0 |
| 1N4715 | 36.0 | 50 | 0.36 | 0.01 | 27.3 |
| 1N4716 | 39.0 | 50 | 0.39 | 0.01 | 29.6 |
| 1N4717 | 43.0 | 50 | 0.43 | 0.01 | 32.6 |

* JEDEC Registered Data

NOTE 1 All types as shown are $\pm 5\%$ tolerance. Also available in 2% and 1% tolerance, suffix C and D respectively.

NOTE 2 ΔV_Z @ 100 μA minus V_Z @ 10 μA .

NOTE 3 The electrical characteristics are measured after allowing the device to stabilize for 20 seconds when mounted with 3/8" minimum lead length from the base.

SILICON 250 mW ZENER DIODES

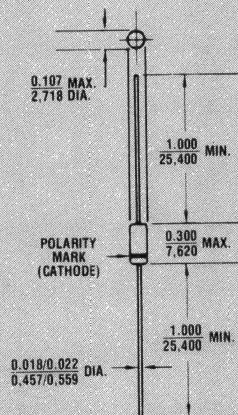


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $300^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N4678 thru 1N4717

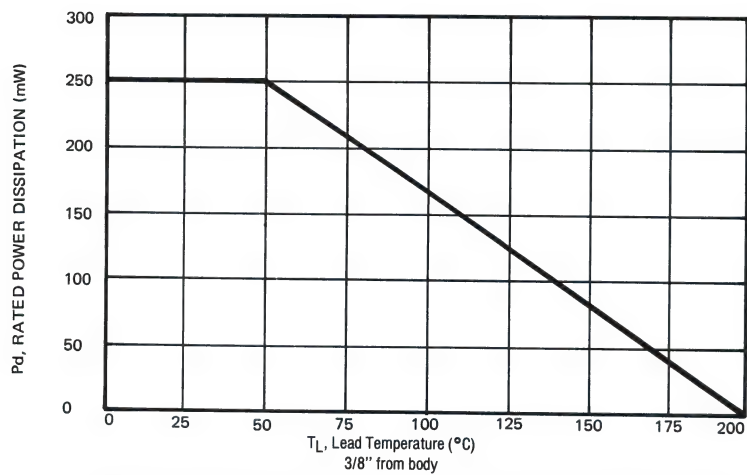


FIGURE 2 POWER DERATING CURVE FOR SUPPLIED DO-7 PACKAGE

1N4728A thru 1N4764A PLASTIC

FEATURES

- 3.3 THRU 100 VOLT VOLTAGE RANGE
- HIGH SURGE CURRENT RATING
- HIGHER VOLTAGES AVAILABLE, SEE 1EZ SERIES

MAXIMUM RATINGS

Junction and Storage Temperature: -65°C to $+200^{\circ}\text{C}$
DC Power Dissipation: 1 Watt
Power Derating: $10\text{mW}/^{\circ}\text{C}$, from 100°C
Forward Voltage @ 200 mA: 1.2 Volts

*ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NUMBER (Note 1) | ZENER VOLTAGE (V_z) (Note 4) | TEST CURRENT (I_{zT}) | MAXIMUM DYNAMIC IMPEDANCE (Z_{zT} @ I_{zT}) (Note 2) | MAXIMUM REVERSE CURRENT (I_{R} @ V_R) | TEST VOLTAGE (V_R) | MAXIMUM REGULATOR CURRENT (I_{zR}) $T_A = 50^{\circ}\text{C}$ | MAXIMUM KNEE IMPEDANCE (Z_{k} @ I_{zK}) (Note 2) | TEST CURRENT (I_{zK}) | MAXIMUM (SURGE) CURRENT (I_S) (Note 3) |
|-------------------------------------|---|---------------------------------|--|--|------------------------------|---|--|---------------------------------|--|
| | VOLTS | mA | OHMS | μA | VOLTS | mA | OHMS | mA | mA |
| 1N4728A | 3.3 | 76 | 10 | 100 | 1 | 276 | 400 | 1.0 | 1380 |
| 1N4728A | 3.6 | 69 | 10 | 100 | 1 | 252 | 400 | 1.0 | 1260 |
| 1N4730A | 3.9 | 64 | 9 | 50 | 1 | 234 | 400 | 1.0 | 1190 |
| 1N4731A | 4.3 | 58 | 9 | 10 | 1 | 217 | 400 | 1.0 | 1070 |
| 1N4732A | 4.7 | 53 | 8 | 10 | 1 | 193 | 500 | 1.0 | 970 |
| 1N4733A | 5.1 | 49 | 7 | 10 | 1 | 178 | 550 | 1.0 | 890 |
| 1N4734A | 5.6 | 45 | 5 | 10 | 2 | 162 | 600 | 1.0 | 810 |
| 1N4735A | 6.2 | 41 | 2 | 10 | 3 | 146 | 700 | 1.0 | 730 |
| 1N4736A | 6.8 | 37 | 3.5 | 10 | 4 | 133 | 700 | 1.0 | 660 |
| 1N4737A | 7.5 | 34 | 4.0 | 10 | 5 | 121 | 700 | 0.5 | 605 |
| 1N4738A | 8.2 | 31 | 4.5 | 10 | 6 | 110 | 700 | 0.5 | 550 |
| 1N4739A | 9.1 | 28 | 5.0 | 10 | 7 | 100 | 700 | 0.5 | 500 |
| 1N4740A | 10 | 25 | 7 | 10 | 7.6 | 91 | 700 | 0.25 | 454 |
| 1N4741A | 11 | 23 | 8 | 5 | 8.4 | 83 | 700 | 0.25 | 414 |
| 1N4742A | 12 | 21 | 9 | 5 | 9.1 | 76 | 700 | 0.25 | 380 |
| 1N4743A | 13 | 19 | 10 | 5 | 9.9 | 69 | 700 | 0.25 | 344 |
| 1N4744A | 15 | 17 | 14 | 5 | 11.4 | 61 | 700 | 0.25 | 304 |
| 1N4745A | 16 | 15.5 | 16 | 5 | 12.2 | 57 | 700 | 0.25 | 285 |
| 1N4746A | 18 | 14 | 20 | 5 | 13.7 | 50 | 750 | 0.25 | 250 |
| 1N4747A | 20 | 12.5 | 22 | 5 | 15.2 | 45 | 750 | 0.25 | 225 |
| 1N4748A | 22 | 11.5 | 23 | 5 | 16.7 | 41 | 750 | 0.25 | 205 |
| 1N4749A | 24 | 10.5 | 25 | 5 | 18.2 | 38 | 750 | 0.25 | 190 |
| 1N4750A | 27 | 9.5 | 35 | 5 | 20.6 | 34 | 750 | 0.25 | 170 |
| 1N4751A | 30 | 8.5 | 40 | 5 | 22.8 | 30 | 1000 | 0.25 | 150 |
| 1N4752A | 33 | 7.5 | 45 | 5 | 25.1 | 27 | 1000 | 0.25 | 135 |
| 1N4753A | 36 | 7.0 | 50 | 5 | 27.4 | 25 | 1000 | 0.25 | 125 |
| 1N4754A | 39 | 6.5 | 60 | 5 | 29.7 | 23 | 1000 | 0.25 | 115 |
| 1N4755A | 43 | 6.0 | 70 | 5 | 32.7 | 22 | 1500 | 0.25 | 110 |
| 1N4756A | 47 | 5.5 | 80 | 5 | 35.8 | 19 | 1500 | 0.25 | 95 |
| 1N4757A | 51 | 5.0 | 95 | 5 | 38.8 | 18 | 1500 | 0.25 | 90 |
| 1N4758A | 56 | 4.5 | 110 | 5 | 42.6 | 16 | 2000 | 0.25 | 80 |
| 1N4759A | 62 | 4.0 | 125 | 5 | 47.1 | 14 | 2000 | 0.25 | 70 |
| 1N4760A | 68 | 3.7 | 150 | 5 | 51.7 | 13 | 2000 | 0.25 | 65 |
| 1N4761A | 75 | 3.3 | 175 | 5 | 56.0 | 12 | 2000 | 0.25 | 60 |
| 1N4762A | 82 | 3.0 | 200 | 5 | 62.2 | 11 | 3000 | 0.25 | 55 |
| 1N4763A | 91 | 2.8 | 250 | 5 | 69.2 | 10 | 3000 | 0.25 | 50 |
| 1N4764A | 100 | 2.5 | 350 | 5 | 76.0 | 9 | 3000 | 0.25 | 45 |

*JEDEC Registered Data

SILICON 1 WATT ZENER DIODES

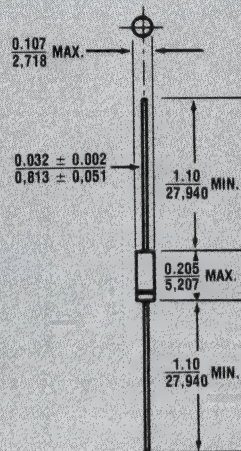


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Molded encapsulation, axial lead package (Case J).

FINISH: Corrosion resistant. Leads are solderable.

THERMAL RESISTANCE: $45^{\circ}\text{C}/\text{Watt}$ junction to lead at 0.375-inches from body.

POLARITY: Banded end is cathode.

WEIGHT: 0.4 grams (Typical).

1N4728A thru 1N4764A PLASTIC

NOTE 1 The JEDEC type numbers shown have a 5% tolerance on nominal zener voltage. No suffix signifies a 10% tolerance, C signifies 2%, and D signifies 1% tolerance.

NOTE 2 The Zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the DC Zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured

at two points to insure a sharp knee on the breakdown curve and eliminate unstable units.

NOTE 3 The reverse surge current is measured at 25°C ambient using a 1/2 square wave or equivalent sine wave pulse 1/120 second duration superimposed on I_{ZT} .

NOTE 4 Voltage measurements to be performed 90 seconds after application of DC current.

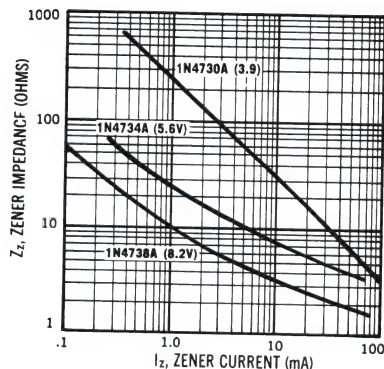


FIGURE 2
TYPICAL ZENER IMPEDANCE vs.
ZENER CURRENT FOR TYPES SHOWN

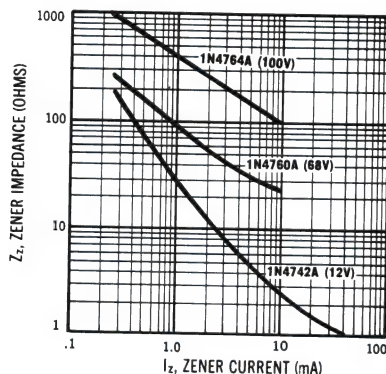


FIGURE 3
TYPICAL ZENER IMPEDANCE vs.
ZENER CURRENT FOR TYPES SHOWN

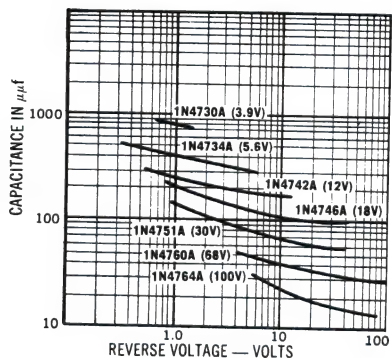


FIGURE 4
CAPACITANCE vs. VOLTAGE FOR
REPRESENTATIVE TYPES

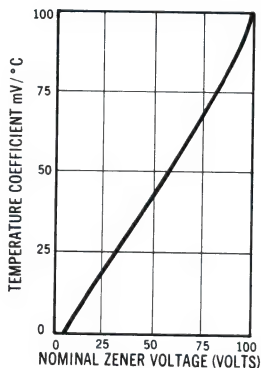


FIGURE 5
TEMP. COEFF. vs.
ZENER VOLTAGE

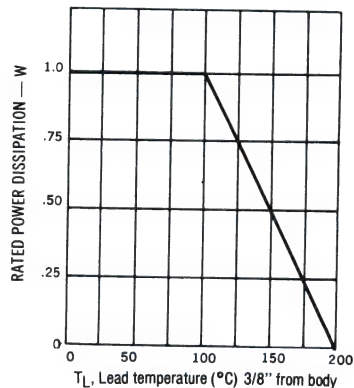


FIGURE 6
POWER DERATING CURVE

1N4728A thru 1N4764A DO-41 GLASS

FEATURES

- 3.3 THRU 100 VOLTS
- HERMETIC GLASS PACKAGE
- CONSULT FACTORY FOR VOLTAGES OVER 100 V

MAXIMUM RATINGS

Junction and Storage Temperature: -65°C to +200°C

Power Dissipation at T_L 100°C; 1.0 Watt

Power Derating from 100°C; 10 mW/°C

T_L = lead temperature at 3/8" from body

*ELECTRICAL CHARACTERISTICS

(at +25°C ambient.)

Maximum forward voltage 1.2 volts at 200 mA

| JEDEC TYPE NUMBER (Note 1) | ZENER VOLTAGE (V_Z) (Note 4) | TEST CURRENT (I_Z) | MAXIMUM DYNAMIC IMPEDANCE (Z_{ZT} @ I_{ZT}) (Note 2) | MAXIMUM REVERSE CURRENT (I_R @ V_R) | TEST VOLTAGE (V_R) | MAXIMUM REGULATOR CURRENT (I_{ZW}) $T_A = 50^\circ\text{C}$ | MAXIMUM KNEE IMPEDANCE (Z_{ZK} @ I_{ZK}) (Note 2) | TEST CURRENT (I_{ZK}) | MAXIMUM SURGE CURRENT (I_S) (Note 3) |
|-------------------------------------|---|------------------------------|--|--|------------------------------|---|---|---------------------------------|--|
| | VOLTS | mA | OHMS | μA | VOLTS | mA | OHMS | mA | mA |
| 1N4728A | 3.3 | 76 | 10 | 100 | 1 | 276 | 400 | 1.0 | 1380 |
| 1N4729A | 3.6 | 69 | 10 | 100 | 1 | 252 | 400 | 1.0 | 1260 |
| 1N4730A | 3.9 | 64 | 9 | 50 | 1 | 234 | 400 | 1.0 | 1190 |
| 1N4731A | 4.3 | 58 | 9 | 10 | 1 | 217 | 400 | 1.0 | 1070 |
| 1N4732A | 4.7 | 53 | 8 | 10 | 1 | 193 | 500 | 1.0 | 970 |
| 1N4733A | 5.1 | 49 | 7 | 10 | 1 | 178 | 550 | 1.0 | 890 |
| 1N4734A | 5.6 | 45 | 5 | 10 | 2 | 162 | 600 | 1.0 | 810 |
| 1N4735A | 6.2 | 41 | 2 | 10 | 3 | 146 | 700 | 1.0 | 730 |
| 1N4736A | 6.8 | 37 | 3.5 | 10 | 4 | 133 | 700 | 1.0 | 660 |
| 1N4737A | 7.5 | 34 | 4.0 | 10 | 5 | 121 | 700 | 0.5 | 605 |
| 1N4738A | 8.2 | 31 | 4.5 | 10 | 6 | 110 | 700 | 0.5 | 550 |
| 1N4739A | 9.1 | 28 | 5.0 | 10 | 7 | 100 | 700 | 0.5 | 500 |
| 1N4740A | 10 | 25 | 7 | 10 | 7.6 | 91 | 700 | 0.25 | 454 |
| 1N4741A | 11 | 23 | 8 | 5 | 8.4 | 83 | 700 | 0.25 | 414 |
| 1N4742A | 12 | 21 | 9 | 5 | 9.1 | 76 | 700 | 0.25 | 380 |
| 1N4743A | 13 | 19 | 10 | 5 | 9.9 | 69 | 700 | 0.25 | 344 |
| 1N4744A | 15 | 17 | 14 | 5 | 11.4 | 61 | 700 | 0.25 | 304 |
| 1N4745A | 16 | 15.5 | 16 | 5 | 12.2 | 57 | 700 | 0.25 | 285 |
| 1N4746A | 18 | 14 | 20 | 5 | 13.7 | 50 | 750 | 0.25 | 250 |
| 1N4747A | 20 | 12.5 | 22 | 5 | 15.2 | 45 | 750 | 0.25 | 225 |
| 1N4748A | 22 | 11.5 | 23 | 5 | 16.7 | 41 | 750 | 0.25 | 205 |
| 1N4749A | 24 | 10.5 | 25 | 5 | 18.2 | 38 | 750 | 0.25 | 190 |
| 1N4750A | 27 | 9.5 | 35 | 5 | 20.6 | 34 | 750 | 0.25 | 170 |
| 1N4751A | 30 | 8.5 | 40 | 5 | 22.8 | 30 | 1000 | 0.25 | 150 |
| 1N4752A | 33 | 7.5 | 45 | 5 | 25.1 | 27 | 1000 | 0.25 | 135 |
| 1N4753A | 36 | 7.0 | 50 | 5 | 27.4 | 25 | 1000 | 0.25 | 125 |
| 1N4754A | 39 | 6.5 | 60 | 5 | 29.7 | 23 | 1000 | 0.25 | 115 |
| 1N4755A | 43 | 6.0 | 70 | 5 | 32.7 | 22 | 1500 | 0.25 | 110 |
| 1N4756A | 47 | 5.5 | 80 | 5 | 35.8 | 19 | 1500 | 0.25 | 95 |
| 1N4757A | 51 | 5.0 | 95 | 5 | 38.8 | 18 | 1500 | 0.25 | 90 |
| 1N4758A | 56 | 4.5 | 110 | 5 | 42.6 | 16 | 2000 | 0.25 | 80 |
| 1N4759A | 62 | 4.0 | 125 | 5 | 47.1 | 14 | 2000 | 0.25 | 70 |
| 1N4760A | 68 | 3.7 | 150 | 5 | 51.7 | 13 | 2000 | 0.25 | 65 |
| 1N4761A | 75 | 3.3 | 175 | 5 | 56.0 | 12 | 2000 | 0.25 | 60 |
| 1N4762A | 82 | 3.0 | 200 | 5 | 62.2 | 11 | 3000 | 0.25 | 55 |
| 1N4763A | 91 | 2.8 | 250 | 5 | 69.2 | 10 | 3000 | 0.25 | 50 |
| 1N4764A | 100 | 2.5 | 350 | 5 | 76.0 | 9 | 3000 | 0.25 | 45 |

*JEDEC Registered Data

SILICON 1 WATT ZENER DIODES

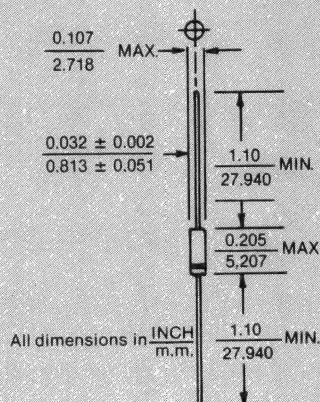


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case, DO-41 Outline.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: Less than 100°C/Watt junction to lead at 0.375-inches from body.

POLARITY: Banded end is cathode.

WEIGHT: 0.378 grams (Typical).

1N4728A DO-41 thru 1N4764A DO-41

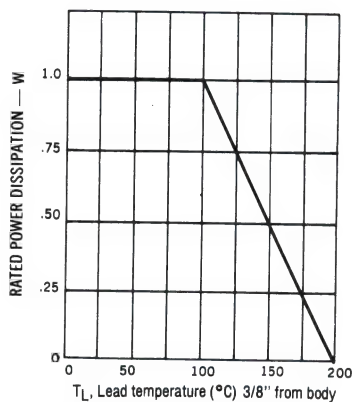


FIGURE 2. POWER DERATING CURVE

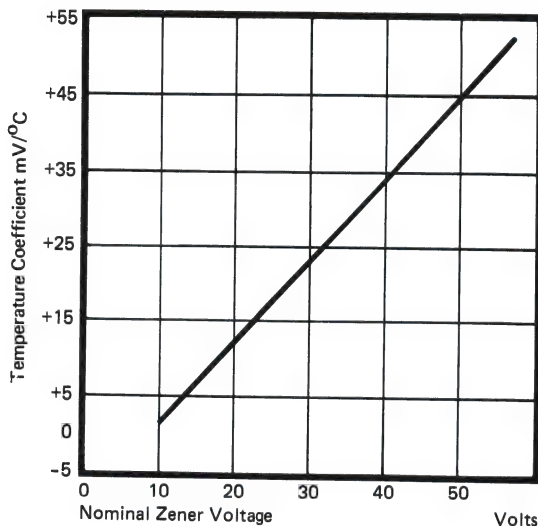


FIGURE 3. TYPICAL TEMPERATURE COEFFICIENT vs ZENER VOLTAGE

NOTE 1. The JEDEC type numbers shown with an 'A' suffix have a 5% tolerance on nominal zener voltage. No suffix signifies a 10% tolerance, C signifies 2%, and D suffix signifies 1% tolerance.

NOTE 2. The Zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the DC Zener current (I_{zk} or I_{zk}) is superimposed on I_{ZT} or I_{zk} . Zener impedance is measured at two points to insure

a sharp knee on the breakdown curve and eliminate unstable units.

NOTE 3. The reverse surge current is measured at 25°C ambient using a 1/2 square wave or equivalent sine wave pulse 1/120 second duration superimposed on I_{ZT} .

NOTE 4. Voltage measurements to be performed 90 seconds after application of DC current.

Microsemi Corp.
The diode experts

SANTA ANA, CA
For more information call:
(714) 979-8220

SCOTTSDALE, AZ

1N4954 thru 1N4996 and 1N5968, 1N5969

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- HIGH PERFORMANCE CHARACTERISTICS

- VERY LOW THERMAL IMPEDANCE
- TX/TXV TYPES AVAILABLE PER MIL-S-19500/356

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C
Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

| TYPE* | ELECTRICAL SPECIFICATIONS AT 25°C | | | | | | | | | | MAXIMUM RATINGS | |
|--------|---|-----------------------------|-------------------------|---------------------------|--|---|-------|--|--|-------------------------------|-----------------|------|
| | NOMINAL ZENER VOLTAGE $V_Z @ I_{ZT}$ | TEST CURRENT I_{ZT} | MAXIMUM ZENER IMPEDANCE | | REGULATION $\Delta BV / \Delta V_Z$ | MAXIMUM REVERSE LEAKAGE CURRENT VOLTAGE | | MAXIMUM TEMPERATURE COEFF. $T_C @ I_{ZT}$ | MAXIMUM CONTINUOUS CURRENT I_{ZM} | SURGE CURRENT I_{ZSM} | mA | AMPS |
| | | | $Z_Z @ I_{ZT}$ | $Z_{ZK}^* @ I_{ZK} = 1mA$ | | $I_R \uparrow \downarrow$ | V_R | | | | | |
| | VOLTS | mA | OHMS | OHMS | VOLTS | μA | VOLTS | %/°C | | | | |
| 1N5968 | 5.6 | 220 | 1.0 | 400 | 0.4 | 5000 | 4.28 | .04 | 865 | 20 | | |
| 1N5969 | 6.2 | 220 | 1.0 | 1000 | 0.5 | 1000 | 4.74 | .04 | 765 | 20 | | |
| 1N4954 | 6.8 | 175 | 1.0 | 1000 | 0.7 | 150 | 5.2 | .05 | 700 | 40 | | |
| 1N4955 | 7.5 | 175 | 1.5 | 800 | 0.7 | 100 | 5.7 | .06 | 630 | 32 | | |
| 1N4956 | 8.2 | 150 | 1.5 | 600 | 0.7 | 50 | 6.2 | .06 | 580 | 24 | | |
| 1N4957 | 9.1 | 150 | 2.0 | 400 | 0.7 | 25 | 6.9 | .06 | 520 | 22 | | |
| 1N4958 | 10.0 | 125 | 2.0 | 125 | 0.8 | 25 | 7.6 | .07 | 475 | 20 | | |
| 1N4959 | 11 | 125 | 2.5 | 130 | 0.8 | 10 | 8.4 | .07 | 430 | 19 | | |
| 1N4960 | 12 | 100 | 2.5 | 140 | 0.8 | 10 | 9.1 | .07 | 395 | 18 | | |
| 1N4961 | 13 | 100 | 3.0 | 145 | 0.8 | 10 | 9.9 | .08 | 365 | 16 | | |
| 1N4962 | 15 | 75 | 3.5 | 150 | 1.0 | 5 | 11.4 | .08 | 315 | 12 | | |
| 1N4963 | 16 | 75 | 3.5 | 155 | 1.1 | 5 | 12.2 | .08 | 294 | 10 | | |
| 1N4964 | 18 | 65 | 4.0 | 160 | 1.2 | 5 | 13.7 | .085 | 264 | 9.0 | | |
| 1N4965 | 20 | 65 | 4.5 | 165 | 1.5 | 2 | 15.2 | .085 | 237 | 8.0 | | |
| 1N4966 | 22 | 50 | 5.0 | 170 | 1.8 | 2 | 16.7 | .085 | 216 | 7.0 | | |
| 1N4967 | 24 | 50 | 5.0 | 175 | 2.0 | 2 | 18.2 | .090 | 198 | 6.5 | | |
| 1N4968 | 27 | 50 | 6.0 | 180 | 2.0 | 2 | 20.6 | .090 | 176 | 6.0 | | |
| 1N4969 | 30 | 40 | 8 | 190 | 2.5 | 2 | 22.8 | .090 | 158 | 5.5 | | |
| 1N4970 | 33 | 40 | 10 | 200 | 2.8 | 2 | 25.1 | .095 | 144 | 5.0 | | |
| 1N4971 | 36 | 30 | 11 | 220 | 3.0 | 2 | 27.4 | .095 | 132 | 4.5 | | |
| 1N4972 | 39 | 30 | 14 | 230 | 3.0 | 2 | 29.7 | .095 | 122 | 4.0 | | |
| 1N4973 | 43 | 30 | 20 | 240 | 3.3 | 2 | 32.7 | .095 | 110 | 3.5 | | |
| 1N4974 | 47 | 25 | 25 | 250 | 3.5 | 2 | 35.8 | .095 | 100 | 3.2 | | |
| 1N4975 | 51 | 25 | 27 | 270 | 4.0 | 2 | 38.8 | .095 | 92 | 3.0 | | |
| 1N4976 | 56 | 20 | 35 | 320 | 4.4 | 2 | 42.6 | .095 | 84 | 2.8 | | |
| 1N4977 | 62 | 20 | 42 | 400 | 5.0 | 2 | 47.1 | .100 | 76 | 2.5 | | |
| 1N4978 | 68 | 20 | 50 | 500 | 5.5 | 2 | 51.7 | .100 | 70 | 2.2 | | |
| 1N4979 | 75 | 20 | 55 | 620 | 6.0 | 2 | 56.0 | .100 | 63.0 | 2.0 | | |
| 1N4980 | 82 | 15 | 80 | 720 | 6.6 | 2 | 62.2 | .100 | 58.0 | 1.8 | | |
| 1N4981 | 91 | 15 | 90 | 760 | 7.5 | 2 | 69.2 | .100 | 52.5 | 1.6 | | |
| 1N4982 | 100 | 12 | 110 | 800 | 8.0 | 2 | 76.0 | .100 | 47.5 | 1.4 | | |
| 1N4983 | 110 | 12 | 125 | 1000 | 9.0 | 2 | 83.6 | .100 | 43.0 | 1.2 | | |
| 1N4984 | 120 | 10 | 170 | 1150 | 10 | 2 | 91.2 | .100 | 39.5 | 1.00 | | |
| 1N4985 | 130 | 10 | 190 | 1250 | 11 | 2 | 98.8 | .105 | 36.6 | 0.80 | | |
| 1N4986 | 150 | 8 | 330 | 1500 | 13 | 2 | 114.0 | .105 | 31.6 | 0.75 | | |
| 1N4987 | 160 | 8 | 350 | 1650 | 14 | 2 | 121.6 | .105 | 29.4 | 0.70 | | |
| 1N4988 | 180 | 5 | 450 | 1750 | 16 | 2 | 136.8 | .110 | 26.4 | 0.60 | | |
| 1N4989 | 200 | 5 | 500 | 1850 | 18 | 2 | 152 | .110 | 23.6 | 0.50 | | |
| 1N4990 | 220 | 5 | 550 | 2000 | 19 | 2 | 167 | .115 | 21.6 | 0.50 | | |
| 1N4991 | 240 | 5 | 650 | 2050 | 22 | 2 | 182 | .115 | 19.8 | 0.40 | | |
| 1N4992 | 270 | 5 | 800 | 2100 | 25 | 2 | 206 | .120 | 17.5 | 0.35 | | |
| 1N4993 | 300 | 4 | 950 | 2150 | 28 | 2 | 228 | .120 | 15.6 | 0.30 | | |
| 1N4994 | 330 | 4 | 1175 | 2200 | 32 | 2 | 251 | .120 | 14.4 | 0.25 | | |
| 1N4995 | 360 | 3 | 1400 | 2300 | 35 | 2 | 274 | .120 | 13.0 | 0.22 | | |
| 1N4996 | 390 | 3 | 1800 | 2500 | 40 | 2 | 297 | .120 | 12.0 | 0.20 | | |

* $I_{ZK} = 5mA$ for 1N5968

5 WATT GLASS ZENER DIODES

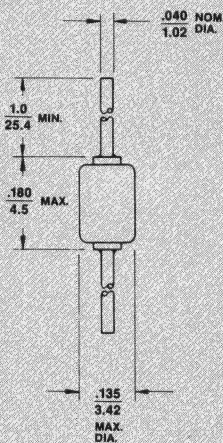


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Silver clad copper or tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N4954 thru 1N4996, 1N5968, 1N5969

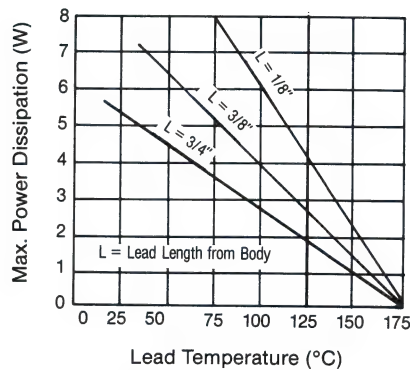


FIGURE 1
POWER DISSIPATION VS. LEAD
TEMPERATURE DERATING CURVE

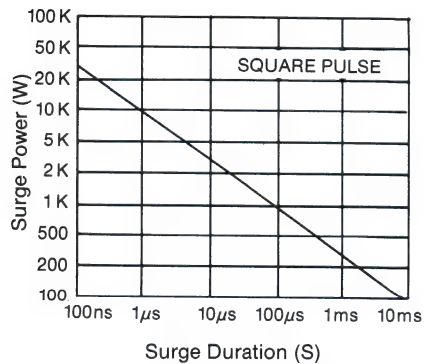


FIGURE 2
SURGE POWER
VS. SURGE DURATION

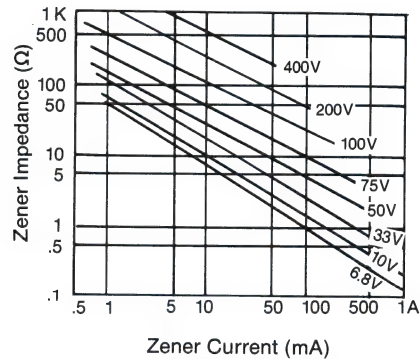


FIGURE 3
TYPICAL ZENER IMPEDANCE
VS. ZENER CURRENT

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

**1N5063 - 1N5117
MZ806 - MZ890,
MZ 210 - MZ 240**

FEATURES

- Microminiature package.
- Voidless hermetically sealed glass package.
- Triple layer passivation.
- Metallurgically bonded.
- High performance characteristics.
- Stable operation at temperatures to 200°C.
- Very low thermal impedance.

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C.

Storage Temperature: -65°C to +200°C.

ELECTRICAL CHARACTERISTICS

| TYPE (Note 1) | | ELECTRICAL SPECIFICATIONS AT 25°C | | | | | | | | MAXIMUM RATINGS | |
|-----------------------|-------------------|---|------------------------------------|------------------------------------|-----------------------|------------------------|---|--|---|---|-------|
| | | NOMINAL ZENER VOLTAGE V _Z @ I _{ZT} | TEST CURRENT I _{ZT} | MAXIMUM REVERSE LEAKAGE CURRENT | | | MAX. ZENER IMPEDANCE Z _Z @ I _{ZT} | TYP. TEMP. COEFFICIENT T _C @ I _{ZT} | MAXIMUM CONTINUOUS CURRENT I _{ZM} | MAXIMUM SURGE CURRENT I _S | |
| | | | | I _R @ V _R | ±5% V _R | ±10% V _R | | | | | |
| | | | | Volts | mA | µA | | | | | Volts |
| Jedec Registration | ±10% Tolerance | Volts | mA | µA | Volts | Volts | Ohms | %/°C | mA | Amps | |
| 1N5063 | MZ806 | 6.8 | 75 | 500 | 5.2 | 4.9 | 2 | .04 | 440 | 10.0 | |
| 1N5064 | MZ807 | 7.5 | 75 | 300 | 5.7 | 5.4 | 2 | .04 | 400 | 8.0 | |
| 1N5065 | MZ808 | 8.2 | 75 | 200 | 6.2 | 5.9 | 3 | .05 | 360 | 7.0 | |
| 1N5066 | MZ809 | 9.1 | 75 | 100 | 6.9 | 6.6 | 3 | .05 | 330 | 6.0 | |
| 1N5067 | MZ810 | 10.0 | 75 | 40 | 7.6 | 7.2 | 4 | .06 | 300 | 5.0 | |
| 1N4883 | MZ812 | 12 | 65 | 10 | 9.1 | 8.6 | 5 | .07 | 250 | 4.0 | |
| 1N5069 | MZ813 | 13 | 50 | 10 | 9.9 | 9.3 | 6 | .07 | 230 | 4.0 | |
| 1N5070 | MZ814 | 14 | 50 | 10 | 10.6 | 10.1 | 6 | .07 | 210 | 4.0 | |
| 1N5071 | MZ815 | 15 | 50 | 10 | 11.4 | 10.8 | 6 | .07 | 200 | 3.0 | |
| 1N5072 | MZ816 | 16 | 50 | 5 | 12.2 | 11.5 | 7 | .07 | 185 | 3.0 | |
| 1N5073 | MZ818 | 18 | 40 | 5 | 13.7 | 12.9 | 8 | .08 | 170 | 2.0 | |
| 1N4884 | MZ820 | 20 | 40 | 5 | 15.2 | 14.4 | 9 | .08 | 150 | 2.0 | |
| 1N5074 | MZ822 | 22 | 30 | 5 | 16.7 | 15.8 | 10 | .08 | 135 | 2.0 | |
| 1N5075 | MZ824 | 24 | 30 | 5 | 18.2 | 17.3 | 10 | .08 | 125 | 1.5 | |
| 1N5076 | MZ827 | 27 | 25 | 1 | 20.6 | 19.4 | 12 | .09 | 110 | 1.5 | |
| 1N5077 | MZ830 | 30 | 25 | 1 | 22.8 | 21.6 | 15 | .090 | 100 | 1.5 | |
| 1N5078 | MZ833 | 33 | 20 | 1 | 25.1 | 23.7 | 21 | .090 | 90 | 1.2 | |
| 1N5079 | MZ836 | 36 | 20 | 1 | 27.4 | 25.9 | 21 | .090 | 85 | 1.0 | |
| 1N5081 | MZ840 | 40 | 20 | 1 | 30.4 | 28.8 | 27 | .095 | 75 | 1.0 | |
| 1N5083 | MZ845 | 45 | 15 | 1 | 34.2 | 32.4 | 37 | .095 | 65 | 0.8 | |
| 1N5085 | MZ850 | 50 | 15 | 1 | 38.0 | 36.0 | 50 | .095 | 60 | 0.8 | |
| 1N5087 | MZ856 | 56 | 10 | 1 | 42.6 | 40.3 | 70 | .095 | 55 | 0.7 | |
| 1N5088 | MZ860 | 60 | 10 | 1 | 45.7 | 43.2 | 70 | .095 | 50 | 0.6 | |
| 1N5091 | MZ870 | 70 | 10 | 1 | 53.3 | 50.5 | 90 | .095 | 45 | 0.6 | |
| 1N5092 | MZ875 | 75 | 10 | 1 | 56.0 | 54.0 | 100 | .095 | 40 | 0.5 | |
| 1N5093 | MZ880 | 80 | 10 | 1 | 60.8 | 57.7 | 115 | .095 | 35 | 0.4 | |
| 1N4096 | MZ890 | 90 | 8.0 | 1 | 68.5 | 64.8 | 150 | .095 | 30 | 0.4 | |
| 1N4097 | MZ210 | 100 | 5.0 | 1 | 76.0 | 72.0 | 175 | .100 | 30 | 0.4 | |
| 1N5096 | MZ211 | 110 | 5.0 | 1 | 83.6 | 79.2 | 250 | .100 | 25 | 0.3 | |
| 1N5097 | MZ212 | 120 | 5.0 | 1 | 91.2 | 86.4 | 325 | .100 | 25 | 0.2 | |
| 1N5098 | MZ213 | 130 | 5.0 | 1 | 98.8 | 93.6 | 375 | .100 | 20 | 0.20 | |
| 1N5099 | MZ214 | 140 | 5.0 | 1 | 106 | 101 | 550 | .100 | 20 | 0.20 | |
| 1N4098 | MZ215 | 150 | 5.0 | 1 | 114 | 108 | 650 | .100 | 20 | 0.20 | |
| 1N5100 | MZ216 | 160 | 4.0 | 1 | 122 | 115 | 700 | .100 | 20 | 0.15 | |
| 1N5101 | MZ217 | 170 | 4.0 | 1 | 129 | 122 | 750 | .100 | 18 | 0.15 | |
| 1N5102 | MZ218 | 180 | 4.0 | 1 | 137 | 129 | 850 | .100 | 18 | 0.10 | |
| 1N5103 | MZ219 | 190 | 4.0 | 1 | 144 | 137 | 900 | .100 | 15 | 0.10 | |
| 1N5104 | MZ220 | 200 | 4.0 | 1 | 152 | 144 | 950 | .100 | 15 | 0.10 | |
| 1N5105 | MZ222 | 220 | 3.0 | 1 | 167 | 158 | 1100 | .100 | 15 | 0.09 | |
| 1N5106 | MZ224 | 240 | 3.0 | 1 | 182 | 173 | 1300 | .105 | 12 | 0.09 | |
| 1N5107 | MZ226 | 260 | 3.0 | 1 | 198 | 187 | 1500 | .105 | 12 | 0.08 | |
| 1N5109 | MZ228 | 280 | 3.0 | 1 | 213 | 202 | 1700 | .105 | 10 | 0.08 | |
| 1N5110 | MZ230 | 300 | 3.0 | 1 | 228 | 216 | 1900 | .105 | 10 | 0.07 | |
| 1N5111 | MZ232 | 320 | 2.0 | 1 | 243 | 230 | 2100 | .105 | 9 | 0.07 | |
| 1N5113 | MZ234 | 340 | 2.0 | 1 | 258 | 245 | 2400 | .110 | 9 | 0.06 | |
| 1N5114 | MZ236 | 360 | 2.0 | 1 | 274 | 259 | 2700 | .110 | 8 | 0.06 | |
| 1N5115 | MZ238 | 380 | 2.0 | 1 | 289 | 274 | 3000 | .110 | 8 | 0.06 | |
| 1N5117 | MZ240 | 400 | 2.0 | 1 | 304 | 288 | 3500 | .110 | 7 | 0.06 | |

NOTE 1: JEDEC registration applies to ± 5% tolerance zeners only.
Specify 5% voltage tolerance by changing first numeral of type number from 8 to 7.
(MZ806 becomes 706) or from 2 to 1 (MZ211 becomes MZ111).

3-WATT GLASS ZENER DIODES

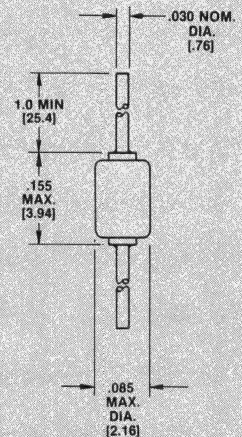


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric with JEDEC number.

POLARITY: Cathode band.

1N5063 - 1N5117, MZ806 - MZ890, MZ 210 - MZ 240

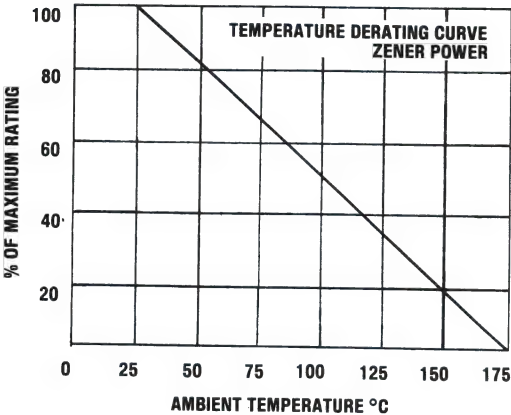


FIGURE 2

EXPLANATION OF ZENER CHARACTERISTICS

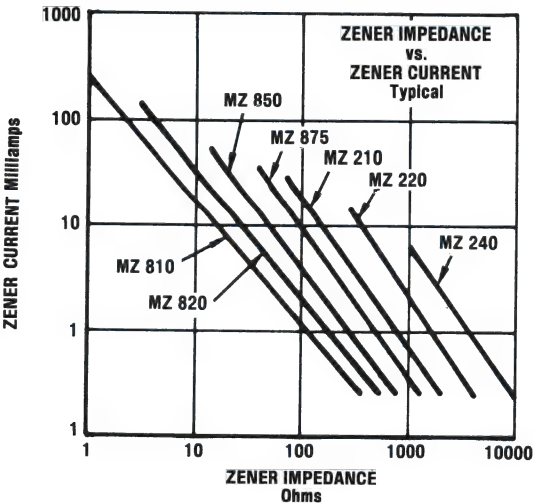


FIGURE 3

1N5221 thru 1N5281 DO-7

FEATURES

- 2.4 THRU 200 VOLTS
- COMPACT PACKAGE

MAXIMUM RATINGS

Operating and Storage Temperature: -65°C to $+200^{\circ}\text{C}$
DC Power Dissipation: 500 mW
Power Derating: 4.0 mW/ $^{\circ}\text{C}$ above 75°C
Forward Voltage @ 200 mA: 1.1 Volts

ELECTRICAL CHARACTERISTICS

See following page for table of parameter values. (Fig. 3)

Table as shown on following page (Fig. 3) lists JEDEC type numbers, which indicate a tolerance of $\pm 20\%$ with guaranteed limits on only V_Z , I_r , and V_f . Devices with guaranteed limits on all six parameters are indicated by suffix A for $\pm 10\%$ tolerance and suffix B for $\pm 5\%$ tolerance. Also available with suffix C or D which indicates 2% and 1% tolerance respectively.

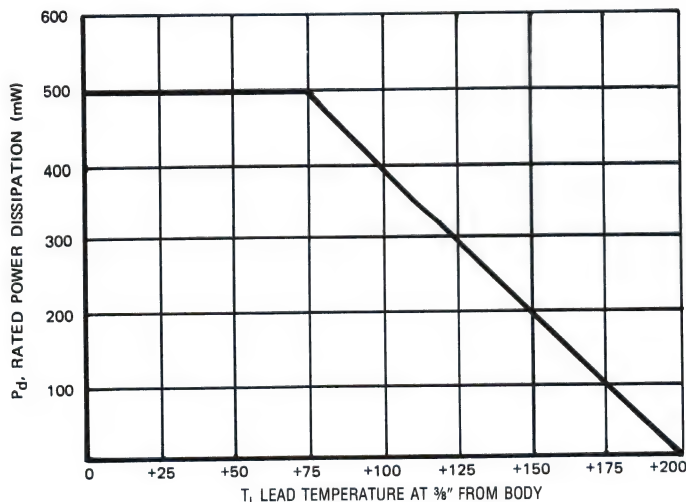


FIGURE 2
POWER DERATING CURVE

SILICON 500 mW ZENER DIODES

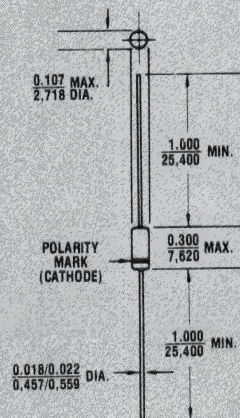


FIGURE 1
All dimensions in INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $300^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

1N5221 thru 1N5281 DO-7

*ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC Type No. Note 1 | Nominal Zener Voltage V _Z @ I _{ZT} Volts | Test Current I _{ZT} mA | Max Zener Impedance A & B Suffix Only Note 2 | | Max Reverse Leakage Current | | | | Max Zener Voltage Temp. Coeff. (A & B Suffix Only) α _{VZ} (%/°C) Note 3 |
|-----------------------------|---|--|--|---|-----------------------------|------------------------------|--|-----|--|
| | | | | | A, B, C & D Suffix Only | | Non-Suffix | | |
| | | | Z _{KT} @ I _{ZT} Ohms | Z _{ZK} @ I _{ZK} = 0.25 mA Ohms | I _R μA | @ V _R Volts | I _R @ V _R Used For Suffix A μA | | |
| | | | | | | A | B, C & D | | |
| 1N5221 | 2.4 | 20 | 30 | 1200 | 100 | 0.95 | 1.0 | 200 | −0.085 |
| 1N5222 | 2.5 | 20 | 30 | 1250 | 100 | 0.95 | 1.0 | 200 | −0.085 |
| 1N5223 | 2.7 | 20 | 30 | 1300 | 75 | 0.95 | 1.0 | 150 | −0.080 |
| 1N5224 | 2.8 | 20 | 30 | 1400 | 75 | 0.95 | 1.0 | 150 | −0.080 |
| 1N5225 | 3.0 | 20 | 29 | 1600 | 50 | 0.95 | 1.0 | 100 | −0.075 |
| 1N5226 | 3.3 | 20 | 28 | 1600 | 25 | 0.95 | 1.0 | 100 | −0.070 |
| 1N5227 | 3.6 | 20 | 24 | 1700 | 15 | 0.95 | 1.0 | 100 | −0.065 |
| 1N5228 | 3.9 | 20 | 23 | 1900 | 10 | 0.95 | 1.0 | 75 | −0.060 |
| 1N5229 | 4.3 | 20 | 22 | 2000 | 5.0 | 0.95 | 1.0 | 50 | ±0.055 |
| 1N5230 | 4.7 | 20 | 19 | 1900 | 5.0 | 1.9 | 2.0 | 50 | ±0.030 |
| 1N5231 | 5.1 | 20 | 17 | 1600 | 5.0 | 1.9 | 2.0 | 50 | ±0.030 |
| 1N5232 | 5.6 | 20 | 11 | 1600 | 5.0 | 2.9 | 3.0 | 50 | +0.038 |
| 1N5233 | 6.0 | 20 | 7.0 | 1600 | 5.0 | 3.3 | 3.5 | 50 | +0.038 |
| 1N5234 | 6.2 | 20 | 7.0 | 1000 | 5.0 | 3.8 | 4.0 | 50 | +0.045 |
| 1N5235 | 6.8 | 20 | 5.0 | 750 | 3.0 | 4.8 | 5.0 | 30 | +0.050 |
| 1N5236 | 7.5 | 20 | 6.0 | 500 | 3.0 | 5.7 | 6.0 | 30 | +0.058 |
| 1N5237 | 8.2 | 20 | 8.0 | 500 | 3.0 | 6.2 | 6.5 | 30 | +0.062 |
| 1N5238 | 8.7 | 20 | 8.0 | 600 | 3.0 | 6.2 | 6.5 | 30 | +0.065 |
| 1N5239 | 9.1 | 20 | 10 | 600 | 3.0 | 6.7 | 7.0 | 30 | +0.068 |
| 1N5240 | 10 | 20 | 17 | 600 | 3.0 | 7.6 | 8.0 | 30 | +0.075 |
| 1N5241 | 11 | 20 | 22 | 600 | 2.0 | 8.0 | 8.4 | 30 | +0.076 |
| 1N5242 | 12 | 20 | 30 | 600 | 1.0 | 8.7 | 9.1 | 10 | +0.077 |
| 1N5243 | 13 | 9.5 | 13 | 600 | 0.5 | 9.4 | 9.9 | 10 | +0.079 |
| 1N5244 | 14 | 9.0 | 15 | 600 | 0.1 | 9.5 | 10 | 10 | +0.082 |
| 1N5245 | 15 | 8.5 | 16 | 600 | 0.1 | 10.5 | 11 | 10 | +0.082 |
| 1N5246 | 16 | 7.8 | 17 | 600 | 0.1 | 11.4 | 12 | 10 | +0.083 |
| 1N5247 | 17 | 7.4 | 19 | 600 | 0.1 | 12.4 | 13 | 10 | +0.084 |
| 1N5248 | 18 | 7.0 | 21 | 600 | 0.1 | 13.3 | 14 | 10 | +0.085 |
| 1N5249 | 19 | 6.6 | 23 | 600 | 0.1 | 13.3 | 14 | 10 | +0.086 |
| 1N5250 | 20 | 6.2 | 25 | 600 | 0.1 | 14.3 | 15 | 10 | +0.086 |
| 1N5251 | 22 | 5.6 | 29 | 600 | 0.1 | 16.2 | 17 | 10 | +0.087 |
| 1N5252 | 24 | 5.2 | 33 | 600 | 0.1 | 17.1 | 18 | 10 | +0.088 |
| 1N5253 | 25 | 5.0 | 35 | 600 | 0.1 | 18.1 | 19 | 10 | +0.089 |
| 1N5254 | 27 | 4.6 | 41 | 600 | 0.1 | 20 | 21 | 10 | +0.090 |
| 1N5255 | 28 | 4.5 | 44 | 600 | 0.1 | 20 | 21 | 10 | +0.091 |
| 1N5256 | 30 | 4.2 | 49 | 600 | 0.1 | 22 | 23 | 10 | +0.091 |
| 1N5257 | 33 | 3.8 | 58 | 700 | 0.1 | 24 | 25 | 10 | +0.092 |
| 1N5258 | 36 | 3.4 | 70 | 700 | 0.1 | 26 | 27 | 10 | +0.093 |
| 1N5259 | 39 | 3.2 | 80 | 800 | 0.1 | 29 | 30 | 10 | +0.094 |
| 1N5260 | 43 | 3.0 | 93 | 900 | 0.1 | 31 | 33 | 10 | +0.095 |
| 1N5261 | 47 | 2.7 | 105 | 1000 | 0.1 | 34 | 36 | 10 | +0.095 |
| 1N5262 | 51 | 2.5 | 125 | 1100 | 0.1 | 37 | 39 | 10 | +0.096 |
| 1N5263 | 56 | 2.2 | 150 | 1300 | 0.1 | 41 | 43 | 10 | +0.096 |
| 1N5264 | 60 | 2.1 | 170 | 1400 | 0.1 | 44 | 46 | 10 | +0.097 |
| 1N5265 | 62 | 2.0 | 185 | 1400 | 0.1 | 45 | 47 | 10 | +0.097 |
| 1N5266 | 68 | 1.8 | 230 | 1600 | 0.1 | 49 | 52 | 10 | +0.097 |
| 1N5267 | 75 | 1.7 | 270 | 1700 | 0.1 | 53 | 56 | 10 | +0.098 |
| 1N5268 | 82 | 1.5 | 330 | 2000 | 0.1 | 59 | 62 | 10 | +0.098 |
| 1N5269 | 87 | 1.4 | 370 | 2200 | 0.1 | 65 | 68 | 10 | +0.099 |
| 1N5270 | 91 | 1.4 | 400 | 2300 | 0.1 | 66 | 69 | 10 | +0.099 |
| 1N5271 | 100 | 1.3 | 500 | 2600 | 0.1 | 72 | 76 | 10 | +0.110 |
| 1N5272 | 110 | 1.1 | 750 | 3000 | 0.1 | 80 | 84 | 10 | +0.110 |
| 1N5273 | 120 | 1.0 | 900 | 4000 | 0.1 | 86 | 91 | 10 | +0.110 |
| 1N5274 | 130 | 0.95 | 1100 | 4500 | 0.1 | 94 | 99 | 10 | +0.110 |
| 1N5275 | 140 | 0.90 | 1300 | 4500 | 0.1 | 101 | 106 | 10 | +0.110 |
| 1N5276 | 150 | 0.85 | 1500 | 5000 | 0.1 | 108 | 114 | 10 | +0.110 |
| 1N5277 | 160 | 0.80 | 1700 | 5500 | 0.1 | 116 | 122 | 10 | +0.110 |
| 1N5278 | 170 | 0.74 | 1900 | 5500 | 0.1 | 123 | 129 | 10 | +0.110 |
| 1N5279 | 180 | 0.68 | 2200 | 6000 | 0.1 | 130 | 137 | 10 | +0.110 |
| 1N5280 | 190 | 0.66 | 2400 | 6500 | 0.1 | 137 | 144 | 10 | +0.110 |
| 1N5281 | 200 | 0.65 | 2500 | 7000 | 0.1 | 144 | 152 | 10 | +0.110 |

*JEDEC registered data

FIGURE 3

NOTE 1 The electrical characteristics are measured after allowing the device to stabilize for 20 seconds when mounted with a $\frac{1}{16}$ " minimum lead length from the case.

NOTE 2 The zener impedance is derived from the 60 HZ ac voltage, which results when an ac current having an r.m.s. value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at two points to insure a sharp knee on the breakdown curve, thereby eliminating unstable units.

NOTE 3 Temperature coefficient (α_{VZ}).

Test conditions for temperature coefficient are as follows:

- $I_{ZT} = 7.5$ mA, $T_1 = 25^\circ\text{C}$,
 $T_2 = 125^\circ\text{C}$ (1N5221A, B thru 1N5242A, B.)
- $I_{ZT} = \text{Rated } I_{ZT}$, $T_1 = 25^\circ\text{C}$,
 $T_2 = 125^\circ\text{C}$ (1N5243A, B thru 1N5281A, B.)

Device to be temperature stabilized with current applied prior to reading breakdown voltage at the specified ambient temperature.

1N5221 thru 1N5281 DO-7

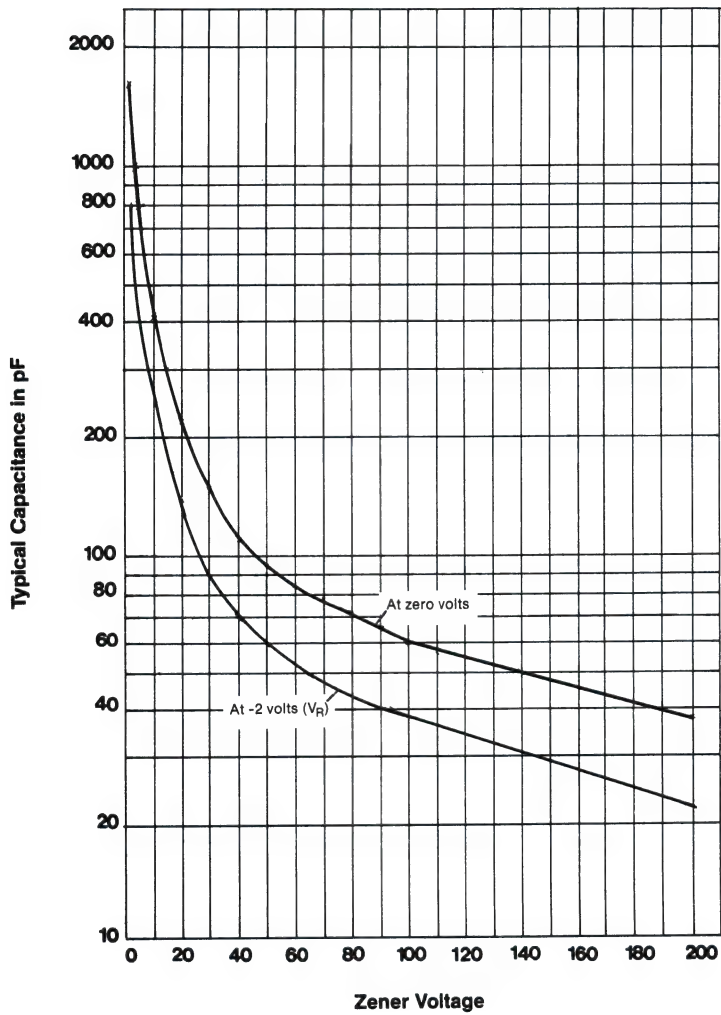


FIGURE 4
CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)

1N5221 thru 1N5281 DO-35

FEATURES

- 2.4 THRU 200 VOLTS
- COMPACT PACKAGE
- CONSULT FACTORY FOR VOLTAGES ABOVE 200 V

MAXIMUM RATINGS

Operating and Storage Temperature: -65°C to $+200^{\circ}\text{C}$
DC Power Dissipation: 500 mW
Power Derating: 4.0 mW/ $^{\circ}\text{C}$ above 75°C
Forward Voltage @ 200 mA: 1.1 Volts

ELECTRICAL CHARACTERISTICS

See following page for table of parameter values. (Fig. 3)

Table as shown on following page (Fig. 3) lists JEDEC type numbers, which indicate a tolerance of $\pm 20\%$ with guaranteed limits on only V_Z , I_r , and V_f . Devices with guaranteed limits on all six parameters are indicated by suffix A for $\pm 10\%$ tolerance and suffix B for $\pm 5\%$ tolerance. Also available with suffix C or D which indicates 2% and 1% tolerance respectively.

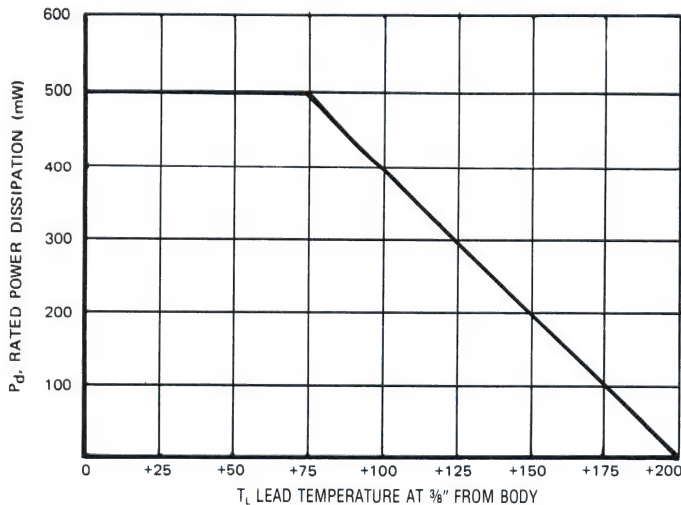


FIGURE 2
POWER DERATING CURVE

SILICON 500 mW ZENER DIODES

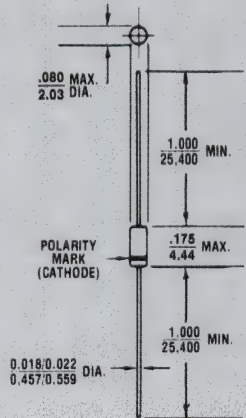


FIGURE 1
All dimensions in $\frac{\text{INCH}}{\text{m.m.}}$

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $150^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

1N5221 thru 1N5281 DO-35

*ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC Type No. Note 1 | Nominal Zener Voltage V _Z @ I _{ZT} Volts | Test Current I _{ZT} mA | Max Zener Impedance A & B Suffix Only Note 2 | | Max Reverse Leakage Current | | | | Max Zener Voltage Temp. Coeff. (A & B Suffix Only) α _{VZ} (% / °C) Note 3 |
|-----------------------------|---|--|--|---|-----------------------------|------------------------------|-----|------------|--|
| | | | | | A, B, C & D Suffix Only | | | Non-Suffix | |
| | | | Z _{ZT} @ I _{ZT} Ohms | Z _{ZK} @ I _{ZK} = 0.25 mA Ohms | I _R μA | @ V _R Volts | A | B, C & D | |
| 1N5221 | 2.4 | 20 | 30 | 1200 | 100 | 0.95 | 1.0 | 200 | -0.085 |
| 1N5222 | 2.5 | 20 | 30 | 1250 | 100 | 0.95 | 1.0 | 200 | -0.085 |
| 1N5223 | 2.7 | 20 | 30 | 1300 | 75 | 0.95 | 1.0 | 150 | -0.080 |
| 1N5224 | 2.8 | 20 | 30 | 1400 | 75 | 0.95 | 1.0 | 150 | -0.080 |
| 1N5225 | 3.0 | 20 | 29 | 1600 | 50 | 0.95 | 1.0 | 100 | -0.075 |
| 1N5226 | 3.3 | 20 | 28 | 1600 | 25 | 0.95 | 1.0 | 100 | -0.070 |
| 1N5227 | 3.6 | 20 | 24 | 1700 | 15 | 0.95 | 1.0 | 100 | -0.065 |
| 1N5228 | 3.9 | 20 | 23 | 1900 | 10 | 0.95 | 1.0 | 75 | -0.060 |
| 1N5229 | 4.3 | 20 | 22 | 2000 | 5.0 | 0.95 | 1.0 | 50 | ±0.055 |
| 1N5230 | 4.7 | 20 | 19 | 1900 | 5.0 | 1.9 | 2.0 | 50 | ±0.030 |
| 1N5231 | 5.1 | 20 | 17 | 1600 | 5.0 | 1.9 | 2.0 | 50 | ±0.030 |
| 1N5232 | 5.6 | 20 | 11 | 1600 | 5.0 | 2.9 | 3.0 | 50 | ±0.038 |
| 1N5233 | 6.0 | 20 | 7.0 | 1600 | 5.0 | 3.3 | 3.5 | 50 | ±0.038 |
| 1N5234 | 6.2 | 20 | 7.0 | 1000 | 5.0 | 3.8 | 4.0 | 50 | ±0.045 |
| 1N5235 | 6.8 | 20 | 5.0 | 750 | 3.0 | 4.8 | 5.0 | 30 | ±0.050 |
| 1N5236 | 7.5 | 20 | 6.0 | 500 | 3.0 | 5.7 | 6.0 | 30 | ±0.058 |
| 1N5237 | 8.2 | 20 | 8.0 | 500 | 3.0 | 6.2 | 6.5 | 30 | ±0.062 |
| 1N5238 | 8.7 | 20 | 8.0 | 600 | 3.0 | 6.2 | 6.5 | 30 | ±0.065 |
| 1N5239 | 9.1 | 20 | 10 | 600 | 3.0 | 6.7 | 7.0 | 30 | ±0.068 |
| 1N5240 | 10 | 20 | 17 | 600 | 3.0 | 7.6 | 8.0 | 30 | ±0.075 |
| 1N5241 | 11 | 20 | 22 | 600 | 2.0 | 8.0 | 8.4 | 30 | ±0.076 |
| 1N5242 | 12 | 20 | 30 | 600 | 1.0 | 8.7 | 9.1 | 10 | ±0.077 |
| 1N5243 | 13 | 9.5 | 13 | 600 | 0.5 | 9.4 | 9.9 | 10 | ±0.079 |
| 1N5244 | 14 | 9.0 | 15 | 600 | 0.1 | 9.5 | 10 | 10 | ±0.082 |
| 1N5245 | 15 | 8.5 | 16 | 600 | 0.1 | 10.5 | 11 | 10 | ±0.082 |
| 1N5246 | 16 | 7.8 | 17 | 600 | 0.1 | 11.4 | 12 | 10 | ±0.083 |
| 1N5247 | 17 | 7.4 | 19 | 600 | 0.1 | 12.4 | 13 | 10 | ±0.084 |
| 1N5248 | 18 | 7.0 | 21 | 600 | 0.1 | 13.3 | 14 | 10 | ±0.085 |
| 1N5249 | 19 | 6.6 | 23 | 600 | 0.1 | 13.3 | 14 | 10 | ±0.086 |
| 1N5250 | 20 | 6.2 | 25 | 600 | 0.1 | 14.3 | 15 | 10 | ±0.086 |
| 1N5251 | 22 | 5.6 | 29 | 600 | 0.1 | 16.2 | 17 | 10 | ±0.087 |
| 1N5252 | 24 | 5.2 | 33 | 600 | 0.1 | 17.1 | 18 | 10 | ±0.088 |
| 1N5253 | 25 | 5.0 | 35 | 600 | 0.1 | 18.1 | 19 | 10 | ±0.089 |
| 1N5254 | 27 | 4.6 | 41 | 600 | 0.1 | 20 | 21 | 10 | ±0.090 |
| 1N5255 | 28 | 4.5 | 44 | 600 | 0.1 | 20 | 21 | 10 | ±0.091 |
| 1N5256 | 30 | 4.2 | 49 | 600 | 0.1 | 22 | 23 | 10 | ±0.091 |
| 1N5257 | 33 | 3.8 | 58 | 700 | 0.1 | 24 | 25 | 10 | ±0.092 |
| 1N5258 | 36 | 3.4 | 70 | 700 | 0.1 | 26 | 27 | 10 | ±0.093 |
| 1N5259 | 39 | 3.2 | 80 | 800 | 0.1 | 29 | 30 | 10 | ±0.094 |
| 1N5260 | 43 | 3.0 | 93 | 900 | 0.1 | 31 | 33 | 10 | ±0.095 |
| 1N5261 | 47 | 2.7 | 105 | 1000 | 0.1 | 34 | 36 | 10 | ±0.095 |
| 1N5262 | 51 | 2.5 | 125 | 1100 | 0.1 | 37 | 39 | 10 | ±0.096 |
| 1N5263 | 56 | 2.2 | 150 | 1300 | 0.1 | 41 | 43 | 10 | ±0.096 |
| 1N5264 | 60 | 2.1 | 170 | 1400 | 0.1 | 44 | 46 | 10 | ±0.097 |
| 1N5265 | 62 | 2.0 | 185 | 1400 | 0.1 | 45 | 47 | 10 | ±0.097 |
| 1N5266 | 68 | 1.8 | 230 | 1600 | 0.1 | 49 | 52 | 10 | ±0.097 |
| 1N5267 | 75 | 1.7 | 270 | 1700 | 0.1 | 53 | 56 | 10 | ±0.098 |
| 1N5268 | 82 | 1.5 | 330 | 2000 | 0.1 | 59 | 62 | 10 | ±0.098 |
| 1N5269 | 87 | 1.4 | 370 | 2200 | 0.1 | 65 | 68 | 10 | ±0.099 |
| 1N5270 | 91 | 1.4 | 400 | 2300 | 0.1 | 66 | 69 | 10 | ±0.099 |
| 1N5271 | 100 | 1.3 | 500 | 2600 | 0.1 | 72 | 76 | 10 | ±0.110 |
| 1N5272 | 110 | 1.1 | 750 | 3000 | 0.1 | 80 | 84 | 10 | ±0.110 |
| 1N5273 | 120 | 1.0 | 900 | 4000 | 0.1 | 86 | 91 | 10 | ±0.110 |
| 1N5274 | 130 | 0.95 | 1100 | 4500 | 0.1 | 94 | 99 | 10 | ±0.110 |
| 1N5275 | 140 | 0.90 | 1300 | 4500 | 0.1 | 101 | 106 | 10 | ±0.110 |
| 1N5276 | 150 | 0.85 | 1500 | 5000 | 0.1 | 108 | 114 | 10 | ±0.110 |
| 1N5277 | 160 | 0.80 | 1700 | 5500 | 0.1 | 116 | 122 | 10 | ±0.110 |
| 1N5278 | 170 | 0.74 | 1900 | 5500 | 0.1 | 123 | 129 | 10 | ±0.110 |
| 1N5279 | 180 | 0.68 | 2200 | 6000 | 0.1 | 130 | 137 | 10 | ±0.110 |
| 1N5280 | 190 | 0.66 | 2400 | 6500 | 0.1 | 137 | 144 | 10 | ±0.110 |
| 1N5281 | 200 | 0.65 | 2500 | 7000 | 0.1 | 144 | 152 | 10 | ±0.110 |

*JEDEC registered data

FIGURE 3

NOTE 1 The electrical characteristics are measured after allowing the device to stabilize for 20 seconds when mounted with a $\frac{3}{8}$ " minimum lead length from the case.

NOTE 2 The zener impedance is derived from the 60 HZ ac voltage, which results when an ac current having an r.m.s. value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at two points to insure a sharp knee on the breakdown curve, thereby, eliminating unstable units.

NOTE 3 Temperature coefficient (α_{VZ}).

Test conditions for temperature coefficient are as follows:

- $I_{ZT} = 7.5$ mA, $T_1 = 25^\circ\text{C}$,
 $T_2 = 125^\circ\text{C}$ (1N5221A, B thru 1N5242A, B.)
- $I_{ZT} = \text{Rated } I_{ZT}$, $T_1 = 25^\circ\text{C}$,
 $T_2 = 125^\circ\text{C}$ (1N5243A, B thru 1N5281A, B.)

Device to be temperature stabilized with current applied prior to reading breakdown voltage at the specified ambient temperature.

1N5221 thru 1N5281 DO-35

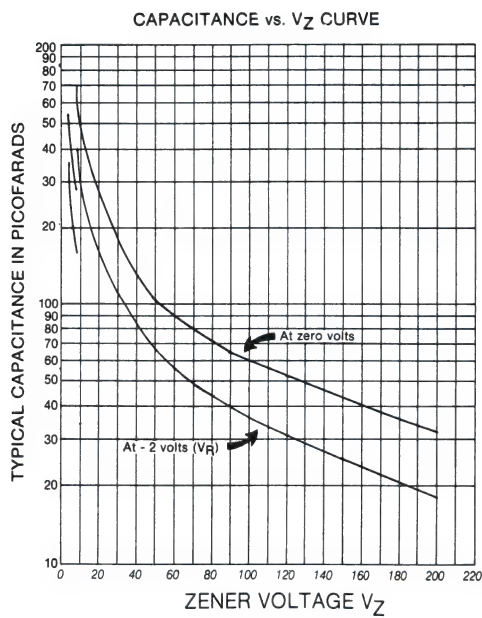


FIGURE 4
CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)

1N5333B thru 1N5388B

FEATURES

- ZENER VOLTAGE 3.3V to 200V
- HIGH SURGE CURRENT CAPABILITY
- FOR AVAILABLE TOLERANCES — SEE NOTE 1

MAXIMUM RATINGS

Operating Temperature: -65°C to +200°C

DC Power Dissipation: 5 Watts

Power Derating: 40 mW/°C above 75°C

Forward Voltage @ 1.0 A: 1.2 Volts

* ELECTRICAL CHARACTERISTICS @ 25°C

| TYPE NUMBER | REGULATOR VOLTAGE (V) V | TEST CURRENT (I) mA dc | MAXIMUM DYNAMIC IMPEDANCE (Z ₀₁) (A & B Suffix) OHMS | MAXIMUM REVERSE CURRENT (I _R) (A Suffix) μA | I ₁ TEST VOLTAGE (V ₁) (Non-Suffix & A Suffix) V | I ₂ TEST VOLTAGE (V ₂) (B, C, D Suffix) V | MAXIMUM REGULATOR CURRENT (I _{RM}) (B, C, D Suffix) mA | MAXIMUM DYNAMIC KNEE IMPEDANCE (Z ₀₁ at 1.0 mA (A, B, C, D Suffix) OHMS | MAXIMUM SURGE CURRENT (I _{2SM}) AMPS | MAXIMUM VOLTAGE REGULATION (ΔV ₁) (A, B, C, D Suffix) VOLTS |
|-------------|----------------------------|---------------------------|---|--|--|---|---|---|---|--|
| 1N5333B | 3.3 | 380 | 3.0 | 300 | 1.0 | 1.0 | 1440 | 400 | 20 | 0.85 |
| 1N5334B | 3.6 | 350 | 2.5 | 150 | 1.0 | 1.0 | 1320 | 500 | 18.7 | 0.80 |
| 1N5335B | 3.9 | 320 | 2.0 | 50 | 1.0 | 1.0 | 1220 | 500 | 17.6 | 0.54 |
| 1N5336B | 4.3 | 290 | 2.0 | 10 | 1.0 | 1.0 | 1100 | 500 | 16.4 | 0.49 |
| 1N5337B | 4.7 | 250 | 2.0 | 5.0 | 1.0 | 1.0 | 1010 | 450 | 15.3 | 0.44 |
| 1N5338B | 5.1 | 240 | 1.5 | 1.0 | 1.0 | 1.0 | 930 | 400 | 14.4 | 0.39 |
| 1N5339B | 5.6 | 220 | 1.0 | 1.0 | 2.0 | 2.0 | 865 | 400 | 13.4 | 0.25 |
| 1N5340B | 6.0 | 200 | 1.0 | 1.0 | 3.0 | 3.0 | 790 | 300 | 12.7 | 0.19 |
| 1N5341B | 6.2 | 200 | 1.0 | 1.0 | 3.0 | 3.0 | 765 | 200 | 12.4 | 0.10 |
| 1N5342B | 6.8 | 175 | 1.0 | 10 | 4.9 | 5.2 | 700 | 200 | 11.5 | 0.15 |
| 1N5343B | 7.5 | 175 | 1.5 | 10 | 5.4 | 5.7 | 630 | 200 | 10.7 | 0.15 |
| 1N5344B | 8.2 | 150 | 1.5 | 10 | 5.9 | 6.2 | 580 | 200 | 10 | 0.20 |
| 1N5345B | 8.7 | 150 | 2.0 | 10 | 6.6 | 6.6 | 545 | 200 | 9.5 | 0.20 |
| 1N5346B | 9.1 | 150 | 2.0 | 7.5 | 6.6 | 6.9 | 520 | 150 | 9.2 | 0.22 |
| 1N5347B | 10 | 125 | 2.0 | 5.0 | 7.2 | 7.6 | 475 | 125 | 8.6 | 0.22 |
| 1N5348B | 11 | 125 | 2.5 | 5.0 | 8.0 | 8.4 | 430 | 125 | 8.0 | 0.25 |
| 1N5349B | 12 | 100 | 2.5 | 2.0 | 8.6 | 9.1 | 395 | 125 | 7.5 | 0.25 |
| 1N5350B | 13 | 100 | 2.5 | 1.0 | 9.4 | 9.9 | 365 | 100 | 7.0 | 0.25 |
| 1N5351B | 14 | 100 | 2.5 | 1.0 | 10.1 | 10.6 | 340 | 75 | 6.7 | 0.25 |
| 1N5352B | 15 | 75 | 2.5 | 1.0 | 10.8 | 11.5 | 315 | 75 | 6.3 | 0.25 |
| 1N5353B | 16 | 75 | 2.5 | 1.0 | 11.5 | 12.2 | 295 | 75 | 6.0 | 0.30 |
| 1N5354B | 17 | 70 | 2.5 | 0.5 | 12.2 | 12.9 | 280 | 75 | 5.8 | 0.35 |
| 1N5355B | 18 | 65 | 2.5 | 0.5 | 13 | 13.7 | 264 | 75 | 5.5 | 0.40 |
| 1N5356B | 19 | 65 | 3.0 | 0.5 | 13.7 | 14.4 | 250 | 75 | 5.3 | 0.40 |
| 1N5357B | 20 | 65 | 3.0 | 0.5 | 14.4 | 15.2 | 237 | 75 | 5.1 | 0.40 |
| 1N5358B | 22 | 50 | 3.5 | 0.5 | 15.8 | 16.7 | 216 | 75 | 4.7 | 0.45 |
| 1N5359B | 24 | 50 | 3.5 | 0.5 | 17.3 | 18.2 | 198 | 100 | 4.4 | 0.55 |
| 1N5360B | 25 | 50 | 4.0 | 0.5 | 18 | 19 | 190 | 110 | 4.3 | 0.55 |
| 1N5361B | 27 | 50 | 5.0 | 0.5 | 19.4 | 20.6 | 176 | 120 | 4.1 | 0.60 |
| 1N5362B | 28 | 50 | 6.0 | 0.5 | 20.1 | 21.2 | 170 | 130 | 3.9 | 0.60 |
| 1N5363B | 30 | 40 | 8.0 | 0.5 | 21.6 | 22.8 | 158 | 140 | 3.7 | 0.60 |
| 1N5364B | 33 | 40 | 10 | 0.5 | 23.8 | 25.1 | 144 | 150 | 3.5 | 0.65 |
| 1N5365B | 36 | 30 | 11 | 0.5 | 25.9 | 27.4 | 132 | 160 | 3.3 | 0.65 |
| 1N5366B | 39 | 30 | 14 | 0.5 | 28.1 | 29.7 | 122 | 170 | 3.1 | 0.70 |
| 1N5367B | 43 | 30 | 20 | 0.5 | 31 | 32.7 | 110 | 190 | 2.8 | 0.70 |
| 1N5368B | 47 | 25 | 25 | 0.5 | 33.8 | 35.8 | 100 | 210 | 2.7 | 0.80 |
| 1N5369B | 51 | 25 | 27 | 0.5 | 36.7 | 38.8 | 93 | 230 | 2.5 | 0.90 |
| 1N5370B | 56 | 20 | 35 | 0.5 | 40.3 | 42.6 | 86 | 280 | 2.3 | 1.00 |
| 1N5371B | 60 | 20 | 40 | 0.5 | 43 | 45.5 | 79 | 350 | 2.2 | 1.20 |
| 1N5372B | 62 | 20 | 42 | 0.5 | 44.6 | 47.1 | 76 | 400 | 2.1 | 1.35 |
| 1N5373B | 68 | 20 | 44 | 0.5 | 49 | 51.7 | 70 | 500 | 2.0 | 1.50 |
| 1N5374B | 75 | 20 | 45 | 0.5 | 54 | 56 | 63 | 620 | 1.9 | 1.60 |
| 1N5375B | 82 | 15 | 65 | 0.5 | 59 | 62.2 | 58 | 720 | 1.8 | 1.80 |
| 1N5376B | 87 | 15 | 75 | 0.5 | 63 | 66 | 54.5 | 760 | 1.7 | 2.00 |
| 1N5377B | 91 | 15 | 75 | 0.5 | 65.5 | 69.2 | 52.5 | 760 | 1.6 | 2.20 |
| 1N5378B | 100 | 12 | 90 | 0.5 | 72 | 76 | 47.5 | 800 | 1.5 | 2.30 |
| 1N5379B | 110 | 12 | 125 | 0.5 | 79.2 | 83.6 | 43 | 1000 | 1.4 | 2.50 |
| 1N5380B | 120 | 10 | 170 | 0.5 | 86.4 | 91.2 | 39.5 | 1150 | 1.3 | 2.50 |
| 1N5381B | 130 | 10 | 190 | 0.5 | 93.6 | 98.8 | 36.6 | 1250 | 1.2 | 2.50 |
| 1N5382B | 140 | 8.0 | 230 | 0.5 | 101 | 106 | 34 | 1500 | 1.2 | 2.50 |
| 1N5383B | 150 | 8.0 | 330 | 0.5 | 108 | 114 | 31.6 | 1500 | 1.1 | 3.00 |
| 1N5384B | 160 | 8.0 | 350 | 0.5 | 115 | 122 | 29.4 | 1650 | 1.1 | 3.00 |
| 1N5385B | 170 | 8.0 | 380 | 0.5 | 122 | 129 | 28 | 1750 | 1.0 | 4.00 |
| 1N5386B | 180 | 5.0 | 430 | 0.5 | 130 | 137 | 26.4 | 1750 | 1.0 | 4.00 |
| 1N5387B | 190 | 5.0 | 450 | 0.5 | 137 | 144 | 25 | 1850 | 0.9 | 5.00 |
| 1N5388B | 200 | 5.0 | 480 | 0.5 | 144 | 152 | 23.6 | 1850 | 0.9 | 5.00 |

* JEDEC Registered Data.

SILICON 5 WATT ZENER DIODES

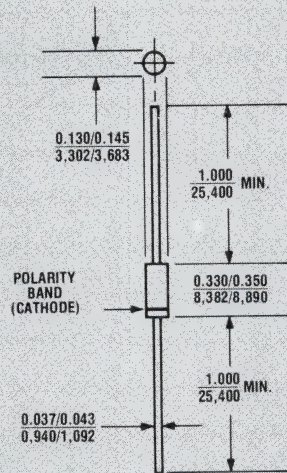


FIGURE 1

All dimensions in INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Void free, transfer molded, thermosetting plastic (T-18).

FINISH: Corrosion resistant, readily solderable.

POLARITY: Cathode Banded.

WEIGHT: 0.7 gram (approx.).

MOUNTING POSITION: Any.

1N5333B thru 1N5388B

NOTE 1 Devices listed have a $\pm 5\%$ tolerance on nominal V_Z . The suffix A denotes a $\pm 10\%$, C denotes $\pm 2\%$, D denotes $\pm 1\%$, and no suffix denotes a $\pm 20\%$ tolerance.

NOTE 2 Nominal Zener Voltage (V_Z) is read with the device in standard test clips with 3/8 to 1/2 inch spacing between clip and case of the diode. Before reading the diode is allowed to stabilize for a period of 40 ± 10 milliseconds at 25°C ($+8, -2^\circ\text{C}$).

NOTE 3 The Zener Impedance (Z_{ZT} or Z_{ZK}) is derived from the 60 Hz ac voltage, which results when an ac current having a rms value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} respectively.

NOTE 4 The Maximum Reverse (leakage) Current is specified for devices with $\pm 20\%$ and $\pm 10\%$ voltage tolerances on nominal V_Z in another column.

NOTE 5 The Maximum Zener Current (I_{ZM}) shown is for $\pm 5\%$ tolerance devices. I_{ZM} for $\pm 10\%$ and $\pm 20\%$ devices can be calculated using the formula:

$$I_{ZM} = \frac{P}{V_{ZM}}$$

where " V_{ZM} " is V_Z at the high end of the voltage tolerance specified and "P" is the rated power of the device.

NOTE 6 The Surge Current (I_{ZSM}) is specified as the maximum peak of a nonrecurrent sine wave of 8.3 milliseconds duration.

NOTE 7 Voltage Regulation (ΔV_Z) is the difference between the voltage measured at 10% and 50% of I_{ZM} .

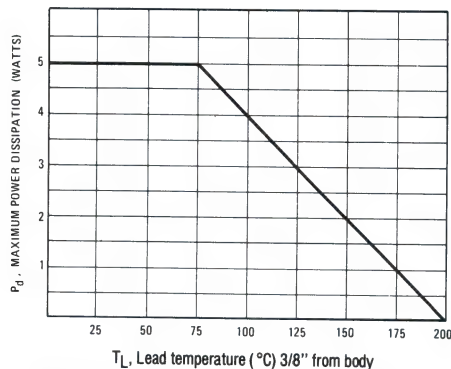


FIGURE 2 POWER DERATING CURVE

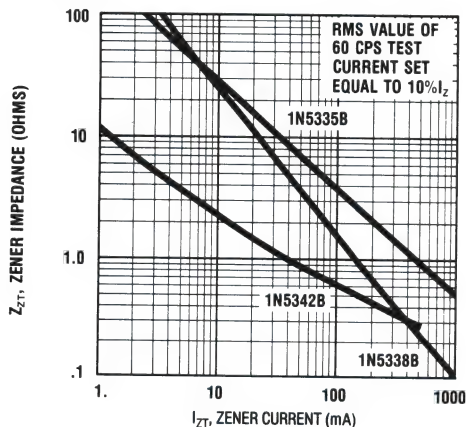


FIGURE 3
TYPICAL ZENER IMPEDANCE VS.
ZENER CURRENT FOR TYPES SHOWN

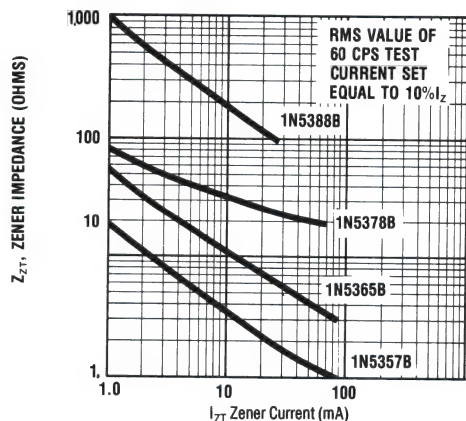


FIGURE 4
TYPICAL ZENER IMPEDANCE VS.
ZENER CURRENT FOR TYPES SHOWN

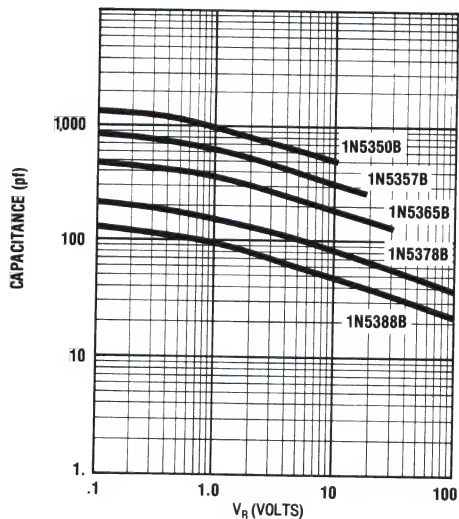


FIGURE 5
TYPICAL CAPACITANCE VS.
REVERSE VOLTAGE FOR 5 WATT ZENERS

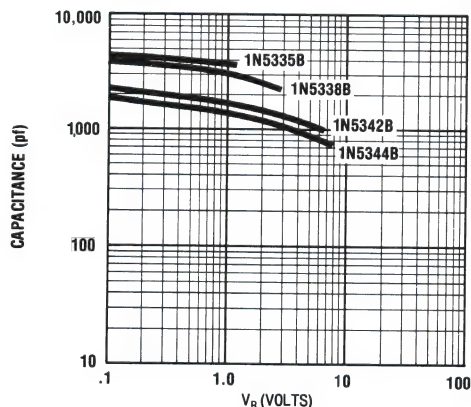


FIGURE 6
TYPICAL CAPACITANCE VS.
REVERSE VOLTAGE FOR 5 WATT ZENERS

1N5518 thru 1N5546

FEATURES

- LOW ZENER NOISE SPECIFIED
- LOW ZENER IMPEDANCE
- LOW LEAKAGE CURRENT
- HERMETICALLY SEALED GLASS PACKAGE
- JAN/JANTX/JANTXV AVAILABLE ON 1N5518 THROUGH 1N5546B PER MIL-S-19500/437

MAXIMUM RATINGS

Operating Temperature: -65°C to +200°C

Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted. Based on dc measurements at thermal equilibrium.
V_F = 1.1 Max @ I_F = 200 mA for all types)

| JEDEC TYPE NO. (Note 1) | NOMINAL ZENER VOLTAGE V _Z @ I _{ZT} VOLTS (Note 2) | TEST CURRENT I _{ZT} mA dc | MAX. ZENER IMPEDANCE B-C-D SUFFIX Z _{ZT} @ I _{ZT} OHMS (Note 3) | MAX. REVERSE LEAKAGE CURRENT | | | B-C-D SUFFIX MAXIMUM DC ZENER CURRENT I _{ZM} mA dc (Note 5) | B-C-D SUFFIX MAX. NOISE DENSITY AT I _Z = 250 µA N _D (MICRO-VOLTS PER SQUARE ROOT CYCLE) | REGULATION FACTOR ΔV _Z VOLTS (Note 6) | LOW V _Z CURRENT I _{ZL} mA dc |
|-------------------------------|--|---|--|-------------------------------------|--------------------|-----------------|---|--|--|--|
| | | | | V _R – VOLTS | | | | | | |
| | | | | I _R µA dc (Note 4) | NON & A- SUFFIX | B-C-D SUFFIX | | | | |
| 1N5518 | 3.3 | 20 | 26 | 5.0 | 0.90 | 1.0 | 115 | 0.5 | 0.90 | 2.0 |
| 1N5519 | 3.6 | 20 | 24 | 3.0 | 0.90 | 1.0 | 105 | 0.5 | 0.90 | 2.0 |
| 1N5520 | 3.9 | 20 | 22 | 1.0 | 0.90 | 1.0 | 96 | 0.5 | 0.85 | 2.0 |
| 1N5521 | 4.3 | 20 | 18 | 3.0 | 1.0 | 1.5 | 88 | 0.5 | 0.75 | 2.0 |
| 1N5522 | 4.7 | 10 | 22 | 2.0 | 1.5 | 2.0 | 81 | 0.5 | 0.60 | 1.0 |
| 1N5523 | 5.1 | 5.0 | 26 | 2.0 | 2.0 | 2.5 | 75 | 0.5 | 0.65 | 0.25 |
| 1N5524 | 5.6 | 3.0 | 30 | 2.0 | 3.0 | 3.5 | 68 | 1.0 | 0.30 | 0.25 |
| 1N5525 | 6.2 | 1.0 | 30 | 1.0 | 4.5 | 5.0 | 61 | 1.0 | 0.20 | 0.01 |
| 1N5526 | 6.8 | 1.0 | 30 | 1.0 | 5.5 | 6.2 | 56 | 1.0 | 0.10 | 0.01 |
| 1N5527 | 7.5 | 1.0 | 35 | 0.5 | 6.0 | 6.8 | 51 | 2.0 | 0.05 | 0.01 |
| 1N5528 | 8.2 | 1.0 | 40 | 0.5 | 6.5 | 7.5 | 46 | 4.0 | 0.05 | 0.01 |
| 1N5529 | 9.1 | 1.0 | 45 | 0.1 | 7.0 | 8.2 | 42 | 4.0 | 0.05 | 0.01 |
| 1N5530 | 10.0 | 1.0 | 60 | 0.05 | 8.0 | 9.1 | 38 | 4.0 | 0.10 | 0.01 |
| 1N5531 | 11.0 | 1.0 | 80 | 0.05 | 9.0 | 9.9 | 35 | 5.0 | 0.20 | 0.01 |
| 1N5532 | 12.0 | 1.0 | 90 | 0.05 | 9.5 | 10.8 | 32 | 5.0 | 0.20 | 0.01 |
| 1N5533 | 13.0 | 1.0 | 90 | 0.01 | 10.5 | 11.7 | 29 | 15 | 0.20 | 0.01 |
| 1N5534 | 14.0 | 1.0 | 100 | 0.01 | 11.5 | 12.6 | 27 | 20 | 0.20 | 0.01 |
| 1N5535 | 15.0 | 1.0 | 100 | 0.01 | 12.5 | 13.5 | 25 | 20 | 0.20 | 0.01 |
| 1N5536 | 16.0 | 1.0 | 100 | 0.01 | 13.0 | 14.4 | 24 | 20 | 0.20 | 0.01 |
| 1N5537 | 17.0 | 1.0 | 100 | 0.01 | 14.0 | 15.3 | 22 | 20 | 0.20 | 0.01 |
| 1N5538 | 18.0 | 1.0 | 100 | 0.01 | 15.0 | 16.2 | 21 | 20 | 0.20 | 0.01 |
| 1N5539 | 19.0 | 1.0 | 100 | 0.01 | 16.0 | 17.1 | 20 | 20 | 0.20 | 0.01 |
| 1N5540 | 20.0 | 1.0 | 100 | 0.01 | 17.0 | 18.0 | 19 | 20 | 0.20 | 0.01 |
| 1N5541 | 22.0 | 1.0 | 100 | 0.01 | 18.0 | 19.8 | 17 | 20 | 0.25 | 0.01 |
| 1N5542 | 24.0 | 1.0 | 100 | 0.01 | 20.0 | 21.6 | 16 | 20 | 0.30 | 0.01 |
| 1N5543 | 25.0 | 1.0 | 100 | 0.01 | 21.0 | 22.4 | 15 | 20 | 0.35 | 0.01 |
| 1N5544 | 28.0 | 1.0 | 100 | 0.01 | 23.0 | 25.2 | 14 | 20 | 0.40 | 0.01 |
| 1N5545 | 30.0 | 1.0 | 100 | 0.01 | 24.0 | 27.0 | 13 | 20 | 0.45 | 0.01 |
| 1N5546 | 33.0 | 1.0 | 100 | 0.01 | 28.0 | 29.7 | 12 | 20 | 0.50 | 0.01 |

NOTE 1 — TOLERANCE AND VOLTAGE DESIGNATION

The JEDEC type numbers shown are ±20% with guaranteed limits for only V_Z, I_R, and V_F. Units with 'A' suffix are ±10% with guaranteed limits for V_Z, I_R, and V_F. Units with guaranteed limits for all six parameters are indicated by a 'B' suffix for ±5.0% units, 'C' suffix for ±2.0% and 'D' suffix for ±1.0%.

NOTE 2 — ZENER VOLTAGE (V_Z) MEASUREMENT

Nominal zener voltage is measured with the device junction in thermal equilibrium with ambient temperature of 25°C.

NOTE 3 — ZENER IMPEDANCE (Z_Z) DERIVATION

The zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the dc zener current (I_{ZT}) is superimposed on I_{ZT}.

NOTE 4 — REVERSE LEAKAGE CURRENT (I_R)

Reverse leakage currents are guaranteed and are measured at V_R as shown on the table.

NOTE 5 — MAXIMUM REGULATOR CURRENT (I_{ZM})

The maximum current shown is based on the maximum voltage of a 5.0% type unit, therefore, it applies only to the 'B' suffix device. The actual I_{ZM} for any device may not exceed the value of 400 milliwatts divided by the actual V_Z of the device.

NOTE 6 — MAXIMUM REGULATION FACTOR (ΔV_Z)

ΔV_Z is the maximum difference between V_Z at I_{ZT} and V_Z at I_{ZL} measured with the device junction in thermal equilibrium.

LOW VOLTAGE AVALANCHE DIODES DO-7

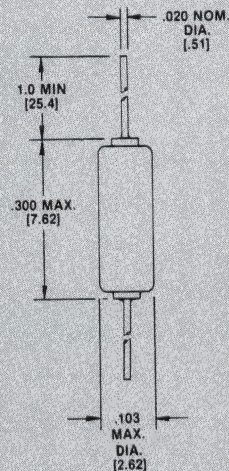


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: Corrosion resistant. Leads are solderable.

MARKING: Body painted, alpha numeric.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

1N5518 thru 1N5546 DO-7

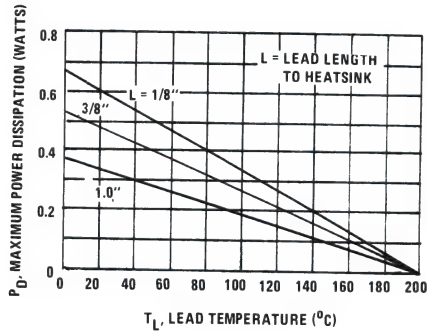


FIGURE 2
POWER-TEMPERATURE
DERATING CURVE

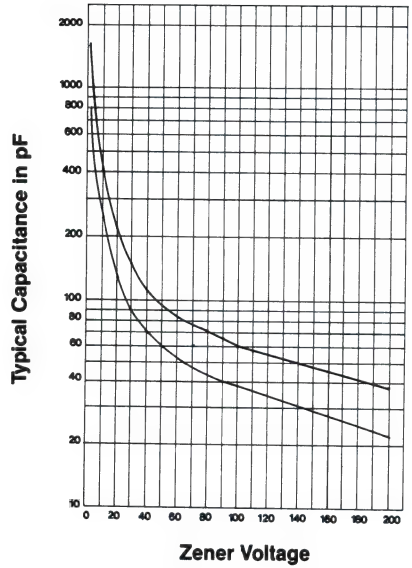


FIGURE 3
CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)

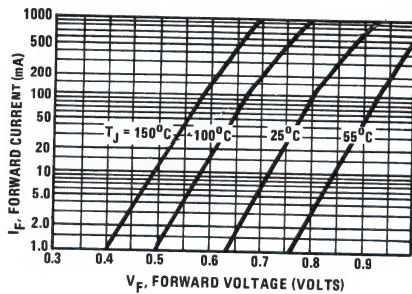


FIGURE 4
TYPICAL FORWARD
CHARACTERISTICS

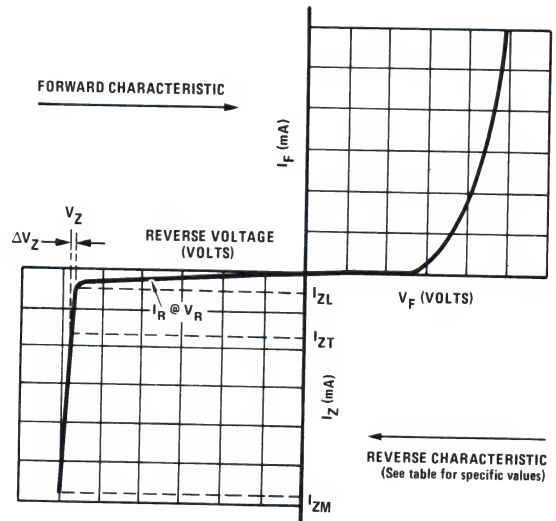


FIGURE 5
ZENER DIODE CHARACTERISTICS
AND SYMBOL IDENTIFICATION

1N5518 thru 1N5546

FEATURES

- LOW ZENER NOISE SPECIFIED
- LOW ZENER IMPEDANCE
- LOW LEAKAGE CURRENT
- HERMETICALLY SEALED GLASS PACKAGE
- JAN/JANTX/JANTXV AVAILABLE ON 1N5518-1 THROUGH 1N5546B-1 PER MIL-S-19500/437

MAXIMUM RATINGS

Operating Temperature: -65°C to +200°C

Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted. Based on dc measurements at thermal equilibrium.
V_F = 1.1 Max @ I_F = 200 mA for all types)

| 1N5518 thru 1N5546 (1/2 WATT, 5% TOL, 200 mA PIV TYPE) | | | | | | | | | | | |
|--|--|-------------------------|--|------------------------------------|--------------------|-----------------|--|--|--|---|--|
| JEDEC TYPE NO. (Note 1) | NOMINAL ZENER VOLTAGE V _Z @ I _{ZT} VOLTS (Note 2) | TEST CURRENT mAdc | MAX. ZENER IMPEDANCE B-C-D SUFFIX Z _{KT} @ I _{ZT} OHMS (Note 3) | MAX. REVERSE LEAKAGE CURRENT | | | B-C-D SUFFIX MAXIMUM DC ZENER CURRENT I _{ZM} mAdc (Note 5) | B-C-D SUFFIX MAX. NOISE DENSITY AT I _Z = 250 µA N _D (MICRO-VOLTS PER SQUARE ROOT CYCLE) | REGULATION FACTOR ΔV _Z VOLTS (Note 6) | LOW V _Z CURRENT I _{ZL} mAdc | |
| | | | | V _R - VOLTS | | | | | | | |
| | | | | I _R µAdc (Note 4) | NON & A- SUFFIX | B-C-D SUFFIX | | | | | |
| 1N5518 | 3.3 | 20 | 26 | 5.0 | 0.90 | 1.0 | 115 | 0.5 | 0.90 | 2.0 | |
| 1N5519 | 3.6 | 20 | 24 | 3.0 | 0.90 | 1.0 | 105 | 0.5 | 0.90 | 2.0 | |
| 1N5520 | 3.9 | 20 | 22 | 1.0 | 0.90 | 1.0 | 98 | 0.5 | 0.95 | 2.0 | |
| 1N5521 | 4.3 | 20 | 18 | 3.0 | 1.0 | 1.5 | 88 | 0.5 | 0.75 | 2.0 | |
| 1N5522 | 4.7 | 10 | 22 | 2.0 | 1.5 | 2.0 | 81 | 0.5 | 0.60 | 1.0 | |
| 1N5523 | 5.1 | 5.0 | 26 | 2.0 | 2.0 | 2.5 | 75 | 0.5 | 0.65 | 0.25 | |
| 1N5524 | 5.6 | 3.0 | 30 | 2.0 | 3.0 | 3.5 | 68 | 1.0 | 0.30 | 0.25 | |
| 1N5525 | 6.2 | 1.0 | 30 | 1.0 | 4.5 | 5.0 | 61 | 1.0 | 0.20 | 0.01 | |
| 1N5526 | 6.8 | 1.0 | 30 | 1.0 | 5.5 | 6.2 | 56 | 1.0 | 0.10 | 0.01 | |
| 1N5527 | 7.5 | 1.0 | 35 | 0.5 | 6.0 | 6.8 | 51 | 2.0 | 0.05 | 0.01 | |
| 1N5528 | 8.2 | 1.0 | 40 | 0.5 | 6.5 | 7.5 | 46 | 4.0 | 0.05 | 0.01 | |
| 1N5529 | 9.1 | 1.0 | 45 | 0.1 | 7.0 | 8.2 | 42 | 4.0 | 0.05 | 0.01 | |
| 1N5530 | 10.0 | 1.0 | 60 | 0.05 | 8.0 | 9.1 | 38 | 4.0 | 0.10 | 0.01 | |
| 1N5531 | 11.0 | 1.0 | 80 | 0.05 | 9.0 | 9.9 | 35 | 5.0 | 0.20 | 0.01 | |
| 1N5532 | 12.0 | 1.0 | 90 | 0.05 | 9.5 | 10.8 | 32 | 10 | 0.20 | 0.01 | |
| 1N5533 | 13.0 | 1.0 | 90 | 0.01 | 10.5 | 11.7 | 29 | 15 | 0.20 | 0.01 | |
| 1N5534 | 14.0 | 1.0 | 100 | 0.01 | 11.5 | 12.6 | 27 | 20 | 0.20 | 0.01 | |
| 1N5535 | 15.0 | 1.0 | 100 | 0.01 | 12.5 | 13.5 | 25 | 20 | 0.20 | 0.01 | |
| 1N5536 | 16.0 | 1.0 | 100 | 0.01 | 13.0 | 14.4 | 24 | 20 | 0.20 | 0.01 | |
| 1N5537 | 17.0 | 1.0 | 100 | 0.01 | 14.0 | 15.3 | 22 | 20 | 0.20 | 0.01 | |
| 1N5538 | 18.0 | 1.0 | 100 | 0.01 | 15.0 | 16.2 | 21 | 20 | 0.20 | 0.01 | |
| 1N5539 | 19.0 | 1.0 | 100 | 0.01 | 16.0 | 17.1 | 20 | 20 | 0.20 | 0.01 | |
| 1N5540 | 20.0 | 1.0 | 100 | 0.01 | 17.0 | 18.0 | 19 | 20 | 0.20 | 0.01 | |
| 1N5541 | 22.0 | 1.0 | 100 | 0.01 | 18.0 | 19.8 | 17 | 20 | 0.25 | 0.01 | |
| 1N5542 | 24.0 | 1.0 | 100 | 0.01 | 20.0 | 21.6 | 16 | 20 | 0.30 | 0.01 | |
| 1N5543 | 25.0 | 1.0 | 100 | 0.01 | 21.0 | 22.4 | 15 | 20 | 0.35 | 0.01 | |
| 1N5544 | 28.0 | 1.0 | 100 | 0.01 | 23.0 | 25.2 | 14 | 20 | 0.40 | 0.01 | |
| 1N5545 | 30.0 | 1.0 | 100 | 0.01 | 24.0 | 27.0 | 13 | 20 | 0.45 | 0.01 | |
| 1N5546 | 33.0 | 1.0 | 100 | 0.01 | 28.0 | 29.7 | 12 | 20 | 0.50 | 0.01 | |

NOTE 1 — TOLERANCE AND VOLTAGE DESIGNATION

The JEDEC type numbers shown are ±20% with guaranteed limits for only V_Z, I_R, and V_F. Units with A suffix are ±10% with guaranteed limits for only V_Z, I_R, and V_F. Units with guaranteed limits for all six parameters are indicated by a B suffix for ±5.0% units, C suffix for ±2.0% and D suffix for ±1.0%.

NOTE 2 — ZENER (V_Z) VOLTAGE MEASUREMENT

Nominal zener voltage is measured with the device junction in thermal equilibrium with ambient temperature of 25°C.

NOTE 3 — ZENER IMPEDANCE (Z_Z) DERIVATION

The zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the dc zener current (I_{ZT}) is superimposed on I_{ZT}.

NOTE 4 — REVERSE LEAKAGE CURRENT (I_R)

Reverse leakage currents are guaranteed and are measured at V_R as shown on the table.

NOTE 5 — MAXIMUM REGULATOR CURRENT (I_{ZM})

The maximum current shown is based on the maximum voltage of a 5.0% type unit, therefore, it applies only to the B suffix device. The actual I_{ZM} for any device may not exceed the value of 400 milliwatts divided by the actual V_Z of the device.

NOTE 6 — MAXIMUM REGULATION FACTOR (ΔV_Z)

ΔV_Z is the maximum difference between V_Z at I_{ZT} and V_Z at I_{ZL} measured with the device junction in thermal equilibrium.

LOW VOLTAGE AVALANCHE DIODES DO-35

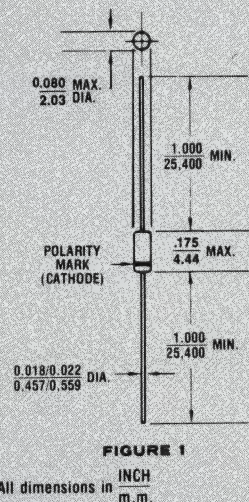


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body. Metalurgically bonded DO-35s exhibit less than 100°C/Watt at zero distance from body.

1N5518 thru 1N5546 DO-35

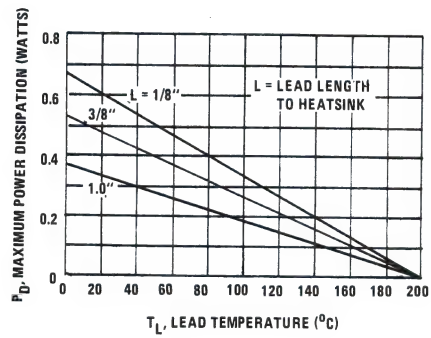


FIGURE 2
POWER-TEMPERATURE
DERATING CURVE

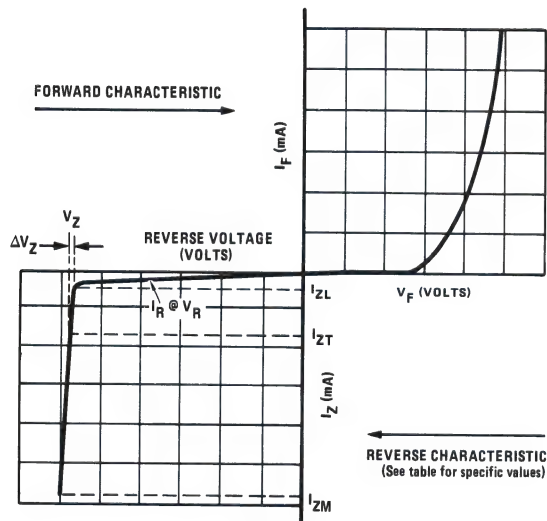


FIGURE 3
ZENER DIODE CHARACTERISTICS
AND SYMBOL IDENTIFICATION

1N5728 thru 1N5757

FEATURES

- ZENER VOLTAGE 4.7 TO 75 V
- SMALL RUGGED DOUBLE SLUG CONSTRUCTION DO-35
- CONSTRUCTED WITH AN OXIDE PASSIVATED ALL DIFFUSED DIE

MAXIMUM RATINGS

Operating Temperature: -65°C to $+200^{\circ}\text{C}$

DC Power Dissipation: 400 mW

Power Derating: 2.63 mW/ $^{\circ}\text{C}$ above 50°C

Forward Voltage @ 10 mA: 0.9 Volts

*ELECTRICAL CHARACTERISTICS @ 25°C

| TYPE NUMBER (Note 1) | REGULATOR VOLTAGE | TEST CURRENT | DYNAMIC IMPEDANCE | REVERSE CURRENT | I_s TEST VOLTAGE | MAXIMUM REGULATOR CURRENT | TEMPERATURE COEFFICIENT |
|----------------------------|----------------------|-----------------|----------------------|----------------------------|-----------------------|---------------------------------|--|
| | (V_Z) VOLTS | (I_Z) MA | (Z_Z) OHMS | (I_R) μA | (V_R) VOLTS | (I_{ZM}) mA | (α_Z) mV/ $^{\circ}\text{C}$ |
| 1N5728B | 4.7 | 10 | 70 | 3.0 | 2 | 70 | -1.0 |
| 1N5729B | 5.1 | 10 | 50 | 3.0 | 2 | 65 | -0.2 |
| 1N5730B | 5.6 | 10 | 25 | 3.0 | 2 | 60 | +1.2 |
| 1N5731B | 6.2 | 10 | 10 | 3.0 | 4 | 55 | +2.3 |
| 1N5732B | 6.8 | 10 | 10 | 3.0 | 4 | 50 | +3.0 |
| 1N5733B | 7.5 | 10 | 10 | 2.0 | 5 | 45 | +4.0 |
| 1N5734B | 8.2 | 10 | 15 | 1.0 | 5 | 40 | +5.0 |
| 1N5735B | 9.1 | 10 | 15 | 0.5 | 6 | 40 | +6.0 |
| 1N5736B | 10 | 10 | 20 | 0.2 | 7 | 35 | +7.0 |
| 1N5737B | 11 | 5 | 20 | 0.1 | 8 | 30 | +8.0 |
| 1N5738B | 12 | 5 | 25 | 0.1 | 8 | 30 | +9.0 |
| 1N5739B | 13 | 5 | 30 | 0.1 | 9 | 25 | +10.5 |
| 1N5740B | 15 | 5 | 30 | 0.1 | 10 | 25 | +12.9 |
| 1N5741B | 16 | 5 | 40 | 0.1 | 11 | 20 | +13 |
| 1N5742B | 18 | 5 | 45 | 0.1 | 12 | 20 | +15 |
| 1N5743B | 20 | 5 | 55 | 0.1 | 14 | 15 | +17 |
| 1N5744B | 22 | 5 | 55 | 0.1 | 15 | 15 | +19 |
| 1N5745B | 24 | 5 | 70 | 0.1 | 17 | 15 | +21 |
| 1N5746B | 27 | 2 | 80 | 0.1 | 19 | 10 | +23.5 |
| 1N5747B | 30 | 2 | 80 | 0.1 | 21 | 10 | +26 |
| 1N5748B | 33 | 2 | 90 | 0.1 | 23 | 10 | +29 |
| 1N5749B | 36 | 2 | 90 | 0.1 | 25 | 10 | +31 |
| 1N5750B | 39 | 2 | 130 | 0.1 | 27 | 9 | +34 |
| 1N5751B | 43 | 2 | 150 | 0.1 | 30 | 9 | +37 |
| 1N5752B | 47 | 2 | 170 | 0.1 | 33 | 8 | +40 |
| 1N5753B | 51 | 2 | 180 | 0.1 | 36 | 7 | +44 |
| 1N5754B | 56 | 2 | 200 | 0.1 | 39 | 6 | +47 |
| 1N5755B | 62 | 2 | 215 | 0.1 | 43 | 6 | +51 |
| 1N5756B | 68 | 2 | 240 | 0.1 | 48 | 5 | +56 |
| 1N5757B | 75 | 2 | 255 | 0.1 | 53 | 5 | +60 |

SILICON 400 mW ZENER DIODES

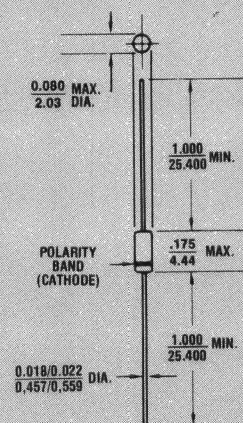


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $200^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N5728 thru 1N5757

NOTE 1 Devices listed have a $\pm 5\%$ voltage tolerance on nominal V_Z . Suffix C denotes a $\pm 2\%$ tolerance and suffix D denotes a $\pm 1\%$ tolerance.

NOTE 2 All static parameters measured under pulsed conditions, $t_p = 300 \mu\text{sec}$.

NOTE 3 Dynamic Impedance measured by superimposing 0.2 mA I_{ac} rms at 1000 hz on I_{DC} .

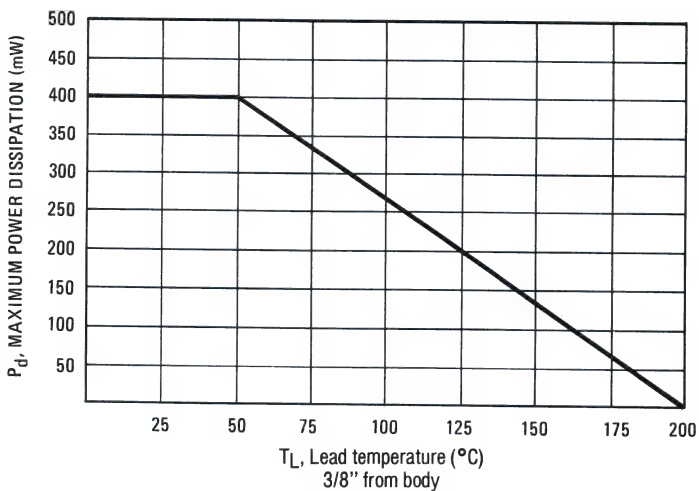


FIGURE 2 POWER DERATING CURVE

1N5913B thru 1N5956B

FEATURES

- ZENER VOLTAGE 3.3 V TO 200 V
- WITHSTANDS LARGE SURGE STRESSES

MAXIMUM RATINGS

Junction and Storage: -55°C to $+200^{\circ}\text{C}$
DC Power Dissipation: 1.5 Watt
12 mW/ $^{\circ}\text{C}$ above 75°C
Forward Voltage @ 200 mA: 1.2 Volts

ELECTRICAL CHARACTERISTICS @ $T_L = 30^{\circ}\text{C}$

| JEDEC TYPE NUMBER | ZENER VOLTAGE V_Z | TEST CURRENT I_{ZT} | DYNAMIC IMPEDANCE Z_{ZT} | KNEE CURRENT I_{ZK} | KNEE IMPEDANCE Z_{ZK} | REVERSE CURRENT I_R | REVERSE VOLTAGE V_R | MAX. DC CURRENT I_{ZM} |
|-------------------------|---------------------------|-----------------------------|----------------------------------|-----------------------------|-------------------------------|-----------------------------|-----------------------------|--------------------------------|
| | Volts | mA | Ω | mA | Ω | μA | Volts | mA |
| 1N5913 | 3.3 | 113.6 | 10 | 1.0 | 500 | 100 | 1.0 | 454 |
| 1N5914 | 3.6 | 104.2 | 9.0 | 1.0 | 500 | 75 | 1.0 | 416 |
| 1N5915 | 3.9 | 96.1 | 7.5 | 1.0 | 500 | 25 | 1.0 | 384 |
| 1N5916 | 4.3 | 87.2 | 6.0 | 1.0 | 500 | 5.0 | 1.0 | 348 |
| 1N5917 | 4.7 | 79.8 | 5.0 | 1.0 | 500 | 5.0 | 1.5 | 319 |
| 1N5918 | 5.1 | 73.5 | 4.0 | 1.0 | 350 | 5.0 | 2.0 | 294 |
| 1N5919 | 5.6 | 66.9 | 2.0 | 1.0 | 250 | 5.0 | 3.0 | 267 |
| 1N5920 | 6.2 | 60.5 | 2.0 | 1.0 | 200 | 5.0 | 4.0 | 241 |
| 1N5921 | 6.8 | 55.1 | 2.5 | 1.0 | 200 | 5.0 | 5.2 | 220 |
| 1N5922 | 7.5 | 50 | 3.0 | 0.5 | 400 | 5.0 | 6.0 | 200 |
| 1N5923 | 8.2 | 45.7 | 3.5 | 0.5 | 400 | 5.0 | 6.5 | 182 |
| 1N5924 | 9.1 | 41.2 | 4.0 | 0.5 | 500 | 5.0 | 7.0 | 164 |
| 1N5925 | 10 | 37.5 | 4.5 | 0.25 | 500 | 5.0 | 8.0 | 150 |
| 1N5926 | 11 | 34.1 | 5.5 | 0.25 | 550 | 1.0 | 8.4 | 125 |
| 1N5927 | 12 | 31.2 | 6.5 | 0.25 | 550 | 1.0 | 9.1 | 125 |
| 1N5928 | 13 | 28.8 | 7.0 | 0.25 | 550 | 1.0 | 9.9 | 115 |
| 1N5929 | 15 | 25 | 9.0 | 0.25 | 600 | 1.0 | 11.4 | 100 |
| 1N5930 | 16 | 23.4 | 10 | 0.25 | 600 | 1.0 | 12.2 | 93 |
| 1N5931 | 18 | 20.8 | 12 | 0.25 | 650 | 1.0 | 13.7 | 83 |
| 1N5932 | 20 | 18.7 | 14 | 0.25 | 650 | 1.0 | 15.2 | 75 |
| 1N5933 | 22 | 17 | 17.5 | 0.25 | 650 | 1.0 | 16.7 | 68 |
| 1N5934 | 24 | 15.6 | 19 | 0.25 | 700 | 1.0 | 18.2 | 62 |
| 1N5935 | 27 | 13.9 | 23 | 0.25 | 700 | 1.0 | 20.6 | 55 |
| 1N5936 | 30 | 12.5 | 28 | 0.25 | 750 | 1.0 | 22.8 | 50 |
| 1N5937 | 33 | 11.4 | 33 | 0.25 | 800 | 1.0 | 25.1 | 45 |
| 1N5938 | 36 | 10.4 | 38 | 0.25 | 850 | 1.0 | 27.4 | 41 |
| 1N5939 | 39 | 9.6 | 45 | 0.25 | 900 | 1.0 | 29.7 | 38 |
| 1N5940 | 43 | 8.7 | 53 | 0.25 | 950 | 1.0 | 32.7 | 34 |
| 1N5941 | 47 | 8.0 | 67 | 0.25 | 1000 | 1.0 | 35.8 | 31 |
| 1N5942 | 51 | 7.3 | 70 | 0.25 | 1100 | 1.0 | 38.8 | 29 |
| 1N5943 | 56 | 6.7 | 86 | 0.25 | 1300 | 1.0 | 42.6 | 26 |
| 1N5944 | 62 | 6.0 | 100 | 0.25 | 1500 | 1.0 | 47.1 | 24 |
| 1N5945 | 68 | 5.5 | 120 | 0.25 | 1700 | 1.0 | 51.2 | 22 |
| 1N5946 | 75 | 5.0 | 140 | 0.25 | 2000 | 1.0 | 56 | 20 |
| 1N5947 | 82 | 4.6 | 160 | 0.25 | 2500 | 1.0 | 62.2 | 18 |
| 1N5948 | 91 | 4.1 | 200 | 0.25 | 3000 | 1.0 | 69.2 | 16 |
| 1N5949 | 100 | 3.7 | 250 | 0.25 | 3100 | 1.0 | 76 | 15 |
| 1N5950 | 110 | 3.4 | 300 | 0.25 | 4000 | 1.0 | 83.6 | 13 |
| 1N5951 | 120 | 3.1 | 380 | 0.25 | 4500 | 1.0 | 91.2 | 12 |
| 1N5952 | 130 | 2.9 | 450 | 0.25 | 5000 | 1.0 | 98.8 | 11 |
| 1N5953 | 150 | 2.5 | 600 | 0.25 | 6000 | 1.0 | 114 | 10 |
| 1N5954 | 160 | 2.3 | 700 | 0.25 | 6500 | 1.0 | 121.6 | 9.0 |
| 1N5955 | 180 | 2.1 | 900 | 0.25 | 7000 | 1.0 | 136.8 | 8.0 |
| 1N5956 | 200 | 1.9 | 1200 | 0.25 | 8000 | 1.0 | 152 | 7.0 |

SILICON 1.5 WATT ZENER DIODES

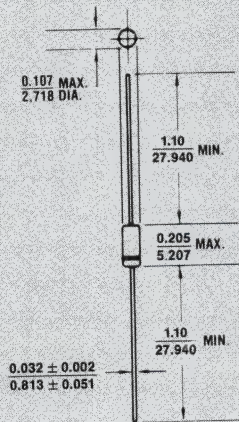


FIGURE 1

All dimensions in INCH
m. m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed, axial
lead glass package (DO-41).

FINISH: Corrosion resistant. Leads
are solderable.

THERMAL RESISTANCE: $60^{\circ}\text{C}/\text{W}$
junction to lead at 0.375-inches
from body.

POLARITY:

Banded end is cathode.

WEIGHT: 0.4 grams (Typical).

1N5913B thru 1N5956B

NOTE 1 No suffix indicates a $\pm 20\%$ tolerance on nominal V_Z . Suffix A denotes a $\pm 10\%$ tolerance, B denotes a $\pm 5\%$ tolerance, C denotes a $\pm 2\%$ tolerance, and D denotes a $\pm 1\%$ tolerance.

NOTE 2 Zener voltage (V_Z) is measured at $T_L = 30^\circ\text{C}$. Voltage measurement to be performed 90 seconds after application of DC current.

NOTE 3 The zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} .

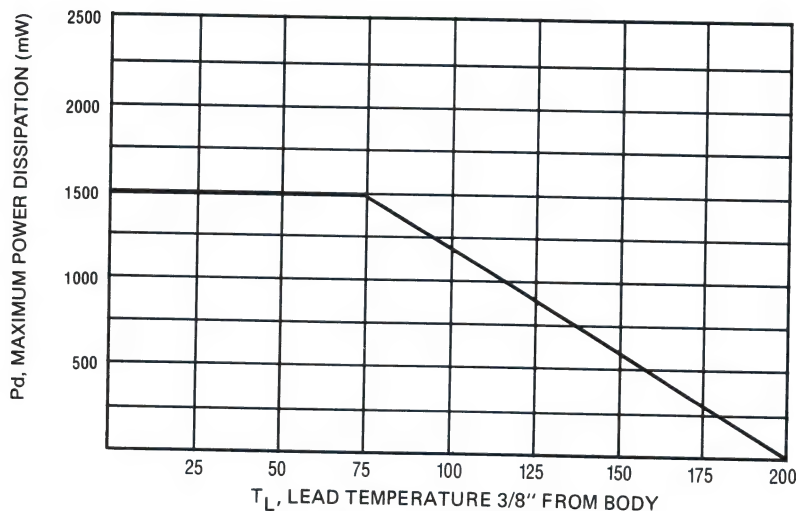


FIGURE 2. POWER DERATING CURVE

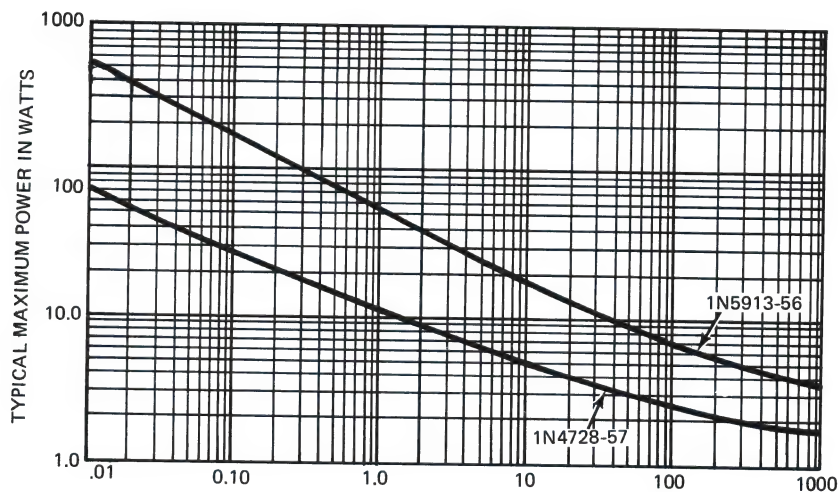
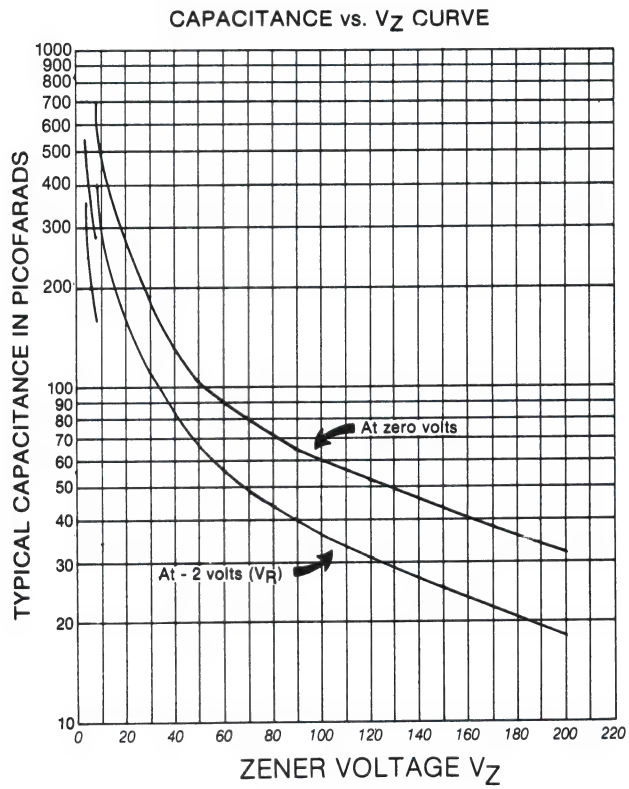


FIGURE 3. TRANSIENT SURGE CAPABILITY OF DO-41 GLASS DIODE

1N5913B thru 1N5956B



1N5985 thru 1N6031

FEATURES

- Popular DO-35 Package—Small and Rugged
- Double Slug Construction
- Constructed with an Oxide Passivated All Diffused Die

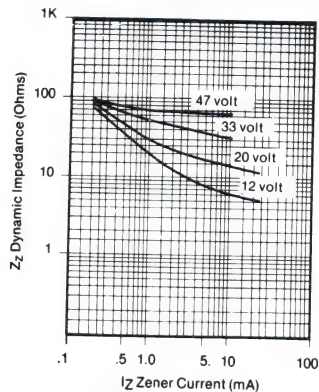
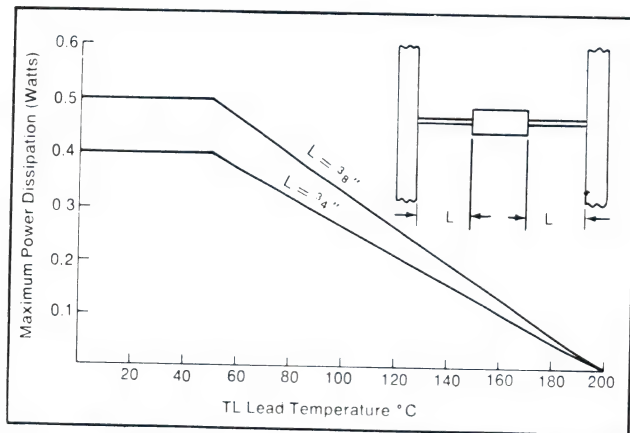
MAXIMUM RATINGS

Operating & Storage Temp.: -65°C to $+200^{\circ}\text{C}$
DC Power Dissipation: At Lead Temp. $T_L \leq 50^{\circ}\text{C}$
Lead length 3/8": 500 mW
Derate above $+50^{\circ}\text{C}$: $3.33\text{mW}/^{\circ}\text{C}$
Forward voltage @ 100mA: 1.5V
and $T_L = 30^{\circ}\text{C}$ $L = 3/8"$

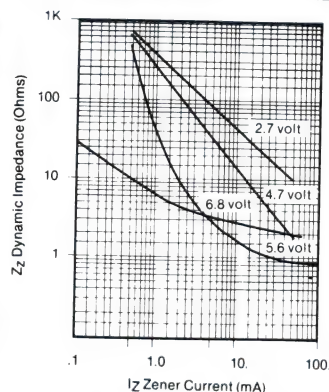
ELECTRICAL CHARACTERISTICS

See the following table:

The type number listed indicates a 20% tolerance. For 10% tolerance, add suffix A; for 5% tolerance, add suffix B; for 2% tolerance add suffix C; for 1% tolerance, add suffix D.



Typical Effect of Zener Current
on Zener Impedance



Typical Effect of Zener Current
on Zener Impedance

SILICON 500 mW ZENER DIODES

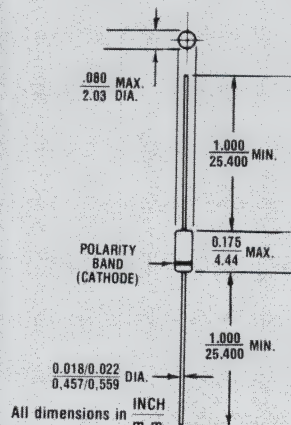


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case, DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $200^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

1N5985 thru 1N6031

***ELECTRICAL CHARACTERISTICS @ 30°C Lead Temperature. Lead Length 3/8".**

| JEDEC Type Number | Nominal Zener Voltage V _Z @ I _{ZT} Volts (Note 2) | Test Current I _{ZT} mA | Max. Zener Impedance (Note 1) | | | | Max. Reverse Leakage Current Current | | | | Max. DC Zener Current I _{ZM} (Note 3) | Typical Temp. Coef. of Zener Voltage α _{VZ} %/°C |
|-------------------------|---|--|---|----------------------|--|----------------------|---|----------------------|-------------------------|----------------------|--|--|
| | | | Z _{ZT} @ I _{ZT} Ohms | | Z _{ZK} @ I _{ZK} = 0.25mA Ohms | | I _R μA | | V _R Volts | | | |
| | | | B, C, D Suffix | A, Non- Suffix | B, C, D Suffix | A, Non- Suffix | B, C, D Suffix | A, Non- Suffix | B, C, D Suffix | A, Non- Suffix | | |
| 1N5985 | 2.4 | 5.0 | 100 | 110 | 1800 | 2000 | 100 | 100 | 1.0 | 0.5 | 208 | -0.09 |
| 1N5986 | 2.7 | 5.0 | 100 | 110 | 1900 | 2200 | 75 | 100 | 1.0 | 0.5 | 185 | -0.075 |
| 1N5987 | 3.0 | 5.0 | 95 | 100 | 2000 | 2300 | 50 | 100 | 1.0 | 0.5 | 167 | -0.07 |
| 1N5988 | 3.3 | 5.0 | 95 | 100 | 2200 | 2400 | 25 | 75 | 1.0 | 0.5 | 152 | -0.06 |
| 1N5989 | 3.6 | 5.0 | 90 | 95 | 2300 | 2500 | 15 | 50 | 1.0 | 0.5 | 139 | -0.055 |
| 1N5990 | 3.9 | 5.0 | 90 | 95 | 2400 | 2500 | 10 | 25 | 1.0 | 1.0 | 128 | -0.045 |
| 1N5991 | 4.3 | 5.0 | 88 | 90 | 2500 | 2500 | 5.0 | 15 | 1.0 | 1.0 | 116 | -0.01 |
| 1N5992 | 4.7 | 5.0 | 70 | 90 | 2200 | 2500 | 3.0 | 10 | 1.5 | 1.0 | 106 | +0.01 |
| 1N5993 | 5.1 | 5.0 | 50 | 88 | 2050 | 2500 | 2.0 | 5.0 | 2.0 | 1.0 | 98 | +0.025 |
| 1N5994 | 5.6 | 5.0 | 25 | 70 | 1800 | 2200 | 2.0 | 3.0 | 3.0 | 1.5 | 89 | +0.035 |
| 1N5995 | 6.2 | 5.0 | 10 | 50 | 1300 | 2050 | 1.0 | 2.0 | 4.0 | 2.0 | 81 | +0.04 |
| 1N5996 | 6.8 | 5.0 | 8.0 | 25 | 750 | 1800 | 1.0 | 2.0 | 5.2 | 3.0 | 74 | +0.044 |
| 1N5997 | 7.5 | 5.0 | 7.0 | 10 | 600 | 1300 | 0.5 | 1.0 | 6.0 | 4.0 | 67 | +0.051 |
| 1N5998 | 8.2 | 5.0 | 7.0 | 15 | 600 | 750 | 0.5 | 1.0 | 6.5 | 5.2 | 61 | +0.055 |
| 1N5999 | 9.1 | 5.0 | 10 | 18 | 600 | 600 | 0.1 | 0.5 | 7.0 | 6.0 | 55 | +0.061 |
| 1N6000 | 10 | 5.0 | 15 | 22 | 600 | 600 | 0.1 | 0.5 | 8.0 | 6.5 | 50 | +0.065 |
| 1N6001 | 11 | 5.0 | 18 | 25 | 600 | 600 | 0.1 | 0.1 | 8.4 | 7.0 | 45 | +0.068 |
| 1N6002 | 12 | 5.0 | 22 | 32 | 600 | 600 | 0.1 | 0.1 | 9.1 | 8.0 | 42 | +0.073 |
| 1N6003 | 13 | 5.0 | 25 | 36 | 600 | 600 | 0.1 | 0.1 | 9.9 | 8.4 | 38 | +0.075 |
| 1N6004 | 15 | 5.0 | 32 | 42 | 600 | 600 | 0.1 | 0.1 | 11 | 9.1 | 33 | +0.079 |
| 1N6005 | 16 | 5.0 | 36 | 48 | 600 | 600 | 0.1 | 0.1 | 12 | 9.9 | 31 | +0.080 |
| 1N6006 | 18 | 5.0 | 42 | 55 | 600 | 600 | 0.1 | 0.1 | 14 | 11 | 28 | +0.083 |
| 1N6007 | 20 | 5.0 | 48 | 62 | 600 | 600 | 0.1 | 0.1 | 15 | 12 | 25 | +0.085 |
| 1N6008 | 22 | 5.0 | 55 | 70 | 600 | 600 | 0.1 | 0.1 | 17 | 14 | 23 | +0.087 |
| 1N6009 | 24 | 5.0 | 62 | 78 | 600 | 600 | 0.1 | 0.1 | 18 | 15 | 21 | +0.090 |
| 1N6010 | 27 | 5.0 | 70 | 88 | 600 | 700 | 0.1 | 0.1 | 21 | 17 | 19 | +0.091 |
| 1N6011 | 30 | 5.0 | 78 | 95 | 600 | 700 | 0.1 | 0.1 | 23 | 18 | 17 | +0.093 |
| 1N6012 | 33 | 5.0 | 88 | 110 | 700 | 800 | 0.1 | 0.1 | 25 | 21 | 15 | +0.094 |
| 1N6013 | 36 | 5.0 | 95 | 130 | 700 | 900 | 0.1 | 0.1 | 27 | 23 | 14 | +0.094 |
| 1N6014 | 39 | 2.0 | 130 | 170 | 800 | 1000 | 0.1 | 0.1 | 30 | 25 | 13 | +0.095 |
| 1N6015 | 43 | 2.0 | 150 | 180 | 900 | 1100 | 0.1 | 0.1 | 33 | 27 | 12 | +0.095 |
| 1N6016 | 47 | 2.0 | 170 | 200 | 1000 | 1300 | 0.1 | 0.1 | 36 | 30 | 11 | +0.096 |
| 1N6017 | 51 | 2.0 | 180 | 225 | 1300 | 1400 | 0.1 | 0.1 | 39 | 33 | 9.8 | +0.096 |
| 1N6018 | 56 | 2.0 | 200 | 240 | 1400 | 1600 | 0.1 | 0.1 | 43 | 36 | 8.9 | +0.096 |
| 1N6019 | 62 | 2.0 | 225 | 265 | 1400 | 1700 | 0.1 | 0.1 | 47 | 39 | 8.0 | +0.097 |
| 1N6020 | 68 | 2.0 | 240 | 280 | 1600 | 2000 | 0.1 | 0.1 | 52 | 43 | 7.4 | +0.097 |
| 1N6021 | 75 | 2.0 | 265 | 300 | 1700 | 2300 | 0.1 | 0.1 | 56 | 47 | 6.7 | +0.098 |
| 1N6022 | 82 | 2.0 | 280 | 350 | 2000 | 2600 | 0.1 | 0.1 | 62 | 52 | 6.1 | +0.098 |
| 1N6023 | 91 | 2.0 | 300 | 400 | 2300 | 3000 | 0.1 | 0.1 | 69 | 56 | 5.5 | +0.099 |
| 1N6024 | 100 | 1.0 | 500 | 800 | 2600 | 4000 | 0.1 | 0.1 | 76 | 62 | 5.0 | +0.110 |
| 1N6025 | 110 | 1.0 | 650 | 950 | 3000 | 4500 | 0.1 | 0.1 | 84 | 69 | 4.5 | +0.110 |
| 1N6026 | 120 | 1.0 | 800 | 1250 | 4000 | 5000 | 0.1 | 0.1 | 91 | 76 | 4.2 | +0.110 |
| 1N6027 | 130 | 1.0 | 950 | 1400 | 4500 | 5500 | 0.1 | 0.1 | 99 | 84 | 3.8 | +0.110 |
| 1N6028 | 150 | 1.0 | 1250 | 1700 | 5000 | 6000 | 0.1 | 0.1 | 114 | 91 | 3.3 | +0.110 |
| 1N6029 | 160 | 1.0 | 1400 | 2000 | 5500 | 7000 | 0.1 | 0.1 | 122 | 99 | 3.1 | +0.110 |
| 1N6030 | 180 | 1.0 | 1700 | 2350 | 6000 | 8000 | 0.1 | 0.1 | 137 | 114 | 2.8 | +0.110 |
| 1N6031 | 200 | 1.0 | 2000 | 2700 | 7000 | 9000 | 0.1 | 0.1 | 152 | 122 | 2.5 | +0.110 |

*Indicates JEDEC Registered Data.

1N5985 thru 1N6031

NOTE 1.

Zener impedance is derived from the 1KHz AC voltage which results when an AC current having an rms value equal to 10% of DC zener current (IZT or IZK) is superimposed on IZT or IZK.

NOTE 2.

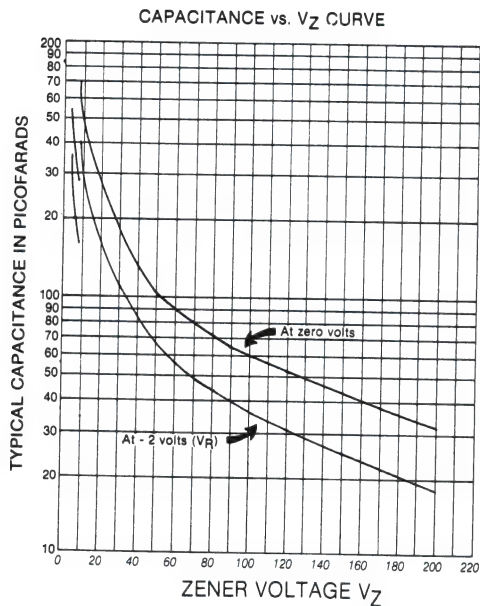
Voltage measurements to be performed 20 seconds after application of the DC test current.

NOTE 3.

The maximum zener current Izm shown is for the nominal voltages. The following formula can be used to determine the worst case current for any tolerance device.

$$I_{zm} = \frac{P}{V_{zm}}$$

Where Vzm is the high end of the voltage tolerance specified and P is the rated power of the device.



1N6309 thru 1N6355

FEATURES

- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- MICROMINIATURE PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED (ABOVE 6.2 VOLTS)
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/533

MAXIMUM RATINGS

Operating Temperature: -65°C to +200°C

Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

| TYPE | V _{Z2} NOM. ±5% @ I _{Z2} | V _{Z1} MIN. @ I _{P1} 250 μA | I _{Z2} TEST CURRENT | Z _Z @ I _{Z2} | Z _{ZK} @ 250 μA | I _{ZM} | V _Z (reg) | I _{ZSM} SURGE | V _R | I _{R1} @ 25°C | I _{R2} @ T _A = 150°C | N _D @ 250 μA 1.3 kHz | αV _Z | C @ 0V |
|--------|---|--|------------------------------------|--|--------------------------------|-----------------|----------------------|---------------------------|----------------|------------------------------|---|---------------------------------------|-----------------|--------------|
| | VOLTS | VOLTS | mA | OHMS | OHMS | mA | VOLTS | AMPS | VOLTS | μA | μA | μV/√Hz | %/°C | pF |
| 1N6309 | 2.4 | 1.1 | 20 | 30 | 1200 | 177 | 1.8 | 2.5 | 1.0 | 100 | 200 | 1.0 | -085 | 2000 |
| 1N6310 | 2.7 | 1.2 | 20 | 30 | 1300 | 157 | 1.8 | 2.2 | 1.0 | 60 | 150 | 1.0 | -080 | 1900 |
| 1N6311 | 3.0 | 1.3 | 20 | 29 | 1400 | 141 | 1.8 | 2.0 | 1.0 | 30 | 100 | 1.0 | -075 | 1800 |
| 1N6312 | 3.3 | 1.5 | 20 | 24 | 1400 | 128 | 1.8 | 1.8 | 1.0 | 5.0 | 20 | 1.0 | -065 | 1650 |
| 1N6313 | 3.6 | 1.8 | 20 | 22 | 1400 | 109 | 1.8 | 1.65 | 1.0 | 3.0 | 12 | 1.0 | -055 | 1600 |
| 1N6314 | 3.9 | 2.0 | 20 | 20 | 1700 | 118 | 1.8 | 1.5 | 1.0 | 2.0 | 12 | 1.0 | -043 | 1400 |
| 1N6315 | 4.3 | 2.4 | 20 | 18 | 1400 | 99 | 0.9 | 1.4 | 1.0 | 2.0 | 12 | 1.0 | -030 | 1350 |
| 1N6316 | 4.7 | 2.8 | 20 | 16 | 1500 | 90 | 0.5 | 1.27 | 1.5 | 5.0 | 12 | 1.0 | -028 | 1300 |
| 1N6317 | 5.1 | 3.3 | 20 | 14 | 1300 | 83 | 0.4 | 1.17 | 2.0 | 5.0 | 12 | 1.0 | +045 | 1200 |
| 1N6318 | 5.6 | 4.3 | 20 | 8.0 | 1200 | 76 | 0.4 | 1.10 | 2.5 | 5.0 | 10 | 2.0 | +050 | 1150 |
| 1N6319 | 6.2 | 5.2 | 20 | 3.0 | 800 | 68 | 0.3 | 0.97 | 3.5 | 5.0 | 10 | 5.0 | 0.60 | 1050 |
| 1N6320 | 6.8 | 6.0 | 20 | 3.0 | 400 | 63 | 0.35 | 1.23 | 4.0 | 2.0 | 10 | 5.0 | 0.62 | 500 |
| 1N6321 | 7.5 | 6.6 | 20 | 4.0 | 400 | 57 | 0.4 | 1.16 | 5.0 | 2.0 | 10 | 5.0 | 0.68 | 900 |
| 1N6322 | 8.2 | 7.5 | 20 | 5.0 | 400 | 52 | 0.4 | 1.07 | 6.0 | 1.0 | 10 | 20 | 0.75 | 800 |
| 1N6323 | 9.1 | 8.4 | 20 | 6.0 | 500 | 47 | 0.5 | 0.97 | 7.0 | 1.0 | 10 | 40 | 0.76 | 700 |
| 1N6324 | 10 | 9.1 | 20 | 6.0 | 500 | 43 | 0.5 | .89 | 8.0 | 1.0 | 10 | 80 | 0.79 | 600 |
| 1N6325 | 11 | 10 | 20 | 7.0 | 550 | 39 | 0.5 | .83 | 8.5 | 1.0 | 10 | 100 | 0.82 | 500 |
| 1N6326 | 12 | 11 | 20 | 7.0 | 550 | 35 | 0.55 | .77 | 9.0 | 1.0 | 10 | 100 | 0.83 | 450 |
| 1N6327 | 13 | 11.9 | 9.5 | 8.0 | 550 | 33 | 0.55 | 0.71 | 9.9 | .05 | 10 | 100 | 0.79 | 400 |
| 1N6328 | 15 | 13.8 | 8.5 | 10 | 600 | 28 | .70 | .62 | 11 | .05 | 10 | 100 | 0.82 | 350 |
| 1N6329 | 16 | 14.7 | 7.8 | 12 | 600 | 27 | .75 | .58 | 12 | .05 | 10 | 100 | 0.83 | 325 |
| 1N6330 | 18 | 16.6 | 7.0 | 14 | 600 | 24 | .85 | .52 | 14 | .05 | 10 | 100 | 0.85 | 300 |
| 1N6331 | 20 | 18.5 | 6.2 | 18 | 500 | 21 | .95 | .47 | 15 | .05 | 10 | 100 | 0.88 | 275 |
| 1N6332 | 22 | 20.4 | 5.6 | 20 | 500 | 19 | 1.05 | .43 | 17 | .05 | 10 | 100 | 0.87 | 260 |
| 1N6333 | 24 | 22.3 | 5.2 | 24 | 500 | 18 | 1.15 | .39 | 18 | .05 | 10 | 100 | 0.88 | 240 |
| 1N6334 | 27 | 25.2 | 4.6 | 27 | 500 | 16 | 1.30 | .35 | 21 | .05 | 10 | 100 | +090 | 220 |
| 1N6335 | 30 | 29 | 4.2 | 32 | 500 | 14 | 1.45 | .31 | 23 | .05 | 10 | 100 | .091 | 200 |
| 1N6336 | 33 | 30.9 | 3.8 | 40 | 600 | 13 | 1.60 | .28 | 25 | .05 | 10 | 100 | .092 | 185 |
| 1N6337 | 36 | 33.7 | 3.4 | 50 | 600 | 12 | 1.75 | .26 | 27 | .05 | 10 | 100 | .093 | 175 |
| 1N6338 | 39 | 36.6 | 3.2 | 55 | 700 | 11 | 1.90 | .24 | 30 | .05 | 10 | 100 | .094 | 170 |
| 1N6339 | 43 | 40.4 | 3.0 | 65 | 800 | 9.9 | 2.10 | .22 | 33 | .05 | 10 | 80 | .095 | 165 |
| 1N6340 | 47 | 44.2 | 2.7 | 75 | 900 | 9.0 | 2.25 | .20 | 36 | .05 | 10 | 80 | .095 | 155 |
| 1N6341 | 51 | 48 | 2.5 | 85 | 1000 | 8.3 | 2.50 | .18 | 39 | .05 | 10 | 80 | .096 | 145 |
| 1N6342 | 56 | 52.7 | 2.2 | 100 | 1200 | 7.6 | 2.70 | .17 | 43 | .05 | 10 | 80 | .097 | 135 |
| 1N6343 | 62 | 58.4 | 2.0 | 125 | 1300 | 6.8 | 2.90 | .15 | 47 | .05 | 10 | 80 | .097 | 130 |
| 1N6344 | 68 | 64.1 | 1.8 | 155 | 1500 | 6.3 | 3.20 | .13 | 52 | .05 | 10 | 80 | .098 | 120 |
| 1N6345 | 75 | 70.8 | 1.7 | 180 | 1600 | 5.7 | 3.40 | .125 | 56 | .05 | 10 | 80 | .098 | 110 |
| 1N6346 | 82 | 77.4 | 1.5 | 220 | 1800 | 5.2 | 3.80 | .115 | 62 | .05 | 10 | 80 | .099 | 105 |
| 1N6347 | 91 | 86 | 1.4 | 270 | 2100 | 4.7 | 4.20 | .100 | 69 | 0.05 | 10 | 80 | .099 | 100 |
| 1N6348 | 100 | 94.5 | 1.3 | 340 | 2400 | 4.3 | 4.40 | .095 | 76 | 0.05 | 10 | 80 | .110 | 95 |
| 1N6349 | 110 | 104 | 1.1 | 500 | 2800 | 3.9 | 4.80 | .085 | 84 | 0.05 | 10 | 80 | .110 | 90 |
| 1N6350 | 120 | 113 | 1.0 | 600 | 3200 | 3.5 | 5.20 | .080 | 91 | 0.05 | 10 | 80 | .110 | 70 |
| 1N6351 | 130 | 122 | 0.95 | 850 | 4100 | 3.3 | 5.60 | .070 | 99 | 0.05 | 10 | 80 | .110 | 65 |
| 1N6352 | 150 | 141 | .85 | 1000 | 4500 | 2.8 | 7.00 | .065 | 114 | 0.05 | 10 | 80 | .110 | 60 |
| 1N6353 | 160 | 151 | .80 | 1200 | 5000 | 2.7 | 7.50 | .060 | 122 | 0.05 | 10 | 80 | .110 | 60 |
| 1N6354 | 180 | 170 | .68 | 1500 | 5600 | 2.4 | 9.00 | .050 | 137 | 0.05 | 10 | 80 | .110 | 55 |
| 1N6355 | 200 | 189 | .65 | 1800 | 6500 | 2.1 | 12.0 | .045 | 152 | 0.05 | 10 | 80 | .110 | 55 |

REGULATOR DIODES

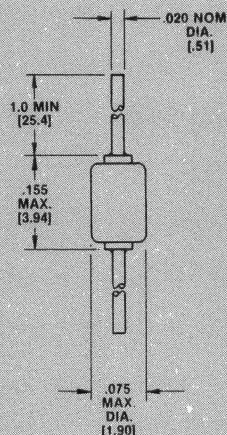


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed hard glass.

LEAD MATERIAL: Copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N6309 thru 1N6355



FIGURE 2. MAXIMUM POWER VS. LEAD TEMPERATURE

1EZ110D5 thru 1EZ200D5

FEATURES

- ZENER VOLTAGE 110 V TO 200 V
- WITHSTANDS LARGE SURGE STRESSES
- ALSO AVAILABLE IN GLASS. [See Note 6.]

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +175°C

DC Power Dissipation: 1 Watt

Power Derating: 13.3 mW/°C above 100°C

Forward Voltage @ 200 mA: 1.2 volts

ELECTRICAL CHARACTERISTICS @ 25°C

| MICRO TYPE NUMBER Note 1 | NOMINAL ZENER VOLTAGE (Note 2 & 5) | | MAXIMUM ZENER IMPEDANCE Note 3 | | | MAXIMUM RATED ZENER CURRENT @ 100°C | TYPICAL TEMP. COEF. OF ZENER VOLTAGE | MAXIMUM SURGE CURRENT I _s |
|-----------------------------------|--|-----|--------------------------------------|-----------------------------------|------|---|--|---|
| | V _Z @ I _{ZT} | | Z _{KT} @ I _{ZT} | Z _{KK} @ I _{ZK} | | I _{ZM} | | |
| | VOLTS | mA | OHMS | OHMS | mA | mA | %/°C | A |
| 1EZ110D5 | 110 | 2.3 | 570 | 5200 | 0.25 | 8.3 | +0.095 | 0.15 |
| 1EZ120D5 | 120 | 2.0 | 710 | 5800 | 0.25 | 8.0 | +0.095 | 0.14 |
| 1EZ130D5 | 130 | 1.9 | 910 | 6500 | 0.25 | 6.9 | +0.095 | 0.13 |
| 1EZ140D5 | 140 | 1.8 | 1100 | 7000 | 0.25 | 6.5 | +0.095 | 0.12 |
| 1EZ150D5 | 150 | 1.7 | 1300 | 7500 | 0.25 | 5.7 | +0.095 | 0.12 |
| 1EZ160D5 | 160 | 1.6 | 1400 | 8000 | 0.25 | 5.4 | +0.095 | 0.11 |
| 1EZ170D5 | 170 | 1.5 | 1450 | 8500 | 0.25 | 5.2 | +0.095 | 0.10 |
| 1EZ180D5 | 180 | 1.4 | 1500 | 9000 | 0.25 | 4.9 | +0.095 | 0.10 |
| 1EZ190D5 | 190 | 1.3 | 1700 | 9500 | 0.25 | 4.7 | +0.095 | 0.10 |
| 1EZ200D5 | 200 | 1.2 | 1900 | 10000 | 0.25 | 4.6 | +0.100 | 0.10 |

NOTE 1 Suffix 5 indicates ± 5% tolerance. Suffix 10 indicates ± 10%, no suffix indicates ± 20%. Also, Suffix 1 indicates ± 1%, 2nd suffix 2 indicates ± 2% on V_Z tolerance.

NOTE 2 Zener Voltage (V_Z) is measured in still air at a temperature of 25°C. The test currents (I_{ZT}) have been selected so that at nominal voltages the dissipation is a constant 0.25 watts. This results in a nominal junction temperature rise of 10°C.

NOTE 3 The Zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK}.

NOTE 4 Maximum Surge Current is a non recurrent maximum peak reverse surge with a pulse width of 8.3 milliseconds at T_A 25°C (+8, -2°)C.

NOTE 5 Voltage measurements to be performed 90 seconds after application of DC current.

SILICON 1 WATT ZENER DIODE

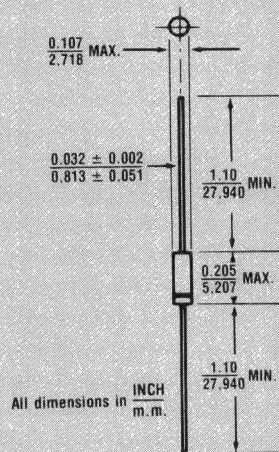


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Molded encapsulation, axial lead package (Case J).

FINISH: Corrosion resistant. Leads are solderable.

THERMAL RESISTANCE: 75°C/Watt.

POLARITY: Banded end is cathode.

WEIGHT: 0.4 grams (Typical).

1EZ110D5 THRU 1EZ200D5

NOTE 6 Glass devices ordered by replacing E in the series type number with G.
Example: 1GZ110D5

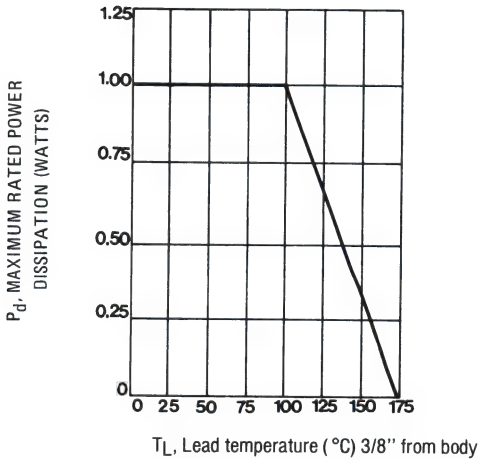
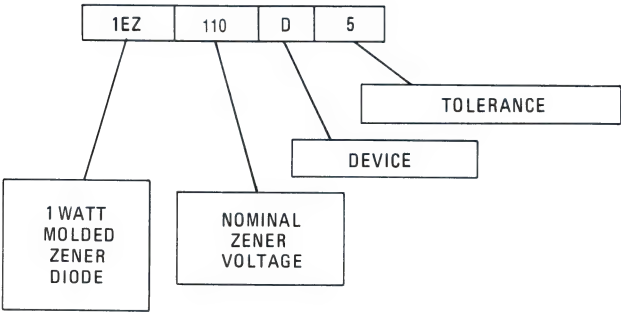


FIGURE 2 POWER DERATING CURVE

2EZ3.6D5 THRU 2EZ200D5

FEATURES

- ZENER VOLTAGE 3.6 to 200V
- HIGH SURGE CURRENT RATING
- 2 WATTS DISSIPATION IN A NORMALLY 1 WATT PACKAGE

MAXIMUM RATINGS

Junction and Storage Temperature: -65°C to +175°C

DC Power Dissipation: 2 Watts

Power Derating: 20 mW/°C above 75°C

Forward Voltage @ 200 mA: 1.2 volts

ELECTRICAL CHARACTERISTICS @ 25°C

| MICRO TYPE NUMBER (Note 1) | NOMINAL ZENER VOLTAGE (Note 2) | | MAXIMUM ZENER IMPEDANCE (Note 1) | | | MAXIMUM REVERSE LEAKAGE CURRENT | | MAXIMUM ZENER CURRENT | MAXIMUM SURGE CURRENT (Note 4) |
|-------------------------------------|--------------------------------------|-------|--|-------------------|------|------------------------------------|-------|-----------------------------|---|
| | V_Z | I_Z | $Z_{ZT} @ I_{ZT}$ | $Z_{ZK} @ I_{ZK}$ | | $I_k @ V_k$ | | I_{ZM} | I_{SURGE} |
| | VOLTS | mA | OHMS | OHMS | mA | μA | VOLTS | mA | A |
| 2EZ3.6D5 | 3.6 | 139 | 5.0 | 400 | 1.0 | 80 | 1.0 | 504 | 4.6 |
| 2EZ3.9D5 | 3.9 | 128 | 5.0 | 400 | 1.0 | 30 | 1.0 | 468 | 4.4 |
| 2EZ4.3D5 | 4.3 | 116 | 4.5 | 400 | 1.0 | 20 | 1.0 | 434 | 4.1 |
| 2EZ4.7D5 | 4.7 | 106 | 4.5 | 550 | 1.0 | 5.0 | 1.0 | 386 | 3.3 |
| 2EZ5.1D5 | 5.1 | 98 | 3.5 | 600 | 1.0 | 5.0 | 1.0 | 356 | 3.5 |
| 2EZ5.6D5 | 5.6 | 89.5 | 2.5 | 500 | 1.0 | 5.0 | 2.0 | 324 | 3.3 |
| 2EZ6.2D5 | 6.2 | 80.5 | 1.5 | 700 | 1.0 | 5.0 | 3.0 | 292 | 3.1 |
| 2EZ6.8D5 | 6.8 | 73.5 | 2.0 | 700 | 1.0 | 5.0 | 4.0 | 266 | 2.9 |
| 2EZ7.5D5 | 7.5 | 66.5 | 2.0 | 700 | 0.5 | 5.0 | 5.0 | 242 | 2.66 |
| 2EZ8.2D5 | 8.2 | 61 | 2.3 | 700 | 0.5 | 5.0 | 6.0 | 220 | 2.44 |
| 2EZ9.1D5 | 9.1 | 55 | 2.5 | 700 | 0.5 | 3.0 | 7.0 | 200 | 2.2 |
| 2EZ10D5 | 10 | 50 | 3.5 | 700 | 0.25 | 3.0 | 7.6 | 182 | 2.0 |
| 2EZ11D5 | 11 | 45.5 | 4.0 | 700 | 0.25 | 1.0 | 8.4 | 166 | 1.82 |
| 2EZ12D5 | 12 | 41.5 | 4.5 | 700 | 0.25 | 1.0 | 9.1 | 152 | 1.66 |
| 2EZ13D5 | 13 | 38.5 | 5.0 | 700 | 0.25 | 0.5 | 9.9 | 138 | 1.54 |
| 2EZ14D5 | 14 | 35.7 | 5.5 | 700 | 0.25 | 0.5 | 10.6 | 130 | 1.43 |
| 2EZ15D5 | 15 | 33.4 | 7.0 | 700 | 0.25 | 0.5 | 11.4 | 122 | 1.33 |
| 2EZ16D5 | 16 | 31.2 | 8.0 | 700 | 0.25 | 0.5 | 12.2 | 114 | 1.25 |
| 2EZ17D5 | 17 | 29.4 | 9.0 | 750 | 0.25 | 0.5 | 13.0 | 107 | 1.18 |
| 2EZ18D5 | 18 | 27.8 | 10 | 750 | 0.25 | 0.5 | 13.7 | 100 | 1.11 |
| 2EZ19D5 | 19 | 26.3 | 11 | 750 | 0.25 | 0.5 | 14.4 | 95 | 1.05 |
| 2EZ20D5 | 20 | 25 | 11 | 750 | 0.25 | 0.5 | 15.2 | 90 | 1.0 |
| 2EZ22D5 | 22 | 22.8 | 12 | 750 | 0.25 | 0.5 | 16.7 | 82 | 0.91 |
| 2EZ24D5 | 24 | 20.8 | 13 | 750 | 0.25 | 0.5 | 18.2 | 76 | 0.83 |
| 2EZ27D5 | 27 | 18.5 | 18 | 750 | 0.25 | 0.5 | 20.6 | 68 | 0.74 |
| 2EZ30D5 | 30 | 16.6 | 20 | 1000 | 0.25 | 0.5 | 22.5 | 60 | 0.67 |
| 2EZ33D5 | 33 | 15.1 | 23 | 1000 | 0.25 | 0.5 | 25.1 | 55 | 0.61 |
| 2EZ36D5 | 36 | 13.9 | 25 | 1000 | 0.25 | 0.5 | 27.4 | 50 | 0.56 |
| 2EZ39D5 | 39 | 12.8 | 30 | 1000 | 0.25 | 0.5 | 29.7 | 47 | 0.51 |
| 2EZ43D5 | 43 | 11.6 | 35 | 1500 | 0.25 | 0.5 | 32.7 | 43 | 0.45 |
| 2EZ47D5 | 47 | 10.6 | 40 | 1500 | 0.25 | 0.5 | 35.8 | 39 | 0.42 |
| 2EZ51D5 | 51 | 9.8 | 48 | 1500 | 0.25 | 0.5 | 38.8 | 36 | 0.39 |
| 2EZ56D5 | 56 | 9.0 | 55 | 2000 | 0.25 | 0.5 | 42.6 | 32 | 0.36 |
| 2EZ62D5 | 62 | 8.1 | 60 | 2000 | 0.25 | 0.5 | 47.1 | 29 | 0.32 |
| 2EZ68D5 | 68 | 7.4 | 75 | 2000 | 0.25 | 0.5 | 51.7 | 27 | 0.29 |
| 2EZ75D5 | 75 | 6.7 | 90 | 2000 | 0.25 | 0.5 | 56 | 24 | 0.27 |
| 2EZ82D5 | 82 | 6.1 | 100 | 3000 | 0.25 | 0.5 | 62.2 | 22 | 0.24 |
| 2EZ91D5 | 91 | 5.5 | 125 | 3000 | 0.25 | 0.5 | 69.2 | 20 | 0.22 |
| 2EZ100D5 | 100 | 5.0 | 175 | 3000 | 0.25 | 0.5 | 76.0 | 18 | 0.20 |
| 2EZ110D5 | 110 | 4.5 | 250 | 4000 | 0.25 | 0.5 | 83.6 | 17 | 0.18 |
| 2EZ120D5 | 120 | 4.2 | 325 | 4500 | 0.25 | 0.5 | 91.2 | 15 | 0.16 |
| 2EZ130D5 | 130 | 3.8 | 400 | 5000 | 0.25 | 0.5 | 98.8 | 14 | 0.15 |
| 2EZ140D5 | 140 | 3.6 | 500 | 5500 | 0.25 | 0.5 | 106.4 | 13 | 0.14 |
| 2EZ150D5 | 150 | 3.3 | 575 | 6000 | 0.25 | 0.5 | 114 | 12 | 0.13 |
| 2EZ160D5 | 160 | 3.1 | 650 | 6500 | 0.25 | 0.5 | 121.6 | 11 | 0.12 |
| 2EZ170D5 | 170 | 2.9 | 675 | 7000 | 0.25 | 0.5 | 130.4 | 11 | 0.12 |
| 2EZ180D5 | 180 | 2.8 | 725 | 7000 | 0.25 | 0.5 | 136.8 | 10 | 0.11 |
| 2EZ190D5 | 190 | 2.6 | 825 | 8000 | 0.25 | 0.5 | 144.8 | 10 | 0.10 |
| 2EZ200D5 | 200 | 2.5 | 900 | 8000 | 0.25 | 0.5 | 152 | 9 | 0.10 |

SILICON 2 WATT ZENER DIODE

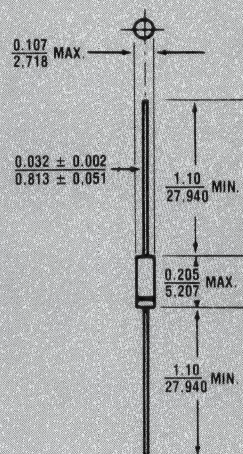


FIGURE 1

All dimensions in $\frac{\text{INCH}}{\text{m.m.}}$

MECHANICAL CHARACTERISTICS

CASE: Molded encapsulation, axial lead package (Case J).

FINISH: Corrosion resistant. Leads are solderable.

THERMAL RESISTANCE: 45°C/Watt.

POLARITY: Banded end is cathode.

WEIGHT: 0.4 grams (Typical).

2EZ3.6D5 THRU 2EZ200D5

NOTE 1 Suffix 5 indicates $\pm 5\%$ tolerance. Suffix 10 indicates $\pm 10\%$, no suffix indicates $\pm 20\%$. Also, Suffix 1 indicates $\pm 1\%$, 2nd suffix 2 indicates $\pm 2\%$ on V_Z tolerance.

NOTE 2 V_Z measured after allowing a 90 sec. stabilization period when mounted with a $\frac{3}{8}$ " minimum lead length from case.

NOTE 3 Dynamic Impedance, Z_Z , determined by superimposing 1 ac rms at 60 hz on I_{DC} where $I_{ac\ rms} = 10\% I_{DC}$.

NOTE 4 Maximum surge current is a maximum peak non-recurrent reverse surge with a maximum pulse width of 8.3 milliseconds.

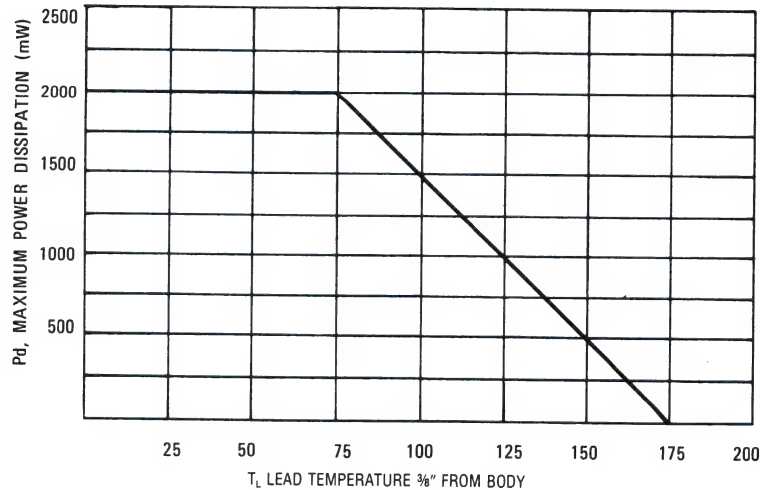
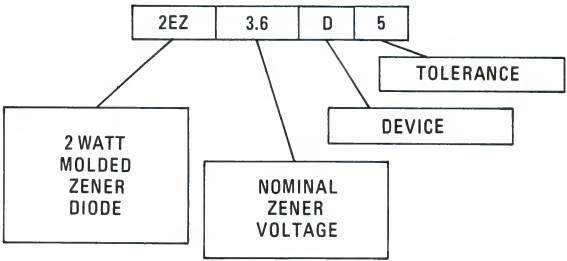


FIGURE 2 POWER DERATING CURVE

3EZ3.9D5 thru 3EZ200D5

FEATURES

- ZENER VOLTAGE 3.9V to 200V
- HIGH SURGE CURRENT RATING
- 3 WATTS DISSIPATION IN A NORMALLY 1 WATT PACKAGE

MAXIMUM RATINGS

Junction and Storage Temperature: -65°C to +175°C

DC Power Dissipation: 3 Watts

Power Derating: 20 mW/°C above 25°C

Forward Voltage @ 200 mA: 1.2 volts

ELECTRICAL CHARACTERISTICS @ 25°C

| MICRO TYPE NUMBER (Note 1) | NOMINAL ZENER VOLTAGE (Note 2) | | MAXIMUM ZENER IMPEDANCE (Note 3) | | | MAXIMUM REVERSE LEAKAGE CURRENT | | MAXIMUM ZENER CURRENT | MAXIMUM SURGE CURRENT (Note 4) |
|-------------------------------------|--------------------------------------|----------------|--|-----------------------------------|---------------------------------|------------------------------------|-------|-----------------------------|---|
| | V _Z | I _Z | Z ₀₇ @ I _{ZT} | Z _{0K} @ I _{ZK} | I _L @ V _L | I _L @ V _L | | I _{ZM} | I _{SR} |
| | VOLTS | mA | OHMS | OHMS | | μA | VOLTS | mA | A |
| 3EZ3.9D5 | 3.9 | 192 | 4.5 | 400 | 1.0 | 80 | 1.0 | 630 | 4.4 |
| 3EZ4.3D5 | 4.3 | 174 | 4.5 | 400 | 1.0 | 30 | 1.0 | 590 | 4.1 |
| 3EZ4.7D5 | 4.7 | 160 | 4.0 | 500 | 1.0 | 20 | 1.0 | 550 | 3.8 |
| 3EZ5.1D5 | 5.1 | 147 | 3.5 | 550 | 1.0 | 5.0 | 1.0 | 520 | 3.5 |
| 3EZ5.6D5 | 5.6 | 134 | 2.5 | 600 | 1.0 | 5.0 | 2.0 | 480 | 3.3 |
| 3EZ6.2D5 | 6.2 | 121 | 1.5 | 700 | 1.0 | 5.0 | 3.0 | 435 | 3.1 |
| 3EZ6.8D5 | 6.8 | 110 | 2.0 | 700 | 1.0 | 5.0 | 4.0 | 393 | 2.9 |
| 3EZ7.5D5 | 7.5 | 100 | 2.0 | 700 | 0.5 | 5.0 | 5.0 | 360 | 2.66 |
| 3EZ8.2D5 | 8.2 | 91 | 2.3 | 700 | 0.5 | 5.0 | 6.0 | 330 | 2.44 |
| 3EZ9.1D5 | 9.1 | 82 | 2.5 | 700 | 0.5 | 3.0 | 7.0 | 297 | 2.2 |
| 3EZ10D5 | 10 | 75 | 3.5 | 700 | 0.25 | 3.0 | 7.6 | 270 | 2.0 |
| 3EZ11D5 | 11 | 68 | 4.0 | 700 | 0.25 | 1.0 | 8.4 | 225 | 1.82 |
| 3EZ12D5 | 12 | 63 | 4.5 | 700 | 0.25 | 1.0 | 9.1 | 246 | 1.66 |
| 3EZ13D5 | 13 | 58 | 4.5 | 700 | 0.25 | 0.5 | 9.9 | 208 | 1.54 |
| 3EZ14D5 | 14 | 53 | 5.0 | 700 | 0.25 | 0.5 | 10.6 | 193 | 1.43 |
| 3EZ15D5 | 15 | 50 | 5.5 | 700 | 0.25 | 0.5 | 11.4 | 180 | 1.33 |
| 3EZ16D5 | 16 | 47 | 5.5 | 700 | 0.25 | 0.5 | 12.2 | 169 | 1.25 |
| 3EZ17D5 | 17 | 44 | 6.0 | 750 | 0.25 | 0.5 | 13 | 150 | 1.18 |
| 3EZ18D5 | 18 | 42 | 6.0 | 750 | 0.25 | 0.5 | 13.7 | 159 | 1.11 |
| 3EZ19D5 | 19 | 40 | 7.0 | 750 | 0.25 | 0.5 | 14.4 | 142 | 1.05 |
| 3EZ20D5 | 20 | 37 | 7.0 | 750 | 0.25 | 0.5 | 15.2 | 135 | 1.0 |
| 3EZ22D5 | 22 | 34 | 8.0 | 750 | 0.25 | 0.5 | 16.7 | 123 | 0.91 |
| 3EZ24D5 | 24 | 31 | 9.0 | 750 | 0.25 | 0.5 | 18.2 | 112 | 0.83 |
| 3EZ27D5 | 27 | 28 | 10 | 750 | 0.25 | 0.5 | 20.6 | 100 | 0.74 |
| 3EZ28D5 | 28 | 27 | 12 | 750 | 0.25 | 0.5 | 21 | 96 | 0.71 |
| 3EZ30D5 | 30 | 25 | 16 | 1000 | 0.25 | 0.5 | 22.5 | 90 | 0.67 |
| 3EZ33D5 | 33 | 23 | 20 | 1000 | 0.25 | 0.5 | 25.1 | 82 | 0.61 |
| 3EZ36D5 | 36 | 21 | 22 | 1000 | 0.25 | 0.5 | 27.4 | 75 | 0.56 |
| 3EZ39D5 | 39 | 19 | 28 | 1000 | 0.25 | 0.5 | 29.7 | 69 | 0.51 |
| 3EZ43D5 | 43 | 17 | 33 | 1500 | 0.25 | 0.5 | 32.7 | 63 | 0.45 |
| 3EZ47D5 | 47 | 16 | 38 | 1500 | 0.25 | 0.5 | 35.6 | 57 | 0.42 |
| 3EZ51D5 | 51 | 15 | 45 | 1500 | 0.25 | 0.5 | 38.8 | 53 | 0.39 |
| 3EZ56D5 | 56 | 13 | 50 | 2000 | 0.25 | 0.5 | 42.6 | 48 | 0.36 |
| 3EZ62D5 | 62 | 12 | 55 | 2000 | 0.25 | 0.5 | 47.1 | 44 | 0.32 |
| 3EZ68D5 | 68 | 11 | 70 | 2000 | 0.25 | 0.5 | 51.7 | 40 | 0.29 |
| 3EZ75D5 | 75 | 10 | 85 | 2000 | 0.25 | 0.5 | 56 | 36 | 0.27 |
| 3EZ82D5 | 82 | 9.1 | 95 | 3000 | 0.25 | 0.5 | 62.2 | 33 | 0.24 |
| 3EZ91D5 | 91 | 8.2 | 115 | 3000 | 0.25 | 0.5 | 69.2 | 30 | 0.22 |
| 3EZ100D5 | 100 | 7.5 | 160 | 3000 | 0.25 | 0.5 | 76 | 27 | 0.20 |
| 3EZ110D5 | 110 | 6.8 | 225 | 4000 | 0.25 | 0.5 | 83.6 | 25 | 0.18 |
| 3EZ120D5 | 120 | 6.3 | 300 | 4500 | 0.25 | 0.5 | 91.2 | 22 | 0.16 |
| 3EZ130D5 | 130 | 5.8 | 375 | 5000 | 0.25 | 0.5 | 98.8 | 21 | 0.15 |
| 3EZ140D5 | 140 | 5.3 | 475 | 5000 | 0.25 | 0.5 | 106.4 | 19 | 0.14 |
| 3EZ150D5 | 150 | 5.0 | 550 | 6000 | 0.25 | 0.5 | 114 | 18 | 0.13 |
| 3EZ160D5 | 160 | 4.7 | 625 | 6500 | 0.25 | 0.5 | 121.6 | 17 | 0.12 |
| 3EZ170D5 | 170 | 4.4 | 650 | 7000 | 0.25 | 0.5 | 130.4 | 16 | 0.12 |
| 3EZ180D5 | 180 | 4.2 | 700 | 7000 | 0.25 | 0.5 | 136.8 | 15 | 0.11 |
| 3EZ190D5 | 190 | 4.0 | 800 | 8000 | 0.25 | 0.5 | 144.8 | 14 | 0.10 |
| 3EZ200D5 | 200 | 3.7 | 875 | 8000 | 0.25 | 0.5 | 152 | 13 | 0.10 |

SILICON 3 WATT ZENER DIODE

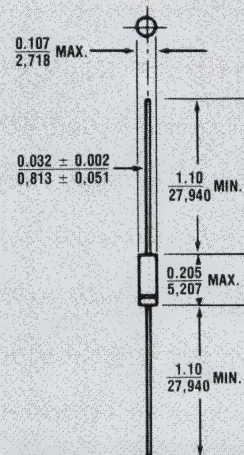


FIGURE 1

All dimensions in
INCH
m. m.

MECHANICAL CHARACTERISTICS

CASE: Molded encapsulation, axial lead package (Case J).

FINISH: Corrosion resistant. Leads are solderable.

THERMAL RESISTANCE: 45°C/Watt junction to lead at 0.375 inches from body.

POLARITY: Banded end is cathode.

WEIGHT: 0.4 grams (Typical).

3EZ3.9D5 thru 3EZ200D5

- NOTE 1** Suffix 1 indicates $\pm 1\%$ tolerance. Suffix 2 indicates $\pm 2\%$ tolerance. Suffix 3 indicates $\pm 3\%$ tolerance. Suffix 4 indicates $\pm 4\%$ tolerance. Suffix 5 indicates $\pm 5\%$ tolerance. Suffix 10 indicates $\pm 10\%$, no suffix indicates $\pm 20\%$.
- NOTE 2** V_Z measured by applying I_Z 40ms ± 10 ms prior to reading. Mounting contacts are located 3/8" to 1/2" from inside edge of mounting clips. Ambient temperature, $T_A = 25^\circ\text{C}$ ($+8^\circ\text{C}/-2^\circ\text{C}$).
- NOTE 3** Dynamic Impedance, Z_Z , measured by superimposing I_{ac} rms at 60 hz on I_{DC} where I_{ac} rms = 10% I_{DC} .
- NOTE 4** Maximum surge current is a maximum peak non-recurrent reverse surge with a maximum pulse width of 8.3 milliseconds.

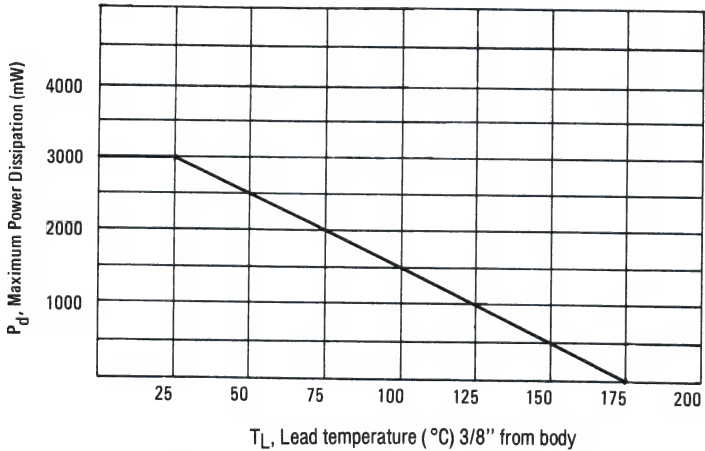
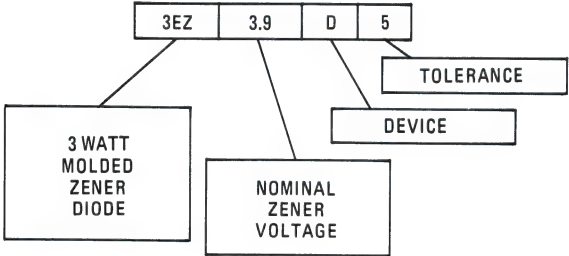


FIGURE 2 POWER DERATING CURVE

micro

Microsemi Corp.

The diode experts

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

MZ5806 thru MZ5891 and MZ5210 thru MZ5240

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- HIGH PERFORMANCE CHARACTERISTICS
- VERY LOW THERMAL IMPEDANCE

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C

Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

| TYPE | ELECTRICAL SPECIFICATIONS AT 25°C | | | | | | | | | | MAXIMUM RATINGS | |
|--------|---|---------------------------------|----------------------------------|-----------------------|------------|---|----------------|--|---|----------------------------------|-----------------|--|
| | NOMINAL ZENER VOLTAGE V _Z @ I _{ZT} | TEST CURRENT I _{ZT} | MAXIMUM ZENER IMPEDANCE | | REGULATION | MAXIMUM REVERSE LEAKAGE CURRENT VOLTAGE | | MAXIMUM TEMPERATURE COEFF. T _C @ I _{ZT} | MAXIMUM CONTINUOUS CURRENT I _{ZM} | SURGE CURRENT I _{SM} | | |
| | | | Z _Z @ I _{ZT} | Z _{ZK} @ 1mA | | I _g | V _g | | | | | |
| | | | OHMS | OHMS | | μA | VOLTS | | | | | |
| 10% | VOLTS | mA | OHMS | OHMS | VOLTS | μA | VOLTS | %/°C | mA | AMPS | | |
| MZ5806 | 6.8 | 175 | 1.0 | 1000 | 0.7 | 300 | 5.2 | .05 | 700 | 40 | | |
| MZ5807 | 7.5 | 175 | 1.5 | 800 | 0.7 | 200 | 5.7 | .06 | 630 | 32 | | |
| MZ5808 | 8.2 | 150 | 1.5 | 600 | 0.7 | 100 | 6.2 | .06 | 580 | 24 | | |
| MZ5809 | 9.1 | 150 | 2.0 | 400 | 0.7 | 50 | 6.9 | .06 | 520 | 22 | | |
| MZ5810 | 10.0 | 125 | 2.0 | 125 | 0.8 | 25 | 7.6 | .07 | 475 | 20 | | |
| MZ5811 | 11 | 125 | 2.5 | 130 | 0.8 | 15 | 8.4 | .07 | 430 | 19 | | |
| MZ5812 | 12 | 100 | 2.5 | 140 | 0.8 | 10 | 9.1 | .07 | 395 | 18 | | |
| MZ5813 | 13 | 100 | 3.0 | 145 | 0.8 | 10 | 9.9 | .08 | 365 | 16 | | |
| MZ5814 | 14 | 100 | 3.0 | 145 | 0.9 | 10 | 11.2 | .08 | 320 | 14 | | |
| MZ5815 | 15 | 75 | 3.5 | 150 | 1.0 | 5 | 11.4 | .08 | 315 | 12 | | |
| MZ5816 | 16 | 75 | 3.5 | 155 | 1.1 | 5 | 12.2 | .08 | 294 | 10 | | |
| MZ5818 | 18 | 65 | 4.0 | 160 | 1.2 | 5 | 13.7 | .085 | 264 | 9.0 | | |
| MZ5820 | 20 | 65 | 4.5 | 165 | 1.5 | 2 | 15.2 | .085 | 237 | 8.0 | | |
| MZ5822 | 22 | 50 | 5.0 | 170 | 1.8 | 2 | 16.7 | .085 | 216 | 7.0 | | |
| MZ5824 | 24 | 50 | 5.0 | 175 | 2.0 | 2 | 18.2 | .090 | 198 | 6.5 | | |
| MZ5827 | 27 | 50 | 6.0 | 180 | 2.0 | 2 | 20.6 | .090 | 176 | 6.0 | | |
| MZ5830 | 30 | 40 | 8 | 190 | 2.5 | 2 | 22.8 | .090 | 158 | 5.5 | | |
| MZ5833 | 33 | 40 | 10 | 200 | 2.8 | 2 | 25.1 | .095 | 144 | 5.0 | | |
| MZ5836 | 36 | 30 | 11 | 220 | 3.0 | 2 | 27.4 | .095 | 132 | 4.5 | | |
| MZ5839 | 39 | 30 | 14 | 230 | 3.0 | 2 | 29.7 | .095 | 122 | 4.0 | | |
| MZ5840 | 40 | 30 | 14 | 230 | 3.0 | 2 | 30.4 | .095 | 116 | 4.0 | | |
| MZ5843 | 43 | 30 | 20 | 240 | 3.3 | 2 | 32.7 | .095 | 110 | 3.5 | | |
| MZ5845 | 45 | 30 | 20 | 240 | 3.3 | 2 | 34.2 | .095 | 105 | 3.5 | | |
| MZ5847 | 47 | 25 | 25 | 250 | 3.5 | 2 | 35.8 | .095 | 100 | 3.2 | | |
| MZ5850 | 50 | 25 | 25 | 260 | 3.8 | 2 | 36.8 | .095 | 96 | 3.0 | | |
| MZ5851 | 51 | 25 | 27 | 270 | 4.0 | 2 | 38.8 | .095 | 92 | 3.0 | | |
| MZ5856 | 56 | 20 | 35 | 320 | 4.4 | 2 | 42.6 | .095 | 84 | 2.8 | | |
| MZ5860 | 60 | 20 | 40 | 360 | 4.8 | 2 | 45.7 | .100 | 78 | 2.5 | | |
| MZ5862 | 62 | 20 | 42 | 400 | 5.0 | 2 | 47.1 | .100 | 76 | 2.5 | | |
| MZ5868 | 68 | 20 | 50 | 500 | 5.5 | 2 | 51.7 | .100 | 70 | 2.2 | | |
| MZ5870 | 70 | 20 | 50 | 580 | 5.8 | 2 | 53.6 | .100 | 65 | 2.3 | | |
| MZ5875 | 75 | 20 | 55 | 620 | 6.0 | 2 | 56.0 | .100 | 63.0 | 2.0 | | |
| MZ5880 | 80 | 15 | 80 | 670 | 6.4 | 2 | 58.6 | .100 | 60.5 | 1.8 | | |
| MZ5882 | 82 | 15 | 80 | 720 | 6.6 | 2 | 62.2 | .100 | 58.0 | 1.8 | | |
| MZ5890 | 90 | 15 | 90 | 740 | 7.3 | 2 | 66.8 | .100 | 54.8 | 1.6 | | |
| MZ5891 | 91 | 15 | 90 | 760 | 7.5 | 2 | 69.2 | .100 | 52.5 | 1.6 | | |
| MZ5210 | 100 | 12 | 110 | 800 | 8.0 | 2 | 76.0 | .100 | 47.5 | 1.4 | | |
| MZ5211 | 110 | 12 | 125 | 1000 | 9.0 | 2 | 83.6 | .100 | 43.0 | 1.2 | | |
| MZ5212 | 120 | 10 | 170 | 1150 | 10 | 2 | 91.2 | .100 | 39.5 | 1.00 | | |
| MZ5213 | 130 | 10 | 190 | 1250 | 11 | 2 | 98.8 | .105 | 36.6 | 0.80 | | |
| MZ5214 | 140 | 8 | 230 | 1350 | 12 | 2 | 102.6 | .105 | 33 | 0.80 | | |
| MZ5215 | 150 | 8 | 330 | 1500 | 13 | 2 | 114.0 | .105 | 31.6 | 0.75 | | |
| MZ5216 | 160 | 8 | 350 | 1650 | 14 | 2 | 121.6 | .105 | 29.4 | 0.70 | | |
| MZ5217 | 170 | 8 | 380 | 1700 | 15 | 2 | 129.2 | .105 | 27.0 | 0.65 | | |
| MZ5218 | 180 | 5 | 450 | 1750 | 16 | 2 | 136.8 | .110 | 26.4 | 0.60 | | |
| MZ5219 | 190 | 5 | 470 | 1800 | 17 | 2 | 148.6 | .110 | 24.0 | 0.55 | | |
| MZ5220 | 200 | 5 | 500 | 1850 | 18 | 2 | 152 | .110 | 23.6 | 0.50 | | |
| MZ5222 | 220 | 5 | 550 | 2000 | 19 | 2 | 167 | .115 | 21.6 | 0.50 | | |
| MZ5224 | 240 | 5 | 650 | 2050 | 22 | 2 | 182 | .115 | 19.8 | 0.40 | | |
| MZ5226 | 260 | 5 | 750 | 2075 | 24 | 2 | 198 | .120 | 18.6 | 0.35 | | |
| MZ5227 | 270 | 5 | 800 | 2100 | 25 | 2 | 206 | .120 | 17.5 | 0.35 | | |
| MZ5228 | 280 | 4 | 850 | 2125 | 26 | 2 | 217 | .120 | 16.0 | 0.30 | | |
| MZ5230 | 300 | 4 | 950 | 2150 | 28 | 2 | 228 | .120 | 15.6 | 0.30 | | |
| MZ5232 | 320 | 4 | 1100 | 2175 | 30 | 2 | 242 | .120 | 14.8 | 0.27 | | |
| MZ5233 | 330 | 4 | 1175 | 2200 | 32 | 2 | 251 | .120 | 14.4 | 0.25 | | |
| MZ5234 | 340 | 4 | 1200 | 2250 | 33 | 2 | 263 | .120 | 13.0 | 0.23 | | |
| MZ5236 | 360 | 3 | 1400 | 2300 | 35 | 2 | 274 | .120 | 13.0 | 0.22 | | |
| MZ5238 | 380 | 3 | 1500 | 2400 | 38 | 2 | 286 | .120 | 12.0 | 0.21 | | |
| MZ5239 | 390 | 3 | 1800 | 2500 | 40 | 2 | 297 | .120 | 12.0 | 0.20 | | |
| MZ5240 | 400 | 3 | 1800 | 2600 | 42 | 2 | 300 | .120 | 11.0 | 0.20 | | |

5-WATT GLASS ZENER DIODES

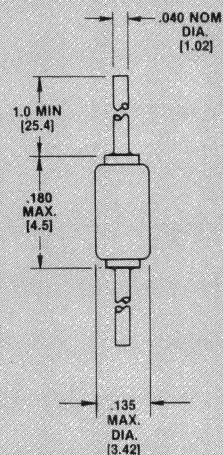


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Silver clad copper or tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

MZ5806 - MZ5891, MZ5210 - MZ5240

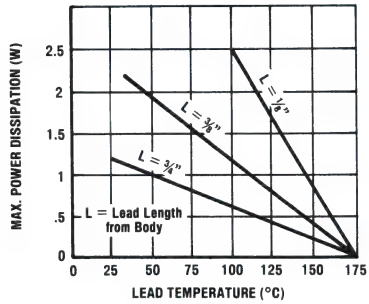


FIGURE 2
POWER DISSIPATION
vs. LEAD TEMPERATURE DERATING CURVE

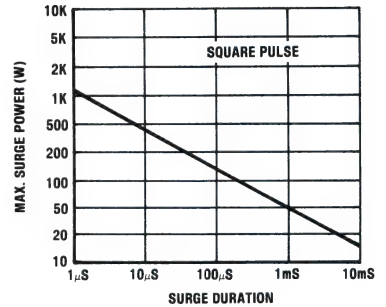


FIGURE 3
vs. SURGE DURATION

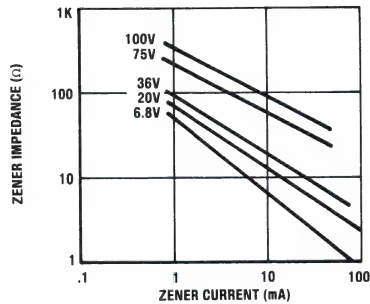


FIGURE 4
TYPICAL ZENER IMPEDANCE
vs. ZENER CURRENT

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

FEATURES

- Low voltage avalanche zener diodes.
- Considerably sharper breakdown than standard 4-10 volt zeners.
- Suppressed field emission breakdown mechanism produces avalanche breakdown with sharpest knee available.
- Glass passivated planar die.
- Rugged subminiature DO-35 package.
- Reference voltages at $< 1\mu\text{W}$ power consumption.
- $\Delta V_Z < 100\text{mV}$ from $100\mu\text{A}$ to 1mA .

MAXIMUM RATINGS

Junction and Storage Temperature: -65°C to $+200^\circ\text{C}$.

DC Power Dissipation: 500mW .

Power Derating: $4\text{mW}/^\circ\text{C}$ above 75°C .

Forward Voltage at 100mA : 1V Maximum.

ELECTRICAL CHARACTERISTICS

| DEVICE TYPE | NOMINAL ZENER VOLTAGE (1) | I_Z | MAXIMUM VOLTAGE REGULATION | MAXIMUM REVERSE LEAKAGE CURRENT | | MAXIMUM D.C. ZENER CURRENT |
|-------------|---------------------------|-------------------|----------------------------|---------------------------------|---------|----------------------------|
| | @ I_Z | | ΔV_Z | I_R | @ V_R | I_{ZM} |
| | (V) | (μA) | (V) | (μA) | (V) | (mA) |
| TS04700 | 4.7 | 1000 | 0.25 (2) | 1.0 | 2.0 | 100 |
| TS05100 | 5.1 | 250 | 0.25 (3) | 1.0 | 3.0 | 96 |
| TS05600 | 5.6 | 25 | 0.1 (4) | 1.0 | 4.5 | 80 |
| TS0600 | 6.0 | 1 | 0.1 (5) | .025 | 4.8 | 75 |
| TS06200 | 6.2 | 1 | 0.1 (5) | .025 | 5.0 | 72 |
| TS06800 | 6.8 | 1 | 0.1 (5) | .025 | 5.2 | 66 |
| TS07100 | 7.1 | 1 | 0.1 (5) | .025 | 5.7 | 64 |
| TS07500 | 7.5 | 1 | 0.1 (5) | .010 | 6.0 | 60 |
| TS08200 | 8.2 | 1 | 0.1 (5) | .010 | 6.5 | 58 |
| TS08700 | 8.7 | 1 | 0.1 (6) | .010 | 7.0 | 54 |
| TS09100 | 9.1 | 1 | 0.1 (6) | .010 | 7.2 | 52 |
| TS10000 | 10.0 | 1 | 0.1 (6) | .010 | 8.0 | 47 |

NOTES: (1) All voltages are $\pm 5\%$ tolerance.
(2) ΔV_Z @ 10mA minus V_Z @ 1mA .
(3) ΔV_Z @ 1mA minus V_Z @ $100\mu\text{A}$.

(4) ΔV_Z @ 1mA minus V_Z @ $25\mu\text{A}$.
(5) ΔV_Z @ 1mA minus V_Z @ $1\mu\text{A}$.
(6) ΔV_Z @ 1mA minus V_Z @ 100nA .

LOW VOLTAGE AVAILANCE DIODES

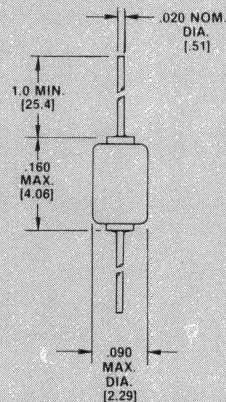


FIGURE 1

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass case.

Lead Material: Tinned copper.

Marking: Body painted, alpha numeric.

Polarity: Cathode band.

TS04700 thru TS10000

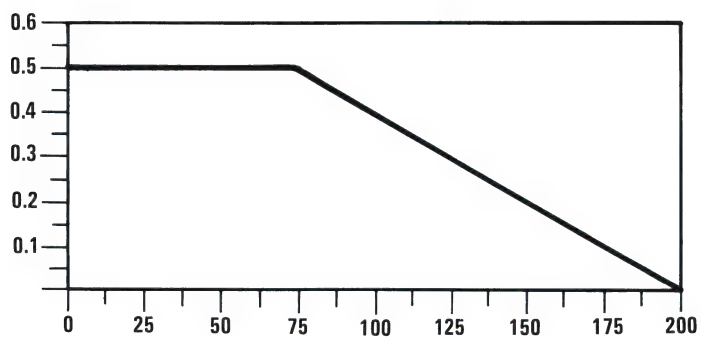


FIGURE 2. POWER DERATING CURVE

QUICK REFERENCE GUIDE

MICROSEMI VOLTAGE REFERENCE (TC) DIODES

| Nominal Voltage V _F @ I _F | Test Current I _F mA | Case Type | Operating Temperature Range, °C | 0.01 % °C | | 0.005 % °C | | 0.002 % °C | | 0.001 % °C | | 0.0005 % °C | | 0.0002 % °C | | Catalog Page No. |
|---|--------------------------------------|-----------------------|--|----------------|------------|----------------|------------|----------------|------------|----------------|------------|----------------|------------|----------------|------------|---------------------|
| | | | | Type Number | Δ VZ mV | Type Number | Δ VZ mV | Type Number | Δ VZ mV | Type Number | Δ VZ mV | Type Number | Δ VZ mV | Type Number | Δ VZ mV | |
| 6.2 | 7.5 | DO-7/DO-35 | -55 to +100 -55°C to +100°C | 1N821 | 96 | 1N823 | 48 | 1N825 | 19 | 1N827 | 9 | 1N829 | 5 | 1N827A | 9 | 119/121 |
| | 1N821A | | | 96 | 1N823A | 48 | 1N825A | 19 | 1N827A | 9 | 1N829A | 5 | | | | |
| 6.3 | 7.5 | DO-7 | -55°C to +100°C | | | | | | | | | | | | | |
| 6.35 | 7.5 | DO-7 | +25°C to +100°C | | | | | | | | | | | | | 129 |
| 6.4 | 0.5 | DO-7/DO-35 | 0 to + 75 -55 to +100 0 to + 75 -55 to +100 0 to + 75 -55 to +100 0 to + 75 -55 to +100 0 to + 75 -55 to +100 0 to + 75 -55 to +100 | 1N4565 | 48 | 1N4566 | 24 | 1N4567 | 10 | 1N4568 | 5 | 1N4569 | 2.2 | 1N4568A | 5 | 135 |
| | 1N4565A | | | 99 | 1N4566A | 50 | 1N4567A | 20 | 1N4568A | 10 | 1N4569A | 5 | | | | |
| | 1N4570 | | | 48 | 1N4571 | 24 | 1N4572 | 10 | 1N4573 | 5 | 1N4574 | 2.2 | 1N4573A | 5 | | |
| | 1N4570A | | | 99 | 1N4571A | 50 | 1N4572A | 20 | 1N4573A | 10 | 1N4574A | 2.2 | 1N4573A | 10 | | |
| | 1N4575 | | | 48 | 1N4576 | 24 | 1N4577 | 10 | 1N4578 | 5 | 1N4579 | 2.2 | 1N4578A | 5 | | |
| | 1N4575A | | | 99 | 1N4576A | 50 | 1N4577A | 20 | 1N4578A | 10 | 1N4579A | 2.2 | 1N4578A | 10 | | |
| 6.5 | 4.0 | DO-7 | -55 to +100 | 1N4580 | 99 | 1N4581 | 50 | 1N4582 | 20 | 1N4583 | 10 | 1N4584 | 2.2 | 1N4583A | 10 | 123 |
| | 1N4580A | | | 99 | 1N4581A | 50 | 1N4582A | 20 | 1N4583A | 10 | 1N4584A | 5 | | | | |
| 6.5 | 7.5 | DO-7 | -55°C to +100°C | 1N3779 | 50 | 1N3781 | 50 | 1N3782 | 20 | 1N3783 | 10 | 1N3784 | 5 | | | |
| 6.6 | 2.0 | DO-7 | -55°C to +100°C | 1N3780 | 50 | 1N3781 | 50 | 1N3782 | 20 | 1N3783 | 10 | 1N3784 | 5 | | | |
| | | | | | | | | | | | | | | | | |
| 8.4 | 10 | DO-7 | -55 to +150 | 1N3154 | 130 | 1N3155 | 65 | 1N3156 | 26 | 1N3157 | 13 | 1N3158 | 6.6 | 1N3157A | 13 | 127 |
| | 8.4 | DO-7 | -55 to +150 | 1N3154A | 172 | 1N3155A | 86 | 1N3156A | 43 | 1N3157A | 22 | 1N3158A | 11 | 1N3157A | 22 | |
| 8.5 | 0.5 | DO-7 | -55 to +75 | 1N4775 | 48 | 1N4776 | 24 | 1N4777 | 10 | 1N4778 | 5 | 1N4779 | 2.2 | 1N4778A | 5 | 139 |
| | 1N4775A | | | 99 | 1N4776A | 48 | 1N4777A | 24 | 1N4778A | 10 | 1N4779A | 2.2 | 1N4778A | 10 | | |
| 9.0 | 7.5 | DO-7 | -55 to +100 | 1N4780 | 64 | 1N4781 | 32 | 1N4782 | 13 | 1N4783 | 6 | 1N4784 | 3.2 | 1N4783A | 6 | 123 |
| | 1N4780A | | | 132 | 1N4781A | 66 | 1N4782A | 26 | 1N4783A | 13 | 1N4784A | 6.6 | 1N4783A | 13 | | |
| 9.1 | 0.5 | DO-7 | -55 to +150 | 1N935 | 67 | 1N936 | 33 | 1N937 | 13 | 1N938 | 6 | 1N939 | 3 | 1N940 | 1.3 | 137 |
| | 1N935A | | | 139 | 1N936A | 69 | 1N937A | 27 | 1N938A | 13 | 1N939A | 7 | 1N940A | 2.7 | | |
| 11.7 | 7.5 | DO-7 | -55 to +100 | 1N355B | 184 | 1N355B | 92 | 1N355B | 47 | 1N355B | 24 | 1N355B | 12 | 1N355B | 12 | 125 |
| | 1N4770 | | | 68 | 1N4771 | 34 | 1N4772 | 14 | 1N4773 | 7 | 1N4774 | 3 | 1N4773A | 7 | | |
| 12.8 | 0.5 | DO-7 | -55 to +100 | 1N941 | 88 | 1N942 | 44 | 1N943 | 18 | 1N944 | 9 | 1N945 | 4 | 1N945A | 9 | 145 |
| | 1N941A | | | 181 | 1N942A | 90 | 1N943A | 36 | 1N944A | 18 | 1N945A | 9 | 1N945A | 9 | | |
| 12.8 | 0.5 | DO-7 | -55 to +100 | 1N4886 | 96 | 1N4887 | 48 | 1N4888 | 24 | 1N4889 | 12 | 1N4890 | 6 | 1N4889A | 12 | 147 |
| | 1N4886A | | | 192 | 1N4887A | 96 | 1N4888A | 48 | 1N4889A | 24 | 1N4890A | 12 | 1N4889A | 24 | | |
| 19.2 | 1.0 | DO-7 | -55 to +100 | 1N4900 | 186 | 1N4901 | 93 | 1N4902 | 46 | 1N4903 | 23 | 1N4904 | 11 | 1N4903A | 23 | 133 |
| | 1N4900A | | | 372 | 1N4901A | 186 | 1N4902A | 93 | 1N4903A | 46 | 1N4904A | 23 | 1N4903A | 46 | | |
| 2.0 | 2.0 | DO-7 | -55 to +100 | 1N4904 | 96 | 1N4905 | 48 | 1N4906 | 24 | 1N4907 | 12 | 1N4908 | 6 | 1N4907A | 12 | 147 |
| | 1N4904A | | | 192 | 1N4905A | 96 | 1N4906A | 48 | 1N4907A | 24 | 1N4908A | 12 | 1N4907A | 24 | | |
| 4.0 | 4.0 | DO-7 | -55 to +100 | 1N4908 | 96 | 1N4909 | 48 | 1N4910 | 24 | 1N4911 | 12 | 1N4912 | 6 | 1N4910A | 12 | 147 |
| | 1N4908A | | | 192 | 1N4909A | 96 | 1N4910A | 48 | 1N4911A | 24 | 1N4912A | 12 | 1N4910A | 24 | | |
| 7.5 | 7.5 | DO-7 | -55 to +100 | 1N4912A | 186 | 1N4913A | 93 | 1N4914A | 46 | 1N4915A | 23 | 1N4916A | 11 | 1N4915A | 23 | 147 |
| | 1N4916A | | | 288 | 1N4917A | 144 | 1N4918A | 72 | 1N4919A | 36 | 1N4920A | 18 | 1N4918A | 72 | | |
| 19.2 | 0.5 | DO-7 | -55 to +100 | 1N4919 | 144 | 1N4920 | 72 | 1N4921 | 36 | 1N4922 | 18 | 1N4923 | 9 | 1N4921A | 36 | 147 |
| | 1N4919A | | | 288 | 1N4920A | 144 | 1N4921A | 72 | 1N4922A | 36 | 1N4923A | 18 | 1N4921A | 72 | | |
| 2.0 | 2.0 | DO-7 | -55 to +100 | 1N4922 | 288 | 1N4923 | 144 | 1N4924 | 72 | 1N4925 | 36 | 1N4926 | 18 | 1N4924A | 72 | 147 |
| | 1N4922A | | | 576 | 1N4923A | 288 | 1N4924A | 144 | 1N4925A | 72 | 1N4926A | 36 | 1N4924A | 144 | | |
| 4.0 | 4.0 | DO-7 | -55 to +100 | 1N4925 | 144 | 1N4926 | 72 | 1N4927 | 36 | 1N4928 | 18 | 1N4929 | 9 | 1N4927A | 36 | 147 |
| | 1N4925A | | | 288 | 1N4926A | 144 | 1N4927A | 72 | 1N4928A | 36 | 1N4929A | 18 | 1N4927A | 72 | | |
| 7.5 | 7.5 | DO-7 | -55 to +100 | 1N4929 | 144 | 1N4930 | 72 | 1N4931 | 36 | 1N4932 | 18 | 1N4933 | 9 | 1N4931A | 36 | 147 |
| | 1N4929A | | | 288 | 1N4930A | 144 | 1N4931A | 72 | 1N4932A | 36 | 1N4933A | 18 | 1N4931A | 72 | | |
| 12.4 to 200 | 10 to 2.5 | Epoxy Case CC DO-18EE | -55 to +100 | 1N4057 | 149 | 1N4057A | 149 | 1N4057A | 149 | 1N4057A | 149 | 1N4057A | 149 | 1N4057A | 149 | 133 |
| | 1N4085 | | | | 1N4085A | | 1N4085A | | 1N4085A | | 1N4085A | | 1N4085A | | | |

1N821 & A thru 1N829 & A DO-7

FEATURES

- ZENER VOLTAGE 6.2 V AND 6.55 V
- 1N821, 823, 825, 827 AND 829 HAVE JAN, JANTX, JANTXV AND -I QUALIFICATIONS TO MIL-S-19500/159
- S1N827A
- RADIATION HARDENED DEVICES AVAILABLE (SEE NOTE 4)
- ALSO AVAILABLE IN DO-35 PACKAGE

MAXIMUM RATINGS

Operating Temperatures: -65°C to +175°C

Storage Temperatures: -65°C to +175°C

DC Power Dissipation: 250 mW @ 25°C ambient

Derating: 1.67 mW/°C above 25°C

*ELECTRICAL CHARACTERISTICS

@ 25°C, unless otherwise specified

| JEDEC TYPE NUMBER | ZENER VOLTAGE (Note 1 and 4) V_Z @ I_{ZT} | ZENER TEST CURRENT I_{ZT} | MAXIMUM ZENER IMPEDANCE (Note 3 and 4) Z_{ZT} | VOLTAGE TEMPERATURE STABILITY (ΔV_{ZT} MAX) -55° to +100° (Note 3 and 4) | EFFECTIVE TEMPERATURE COEFFICIENT α_{VZ} |
|-------------------------|--|--------------------------------------|---|--|--|
| | VOLTS | mA | OHMS | mV | %/°C |
| 1N821 | 5.9 - 6.5 | 7.5 | 15 | 96 | 0.01 |
| 1N821A | 5.9 - 6.5 | 7.5 | 10 | 96 | 0.01 |
| 1N822† | 5.9 - 6.5 | 7.5 | 15 | 96 | 0.01 |
| 1N823 | 5.9 - 6.5 | 7.5 | 15 | 48 | 0.005 |
| 1N823A | 5.9 - 6.5 | 7.5 | 10 | 48 | 0.005 |
| 1N824† | 5.9 - 6.5 | 7.5 | 15 | 48 | 0.005 |
| 1N825 | 5.9 - 6.5 | 7.5 | 15 | 19 | 0.002 |
| 1N825A | 5.9 - 6.5 | 7.5 | 10 | 19 | 0.002 |
| 1N826 | 6.2 - 6.9 | 7.5 | 15 | 20 | 0.002 |
| 1N827 | 5.9 - 6.5 | 7.5 | 15 | 9 | 0.001 |
| 1N827A | 5.9 - 6.5 | 7.5 | 10 | 9 | 0.001 |
| 1N828 | 6.2 - 6.9 | 7.5 | 15 | 10 | 0.001 |
| 1N829 | 5.9 - 6.5 | 7.5 | 15 | 5 | 0.0005 |

† Double Anode; Electrical Specifications Apply Under Both Bias Polarities.

* JEDEC Registered Data

NOTE 1 When ordering devices with tighter tolerances than specified, use a nominal V_Z voltage of 6.35V.

NOTE 2 Measured by superimposing 0.75 mA ac rms on 7.5 mA DC @ 25°C.

NOTE 3 The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.

NOTE 4 Voltage measurements to be performed 15 seconds after application of DC current.

NOTE 5 Designate Radiation Hardened devices with "RH" prefix instead of "1N", i.e., RH829A instead of 1N829A.

6.2 & 6.55 VOLT TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

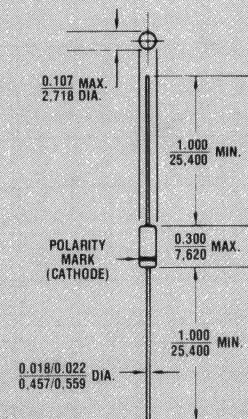


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N821 thru 1N829A DO-7

The curve shown in Figure 3 is typical of the diode series and greatly simplifies the estimation of the Temperature Coefficient (TC) when the diode is operated at currents other than 7.5 mA.

EXAMPLE: A diode in this series is operated at a current of 7.5mA and has specified Temperature Coefficient (TC) limits of $\pm 0.005\%/^{\circ}\text{C}$. To obtain the typical Temperature Coefficient limits for this same diode operated at a current of 6.0mA, the new TC limits ($\%/^{\circ}\text{C}$) can be estimated using the graph in FIGURE 3.

At a test current of 6.0mA the change in Temperature Coefficient (TC) is approximately $-0.0006\%/^{\circ}\text{C}$. The algebraic sum of $\pm 0.005\%/^{\circ}\text{C}$ and $-0.0006\%/^{\circ}\text{C}$ gives the new estimated limits of $+0.0044\%/^{\circ}\text{C}$ and $-0.0056\%/^{\circ}\text{C}$.

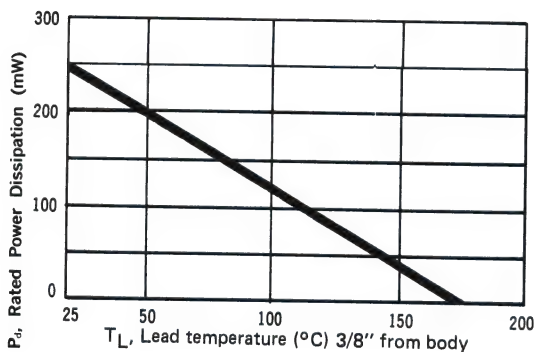


FIGURE 2
POWER DERATING CURVE

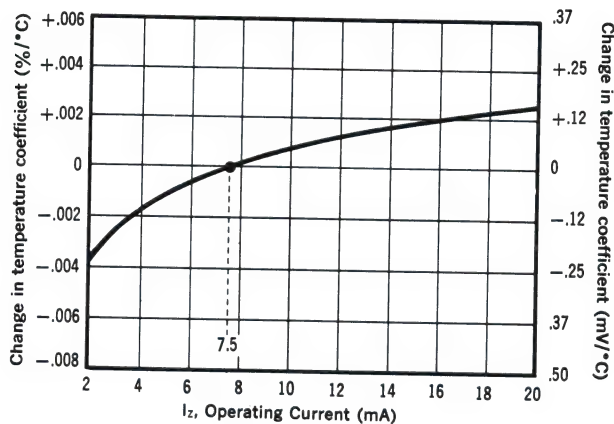


FIGURE 3
TYPICAL CHANGE OF TEMPERATURE COEFFICIENT
WITH CHANGE IN OPERATING CURRENT

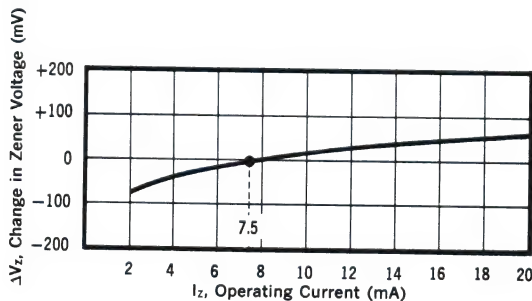


FIGURE 4
TYPICAL CHANGE OF ZENER VOLTAGE WITH
CHANGE IN OPERATING CURRENT

This curve in Figure 4 illustrates the change of diode voltage arising from the effect of impedance. It is in effect an exploded view of the zener operating region of the I-V characteristic.

In conjunction with Figure 3, this curve can be used to estimate total voltage regulation under conditions of both varying temperature and current.

1N821 & A thru 1N829 & A DO-35

FEATURES

- ZENER VOLTAGE 6.2 V AND 6.55 V
- 1N821, 823, 825, 827 AND 829 HAVE JAN, JANTX, JANTXV-1 QUALIFICATIONS TO MIL-S-19500/159

MAXIMUM RATINGS

Operating Temperatures: -65°C to +175°C

Storage Temperatures: -65°C to +175°C

DC Power Dissipation: 250 mW @ 25°C ambient

Derating: 1.67 mW/°C above 25°C

*ELECTRICAL CHARACTERISTICS

@ 25°C, unless otherwise specified

| JEDEC TYPE NUMBER | ZENER VOLTAGE (Note 1 and 4) V_Z @ I_{ZT} | ZENER TEST CURRENT I_{ZT} | MAXIMUM ZENER IMPEDANCE (Note 3 and 4) Z_{ZT} | VOLTAGE TEMPERATURE STABILITY (ΔV_{ZT} MAX) -55° to +100° (Note 3 and 4) | EFFECTIVE TEMPERATURE COEFFICIENT α_{VZ} |
|-------------------------|--|--------------------------------------|---|--|--|
| | VOLTS | mA | OHMS | mV | %/°C |
| 1N821 | 5.9 - 6.5 | 7.5 | 15 | 96 | 0.01 |
| 1N821A | 5.9 - 6.5 | 7.5 | 10 | 96 | 0.01 |
| 1N822† | 5.9 - 6.5 | 7.5 | 15 | 96 | 0.01 |
| 1N823 | 5.9 - 6.5 | 7.5 | 15 | 48 | 0.005 |
| 1N823A | 5.9 - 6.5 | 7.5 | 10 | 48 | 0.005 |
| 1N824† | 5.9 - 6.5 | 7.5 | 15 | 48 | 0.005 |
| 1N825 | 5.9 - 6.5 | 7.5 | 15 | 19 | 0.002 |
| 1N825A | 5.9 - 6.5 | 7.5 | 10 | 19 | 0.002 |
| 1N826 | 6.2 - 6.9 | 7.5 | 15 | 20 | 0.002 |
| 1N827 | 5.9 - 6.5 | 7.5 | 15 | 9 | 0.001 |
| 1N827A | 5.9 - 6.5 | 7.5 | 10 | 9 | 0.001 |
| 1N828 | 6.2 - 6.9 | 7.5 | 15 | 10 | 0.001 |
| 1N829 | 5.9 - 6.5 | 7.5 | 15 | 5 | 0.0005 |

† Double Anode; Electrical Specifications Apply Under Both Bias Polarities.

*JEDEC Registered Data

NOTE 1 When ordering devices with tighter tolerances than specified, use a nominal V_Z voltage of 6.35 V.

NOTE 2 Measured by superimposing 0.75 mA ac rms on 7.5 mA DC @ 25°C.

NOTE 3 The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.

NOTE 4 Voltage measurements to be performed 15 seconds after application of DC current.

6.2 & 6.55 VOLT TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

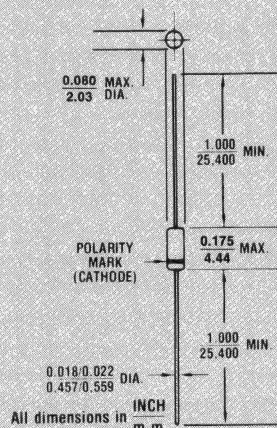


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 150°C/W (Typical) junction to lead at 0.375-inches from body. Metallurgically bonded DO-35's exhibit less than 100°C/W at zero distance from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITIONS: Any.

1N821 thru 1N829A DO-35

The curve shown in Figure 3 is typical of the diode series and greatly simplifies the estimation of the Temperature Coefficient (TC) when the diode is operated at currents other than 7.5 mA.

EXAMPLE: A diode in this series is operated at a current of 7.5 mA and has specified Temperature Coefficient (TC) limits of $\pm 0.005\%/^{\circ}\text{C}$. To obtain the typical Temperature Coefficient limits for this same diode operated at a current of 6.0 mA, the new TC limits ($\%/^{\circ}\text{C}$) can be estimated using the graph in FIGURE 3.

At a test current of 6.0 mA the change in Temperature Coefficient (TC) is approximately $-0.0006\%/^{\circ}\text{C}$. The algebraic sum of $\pm 0.005\%/^{\circ}\text{C}$ and $-0.0006\%/^{\circ}\text{C}$ gives the new estimated limits of $+0.0044\%/^{\circ}\text{C}$ and $-0.0056\%/^{\circ}\text{C}$.

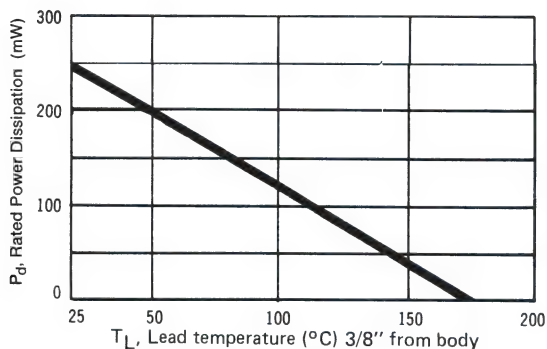


FIGURE 2
POWER DERATING CURVE

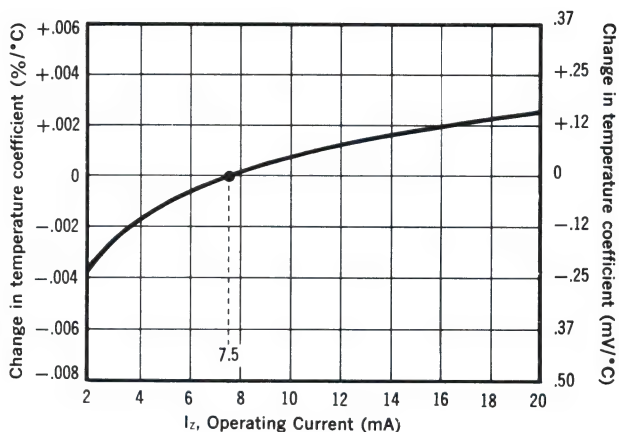


FIGURE 3
TYPICAL CHANGE OF TEMPERATURE COEFFICIENT
WITH CHANGE IN OPERATING CURRENT

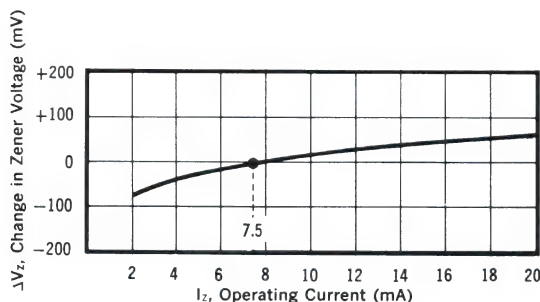


FIGURE 4
TYPICAL CHANGE OF ZENER VOLTAGE WITH
CHANGE IN OPERATING CURRENT

This curve in Figure 4 illustrates the change of diode voltage arising from the effect of impedance. It is in effect an exploded view of the zener operating region of the I-V characteristic.

In conjunction with Figure 3, this curve can be used to estimate total voltage regulation under conditions of both varying temperature and current.



SANTA ANA, CA

SCOTTSDALE, AZ
For more information call:
(602) 941-6300

1N935, A & B thru 1N940, A & B

FEATURES

- ZENER VOLTAGE 9.0 V
- 1N935B, 937B, 938B, 940B HAVE JAN, JANTX, JANTXV, AND -I QUALIFICATIONS TO MIL-S-19500/156
- S1N939A
- RADIATION HARDENED DEVICES AVAILABLE (SEE NOTE 5)

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.
Storage Temperature: -65°C to $+175^{\circ}\text{C}$
DC Power Dissipation: 500 mW @ 25°C .
Power Derating: 3.33 mW/ $^{\circ}\text{C}$ above 25°C .

* ELECTRICAL CHARACTERISTICS @ 25°C , unless otherwise specified

| JEDEC TYPE NUMBERS | ZENER VOLTAGE V_z @ I_{zT} (NOTE 1 & 4) | ZENER TEST CURRENT I_{zT} | MAXIMUM ZENER IMPEDANCE (NOTE 2) Z_{zT} | VOLTAGE TEMPERATURE STABILITY (NOTE 3 & 4) ΔV_z MAXIMUM | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT α_{Vz} |
|--------------------------|--|--------------------------------------|---|---|----------------------|--|
| | VOLTS | mA | OHMS | mV | $^{\circ}\text{C}$ | %/ $^{\circ}\text{C}$ |
| 1N935 | 8.55-9.45 | 7.5 | 20 | 67 | 0 to +75 | 0.01 |
| 1N935A | 8.55-9.45 | 7.5 | 20 | 139 | -55 to +100 | 0.01 |
| 1N935B | 8.55-9.45 | 7.5 | 20 | 184 | -55 to +150 | 0.01 |
| 1N936 | 8.55-9.45 | 7.5 | 20 | 33 | 0 to +75 | 0.005 |
| 1N936A | 8.55-9.45 | 7.5 | 20 | 69 | -55 to +100 | 0.005 |
| 1N936B | 8.55-9.45 | 7.5 | 20 | 92 | -55 to +150 | 0.005 |
| 1N937 | 8.55-9.45 | 7.5 | 20 | 13 | 0 to +75 | 0.002 |
| 1N937A | 8.55-9.45 | 7.5 | 20 | 27 | -55 to +100 | 0.002 |
| 1N937B | 8.55-9.45 | 7.5 | 20 | 37 | -55 to +150 | 0.002 |
| 1N938 | 8.55-9.45 | 7.5 | 20 | 6 | 0 to +75 | 0.001 |
| 1N938A | 8.55-9.45 | 7.5 | 20 | 13 | -55 to +100 | 0.001 |
| 1N938B | 8.55-9.45 | 7.5 | 20 | 18 | -55 to +150 | 0.001 |
| 1N939 | 8.55-9.45 | 7.5 | 20 | 3 | 0 to +75 | 0.0005 |
| 1N939A | 8.55-9.45 | 7.5 | 20 | 7 | -55 to +100 | 0.0005 |
| 1N939B | 8.55-9.45 | 7.5 | 20 | 9 | -55 to +150 | 0.0005 |
| 1N940 | 8.55-9.45 | 7.5 | 20 | 1.3 | 0 to +75 | 0.0002 |
| 1N940A | 8.55-9.45 | 7.5 | 20 | 2.7 | -55 to +100 | 0.0002 |
| 1N940B | 8.55-9.45 | 7.5 | 20 | 3.7 | -55 to +150 | 0.0002 |

*JEDEC Registered Data

NOTE 1 When ordering devices with tighter tolerances than specified, use a nominal center voltage of 9.2V.

NOTE 2 Measured by superimposing 0.75 mA ac rms on 7.5 mA DC @ 25°C .

NOTE 3 The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.

NOTE 4 Voltage measurements to be performed 15 seconds after application of DC current.

NOTE 5 Designate Radiation Hardened devices with "RH" prefix instead of "1N", i.e. RH938A instead of 1N938A.

9.0 VOLT TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

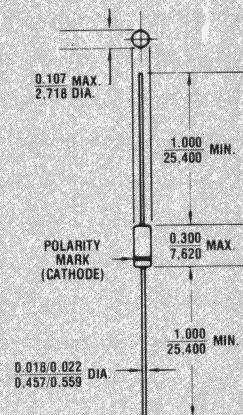


FIGURE 1

INCH

m.m.

All dimensions in

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case, DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $300^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N935 thru 1N940B

NOTE 5

The curve shown in Fig. 3 is typical of the diode series and greatly simplifies the estimation of the Temperature Coefficient (TC) when the diode is operated at currents other than 7.5 mA.

EXAMPLE: A diode in this series is operated at a current of 7.5 mA and has specified Temperature Coefficient (TC) limits of $\pm 0.005\%/^{\circ}\text{C}$. To obtain the typical Temperature Coefficient limits for this same diode operated at a current of 6.0 mA, the new TC limits ($\%/^{\circ}\text{C}$) can be estimated using the graph in FIGURE 3.

At a test current of 6.0 mA the change in Temperature Coefficient (TC) is approximately $-0.0009\%/^{\circ}\text{C}$. The algebraic sum of $\pm 0.005\%/^{\circ}\text{C}$ and $-0.0009\%/^{\circ}\text{C}$ gives the new limits of $+0.0041\%/^{\circ}\text{C}$ and $-0.0059\%/^{\circ}\text{C}$.

NOTE 6

The curve in Figure 4 illustrates the change of diode voltage arising from the effect of impedance. It is, in effect, an exploded view of the zener operating region of the I-V characteristic.

In conjunction with Fig. 3 this curve can be used to estimate total voltage regulation under conditions of both varying temperature and current.

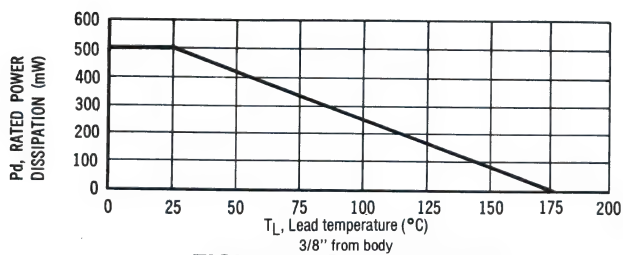


FIGURE 2 Power Derating Curve

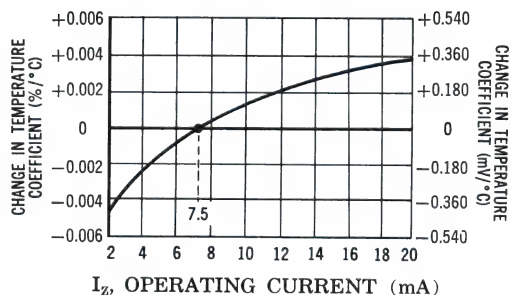


FIGURE 3 Typical change of Temperature Coefficient with Change in Operating Current.

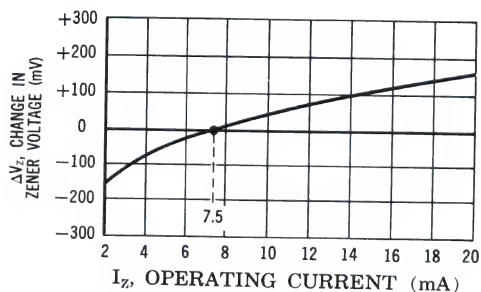


FIGURE 4 Typical change of Zener Voltage with Change in Operating Current.

1N941 thru 1N946B

FEATURES

- ZENER VOLTAGE 11.7 V
- 1N941B, 943B, 944B, 945B HAVE JAN, JANTX, JANTXV, AND -1 QUALIFICATIONS TO MIL-S-19500/157
- S1N944B
- RADIATION HARDENED DEVICES AVAILABLE (SEE NOTE 4)

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.
Storage Temperature: -65°C to $+175^{\circ}\text{C}$.
DC Power Dissipation: 500 mW @ 25°C ambient.
Power Derating: 3.33 mW/ $^{\circ}\text{C}$ above 25°C .

* ELECTRICAL CHARACTERISTICS

@ 25°C , unless otherwise specified

| JEDEC TYPE NUMBERS | ZENER VOLTAGE V_Z @ I_{ZT} (NOTE 3) | ZENER TEST CURRENT I_{ZT} | MAXIMUM ZENER IMPEDANCE (NOTE 1) Z_{ZT} | VOLTAGE TEMPERATURE STABILITY (NOTE 2 & 3) ΔV_{ZT} MAXIMUM | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT C_{VZ} |
|--------------------------|--|--------------------------------------|---|---|----------------------|---|
| | VOLTS | mA | OHMS | mV | $^{\circ}\text{C}$ | %/ $^{\circ}\text{C}$ |
| 1N941 | 11.12-12.28 | 7.5 | 30 | 88 | 0 to +75 | .01 |
| 1N941A | 11.12-12.28 | 7.5 | 30 | 181 | -55 to +100 | .01 |
| 1N941B | 11.12-12.28 | 7.5 | 30 | 239 | -55 to +150 | .01 |
| 1N942 | 11.12-12.28 | 7.5 | 30 | 44 | 0 to +75 | .005 |
| 1N942A | 11.12-12.28 | 7.5 | 30 | 90 | -55 to +100 | .005 |
| 1N942B | 11.12-12.28 | 7.5 | 30 | 120 | -55 to +150 | .005 |
| 1N943 | 11.12-12.28 | 7.5 | 30 | 18 | 0 to +75 | .002 |
| 1N943A | 11.12-12.28 | 7.5 | 30 | 36 | -55 to +100 | .002 |
| 1N943B | 11.12-12.28 | 7.5 | 30 | 47 | -55 to +150 | .002 |
| 1N944 | 11.12-12.28 | 7.5 | 30 | 9 | 0 to +75 | .001 |
| 1N944A | 11.12-12.28 | 7.5 | 30 | 18 | -55 to +100 | .001 |
| 1N944B | 11.12-12.28 | 7.5 | 30 | 24 | -55 to +150 | .001 |
| 1N945 | 11.12-12.28 | 7.5 | 30 | 4 | 0 to +75 | .0005 |
| 1N945A | 11.12-12.28 | 7.5 | 30 | 9 | -55 to +100 | .0005 |
| 1N945B | 11.12-12.28 | 7.5 | 30 | 12 | -55 to +150 | .0005 |
| 1N946 | 11.12-12.28 | 7.5 | 30 | 1.8 | 0 to +75 | .0002 |
| 1N946A | 11.12-12.28 | 7.5 | 30 | 3.6 | -55 to +100 | .0002 |
| 1N946B | 11.12-12.28 | 7.5 | 30 | 4.7 | -55 to +150 | .0002 |

*JEDEC Registered Data

NOTE 1 Measured by superimposing 0.75 mA ac rms on 7.5 mA DC @ 25°C .

NOTE 2 The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.

NOTE 3 Voltage measurements to be performed 15 seconds after application of DC current.

NOTE 4 Designate Radiation Hardened devices with "RH" prefix instead of "1N", i.e. RH944B instead of 1N944B.

11.7 VOLT TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

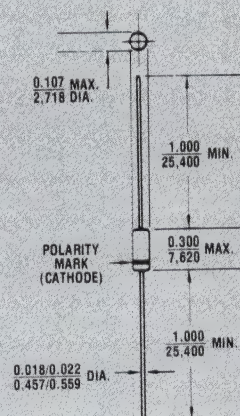


FIGURE 1

INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $300^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N941 thru 1N946B

NOTE 4

The curve shown in Figure 3 is typical of the diode series and greatly simplifies the estimation of the Temperature Coefficient (TC) when the diode is operated at currents other than 7.5 mA.

EXAMPLE: A diode in this series is operated at a current of 7.5 mA and has specified Temperature Coefficient (TV) limits of $\pm 0.002\%/^{\circ}\text{C}$. To obtain the typical Temperature Coefficient limits for this same diode operated at a current of 6.0 mA, the new TC limits ($\%/^{\circ}\text{C}$) can be estimated using the graph in FIGURE 3.

At a test current of 6.0 mA the change in Temperature Coefficient (TC) is approximately $-0.0009\%/^{\circ}\text{C}$. The algebraic sum of $\pm 0.002\%/^{\circ}\text{C}$ and $-0.0009\%/^{\circ}\text{C}$ gives the new limits of $+0.0011\%/^{\circ}\text{C}$ and $-0.0029\%/^{\circ}\text{C}$.

NOTE 5

The curve in Figure 4 illustrates the change of diode voltage arising from the effect of impedance. It is, in effect, an exploded view of the zener operating region of the I-V characteristic.

In conjunction with Fig. 3 this curve can be used to estimate total voltage regulation under conditions of both varying temperature and current.

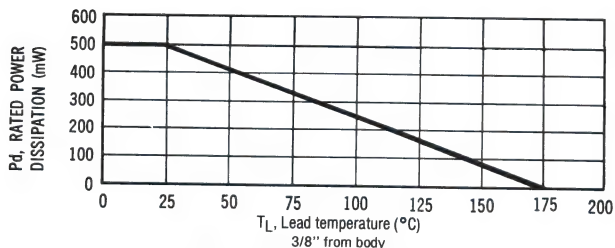


FIGURE 2 Power Derating Curve

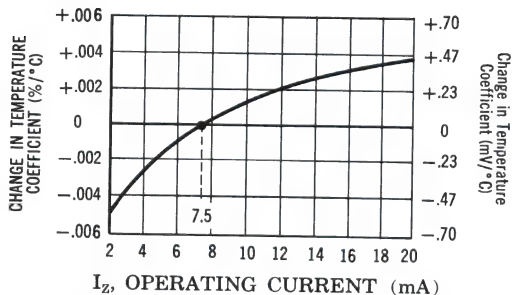


FIGURE 3 Typical change of Temperature Coefficient with Change in Operating Current.

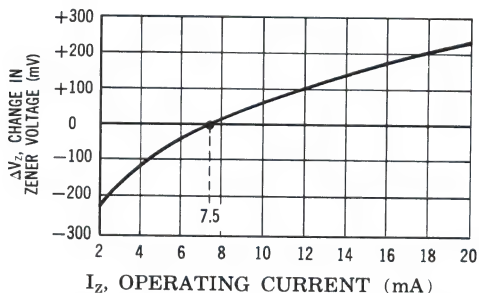


FIGURE 4 Typical change of Zener Voltage with Change in Operating Current.



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(602) 941-6300

1N3154 & A thru 1N3157 & A

FEATURES

- ZENER VOLTAGE 8.4 V
- 1N3154 THRU 1N3157 HAVE JAN, JANTX, JANTXV, AND -1 QUALIFICATIONS TO MIL-S-19500/158
- HIGH LEVEL STABILITY WITH VIBRATION, THERMAL SHOCK & MECHANICAL SHOCK
- RADIATION HARDENED DEVICES AVAILABLE (SEE NOTE 5)

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$

Storage Temperature: -65°C to $+175^{\circ}\text{C}$

DC Power Dissipation: 500 mW

Power Derating: 3.33 mW/ $^{\circ}\text{C}$ above 25°C

* ELECTRICAL CHARACTERISTICS

@ 25°C , unless otherwise specified

| JEDEC TYPE NUMBERS | ZENER VOLTAGE V_Z @ I_{ZT} (Note 1 & 4) | ZENER TEST CURRENT I_{ZT} | MAXIMUM ZENER IMPEDANCE (NOTE 2) Z_{ZT} | VOLTAGE TEMPERATURE STABILITY (NOTE 3 & 4) ΔV_Z , MAXIMUM | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT α_{VZ} |
|--------------------------|--|--------------------------------------|---|--|------------------------------------|--|
| | VOLTS | mA | OHMS | mV | $^{\circ}\text{C}$ | %/ $^{\circ}\text{C}$ |
| 1N3154 1N3154A | 8.00-8.80 8.00-8.80 | 10 10 | 15 15 | 130 172 | -55 to $+100$ -55 to $+150$ | .01 .01 |
| 1N3155 1N3155A | 8.00-8.80 8.00-8.80 | 10 10 | 15 15 | 65 86 | -55 to $+100$ -55 to $+150$ | .005 .005 |
| 1N3156 1N3156A | 8.00-8.80 8.00-8.80 | 10 10 | 15 15 | 26 34 | -55 to $+100$ -55 to $+150$ | .002 .002 |
| 1N3157 1N3157A | 8.00-8.80 8.00-8.80 | 10 10 | 15 15 | 13 17 | -55 to $+100$ -55 to $+150$ | .001 .001 |

* JEDEC Registered Data

NOTE 1 When ordering devices with higher tolerance than specified, use a nominal center voltage of 8.7 volts.

NOTE 2 Measured by superimposing 1.0 mA ac rms on 10 mA DC @ 25°C .

NOTE 3 The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV at any discrete temperature between the established limits.

NOTE 4 Voltage measurements to be performed 15 seconds after application of DC current.

NOTE 5 Designate Radiation Hardened devices with "RH" prefix instead of "1N", i.e. RH3157A instead of 1N3157A.

8.4 VOLT TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

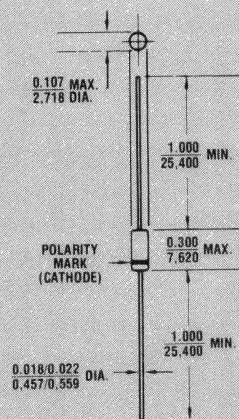


FIGURE 1

INCH
All dimensions in
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $300^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N3154 thru 1N3157A

NOTE 5

The curve in Figure 3 is typical of the diode series and greatly simplifies the estimation of the Temperature Coefficient (TC) when the diode is operated at currents other than 10 mA.

EXAMPLE: A diode in this series is operated at a current of 10 mA and has specified Temperature Coefficient (TC) limits of $\pm 0.005\%/^{\circ}\text{C}$. To obtain the typical Temperature Coefficient limits for this same diode operated at a current of 7.5 mA, the new TC limits ($\%/^{\circ}\text{C}$) can be estimated using the graph in FIGURE 3.

At a test current of 7.5 mA the change in Temperature Coefficient (TC) is approximately $-0.0012\%/^{\circ}\text{C}$. The algebraic sum of $\pm 0.005\%/^{\circ}\text{C}$ and $-0.0012\%/^{\circ}\text{C}$ gives the new limits of $+0.0038\%/^{\circ}\text{C}$ and $-0.0062\%/^{\circ}\text{C}$.

NOTE 6

The curve in Figure 4 illustrates the change of diode voltage arising from the effect of impedance. It is in effect an exploded view of the zener operating region of the I-V characteristic.

In conjunction with Fig. 3 this curve can be used to estimate total voltage regulation under conditions of both varying temperature and current.

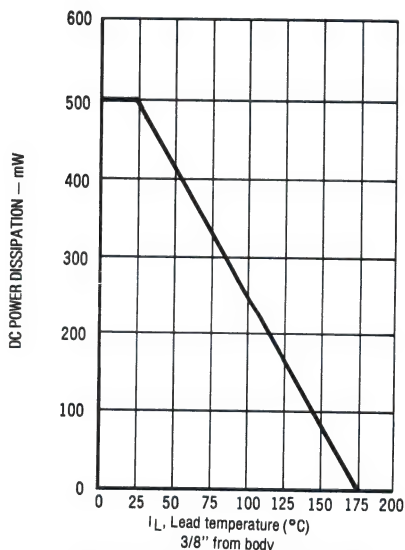


FIGURE 2 Power Derating Curve

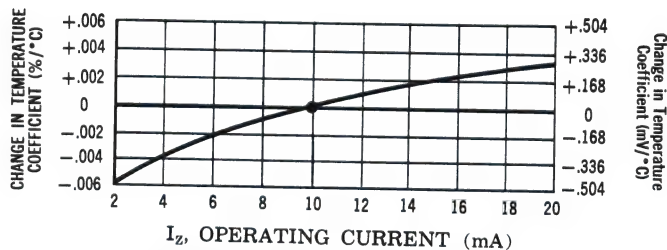


FIGURE 3 Typical change of Temperature Coefficient with Change in Operating Current.

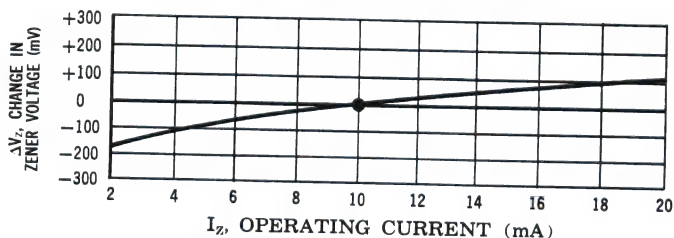


FIGURE 4 Typical change of Zener Voltage with Change in Operating Current.



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1N3501 thru 1N3504 WITH CERTIFIED ZENER VOLTAGE STABILITY

DESCRIPTION

This series of Microsemi 250mW Ultra-Stable Reference Diodes offers a **CERTIFIED REFERENCE VOLTAGE STABILITY** as measured over an actual operating period of 1000 hours. Standard stabilities are 20, 50, and 100 PPM/1000 hours. Units having stabilities of less than 20 PPM/1000 hours are available on special request.

Ultra-Stable Certified Reference Diodes, available in standard or radiation hardened construction, can be used in any circuit that requires a stable reference voltage that is insensitive to shock, vibration, or position. Their inherent stability allows them to be used in circuits requiring an extremely high degree of voltage time stability such as those in Digital Voltmeters, Computers, X-Y Recorders, Missile Guidance and Environmental Control Systems, and Portable Reference Standards.

All devices in this series have been subjected to Microsemi's 1000 hour Stability Test Sequence, consisting of a 1000 hour power age with reference voltage measured once every 168 hours giving a total of 7 individual test points. The stability test is performed at $80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$.

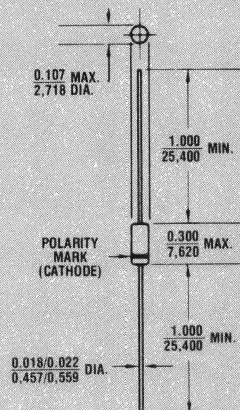
A Certificate containing the following data is supplied with each diode:

1. The stability test voltage readings.
2. The voltage drift as referenced to "Zero Hour" in both μV and in PPM (Parts-Per-Million).

To certify these diodes to such tight stabilities as 20 PPM/1000 hours, every factor of environment, both ambient and electrical is considered and controlled to "Standards Laboratory" accuracy.

To specify radiation hardened devices, use "RH" prefix instead of "1N", i.e. RH3504 instead of 1N3504.

6.35 VOLT ULTRA STABLE TEMPERATURE COMPENSATED ZENER REFERENCE DIODES



All dimensions in $\frac{\text{INCH}}{\text{m.m.}}$

FIGURE 1

6.35 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

MAXIMUM RATINGS (See Fig. 5)

Operating Temperature Range: -65° to $+150^{\circ}\text{C}$

Maximum Lead Temperature $1/8 \pm 1/32$ inch from case for 8 seconds: 230°C

Maximum DC Power Dissipation at or below 25°C Ambient: 250 mW

Linear Derating: 2.0 mW/ $^{\circ}\text{C}$ (See Figure 5)

Maximum Steady State Current (I_{ZM}) at 125°C : 7.5 mA

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass

Dimensions: DO-7 outline

Finish: All external surfaces are corrosion resistant and leads are readily solderable

Polarity: Diode to be operated with the banded end positive

Weight: 0.2 grams (typical)

Mounting Position: Any

ELECTRICAL CHARACTERISTICS @ 25°C unless otherwise specified

| JEDEC TYPE NUMBER | NOMINAL ZENER VOLTAGE V_Z @ I_{ZT} | ZENER TEST CURRENT $\pm 0.01 \text{ mA}$ I_{ZT} | MAXIMUM ZENER IMPEDANCE Z_{ZT} @ I_{ZT} (NOTE 1) | VOLTAGE TEMPERATURE STABILITY ΔV_{ZT} MAXIMUM (NOTE 2) | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT | VOLTAGE TIME STABILITY @ 80°C INITIAL-TO PEAK ΔV_{ZT} MAXIMUM (NOTE 3) | EFFECTIVE VOLTAGE TIME STABILITY INITIAL-TO-PEAK |
|-------------------|---|---|--|--|--------------------|-----------------------------------|---|---|
| | VOLTS | mA | OHMS | mV | $^{\circ}\text{C}$ | %/ $^{\circ}\text{C}$ | $\mu\text{V}/1000 \text{ HRS.}$ | PPM/1000 HRS. |
| 1N3501 | 6.2-6.5 | 7.5 | 12 | 6 | 25 to 100 | .001 | 635 | 100 |
| 1N3502 | 6.2-6.5 | 7.5 | 12 | 3 | 25 to 100 | .0005 | 635 | 100 |
| 1N3503 | 6.2-6.5 | 7.5 | 12 | 6 | 25 to 100 | .001 | 318 | 50 |
| 1N3504 | 6.2-6.5 | 7.5 | 12 | 6 | 25 to 100 | .001 | 127 | 20 |

NOTE 1

The zener impedance is derived from the 60 Hz ac voltage which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT}) is superimposed on I_{ZT} .

NOTE 2

The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.

NOTE 3

When operated at:

$$I_{ZT} = 7.5 \text{ mA} \pm 0.0001 \text{ mA}$$

$$T_A = 80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$$

(See Precautions Below)

NOTES AND PRECAUTIONS FOR CERTIFIED REFERENCE DIODES

1. DIODE IDENTIFICATION: The diodes are shipped attached to their certification papers and each diode is individually packaged with the diode identification on the package. Identification includes JEDEC type number and a diode serial number consisting of 7 digits showing the lot number and diode number, which provide traceability to factory records.

2. PRECAUTIONS: The normal precautions must be taken when soldering as with any semiconductor device, such as a thermal shunt between the soldering iron and the diode body. "Mechanical" rather than solder mounting is preferred for optimum performance. Mounting the diode inside a large thermal mass such as aluminum, copper, brass, or epoxy will reduce thermally induced voltage fluctuations discernible as low frequency noise in the 0-3 Hz region of the spectrum.

Certain precautions must be taken to ensure that the diode's stability is fully utilized in the circuit. If the current through the zener is not controlled, the reference voltage will shift due to diode impedance ($\Delta V_Z = \Delta I_Z \times Z_{ZT}$). If the diode's junction temperature is allowed to change, due to a change in ambient

or case temperature or due to a power level change, a shift in voltage will occur consistent with the temperature coefficient of the diode. In addition, the device must be physically mounted so as to give the diode a constant thermal resistance, junction-to-ambient. Drafts, circulating oil, and even the minute convection currents produced by a diode in a closed container can cause shifts in reference voltage greater than those that can be attributed to the diode's inherent stability.

The certified stability of a diode is achieved only under steady state, constant temperature conditions. If the diode is operated at conditions other than the certification test conditions, it is recommended that it be operated for a period of 2 to 3 weeks under circuit operating conditions to achieve rated stability.

A slight derating of voltage-time stability (ΔV_{ZT}) may be experienced if the diode is operated outside the "stable-area" defined in Figure 5.

Temperature coefficients much lower than specified can be attained by operating the diode at the "O" TC crossover current (the current at which the tempera-

6.35 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

ture coefficient changes from positive to negative).

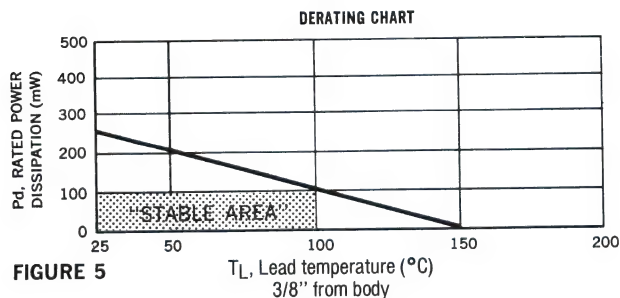
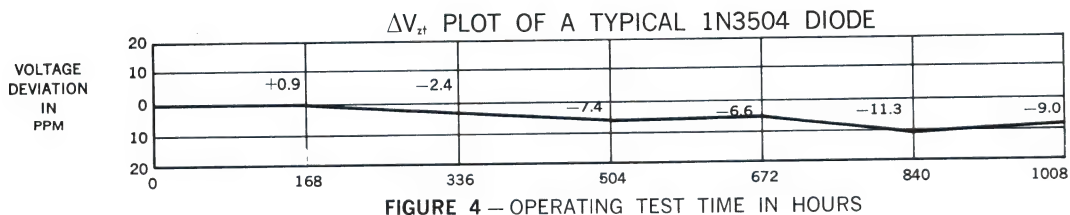
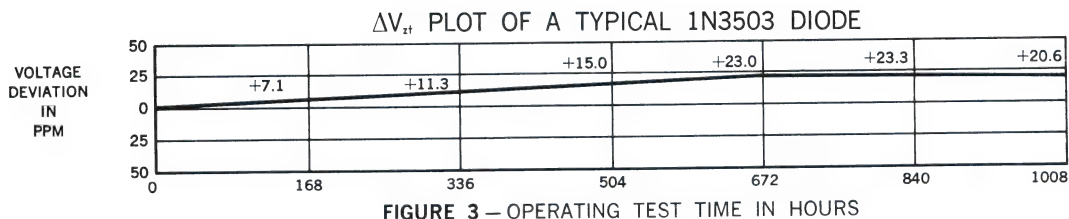
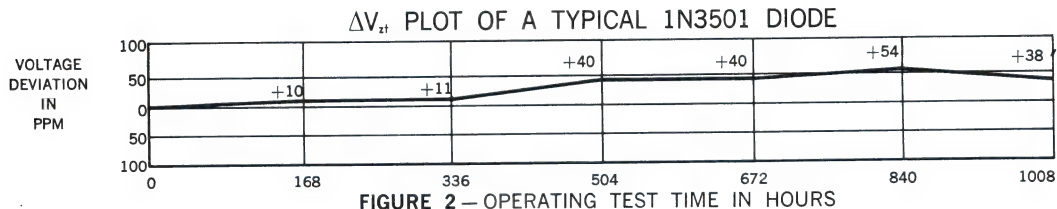
3. MICROSEM¹ TEST METHOD:

Microsem¹ uses a potentiometric method of zener voltage measurement on certified reference diodes. The measurement facility is calibrated utilizing Primary Voltage Standards directly traceable to the National Bureau of Standards. Room ambient temperature is controlled to $\pm 0.5^\circ\text{C}$. Zener voltage is measured to seven digits (1 microvolt resolution). Oil bath temperature is controlled to better than 0.1°C , and current is constant and repeatable to

better than $0.1\ \mu\text{A}$. Test clips are designed for the four-terminal method of measurement (separate voltage and current connections) to eliminate errors caused by resistance. The diodes are thermally shielded by an aluminum thermal filter to reduce thermally created error-causing voltage fluctuations.

4. 1000 HOUR STABILITY TEST

SEQUENCE: Voltage is measured seven times during the test with the last six measurements referenced to the first. The measurements are taken 168 hours apart, giving a total test time of 1008 hours.

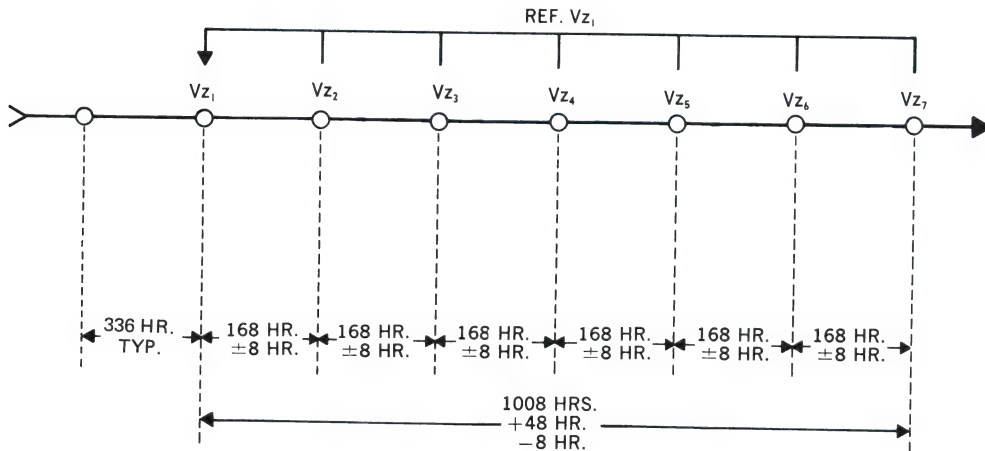


THE "STABLE AREA" IS DEFINED AS THE AREA IN WHICH THE MAXIMUM TIME STABILITY (ΔV_{zt}) IS ATTAINABLE.

A SLIGHT DERATING IN THE TIME STABILITY MAY BE EXPECTED IF THE DIODE IS OPERATED OUTSIDE THIS AREA.

6.35 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

1000 HOUR STABILITY TEST SEQUENCE



Notes:

Test Temperature $80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$

Test Current 7.5 mA. with a constancy and repeatability of ± 0.1 microamp.

The first 336 hours of operation is a stabilization period. The stability of a diode is measured by the worst voltage difference (ΔV_Z) referenced to V_{z1} .

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

1N4057 thru 1N4085A

FEATURES

- ZENER VOLTAGE 12.4V to 200V
- TEMPERATURE COEFFICIENT RANGE: 0.005%/°C to 0.002%/°C

MAXIMUM RATINGS

See Electrical Characteristics Below

DC Power Dissipation: Case CC: 1.5W

At 25°C derate

Case DD: 2W

Linearly to Zero

Case EE: 2.5W

at +150°C

@ 25°C, unless

otherwise specified

*ELECTRICAL CHARACTERISTICS

| JEDEC TYPE NUMBER | ZENER VOLTAGE V _Z (a I _{ZT}) (See Note 1) | ZENER TEST CURRENT (I _{ZT}) MA | MAXIMUM DYNAMICS IMPEDANCE (a I _{ZT}) OHMS | MAXIMUM TEMPER- ATURE COEFFICIENT (See Note 2) α _{VZ} ± % / °C | TEMPERATURE RANGE °C | CASE TYPE NO. |
|-------------------------|---|---|---|--|----------------------------|---------------------|
| 1N4057 | 12.4 | 10.0 | 25 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4057A | 12.4 | 10.0 | 25 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4058 | 14.6 | 10.0 | 30 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4058A | 14.6 | 10.0 | 30 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4059 | 16.8 | 10.0 | 30 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4059A | 16.8 | 10.0 | 30 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4060 | 18.5 | 10.0 | 30 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4060A | 18.5 | 10.0 | 30 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4061 | 21 | 10.0 | 35 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4061A | 21 | 10.0 | 35 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4062 | 23 | 10.0 | 40 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4062A | 23 | 10.0 | 40 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4063 | 27 | 10.0 | 45 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4063A | 27 | 10.0 | 45 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4064 | 30 | 10.0 | 50 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4064A | 30 | 10.0 | 50 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4065 | 33 | 10.0 | 55 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4065A | 33 | 10.0 | 55 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4066 | 37 | 7.5 | 80 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4066A | 37 | 7.5 | 80 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4067 | 43 | 7.5 | 90 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4067A | 43 | 7.5 | 90 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4068 | 47 | 7.5 | 100 | ±0.005 | 55 to +25 to +100 | CC |
| 1N4068A | 47 | 7.5 | 100 | ±0.002 | 55 to +25 to +100 | CC |
| 1N4069 | 51 | 7.5 | 110 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4069A | 51 | 7.5 | 110 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4070 | 56 | 7.5 | 120 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4070A | 56 | 7.5 | 120 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4071 | 62 | 7.5 | 135 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4071A | 62 | 7.5 | 135 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4072 | 68 | 5.0 | 230 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4072A | 68 | 5.0 | 230 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4073 | 75 | 5.0 | 250 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4073A | 75 | 5.0 | 250 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4074 | 82 | 5.0 | 270 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4074A | 82 | 5.0 | 270 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4075 | 87 | 5.0 | 290 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4075A | 87 | 5.0 | 290 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4076 | 91 | 5.0 | 310 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4076A | 91 | 5.0 | 310 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4077 | 100 | 5.0 | 340 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4077A | 100 | 5.0 | 340 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4078 | 105 | 2.5 | 700 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4078A | 105 | 2.5 | 700 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4079 | 110 | 2.5 | 740 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4079A | 110 | 2.5 | 740 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4080 | 120 | 2.5 | 800 | ±0.005 | 55 to +25 to +100 | DD |
| 1N4080A | 120 | 2.5 | 800 | ±0.002 | 55 to +25 to +100 | DD |
| 1N4081 | 130 | 2.5 | 840 | ±0.005 | 55 to +25 to +100 | EE |
| 1N4081A | 130 | 2.5 | 840 | ±0.002 | 55 to +25 to +100 | EE |
| 1N4082 | 140 | 2.5 | 960 | ±0.005 | 55 to +25 to +100 | EE |
| 1N4082A | 140 | 2.5 | 960 | ±0.002 | 55 to +25 to +100 | EE |
| 1N4083 | 150 | 2.5 | 1020 | ±0.005 | 55 to +25 to +100 | EE |
| 1N4083A | 150 | 2.5 | 1020 | ±0.002 | 55 to +25 to +100 | EE |
| 1N4084 | 175 | 2.5 | 1150 | ±0.005 | 55 to +25 to +100 | EE |
| 1N4084A | 175 | 2.5 | 1150 | ±0.002 | 55 to +25 to +100 | EE |
| 1N4085 | 200 | 2.5 | 1350 | ±0.005 | 55 to +25 to +100 | EE |
| 1N4085A | 200 | 2.5 | 1350 | ±0.002 | 55 to +25 to +100 | EE |

* JEDEC Registered Data

HIGH VOLTAGE TEMPERATURE COMPENSATED ZENER DIODES

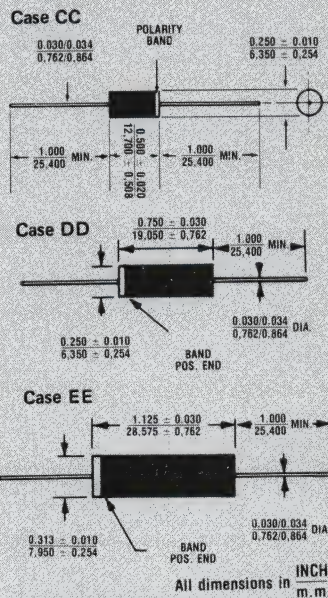


FIGURE 1

MECHANICAL CHARACTERISTICS

FINISH: All external surfaces are corrosion resistant and leads solderable.

MOUNTING POSITION: Any.

1N4057 thru 1N4085A

NOTE 1

Voltage measurements to be performed 15 seconds after application of DC current.

NOTE 2

The 1N4057 through 1N4085 series is specified over the temperature range -55°C to $+100^{\circ}\text{C}$ with measurements made at -55°C , $+100^{\circ}\text{C}$, and at the reference temperature $+25^{\circ}\text{C}$. The maximum voltage change over the range -55°C to $+25^{\circ}\text{C}$ and $+25^{\circ}\text{C}$ to $+100^{\circ}\text{C}$ for this series is limited to the values (expressed in $\text{mV}/^{\circ}\text{C}$) shown in the table on the reverse page. These values are computed by considering the temperature coefficient to be an average over the temperature range. For example, there is an 80°C change in temperature from -55°C to $+25^{\circ}\text{C}$. At an average temperature coefficient of $0.005\%/^{\circ}\text{C}$, the maximum percentage change in voltage would be: $80^{\circ}\text{C} \times 0.005\%/^{\circ}\text{C}$ or 0.4% . For the 1N4057, having a nominal zener voltage of 12.4 volts, the maximum allowable voltage change would be: 0.4% of 12.4 volts or 49.6 millivolts.

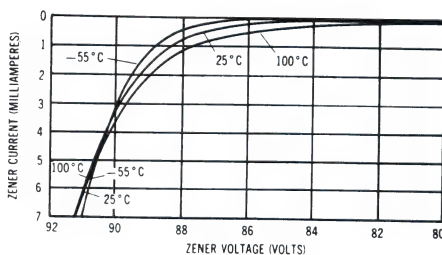


FIGURE 2

TYPICAL VOLT-AMPERE CURVE OF 1N4076A

FEATURES

- 6.4 V $\pm 5\%$ ZENER VOLTAGE (NOTE 1)
- TEMPERATURE COEFFICIENT RANGE: 0.01%/°C TO 0.0005%/°C
- ZENER TEST CURRENT RANGE: 500 μ A TO 4 mA
- 1N4565A THRU 1N4574A HAVE JAN, JANTX, JANTXV QUALIFICATIONS TO MIL-8-19500/452
- RADIATION HARDENED DEVICES AVAILABLE (SEE NOTE 4)
- ALSO AVAILABLE IN DO-35 PACKAGE WITH JAN, JANTX, JANTXV-1 QUALIFICATIONS

MAXIMUM RATINGS

Power Dissipation: 400 mW, at 50°C ambient
(derate 3.2mw/°C above 50°C ambient)

Operating and Storage Temperature: -65 to +175°C

Leakage Current: @ 3 V: 10 μ A

@ 25°C, unless
otherwise specified

* ELECTRICAL CHARACTERISTICS

| JEDEC TYPE NO. | (NOTE 3) ZENER TEST CURRENT mA | MAXIMUM VOLTAGE TEMPERATURE COEFFICIENT | | | MAX. DYNAMIC ZENER IMPEDANCE OHMS (Note 2) |
|-------------------|---|---|----------------------------------|---------------|---|
| | | $\alpha_{VZ} \pm \%/^{\circ}\text{C}$ | $\pm \text{mV}/^{\circ}\text{C}$ | TEMP. RANGE | |
| 1N4565 | 5 | .01 | .64 | 0 to +75°C | 200 |
| 1N4565A | 5 | .01 | .64 | -55 to +100°C | 200 |
| 1N4566 | 5 | .005 | .32 | 0 to +75°C | 200 |
| 1N4566A | 5 | .005 | .32 | -55 to +100°C | 200 |
| 1N4567 | 5 | .002 | .13 | 0 to +75°C | 200 |
| 1N4567A | 5 | .002 | .13 | -55 to +100°C | 200 |
| 1N4568 | 5 | .001 | .06 | 0 to +75°C | 200 |
| 1N4568A | 5 | .001 | .06 | -55 to +100°C | 200 |
| 1N4569 | 5 | .0005 | .03 | 0 to +75°C | 200 |
| 1N4569A | 5 | .0005 | .03 | -55 to +100°C | 200 |
| 1N4570 | 1.0 | .01 | .64 | 0 to +75°C | 100 |
| 1N4570A | 1.0 | .01 | .64 | -55 to +100°C | 100 |
| 1N4571 | 1.0 | .005 | .32 | 0 to +75°C | 100 |
| 1N4571A | 1.0 | .005 | .32 | -55 to +100°C | 100 |
| 1N4572 | 1.0 | .002 | .13 | 0 to +75°C | 100 |
| 1N4572A | 1.0 | .002 | .13 | -55 to +100°C | 100 |
| 1N4573 | 1.0 | .001 | .06 | 0 to +75°C | 100 |
| 1N4573A | 1.0 | .001 | .06 | -55 to +100°C | 100 |
| 1N4574 | 1.0 | .0005 | .03 | 0 to +75°C | 100 |
| 1N4574A | 1.0 | .0005 | .03 | -55 to +100°C | 100 |
| 1N4575 | 2.0 | .01 | .64 | 0 to +75°C | 50 |
| 1N4575A | 2.0 | .01 | .64 | -55 to +100°C | 50 |
| 1N4576 | 2.0 | .005 | .32 | 0 to +75°C | 50 |
| 1N4576A | 2.0 | .005 | .32 | -55 to +100°C | 50 |
| 1N4577 | 2.0 | .002 | .13 | 0 to +75°C | 50 |
| 1N4577A | 2.0 | .002 | .13 | -55 to +100°C | 50 |
| 1N4578 | 2.0 | .001 | .06 | 0 to +75°C | 50 |
| 1N4578A | 2.0 | .001 | .06 | -55 to +100°C | 50 |
| 1N4579 | 2.0 | .0005 | .03 | 0 to +75°C | 50 |
| 1N4579A | 2.0 | .0005 | .03 | -55 to +100°C | 50 |
| 1N4580 | 4.0 | .01 | .64 | 0 to +75°C | 25 |
| 1N4580A | 4.0 | .01 | .64 | -55 to +100°C | 25 |
| 1N4581 | 4.0 | .005 | .32 | 0 to +75°C | 25 |
| 1N4581A | 4.0 | .005 | .32 | -55 to +100°C | 25 |
| 1N4582 | 4.0 | .002 | .13 | 0 to +75°C | 25 |
| 1N4582A | 4.0 | .002 | .13 | -55 to +100°C | 25 |
| 1N4583 | 4.0 | .001 | .06 | 0 to +75°C | 25 |
| 1N4583A | 4.0 | .001 | .06 | -55 to +100°C | 25 |
| 1N4584 | 4.0 | .0005 | .03 | 0 to +75°C | 25 |
| 1N4584A | 4.0 | .0005 | .03 | -55 to +100°C | 25 |

* JEDEC Registered Data

NOTE 1 For specific device selections above requiring tighter tolerances than $\pm 5\%$, inquire with factory as to nominal zener voltage available.

NOTE 2 Measured by superimposing rms AC current equal to 10% zener test current @ 25°C. The temperature coefficient of zener impedance is approx. +0.3%/°C.

NOTE 3 Voltage measurements to be performed 15 seconds after application of DC current.

NOTE 4 Designate Radiation Hardened devices with "RH" prefix instead of "1N," i.e., RH4584A.

1N4565 & A thru 1N4584 & A

6.4 VOLT TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

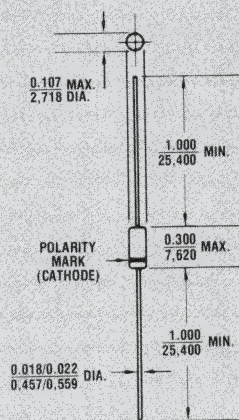


FIGURE 1

All dimensions in
INCH
m. m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

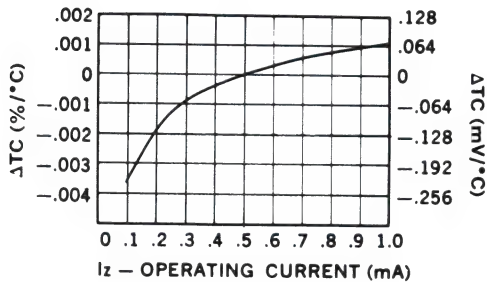
POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

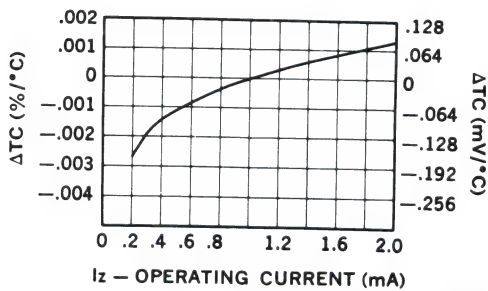
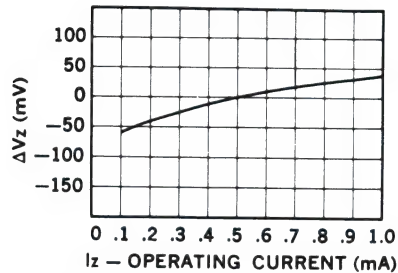
1N4565 thru 1N4584A

TYPICAL CHANGE OF
TEMPERATURE COEFFICIENT
WITH CHANGE IN
OPERATING CURRENT

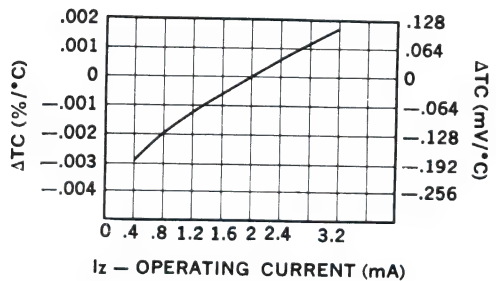
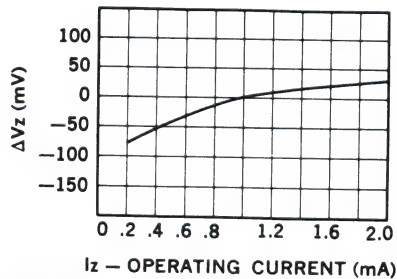


1N4565 — 1N4569A

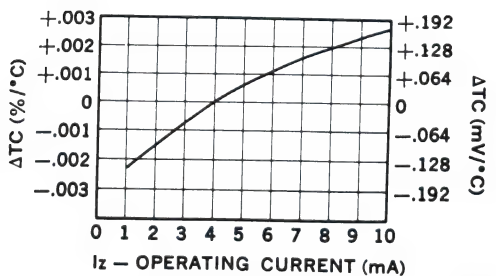
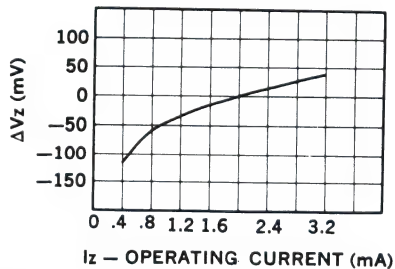
TYPICAL CHANGE
IN ZENER VOLTAGE
WITH CHANGE IN
OPERATING CURRENT



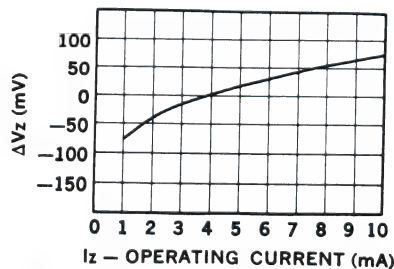
1N4570 — 1N4574A



1N4575 — 1N4579A



1N4580 — 1N4584A



1N4765 thru 1N4774A

FEATURES

- ZENER VOLTAGE 9.1 V
- TEMPERATURE COEFFICIENT RANGE: 0.01%/°C TO 0.0005%/°C
- RADIATION HARDENED DEVICES AVAILABLE (SEE NOTE 4)

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C

DC Power Dissipation: 250 mW

Power Derating: 2 mW/°C above 50°C

* ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NUMBER | ZENER VOLTAGE (NOTE 3) | ZENER TEST CURRENT | MAXIMUM DYNAMIC IMPEDANCE (Note 1) | MAXIMUM VOLTAGE TEMPERATURE STABILITY (NOTE 2 & 3) | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COMPENSATIONS α_{VZ} |
|-------------------------|------------------------------|--------------------------|---|--|----------------------|--|
| | $V_Z @ I_{ZT}$ VOLTS | I_{ZT} mA | Z_{ZT} OHMS | ΔV_{ZT} mV | | |
| 1N4765 | 9.1 | 0.5 | 350 | 68 | 0 to +75 | 0.01 |
| 1N4765A | 9.1 | 0.5 | 350 | 141 | -55 to +100 | 0.01 |
| 1N4766 | 9.1 | 0.5 | 350 | 34 | 0 to +75 | 0.005 |
| 1N4766A | 9.1 | 0.5 | 350 | 70 | -55 to +100 | 0.005 |
| 1N4767 | 9.1 | 0.5 | 350 | 14 | 0 to +75 | 0.002 |
| 1N4767A | 9.1 | 0.5 | 350 | 28 | -55 to +100 | 0.002 |
| 1N4768 | 9.1 | 0.5 | 350 | 7 | 0 to +75 | 0.001 |
| 1N4768A | 9.1 | 0.5 | 350 | 14 | -55 to +100 | 0.001 |
| 1N4769 | 9.1 | 0.5 | 350 | 3 | 0 to +75 | 0.0005 |
| 1N4769A | 9.1 | 0.5 | 350 | 7 | -55 to +100 | 0.0005 |
| 1N4770 | 9.1 | 1.0 | 200 | 68 | 0 to +75 | 0.01 |
| 1N4770A | 9.1 | 1.0 | 200 | 141 | -55 to +100 | 0.01 |
| 1N4771 | 9.1 | 1.0 | 200 | 34 | 0 to +75 | 0.005 |
| 1N4771A | 9.1 | 1.0 | 200 | 70 | -55 to +100 | 0.005 |
| 1N4772 | 9.1 | 1.0 | 200 | 14 | 0 to +75 | 0.002 |
| 1N4772A | 9.1 | 1.0 | 200 | 28 | -55 to +100 | 0.002 |
| 1N4773 | 9.1 | 1.0 | 200 | 7 | 0 to +75 | 0.001 |
| 1N4773A | 9.1 | 1.0 | 200 | 14 | -55 to +100 | 0.001 |
| 1N4774 | 9.1 | 1.0 | 200 | 3 | 0 to +75 | 0.0005 |
| 1N4774A | 9.1 | 1.0 | 200 | 7 | -55 to +100 | 0.0005 |

*JEDEC Registered Data.

NOTE 1 Measured by superimposing I_Z ac rms on I_Z DC @ +25°C where I_Z ac rms = 10% I_Z DC.

NOTE 2 Maximum allowable change between any two discrete temperatures over the specified temperature range.

NOTE 3 Voltage measurements to be performed 15 seconds after application of DC current.

NOTE 4 Designate Radiation Hardened devices with "RH" prefix instead of "1N," i.e., RH4774A.

9.1 VOLT TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

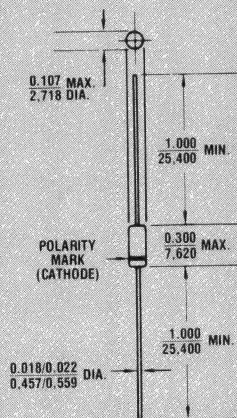


FIGURE 1

INCH
All dimensions in
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N4765 thru 1N4774A

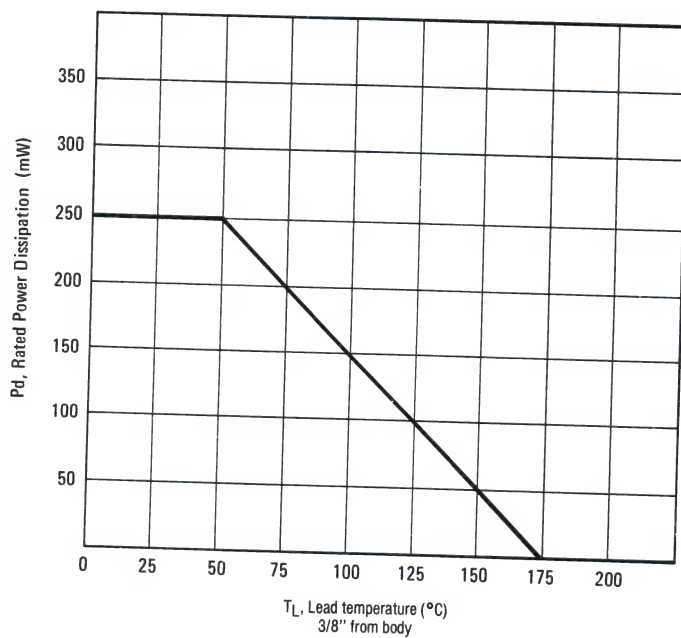


FIGURE 2 POWER DERATING CURVE

1N4775 thru 1N4784A

FEATURES

- ZENER VOLTAGE 8.5 V (SEE NOTE 4)
- TEMPERATURE COEFFICIENT RANGE: 0.01%/°C TO 0.0005%/°C
- RADIATION HARDENED DEVICES AVAILABLE (SEE NOTE 1)

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C
DC Power Dissipation: 250 mW
Power Derating: 2 mW/°C above 50°C

*ELECTRICAL CHARACTERISTICS

@ 25°C, unless otherwise specified

| JEDEC TYPE NUMBER | ZENER VOLTAGE (NOTE 5) | ZENER TEST CURRENT | MAXIMUM DYNAMIC IMPEDANCE (NOTE 2) | MAXIMUM VOLTAGE TEMPERATURE STABILITY (NOTES 3 & 5) | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COMPENSATIONS α_{VZ} |
|-------------------------|------------------------------|--------------------------|---|---|----------------------|--|
| | $V_Z @ I_{ZT}$ | I_{ZT} | Z_{ZT} | ΔV_{ZT} | °C | %/°C |
| | VOLTS | mA | OHMS | mV | | |
| 1N4775 | 8.5 | 0.5 | 200 | 64 | 0 to +75 | 0.01 |
| 1N4775A | 8.5 | 0.5 | 200 | 132 | -55 to +100 | 0.01 |
| 1N4776 | 8.5 | 0.5 | 200 | 32 | 0 to +75 | 0.005 |
| 1N4776A | 8.5 | 0.5 | 200 | 66 | -55 to +100 | 0.005 |
| 1N4777 | 8.5 | 0.5 | 200 | 13 | 0 to +75 | 0.002 |
| 1N4777A | 8.5 | 0.5 | 200 | 26 | -55 to +100 | 0.002 |
| 1N4778 | 8.5 | 0.5 | 200 | 6 | 0 to +75 | 0.001 |
| 1N4778A | 8.5 | 0.5 | 200 | 13 | -55 to +100 | 0.001 |
| 1N4779 | 8.5 | 0.5 | 200 | 3 | 0 to +75 | 0.0005 |
| 1N4779A | 8.5 | 0.5 | 200 | 7 | -55 to +100 | 0.0005 |
| 1N4780 | 8.5 | 1.0 | 100 | 64 | 0 to +75 | 0.01 |
| 1N4780A | 8.5 | 1.0 | 100 | 132 | -55 to +100 | 0.01 |
| 1N4781 | 8.5 | 1.0 | 100 | 32 | 0 to +75 | 0.005 |
| 1N4781A | 8.5 | 1.0 | 100 | 66 | -55 to +100 | 0.005 |
| 1N4782 | 8.5 | 1.0 | 100 | 13 | 0 to +75 | 0.002 |
| 1N4782A | 8.5 | 1.0 | 100 | 26 | -55 to +100 | 0.002 |
| 1N4783 | 8.5 | 1.0 | 100 | 6 | 0 to +75 | 0.001 |
| 1N4783A | 8.5 | 1.0 | 100 | 13 | -55 to +100 | 0.001 |
| 1N4784 | 8.5 | 1.0 | 100 | 3 | 0 to +75 | 0.0005 |
| 1N4784A | 8.5 | 1.0 | 100 | 7 | -55 to +100 | 0.0005 |

*JEDEC Registered Data.

NOTE 1 Designate Radiation Hardened devices with "RH" prefix instead of "1N," i.e., RH4784A.

8.5 VOLT TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

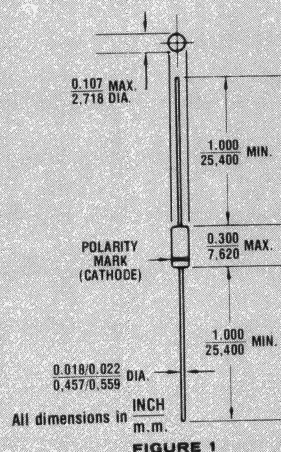


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N4775 thru 1N4784A

NOTE 2 Measured by superimposing I_Z ac rms on I_Z DC @ 75°C where I_Z ac rms = 10% I_Z DC.

NOTE 3 Maximum allowable change between any two discrete temperatures over the specified temperature change.

NOTE 4 When ordering devices with a tighter tolerance than specified, use a nominal center voltage of 8.8 volts.

NOTE 5 Voltage measurements to be performed 15 seconds after application of DC current.

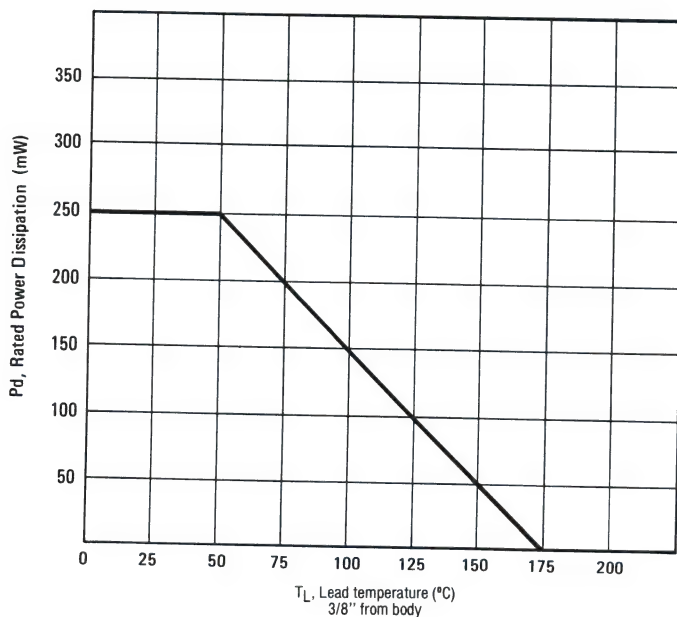
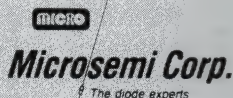


FIGURE 2 POWER DERATING CURVE



SANTA ANA, CA

SCOTTSDALE, AZ
For more information call:
(602) 941-6300

1N4890 thru 1N4895 and 1N4890A thru 1N4895A WITH CERTIFIED ZENER VOLTAGE STABILITY

DESCRIPTION

This series of Microsemi 400mW Ultra-Stable Reference Diodes offers a CERTIFIED REFERENCE VOLTAGE STABILITY as measured over an actual operating period of 1000 hours. Standard stabilities are 10, 20, and 50 PPM/1000 hours. Units having stabilities of less than 5 PPM/1000 hours are available on special request.

Ultra-Stable Certified Reference Diodes, available in standard or radiation hardened construction, can be used in any circuit that requires a stable reference voltage that is insensitive to shock, vibration, or position. Their inherent stability allows them to be used in circuits requiring an extremely high degree of voltage time stability such as those in Digital Voltmeters, Computers, X-Y Recorders, Missile Guidance and Environmental Control Systems, and Portable Reference Standards. Wherever accurate and reliable measurements are to be made, the Microsemi "Ultra-Stable" diode excels as the Standard Reference device.

All devices in this series have been subjected to Microsemi's 1000 hour Stability Test Sequence, consisting of a 1000 hour power age with reference voltage measured once every 168 hours giving a total of 7 individual test points. The stability test is performed at $80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$.

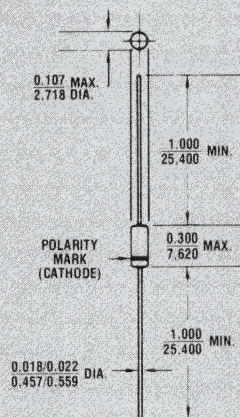
A Certificate containing the following data is supplied with each diode:

1. The stability test voltage readings.
2. The voltage drift as referenced to "Zero Hour" in both μV and in PPM (Parts-Per-Million).

To certify these diodes to such tight stabilities as 10 PPM/1000 hours, every factor of environment, both ambient and electrical is considered and controlled to "Standards Laboratory" accuracy. Room ambient temperature is controlled to $\pm 1^{\circ}\text{C}$. The temperature of the oil bath is controlled to better than $\pm 0.1^{\circ}\text{C}$. Test current is maintained constant and repeatable to within 0.0001 mA. The measurement facility is calibrated utilizing Primary Voltage Standards directly traceable to the National Bureau of Standards.

To specify radiation hardened devices, use "RH" prefix instead of "1N", i.e. RH4895A instead of 1N4895A.

6.35 VOLT ULTRA STABLE TEMPERATURE COMPENSATED ZENER REFERENCE DIODES



All dimensions in
INCH
m.m.

FIGURE 1

6.35 VOLT ULTRA-STABLE (T. C.) ZENER REFERENCE DIODES

MAXIMUM RATINGS (See Fig. 5)

Operating Temperature Range: -65°C to $+175^{\circ}\text{C}$
 Maximum Lead Temperature $1/16 \pm 1/32$ inch from case for 10 seconds: 230°C
 Maximum DC Power Dissipation at or below 50°C Ambient: 400 mW
 Linear Derating: $3.2 \text{ mW}/^{\circ}\text{C}$ (See Figure 5)
 Maximum Steady State Current (I_{ZM}) at 150°C : 7.5 mA

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass
 Dimensions: DO-7 outline
 Finish: All external surfaces are corrosion resistant and leads are readily solderable
 Polarity: Diode to be operated with the banded end positive
 Weight: 0.2 grams (typical)
 Mounting Position: Any

***ELECTRICAL CHARACTERISTICS** @ 25°C , unless otherwise specified

| JEDEC TYPE NUMBER | NOMINAL ZENER VOLTAGE $\pm 5\%$ V_Z @ I_{ZT} | ZENER TEST CURRENT $\pm 0.01 \text{ mA}$ I_{ZT} | MAXIMUM ZENER IMPEDANCE Z_{ZT} @ I_{ZT} (NOTE 1) | VOLTAGE TEMPERATURE STABILITY ΔV_{ZT} MAXIMUM (NOTE 2) | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT α_{VZ} | VOLTAGE TIME STABILITY @ 80°C INITIAL-TO PEAK ΔV_{ZT} MAXIMUM (NOTE 3) | EFFECTIVE VOLTAGE TIME STABILITY INITIAL-TO-PEAK |
|-------------------|--|---|--|--|--------------------|---|--|--|
| | VOLTS | mA | OHMS | mV | $^{\circ}\text{C}$ | $\%/^{\circ}\text{C}$ | $\mu\text{V}/1000 \text{ HRS.}$ | PPM/1000 HRS. |
| 1N4890 | 6.35 | 7.5 | 10 | 5.0 | 25 to 100 | 0.001 | 318 | 50 |
| 1N4890A | 6.35 | 7.5 | 10 | 10.0 | -55 to 100 | 0.001 | 318 | 50 |
| 1N4891 | 6.35 | 7.5 | 10 | 2.5 | 25 to 100 | 0.0005 | 318 | 50 |
| 1N4891A | 6.35 | 7.5 | 10 | 5.0 | -55 to 100 | 0.0005 | 318 | 50 |
| 1N4892 | 6.35 | 7.5 | 10 | 5.0 | 25 to 100 | 0.001 | 127 | 20 |
| 1N4892A | 6.35 | 7.5 | 10 | 10.0 | -55 to 100 | 0.001 | 127 | 20 |
| 1N4893 | 6.35 | 7.5 | 10 | 2.5 | 25 to 100 | 0.0005 | 127 | 20 |
| 1N4893A | 6.35 | 7.5 | 10 | 5.0 | -55 to 100 | 0.0005 | 127 | 20 |
| 1N4894 | 6.35 | 7.5 | 10 | 5.0 | 25 to 100 | 0.001 | 64 | 10 |
| 1N4894A | 6.35 | 7.5 | 10 | 10.0 | -55 to 100 | 0.001 | 64 | 10 |
| 1N4895 | 6.35 | 7.5 | 10 | 2.5 | 25 to 100 | 0.0005 | 64 | 10 |
| 1N4895A | 6.35 | 7.5 | 10 | 5.0 | -55 to 100 | 0.0005 | 64 | 10 |

NOTE 1

The zener impedance is derived from the 60 Hz ac voltage which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT}) is superimposed on I_{ZT} .

NOTE 2

Maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.

NOTE 3

When operated at:

$I_{ZT} = 7.5 \text{ mA} \pm 0.0001 \text{ mA}$

$T_A = 80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$

(See Note 2 Below)

NOTES AND PRECAUTIONS FOR CERTIFIED REFERENCE DIODES

1. DIODE IDENTIFICATION: The diodes are shipped attached to their certification papers and each diode is individually packaged with the diode identification on the package. Identification includes JEDEC type number and a diode serial number consisting of 7 digits showing the lot number and diode number, which provide traceability to factory records.

2. PRECAUTIONS: The normal precautions must be taken when soldering as with any semiconductor device, such as a thermal shunt between the

soldering iron and the diode body. "Mechanical" rather than solder mounting is preferred for optimum performance. Mounting the diode inside a large thermal mass such as aluminum, copper, brass, or epoxy will reduce thermally induced voltage fluctuations discernible as low frequency noise in the 0-3 Hz region of the spectrum.

Certain precautions must be taken to ensure that the diode's stability is fully utilized in the circuit. If the current through the zener is not controlled, the refer-

6.35 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

ence voltage will shift due to diode impedance ($\Delta V_Z = \Delta I_Z \times Z_{ZT}$). If the diode's junction temperature is allowed to change, due to a change in ambient or case temperature or due to a power level change, a shift in voltage will occur consistent with the temperature coefficient of the diode. In addition, the device must be physically mounted so as to give the diode a constant thermal resistance, junction-to-ambient. Drafts, circulating oil, and even the minute convection currents produced by a diode in a closed container can cause shifts in reference voltage greater than those that can be attributed to the diode's inherent stability.

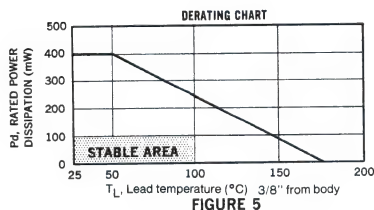
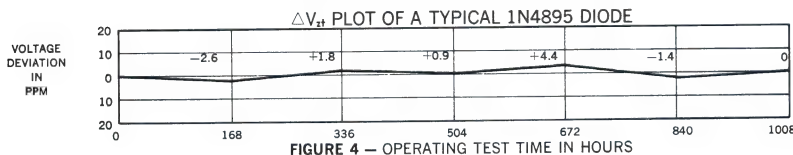
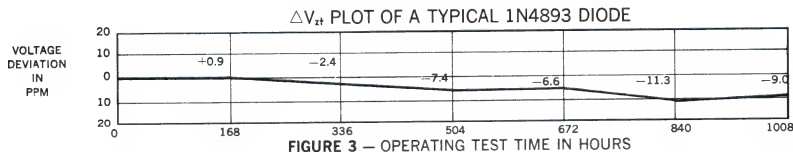
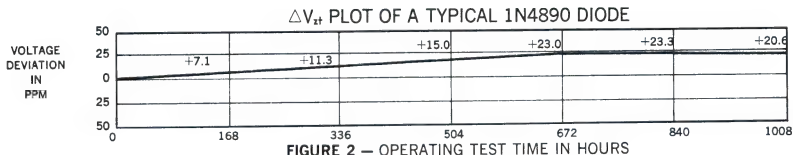
It *must* be understood that the certified stability is possible only under steady-state, constant temperature conditions. The stability of an ultra-stable zener reference diode may be upset by severe changes in junction temperature. In addition, a slight derating of voltage-time stability (ΔV_{ZT}) may be experienced if the diode is operated outside the "stable-area" defined in Figure 5. The effect of turning the diode's current off and on at a constant temperature is negligible (except for thermal warmup of diode). The certified stability of the diode is considered to be a worst case "inherent" junction stability, and will be realized only after 2 or 3 weeks of operation under *actual operating conditions*. This might be in the user's circuit or finished product, however, the device must have this time to reach an "equilibrium" at operating conditions. The "inherent" stability of the

device is never upset unless maximum ratings are surpassed. A new "equilibrium" must be reached with each new operating condition.

Temperature coefficients much lower than specified can be attained by operating the diode at "0" TC crossover current (the point at which TC goes from positive to negative or vice-versa), however, a new "equilibrium" must be reached before full stability will be attained.

3. MICROSEMI TEST METHOD: Microsemi uses a potentiometric method of zener voltage measurement on certified reference diodes. Zener voltage is measured to seven digits (1 microvolt resolution). Voltage calibration is directly traceable to the National Bureau of Standards. Oil bath temperature is controlled to better than 0.1°C, and current is constant and repeatable to better than $\pm 0.1 \mu A$. Test clips are designed for the four-terminal method of measurement (separate voltage and current connections) to eliminate errors caused by resistance. The diodes are thermally shielded by an aluminum thermal filter to reduce thermally created error causing voltage fluctuations.

4. 1000 HOUR STABILITY TEST SEQUENCE: Voltage is measured seven times during the test with the last six measurements referenced to the first. The measurements are taken 168 hours apart, giving a total test time of 1008 hours.

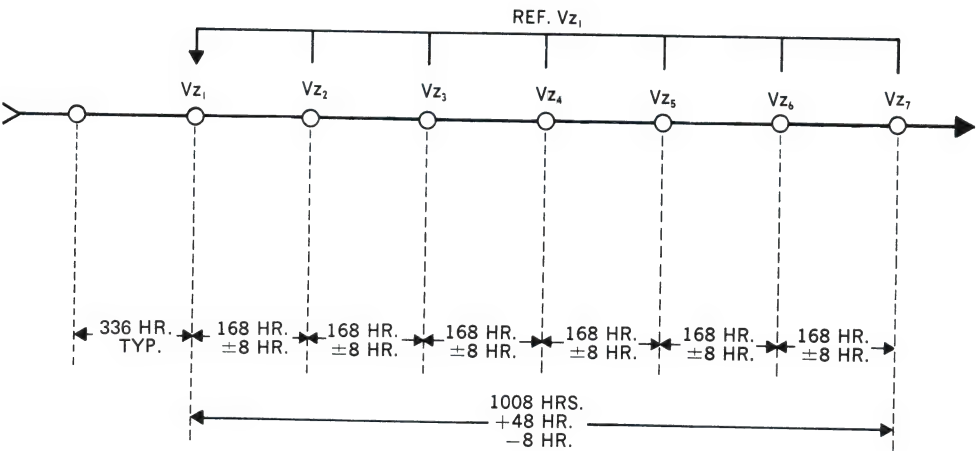


THE "STABLE AREA" IS DEFINED AS THE AREA IN WHICH THE MAXIMUM TIME STABILITY (ΔV_{ZT}) IS ATTAINABLE.

A SLIGHT DERATING IN THE TIME STABILITY MAY BE EXPECTED IF THE DIODE IS OPERATED OUTSIDE THIS AREA.

6.35 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

1000 HOUR STABILITY TEST SEQUENCE



Notes:

Test Temperature $80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$

Test Current 7.5 mA, with a constancy and repeatability of ± 0.1 microamp.

The first 336 hours of operation is a stabilization period. The stability of a diode is measured by the worst voltage difference (ΔV_z) referenced to V_{z1} .

1N4896 thru 1N4915A

FEATURES

- ZENER VOLTAGE 12.8V
- TEMPERATURE COEFFICIENT RANGE: 0.01%/°C to 0.001%/°C
- N_D YIELDS MAXIMUM-RMS NOISE FOR ANY BANDWIDTH

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +175°C

DC Power Dissipation: 400 mW

Power Derating: 3.20 mW/°C above 50°C

* ELECTRICAL CHARACTERISTICS

@ 25°C, unless otherwise specified

| JEDEC TYPE NUMBER | TEST CURRENT I_{ZT} (Note 1 & 5) | MAX. VOLTAGE CHANGE WITH TEMPERATURE ΔV_{ZT} (Note 2 & 5) | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT α_{VZ} (Note 3) | MAXIMUM DYNAMIC IMPEDANCE Z_{ZT} (Note 4) | MAXIMUM NOISE DENSITY N_D |
|-------------------------|---|---|----------------------|--|---|--------------------------------------|
| | mA | VOLTS | °C | ± %/°C | OHMS | $\mu V/\sqrt{cps}$ |
| 1N4896 | 0.5 | 0.096 | +25 to +100 | 0.01 | 400 | 0.8 |
| 1N4896A | 0.5 | 0.198 | -55 to +100 | 0.01 | 400 | 0.8 |
| 1N4897 | 0.5 | 0.048 | +25 to +100 | 0.005 | 400 | 0.8 |
| 1N4897A | 0.5 | 0.099 | -55 to +100 | 0.005 | 400 | 0.8 |
| 1N4898 | 0.5 | 0.019 | +25 to +100 | 0.002 | 400 | 0.8 |
| 1N4898A | 0.5 | 0.040 | -55 to +100 | 0.002 | 400 | 0.8 |
| 1N4899 | 0.5 | 0.010 | +25 to +100 | 0.001 | 400 | 0.8 |
| 1N4899A | 0.5 | 0.020 | -55 to +100 | 0.001 | 400 | 0.8 |
| 1N4900 | 1.0 | 0.096 | +25 to +100 | 0.01 | 200 | 0.4 |
| 1N4900A | 1.0 | 0.198 | -55 to +100 | 0.01 | 200 | 0.4 |
| 1N4901 | 1.0 | 0.048 | +25 to +100 | 0.005 | 200 | 0.4 |
| 1N4901A | 1.0 | 0.099 | -55 to +100 | 0.005 | 200 | 0.4 |
| 1N4902 | 1.0 | 0.019 | +25 to +100 | 0.002 | 200 | 0.4 |
| 1N4902A | 1.0 | 0.040 | -55 to +100 | 0.002 | 200 | 0.4 |
| 1N4903 | 1.0 | 0.010 | +25 to +100 | 0.001 | 200 | 0.4 |
| 1N4903A | 1.0 | 0.020 | -55 to +100 | 0.001 | 200 | 0.4 |
| 1N4904 | 2.0 | 0.096 | +25 to +100 | 0.01 | 100 | 0.25 |
| 1N4904A | 2.0 | 0.198 | -55 to +100 | 0.01 | 100 | 0.25 |
| 1N4905 | 2.0 | 0.048 | +25 to +100 | 0.005 | 100 | 0.25 |
| 1N4905A | 2.0 | 0.099 | -55 to +100 | 0.005 | 100 | 0.25 |
| 1N4906 | 2.0 | 0.019 | +25 to +100 | 0.002 | 100 | 0.25 |
| 1N4906A | 2.0 | 0.040 | -55 to +100 | 0.002 | 100 | 0.25 |
| 1N4907 | 2.0 | 0.010 | +25 to +100 | 0.001 | 100 | 0.25 |
| 1N4907A | 2.0 | 0.020 | -55 to +100 | 0.001 | 100 | 0.25 |
| 1N4908 | 4.0 | 0.096 | +25 to +100 | 0.01 | 50 | 0.22 |
| 1N4908A | 4.0 | 0.198 | -55 to +100 | 0.01 | 50 | 0.22 |
| 1N4909 | 4.0 | 0.048 | +25 to +100 | 0.005 | 50 | 0.22 |
| 1N4909A | 4.0 | 0.099 | -55 to +100 | 0.005 | 50 | 0.22 |
| 1N4910 | 4.0 | 0.019 | +25 to +100 | 0.002 | 50 | 0.22 |
| 1N4910A | 4.0 | 0.040 | -55 to +100 | 0.002 | 50 | 0.22 |
| 1N4911 | 4.0 | 0.010 | +25 to +100 | 0.001 | 50 | 0.22 |
| 1N4911A | 4.0 | 0.020 | -55 to +100 | 0.001 | 50 | 0.22 |
| 1N4912 | 7.5 | 0.096 | +25 to +100 | 0.01 | 25 | 0.20 |
| 1N4912A | 7.5 | 0.198 | -55 to +100 | 0.01 | 25 | 0.20 |
| 1N4913 | 7.5 | 0.048 | +25 to +100 | 0.005 | 25 | 0.20 |
| 1N4913A | 7.5 | 0.099 | -55 to +100 | 0.005 | 25 | 0.20 |
| 1N4914 | 7.5 | 0.019 | +25 to +100 | 0.002 | 25 | 0.20 |
| 1N4914A | 7.5 | 0.040 | -55 to +100 | 0.002 | 25 | 0.20 |
| 1N4915 | 7.5 | 0.010 | +25 to +100 | 0.001 | 25 | 0.20 |
| 1N4915A | 7.5 | 0.020 | -55 to +100 | 0.001 | 25 | 0.20 |

*JEDEC Registered Data.

12.8 VOLT LOW NOISE TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

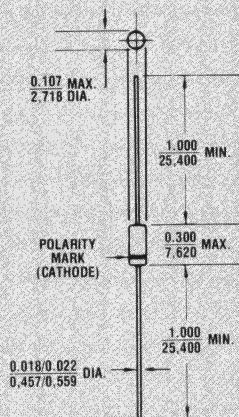


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N4896 thru 1N4915A

NOTE 1 Nominal voltage for all types is 12.8 Volts $\pm 5\%$.

NOTE 2 Referred to as the 'box' measurement method, the ΔV_{ZT} is the maximum voltage variance that will occur as the voltage is scanned thru all temperatures between the temperature range limits.

NOTE 3 The effective temperature coefficients are tabulated in $\%/^{\circ}\text{C}$ primarily for information only since temperature compensated diodes inherently have a non-linear voltage-temperature characteristic.

NOTE 4 The dynamic Zener impedance Z_{ZT} is derived from the resulting a.c. voltage developed when a 60 cps, rms a.c. current equal to 10% of the D.C. Zener current I_{ZT} is superimposed on I_{ZT}

NOTE 5 Voltage measurements to be performed 15 seconds after application of DC current.

Noise Density (N_D) is specified in Microvolts-rms per square root cycle. Actual measurement is performed using a 1.4 KC (1 octave) frequency band-pass at the Zener test current (I_{ZT}) @ 25°C ambient temperature.

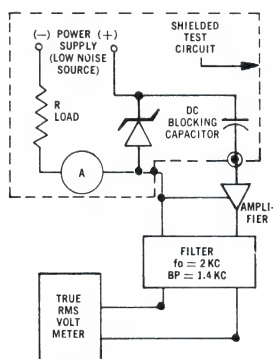


FIGURE 2 NOISE DENSITY MEASUREMENT CIRCUIT

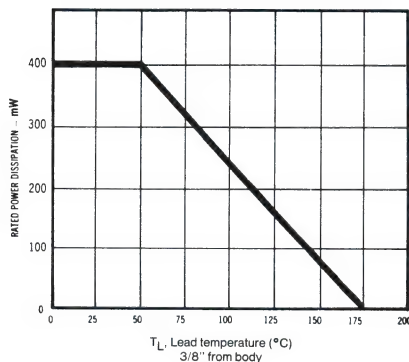


FIGURE 3 POWER DERATING CURVE



SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

1N4916 thru 1N4932A

FEATURES

- ZENER VOLTAGE 19.2V
- TEMPERATURE COEFFICIENT RANGE: 0.01%/°C to 0.001%/°C
- N_D YIELDS MAXIMUM-RMS NOISE FOR ANY BANDWIDTH

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +175°C

DC Power Dissipation: 400 mW

Power Derating: 3.20 mW/°C above 50°C

*ELECTRICAL CHARACTERISTICS

@ 25°C, unless otherwise specified

| JEDEC TYPE NUMBER | TEST CURRENT I_{ZT} (Note 1 & 5) | MAX. VOLTAGE CHANGE WITH TEMPERATURE ΔV_{ZT} (Note 2 & 5) | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT α_{VZ} (Note 3) | MAXIMUM DYNAMIC IMPEDANCE Z_{ZT} (Note 4) | MAXIMUM NOISE DENSITY N_D |
|-------------------------|---|---|----------------------|--|---|--------------------------------------|
| | mA | VOLTS | °C | ± %/°C | OHMS | $\mu V/\sqrt{\text{cps}}$ |
| 1N4916 | 0.5 | 0.144 | +25 to +100 | 0.01 | 600 | 1.0 |
| 1N4916A | 0.5 | 0.298 | -55 to +100 | 0.01 | 600 | 1.0 |
| 1N4917 | 0.5 | 0.072 | +25 to +100 | 0.005 | 600 | 1.0 |
| 1N4917A | 0.5 | 0.149 | -55 to +100 | 0.005 | 600 | 1.0 |
| 1N4918 | 0.5 | 0.029 | +25 to +100 | 0.002 | 600 | 1.0 |
| 1N4918A | 0.5 | 0.060 | -55 to +100 | 0.002 | 600 | 1.0 |
| 1N4919 | 1.0 | 0.144 | +25 to +100 | 0.01 | 300 | 0.5 |
| 1N4919A | 1.0 | 0.298 | -55 to +100 | 0.01 | 300 | 0.5 |
| 1N4920 | 1.0 | 0.072 | +25 to +100 | 0.005 | 300 | 0.5 |
| 1N4920A | 1.0 | 0.149 | -55 to +100 | 0.005 | 300 | 0.5 |
| 1N4921 | 1.0 | 0.029 | +25 to +100 | 0.002 | 300 | 0.5 |
| 1N4921A | 1.0 | 0.060 | -55 to +100 | 0.002 | 300 | 0.5 |
| 1N4922 | 2.0 | 0.144 | +25 to +100 | 0.01 | 150 | 0.25 |
| 1N4922A | 2.0 | 0.298 | -55 to +100 | 0.01 | 150 | 0.25 |
| 1N4923 | 2.0 | 0.072 | +25 to +100 | 0.005 | 150 | 0.25 |
| 1N4923A | 2.0 | 0.149 | -55 to +100 | 0.005 | 150 | 0.25 |
| 1N4924 | 2.0 | 0.029 | +25 to +100 | 0.002 | 150 | 0.25 |
| 1N4924A | 2.0 | 0.060 | -55 to +100 | 0.002 | 150 | 0.25 |
| 1N4925 | 4.0 | 0.144 | +25 to +100 | 0.01 | 75 | 0.22 |
| 1N4925A | 4.0 | 0.298 | -55 to +100 | 0.01 | 75 | 0.22 |
| 1N4926 | 4.0 | 0.072 | +25 to +100 | 0.005 | 75 | 0.22 |
| 1N4926A | 4.0 | 0.149 | -55 to +100 | 0.005 | 75 | 0.22 |
| 1N4927 | 4.0 | 0.029 | +25 to +100 | 0.002 | 75 | 0.22 |
| 1N4927A | 4.0 | 0.060 | -55 to +100 | 0.002 | 75 | 0.22 |
| 1N4928 | 4.0 | 0.014 | +25 to +100 | 0.001 | 75 | 0.22 |
| 1N4928A | 4.0 | 0.030 | -55 to +100 | 0.001 | 75 | 0.22 |
| 1N4929 | 7.5 | 0.144 | +25 to +100 | 0.01 | 36 | 0.20 |
| 1N4929A | 7.5 | 0.298 | -55 to +100 | 0.01 | 36 | 0.20 |
| 1N4930 | 7.5 | 0.072 | +25 to +100 | 0.005 | 36 | 0.20 |
| 1N4930A | 7.5 | 0.149 | -55 to +100 | 0.005 | 36 | 0.20 |
| 1N4931 | 7.5 | 0.029 | +25 to +100 | 0.002 | 36 | 0.20 |
| 1N4931A | 7.5 | 0.060 | -55 to +100 | 0.002 | 36 | 0.20 |
| 1N4932 | 7.5 | 0.014 | +25 to +100 | 0.001 | 36 | 0.20 |
| 1N4932A | 7.5 | 0.030 | -55 to +100 | 0.001 | 36 | 0.20 |

*JEDEC Registered Data.

19.2 VOLT LOW NOISE TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

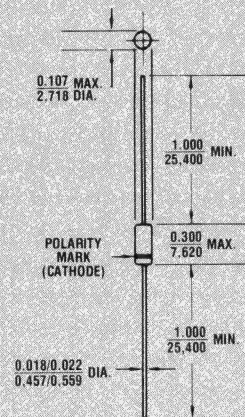


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass
case. DO-7.

FINISH: All external surfaces are
corrosion resistant and leads sol-
derable.

THERMAL RESISTANCE: 300°C/
W (Typical) junction to lead at
0.375-inches from body.

POLARITY: Diode to be operated
with the banded end positive
with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N4916 thru 1N4932A

NOTE 1 Nominal voltage for all types is 19.2 Volts $\pm 5\%$.

NOTE 2 Referred to as the 'box' measurement method, the ΔV_{ZT} is the maximum voltage variance that will occur as the voltage is scanned thru all temperatures between the temperature range limits.

NOTE 3 The effective temperature coefficients are tabulated in $\%/^{\circ}\text{C}$ primarily for information only because temperature compensated diodes inherently have a non-linear voltage-temperature relationship.

NOTE 4 The dynamic Zener impedance Z_{ZT} is derived from the resulting a.c. voltage developed when a 60 cps, rms, a.c. current equal to 10% of the D.C. Zener current I_{ZT} is superimposed on I_{ZT} .

NOTE 5 Voltage measurements to be performed 15 seconds after application of DC current.

Noise Density (N_D) is specified in Microvolts-rms per square root cycle. Actual measurement is performed using a 1.4 KC (1 octave) frequency band-pass at the Zener test current (I_{ZT}) @ 25°C ambient temperature.

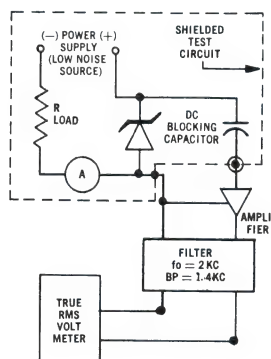


FIGURE 2
NOISE DENSITY MEASUREMENT CIRCUIT

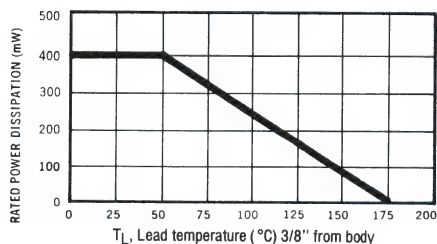


FIGURE 3
POWER DERATING CURVE

Microsemi Corp.
The diode experts

SANTA ANA, CA

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

**USR 931
thru
USR 934**

DESCRIPTION

This series of Microsemi 400mW Ultra-Stable Reference Diodes offers a **CERTIFIED REFERENCE VOLTAGE STABILITY** as measured over an actual operating period of 1000 hours. Standard stabilities are 10, 20, and 50 PPM/1000 hours. Units having stabilities of less than 5 PPM/1000 hours are available on special request.

Ultra-Stable Certified Reference Diodes, available in standard or radiation hardened construction, can be used in any circuit that requires a stable reference voltage that is insensitive to shock, vibration, or position. Their inherent stability allows them to be used in circuits requiring an extremely high degree of voltage time stability such as those in Digital Voltmeters, Computers, X-Y Recorders, Missile Guidance and Environmental Control Systems, and Portable Reference Standards. Wherever accurate and reliable measurements are to be made, the Microsemi "Ultra-Stable" diode excels as the Standard Reference device.

All devices in this series have been subjected to Microsemi's 1000 hour Stability Test Sequence, consisting of a 1000 hour power age with reference voltage measured once every 168 hours giving a total of 7 individual test points. The stability test is performed at $80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$.

A Certificate containing the following data is supplied with each diode:

1. The stability test voltage readings.
2. The voltage drift as referenced to "Zero Hour" in both μV and in PPM (Parts-Per-Million).

To certify these diodes to such tight stabilities as 10 PPM/1000 hours, every factor of environment, both ambient and electrical is considered and controlled to "Standards Laboratory" accuracy. Room ambient temperature is controlled to $\pm 1^{\circ}\text{C}$. The temperature of the oil bath is controlled to better than $\pm 0.1^{\circ}\text{C}$. Test current is maintained constant and repeatable to within 0.0001 mA. The measurement facility is calibrated utilizing Primary Voltage Standards directly traceable to the National Bureau of Standards.

**WITH CERTIFIED
ZENER VOLTAGE
STABILITY
9.3 VOLT
ULTRA STABLE
TEMPERATURE
COMPENSATED
ZENER REFERENCE
DIODES**

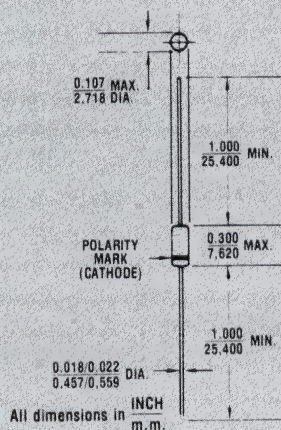


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $300^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams

MOUNTING POSITION: Any.

9.3 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

MAXIMUM RATINGS (See Fig. 6)

Operating Temperature Range:
-65°C to +175°C

Maximum Lead Temperature 1/8 ± 1/32 inch
from case for 8 seconds: 230°C

Maximum DC Power Dissipation at or below
50°C Ambient

Linear Derating: 3.2 mW/°C (See Figure 6)

Maximum Steady State Current (I_{ZM}) at
+150°C: 7.5 mA

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass

Dimensions: DO-7 outline

Finish: All external surfaces are corrosion re-
sistant and leads are readily solderable

Polarity: Diode to be operated with the banded
end positive

Weight: 0.2 grams (typical)

Mounting Position: Any

ELECTRICAL CHARACTERISTICS at 25°C, unless otherwise specified.

| MICRO TYPE NUMBER | NOMINAL ZENER VOLTAGE $V_Z @ I_{ZT}$ | ZENER TEST CURRENT $\pm 0.01 \text{ mA}$ I_{ZT} | MAXIMUM ZENER IMPEDANCE $Z_{ZT} @ I_{ZT}$ (NOTE 1) | VOLTAGE TEMPERATURE STABILITY ΔV_{ZT} MAXIMUM (NOTE 2) | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT | VOLTAGE TIME STABILITY @ 80°C INITIAL-TO-PEAK ΔV_{ZT} MAXIMUM (NOTE 3) | EFFECTIVE VOLTAGE TIME STABILITY INITIAL-TO- PEAK |
|-------------------------|---|---|--|---|----------------------|---|---|--|
| | VOLTS | mA | OHMS | mV | °C | %/°C | $\mu\text{V}/1000 \text{ HRS.}$ | PPM/1000 HRS. |
| USR931 | 9.3 | 7.5 | 20 | 3.4 | 25 to 100 | .0005 | 465 | 50 |
| USR932 | 9.3 | 7.5 | 20 | 3.4 | 25 to 100 | .0005 | 186 | 20 |
| USR933 | 9.3 | 7.5 | 20 | 3.4 | 25 to 100 | .0005 | 93 | 10 |
| USR934 | 9.3 | 7.5 | 20 | 3.4 | 25 to 100 | .0005 | 46 | 5 |

NOTE 1

The zener impedance is derived from the 60 Hz ac voltage which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT}) is superimposed on I_{ZT} .

NOTE 2

The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.

NOTE 3

When operated at:

$$I_{ZT} = 7.5 \text{ mA} \pm 0.0001 \text{ mA}$$

$$T_A = 80^\circ\text{C} \pm 0.1^\circ\text{C}$$

(See Note 2 Below)

NOTES AND PRECAUTIONS FOR CERTIFIED REFERENCE DIODES

1. DIODE IDENTIFICATION: The diodes are shipped attached to their certification papers and each diode is individually packaged with the diode identification on the package. Identification includes MICRO type number and a diode serial number consisting of 7 digits showing the lot number and diode number, which provide traceability to factory records.

2. PRECAUTIONS: The normal precautions must be taken when soldering as with any semiconductor device, such as a thermal shunt between the soldering iron and the diode body. "Mechanical" rather than solder mounting is preferred for optimum performance. Mounting the diode inside a large thermal mass such as aluminum, copper, brass, or epoxy will reduce thermally induced voltage fluctuations discernible as low frequency noise in the 0-3 Hz region of the spectrum.

Certain precautions must be taken to ensure that the diode's stability is fully utilized in the circuit. If the

current through the zener is not controlled, the reference voltage will shift due to diode impedance ($\Delta V_Z = \Delta I_Z \times Z_{ZT}$). If the diode's junction temperature is allowed to change, due to a change in ambient or case temperature or due to a power level change, a shift in voltage will occur consistent with the temperature coefficient of the diode. In addition, the device must be physically mounted so as to give the diode a constant thermal resistance, junction-to-ambient. Drafts, circulating oil, and even the minute convection currents produced by a diode in a closed container can cause shifts in reference voltage greater than those that can be attributed to the diode's inherent stability.

The certified stability of a diode is achieved only under steady state, constant temperature conditions. If the diode is operated at conditions other than the certification test conditions, it is recommended that it be operated for a period of 2 to 3 weeks under circuit

operating conditions to achieve rated stability.

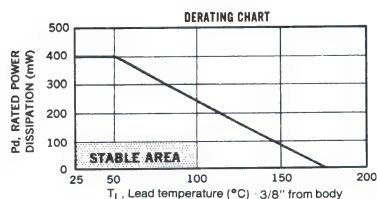
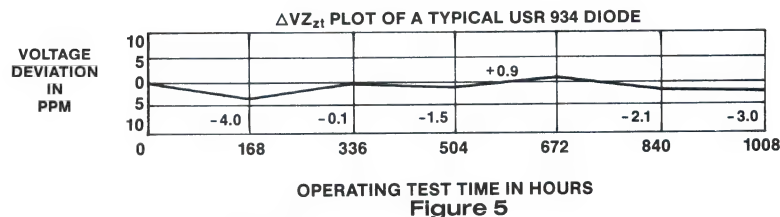
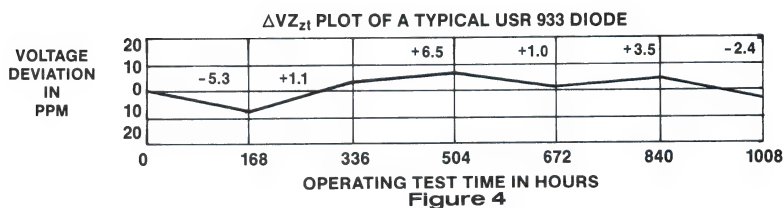
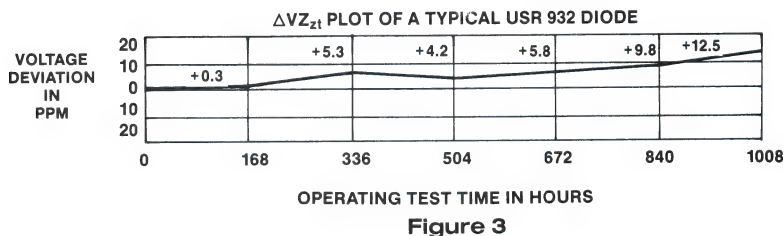
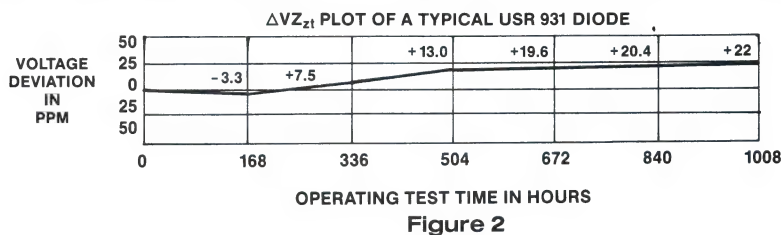
A slight derating of voltage-time stability (ΔV_{ZT}) may be experienced if the diode is operated outside the "stable-area" defined in Figure 6.

Temperature coefficients much lower than specified can be attained by operating the diode at "0" TC crossover current (the current at which the TC goes from positive to negative or vice-versa), however, a new "equilibrium" must be reached before full stability will be attained.

3. MICROSEMI TEST METHOD: Microsemi uses a potentiometric method of zener voltage measurement on certified reference diodes. Zener voltage is measured to seven digits (1 microvolt

resolution). Voltage calibration is directly traceable to the National Bureau of Standards. Oil bath temperature is controlled to better than 0.1°C , and current is constant and repeatable to better than $\pm 0.1 \mu\text{A}$. Test clips are designed for the four-terminal method of measurement (separate voltage and current connections) to eliminate errors caused by resistance. The diodes are thermally shielded by an aluminum thermal filter to reduce thermally created error causing voltage fluctuations.

4. 1000 HOUR STABILITY TEST SEQUENCE: Voltage is measured seven times during the test with the last six measurements referenced to the first. The measurements are taken 168 hours apart, giving a total test time of 1008 hours.



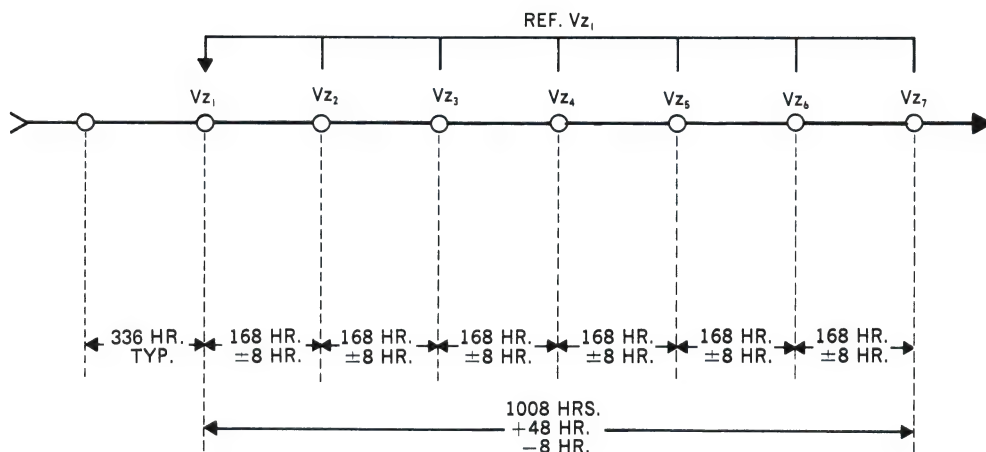
THE "STABLE AREA" IS DEFINED AS THE AREA IN WHICH THE MAXIMUM TIME STABILITY (ΔV_{ZT}) IS ATTAINABLE.

A SLIGHT DERATING IN THE TIME STABILITY MAY BE EXPECTED IF THE DIODE IS OPERATED OUTSIDE THIS AREA.

Figure 6

9.3 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

1000 HOUR STABILITY TEST SEQUENCE



Notes:

Test Temperature $80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$

Test Current 7.5 mA. with a constancy and repeatability of ± 0.1 microamp.

The first 336 hours of operation is a stabilization period. The stability of a diode is measured by the worst voltage difference (ΔV_Z) referenced to V_{Z1} .



SANTA ANA, CA

SCOTTSDALE, AZ
For more information call:
(602) 941-6300

**USR 1171
thru
USR 1174**

DESCRIPTION

This series of Microsemi 400mW Ultra-Stable Reference Diodes offers a **CERTIFIED REFERENCE VOLTAGE STABILITY** as measured over an actual operating period of 1000 hours. Standard stabilities are 10, 20, and 50 PPM/1000 hours. Units having stabilities of less than 5 PPM/1000 hours are available on special request.

Ultra-Stable Certified Reference Diodes, available in standard or radiation hardened construction, can be used in any circuit that requires a stable reference voltage that is insensitive to shock, vibration, or position. Their inherent stability allows them to be used in circuits requiring an extremely high degree of voltage time stability such as those in Digital Voltmeters, Computers, X-Y Recorders, Missile Guidance and Environmental Control Systems, and Portable Reference Standards. Wherever accurate and reliable measurements are to be made, the Microsemi "Ultra-Stable" diode excels as the Standard Reference device.

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A Certificate containing the following data is supplied with each diode:

1. The stability test voltage readings.
2. The voltage drift as referenced to "Zero Hour" in both μV and in PPM (Parts-Per-Million).

To certify these diodes to such tight stabilities as 10 PPM/1000 hours, every factor of environment, both ambient and electrical is considered and controlled to "Standards Laboratory" accuracy. Room ambient temperature is controlled to $\pm 1^{\circ}\text{C}$. The temperature of the oil bath is controlled to better than $\pm 0.1^{\circ}\text{C}$. Test current is maintained constant and repeatable to within 0.0001 mA. The measurement facility is calibrated utilizing Primary Voltage Standards directly traceable to the National Bureau of Standards.

11.7 VOLT ULTRA STABLE TEMPERATURE COMPENSATED ZENER REFERENCE DIODES

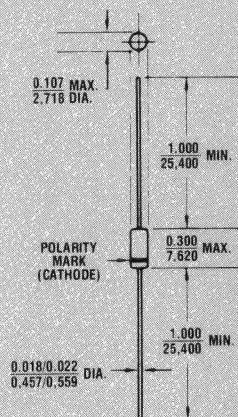


FIGURE 1

All dimensions in
 $\frac{\text{INCH}}{\text{m.m.}}$

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $300^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

11.7 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

MAXIMUM RATINGS (See Fig. 6)

Operating Temperature Range:
-65°C to +175°C

Maximum Lead Temperature 1/8 ±1/32 inch
from case for 8 seconds: 230°C

Maximum DC Power Dissipation at or below
50°C Ambient: 400 mW

Linear Derating: 3.2 mW/°C (See Figure 6)

Maximum Steady State Current (I_{ZM}) at
+150°C: 7.5 mA

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass

Dimensions: DO-7 outline

Finish: All external surfaces are corrosion re-
sistant and leads are readily solderable

Polarity: Diode to be operated with the banded
end positive

Weight: 0.2 grams (typical)

Mounting Position: Any

ELECTRICAL CHARACTERISTICS at 25°C, unless otherwise specified.

| MICRO TYPE NUMBER | NOMINAL ZENER VOLTAGE $V_Z @ I_{ZT}$ | ZENER TEST CURRENT $\pm 0.01 \text{ mA}$ I_{ZT} | MAXIMUM ZENER IMPEDANCE $Z_{ZT} @ I_{ZT}$ (NOTE 1) | VOLTAGE TEMPERATURE STABILITY ΔV_{ZT} MAXIMUM (NOTE 2) | TEMPERATURE RANGE | EFFECTIVE TEMPERATURE COEFFICIENT | VOLTAGE TIME STABILITY @ 80°C INITIAL-TO-PEAK ΔV_{ZT} MAXIMUM (NOTE 3) | EFFECTIVE VOLTAGE TIME STABILITY INITIAL-TO- PEAK |
|-------------------------|---|---|--|---|----------------------|---|---|--|
| | VOLTS | mA | OHMS | mV | °C | %/°C | $\mu\text{V}/1000 \text{ HRS.}$ | PPM/1000 HRS. |
| USR1171 | 11.7 | 7.5 | 30 | 4.3 | 25 to 100 | .0005 | 585.0 | 50 |
| USR1172 | 11.7 | 7.5 | 30 | 4.3 | 25 to 100 | .0005 | 234.0 | 20 |
| USR1173 | 11.7 | 7.5 | 30 | 4.3 | 25 to 100 | .0005 | 117.0 | 10 |
| USR1174 | 11.7 | 7.5 | 30 | 4.3 | 25 to 100 | .0005 | 58.5 | 5 |

NOTE 1

The zener impedance is derived from the 60 Hz ac voltage which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT}) is superimposed on I_{ZT} .

NOTE 2

The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.

NOTE 3

When operated at:
 $I_{ZT} = 7.5 \text{ mA} \pm 0.0001 \text{ mA}$
 $T_A = 80^\circ\text{C} \pm 0.1^\circ\text{C}$
(See Precautions Below)

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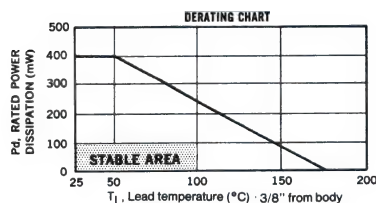
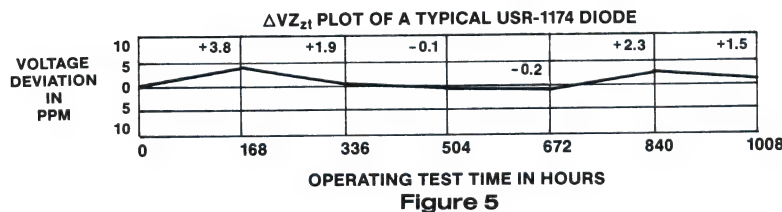
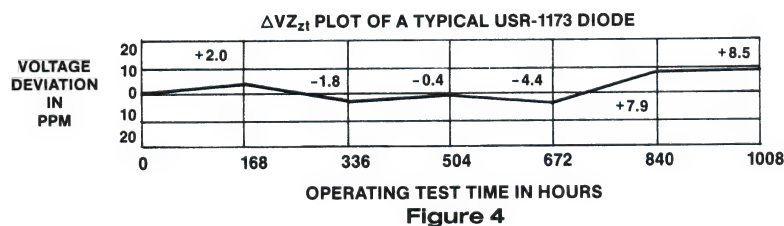
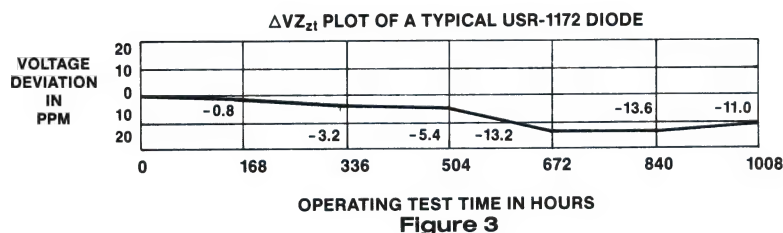
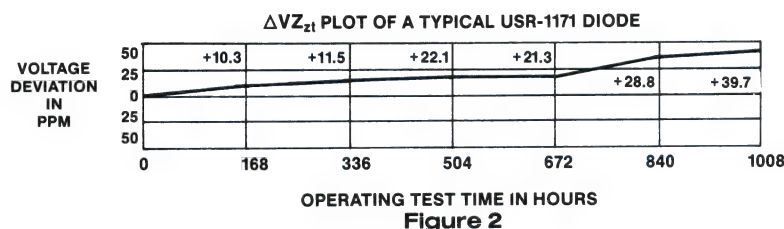
11.7 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

Temperature coefficients much lower than specified can be attained by operating the diode at "0" TC crossover current (the current at which the TC goes from positive to negative or vice-versa), however, a new "equilibrium" must be reached before full stability will be attained.

3. MICROSEMI TEST METHOD: Microsemi uses a potentiometric method of zener voltage measurement on certified reference diodes. Zener voltage is measured to seven digits (1 microvolt resolution). Voltage calibration is directly traceable to the National Bureau of Standards. Oil bath temperature is controlled to better than 0.1°C, and

current is constant and repeatable to better than $\pm 0.1 \mu\text{A}$. Test clips are designed for the four-terminal method of measurement (separate voltage and current connections) to eliminate errors caused by resistance. The diodes are thermally shielded by an aluminum thermal filter to reduce thermally created error causing voltage fluctuations.

4. 1000 HOUR STABILITY TEST SEQUENCE: Voltage is measured seven times during the test with the last six measurements referenced to the first. The measurements are taken 336 hours apart, giving a total test time of 1008 hours.



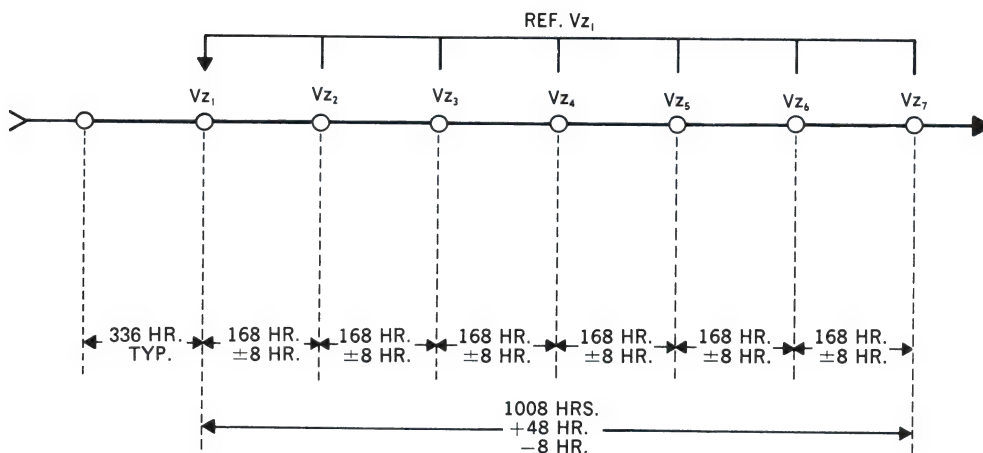
THE "STABLE AREA" IS DEFINED AS THE AREA IN WHICH THE MAXIMUM TIME STABILITY (ΔV_{μ}) IS ATTAINABLE.

A SLIGHT DERATING IN THE TIME STABILITY MAY BE EXPECTED IF THE DIODE IS OPERATED OUTSIDE THIS AREA.

Figure 6

11.7 VOLT ULTRA-STABLE (T.C.) ZENER REFERENCE DIODES

1000 HOUR STABILITY TEST SEQUENCE



Notes:

Test Temperature $80^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$

Test Current 7.5 mA. with a constancy and repeatability of ± 0.1 microamp.

The first 336 hours of operation is a stabilization period. The stability of a diode is measured by the worst voltage difference (ΔV_Z) referenced to V_{Z1} .

RECTIFIER and SIGNAL SELECTION GUIDE

| Avg. DC Output (A) | | .5 A | | | 1.0 A | | | | | |
|----------------------|-------|------------------------------|----------------------|-----------------|---------------|------------|------------|--------------------------------------|--------------------|--------------------|
| Package Style | | | | A | A | A | A | A | A | |
| Reverse Rec. Time | | 4-5 nsec | 50-100 nsec | 250-400 nsec | ≥ 400 nsec | 20 nsec | 75 nsec | 100-200 nsec | 250-500 nsec | > 500 nsec |
| Peak Reverse Voltage | VOLTS | | | | | MB207 | MB341 | MB313 MB314 | | |
| | 50 | | | | | | | | | |
| | 75 | 1N4150 1N4150-1† | | | | MB208 | | | | |
| | 100 | 1N914† 1N4148 1N4148-1 | | MB315 | | MB209 | MB342 | MB316 MB215 | | |
| | 125 | | | | | MB210 | | | | |
| | 150 | | | | | MB211 | MB343 | | | |
| | 200 | | 1N4938* 1N4938-1† | MB318 | 1N645† | MB215 | MB344 | MB319 1N4942† 1N5615† MB216 | | 1N3611† 1N4245† |
| | 250 | | | | | | MB345 | MB217 | | |
| | 300 | | | MB321 | | | | MB322 | MB218 | |
| | 400 | | | MB324 | 1N647† | | | MB325 1N4944† 1N5617† | MB219 | 1N3612† 1N4246† |
| | 500 | | MB403 MC8936 | MB327 | | | | MB328 | MB220 | |
| | 600 | | | MB330 | 1N649 | | | MB331 | 1N4946† 1N5619† | 1N3613† 1N4247† |
| 800 | | MB401 | | | | | | 1N4947† 1N5621† | 1N3614† 1N4248† | |
| 1000 | | MB402 | | | | | | 1N4948† 1N5623† | 1N3957† 1N4249† | |

*MIL-S-19500 Devices †Microsemi Corp. QPL

RECTIFIER and SIGNAL SELECTION GUIDE

| Avg. DC Output (A) | | | | 2.0 A | | 3.0 A | | | | |
|----------------------|-------|---------|---------|-------------------------|-----------------------------|---------|----------------------------|---------|--------------------------------------|------------|
| Package Style | | A | A | A | A | A | A | A | E | |
| Reverse Rec. Time | | 20 nsec | 75 nsec | 250-500 nsec | 25 nsec | 30 nsec | 50 nsec | 75 nsec | 100-400 nsec | > 400 nsec |
| Peak Reverse Voltage | VOLTS | MB200 | MB346 | MB366 MB314 | 1N5802† MB7678 MB7681 | 1N6073† | | | 1N5415† MB335 MX3105 | |
| | 50 | | | | | | | | | |
| | 75 | MB201 | | | 1N5803 | | | | | |
| | 100 | MB202 | MB347 | MB367 MB317 | 1N5804† MB7679 MB7682 | 1N6074† | | | 1N5416† 1N5186 MB336 MX3110 | 30S1 |
| | 125 | MB203 | | | 1N5805 | | | | | |
| | 150 | MB204 | MB348 | | 1N5806† MB7680 MB7683 | 1N6075† | | | MX3115 | |
| | 200 | MB206 | MB349 | MB368 MB320 | | MB7748 | MB7684 | | 1N5417† 1N5187 MB337 MX3120 | 30S2 |
| | 250 | | MB350 | | | | | | | |
| | 300 | | | MB323 | | | MB7685 | | | 30S3 |
| | 400 | | | MB369 MB326 | | MB7749 | MB7686 | | 1N5418† 1N5188 MB338 | 30S4 |
| | 500 | | | MB370 | | MB7750 | | | 1N5419† 1N5189 MB339 | 30S5 |
| | 600 | | | MB329 MB371 MB332 | | | MB7751 (700V) MB7752 | | 1N5420† 1N5190 MB340 | 30S6 |
| 800 | | | | | | | MB7753 | | 30S8 | |
| 1000 | | | | | | | | MB7754 | 30S10 | |

*MIL-S-19500 Devices †Microsemi Corp. QPL

RECTIFIER and SIGNAL SELECTION GUIDE

| 4 A | 5 A | | | | 6 A | | | 6.5 A | 7.5 A |
|-----------------------------|----------------------------|------------|------------|-------------|-------------------------------|-------------|---------------|-----------------|-----------------|
| | E | E | E | E | E | DO4 | | G | G |
| 100-400 nsec | 30 nsec | 50 nsec | 75 nsec | 100 nsec | 30-75 nsec | 300 nsec | > 300 nsec | 300-500 nsec | 300-500 nsec |
| MR4305A MX4105 40SL05 | MV7292 | | | | 1N5807† 1N6076* MES1301 | 1N3879 | 60S05 | MTR4405A | MTR5405A |
| | | | | | 1N5808 | | | | |
| MR4310A MX4110 40SL1 | MV7293 | | | | 1N5809† 1N6077* MES1302 | 1N3880 | 60S1 | MTR4410A | MTR5410A |
| | | | | | 1N5810 | | | | |
| MX4115 | MV7294 | | | | 1N5811† 1N6078* MES1303 | | | | |
| MR4320A MX4120 40SL2 | MV7352 | MV7295 | | | | 1N3881 | 60S2 | MTR4420A | MTR5420A |
| | | | | | | | | | |
| 40SL3 | | MV7296 | | | | 1N3882 | 60S3 | MTR4440A | MTR5440A |
| MR4340A 40SL4 | MV7353 | MV7297 | | | | 1N3883 | 60S4 | | |
| MR4350A 40SL5 | MV7354 | | | | | | 60S5 | | |
| MR4360A 40SL6 | | | | | | | 60S6 | | |
| 40SL8 | MV7355 (700V) MV7356 | | MV7357 | | | | 60S8 | | |
| 40SL10 | | | | MV7358 | | | 60S10 | | |

*MIL-S-19500 Devices †Microsemi Corp. QPL

RECTIFIER and SIGNAL SELECTION GUIDE

| Avg. DC Output (A) | | 9A | 12A | | 20-25A | | | |
|----------------------|-------|--------------|---------|----------|-------------------|--|--|--|
| Package Style | | G | G | DO4 | DO4 | | | |
| Reverse Rec. Time | | 300-500 nsec | 30 nsec | 200 nsec | 35 nsec | | | |
| Peak Reverse Voltage | VOLTS | MTR6405A | 1N6079* | 1N3889 | 1N5812* MES701 | | | |
| | 50 | | | | | | | |
| | 75 | | | | 1N5813 | | | |
| | 100 | MTR6410A | 1N6080* | 1N3890† | 1N5814* MES702 | | | |
| | 125 | | | | 1N5815 | | | |
| | 150 | | 1N6081* | | 1N5816* | | | |
| | 200 | MTR6420A | | 1N3891† | | | | |
| | 250 | | | | | | | |
| | 300 | MTR6440A | | 1N3892† | | | | |
| | 400 | | | 1N3893† | | | | |
| | 500 | | | | | | | |
| | 600 | | | | | | | |
| | 800 | | | | | | | |
| | 1000 | | | | | | | |

*MIL-S-19500 Devices †Microsemi Corp. QPL

1N483B thru 1N486B and 1N5194 thru 1N5196

FEATURES

- Voidless hermetically sealed glass package.
- Triple layer passivation.
- Metallurgically bonded.
- TX types available per MIL-S-19500/118C.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+200^{\circ}\text{C}$.
Storage Temperature: -65°C to $+200^{\circ}\text{C}$.
Surge Current: 2A

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | BREAKDOWN VOLTAGE (MIN.) $B_V @ 100 \mu\text{A}$ | AVERAGE RECTIFIED CURRENT I_o | | FORWARD VOLTAGE DROP (MAX.) V_F | REVERSE CURRENT (MAX.) $I_R @ \text{PIV}$ | | SURGE CURRENT (MAX.) (NOTE 1) I_{FS} surge | JUNCTION CAPACITANCE $C @ 0\text{V}$ |
|------------|---|---|--|-------|---|--|-------|--|--|
| | VOLTS | VOLTS | 25°C | 150°C | VOLTS | 25°C | 150°C | AMPS | pF |
| JAN 1N483B | 70 | 80 | .2 | .05 | 1.0V (pk) | .025 | 5 | 2 | 8 |
| JAN 1N485B | 180 | 200 | .2 | .05 | @ | .025 | 5 | 2 | 8 |
| JAN 1N486B | 225 | 250 | .2 | .05 | 100mA pulse | .025 | 5 | 2 | 8 |
| JAN 1N5194 | SAME AS JAN 1N483B | | | | } EXCEPT: PACKAGE D035 | | | | |
| JAN 1N5195 | | | | | | | | | |
| JAN 1N5196 | | | | | | | | | |

PACKAGE: D07 for JAN 1N483B, 485B, 486B.
D035 for JAN 1N5194, JAN 1N5195, and JAN 1N5196.

NOTE 1: $I_o = 200\text{mA}$ dc, 10 - 8.3msec surges

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass case.
Lead Material: Tinned copper.
Marking: Body painted, alpha numeric.
Polarity: Cathode band.

GENERAL PURPOSE SILICON DIODES

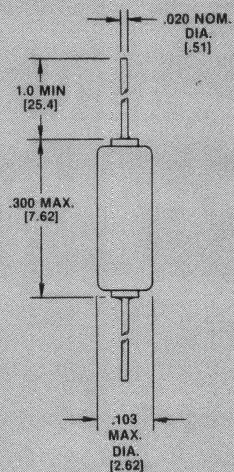


FIGURE 1A
PACKAGE D07

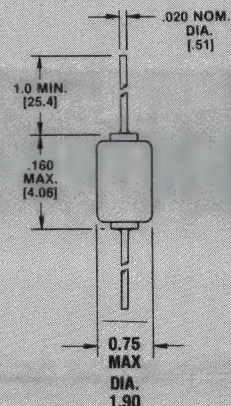


FIGURE 1B
PACKAGE D035

1N483B - 1N486B, 1N5194 - 1N5196

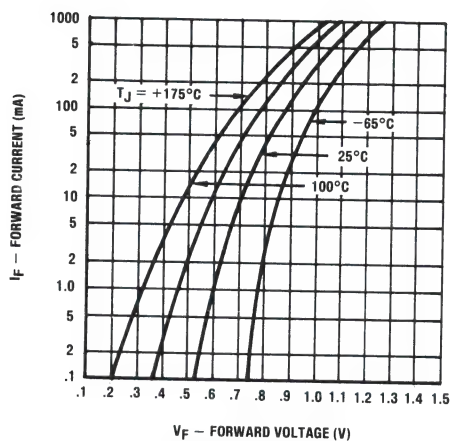


FIGURE 2
FORWARD VOLTAGE vs. FORWARD CURRENT

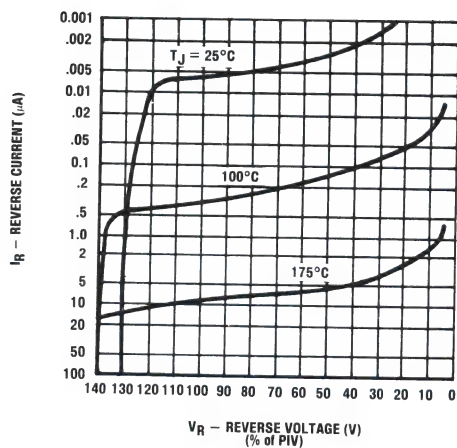


FIGURE 3
REVERSE VOLTAGE vs. REVERSE CURRENT



FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- STANDARD RECOVERY
- PIV TO 600 VOLTS
- JANS/TX/TXV TYPES AVAILABLE PER MIL-S-19500/240

MAXIMUM RATINGS

Operating Temperature: - 65°C to + 150°C

Storage Temperature: - 65°C to + 200°C

Surge Current: 5 A (8.3 msec.)

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | BREAKDOWN VOLTAGE (MIN.) BV @ 100 μ A | AVERAGE RECTIFIED CURRENT Io | | FORWARD VOLTAGE DROP (MAX.) VF | REVERSE CURRENT (MAX.) IR @ PIV | SURGE CURRENT (MAX.) (NOTE 1) IF (surge) | JUNCTION CAPACITANCE (MAX.) C @ -4V | |
|-------------|---|--|---------------------------------------|-------|--|--|--|--|----|
| | VOLTS | VOLTS | AMPS | | VOLTS | μ A | AMPS | pF | |
| | | | 25°C | 150°C | | 25°C | 100°C | | |
| JAN 1N645-1 | 225 | 270 | .4 | .15 | 1.0V | .05 | 25 | 5 | 20 |
| JAN 1N647-1 | 400 | 480 | .4 | .15 | MAX. @ | .05 | 25 | 5 | 20 |
| JAN 1N649-1 | 600 | 720 | .4 | .15 | 400mAdc (pulsed) | .05 | 25 | 5 | 20 |

NOTE 1: TA = 150°C, Io = 150mAdc, 10 - 8.3 msec surges.

MILITARY RECTIFIERS

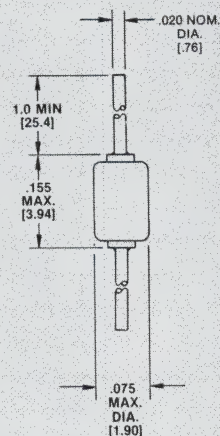


FIGURE 1

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass case.

Lead Material: Tinned copper.

Marking: Body painted, alpha numeric.

Polarity: Cathode band.

1N645-1 thru 1N649-1

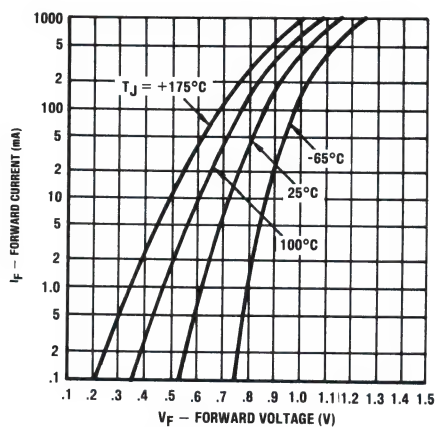


FIGURE 2
FORWARD VOLTAGE vs. FORWARD CURRENT

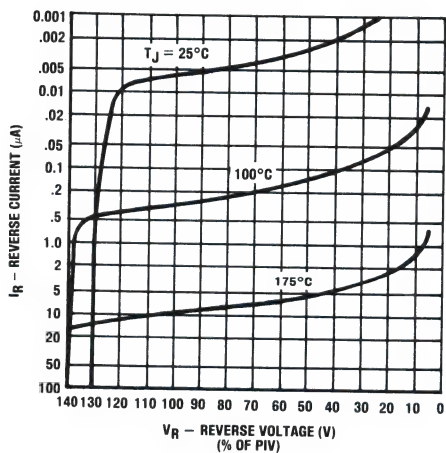


FIGURE 3
REVERSE VOLTAGE vs. REVERSE CURRENT



Microsemi Corp.

The diode experts

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

**1N897 - 1N902,
1N3064M, 1N3069M
1N3206, 1N3207,
MC914, MC914A,
MC916, MC916A,
MC001, MC001A,
MC002**

FEATURES

- Microminiature package.
- Fast recovery.
- Hermetically sealed glass package.
- Stable surface films integrally bonded to the device crystal.
- Meet or exceed requirements of MIL-S-19500

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.

Storage Temperature: -65°C to $+175^{\circ}\text{C}$.

Power Dissipation: 300 mW @ 25°C Au plated silver leads.
250 mW @ 25°C Au plated kovar leads.

ELECTRICAL CHARACTERISTICS

| TYPE | BREAKDOWN VOLTAGE (MIN.) @ 100 μ A B_V | FORWARD CURRENT (MIN.) @ 1.0V I_F | REVERSE CURRENT (MAX.) I_R @ V_R | | TEST VOLTAGE V_R | CAPACITANCE (MAX.) @ 0 V C_0 | REVERSE RECOVERY (MAX.) (NOTES BELOW) t_r |
|-----------|--|---|---|-------------|--------------------------|---|---|
| | | | μ A | | | | |
| | VOLTS | mA | 25°C | 100°C | | | |
| 1N897 | 50 | 5 | 0.1 0.025 | 20.0 5.0 | -40V -10V | — | 100K n in .1 μ sec (1) |
| 1N898 | 50 | 100 | 5.0 0.025 | 20.0 5.0 | -40V -10V | — | 100K n in .3 μ sec. (1) |
| 1N899 | 100 | 5 | 0.1 0.025 | 20.0 5.0 | -80V -10V | — | 100K n in .3 μ sec. (1) |
| 1N900 | 100 | 50 | 0.1 0.025 | 20.0 5.0 | -80V -10V | — | 100K n in .3 μ sec. (1) |
| 1N901 | 100 | 100 | 0.5 0.025 | 20.0 5.0 | -80V -10V | — | 100K n in .3 μ sec. (1) |
| 1N902 | 200 | 10 | 1.0 | 15.0 | -100V | — | 200K n in .3 μ sec. (1) |
| MC914 | 100 | 10 | 0.025 | 15.0(5) | -20V | 4.0 | 4.0(2) |
| MC914A | 100 | 20 | 0.025 | 50.0(5) | -20V | 4.0 | 4.0(2) |
| MC916 | 100 | 10 | 0.025 | 50.0(5) | -20V | 2.0 | 4.0(2) |
| MC916A | 100 | 20 | 0.025 | 50.0(5) | -20V | 2.0 | 4.0(2) |
| MC001 | 75 | 10 | 0.1 | 100.0(5) | -50V | 2.0 | 2.0(2) |
| MC001A | 75 | 20 | 0.1 | 100.0(5) | -50V | 2.0 | 2.0(2) |
| MC002 | 200 | 100 | 0.1 | 100.0(5) | -150V | 5.0 | 50.0(3) |
| 1N3064M | 75(@5 μ A) | 10 | 0.1 | 100.0(5) | -50V | 2.0 | 4.0(4) |
| 1N3069M | 65(@5 μ A) | 50 | 0.1 | 100.0(5) | -50V | 6.0 | 50.0(3) |
| 1N3206 | 100 | 10 | 0.025 | 50.0(5) | -20V | 4.0 | 4.0(2) |
| JAN1N3206 | 100 | 10 | 0.025 0.5 | 30.0(5) | -20V -80V | 2.0 | 4.0(2) |
| JAN1N3207 | 60 | 150 | 0.05 | 60.0(5) | -20V | 15.0 | 6.0(2) |
| 1N3207 | 60 | 150 | 0.05 | 10.0 | -20V | 6.0 | 6.0(2) |

NOTES:

- (1) JAN256 Recovery Test Circuit Conditions 5mA to -40V.
- (2) Recovery to 1.0 mA reverse, switching from 10 mA forward to -6.0 Volts. $R_L = 100$ ohms.
- (3) Recovery to 1.0 mA reverse, switching from 30 mA forward to 30 mA reverse. $R_L = 150$ ohms.
- (4) Recovery to 1.0 mA reverse, switching from 10 mA forward to 10 mA reverse. $R_L = 100$ ohms.
- (5) I_R measured at 150°C .

MICRO-DIODES

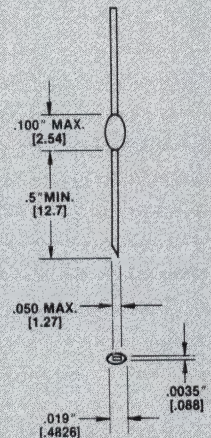


FIGURE 1
PACKAGE "H"

MECHANICAL CHARACTERISTICS

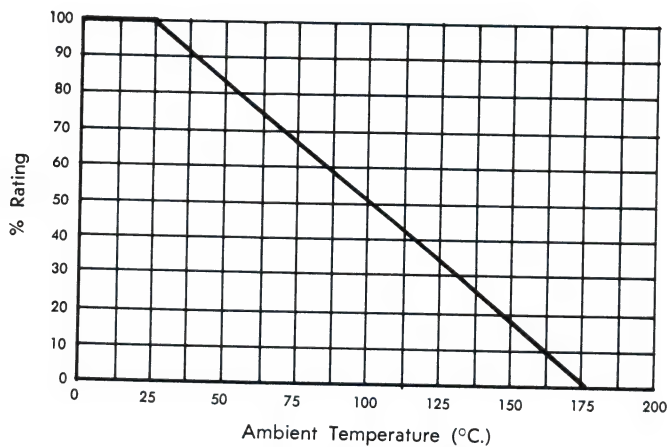
Case: Ultra stable epoxy encapsulation.

Lead Material: Gold plated kovar or gold plated silver.

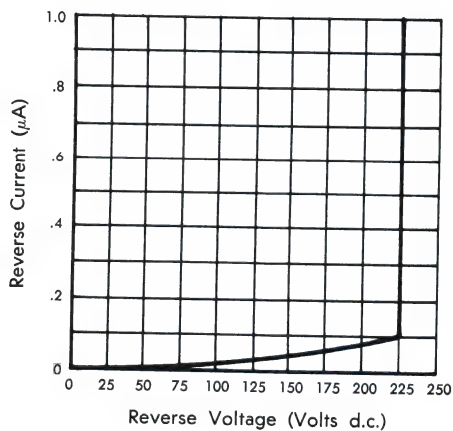
Markings: EIA color code bands.

Polarity: Color bands on cathode lead.

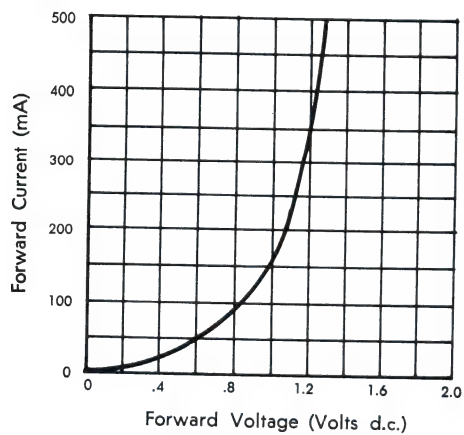
**1N897 - 1N902, 1N3064M, 1N3069M,
1N3206, 1N3207, MC914, MC914A, MC916,
MC916A, MC001, MC001A, MC002**



**FIGURE 2
TEMPERATURE DERATING CURVE**



**FIGURE 3
TYPICAL REVERSE
CHARACTERISTICS (25°C)**



**FIGURE 4
TYPICAL FORWARD CURRENT
CHARACTERISTICS (25°C)**

FEATURES

- MICROMINIATURE PACKAGE
- HERMETICALLY SEALED
- ULTRASTABLE OPERATION
- JAN, TX, TXV DEVICES AVAILABLE PER MIL-S-19500/116

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C

Storage Temperature: -65°C to +200°C

Surge Current: 500 mA (8.3 msec.)

ELECTRICAL CHARACTERISTICS at 25°C unless otherwise specified.

| V_{DR} | V_{RWM} | I_O | V_I @ $I_F = 50$ mA | V_I @ $I_F = 10$ mA | I_{rr} (Note 1) | V_{Ir} (Note 2) |
|------------|------------|-------|--------------------------|--------------------------|----------------------|----------------------|
| Volts (pk) | Volts (pk) | mA | V dc | V dc | nsec | nsec |
| 100 | 75 | 75 | 1.2 | 1.0 | 5 | 20 |

| I_R @ 20V dc | I_R @ 75V dc | I_R @ 20V dc $T_A = 150^\circ\text{C}$ | I_R @ 75V dc $T_A = 150^\circ\text{C}$ | CAPACITANCE (Note 3) | CAPACITANCE (Note 4) |
|-------------------|-------------------|--|--|-------------------------|-------------------------|
| nA | μA | μA | μA | pF | pF |
| 25 | 0.5 | 50 | 100 | 4.0 | 2.8 |

NOTE 1: $I_F = I_R = 10$ mA, $R_L = 100$ ohms.

NOTE 2: $I_F = 50$ mA dc.

NOTE 3: $V_R = 0$ V, $f = 1$ MHz, $V_{SIG} = 50$ mV (pk to pk).

NOTE 4: $V_R = 1.5$ V dc, $f = 1$ MHz, $V_{SIG} = 50$ mV (pk to pk).

MILITARY SWITCHING DIODES

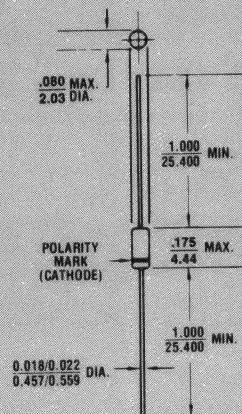


FIGURE 1

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

SANTA ANA, CA
For more information call:
(714) 979-8220

SCOTTSDALE, AZ

FEATURES

- Hermetically sealed TO-18 package.
- Weldable gold plated kovar leads.
- Temperature stability, uniformity and reliability.
- Available with 2% tolerance on Peak Point Current.
- Meets requirements of MIL-S-19500

MAXIMUM RATINGS

Operating Temperature: -65°C to $+150^{\circ}\text{C}$.
Storage Temperature: -65°C to $+200^{\circ}\text{C}$.
Lead Temperature (.25-inches from case for 10 seconds): $+250^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

| ELECTRICAL CHARACTERISTICS | | | | | | | | | | | |
|----------------------------|-----------------------------------|-------|--|--|--|---|------|--|---------------------------------------|--|-------|
| STATIC CHARACTERISTICS | | | | | | | | | | DYNAMIC CHARACTERISTICS | |
| JEDEC TYPE NUMBER | PEAK POINT CURRENT I_p | | MAXIMUM VALLEY POINT CURRENT I_v | MAXIMUM PEAK POINT VOLTAGE V_p | MAXIMUM VALLEY POINT VOLTAGE V_v | FORWARD VOLTAGE @ APPLIED CURRENT V_F @ I_F | | MAX. FORWARD CURRENT I_F (MAX.) @ 25°C | DERATE I_F MAX. ABOVE 25°C | MAX. REVERSE CURRENT I_R (MAX.) @ 25°C | |
| | mA | | mA | mV | mV | mV | | mA | mA | $\mu A/^{\circ}C$ | mA |
| | MIN. | MAX. | | | | MIN. | MAX. | | | | |
| | | | | | | | | | | | |
| 1N2927 | .09 | .11 | .035 | 75 | 475 | 600 | 1000 | .11 | 0.50 | 3.5 | 1.0 |
| 1N2927A | .098 | .102 | .030 | 70 | 475 | 650 | 1000 | .102 | 0.50 | 3.5 | 1.0 |
| 1N2928 | .42 | .52 | .170 | 80 | 490 | 670 | 1000 | .52 | 2.50 | 18.0 | 5.0 |
| 1N2928A | .46 | .48 | .145 | 74 | 490 | 710 | 1000 | | 2.50 | 18.0 | 5.0 |
| 1N2929 | .90 | 1.10 | .350 | 80 | 500 | 700 | 1000 | 1.10 | 5.0 | 35.0 | 10.0 |
| 1N2929A | .98 | 1.02 | .300 | 75 | 500 | 730 | 1000 | 1.02 | 5.0 | 35.0 | 10.0 |
| 1N2930 | 4.23 | 5.17 | 1.70 | 85 | 520 | 740 | 1000 | 5.17 | 15.0 | 100.0 | 30.0 |
| 1N2930A | 4.61 | 4.79 | 1.45 | 79 | 520 | 750 | 1000 | 4.79 | 15.0 | 100.0 | 30.0 |
| 1N2931 | 9.0 | 11.0 | 3.50 | 85 | 530 | 740 | 1000 | 11.0 | 25.0 | 150.0 | 50.0 |
| 1N2931A | 9.8 | 10.2 | 3.0 | 80 | 530 | 750 | 1000 | 10.2 | 25.0 | 150.0 | 50.0 |
| 1N2932 | 19.8 | 24.2 | 8.0 | 90 | 530 | 740 | 1000 | 24.2 | 40.0 | 240.0 | 80.0 |
| 1N2932A | 21.56 | 22.44 | 6.5 | 82 | 530 | 750 | 1000 | 22.44 | 40.0 | 240.0 | 80.0 |
| 1N2933 | 42.3 | 51.7 | 17.0 | 90 | 530 | 740 | 1000 | 51.7 | 75.0 | 450.0 | 150.0 |
| 1N2933A | 46.06 | 47.94 | 14.5 | 83 | 530 | 750 | 1000 | 47.94 | 75.0 | 450.0 | 150.0 |
| 1N2934 | 90.0 | 110.0 | 35.0 | 90 | 530 | 720 | 1000 | 110.0 | 150.0 | 900.0 | 300.0 |
| 1N2934A | 98.0 | 102.0 | 30.0 | 85 | 530 | 730 | 1000 | 102.0 | 150.0 | 900.0 | 300.0 |

NOTE: All parameters tested at $\frac{3}{16}$ inch lead length from case.

SILICON TUNNEL DIODES

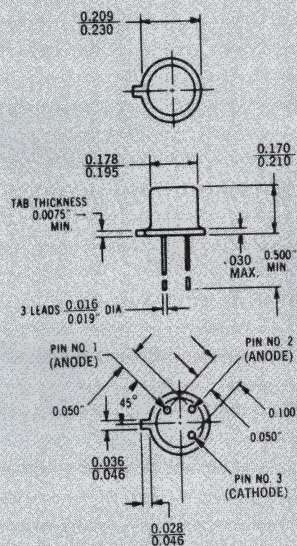


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed TO-18 package.

LEAD MATERIAL: Gold plated kovar.

MARKING: Alpha numeric with JEDEC number.

POLARITY: Pins 1 and 2 (Anode) connected internally. Pin 3 (Cathode) in electrical contact with case.

1N2927 - 1N2934A

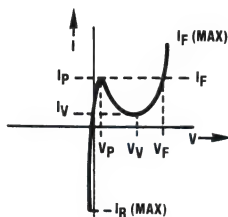


FIGURE 2
TUNNEL DIODE CHARACTERISTIC

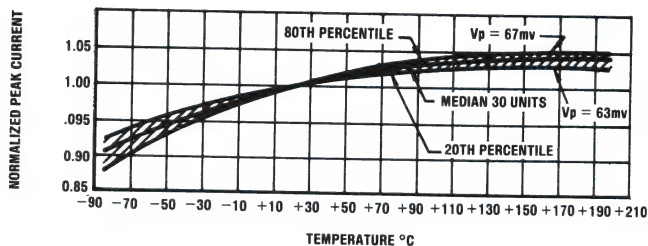


FIGURE 3
PEAK CURRENT vs. TEMPERATURE

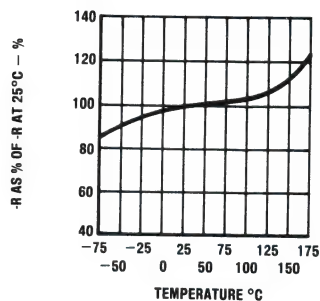


FIGURE 4
NEGATIVE RESISTANCE vs. TEMPERATURE

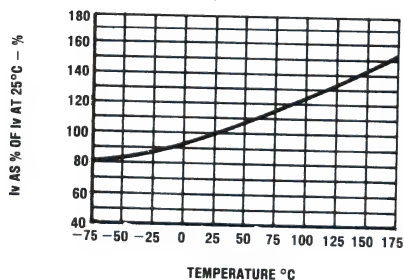


FIGURE 5
VALLEY CURRENT vs. TEMPERATURE

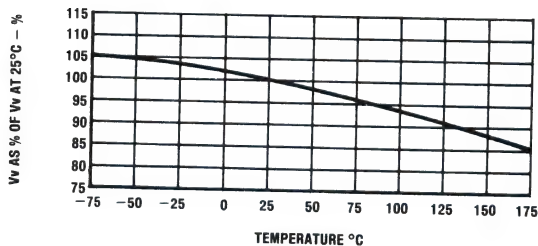


FIGURE 6
VALLEY VOLTAGE vs. TEMPERATURE

SANTA ANA, CA
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(714) 979-8220

SCOTTSDALE, AZ

FEATURES

- HIGH CONDUCTANCE
- EXTREMELY LOW REVERSE CURRENT
- ULTRA-STABLE OPERATION UP TO +150°C
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/241
- METALLURGICALLY BONDED

MAXIMUM RATINGS

Operating Temperature: -65°C to +150°C
Storage Temperature: -65°C to +200°C
Surge Current: 4 Amps

ELECTRICAL CHARACTERISTICS

| TYPE | FORWARD VOLTAGE DROP $V_F @ I_F$ | | FORWARD CURRENT I_F | REVERSE CURRENT (MAX) $I_R @ 125V$ | | REVERSE CURRENT (MAX) $I_R @ 30V$ | REVERSE RECOVERY (MAX) t_{rr} | JUNCTION CAPACITANCE (MAX) $C @ 0V$ |
|--------|-------------------------------------|------|--------------------------|---------------------------------------|-------|--------------------------------------|------------------------------------|--|
| | MIN | MAX | | 25°C | 125°C | | | |
| 1N3595 | .83 | 1.00 | 200 | 1.0 | 500 | 300 | 3.0 | 8.0 |
| | .79 | .92 | 100 | 1.0 | | 300 | 3.0 | 8.0 |
| | .74 | .88 | 50 | 1.0 | | 300 | 3.0 | 8.0 |
| | .65 | .80 | 10 | 1.0 | 3μA | 300 | 3.0 | 8.0 |
| | .60 | .75 | 5 | 1.0 | @ | 300 | 3.0 | 8.0 |
| | .52 | .68 | 1 | 1.0 | 150°C | 300 | 3.0 | 8.0 |
| | 2.6 | 2.6 | | | | | | |
| | | | | | | | | |

GENERAL PURPOSE DIODES

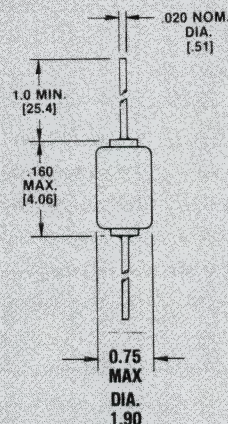


FIGURE 1
PACKAGE D035

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N3595

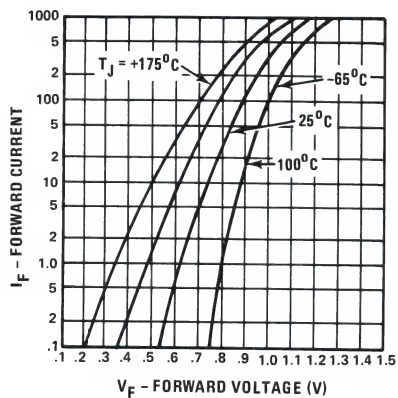


FIGURE 2
TYPICAL FORWARD VOLTAGE VS.
FORWARD CURRENT

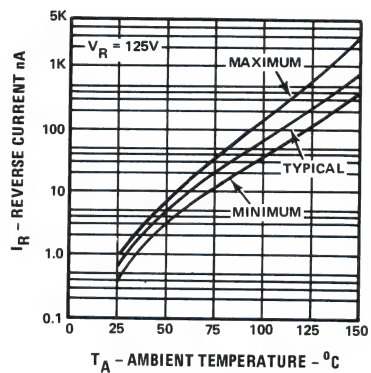


FIGURE 3
REVERSE CURRENT VS.
AMBIENT TEMPERATURE

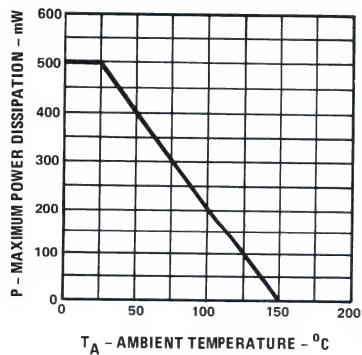


FIGURE 4
POWER DERATING CURVE

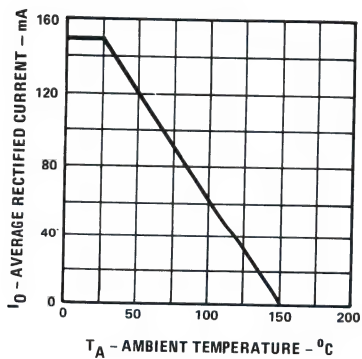


FIGURE 5
AVERAGE RECTIFIED CURRENT
VS. AMBIENT TEMPERATURE

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- STANDARD RECOVERY
- PIV TO 1000 VOLTS
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/228

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$

Storage Temperature: -65°C to $+200^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | BREAKDOWN VOLTAGE (MIN.) B_V @ 100 μA | AVERAGE RECTIFIED CURRENT I_O | | FORWARD VOLTAGE (MAX.) V_F @ 1 A | REVERSE CURRENT (MAX.) I_R @ PIV | | SURGE CURRENT (MAX.) (NOTE 1) I_F (surge) |
|------------|---|---|--|-------|---|---|-------|---|
| | VOLTS | VOLTS | AMPS | | VOLTS | μA | | AMPS |
| | | | 100°C | 150°C | | 25°C | 150°C | |
| JAN 1N3611 | 200 | 240 | 1.0 | .3 | 1.1 | 1.0 | 300 | 30 |
| JAN 1N3612 | 400 | 480 | 1.0 | .3 | 1.1 | 1.0 | 300 | 30 |
| JAN 1N3613 | 600 | 720 | 1.0 | .3 | 1.1 | 1.0 | 300 | 30 |
| JAN 1N3614 | 800 | 920 | 1.0 | .3 | 1.1 | 1.0 | 300 | 30 |
| JAN 1N3957 | 1000 | 1150 | 1.0 | .3 | 1.1 | 1.0 | 300 | 30 |

NOTE 1: $T_A = 150^{\circ}\text{C}$, $f = 60 \text{ Hz}$, $I_O = 300 \text{ mA}$, 10-8 m sec. surges @ 1/minute.

MILITARY RECTIFIERS

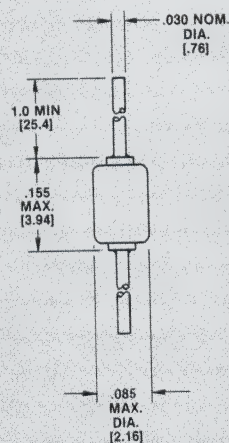


FIGURE 1
PACKAGE "A"

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N3611 thru 1N3614, 1N3957

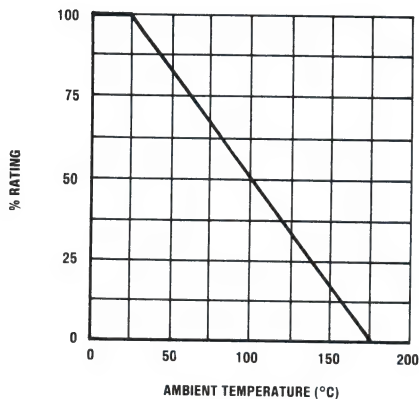


FIGURE 2
TEMPERATURE
DERATING CURVE

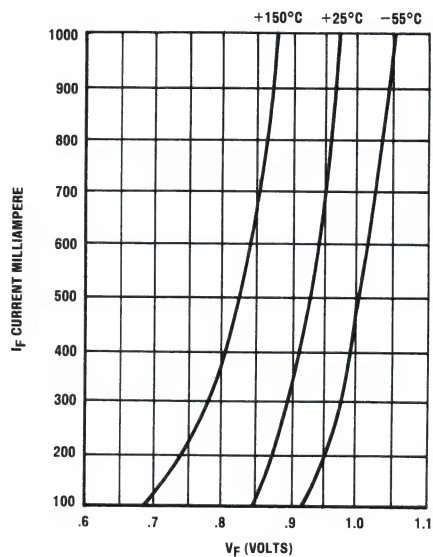


FIGURE 3
TYPICAL FORWARD
CONDUCTANCE CURVE

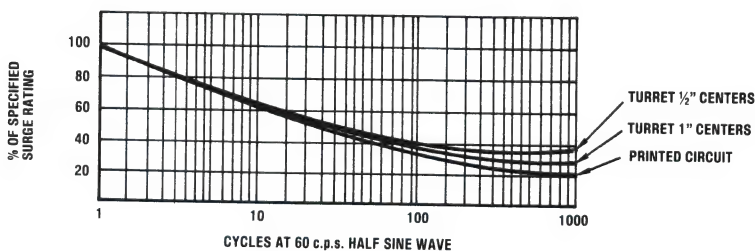


FIGURE 4
ALLOWABLE PEAK SURGE vs DURATION

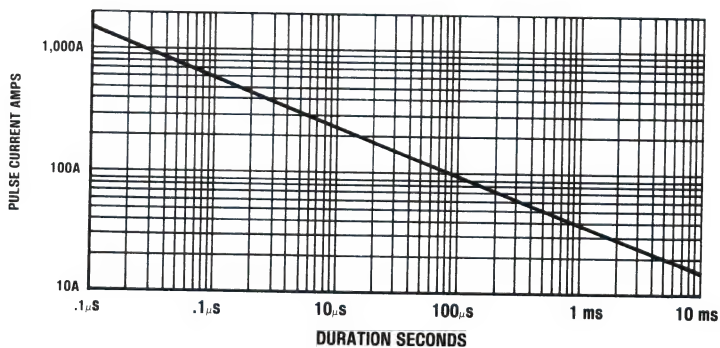


FIGURE 5
SURGE DURATION vs PULSE CURRENT
Square Pulse Current vs Duration for Non-Repetitive Pulse

1N3643 thru 1N3647 1N5181 thru 1N5184

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- LOWEST REVERSE LEAKAGE AVAILABLE
- LOWEST THERMAL RESISTANCE AVAILABLE
- MAXIMUM BREAKDOWN VOLTAGE PER DIE
- ABSOLUTE HIGH VOLTAGE / HIGH TEMPERATURE STABILITY
- MEET OR EXCEED REQUIREMENTS OF MIL-S-19500
- 1N3644 THRU 1N3647 JAN, JANTX TYPES AVAILABLE PER MIL-S-19500/279

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C

Storage Temperature: -65°C to +175°C

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | AVERAGE RECTIFIED CURRENT I_o | | FORWARD VOLTAGE (MAX.) V_F (SEE NOTES) | REVERSE CURRENT (MAX.) I_R @ PIV | | | | SURGE CURRENT (MAX.) | |
|------------|---|--|-----|--|---|-------|----|------|----------------------------|-------|
| | | mA | | | μA | | | | | |
| | | VOLTS | | | 55°C | 100°C | | 25°C | 55°C | 125°C |
| 1N3643 | 1000 | 250 | 150 | 5.0(1) | 5 | — | — | — | — | 14 |
| JAN 1N3644 | 1500 | 250 | 150 | 5.0(1) | 5 | — | — | — | — | 14 |
| JAN 1N3645 | 2000 | 250 | 150 | 5.0(1) | 5 | — | — | — | — | 14 |
| JAN 1N3646 | 2500 | 250 | 150 | 5.0(1) | 5 | — | — | — | — | 14 |
| JAN 1N3647 | 3000 | 250 | 150 | 5.0(1) | 5 | — | — | — | — | 14 |
| 1N4254 | 1500 | 250 | 150 | 3.5(2) | 1 | — | 20 | — | — | 10 |
| 1N4255 | 2000 | 250 | 150 | 3.5(2) | 1 | — | 20 | — | — | 10 |
| 1N4256 | 2500 | 250 | 150 | 3.5(2) | 1 | — | 20 | — | — | 10 |
| 1N4257 | 3000 | 250 | 150 | 3.5(2) | 1 | — | 20 | — | — | 10 |
| 1N5181 | 4000 | 100 | 60 | 10(2) | — | 5 | — | 1000 | — | 4 |
| 1N5182 | 5000 | 100 | 60 | 10(2) | — | 5 | — | 1000 | — | 4 |
| 1N5183 | 7500 | 100 | 60 | 10(2) | — | 5 | — | 1000 | — | 4 |
| 1N5184 | 10,000 | 100 | 60 | 10(2) | — | 5 | — | 1000 | — | 4 |

NOTE 1: V_F @ 250mA

NOTE 2: V_F @ 100mA

HIGH VOLTAGE RECTIFIERS

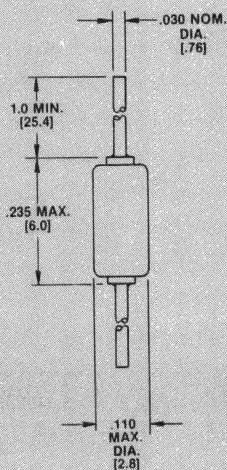


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed hard glass.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N3643 thru 1N3647 1N5181 thru 1N5184

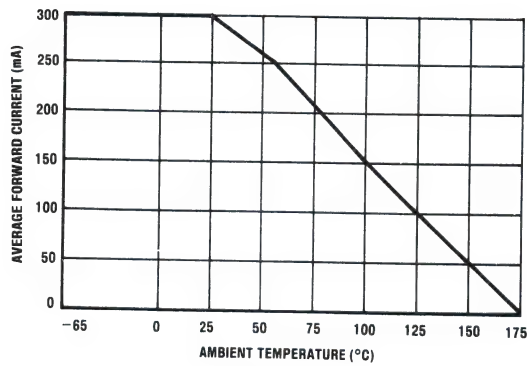


FIGURE 2
HVE/HVE 10-30/1N3643-47

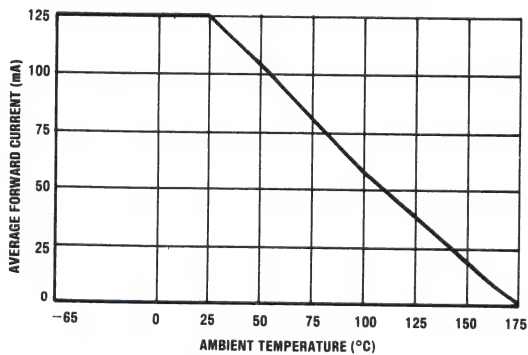


FIGURE 3
HVE/HVE 40-100/1N5181-84

1N3879 thru 1N3883

FEATURES

- $\leq 0.3 \mu\text{SEC}$ RECOVERY TIME
- LOW OVERSHOOT CURRENT

MAXIMUM RATINGS @ 25°C unless otherwise specified

Surge Current: $\frac{1}{2}$ cycle of 60 Hz @ $\leq 100^\circ\text{C}$ 75A
10 cycles of 60 Hz @ $\leq 100^\circ\text{C}$ 35A

Operating Temperature: -65 to 150°C

Storage Temperature: -65 to 175°C

*ELECTRICAL CHARACTERISTICS

@ 25°C unless otherwise specified

| JEDEC TYPE NUMBER | RATED DC BLOCKING VOLTAGE | PEAK REVERSE VOLTAGE | AVERAGE FORWARD CURRENT | MAXIMUM FORWARD VOLTAGE | | MAXIMUM REVERSE CURRENT | | |
|-------------------------|---------------------------------|----------------------------|-------------------------------|--|--------------|--|-------|-------------|
| | | | | | | 25°C | | 100°C |
| | | | | $I_F = 6\text{A}$ $I_O = 6\text{A} @ V_{RM}$ | | $V_R = \text{Rated Value}$ $I_O = 6\text{A}$ $f = 60\text{Hz}$ | | |
| | | | | -65 to 100°C | | -65 to 100°C | | |
| | | | | V_F | V_F (PEAK) | I_R | I_R | I_R (Ave) |
| | V_R | V_{RM} | I_O | VOLTS | VOLTS | μA | mA | mA |
| 1N3879 | 50 | 50 | 6 | 1.4 | 1.5 | 15 | 1.0 | 3.0 |
| 1N3880 | 100 | 100 | 6 | 1.4 | 1.5 | 15 | 1.0 | 3.0 |
| 1N3881 | 200 | 200 | 6 | 1.4 | 1.5 | 15 | 1.0 | 3.0 |
| 1N3882 | 300 | 300 | 6 | 1.4 | 1.5 | 15 | 1.0 | 3.0 |
| 1N3883 | 400 | 400 | 6 | 1.4 | 1.5 | 15 | 1.0 | 3.0 |

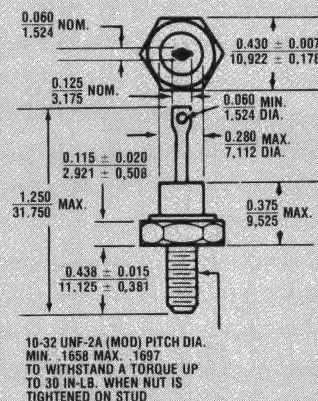
*SWITCHING CHARACTERISTICS

@ 25°C unless otherwise specified, and at $I_F = 1.0\text{Amps}$

| JEDEC TYPE NUMBER | MAXIMUM RECOVERY TIME | PEAK REVERSE RECOVERY CURRENT |
|-------------------------|-----------------------------|-------------------------------------|
| | SEE FIG. 1, 2 & 3 | |
| | t_{rr} | $I_{RM} (REC)$ |
| | nSec | AMPS |
| 1N3879 | 300 | 2.0 |
| 1N3880 | 300 | 2.0 |
| 1N3881 | 300 | 2.0 |
| 1N3882 | 300 | 2.0 |
| 1N3883 | 300 | 2.0 |

*JEDEC Registered Data

6 AMP SILICON FAST RECOVERY RECTIFIER



All dimensions in $\frac{\text{INCH}}{\text{m.m.}}$

MECHANICAL CHARACTERISTICS

CASE: Industry Standard DO-4, 7/16" Hex. stud with 10-32 threads, welded, hermetically sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and terminal solderable.

WEIGHT: 7.5 grams.

MOUNTING POSITION: Any.

POLARITY: Standard Polarity: Cathode-to-stud. Reverse Polarity: Anode-to-stud. (Suffix R.)

MOUNTING HARDWARE: See page 41.

1N3879 thru 1N3883

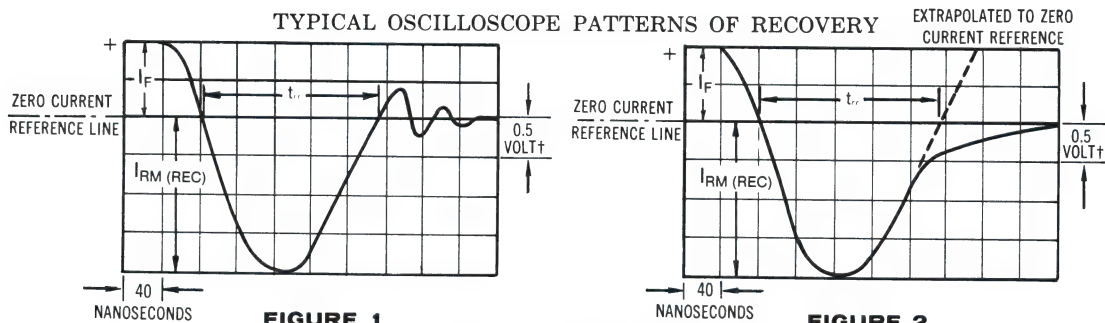
6 AMP SILICON FAST RECOVERY RECTIFIER

NOTE 1 The relay is a make-before-break, wetted-mercury-contact type driven by a 60 Hz sine wave. Conduction time is 640 μ Sec and it is open approximately 7.7 mSec.

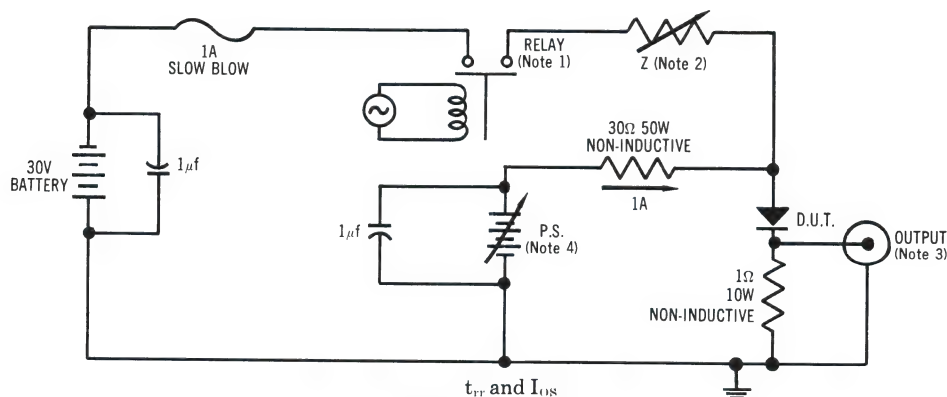
NOTE 2 Z is a 3 Ω , 25 W rheostat adjusted for a resistance of 1.4 Ω from the relay to the anode. The inductance between the same points is 38 μ h.

NOTE 3 Monitoring oscilloscope characteristics: $t_r \leq 14$ nSec, $R_{in} = 9$ M Ω , $C_{in} \leq 12$ pf, $L_{in} \leq 0.5$ μ h.

NOTE 4 Power supply has an output impedance of 0.5 Ω from DC to 2 kHz.

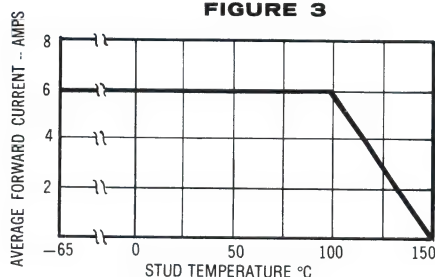


†Voltage sensed across 1-ohm resistor; each division therefore equivalent to 0.5 ampere current.



*** TEST CIRCUIT**

FIGURE 3



*** DERATING CURVE**

FIGURE 4

1N3889 thru 1N3893

FEATURES

- 1N3890, 1N3891, AND 1N3893 HAVE JAN, JANTX AND JANTXV STANDARD AND REVERSE POLARITY DEVICES TO MIL-S-19500/304
- $\leq 0.2 \mu\text{SEC}$ RECOVERY TIME
- LOW OVERSHOOT CURRENT

MAXIMUM RATINGS @ 25°C unless otherwise specified

Surge Current: $\frac{1}{2}$ cycle of 60 Hz @ $\leq 100^\circ\text{C}$. . . 150 A
10 cycles of 60 Hz @ $\leq 100^\circ\text{C}$. . . 70 A

Operating Temperature: -65 to 150°C

Storage Temperature: -65 to 175°C

*ELECTRICAL CHARACTERISTICS

@ 25°C unless otherwise specified

| JEDEC TYPE NUMBER | RATED DC BLOCKING VOLTAGE | PEAK REVERSE VOLTAGE | AVERAGE FORWARD CURRENT | MAXIMUM FORWARD VOLTAGE | | MAX. REVERSE CURRENT | | |
|-------------------------|---------------------------------|---------------------------------|---------------------------------|-------------------------------|--|--|-------|--------------------|
| | | | | | | 25°C | | 100°C |
| | | | | | | $V_R = \text{Rated Value}$ | | |
| | | | | | | @ V_{RM} $I_O = 12A$ $f = 60\text{Hz}$ | | |
| | -65 to 100°C | -65 to 100°C | -65 to 100°C | $I_F = 12A$ | $I_O = 12A @ V_{RM}$ -65 to 100°C | I_R | I_R | $I_R (\text{Ave})$ |
| | V_R | V_{RM} | I_O | V_F | $V_F (\text{Peak})$ | μA | mA | mA |
| | Volts | Volts | Amps | Volts | Volts | | | |
| 1N3889 | 50 | 50 | 12 | 1.4 | 1.5 | 25 | 3.0 | 5.0 |
| 1N3890 | 100 | 100 | 12 | 1.4 | 1.5 | 25 | 3.0 | 5.0 |
| 1N3891 | 200 | 200 | 12 | 1.4 | 1.5 | 25 | 3.0 | 5.0 |
| 1N3892 | 300 | 300 | 12 | 1.4 | 1.5 | 25 | 3.0 | 5.0 |
| 1N3893 | 400 | 400 | 12 | 1.4 | 1.5 | 25 | 3.0 | 5.0 |

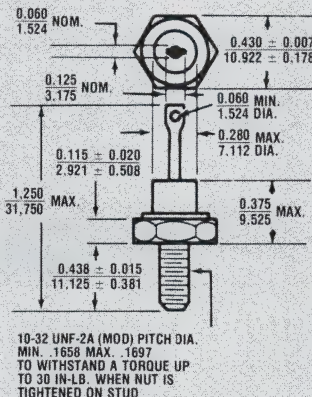
*SWITCHING CHARACTERISTICS

@ 25°C unless otherwise specified, and at $I_F = 1.0$ Amps

| JEDEC TYPE NUMBER | MAXIMUM RECOVERY TIME | PEAK REVERSE RECOVERY CURRENT |
|-------------------------|-----------------------------|-------------------------------------|
| | SEE FIG. 1, 2 & 3 | |
| | t_{rr} | $I_{RM} \text{ (REC)}$ |
| | nSec | Amps |
| 1N3889 | 200 | 2.0 |
| 1N3890 | 200 | 2.0 |
| 1N3891 | 200 | 2.0 |
| 1N3892 | 200 | 2.0 |
| 1N3893 | 200 | 2.0 |

*JEDEC Registered Data

12 AMP SILICON FAST RECOVERY RECTIFIER



All dimensions in $\frac{\text{INCH}}{\text{m.m.}}$

MECHANICAL CHARACTERISTICS

CASE: Industry Standard DO-4, 7/16" Hex. stud with 10-32 threads, welded, hermetically sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and terminal solderable.

WEIGHT: 7.5 grams.

MOUNTING POSITION: Any.

POLARITY: Standard Polarity: Cathode-to-stud. Reverse Polarity: Anode-to-stud. (Suffix R.)

MOUNTING HARDWARE: See page 41.

1N3889 thru 1N3893

12 AMP SILICON FAST RECOVERY RECTIFIER

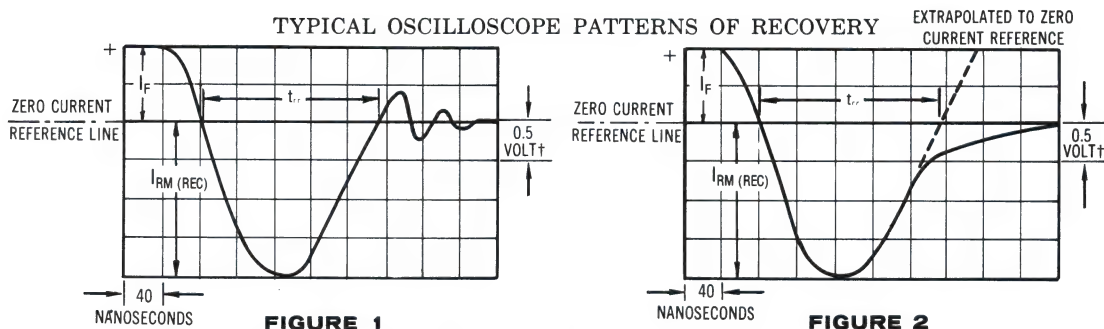
NOTE 1 The relay is a make-before-break, wetted-mercury-contact type driven by a 60 Hz sine wave. Conduction time is 640 μ Sec and it is open approximately 7.7 mSec.

NOTE 2 Z is a 3 Ω , 25 W rheostat adjusted for a resistance of 1.4 Ω from the relay to the anode. The inductance between the same points is 38 μ h.

NOTE 3 Monitoring oscilloscope characteristics: $t_r \leq 14$ nSec, $R_{in} = 9$ M Ω , $C_{in} \leq 12$ pf, $L_{in} \leq 0.5$ μ h.

NOTE 4 Power supply has an output impedance of 0.5 Ω from DC to 2 kHz.

TYPICAL OSCILLOSCOPE PATTERNS OF RECOVERY



†Voltage sensed across 1-ohm resistor; each division therefore equivalent to 0.5 ampere current.

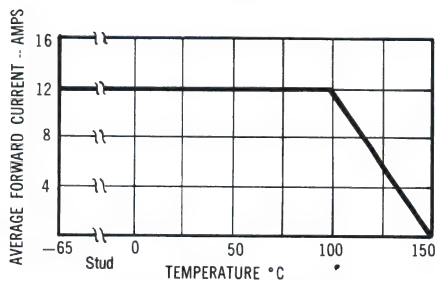
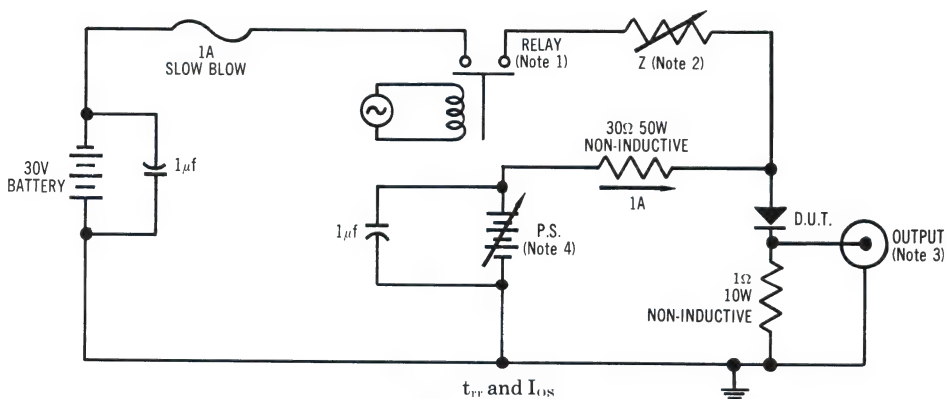


FIGURE 4

1N4001 thru 1N4007

FEATURES

- Low cost.
- High current capability.
- Low leakage.
- Low forward voltage.
- High surge capability.
- JEDEC DO-41 molded plastic case.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.
Storage Temperature: -65°C to $+175^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK REVERSE VOLTAGE | MAX. RMS VOLTAGE | MAX. DC BLOCKING VOLTAGE | MAX. AVERAGE FORWARD RECTIFIED CURRENT | PEAK FORWARD SURGE CURRENT I_F (SURGE) | MAX. FORWARD VOLTAGE @ 1A DC | MAX. DC REVERSE CURRENT @ RATED DC BLOCKING VOLTAGE | TYPICAL JUNCTION CAPACITANCE @ $V_R = 4\text{V}$ |
|--------|----------------------------|------------------------|--------------------------------|--|--|---------------------------------------|--|---|
| | V | V | V | A | A | V | μA | pF |
| 1N4001 | 50 | 35 | 50 | 1.0 | 50 | 1.1 | 5.0 | 20 |
| 1N4002 | 100 | 70 | 100 | 1.0 | 50 | 1.1 | 5.0 | 20 |
| 1N4003 | 200 | 140 | 200 | 1.0 | 50 | 1.1 | 5.0 | 20 |
| 1N4004 | 400 | 280 | 400 | 1.0 | 50 | 1.1 | 5.0 | 20 |
| 1N4005 | 600 | 420 | 600 | 1.0 | 50 | 1.1 | 5.0 | 20 |
| 1N4006 | 800 | 560 | 800 | 1.0 | 50 | 1.1 | 5.0 | 20 |
| 1N4007 | 1000 | 700 | 1000 | 1.0 | 50 | 1.1 | 5.0 | 20 |

1A PLASTIC SILICON RECTIFIERS

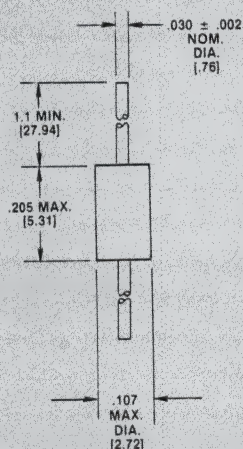


FIGURE 1

All dimensions in $\frac{1}{16}$ INCH
m. m.

MECHANICAL CHARACTERISTICS

CASE: Molded plastic.

LEAD MATERIAL: Copper, plated tin.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N4001 thru 1N4007

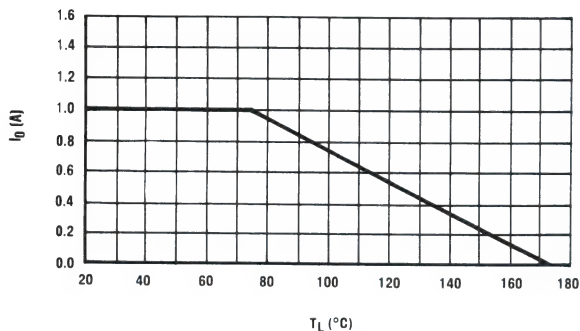


FIGURE 2
FORWARD DERATING CURVE

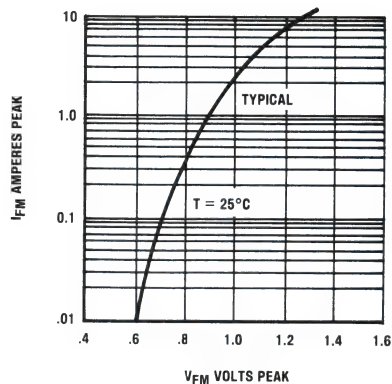


FIGURE 3
FORWARD CHARACTERISTICS

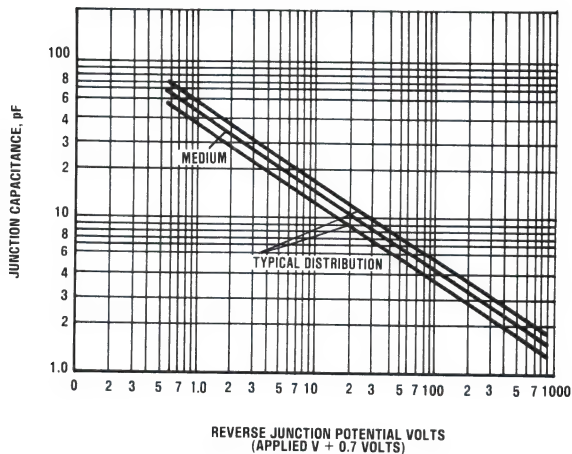


FIGURE 4
JUNCTION CAPACITANCE

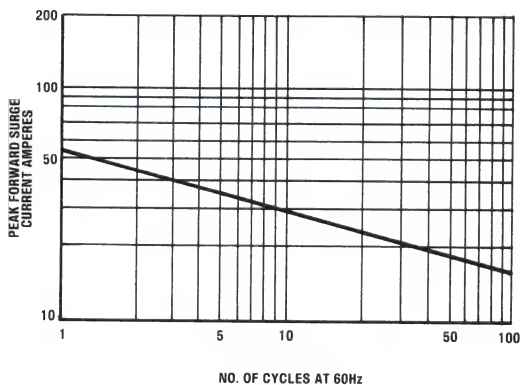


FIGURE 5
PEAK FORWARD SURGE CURRENT

FEATURES

- MICROMINIATURE PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- HERMETICALLY SEALED GLASS PACKAGE
- JANS, TXV, TX AND JAN TYPES AVAILABLE PER MIL-S-19500/116
- VOIDLESS CONSTRUCTION

MAXIMUM RATINGS

Operating Temperature: -65°C to +200°C

Storage Temperature: -65°C to +200°C

Surge Current: 500 mA (8.3 msec.)

ELECTRICAL CHARACTERISTICS at 25°C unless otherwise specified.

| V_{BR} | V_{RWM} | I_0 | V_f @ $I_f = 100 \text{ mA}$ | V_f @ $I_f = 10 \text{ mA}$ | t_{rr} (Note 1) | V_{rr} (Note 2) |
|------------|------------|-------|-----------------------------------|----------------------------------|----------------------|----------------------|
| Volts (pk) | Volts (pk) | mA | V dc | V dc | nsec | nsec |
| 100 | 75 | 200 | 1.2 | 1.0 | 5 | 20 |

| I_R @ 20V dc | I_R @ 75V dc | I_R @ 20V $T_A = 150^\circ\text{C}$ | I_R @ 75V dc $T_A = 150^\circ\text{C}$ | CAPACITANCE (Note 3) | CAPACITANCE (Note 4) |
|-------------------|-------------------|---|--|-------------------------|-------------------------|
| nA | μA | μA | μA | pF | pF |
| 25 | 0.5 | 50 | 100 | 4.0 | 2.8 |

NOTE 1: $I_F = I_R = 10 \text{ mA}$, $R_L = 100 \text{ ohms}$.

NOTE 2: $I_F = 50 \text{ mA dc}$.

NOTE 3: $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$, $V_{SIG} = 50 \text{ mV (pk to pk)}$.

NOTE 4: $V_R = 1.5 \text{ V dc}$, $f = 1 \text{ MHz}$, $V_{SIG} = 50 \text{ mV (pk to pk)}$.

MILITARY SWITCHING DIODES

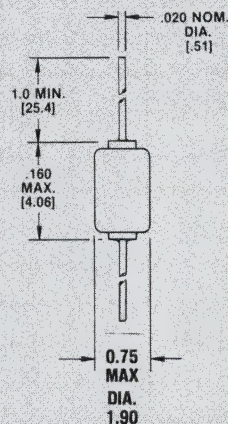


FIGURE 1
PACKAGE D035

All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

FEATURES

- MICROMINIATURE PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- HERMETICALLY SEALED GLASS PACKAGE
- JAN, TX, AND TXV TYPES AVAILABLE PER MIL-S-19500/116

MAXIMUM RATINGS

Operating Temperature: -65°C to +200°C

Storage Temperature: -65°C to +200°C

Surge Current: 500 mA (8.3 msec.)

ELECTRICAL CHARACTERISTICS at 25°C unless otherwise specified.

| V_{BR} | V_{RWM} | I_0 | V_I @ $I_F = 100 \text{ mA}$ | V_I @ $I_F = 10 \text{ mA}$ | I_{rr} (Note 1) | V_{Ir} (Note 2) |
|------------|------------|-------|-----------------------------------|----------------------------------|----------------------|----------------------|
| Volts (pk) | Volts (pk) | mA | V dc | V dc | nsec | nsec |
| 100 | 75 | 200 | 1.2 | 1.0 | 5 | 20 |

| I_R @ 20V dc | I_R @ 75V dc | I_R @ 20V $T_A = 150^\circ\text{C}$ | I_R @ 75V dc $T_A = 150^\circ\text{C}$ | CAPACITANCE (Note 3) | CAPACITANCE (Note 4) |
|-------------------|-------------------|---|--|-------------------------|-------------------------|
| nA | μA | μA | μA | pF | pF |
| 25 | 0.5 | 50 | 100 | 4.0 | 2.8 |

NOTE 1: $I_F = I_R = 10 \text{ mA}$, $R_L = 100 \text{ ohms}$.

NOTE 2: $I_F = 50 \text{ mA dc}$.

NOTE 3: $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$, $V_{SIG} = 50 \text{ mV}$ (pk to pk).

NOTE 4: $V_R = 1.5 \text{ V dc}$, $f = 1 \text{ MHz}$, $V_{SIG} = 50 \text{ mV}$ (pk to pk).

JAN1N4148-1

MILITARY SWITCHING DIODES

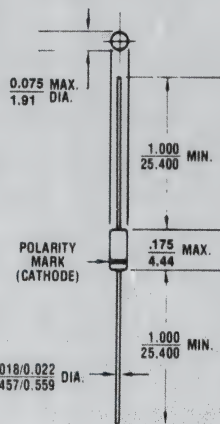


FIGURE 1

All dimensions in INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- METALLURGICALLY BONDED
- JANS/TXV, TX TYPES AVAILABLE PER MIL-S-19500/231

MAXIMUM RATINGS

Operating Temperature: -65°C to $+150^{\circ}\text{C}$
Storage Temperature: -65°C to $+200^{\circ}\text{C}$
Surge Current: 4 Amps ($t_P = 1\mu\text{s}$); 0.5 A ($t_P = 1\text{s}$)

ELECTRICAL CHARACTERISTICS at 25°C unless otherwise specified.

| V_{BR} | V_{RWM} | I_O | I_R @ $V_R = 50\text{Vdc}$ | I_R @ $V_R = 50\text{Vdc}$ | I_{rr} (Note 1) | I_{rr} (Note 2) |
|----------|------------|-------|---------------------------------|---------------------------------|----------------------|----------------------|
| Volts | Volts (pk) | mA | $\mu\text{A dc}$ | $\mu\text{A dc}^*$ | nsec | nsec |
| 75 | 50 | 200 | 0.1 | 100 | 4 | 6 |

* $T_A = 150^{\circ}\text{C}$

| CAPACITANCE $V_R = 0\text{ Volts}$ 1 MHz, 50 mVpp | V_{f1} @ $I_F = 1\text{ mA dc}$ | V_{f2} @ $I_F = 10\text{ mA}$ | V_{f3} @ $I_F = 50\text{ mA}$ (pulsed) | V_{f4} @ $I_F = 100\text{ mA}$ (pulsed) | V_{f5} @ $I_F = 200\text{ mA}$ (pulsed) |
|---|--------------------------------------|------------------------------------|--|---|---|
| pF | Vdc | Vdc | Vdc | Vdc | Vdc |
| 2.5 | 0.54 - 0.62 | 0.66 - 0.74 | 0.76 - 0.86 | 0.82 - 0.92 | 0.87 - 1.00 |

NOTE 1: $I_F = I_R = 10 - 200\text{ mA dc}$, $R_L = 100\text{ ohms}$.

NOTE 2: $I_F = I_R = 200 - 400\text{ mA dc}$, $R_L = 100\text{ ohms}$.

MILITARY SWITCHING DIODES

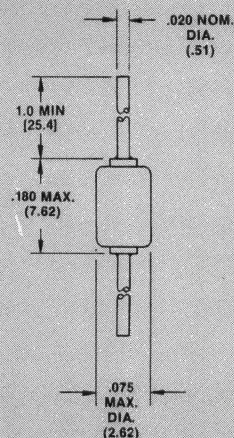


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

1N4245 thru 1N4249

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- STANDARD RECOVERY
- PIV TO 1000 VOLTS
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/286

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C

Storage Temperature: -65°C to +200°C

Power Dissipation: (A) 3 Amp/MIL-STD-750 (See Figure 2)

(B) 1 Amp/no heat sink @ +55°C

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | BREAKDOWN VOLTAGE (MIN.) BV @ 100 μ A | AVERAGE RECTIFIED CURRENT I _o | | FORWARD VOLTAGE (MAX.) V _F @ 3 A | REVERSE CURRENT (MAX.) I _R @ PIV | | SURGE CURRENT (MAX.) (NOTE 1) I _F (surge) | REVERSE RECOVERY (MAX.) (NOTE 2) t _{rr} |
|------------|---|--|---|-------|--|--|-------|--|--|
| | VOLTS | VOLTS | AMPS | | VOLTS | μ A | | AMPS | μ sec. |
| | | | 100°C | 150°C | | 25°C | 150°C | | |
| JAN 1N4245 | 200 | 240 | 1.00 | .333 | 1.3 | 1.0 | 150 | 25 | 5.0 |
| JAN 1N4246 | 400 | 480 | 1.00 | .333 | 1.3 | 1.0 | 150 | 25 | 5.0 |
| JAN 1N4247 | 600 | 720 | 1.00 | .333 | 1.3 | 1.0 | 150 | 25 | 5.0 |
| JAN 1N4248 | 800 | 960 | 1.00 | .333 | 1.3 | 1.0 | 150 | 25 | 5.0 |
| JAN 1N4249 | 1000 | 1150 | 1.00 | .333 | 1.3 | 1.0 | 150 | 25 | 5.0 |

NOTE 1: T_A = 100°C, f = 60 Hz, I_O = 1A, 10-8 m sec. surges @ 1/minute.

NOTE 2: I_F = 5A, I_{rr} = 1A, I_{rr} = .250A

MILITARY RECTIFIERS

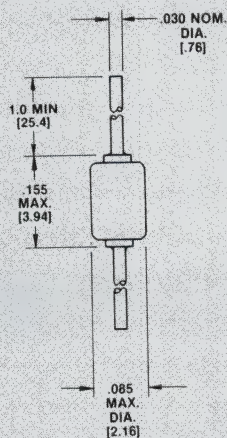


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N4245 thru 1N4249

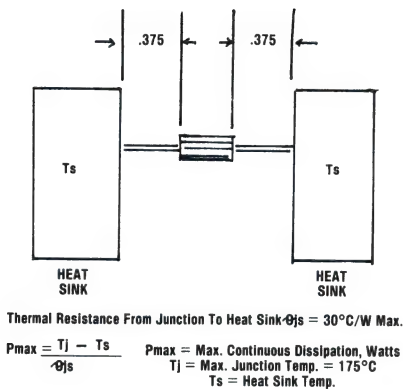


FIGURE 2
MIL STD 750 METHOD 1026(A)

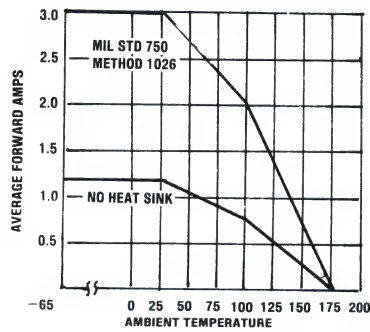


FIGURE 3
MAXIMUM FORWARD CURRENT
VS AMBIENT TEMPERATURE

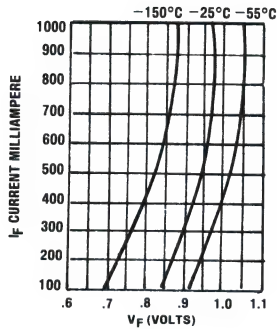


FIGURE 4
TYPICAL FORWARD
CONDUCTANCE CURVE

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

FEATURES

- MICROMINIATURE PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- JAN, TX, TXV AVAILABLE TO REQUIREMENTS OF MIL-S-19500/169

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C

Storage Temperature: -65°C to +200°C

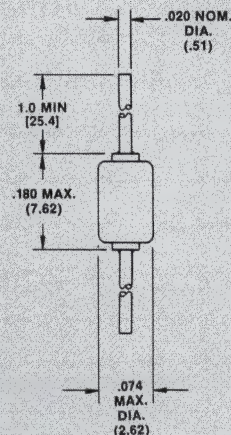
Surge Current: 2.0 Amps @ 1 microsecond

Forward Current: $I_F = 100$ mA dc, derate at 0.667 mA/°C above $T_A = 25^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at 25°C unless otherwise specified.

| TYPE | FORWARD VOLTAGE DROP $V_F @ I_F$ | BREAKDOWN VOLTAGE B_V | REVERSE CURRENT (max) $I_R @ 175\text{ V}$ | | REVERSE RECOVERY (max) (Note 1) t_{rr} | JUNCTION CAPACITANCE (max) $C @ 0\text{ V}$ |
|----------|-------------------------------------|----------------------------|--|-------|---|---|
| | Volts | V dc | nA | | nsec | pF |
| | max | | 25°C | 150°C | | |
| 1N4938 | 1.00 | 200 | 0.1 | 100 | 50.0 | 5.0 |
| 1N4938-1 | 1.00 | 200 | 0.1 | 100 | 50.0 | 5.0 |

MILITARY SWITCHING DIODES



MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed hard glass case.

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- FAST RECOVERY
- PIV TO 1000 VOLTS
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/286

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C

Storage Temperature: -65°C to +200°C

Power Dissipation: (A) 3 Amp/MIL-STD-750 (See Figure 2)

(B) 1 Amp/no heat sink @ +55°C

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MAX.) PIV | BREAKDOWN VOLTAGE (MIN.) BV @ 50 μ A | AVERAGE RECTIFIED CURRENT Io | | FORWARD VOLTAGE (MAX.) VF @ 1 A | REVERSE CURRENT (MAX.) IR @ PIV | | CAPACITANCE (MAX.) Co @ -12V | SURGE CURRENT (MAX.) (NOTE 1) If(surge) | REVERSE RECOVERY (MAX.) (NOTE 2) trr |
|------------|---|---|---------------------------------------|-------|--|--|-------|------------------------------------|---|--|
| | VOLTS | VOLTS | AMPS | | VOLTS | μ A | | pF | AMPS | n sec. |
| | | | 55°C | 100°C | | 25°C | 150°C | | | |
| JAN 1N4942 | 200 | 220 | 1.0 | .750 | 1.3 | 1.0 | 200 | 45 | 15 | 150 |
| JAN 1N4944 | 400 | 440 | 1.0 | .750 | 1.3 | 1.0 | 200 | 35 | 15 | 150 |
| JAN 1N4946 | 600 | 660 | 1.0 | .750 | 1.3 | 1.0 | 200 | 25 | 15 | 250 |
| JAN 1N4947 | 800 | 880 | 1.0 | .750 | 1.3 | 1.0 | 200 | 25 | 15 | 250 |
| JAN 1N4948 | 1000 | 1100 | 1.0 | .750 | 1.3 | 1.0 | 200 | 15 | 15 | 500 |

NOTE 1: TA = 100°C, f = 60 Hz, Io = 750 mA, 10-8 m sec. surges @ 1/minute.

NOTE 2: 1F = .5A, IRR = 1 A, trr = .250 A.

MILITARY RECTIFIERS

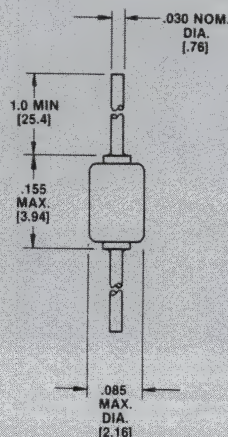


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N4942 thru 1N4948

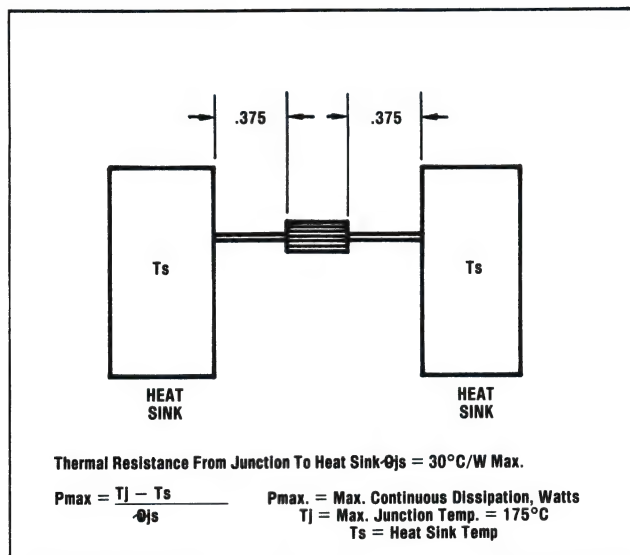


FIGURE 2
MIL STD 750 METHOD 1026 (A)

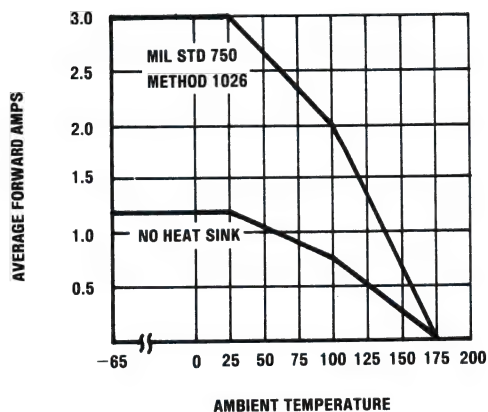


FIGURE 3
MAXIMUM FORWARD CURRENT
vs AMBIENT TEMPERATURE

1N5186 thru 1N5190

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- FAST RECOVERY
- PIV TO 600 VOLTS
- MEETS REQUIREMENTS OF MIL-S-19500/424

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C

Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

| TYPE | PIV | MINIMUM REVERSE BREAKDOWN VOLTAGE @ 50 μ A | FORWARD VOLTAGE VF @ 9Adc | | MAXIMUM REVERSE CURRENT @ PIV | | MAXIMUM REVERSE RECOVERY TIME tRRc |
|--------|------|--|------------------------------------|------|-------------------------------------|-------------|--|
| | | | MIN. | MAX. | 25°C | 100°C | |
| 1N5186 | 100V | 120V | 0.9V(pk) 1.5V(pk) | | 2.0 μ A | 100 μ A | 150 |
| 1N5187 | 200V | 240V | | | | | 200 |
| 1N5188 | 400V | 480V | | | | | 250 |
| 1N5189 | 500V | 550V | | | | | 300 |
| 1N5190 | 600V | 660V | | | | | 400 |

FAST SWITCHING RECTIFIERS

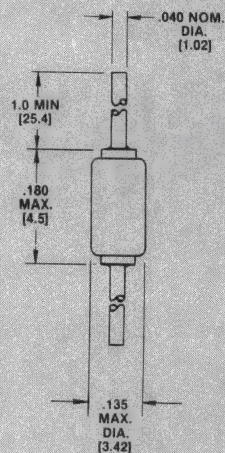


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Silver clad copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N5400 thru 1N5408

FEATURES

- Low cost.
- High current capability.
- Low leakage.
- Low forward voltage.
- High surge capability.
- JEDEC DO-27 molded plastic case.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.
Storage Temperature: -65°C to $+175^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK REVERSE VOLTAGE | MAX. RMS VOLTAGE | MAX. DC BLOCKING VOLTAGE | MAX. AVERAGE FORWARD RECTIFIED CURRENT | PEAK FORWARD SURGE CURRENT I_F (SURGE) | MAX. FORWARD VOLTAGE @ 3A DC | MAX. DC REVERSE CURRENT @ RATED DC BLOCKING VOLTAGE | TYPICAL JUNCTION CAPACITANCE @ $V_R = 4\text{V}$ |
|--------|----------------------------|------------------------|--------------------------------|--|--|---------------------------------------|--|---|
| | V | V | V | A | A | V | μA | pF |
| 1N5400 | 50 | 35 | 50 | 3.0 | 200 | 1.0 | 10 | 70 |
| 1N5401 | 100 | 70 | 100 | 3.0 | 200 | 1.0 | 10 | 70 |
| 1N5402 | 200 | 140 | 200 | 3.0 | 200 | 1.0 | 10 | 70 |
| 1N5403 | 300 | 210 | 300 | 3.0 | 200 | 1.0 | 10 | 70 |
| 1N5404 | 400 | 280 | 400 | 3.0 | 200 | 1.0 | 10 | 70 |
| 1N5405 | 500 | 350 | 500 | 3.0 | 200 | 1.0 | 10 | 70 |
| 1N5406 | 600 | 420 | 600 | 3.0 | 200 | 1.0 | 10 | 70 |
| 1N5407 | 800 | 560 | 800 | 3.0 | 200 | 1.0 | 10 | 70 |
| 1N5408 | 1000 | 700 | 1000 | 3.0 | 200 | 1.0 | 10 | 70 |

NOTE 1: Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

NOTE 2: Special silicon rectifiers also available.

3A PLASTIC SILICON RECTIFIERS

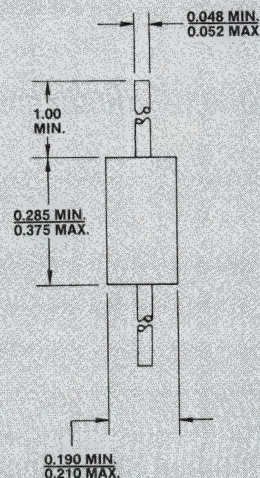


FIGURE 1

All Dimensions in INCHES

MECHANICAL CHARACTERISTICS

CASE: Molded plastic.

LEAD MATERIAL: Copper, plated tin.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N5400 thru 1N5408

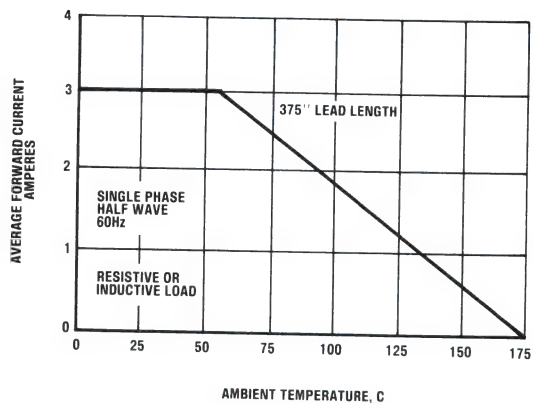


FIGURE 2
FORWARD DERATING CURVE

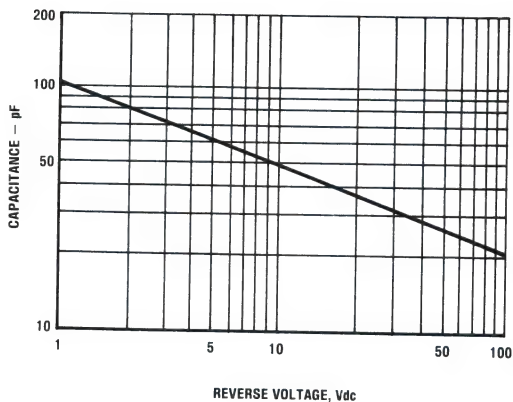


FIGURE 3
TYPICAL JUNCTION CAPACITANCE
vs. REVERSE VOLTAGE

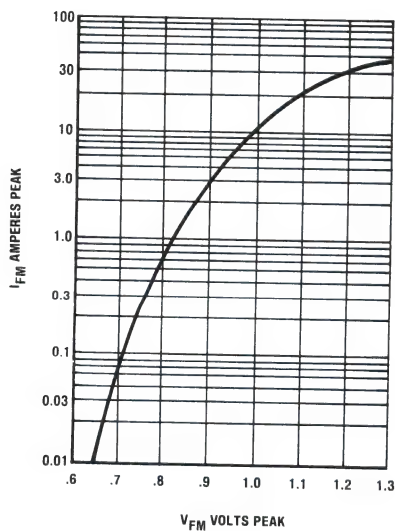


FIGURE 4
TYPICAL INSTANTANEOUS
FORWARD CHARACTERISTICS

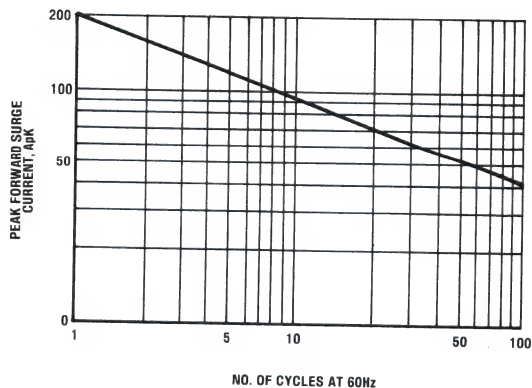


FIGURE 5
MAXIMUM NON REPETITIVE SURGE CURRENT

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- FAST RECOVERY
- PIV TO 600 VOLTS
- JAN/JANS/TX/TXV TYPES AVAILABLE PER MIL-S-19500/411

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C
Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

| TYPE | PIV | MINIMUM REVERSE BREAKDOWN VOLTAGE @ 50 μ A | FORWARD VOLTAGE VF @ 9Adc | | MAXIMUM REVERSE CURRENT | | MAXIMUM REVERSE RECOVERY TIME nsec |
|---------------------|------|--|------------------------------------|------|-------------------------------|------------|--|
| | | | MIN. | MAX. | 25°C | 100°C | |
| J, JTX, JTXV 1N5415 | 50V | 55V | 0.6V(pk) 1.5V(pk) | | 1.0 μ A | 20 μ A | 150 |
| J, JTX, JTXV 1N5416 | 100V | 110V | | | | | 150 |
| J, JTX, JTXV 1N5417 | 200V | 220V | | | | | 150 |
| J, JTX, JTXV 1N5418 | 400V | 440V | | | | | 150 |
| J, JTX, JTXV 1N5419 | 500V | 550V | | | | | 250 |
| J, JTX, JTXV 1N5420 | 600V | 660V | | | | | 400 |

FAST SWITCHING RECTIFIERS

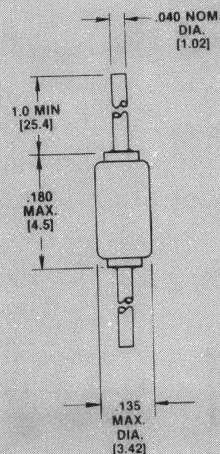


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Silver clad copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N5415 - 1N5420

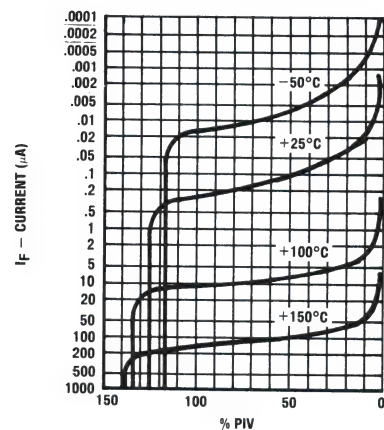


FIGURE 2
TYPICAL REVERSE CURRENT vs. PIV

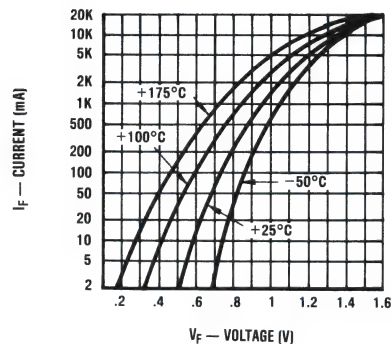


FIGURE 3
TYPICAL FORWARD CURRENT
vs. FORWARD VOLTAGE

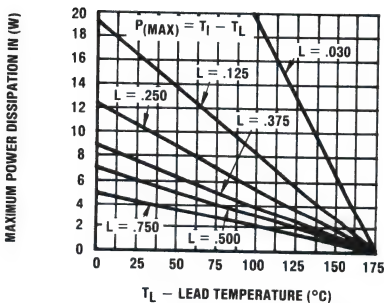


FIGURE 4
MAXIMUM POWER
vs. LEAD TEMPERATURE

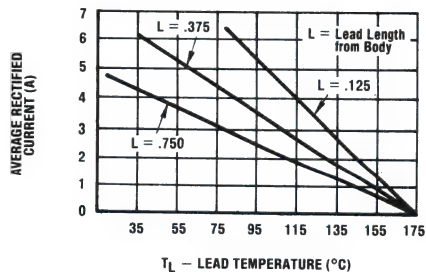


FIGURE 5
MAXIMUM CURRENT vs. LEAD TEMPERATURE

SANTA ANA, CA

For more information call:
 (714) 979-8220

SCOTTSDALE, AZ

**1N5550
 thru
 1N5554**

FEATURES

- Voidless hermetically sealed glass package.
- Triple layer passivation.
- Metallurgically bonded.
- JAN/TX/TXV available per MIL-S-19500/420.

MAXIMUM RATINGS

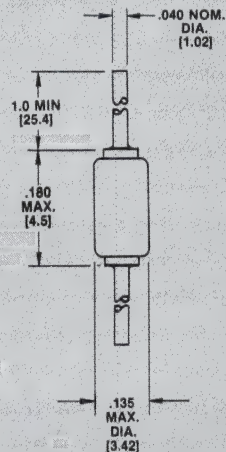
Operating Temperature: -65°C to $+175^{\circ}\text{C}$.

Storage Temperature: -65°C to $+175^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

| TYPE | MINIMUM REVERSE BREAKDOWN VOLTAGE @ 50 μA | PEAK INVERSE VOLTAGE PIV VOLTS | AVERAGE RECTIFIED CURRENT I_{g} AMPS (55°C) | FORWARD VOLTAGE V_{f} @ 9A (pk) | | REVERSE CURRENT I_{R} @ PIV μA | REVERSE RECOVERY t_{rr} μSEC |
|--------|--|--|--|---|-----------|---|---|
| | | | | MIN. | MAX. | | |
| 1N5550 | 240 | 200 | 5.0 | .6V (pk) | 1.2V (pk) | 1.0 | 2.0 |
| 1N5551 | 480 | 400 | 5.0 | .6V (pk) | 1.2V (pk) | 1.0 | 2.0 |
| 1N5552 | 660 | 600 | 5.0 | .6V (pk) | 1.2V (pk) | 1.0 | 2.0 |
| 1N5553 | 880 | 800 | 5.0 | .6V (pk) | 1.3V (pk) | 1.0 | 2.0 |
| 1N5554 | 1100 | 1000 | 5.0 | .6V (pk) | 1.3V (pk) | 1.0 | 2.0 |

RECTIFIERS



MECHANICAL CHARACTERISTICS

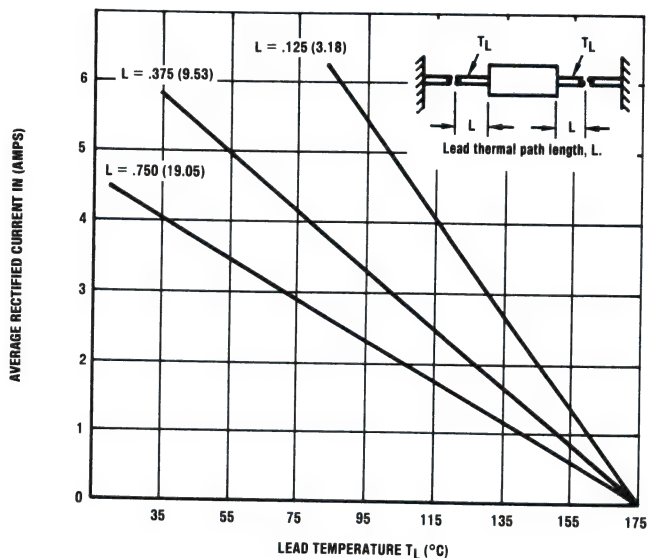
CASE: Hermetically sealed hard glass.

LEAD MATERIAL: Tinned Copper.

MARKING: Body painted, alpha numeric.

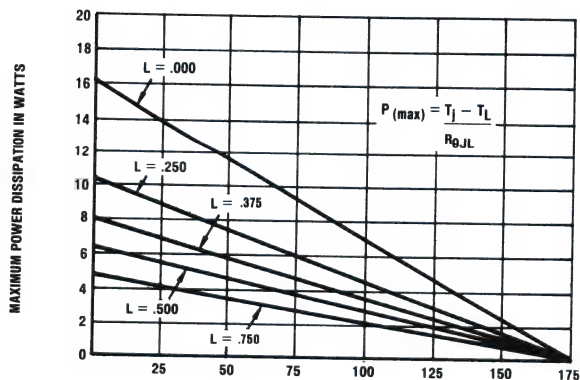
POLARITY: Cathode band.

1N5550 thru 1N5554



- NOTES: 1. Dimensions are in inches.
2. Metric equivalents (to the nearest .01 mm) are given for general information only and are based upon 1 inch = 25.4 mm.

FIGURE 2
MAXIMUM CURRENT vs. LEAD TEMPERATURE



| L | $R_{\theta JL}$ |
|--------------|-----------------------------|
| INCHES | $^{\circ}\text{C}/\text{W}$ |
| .000 | 11 |
| .250 (6.35) | 16.5 |
| .375 (9.53) | 22 |
| .500 (12.70) | 26 |
| .750 (19.05) | 35.5 |

Maximum lead temperature in $^{\circ}\text{C}$ (T_L) at point "L" from body
(For maximum operating junction temperature of 175 $^{\circ}\text{C}$ with equal two-lead conditions).

- NOTES: 1. Dimensions are in inches.
2. Metric equivalents (to the nearest .01 mm) are given for general information only and are based upon 1 inch = 25.4 mm.

FIGURE 3
MAXIMUM POWER IN WATTS vs. LEAD TEMPERATURE

MICRO

Microsemi Corp.

The diode experts

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

1N5614 thru
1N5622

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- STANDARD RECOVERY
- PIV TO 1000 VOLTS
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/427

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C
Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

| ELECTRICAL CHARACTERISTICS | | | | | | | | | |
|----------------------------|---|---|---|-------|--|--|-------|--|--|
| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | BREAKDOWN VOLTAGE (MIN.) B _V @ 50 μ A | AVERAGE RECTIFIED CURRENT I _O | | FORWARD VOLTAGE (MAX.) V _F @ 3 A | REVERSE CURRENT (MAX.) I _R @ PIV | | SURGE CURRENT (MAX.) (NOTE 1) I _F (surge) | REVERSE RECOVERY (MAX.) (NOTE 2) t _{rr} |
| | VOLTS | VOLTS | AMPS | | VOLTS | μ A | | AMPS | μ sec. |
| | | | 50°C | 100°C | | 25°C | 100°C | | |
| JAN 1N5614 | 200 | 220 | 1.00 | .750 | .8 MIN. | 1.0 | 25 | 30 | 2.0 |
| JAN 1N5616 | 400 | 440 | 1.00 | .750 | | 1.0 | 25 | 30 | 2.0 |
| JAN 1N5618 | 600 | 660 | 1.00 | .750 | 1.3 MAX. | 1.0 | 25 | 30 | 2.0 |
| JAN 1N5620 | 800 | 880 | 1.00 | .750 | | 1.0 | 25 | 30 | 2.0 |
| JAN 1N5622 | 1000 | 1100 | 1.00 | .750 | | 1.0 | 25 | 30 | 2.0 |

NOTE 1: T_A = 100°C, f = 60 Hz, I_O = 75A, 10-8 m sec. surges @ 1/minute.

NOTE 2: I_F, I_{rr} = 1A, I_{rr} = .250A.

MILITARY RECTIFIERS

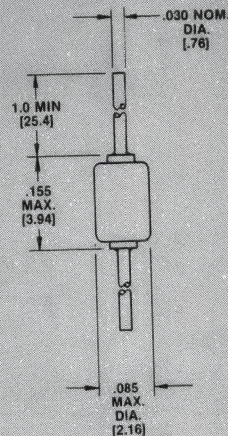


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N5614 thru 1N5622

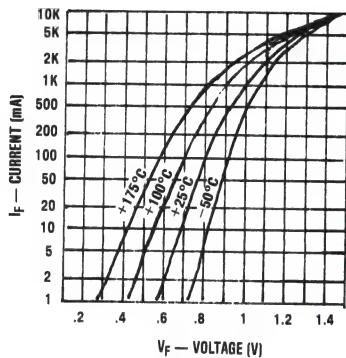


FIGURE 2
TYPICAL FORWARD VOLTAGE
vs FORWARD CURRENT

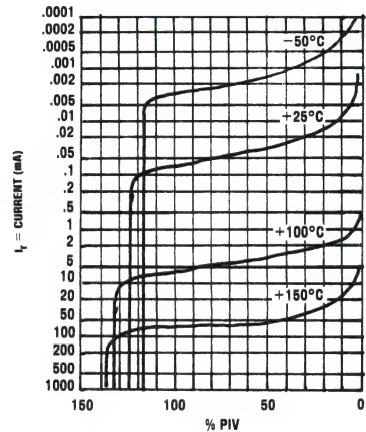


FIGURE 3
TYPICAL REVERSE CURRENT vs PIV

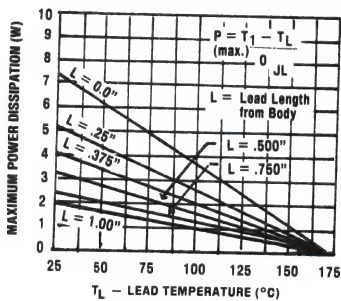


FIGURE 4
MAXIMUM POWER DISSIPATION
vs LEAD TEMPERATURE

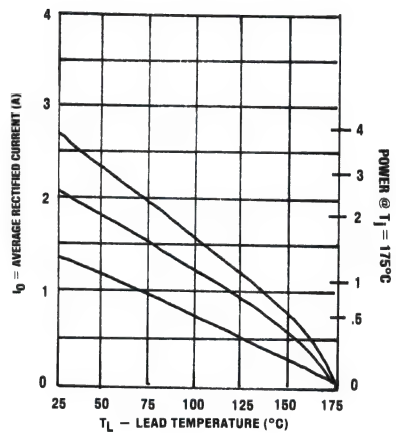


FIGURE 5
MAXIMUM CURRENT
vs LEAD TEMPERATURE

**1N5615
thru
1N5623**



FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- FAST RECOVERY
- PIV TO 1000 VOLTS
- JANS/TX/TXV TYPES AVAILABLE PER MIL-S-19500/429

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.
Storage Temperature: -65°C to $+200^{\circ}\text{C}$.
Thermal Resistance: -38°C/W
Surge Current: 25A.

ELECTRICAL CHARACTERISTICS

| ELECTRICAL CHARACTERISTICS | | | | | | | | | | |
|----------------------------|---|---|---|-------|---|--|-------|-----------------------------------|--|--|
| TYPE | PEAK INVERSE VOLTAGE (MAX.) PIV | BREAKDOWN VOLTAGE (MIN.) BV @ 50μA | AVERAGE RECTIFIED CURRENT I ₀ | | FORWARD VOLTAGE (MAX.) V _F @ 3A | REVERSE CURRENT (MAX.) I _R @ PIV | | CAPACITANCE (MAX.) C @ -12V | SURGE CURRENT (MAX.) (NOTE 1) I _F (surge) | REVERSE RECOVERY (MAX.) (NOTE 2) t _{rr} |
| | VOLTS | VOLTS | AMPS | | VOLTS | μA | | pF | AMPS | n sec |
| | | | 55°C | 100°C | | 25°C | 100°C | | | |
| JAN 1N5615 | 200 | 220 | 1.0 | .750 | .8 MIN. | .5 | 25 | 45 | 25 | 150 |
| JAN 1N5617 | 400 | 440 | 1.0 | .750 | | .5 | 25 | 35 | 25 | 150 |
| JAN 1N5619 | 600 | 660 | 1.0 | .750 | | .5 | 25 | 25 | 25 | 250 |
| JAN 1N5621 | 800 | 880 | 1.0 | .750 | 1.6 MAX. | .5 | 25 | 20 | 25 | 300 |
| JAN 1N5623 | 1000 | 1100 | 1.0 | .750 | | .5 | 25 | 15 | 25 | 500 |

NOTE 1: $T_A = 100^{\circ}\text{C}$, $f = 60\text{ Hz}$, $I_O = 750\text{ mA}$, 10-8 msec surges @ 1/minute

NOTE 2: $I_F = .5\text{ A}$, $I_{rr} = 1\text{ A}$, $I_{rr} = .250\text{ A}$

MILITARY RECTIFIERS

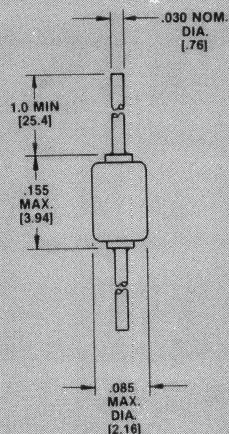


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N5615 thru 1N5623

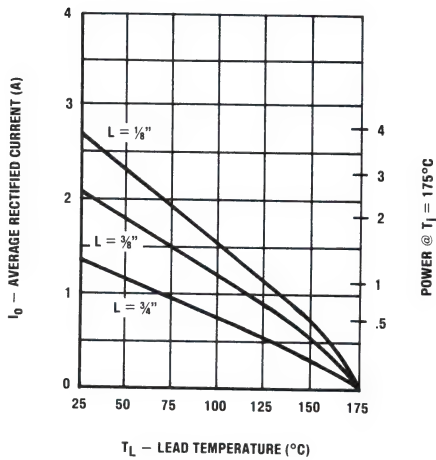


FIGURE 2
MAXIMUM CURRENT
vs LEAD TEMPERATURE

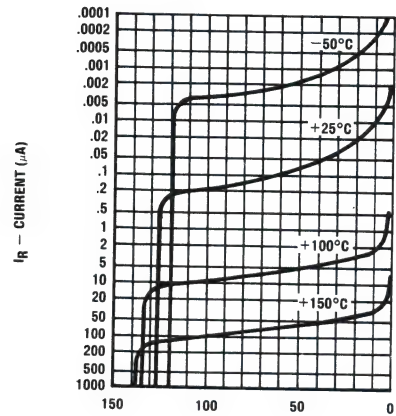


FIGURE 3
TYPICAL REVERSE CURRENT
vs. PIV

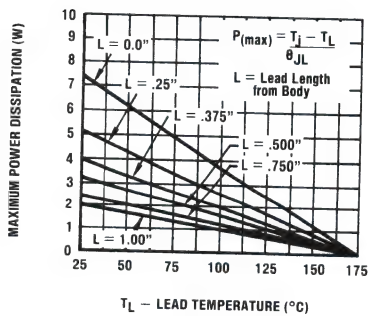


FIGURE 4
MAXIMUM POWER
vs. LEAD TEMPERATURE

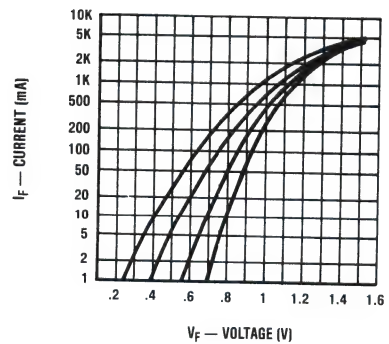


FIGURE 5
TYPICAL FORWARD VOLTAGE
vs. FORWARD CURRENT

1N5802 thru 1N5806

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- ULTRA FAST RECOVERY
- PIV TO 150 VOLTS
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/477

MAXIMUM RATINGS

Operating Temperature: -55°C to $+200^{\circ}\text{C}$.
Storage Temperature: -55°C to $+200^{\circ}\text{C}$.
Surge: Pulse 8.3ms, 35 A

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | BREAKDOWN VOLTAGE (MIN.) B_V @ $100\mu\text{A}$ | AVERAGE RECTIFIED CURRENT I_o | FORWARD VOLTAGE DROP (MAX.) V_F | REVERSE CURRENT (MAX.) I_R @ PIV | SURGE CURRENT (MAX.) (NOTE 1) I_F (surge) | JUNCTION CAPACITANCE (MAX.) C @ -10 V | REVERSE RECOVERY TIME (MAX.) (NOTE 2) |
|------------|---|--|--|---|---|---|---|---|
| | VOLTS | VOLTS | AMPS | VOLTS | μA | AMPS | pF | n sec |
| | | | $T_A = 55^{\circ}\text{C}$ | 25°C | 100°C | 25°C | 100°C | |
| JAN 1N5802 | 50 | 60 | 1.0 | .875 @ | 1.0 | 50 | 35 | 25 |
| JAN 1N5804 | 100 | 110 | 1.0 | 1A (pk) | .8 @ | 1.0 | 50 | 35 |
| JAN 1N5806 | 150 | 160 | 1.0 | .975 @ 2.5A pk) | 1A (pk) | 1.0 | 50 | 35 |
| 1N5802 | 50 | 55 | 2.5 | .875 | .80 | 1.0 | 50 | 35 |
| 1N5803 | 75 | 80 | @ | @ | @ | 1.0 | 50 | 35 |
| 1N5804 | 100 | 110 | $T_L =$ | 1.0 Adc | 2.5Adc | 1.0 | @ | single |
| 1N5805 | 125 | 135 | 75°C | 250msec | @ | 1.0 | 75°C | cycle |
| 1N5806 | 150 | 160 | ($L = \frac{1}{2}$ " | pulse | 75°C | 1.0 | | 8.3msec |
| | | | width | | | | | |

NOTE 1: JAN $T_A = 55^{\circ}\text{C}$ @ rated I_o , 10–8.3 msec surges

NOTE 2: $I_F = 1.0\text{A}$, $I_R = 1.0\text{A}$, recover to .1A

MILITARY RECTIFIERS

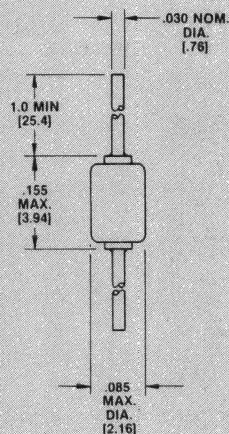


FIGURE 1
PACKAGE "A"

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N5802 thru 1N5806

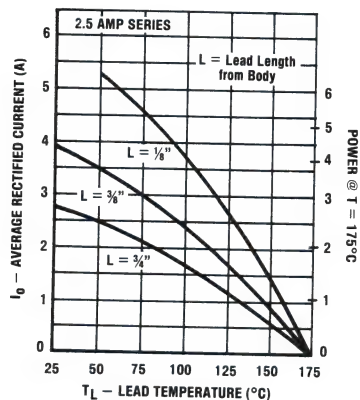


FIGURE 2
OUTPUT CURRENT vs. LEAD TEMP.

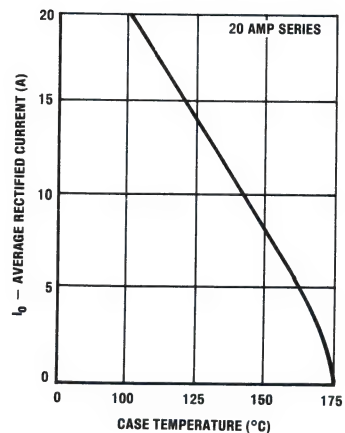


FIGURE 3
OUTPUT CURRENT vs. CASE TEMP.

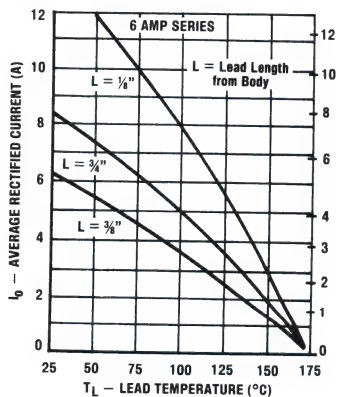


FIGURE 4
OUTPUT CURRENT vs. LEAD TEMP.

1N5807 thru 1N5811

FEATURES

- MICROMINIATURE PACKAGE
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- TRIPLE LAYER PASSIVATION
- METALLURGICALLY BONDED
- ULTRA FAST RECOVERY
- HIGH SURGE CAPABILITY AND EXTREMELY STABLE CHARACTERISTICS
- PIV TO 160 VOLTS
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/477

MAXIMUM RATINGS

Operating Temperature: -55°C to $+200^{\circ}\text{C}$.
Storage Temperature: -55°C to $+200^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | BREAKDOWN VOLTAGE (MIN.) BV @ 100μA | AVERAGE RECTIFIED CURRENT Io | FORWARD VOLTAGE DROP (MAX.) VF | | REVERSE CURRENT (MAX.) IR @ PIV | | SURGE CURRENT (MAX.) (NOTE 1) IF (surge) | JUNCTION CAPACITANCE (MAX.) C @ -10 V | REVERSE RECOVERY TIME (MAX.) (NOTE 2) |
|------------|---|--|---------------------------------------|--|---------|--|-------|--|--|---|
| | | | | VOLTS | | μA | | | | |
| | VOLTS | VOLTS | AMPS | VOLTS | | μA | | AMPS | pF | nsec |
| | | | TA55°C | 25°C | 100°C | 25°C | 100°C | | | |
| JAN 1N5807 | 50 | 60 | 3.0 | .875 | | 5 | 150 | 125 | 60 | 30 |
| JAN 1N5809 | 100 | 110 | 3.0 | @ | .8 @ | 5 | 150 | 125 | 60 | 30 |
| JAN 1N5811 | 150 | 160 | 3.0 | 4A (pk) | 4A (pk) | 5 | 150 | 125 | 60 | 30 |
| | | | | .925 | @ | | | | | |
| | | | | 6A (pk) | | | | | | |
| 1N5807 | 50 | 55 | 6.0 | .875 | .700 | 5 | | 125 | | 30 |
| 1N5808 | 75 | 80 | @ | @ | @ | 5 | 150 | | | 30 |
| 1N5809 | 100 | 110 | TL = | 4Adc | 6Adc | 5 | @ | Single | | 30 |
| 1N5810 | 125 | 135 | 75°C | 250 | 250 | 5 | 75°C | cycle | 50 | 30 |
| 1N5811 | 150 | 160 | (L = ½") | msec | msec | 5 | | 8.3msec | typ. | 30 |
| | | | | pulse | pulse | | | | | |
| | | | | width | width | | | | | |

NOTE 1: $T_A = 55^{\circ}\text{C}$ @ rated I_O and V_{RM} , 10–8.3 msec surges

NOTE 2: $I_F = 1.0\text{A}$, $I_R = 1.0\text{A}$, recover to .1A

RECTIFIERS

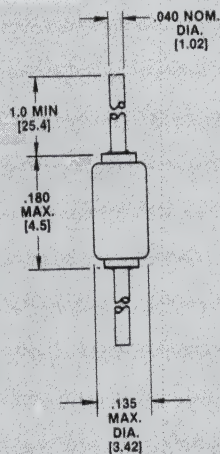


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed hard glass.

LEAD MATERIAL: Silver clad copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N5807 thru 1N5811

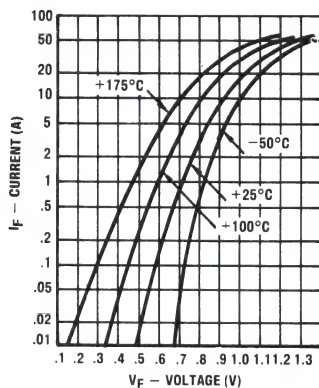


FIGURE 2
TYPICAL FORWARD CURRENT
vs. FORWARD VOLTAGE

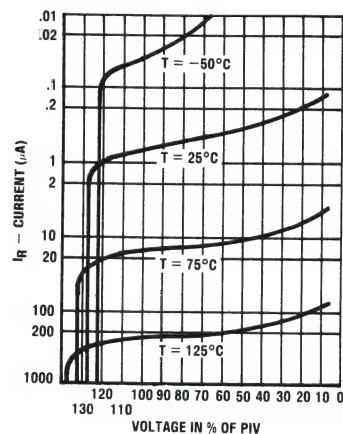


FIGURE 3
TYPICAL REVERSE CURRENT
vs. VOLTAGE

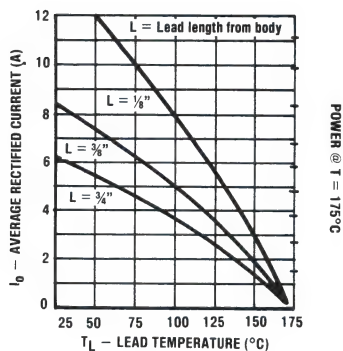


FIGURE 4
OUTPUT CURRENT vs. LEAD TEMP.

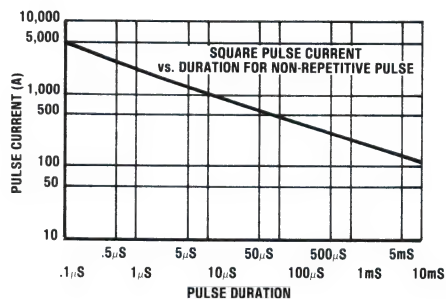
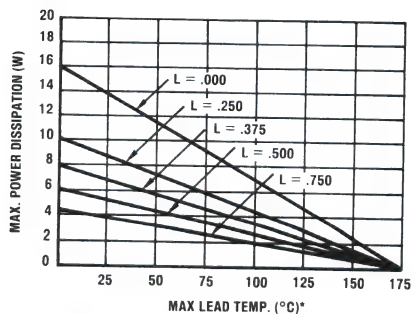


FIGURE 5
FORWARD PULSE CURRENT vs. DURATION



*Maximum lead temp. in °C (T_L) at point "L" from body.
(For max. operating junction temp. of 175°C with equal
two-lead conditions.)

FIGURE 6
MAXIMUM LEAD TEMP. vs P_d

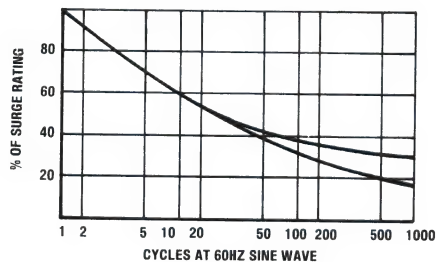


FIGURE 7
MULTIPLE SURGE CURRENT vs. DURATION

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

FEATURES

- Triple layer passivation.
- Metallurgically bonded.
- Ultra fast recovery.
- Voidless hermetically sealed glass package.
- JAN/TX/TXV available for 1N6074, 1N6075 per MIL-S-19500/503.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+155^{\circ}\text{C}$.
Storage Temperature: -65°C to $+155^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

(@ 25°C unless otherwise specified)

| TYPE | PEAK INVERSE VOLTAGE V_{PIV} | FORWARD VOLTAGE V_F (PULSED) | AVERAGE RECTIFIED CURRENT I_R | REVERSE CURRENT @ V_{PIV} I_R | REVERSE* RECOVERY TIME t_{rr} | SURGE CURRENT I_F (SURGE) |
|--------|---|---|--|--|--|-----------------------------------|
| | VOLTS | VOLTS | AMPS | μA | ns | AMPS |
| 1N6073 | 50 | 2.04 | 3.0 | 1.0 | 30 | 35 |
| 1N6074 | 100 | 2.04 | 3.0 | 1.0 | 30 | 35 |
| 1N6075 | 150 | 2.04 | 3.0 | 1.0 | 30 | 35 |
| 1N6076 | 50 | 1.76 | 6.0 | 5.0 | 30 | 75 |
| 1N6077 | 100 | 1.76 | 6.0 | 5.0 | 30 | 75 |
| 1N6078 | 150 | 1.76 | 6.0 | 5.0 | 30 | 75 |
| 1N6079 | 50 | 1.50 | 12.0 | 10.0 | 30 | 175 |
| 1N6080 | 100 | 1.50 | 12.0 | 10.0 | 30 | 175 |
| 1N6081 | 150 | 1.50 | 12.0 | 10.0 | 30 | 175 |

*NOTE: $I_F = 0.5\text{A}$, $I_R = -1.0\text{A}$ and $I_{RR} = -0.25\text{A}$

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed hard glass.

Lead Material: 1N6073-75 & 1N6079-81 — Tinned copper.
1N6076-78 — Gold clad copper.

Marking: Body painted, alpha numeric.

Polarity: Cathode band.

POWER RECTIFIERS

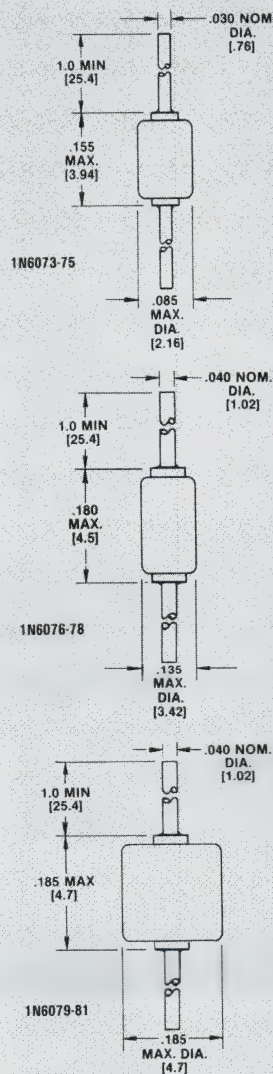


FIGURE 1

1N6073 thru 1N6081

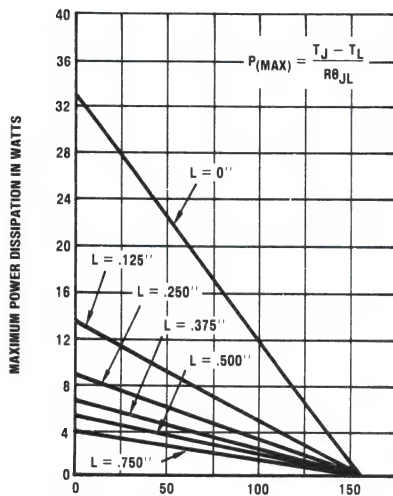


FIGURE 2. Maximum power in watts vs lead temperature for 1N6079, 1N6080 and 1N6081

| L | $R_{\theta_{JL}}$ |
|---------------|-------------------|
| INCHES (mm) | °C/W |
| 0.000 | 5.0 |
| 0.125 (3.17) | 11.5 |
| 0.250 (6.35) | 17.5 |
| 0.375 (9.53) | 23.5 |
| 0.500 (12.70) | 29.0 |
| 0.750 (19.05) | 40.0 |

Maximum lead temperature in °C (T_L) at point "L" from body (for maximum operating junction temperature with equal two-lead conditions).

NOTES:

1. Dimensions are in inches.
2. Metric equivalents (to the nearest .01 mm) are given for general information only and are based upon 1 inch = 25.4 mm.

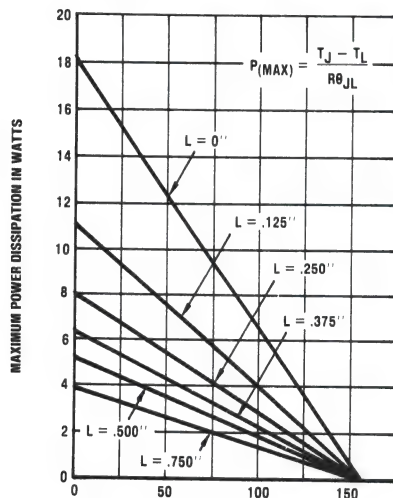


FIGURE 3. Maximum power in watts vs lead temperature for 1N6076, 1N6077 and 1N6078

| L | $R_{\theta_{JL}}$ |
|---------------|-------------------|
| INCHES (mm) | °C/W |
| 0.000 | 8.5 |
| 0.125 (3.17) | 14.0 |
| 0.250 (6.35) | 19.5 |
| 0.375 (9.53) | 25.0 |
| 0.500 (12.70) | 30.0 |
| 0.750 (19.05) | 40.0 |

Maximum lead temperature in °C (T_L) at point "L" from body (for maximum operating junction temperature with equal two-lead conditions).

NOTES:

1. Dimensions are in inches.
2. Metric equivalents (to the nearest .01 mm) are given for general information only and are based upon 1 inch = 25.4 mm.

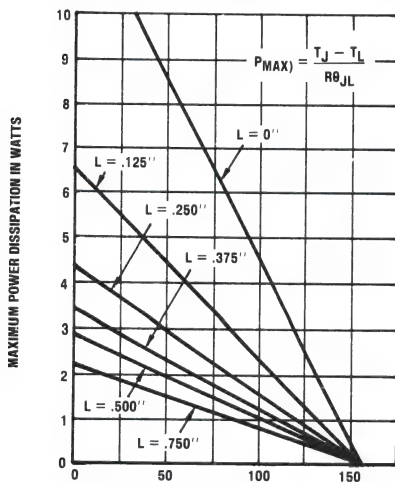


FIGURE 4. Maximum power in watts vs lead temperature for 1N6073, 1N6074 and 1N6075

| L | $R_{\theta_{JL}}$ |
|---------------|-------------------|
| INCHES (mm) | °C/W |
| 0.000 | 13 |
| 0.125 (3.17) | 24 |
| 0.250 (6.35) | 35 |
| 0.375 (9.53) | 46 |
| 0.500 (12.70) | 54 |
| 0.750 (19.05) | 70 |

Maximum lead temperature in °C (T_L) at point "L" from body (for maximum operating junction temperature with equal two-lead conditions).

NOTES:

1. Dimensions are in inches.
2. Metric equivalents (to the nearest .01 mm) are given for general information only and are based upon 1 inch = 25.4 mm.

DESCRIPTION/FEATURES

- ECONOMICAL SERIES
- HIGH SURGE, 150 AMP MAXIMUM
- UNIVERSAL REPLACEMENT FOR MANY GLASS, EPOXY, ENCAPSULATED, AND METALLIC RECTIFIERS
- PEAK REVERSE VOLTAGES THROUGH 1000 VOLTS

VOLTAGE RATINGS

| | V_{RRM} — Max. Repetitive Peak Reverse Voltage (V) $T_J = -65^{\circ}\text{C}$ to 175°C | V_R — Max. Direct Reverse Voltage (V) $T_J = -65^{\circ}\text{C}$ to 175°C |
|-------------|--|---|
| Part Number | | |
| 30S1 | 100 | 100 |
| 30S2 | 200 | 200 |
| 30S3 | 300 | 300 |
| 30S4 | 400 | 400 |
| 30S5 | 500 | 500 |
| 30S6 | 600 | 600 |
| 30S8 | 800 | 800 |
| 30S10 | 1000 | 1000 |

ELECTRICAL SPECIFICATIONS

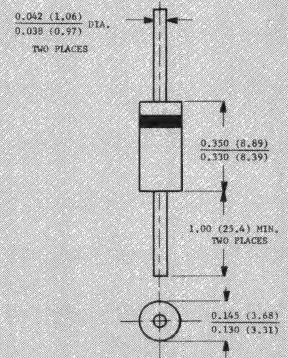
| | | Units | Conditions |
|---|------|---------------|---|
| $I_{F(AV)}$ Max. average forward current | 3.0 | A | 1 phase operation, 180° conduction. $T_L = 125^{\circ}\text{C}$, lead length 9.5 mm (0.375 in.) |
| I_{FSM} Max. peak one-cycle non-repetitive surge current | 143 | A | Half cycle 50 Hz sine wave or 6 ms rectangular pulse |
| | 150 | | Half cycle 60 Hz sine wave or 5 ms rectangular pulse |
| | 170 | | Following any rated load condition and with rated V_{RRM} applied. |
| | 178 | | Half cycle 50 Hz sine wave or 6 ms rectangular pulse |
| I_{2t} Max. I_{2t} for fusing | 103 | A^2s | Half cycle 60 Hz sine wave or 5 ms rectangular pulse |
| | 94 | | Following any rated load condition and with V_{RRM} applied following surge = 0. |
| | 146 | | $t = 10$ ms With rated V_{RRM} applied following surge, initial $T_J = 175^{\circ}\text{C}$. |
| | 133 | | $t = 8.3$ ms |
| Max. I_{2t} for individual device fusing | 146 | | $t = 10$ ms With $V_{RRM} = 0$ following surge, initial $T_J = 175^{\circ}\text{C}$. |
| | 133 | | $t = 8.3$ ms |
| $I_2\sqrt{t}$ Max. $I_2\sqrt{t}$ for individual device fusing | 1450 | $A^2\sqrt{s}$ | $t = 0.1$ to 10 ms, $V_{RRM} = 0$ following surge. |
| V_{FM} Max. peak forward voltage | 1.0 | V | $I_{F(AV)} = 3A$ (9.4A peak); $T_J = 25^{\circ}\text{C}$. |
| $I_{R(AV)}$ Max. average reverse current | 0.3 | mA | Max. rated $I_{F(AV)}$, V_{RRM} and $T_L = 100^{\circ}\text{C}$. ($l = 9.5$ mm (0.375 in.)) |

① $I_2\sqrt{t}$ for time $t_X = I_2\sqrt{t} \cdot \sqrt{t_X}$.

TERMAL-MECHANICAL SPECIFICATIONS

| | | | |
|---|--------------|--------------------|--|
| T_J Max. operating junction temperature range | -65 to 175 | $^{\circ}\text{C}$ | |
| T_{stg} Max. storage temperature range | -65 to 175 | $^{\circ}\text{C}$ | |
| R_{thJC} Max. internal thermal resistance, junction-to-lead | 16.5 | deg. C/W | DC operation, double-side cooled, measured 9.5 mm (0.375 in.) from body. |
| wt Approximate weight | 0.65 (0.023) | g (oz.) | |

3 AMP MEDIUM POWER SILICON RECTIFIER DIODES



Cathode Indicated by Color Band
All Dimensions in Inches (Millimeters).

MECHANICAL CHARACTERISTICS

CASE: Molded plastic use Flame Retardant Epoxy.

TERMINALS: Axial leads, solderable per MIL-STD-202, Method 208.

POLARITY: Color band denotes cathode.

MOUNTING POSITION: Any.

30S Series

RATING AND CHARACTERISTIC CURVES

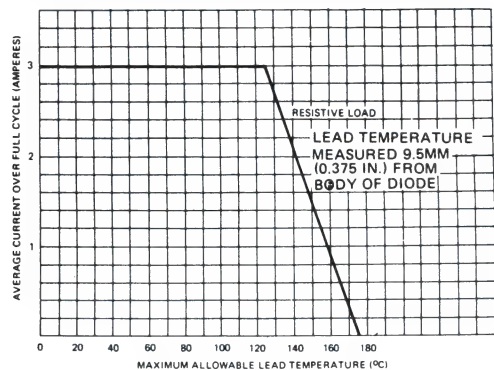


Fig. 1 – Average Forward Current Vs. Lead Temperature at Heat Sinks, $l = 9.5$ mm (3/8 Inch) (Single Phase Operation)

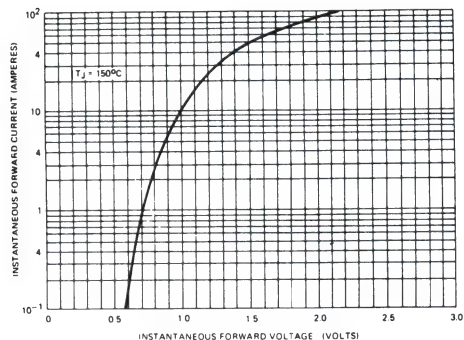


Fig. 2 – Maximum Forward Voltage Vs. Forward Current

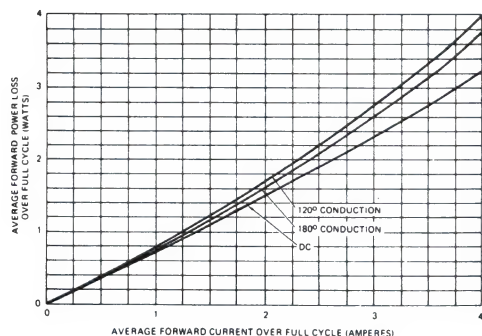


Fig. 3 – Maximum Forward Power Loss Vs. Forward Current (Sinusoidal Current Waveform)

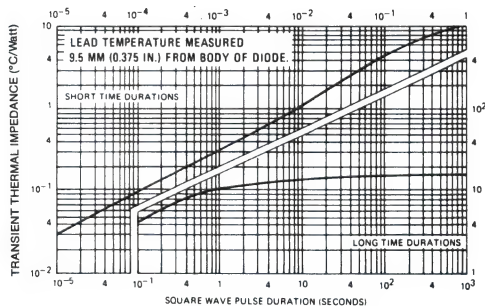


Fig. 4 – Maximum Transient Thermal Impedance, Junction-to-Lead, Vs. Pulse Duration

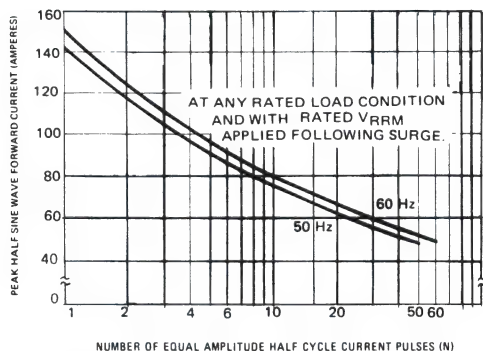


Fig. 5 – Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses

40SL SERIES

DESCRIPTION/FEATURES

- ECONOMICAL 6 AMPS AVERAGE MOLDED DEVICE OFFERS CAPABILITY OF STUD-MOUNTED RECTIFIERS
- 400 AMPS SURGE PROVIDES HIGH IN-RUSH CURRENT CAPABILITY
- WIDE VOLTAGE RANGE AVAILABLE: 50 TO 1000 VOLTS V_{RRM}

MAJOR RATINGS AND CHARACTERISTICS

| | 40 SL | |
|-------------------|------------|------------------|
| $I_F(AV)$ | 4 | A |
| at Max. T_L | 62 | °C |
| I_{FSM} at 50Hz | 143 | A |
| I_{FSM} at 60Hz | 150 | A |
| I^2_t at 50Hz | 103 | A ² s |
| I^2_t at 60Hz | 94 | A ² s |
| T_J | -40 to 150 | °C |
| V_{RRM} Range | 50 - 1000 | V |
| t_{rr} | 200 | ns |

VOLTAGE RATINGS

| Part Number | V_{RRM} (V) Max. Repetitive Peak Reverse Voltage | V_R (V) Max. Direct Reverse Voltage |
|-------------|---|--|
| | $T_J = -40^\circ\text{C}$ to 200°C | $T_J = -40^\circ\text{C}$ to 200°C |
| 40SL05 | 50 | 50 |
| 40SL1 | 100 | 100 |
| 40SL2 | 200 | 200 |
| 40SL4 | 400 | 400 |
| 40SL5 | 500 | 500 |
| 40SL6 | 600 | 600 |
| 40SL8 | 800 | 800 |
| 40SL10 | 1000 | 1000 |

ELECTRICAL SPECIFICATIONS

| | 40SL | Units | Conditions |
|---|------|---------------------------|---|
| $I_F(AV)$ Max. average forward current | 4 | A | 1-phase operation, 180° conduction. $T_L = 95^\circ\text{C}$, $l = 9.5$ mm (0.375 in.) |
| I_{FSM} Max. peak one-cycle non-repetitive surge current | 143 | A | Half cycle 50Hz sine wave or 6ms rectangular pulse Following any rated load condition and with rated V_{RRM} applied. |
| | 150 | | Half cycle 60Hz sine wave or 5ms rectangular pulse |
| | 170 | | Half cycle 50Hz sine wave or 6ms rectangular pulse Following any rated load condition and with V_{RRM} applied following surge = 0. |
| | 178 | | Half cycle 60Hz sine wave or 5ms rectangular pulse |
| I^2_t Max. I^2_t for fusing | 103 | A ² s | $t = 10$ ms With rated V_{RRM} applied following surge, initial $T_J = 175^\circ\text{C}$. |
| | 94 | | $t = 8.3$ ms |
| | 145 | | $t = 10$ ms With $V_{RRM} = 0$ following surge, initial $T_J = 175^\circ\text{C}$. |
| | 132 | | $t = 8.3$ ms |
| $I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for individual device fusing (Note 1.) | 1450 | A ² \sqrt{s} | $t = 0.1$ to 10ms, $V_{RRM} = 0$ following surge. |
| V_{FM} Max. peak forward voltage | 1.40 | V | $I_{F(AV)} = 4$ A (12.6A peak), $T_J = 25^\circ\text{C}$ |
| $I_R(AV)$ Max. average reverse current | 5 | mA | $T_L = 62^\circ\text{C}$, $V_{RRM} = \text{rated } V_{RRM}$. $I_{F(AV)} = \text{rated } I_{F(AV)}$, 1 phase operation. |
| I_R Max. dc reverse current | 3 | mA | $T_L = 100^\circ\text{C}$ |
| | 25 | μA | $T_L = 25^\circ\text{C}$ $V_R = \text{Rated } V_R$ |
| t_{rr} Max. reverse recovery time | 200 | ns | $T_L = 25^\circ\text{C}$, $I_F = 1$ A, $V_R = 30$ V |
| | | | $di/dt = 25$ A/ μs |
| $I_{RM}(REC)$ Max. peak reverse recovery current | 5 | A | $T_L = 25^\circ\text{C}$, $I_{FM} = 12.5$ A $t_p \approx 1.6\mu\text{s}$, $di/dt = 25$ A/ μs |

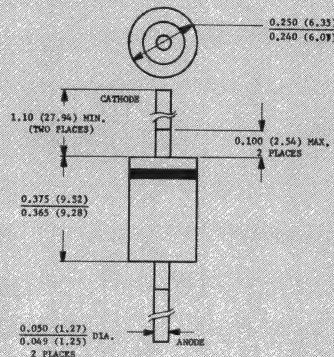
THERMAL MECHANICAL SPECIFICATIONS

| | | |
|--|--------------|--------------------|
| T_J Max. operating junction temperature range | -40°C to 150 | °C |
| T_{stg} Max. storage temperature range | -40°C to 175 | °C |
| R_{thJC} Max. internal thermal resistance, junction-to-leads | -- | deg C/W (Note 2.) |
| l Length of leads (l) (1/8") 3.2 mm | 11.0 | deg C/W $\pm 10\%$ |
| | 14.7 | |
| | 20.0 | |
| wt Approximate weight | 1.5 (0.053) | g (oz) |

Note 1. I^2t for time $t_x = I^2\sqrt{t} \cdot \sqrt{t_x}$

Note 2. DC operation, double side cooled, measured 9.5 mm (0.375 in.) from body.

4 AMP AXIAL-LEAD FAST RECOVERY RECTIFIER DIODES



All Dimensions in Inches and (Millimeters)

MECHANICAL CHARACTERISTICS

CASE: Molded plastic use Flame Retardant Epoxy.

TERMINALS: Axial leads, solderable per MIL-STD-202, Method 208.

POLARITY: Color band denotes cathode.

MOUNTING POSITION: Any.

40SL Series

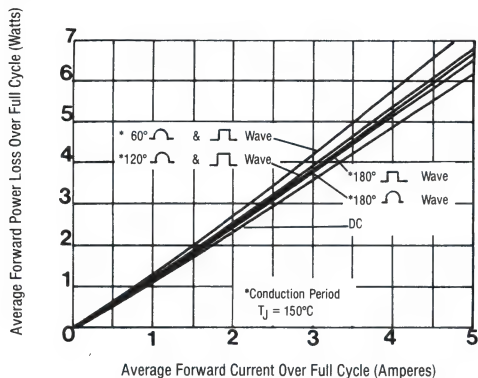


FIGURE 1
MAXIMUM LOW-LEVEL AVERAGE
FORWARD POWER LOSS VS.
AVERAGE FORWARD CURRENT

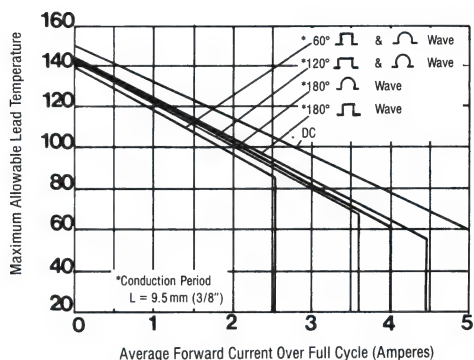


FIGURE 2
AVERAGE FORWARD CURRENT
VS. LEAD TEMPERATURE

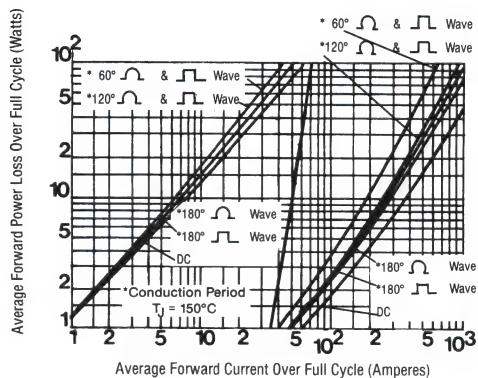


FIGURE 3
MAXIMUM HIGH-LEVEL FORWARD
POWER LOSS VS. AVERAGE
FORWARD CURRENT

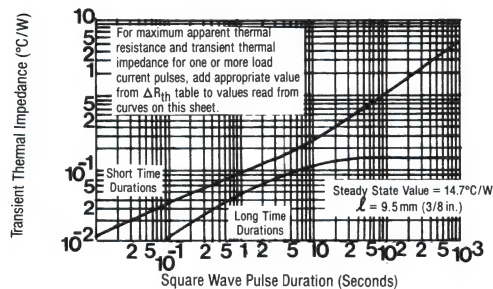


FIGURE 4
MAXIMUM TRANSIENT THERMAL
IMPEDANCE JUNCTION TO LEAD
VS. PULSE DURATION

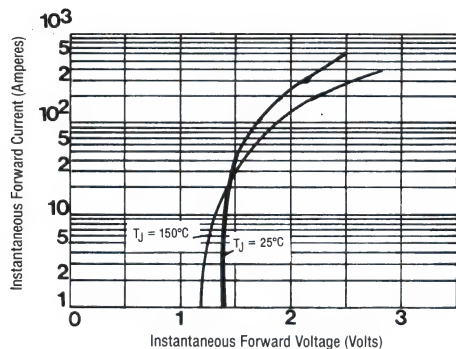


FIGURE 5
MAXIMUM FORWARD VOLTAGE
VS. FORWARD CURRENT

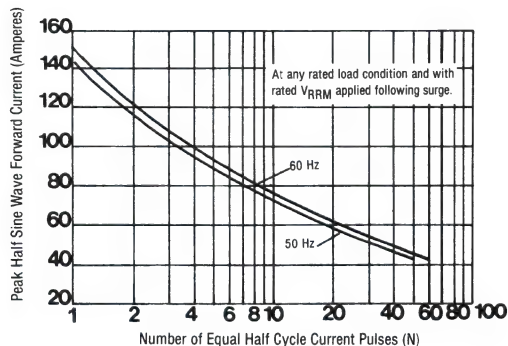


FIGURE 6
MAXIMUM NON-REPETITIVE
SURGE CURRENT VS. NUMBER
OF CURRENT PULSES

DESCRIPTION/FEATURES

- ECONOMICAL 6 AMPS AVERAGE MOLDED DEVICE OFFERS CAPABILITY OF STUD-MOUNTED RECTIFIERS
- 400 AMPS SURGE PROVIDES HIGH IN-RUSH CURRENT CAPABILITY
- WIDE VOLTAGE RANGE AVAILABLE: 50 TO 1000 VOLTS V_{RRM}

Major Ratings and Characteristics

| | 60S | |
|-----------------|------------|-------------|
| $I_F(AV)$ | 6 | A |
| @ Max. T_L | 95 | $^{\circ}C$ |
| I_{FSM} | | |
| @ 50 Hz | 382 | A |
| @ 60 Hz | 400 | |
| I^2_t | | A^2s |
| @ 50 Hz | 712 | |
| @ 60 Hz | 650 | |
| T_J | -40 to 175 | $^{\circ}C$ |
| V_{RRM} Range | 50-1000 | V |

VOLTAGE RATINGS

| Part Number | V_{RRM} Max. Repetitive Peak Reverse Voltage (V) $T_J = -40^{\circ}C$ to $200^{\circ}C$ | V_R - Max. Direct Reverse Voltage (V) $T_J = -40^{\circ}C$ to $200^{\circ}C$ |
|-------------|--|---|
| | $T_J = -40^{\circ}C$ to $200^{\circ}C$ | $T_J = -40^{\circ}C$ to $200^{\circ}C$ |
| 60S05 | 50 | 50 |
| 60S1 | 100 | 100 |
| 60S2 | 200 | 200 |
| 60S4 | 400 | 400 |
| 60S6 | 500 | 500 |
| 60S6 | 600 | 600 |
| 60S8 | 800 | 800 |
| 60S10 | 1000 | 1000 |

ELECTRICAL SPECIFICATIONS

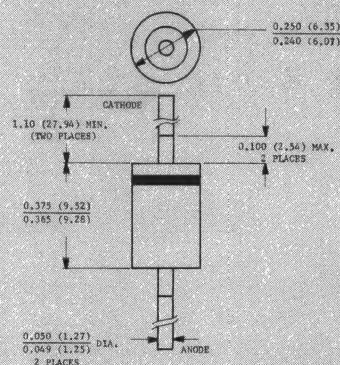
| | 60S | Units | Conditions |
|---|---------------------------|----------------|---|
| $I_F(AV)$ Max. average forward current | 6 | A | 1-phase operation, 180° conduction, $T_L = 95^{\circ}C$, $t = 9.5$ mm (0.375 in.) |
| I_{FSM} Max. peak one-cycle non-repetitive surge current | 382 400 454 475 | A | Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with rated V_{RRM} applied. Half cycle 60 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with V_{RRM} applied. Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with V_{RRM} applied following surge = 0. Half cycle 60 Hz sine wave or 6 ms rectangular pulse |
| I^2_t Max. I^2_t for fusing | 712 650 1006 919 | A^2s | $t = 10$ ms With rated V_{RRM} applied following surge, initial $T_J = 175^{\circ}C$ $t = 8.3$ ms With $V_{RRM} = 0$ following surge, initial $T_J = 175^{\circ}C$ $t = 10$ ms With $V_{RRM} = 0$ following surge, initial $T_J = 175^{\circ}C$ $t = 8.3$ ms |
| $I^2 \sqrt{t}$ Max. $I^2 \sqrt{t}$ for individual device fusing | 10330 | $A^2 \sqrt{s}$ | $t = 0.1$ to 10 ms, $V_{RRM} = 0$ following surge. |
| V_{FM} Max. peak forward voltage | 1.00 | V | $I_F(AV) = 6A$ (18.8A peak), $T_J = 25^{\circ}C$ |
| $I_R(AV)$ Max. average reverse current | 2.0 1 0.8 0.5 | mA | Max. rated $I_F(AV)$ and V_{RRM} , $T_C = 95^{\circ}C$, length of leads to the temperature measurement points (heat sinks) = 9.5 mm (0.375 in.) |

THERMAL-MECHANICAL SPECIFICATIONS

| | | | |
|--|-------------|-------------|--|
| T_J Max. operating junction temperature range | -40 to 175 | $^{\circ}C$ | |
| T_{stg} Max. storage temperature range | -40 to 175 | $^{\circ}C$ | |
| R_{thJC} Max. internal thermal resistance, junction-to-leads | - | | |
| θ Length of leads (2) (1/8") 3.2 mm | 11.0 | deg C/W | DC operation, double side cooled, measured 9.5 mm (0.375 in.) from body. |
| Length of leads (2) (3/8") 9.5 mm | 14.7 | | $\pm 10\%$ |
| Length of leads (2) (3/4") 19 mm | 20.0 | | |
| wt Approximate weight | 1.5 (0.053) | g (oz) | |

Note (1): $I^2 t$ for time $t_x = I^2 \sqrt{t} \cdot \sqrt{t_x}$

6 AMP AXIAL-LEAD SILICON RECTIFIER DIODES



All Dimensions in Inches and (Millimeters)

MECHANICAL CHARACTERISTICS

CASE: Molded plastic use Flame Retardant Epoxy.

TERMINALS: Axial leads, solderable per MIL-STD-202, Method 208.

POLARITY: Color band denotes cathode.

MOUNTING POSITION: Any.

60S Series

RATING AND CHARACTERISTIC CURVES

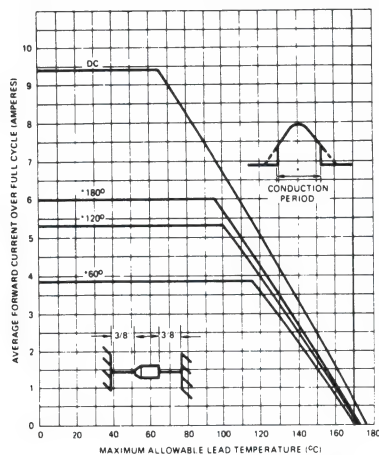


Fig. 1 — Average Forward Current Vs. Lead Temperature at Heat Sinks ($\ell = 3/8$ inch)

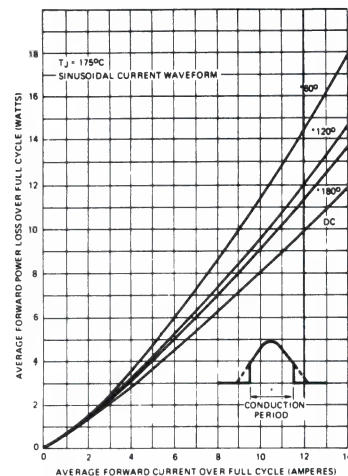


Fig. 2 — Maximum Average Forward Power Loss Vs. Low-Level Average Forward Current

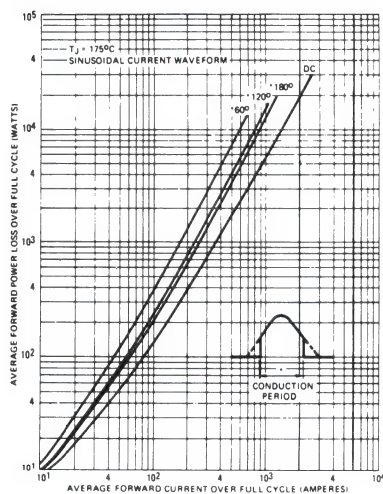


Fig. 3 — Maximum Average Forward Power Loss Vs. High-Level Forward Current

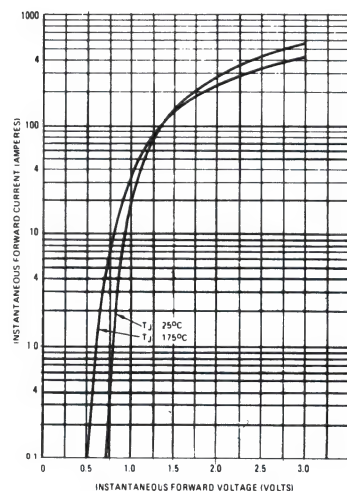


Fig. 4 — Maximum Instantaneous Forward Voltage Vs. Instantaneous Forward Current

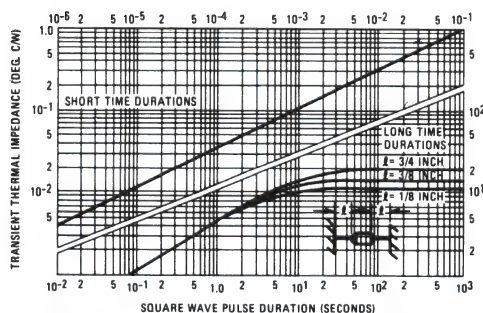


Fig. 5 — Maximum Transient Thermal Impedance, Vs. Square Wave Pulse Duration

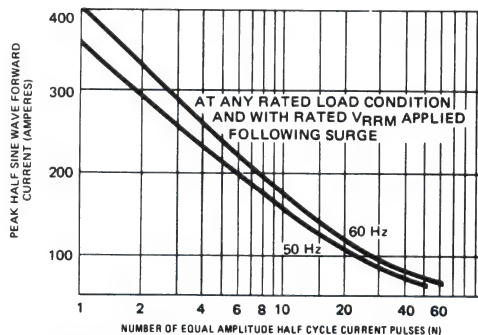


Fig. 6 — Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

MB200 thru MB206 MB207 thru MB213

FEATURES

- Microminiature package.
- Voidless hermetically sealed glass package.
- Triple layer passivation.
- Metallurgically bonded.
- Ultra fast recovery.
- PIV to 215 volts.
- Meet or exceed requirements of MIL-S-19500.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.

Storage Temperature: -65°C to $+200^{\circ}\text{C}$.

*Power Dissipation: 2 Watts @ 25°C .

*This rating applies when diodes are mounted on turret terminals
(.060" diameter x .375" minimum height) on .5" centers in free air.
With fan cooling of at least 250 linear feet per minute air velocity this
rating is 3.0 watts at 25°C .

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | BREAKDOWN VOLTAGE (MIN.) BV @ 100.μA | AVERAGE RECTIFIED CURRENT Io | FORWARD VOLTAGE DROP (MAX.) VF | REVERSE CURRENT (MAX.) IR @ PIV | | SURGE CURRENT (MAX.) (NOTE 1) IF(surge) | JUNCTION CAPACITANCE (MAX.) C @ V | | REVERSE RECOVERY TIME (MAX.) (NOTE 2) | |
|-------|---|---|---------------------------------------|--|--|-------|---|--|------|---|-------|
| | | | | | μA | | | pF | | | n sec |
| | | | | | 25°C | 100°C | | 0V | -10V | | |
| | VOLTS | VOLTS | AMPS | VOLTS | | | AMPS | | | | |
| | | | TA55°C | | | | | | | | |
| MB200 | 40 | 55 | 2.0 | 1.0V | .5 | 100 | 25 | 35 | 20 | 20 | |
| MB201 | 65 | 85 | 2.0 | @ | .5 | 100 | 25 | 35 | 20 | 20 | |
| MB202 | 90 | 110 | 2.0 | 1.667 Adc | .5 | 100 | 25 | 35 | 20 | 20 | |
| MB204 | 135 | 165 | 2.0 | (250 msec pulse) | .5 | 100 | 25 | 35 | 20 | 20 | |
| MB206 | 185 | 215 | 2.0 | | 1.5 | 200 | 25 | 35 | 20 | 20 | |
| MB207 | 40 | 55 | 2.0 | 1.0V | 1.0 | 200 | 25 | 25 | 15 | 20 | |
| MB208 | 65 | 85 | 2.0 | @ | 1.0 | 200 | 25 | 25 | 15 | 20 | |
| MB209 | 90 | 110 | 2.0 | 1.25 Adc | 1.0 | 200 | 25 | 25 | 15 | 20 | |
| MB211 | 135 | 165 | 2.0 | (250 msec pulse) | 1.0 | 200 | 25 | 25 | 15 | 20 | |
| MB213 | 185 | 215 | 2.0 | | 3.0 | 400 | 25 | 25 | 15 | 20 | |

NOTE 1: Single cycle 8.3 msec surge

NOTE 2: $I_F = 1\text{A}$, $I_R = 1.0\text{A}$, recover to .5A

RECTIFIERS

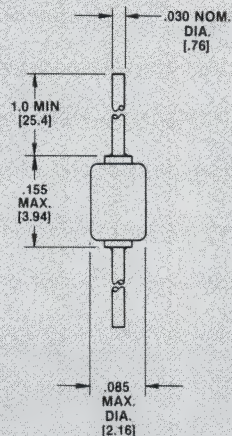


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed hard glass.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

MB200 thru MB206
MB207 thru MB213

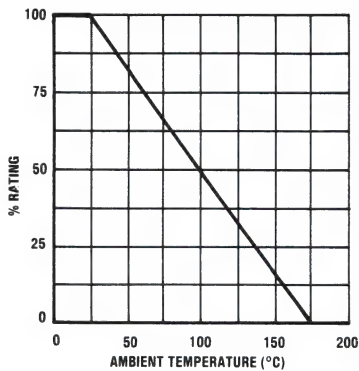


FIGURE 2
TEMPERATURE
DERATING CURVE

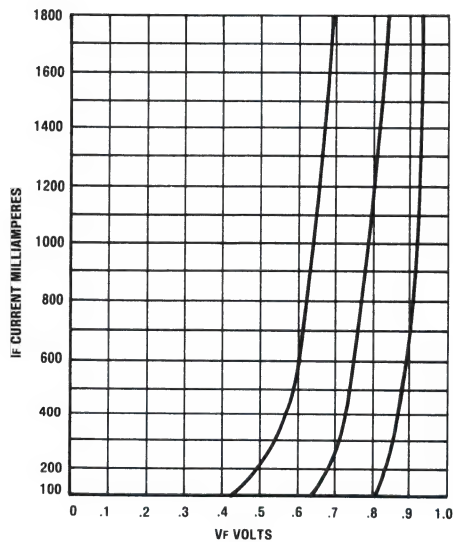


FIGURE 3
FORWARD CONDUCTANCE CURVE**

****Special band spread requirements can be supplied upon request.**

FEATURES

- Microminiature package.
- Standard recovery.
- Hermetically sealed glass package.
- Stable surface films integrally bonded to the device crystal.
- Meet or exceed requirements of MIL-S-19500.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.

Storage Temperature: 175°C .

Power Dissipation: 300 mW @ 25°C Au plated silver leads.
250 mW @ 25°C Au plated kovar leads

ELECTRICAL CHARACTERISTICS

| TYPE | BREAKDOWN VOLTAGE (MIN.) @ 100 μA B_V | FORWARD CURRENT (MIN.) @ 1.0 V I_F | REVERSE CURRENT (MAX.) I_R @ V_R | | TEST VOLTAGE V_R | AVERAGE RECTIFIED CURRENT I_o |
|--------|--|--|---|-----------------------|-----------------------|------------------------------------|
| | VOLTS | mA | μA | | VOLTS | mA |
| | | | 25°C | 150°C | | |
| MC456A | 30 | 100 | 0.025 | 5.0 | -25V | 150 |
| MC457A | 70 | 100 | 0.025 | 5.0 | -60V | 150 |
| MC458A | 150 | 100 | 0.025 | 5.0 | -125V | 150 |
| MC459A | 200 | 100 | 0.025 | 5.0 | -175V | 150 |
| MC461A | 30 | 100 | 0.5 | 30.0 | -25V | 150 |
| MC462A | 70 | 100 | 0.5 | 30.0 | -60V | 150 |
| MC463A | 200 | 100 | 0.5 | 30.0 | -175V | 150 |
| MC464A | 150 | 100 | 0.5 | 30.0 | -125V | 150 |
| MC482B | 40 | 100 | 0.025 | 5.0 | -30V | 150 |
| MC483B | 80 | 100 | 0.025 | 5.0 | -60V | 150 |
| MC484B | 150 | 100 | 0.025 | 5.0 | -125V | 150 |
| MC485B | 200 | 100 | 0.025 | 5.0 | -175V | 150 |
| MC486B | 250 | 100 | 0.025 | 5.0 | -225V | 150 |

NOTES:

- Power Dissipation: 300 mw @ 25°C .
- Operating Temperature Range: @ -65°C to $+175^{\circ}\text{C}$.
- Storage Temperature: 200°C .

MICRO-DIODES

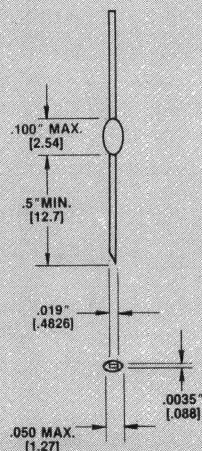


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Ultra stable epoxy encapsulation.

LEAD MATERIAL: Gold plated kovar or gold plated silver.

MARKING: EIA color code bands.

POLARITY: Color bands on cathode leads.

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

MC5600 - MC5607

FEATURES

- METALLURGICALLY BONDED, HERMETICALLY SEALED
- MONOLITHIC VOIDLESS CONSTRUCTION
- LOWEST REVERSE LEAKAGE
- SMALL PACKAGE SIZE
- LOWEST THERMAL RESISTANCE
- MAXIMUM BREAKDOWN VOLTAGE PER DIE
- ABSOLUTE HIGH VOLTAGE / HIGH TEMPERATURE STABILITY

OPERATING TEMPERATURE

MC5600-MC5603: -65°C to +150°C
(derate I_0 : 4 mA/°C above 25°C)

MC5604-MC5607: -65°C to +125°C
(derate I_0 : 2.5 mA/°C above 25°C)

Storage Temperature (MC5600-MC5607):
-65°C to +175°C

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK INVERSE VOLTAGE (MIN.) PIV | AVERAGE RECTIFIED CURRENT I_0 | | FORWARD VOLTAGE (MAX.) $V_F @ 100\text{mA}$ | REVERSE CURRENT (MAX.) $I_R @ \text{PIV}$ | REVERSE CURRENT (MAX.) $I_R @ \text{PIV}$ | SURGE CURRENT (MAX.) |
|---------|---|--|-------|--|--|--|----------------------------|
| | VOLTS | mA | | VOLTS | μA | μA | AMPS |
| | | 25°C | 100°C | | | 100°C | |
| MC 5600 | 1500 | 500 | 200 | 2.0 | 1.0 | 20 | 10 |
| MC 5601 | 2000 | 500 | 200 | 3.0 | 1.0 | 20 | 8 |
| MC 5602 | 2500 | 500 | 200 | 4.0 | 1.0 | 20 | 6 |
| MC 5603 | 3000 | 500 | 200 | 5.0 | 1.0 | 20 | 5 |
| MC 5604 | 4000 | 250 | 60 | 6.0 | 1.0 | 20 | 4 |
| MC 5605 | 5000 | 250 | 60 | 7.0 | 1.0 | 20 | 3.0 |
| MC 5606 | 7500 | 250 | 60 | 9.0 | 1.0 | 20 | 2.7 |
| MC 5607 | 10,000 | 250 | 60 | 10.0 | 1.0 | 20 | 2.5 |

MICRO SIZE HIGH VOLTAGE SILICON RECTIFIERS

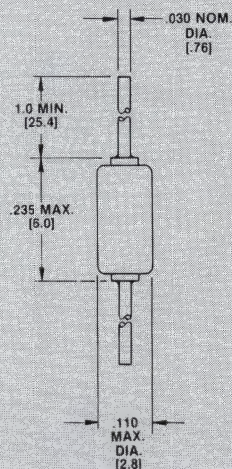


FIGURE 1

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass package.

LEAD MATERIAL: Tinned copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

MC5610 thru MC5619

FEATURES

- Monolithic voidless construction.
- Triple layer passivation.
- Lowest reverse leakage.
- Smallest package available.
- Lowest thermal resistance.
- Maximum breakdown voltage per die.
- Absolute high voltage/high temperature stability.

DESCRIPTION

The MC5610 through MC5619 series of high power silicon rectifiers feature the smallest packages available. Metallurgically bonded and hermetically sealed, they exceed all requirements of aerospace and military specifications, including MIL-S-19500. Typical applications include transmitters, power supplies, radar equipment and X-ray machines.

ELECTRICAL CHARACTERISTICS

| TYPE NO. | PEAK INVERSE VOLTAGE | RMS VOLTAGE | DC BLOCKING VOLTAGE | NOTE 2. AVERAGE RECTIFIED CURRENT @ $T_L =$ | | Max. Static FORWARD VOLTAGE @ 100mA | Max. Static REVERSE CURRENT @ PIV | Max. Static REVERSE CURRENT @ PIV | ONE CYCLE SURGE | t_{rr} 1/ |
|----------|----------------------|-------------|---------------------|---|-------|-------------------------------------|-----------------------------------|-----------------------------------|-----------------|----------------|
| | | | | 55°C | 100°C | | | | | |
| | VOLTS | VOLTS | VOLTS | mA | mA | VOLTS | μA | μA | AMPS | n SEC |
| MC 5610 | 1500 | 1050 | 1500 | 790 | 415 | 3.0 | 1.0 | 25 | 8 | 300 |
| MC 5611 | 2000 | 1400 | 2000 | 630 | 330 | 4.0 | 1.0 | 25 | 6 | 300 |
| MC 5612 | 2500 | 1750 | 2500 | 530 | 280 | 5.0 | 1.0 | 25 | 5 | 300 |
| MC 5613 | 1500 | 1050 | 1500 | 975 | 515 | 3.0 | 1.0 | 20 | 8 | 300 |
| MC 5614 | 2000 | 1400 | 2000 | 790 | 415 | 4.0 | 1.0 | 20 | 6 | 300 |
| MC 5615 | 2500 | 1750 | 2500 | 665 | 350 | 5.0 | 1.0 | 20 | 5 | 300 |
| MC 5616 | 3000 | 2100 | 3000 | 570 | 300 | 6.0 | 1.0 | 20 | 4 | 300 |
| MC 5617 | 4000 | 2800 | 4000 | 330 | 120 | 8.0 | 2.5 | 50 | 3 | 300 |
| MC 5618 | 4500 | 3150 | 4500 | 300 | 110 | 9.0 | 2.5 | 50 | 2.7 | 300 |
| MC 5619 | 5000 | 3500 | 5000 | 275 | 100 | 10.0 | 2.5 | 50 | 2.5 | 300 |

NOTE 1: $I_F = 50$ mA, $I_R = 100$ mA, $I_{RR} = 25$ mA

NOTE 2: Heat sink $\frac{3}{8}$ " from body

MECHANICAL CHARACTERISTICS

Tinned copper leads. Refer to Figure 1

Positive terminal (cathode) marked with band.

Operating temperature range:

MC5610-MC5612. -55°C to 150°C

MC5613-MC5616. -65°C to 150°C

MC5617-MC5619. -65°C to 125°C

Storage temperature range (MC5610-MC5619). -65°C to 175°C

FAST RECOVERY HIGH POWER MICRO HIGH VOLTAGE RECTIFIERS

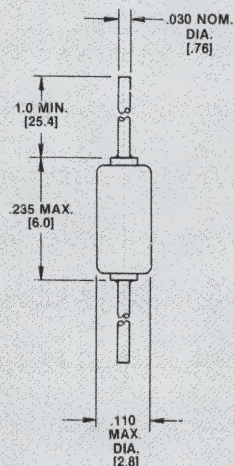


FIGURE 1

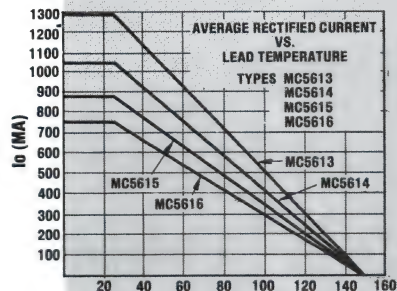


FIGURE 2
LEAD TEMPERATURE (°C)
(L = $\frac{3}{8}$ INCH)

MR1001 thru MR1007

FEATURES

- Low cost.
- High current capability.
- Low leakage.
- Low forward voltage.
- High surge capability.
- JEDEC DO-41 molded plastic case.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.
Storage Temperature: -65°C to $+175^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK REVERSE VOLTAGE | MAX. RMS VOLTAGE | MAX. DC BLOCKING VOLTAGE | MAX. AVERAGE FORWARD RECTIFIED CURRENT | PEAK FORWARD SURGE CURRENT I_F (SURGE) | MAX. FORWARD VOLTAGE @ 1A DC | MAX. DC REVERSE CURRENT @ RATED DC BLOCKING VOLTAGE | TYPICAL JUNCTION CAPACITANCE @ $V_R = 4V$ | MAX. REVERSE RECOVERY TIME t_{rr} |
|--------|----------------------------|------------------------|--------------------------------|--|--|---------------------------------------|--|--|--|
| | V | V | V | A | A | V | μA | pF | ns |
| MR1001 | 50 | 35 | 50 | 1.0 | 30 | 1.2 | 5.0 | 15 | 200 |
| MR1002 | 100 | 70 | 100 | 1.0 | 30 | 1.2 | 5.0 | 15 | 200 |
| MR1003 | 200 | 140 | 200 | 1.0 | 30 | 1.2 | 5.0 | 15 | 200 |
| MR1004 | 400 | 280 | 400 | 1.0 | 30 | 1.2 | 5.0 | 15 | 200 |
| MR1005 | 600 | 420 | 600 | 1.0 | 30 | 1.2 | 5.0 | 15 | 250 |
| MR1006 | 800 | 560 | 800 | 1.0 | 30 | 1.2 | 5.0 | 15 | 500 |
| MR1007 | 1000 | 700 | 1000 | 1.0 | 30 | 1.2 | 5.0 | 15 | 500 |

NOTE 1: Ratings at 25°C ambient temperature unless otherwise specified.

NOTE 2: Special fast recovery rectifiers also available.

NOTE 3: Reverse recovery test conditions:
 $I_F = 0.5A$, $I_{RM}(\text{REC}) = 1.0A$, and $i_R(\text{REC}) = 0.25A$

1A FAST RECOVERY RECTIFIERS

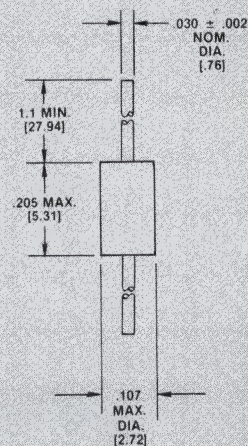


FIGURE 1

All dimensions in $\frac{\text{INCH}}{\text{m. m.}}$

MECHANICAL CHARACTERISTICS

CASE: Molded plastic.

LEAD MATERIAL: Copper,
plated tin.

MARKING: Body painted, alpha
numeric.

POLARITY: Cathode band.

MR1001 thru MR1007

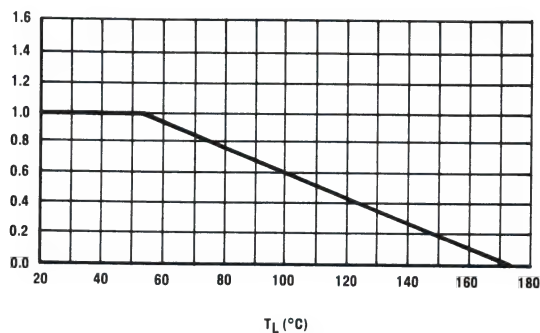


FIGURE 2
FORWARD CURRENT DERATING CURVE

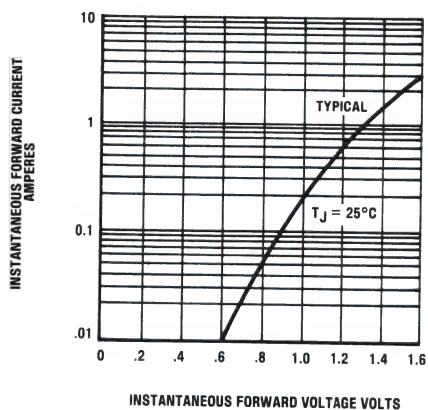


FIGURE 3
TYPICAL FORWARD VOLTAGE DROP Vs.
OUTPUT CURRENT (INSTANTANEOUS).

MR3001 thru MR3007

FEATURES

- Low cost.
- High current capability.
- Low leakage.
- Low forward voltage.
- High surge capability.
- JEDEC DO-27 molded plastic case.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.
 Storage Temperature: -65°C to $+175^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

| TYPE | PEAK REVERSE VOLTAGE | MAX. RMS VOLTAGE | MAX. DC BLOCKING VOLTAGE | MAX. AVERAGE FORWARD RECTIFIED CURRENT | PEAK FORWARD SURGE CURRENT I_F (SURGE) | MAX. FORWARD VOLTAGE @ 1 A DC | MAX. DC REVERSE CURRENT @ RATED DC BLOCKING VOLTAGE | TYPICAL JUNCTION CAPACITANCE @ $V_R = 4\text{V}$ | MAX. REVERSE RECOVERY TIME t_{rr} |
|--------|----------------------------|------------------------|--------------------------------|--|--|--|--|---|---|
| | V | V | V | A | A | V | μA | pF | ns |
| MR3001 | 50 | 35 | 50 | 3.0 | 200 | 1.2 | 10 | 60 | 200 |
| MR3002 | 100 | 70 | 100 | 3.0 | 200 | 1.2 | 10 | 60 | 200 |
| MR3003 | 200 | 140 | 200 | 3.0 | 200 | 1.2 | 10 | 60 | 200 |
| MR3004 | 400 | 280 | 400 | 3.0 | 200 | 1.2 | 10 | 60 | 200 |
| MR3005 | 600 | 420 | 600 | 3.0 | 200 | 1.2 | 10 | 60 | 250 |
| MR3006 | 800 | 560 | 800 | 3.0 | 200 | 1.2 | 10 | 60 | 500 |
| MR3007 | 1000 | 700 | 1000 | 3.0 | 200 | 1.2 | 10 | 60 | 500 |

NOTE 1: Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60Hz resistive or inductive load.
 For capacitive load, derate current by 20%.

NOTE 2: Special fast recovery rectifiers also available.

NOTE 3: Reverse recovery test conditions:
 $I_F = 0.5\text{A}$, $I_{RM}(\text{REC}) = 1.0\text{A}$, and $I_R(\text{REC}) = 0.25\text{A}$

3A FAST RECOVERY RECTIFIERS

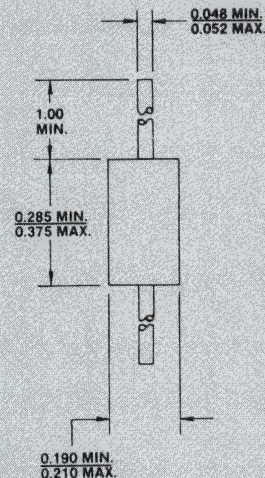


FIGURE 1

ALL DIMENSIONS IN INCHES.

MECHANICAL CHARACTERISTICS

CASE: Molded plastic.
 LEAD MATERIAL: Copper, plated tin.
 MARKING: Body painted, alpha numeric.
 POLARITY: Cathode band.

MR3001 thru MR3007

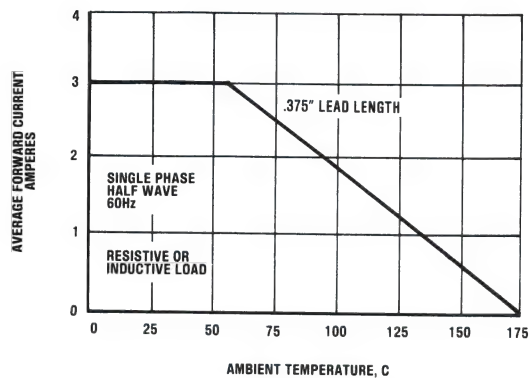


FIGURE 2
FORWARD DERATING CURVE

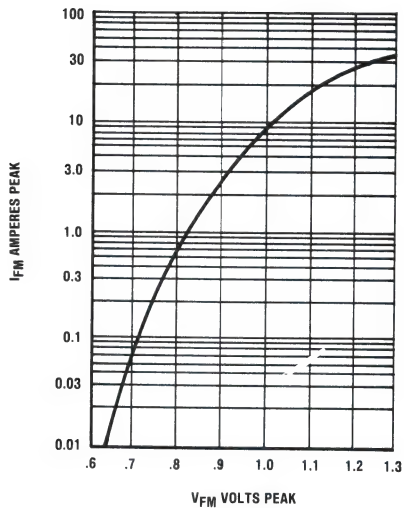


FIGURE 3
TYPICAL INSTANTANEOUS
FORWARD CHARACTERISTICS

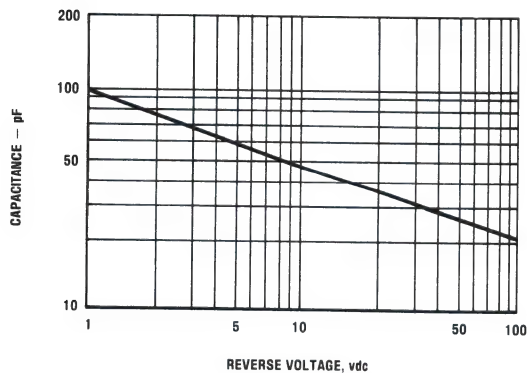


FIGURE 4
TYPICAL JUNCTION CAPACITANCE
vs REVERSE VOLTAGE

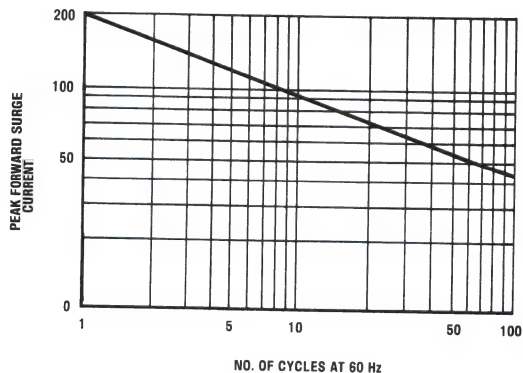


FIGURE 5
MAXIMUM NON REPETITIVE SURGE CURRENT

MSB05 MSB1, MSB2, MSB4, MSB6, MSB8, MSB10

FEATURES

- DUAL IN-LINE SUBMINIATURE PACKAGE (DIP)
- MACHINE INSERTABLE
- MOLDED EPOXY PACKAGE
- LOW COST
- UTILIZES HIGH QUALITY GLASS PASSIVATED DICE FOR IMPROVED RELIABILITY
- HIGH SURGE CAPABILITY — 50 A (SINGLE CYCLE)
- BREAKDOWN VOLTAGES TO 1000 V

MAXIMUM RATINGS

Operating Temperature: -55°C to +125°C

Storage Temperature: -55°C to +150°C

ELECTRICAL CHARACTERISTICS

| TYPE | WKG. PK. REV. D.C. VOLTS $V_{RWM} \& V_R$ 1/ | Max. RMS INPUT VOLTAGE V_{rms} 2/ | Max. TRANSIENT RATED PK. VOLTAGE TRV 1/ | AVG. OUTPUT CURRENT RES./IND. LOAD I_{out}/I_{AV} @ $T_A = 40^\circ C$ | MAX. SINGLE CYCLE SURGE CURRENT I_{surge} 1/ | MAX. PK. FORWARD VOLTAGE V_{FM} @ $T_A = 25^\circ C$ & $I_{FM} =$ 1.0A PK. 1/ VOLTS | MAX. D.C. REV. CURRENT I_R 1/ @ RATED V_R μAmps $T_A = 25^\circ C$ $T_A = 150^\circ C$ |
|-------|---|---|---|--|---|--|--|
| MSB05 | 50 | 35 | 100 | 1.0 | 50 | 1.1 | 3.0 500 |
| MSB1 | 100 | 70 | 150 | 1.0 | 50 | 1.1 | 3.0 500 |
| MSB2 | 200 | 140 | 300 | 1.0 | 50 | 1.1 | 3.0 500 |
| MSB4 | 400 | 280 | 500 | 1.0 | 50 | 1.1 | 3.0 500 |
| MSB6 | 600 | 420 | 700 | 1.0 | 50 | 1.1 | 3.0 500 |
| MSB8 | 800 | 560 | 900 | 1.0 | 50 | 1.1 | 3.0 500 |
| MSB10 | 1000 | 700 | 1100 | 1.0 | 50 | 1.1 | 3.0 500 |

NOTE: 1. Per rectifier element

2. At a power line frequency of 50/60 hertz

DIP BRIDGE RECTIFIERS

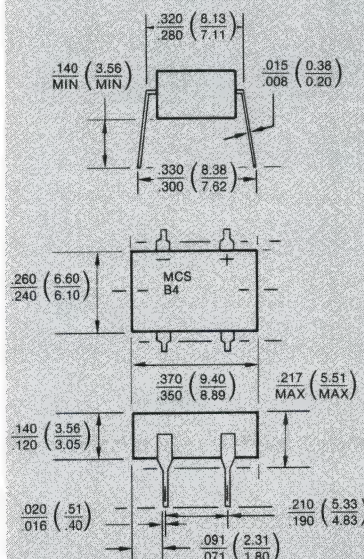


FIGURE 1

All Dimensions in INCHES and (m.m.)

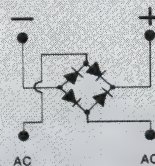
MECHANICAL CHARACTERISTICS

CASE: Molded epoxy.

LEAD MATERIAL: Copper plated tin, solderable per MIL-STD-202, Method 208.

MARKING: Body painted, alpha numeric.

POLARITY: Reference mark.



MSB05, MSB1, MSB2, MSB4, MSB6, MSB8, MSB10

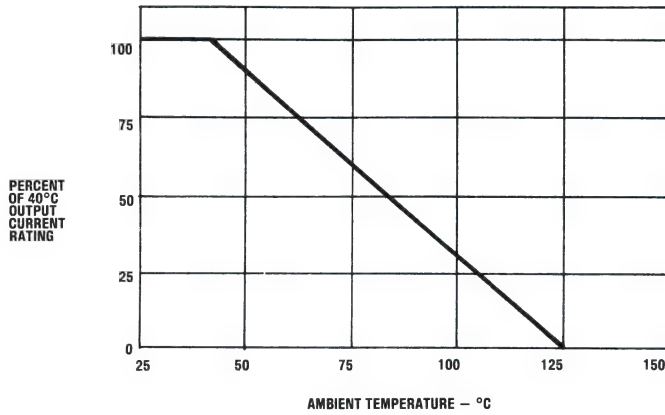


FIGURE 2
OUTPUT CURRENT DERATING SCHEDULE

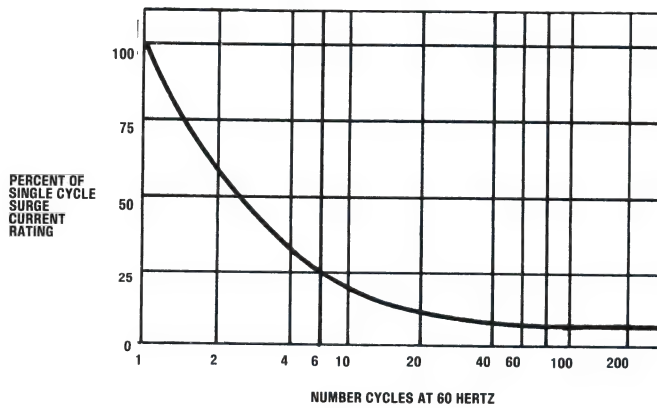


FIGURE 3
FORWARD SURGE CURRENT SCHEDULE
(PER ELEMENT; -55°C to +150°C)



Microsemi Corp.

The diode experts

SANTA ANA, CA

For more information call:
(714) 979-8220

SCOTTSDALE, AZ

**MT5100-MT5103
MT5139, MT5140,
MT2060, MT2060A
MT2061, MT2061A**

FEATURES

- Exhibits leakage currents approaching the theoretical bulk characteristics of silicon.
- Oxide and glass junctions passivated for long-term stable device performance.
- Voidless hermetically sealed glass package.
- Exceeds MIL-S-19500 requirements.

MAXIMUM RATINGS

Storage Temperature: -65°C to $+200^{\circ}\text{C}$.
Operating Temperature: -65°C to $+200^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS

| TYPE NUMBER | MIN. BV @ 100 μA @ 25°C VOLTS | V _r VOLTS | MAX. I _r @ V _r @ 25°C PICO AMPS | MAX. I _r @ V _r @ 150°C NANO AMPS | MAX. I _r @ V _r @ 200°C MICRO AMPS | I _f @ 1.2V MA | MAX. Cap. @ 0V PF | MAX. Cap. @ 10V PF | Pkg. |
|----------------|---|-------------------------|--|---|--|--------------------------------|----------------------------|-----------------------------|------|
| MT 5100 | 75 | 20 | 10 | 50 | 1 | 100 | 6 | 3 | B |
| MT 5101 | 75 | 20 | 20 | 100 | 2 | 100 | 6 | 3 | B |
| MT 5102 | 75 | 20 | 10 | 50 | 1 | 80 | 6 | 3 | B |
| MT 5103 | 75 | 20 | 20 | 100 | 2 | 80 | 6 | 3 | B |
| MT 5139 | 60 | 50 | 50 | 75 | 1 | 100 | 6 | 3 | B |
| MT 5140 | 110 | 100 | 125 | 125 | 2 | 100 | 6 | 3 | B |
| MT 2060 | 600 | 500 | 2000 | 6000 | 40 | 400 | 10 | 5 | B |
| MT 2060A | 600 | 500 | 2000 | 6000 | 40 | 400 | 16 | 8 | A |
| MT 2061 | 600 | 500 | 1000 | 3000 | 20 | 400 | 10 | 5 | B |
| MT 2061A | 600 | 500 | 1000 | 3000 | 20 | 400 | 16 | 8 | A |

MECHANICAL CHARACTERISTICS

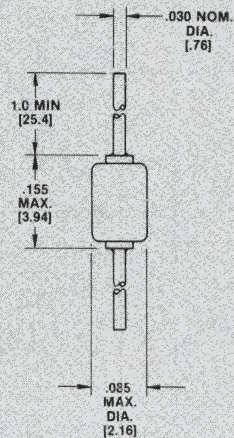
Case: Hermetically sealed glass case.

Lead Material: Tinned copper. (A package) (Copper Clad Steel — B package)

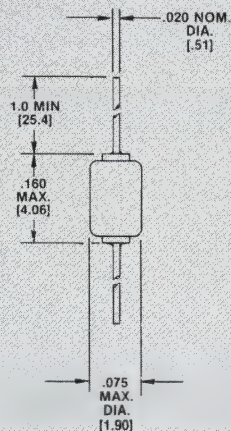
Marking: Body painted, alpha numeric.

Polarity: Cathode band.

PICO AMP LOW LEAKAGE DIODES



PACKAGE "A"



PACKAGE "B"

MT5100 - MT5103
MT5139, MT5140,
MT2060, MT2060A
MT2061, MT2061A

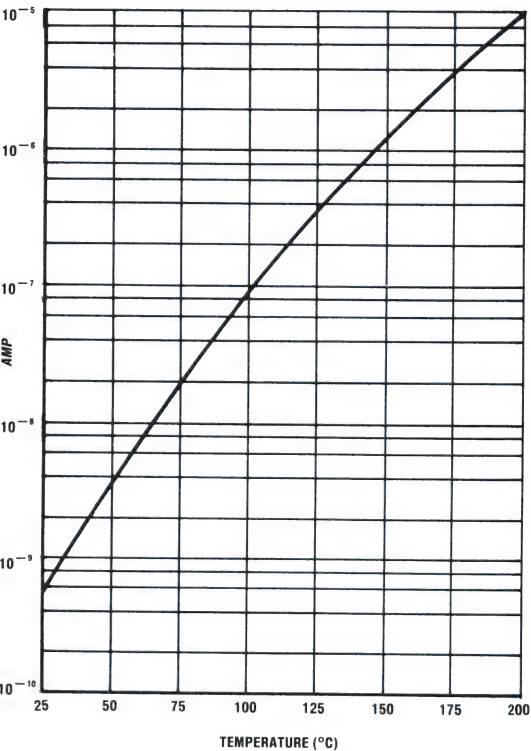


FIGURE 2
MAXIMUM I_r LIMIT @ 500V CURVE
(MT 2060, MT 2060A, MT 2061, MT 2061A)

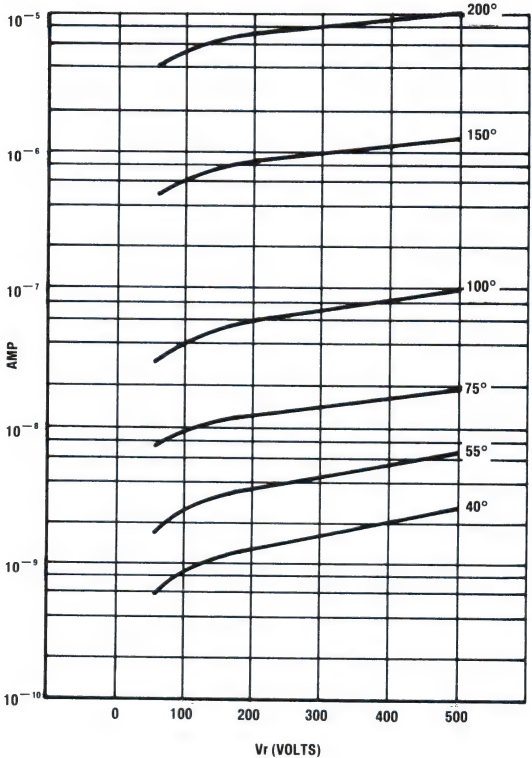


FIGURE 3
MAXIMUM I_r CURVES
(as applicable to maximum V_R)

GUIDE TO SELECTING A TRANSIENT ABSORPTION ZENER BY POWER RATING

| PART NUMBER SERIES | LOW TO 600W RATED STAND OFF VOLTAGE | | MEDIUM TO 1500W RATED STAND OFF VOLTAGE | | HIGH TO 15000W+ RATED STAND OFF VOLTAGE | |
|----------------------------|---|-------------|---|--------------|---|--------|
| | MIN. | MAX.** | MIN. | MAX.** | MIN. | MAX.** |
| TS-7 | | 5.0 230W | | | | |
| P5KE5.0 thru P5KE170 | 5.0 | 500W | | | | 170 |
| SOV5.0 thru SOV28 | 5.0 | 500W | | | | 28 |
| GMP-5 | | 5.0 500W | | | | |
| DLTS-5 thru DLTS-30 | 5.0 | 500W | | | | 30 |
| 1N6102 thru 1N6137 | 5.2 | 500W | | | | 152 |
| 1N6102 thru 1N6102A | 5.2 | 500W | | | | 152 |
| 1N6461 thru 1N6468 | 5.0 | 500W | | | | 51.6 |
| P6KE6.8 thru P6KE200A | 5.0 | 600W | | | | 200 |
| P7KE10 thru P7KE100 | | | 10 | 700W | | 100 |
| 1.0KE5 thru 1.0KE170A | | | 5.0 | 1000W | | 170 |
| 1.2KE5 thru 1.2KE170A | | | 5.0 | 1200W | | 170 |
| 1.5KE6.8 thru 1.5KE200A | | | 5.5 | 1500W | | 171 |
| 1N5555 thru 1N5558* | | | 30.5 | 1500W | | 175 |
| 1N5629 thru 1N5665* | | | 5.5 | 1500W | | 171 |
| 1N5907 and 1N5908* | | | | 5.0 1500W | | |
| 1N6036 thru 1N6072A* | | | 5.5 | 1500W | | 185 |
| 1N6138 thru 1N6137* | | | 5.2 | 1500W | | 152 |
| 1N6138A thru 1N6173A | | | 5.2 | 1500W | | 152 |
| 1N6267 thru 1N6030A | | | 5.5 | 1500W | | 171 |
| 1N6356 thru 1N6372 | | | 5.0 | 1500W | | 45 |
| 1N6373 thru 1N6389 | | | 5.0 | 1500W | | 45 |
| 1N6469 thru 1N6476 | | | 5.0 | 1500W | | 51.6 |
| ICT-5 thru ICT-45C | | | 5.0 | 1500W | | 45 |
| ICTE-5 thru ICTE-45C | | | 5.0 | 1500W | | 45 |
| LC6.5 thru LC170A | | | 6.5 | 1500W | | 170 |
| LCE6.5 thru LCE170A | | | 6.5 | 1500W | | 170 |
| MPT-5 thru MPT-45C | | | 5.0 | 1500W | | 45 |
| MPTE-5 thru MPTE-45 | | | 5.0 | 1500W | | 45 |

* Available in JAN, JANTX, JANTXV PER MIL-S-19500 ** Consult factory for higher stand off voltages.

GUIDE TO SELECTING A TRANSIENT ABSORPTION ZENER BY POWER RATING

| PART NUMBER SERIES | LOW TO 600W RATED | | MEDIUM TO 1500W RATED | | HIGH TO 15000W+ RATED | |
|------------------------------|----------------------|--------|--------------------------|--------|--------------------------|--------|
| | STAND OFF VOLTAGE | | STAND OFF VOLTAGE | | STAND OFF VOLTAGE | |
| | MIN. | MAX.** | MIN. | MAX.** | MIN. | MAX.** |
| LDTS 14 thru LDTS 30A | | | | | 14 | 30 |
| 5KP5.0 thru 5KP110A | | | | | 3000W | 110 |
| PHP8.4 thru PHP30 | | | | | 5.0 | 5000W |
| PIP8.4 thru PJP30 | | | | | 12.0 | 7500W |
| PHP60 thru PHP500 | | | | | 12.0 | 42.5 |
| PIP60 thru PIP500 | | | | | 7500W | 42.5 |
| 704-15K36 thru 704-15K367 | | | | | 85 | 708 |
| 60KS 200C | | | | | 15000W | 708 |
| | | | | | 85 | 15000W |
| | | | | | 31.5 | 15000W |
| | | | | | 180 | 60000W |

*Available in JAN, JANTX, JANTXV PER MIL-S-19500

**Consult factory for higher stand off voltages.

FEATURES

- PROTECTS CIRCUITS FROM HARMFUL TRANSIENTS
- ABSORBS TRANSIENTS UP TO 1500 WATTS FOR 1MSEC.
- CLAMPING RESPONSE TIME OF 1 PICO SECOND
- 1 WATT CONTINUOUS POWER DISSIPATION
- WORKING VOLTAGE RANGE FROM 30.5 V TO 175 V
- HERMETIC SEALED DO-13 METAL PACKAGE
- JAN/TX/TXV AVAILABLE PER MIL-S-19500/434

DESCRIPTION

Transient Absorption Zeners are PN silicon junction zeners. Unlike the voltage regulation characteristics of a zener diode, the TAZ is designed for transient voltage suppression. Due to the TAZ's fast response time, protection level, and high discharge capability, its application area is very wide for protection against induced lighting, inductive and switching type transients, and can protect any kind of transient sensitive component/equipment, i.e., integrated circuits including secondary protection device in connection with SVP's in telecommunication applications. The use of TAZ devices in airborne avionics and electrical systems has proven to be highly effective.

MAXIMUM RATINGS

1500 Watts for 1mS at Lead Temperature (TZ) 25°C (See Derating Curves Figs. 1-4)

Operating and Storage Temperatures: -65° to +175°C

D.C. Power Dissipation: 1 Watt at TZ = +25°C 3/8" from body

Forward Surge Rating: 200 Amps for 8.3 mS at T_A = +25°C Duty Cycle of 4 pulses per minute maximum.

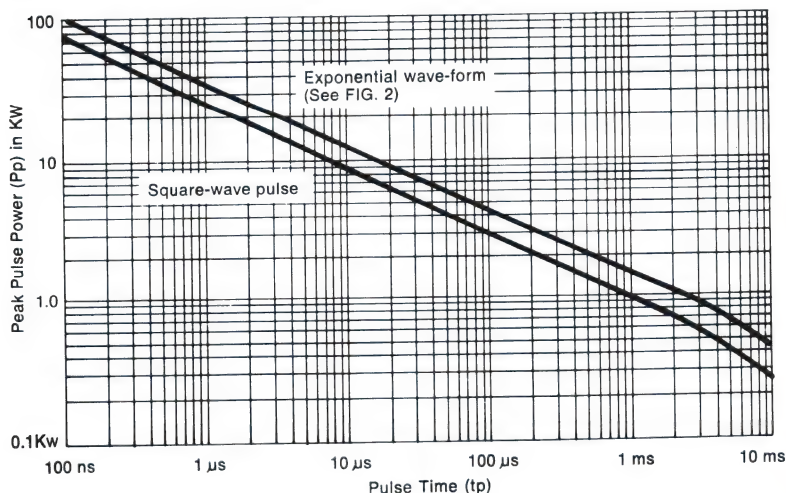
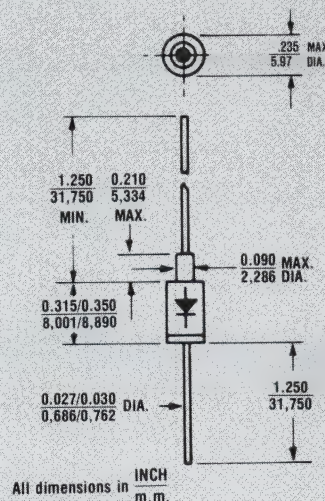


FIG. 1. Non-repetitive peak pulse power rating curve

Note: Peak power defined as peak voltage times peak current

TRANSIENT ABSORPTION ZENER



All dimensions in INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: DO-13, welded, hermetically sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 100°C/W (Typical) junction to ambient.

POLARITY: Cathode connected to case and marked.

WEIGHT: 1.4 grams.

MOUNTING POSITION: Any.

1N5555, 1N5556, 1N5557, 1N5558

ELECTRICAL CHARACTERISTICS

| Jedec Type No. | Minimum Breakdown Voltage V_{BR} at I_T | Test Current (I_T) | Rated Standoff Voltage (V_{WM}) | Maximum (RMS) Reverse Voltage V_{rwm} | Maximum Reverse Leakage Current (I_D) at V_{WM} | Maximum Peak Reverse Voltage (V_C Max.) at I_{pp} | Maximum Reverse Surge Current (I_{pp}) | Maximum Temperature Coefficient of $V_{(BR)}$ α_{VZ} (T_A) -55°C to 100°C at 1.0 mAdc |
|----------------|---|------------------------|-------------------------------------|---|---|--|--|--|
| | Vdc | mAdc | Vdc | V_{rms} | μ Adc | V | A | %/°C |
| 1N5555 | 33.0 | 1.0 | 30.5 | 21.5 | 5 | 47.5 | 32 | + .093 |
| 1N5556 | 43.7 | 1.0 | 40.3 | 28.5 | 5 | 63.5 | 24 | + .094 |
| 1N5557 | 54.0 | 1.0 | 49.3 | 34.5 | 5 | 78.5 | 19 | + .096 |
| 1N5558 | 191.0 | 1.0 | 175.0 | 124.0 | 5 | 265.0 | 5.7 | + .100 |

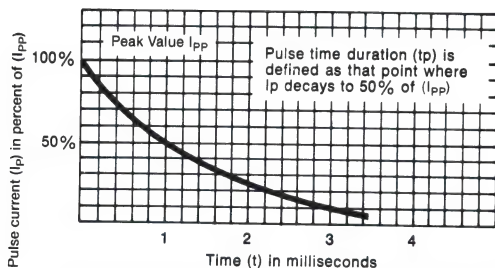


FIG. 2. Pulse wave form for exponential surge

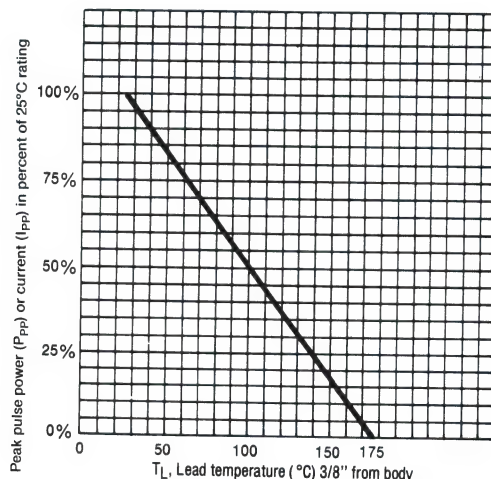


FIG. 3. Derating curve

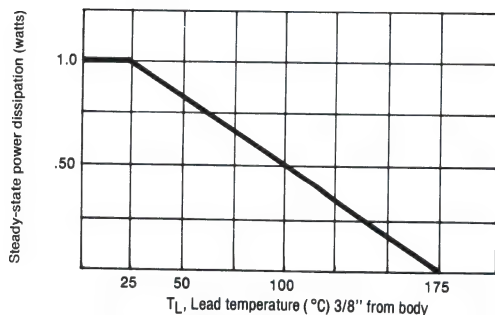


FIG. 4. Steady-state power derating curve

ABBREVIATIONS AND SYMBOLS

V_{WM} Stand Off Voltage: Applied Reverse Voltage to assure a nonconductive condition. (See Note 1.) $V_{(BR)}$ This is the minimum Breakdown Voltage the device will exhibit and is used to assure that conduction does not occur prior to this voltage level at 25°C.

V_C Maximum Clamping Voltage. The maximum peak voltage appearing across the TAZ when subjected to the peak pulse current in a one millisecond time interval. The peak pulse voltages are the combi-

nation of voltage rise due to both the series resistance and thermal rise.

I_{pp} — Peak Pulse Current— See Figure 2.

P_{pp} — Peak Pulse Power

I_D — Reverse Leakage

I_T — Current that $V_{(BR)}$ is measured at.

Note 1:

A TAZ is normally selected according to the reverse "Stand Off Voltage" (V_{WM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

micro

Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

**1N5629
thru
1N5665**

FEATURES

- PROTECTS CIRCUITS FROM HARMFUL TRANSIENTS
- ABSORBS 1 MS TRANSIENTS UP TO 1500 WATTS
- CLAMPS TRANSIENT IN 1 PICO SEC
- 1 WATT CONTINUOUS POWER DISSIPATION
- WORKING VOLTAGE RANGE 5V TO 171V
- HERMETIC DO-13 METAL PACKAGE
- JAN/TX/TXV AVAILABLE PER MIL-S-19500/500

MAXIMUM RATINGS

1500 watts for 1 ms at lead temp (T_A) 25°C

See rating curves Figs. 1 thru 4

Operating and storage temp -65° to 175°C

DC power dissipation 1 watt at $T_A = 25^{\circ}\text{C}$, $3/8"$ from body.

Derate at $6.67 \text{ mW}/^{\circ}\text{C}$

Forward surge current 200 amps for 8.3 ms at $T_A = 25^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

See following table

No suffix 10% tolerance

Suffix A 5% tolerance

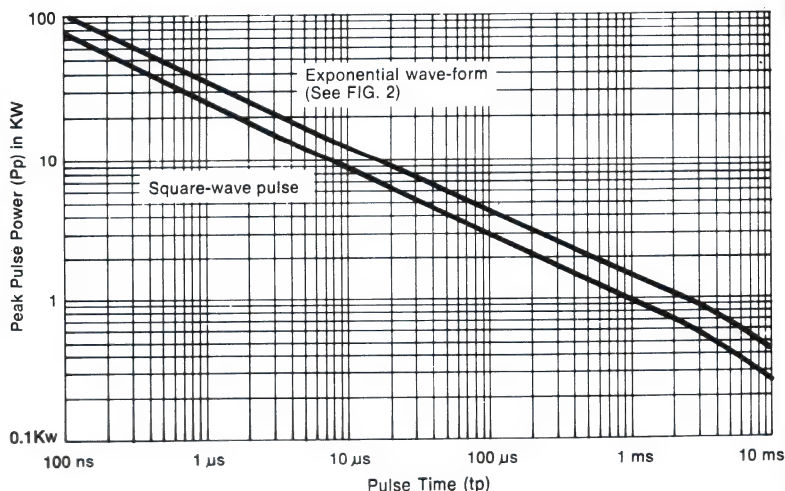
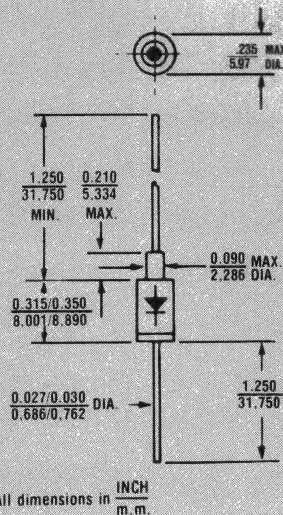


FIG. 1. Non-repetitive peak pulse power rating curve

Note: Peak power defined as peak voltage times peak current

TRANSIENT ABSORPTION ZENER



All dimensions in
INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: DO-13, welded, hermetically sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: $100^{\circ}\text{C}/\text{W}$ (Typical) junction to lead at 0.375-inches from body.

POLARITY: Cathode connected to case and marked.

WEIGHT: 1.4 grams (Appx.)

MOUNTING POSITION: Any.

1N5629 thru 1N5665

*ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

| Type No. | Breakdown Voltage (V_{BR}) Min. Max. | | Test Current (I_T) | Rated Standoff Voltage (V_{WM}) | Maximum Reverse Leakage Current (I_D at V_{WM}) | Maximum Peak Reverse Voltage (V_C max. at I_{PP}) | Maximum Peak Pulse Current (I_{PP}) | Maximum Temperature Coefficient of V_{BR} ($\Delta V_{BR}/\Delta T$) -55°C to 100°C |
|----------|---|-------|------------------------|-------------------------------------|---|---|---|---|
| | Vdc | Vdc | mAdc | V | μAdc | V | A | %/°C |
| 1N5629 | 6.12 | 7.48 | 10 | 5.50 | 1000 | 10.8 | 139 | .057 |
| 1N5629A | 6.45 | 7.14 | 10 | 5.80 | 1000 | 10.5 | 143 | .057 |
| 1N5630 | 6.75 | 8.25 | 10 | 6.05 | 500 | 11.7 | 128 | .061 |
| 1N5630A | 7.13 | 7.88 | 10 | 6.40 | 500 | 11.3 | 132 | .061 |
| 1N5631 | 7.38 | 9.02 | 10 | 6.63 | 200 | 12.5 | 120 | .065 |
| 1N5631A | 7.79 | 8.61 | 10 | 7.02 | 200 | 12.1 | 124 | .065 |
| 1N5632 | 8.19 | 10.0 | 1 | 7.37 | 50 | 13.8 | 109 | .068 |
| 1N5632A | 8.65 | 9.55 | 1 | 7.78 | 50 | 13.4 | 112 | .068 |
| 1N5633 | 9.00 | 11.0 | 1 | 8.10 | 10 | 15.0 | 100 | .073 |
| 1N5633A | 9.5 | 10.5 | 1 | 8.55 | 10 | 14.5 | 103 | .073 |
| 1N5634 | 9.9 | 12.1 | 1 | 8.92 | 5 | 16.2 | 93 | .075 |
| 1N5634A | 10.5 | 11.6 | 1 | 9.40 | 5 | 15.6 | 96 | .075 |
| 1N5635 | 10.8 | 13.2 | 1 | 9.72 | 5 | 17.3 | 87 | .078 |
| 1N5635A | 11.4 | 12.6 | 1 | 10.2 | 5 | 16.7 | 90 | .078 |
| 1N5636 | 11.7 | 14.3 | 1 | 10.5 | 5 | 19.0 | 79 | .081 |
| 1N5636A | 12.4 | 13.7 | 1 | 11.1 | 5 | 18.2 | 82 | .081 |
| 1N5637 | 13.5 | 16.5 | 1 | 12.1 | 5 | 22.0 | 68 | .084 |
| 1N5637A | 14.3 | 15.8 | 1 | 12.8 | 5 | 21.2 | 71 | .084 |
| 1N5638 | 14.4 | 17.6 | 1 | 12.9 | 5 | 23.5 | 64 | .086 |
| 1N5638A | 15.2 | 16.8 | 1 | 13.6 | 5 | 22.5 | 67 | .086 |
| 1N5639 | 16.2 | 19.8 | 1 | 14.5 | 5 | 26.5 | 56.5 | .088 |
| 1N5639A | 17.1 | 18.9 | 1 | 15.3 | 5 | 25.2 | 59.5 | .088 |
| 1N5640 | 18.0 | 22.0 | 1 | 16.2 | 5 | 29.1 | 51.5 | .090 |
| 1N5640A | 19.0 | 21.0 | 1 | 17.1 | 5 | 27.7 | 54 | .090 |
| 1N5641 | 19.8 | 24.2 | 1 | 17.8 | 5 | 31.9 | 47 | .092 |
| 1N5641A | 20.9 | 23.1 | 1 | 18.8 | 5 | 30.6 | 49 | .092 |
| 1N5642 | 21.6 | 26.4 | 1 | 19.4 | 5 | 34.7 | 43 | .094 |
| 1N5642A | 22.8 | 25.2 | 1 | 20.5 | 5 | 33.2 | 45 | .094 |
| 1N5643 | 24.3 | 29.7 | 1 | 21.8 | 5 | 39.1 | 38.5 | .096 |
| 1N5643A | 25.7 | 28.4 | 1 | 23.1 | 5 | 37.5 | 40 | .096 |
| 1N5644 | 27.0 | 33.0 | 1 | 24.3 | 5 | 43.5 | 34.5 | .097 |
| 1N5644A | 28.5 | 31.5 | 1 | 25.6 | 5 | 41.4 | 36 | .097 |
| 1N5645 | 29.7 | 36.3 | 1 | 26.8 | 5 | 47.7 | 31.5 | .098 |
| 1N5645A | 31.4 | 34.7 | 1 | 28.2 | 5 | 45.7 | 33 | .098 |
| 1N5646 | 32.4 | 39.6 | 1 | 29.1 | 5 | 52.0 | 29 | .099 |
| 1N5646A | 34.2 | 37.9 | 1 | 30.8 | 5 | 49.9 | 30 | .099 |
| 1N5647 | 35.1 | 42.9 | 1 | 31.6 | 5 | 56.4 | 26.5 | .100 |
| 1N5647A | 37.1 | 41.0 | 1 | 33.3 | 5 | 53.9 | 28 | .100 |
| 1N5648 | 38.7 | 47.3 | 1 | 34.8 | 5 | 61.9 | 24 | .101 |
| 1N5648A | 40.9 | 45.2 | 1 | 36.8 | 5 | 59.3 | 25.3 | .101 |
| 1N5649 | 42.3 | 51.7 | 1 | 38.1 | 5 | 67.8 | 22.2 | .101 |
| 1N5649A | 44.7 | 49.4 | 1 | 40.2 | 5 | 64.8 | 23.2 | .101 |
| 1N5650 | 45.9 | 56.1 | 1 | 41.3 | 5 | 73.5 | 20.4 | .102 |
| 1N5650A | 48.5 | 53.6 | 1 | 43.6 | 5 | 70.1 | 21.4 | .102 |
| 1N5651 | 50.4 | 61.6 | 1 | 45.4 | 5 | 80.5 | 18.6 | .103 |
| 1N5651A | 53.2 | 58.8 | 1 | 47.8 | 5 | 77.0 | 19.5 | .103 |
| 1N5652 | 55.8 | 68.2 | 1 | 50.2 | 5 | 89.0 | 16.9 | .104 |
| 1N5652A | 58.9 | 65.1 | 1 | 53.0 | 5 | 85.0 | 17.7 | .104 |
| 1N5653 | 61.2 | 74.8 | 1 | 55.1 | 5 | 98.0 | 15.3 | .104 |
| 1N5653A | 64.6 | 71.4 | 1 | 58.1 | 5 | 92.0 | 16.3 | .104 |
| 1N5654 | 67.5 | 82.5 | 1 | 60.7 | 5 | 108 | 13.9 | .105 |
| 1N5654A | 71.3 | 78.8 | 1 | 64.1 | 5 | 103 | 14.6 | .105 |
| 1N5655 | 73.8 | 90.2 | 1 | 66.4 | 5 | 118 | 12.7 | .105 |
| 1N5655A | 77.9 | 86.1 | 1 | 70.1 | 5 | 113 | 13.3 | .105 |
| 1N5656 | 81.9 | 100.0 | 1 | 73.7 | 5 | 131 | 11.4 | .106 |
| 1N5656A | 86.5 | 95.5 | 1 | 77.8 | 5 | 125 | 12.0 | .106 |
| 1N5657 | 90 | 110 | 1 | 81.0 | 5 | 144 | 10.4 | .106 |
| 1N5657A | 95 | 105 | 1 | 85.5 | 5 | 137 | 11.0 | .106 |
| 1N5658 | 99 | 121 | 1 | 89.2 | 5 | 158 | 9.5 | .107 |
| 1N5658A | 105 | 116 | 1 | 94.0 | 5 | 152 | 9.9 | .107 |
| 1N5659 | 108 | 132 | 1 | 97.2 | 5 | 173 | 8.7 | .107 |
| 1N5659A | 114 | 125 | 1 | 102 | 5 | 165 | 9.1 | .107 |
| 1N5660 | 117 | 143 | 1 | 105 | 5 | 187 | 8.0 | .107 |
| 1N5660A | 124 | 137 | 1 | 111 | 5 | 179 | 8.4 | .107 |
| 1N5661 | 135 | 165 | 1 | 121 | 5 | 215 | 7.0 | .108 |
| 1N5661A | 143 | 158 | 1 | 128 | 5 | 207 | 7.2 | .108 |
| 1N5662 | 144 | 176 | 1 | 130 | 5 | 230 | 6.5 | .108 |
| 1N5662A | 152 | 168 | 1 | 136 | 5 | 219 | 6.8 | .108 |
| 1N5663 | 153 | 187 | 1 | 138 | 5 | 244 | 6.2 | .108 |
| 1N5663A | 162 | 179 | 1 | 145 | 5 | 234 | 6.4 | .108 |
| 1N5664 | 162 | 198 | 1 | 146 | 5 | 258 | 5.8 | .108 |
| 1N5664A | 171 | 189 | 1 | 154 | 5 | 246 | 6.1 | .108 |
| 1N5665 | 180 | 220 | 1 | 162 | 5 | 287 | 5.2 | .108 |
| 1N5665A | 190 | 210 | 1 | 171 | 5 | 274 | 5.5 | .108 |

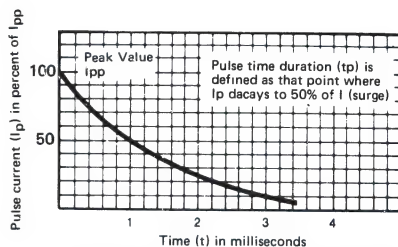


FIG. 2. Pulse wave form for exponential surge

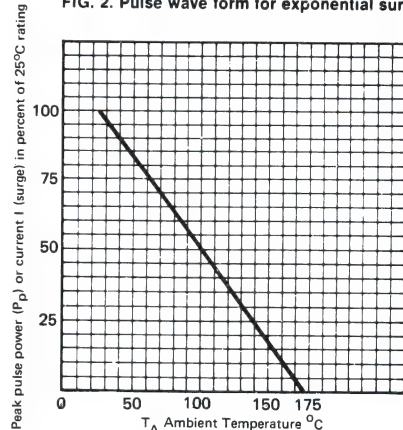


FIG. 3. Derating curve

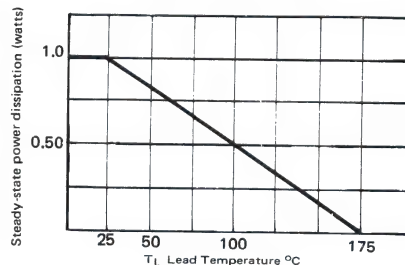


FIG. 4. Steady-state power derating curve

ABBREVIATIONS AND SYMBOLS

V_{WM} Stand Off Voltage: Applied Reverse Voltage to assure a nonconductive condition. (See Note 1.)

V_{BR} This is the Breakdown Voltage the device will exhibit and is used to assure that conduction does not occur prior to this voltage level at 25°C .

V_C Maximum Clamping Voltage. The maximum peak voltage appearing across the Zener when subjected to the peak pulse current in a one millisecond time interval. The peak pulse voltages are the combi-

nation of voltage rise due to both the series resistance and thermal rise.

I_{PP} Peak Pulse Current—See Figure 2.

P_{PP} —Peak Pulse Power.

I_D —Reverse Leakage.

I_T —Current that V_{BR} is measured at.

Note 1:

A TAZ is normally selected according to the rated "Stand Off Voltage" V_{WM} which should be equal to or greater than the DC or continuous peak operating voltage level.

* V_{BR} is measured after I_T has been applied for ≤ 300 ms

Forward voltage V_F , at $I_F = 1$ AMP, 1.2V max.

Forward current I_F shall be applied for 30 secs. before V_F is measured.

1N5907 and 1N5908

FEATURES

- 5.0 VOLTS REVERSE STAND-OFF VOLTAGE
- DESIGNED FOR T²L LOGIC PROTECTION
- 1500 WATTS PEAK PULSE POWER DISSIPATION

The 1N5907 TAZ, packaged in a hermetically sealed glass-to-metal package, is available in JAN, JANTX and JANTXV qualified to MIL-STD-19500/500. The 1N5907 and 1N5908 protect TTL, ECL, DTL, MOS and MSI integrated circuits requiring 5.0 volt or lower power supplies. These devices are rated for a peak pulse power of 1500 watts for 1 millisecond.

These devices are specified at high current pulses, such type that would be seen from inductive switching transients. They provide both protection from line transients as well as preventing transients from being injected onto the line. Both hermetic seal and molded types are available.

MAXIMUM RATINGS

1500 Watts of Peak Pulse Power dissipation at 25°C (see derating curve)

$t_{clamping}$ (0 volts to BV min): Less than 1×10^{-12} second (theoretical)

Operating and Storage temperatures: -65° to +175°C

Forward surge rating: half cycle 200amps, 1/120 second at 25°C

Steady State power dissipation:

1N5907 — 1.0 watt

1N5908 — 5.0 watts at $T_L = 75^\circ\text{C}$,

Lead Length = 3/8"

Repetition rate (duty cycle): 1N5907 — .01%, 1N5908 — .05%

ELECTRICAL CHARACTERISTICS @ 25°C

| JEDEC TYPE NUMBER | REVERSE STAND-OFF VOLTAGE (NOTE 1) VRM VOLTS | MINIMUM BREAKDOWN VOLTAGE @ 1 mA V _{BR} VOLTS | MAXIMUM REVERSE LEAKAGE V @ W _M I ₀ μA | MAXIMUM CLAMPING VOLTAGE @ I _{PP1} (FIG. 3) V _C VOLTS | PEAK PULSE CURRENT (FIG. 3) I _{PP1} A | MAXIMUM CLAMPING VOLTAGE @ I _{PP2} (FIG. 3) V _C VOLTS | PEAK PULSE CURRENT (FIG. 3) I _{PP2} A | MAXIMUM CLAMPING VOLTAGE @ I _{PP3} (FIG. 3) V _C VOLTS | PEAK PULSE CURRENT (FIG. 3) I _{PP3} A |
|-------------------------|---|---|---|---|---|---|---|---|---|
| * 1N5907 | 5.0 | 6.0 | 300 | 7.6 | 30 | 8.0 | 60 | 8.5 | 120 |
| 1N5908 | 5.0 | 6.0 | 300 | 7.6 | 30 | 8.0 | 60 | 8.5 | 120 |

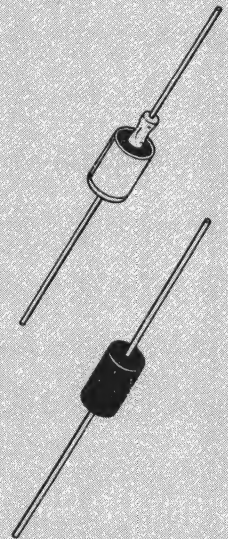
* Available in JAN, JTX & JTXV per MIL-S-19500/500.

Clamping Factor: 1.33 at full rated power
1.20 at 50% rated power

Clamping Factor: The ratio of the actual V_C (Clamping Voltage) to the V_{BR} (Breakdown Voltage) as measured on a specific device.

Capacitance: 15,000 pF at 0 Volts (typical).

TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: Standard DO-13 package,
glass and hermetically sealed.
(1N5907)

Molded Case (1N5908)

POLARITY: Banded end is cathode.

WEIGHT: 1.5 grams (Appx.)

MOUNTING POSITION: Any.

1N5907 and 1N5908

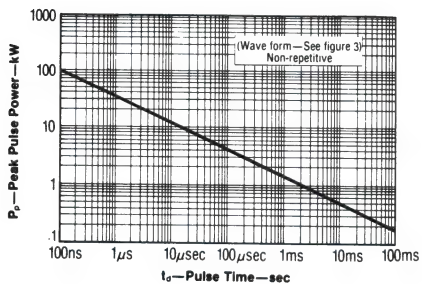


FIGURE 1
PEAK PULSE POWER
VS. PULSE TIME

Peak Pulse Power (Pp) or Current (Ipp)
in percent of 25°C rating

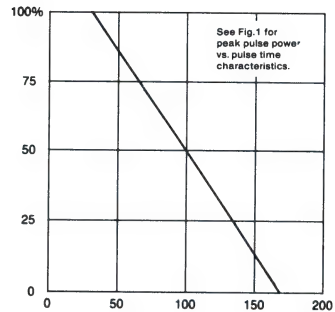


FIGURE 2
DERATING CURVE

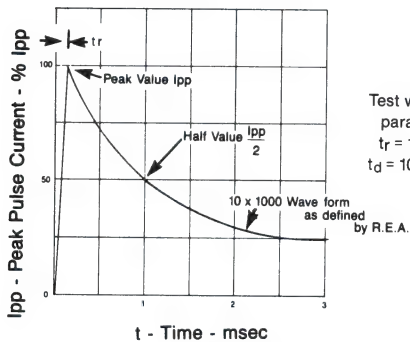


FIGURE 3
PULSE WAVEFORM

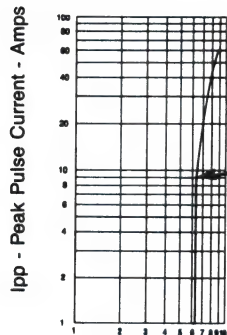
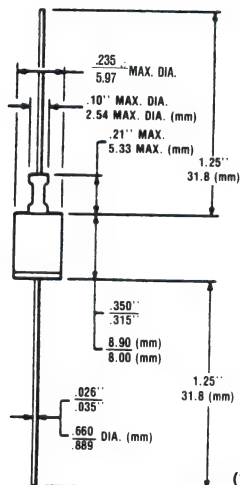


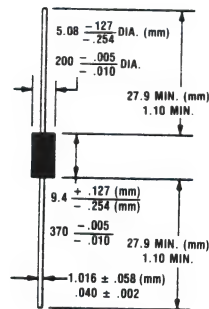
FIGURE 4
TYPICAL CLAMPING VOLTAGE (V_C)
VS. PEAK PULSE CURRENT (I_{PP})



(1N5907) CASE DO-13

PACKAGE DIMENSIONS

Note 1: A TAZ is normally selected according to the reverse "Stand Off Voltage" V_{RM} which should be equal to or greater than the DC or continuous peak operating voltage level.



(1N5908)

FEATURES

- 1500 WATTS PEAK POWER DISSIPATION
- AVAILABLE IN STANDOFF VOLTAGES FROM 5.5V TO 185V
- DO-13 HERMETICALLY SEALED PACKAGE
- BIDIRECTIONAL
- UL RECOGNIZED (1N6070A)
- JAN/TX/TXV AVAILABLE PER MIL-S-19500/507

DESCRIPTION

These TAZ devices are a series of Bidirectional Silicon Transient Suppressors used in AC applications where large voltage transients can permanently damage voltage-sensitive components.

These devices are manufactured using two silicon PN, low voltage junction in a back to back configuration. They are characterized by their high surge capability, extremely fast response time, and low impedance, (R_{on}).

TAZ has a peak pulse power rating of 1500 watts for one millisecond and therefore can be used in applications where induced lightning on rural or remote transmission lines represents a hazard to electronic circuitry. The response time of TAZ clamping action is less than (5×10^{-9}) sec; therefore, they can protect Integrated Circuits, MOS devices, Hybrids, and other voltage-sensitive semiconductors and components.

This series of devices has been proven very effective as EMP Suppressors.

MAXIMUM RATINGS

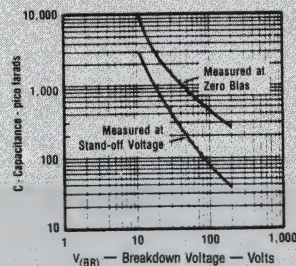
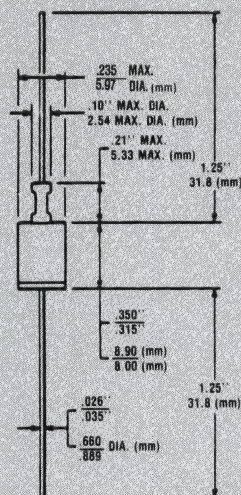
1500 watts of peak pulse power dissipation at 25°C
 $t_{clamping}$ (0 volts to $V_{(BR)}$ min): less than 5×10^{-9} seconds
 Operating and storage temperatures -65°C to +175°C
 Steady state power dissipation: 1.0 watts at $T_L = 25^\circ\text{C}$, 3/8" from body.
 Repetition rate (duty cycle): .01%

ELECTRICAL CHARACTERISTICS

Clamping Factor: 1.33 @ full rated power
 1.20 @ 50% rated power

Clamping Factor: The ratio of the actual V_C (Clamping Voltage) to the $V_{(BR)}$ (Breakdown Voltage) as measured on a specific device.

TRANSIENT ABSORPTION ZENER



TYPICAL CAPACITANCE vs. BREAKDOWN VOLTAGE

MECHANICAL CHARACTERISTICS

Standard DO-13 package, glass and metal hermetically sealed

WEIGHT: 1.5 grams (approximate)

FINISH: All external surfaces are corrosion resistant and leads solderable.

POLARITY: Bidirectional not marked.

MOUNTING POSITION: Any.

1N6036 thru 1N6072A

ELECTRICAL CHARACTERISTICS @ 25°C (Test Both Polarities)

| JEDEC Type Number | Rated Stand-off Voltage (Note 1) | Breakdown Voltage | | Maximum Clamping Voltage @ I_{PP} (1 mSEC) | Maximum Reverse Leakage @ V_{RM} | Maximum Peak Pulse Current (Fig. 2) | Maximum Temperature Coefficient of V_{BR} |
|-------------------------|---|----------------------|---------------|--|---|--|--|
| | V_{RM} Volts | $V_{(BR)}$ Volts | @ I_T mA | | | | |
| 1N6036 | 5.5 | 6.75 - 8.25 | 10 | 11.7 | 1000 | 128 | .061 |
| *1N6036A | 6.0 | 7.13 - 7.88 | 10 | 11.3 | 1000 | 132 | .061 |
| 1N6037 | 6.5 | 7.38 - 9.02 | 10 | 12.5 | 500 | 120 | .065 |
| *1N6037A | 7.0 | 7.79 - 8.61 | 10 | 12.1 | 500 | 124 | .065 |
| 1N6038 | 7.0 | 8.19 - 10.00 | 10 | 13.8 | 200 | 109 | .068 |
| *1N6038A | 7.5 | 8.65 - 9.55 | 10 | 13.4 | 200 | 112 | .068 |
| 1N6039 | 8.0 | 9.0 - 11.0 | 1 | 15.0 | 50 | 100 | .073 |
| *1N6039A | 8.5 | 9.5 - 10.5 | 1 | 14.5 | 50 | 103 | .073 |
| 1N6040 | 8.5 | 9.9 - 12.1 | 1 | 16.2 | 10 | 93 | .075 |
| *1N6040A | 9.0 | 10.5 - 11.6 | 1 | 15.6 | 10 | 96 | .075 |
| 1N6041 | 9.0 | 10.8 - 13.2 | 1 | 17.3 | 5 | 87 | .078 |
| *1N6041A | 10.0 | 11.4 - 12.6 | 1 | 16.7 | 5 | 90 | .078 |
| 1N6042 | 10.0 | 11.7 - 14.3 | 1 | 19.0 | 5 | 79 | .081 |
| *1N6042A | 11.0 | 12.4 - 13.7 | 1 | 18.2 | 5 | 82 | .081 |
| 1N6043 | 11.0 | 13.5 - 16.5 | 1 | 22.0 | 5 | 68 | .084 |
| *1N6043A | 12.0 | 14.3 - 15.8 | 1 | 21.2 | 5 | 71 | .084 |
| 1N6044 | 12.0 | 14.4 - 17.5 | 1 | 23.5 | 5 | 64 | .086 |
| *1N6044A | 13.0 | 15.2 - 16.8 | 1 | 22.5 | 5 | 67 | .088 |
| 1N6045 | 14.0 | 16.2 - 19.8 | 1 | 26.5 | 5 | 56.5 | .088 |
| *1N6045A | 15.0 | 17.1 - 18.9 | 1 | 25.2 | 5 | 59.5 | .088 |
| 1N6046 | 16.0 | 18.0 - 22.0 | 1 | 29.1 | 5 | 51.5 | .090 |
| *1N6046A | 17.0 | 19.0 - 21.0 | 1 | 27.7 | 5 | 54 | .090 |
| 1N6047 | 17.0 | 19.8 - 24.2 | 1 | 31.9 | 5 | 47 | .092 |
| *1N6047A | 18.0 | 20.9 - 23.1 | 1 | 30.6 | 5 | 49 | .092 |
| 1N6048 | 19.0 | 21.6 - 26.4 | 1 | 34.7 | 5 | 43 | .094 |
| *1N6048A | 20.0 | 22.8 - 25.2 | 1 | 33.2 | 5 | 45 | .094 |
| 1N6049 | 21.0 | 24.3 - 29.7 | 1 | 39.1 | 5 | 38.5 | .095 |
| *1N6049A | 22.0 | 25.7 - 28.4 | 1 | 37.5 | 5 | 40 | .096 |
| 1N6050 | 24.0 | 27.0 - 33.0 | 1 | 43.5 | 5 | 34.5 | .097 |
| *1N6050A | 25.0 | 28.5 - 31.5 | 1 | 41.4 | 5 | 36 | .097 |
| 1N6051 | 26.0 | 29.7 - 36.3 | 1 | 47.7 | 5 | 31.5 | .098 |
| *1N6051A | 28.0 | 31.4 - 34.7 | 1 | 45.7 | 5 | 33 | .098 |
| 1N6052 | 29.0 | 32.4 - 39.6 | 1 | 52.0 | 5 | 29 | .099 |
| *1N6052A | 30.0 | 34.2 - 37.8 | 1 | 49.9 | 5 | 30 | .099 |
| 1N6053 | 31.0 | 35.1 - 42.9 | 1 | 56.4 | 5 | 26.5 | .100 |
| *1N6053A | 33.0 | 37.1 - 41.0 | 1 | 53.9 | 5 | 28 | .100 |
| 1N6054 | 34.0 | 38.7 - 47.3 | 1 | 61.9 | 5 | 24 | .101 |
| *1N6054A | 36.0 | 40.9 - 45.2 | 1 | 59.3 | 5 | 25.3 | .101 |
| 1N6055 | 38.0 | 42.3 - 51.7 | 1 | 67.8 | 5 | 22.2 | .101 |
| *1N6055A | 40.0 | 44.7 - 49.4 | 1 | 64.8 | 5 | 23.2 | .101 |
| 1N6056 | 41.0 | 45.9 - 56.1 | 1 | 73.5 | 5 | 20.4 | .102 |
| *1N6056A | 43.0 | 48.5 - 53.6 | 1 | 70.1 | 5 | 21.4 | .102 |
| 1N6057 | 45.0 | 50.4 - 61.6 | 1 | 80.5 | 5 | 18.6 | .103 |
| *1N6057A | 47.0 | 53.2 - 58.8 | 1 | 77.0 | 5 | 19.5 | .103 |
| 1N6058 | 48.0 | 55.8 - 68.2 | 1 | 89.0 | 5 | 16.9 | .104 |
| *1N6058A | 53.0 | 58.9 - 65.1 | 1 | 85.0 | 5 | 17.7 | .104 |
| 1N6059 | 55.0 | 61.2 - 74.8 | 1 | 98.0 | 5 | 15.3 | .104 |
| *1N6059A | 58.0 | 64.6 - 71.4 | 1 | 92.0 | 5 | 16.3 | .104 |
| 1N6060 | 60.0 | 67.5 - 82.5 | 1 | 108.0 | 5 | 13.9 | .105 |
| *1N6060A | 64.0 | 71.3 - 78.8 | 1 | 103.0 | 5 | 14.6 | .105 |
| 1N6061 | 66.0 | 73.8 - 90.2 | 1 | 118.0 | 5 | 12.7 | .105 |
| *1N6061A | 70.0 | 77.9 - 86.1 | 1 | 113.0 | 5 | 13.3 | .105 |
| 1N6062 | 73.0 | 81.9 - 100.0 | 1 | 131.0 | 5 | 11.4 | .106 |
| *1N6062A | 75.0 | 86.5 - 95.5 | 1 | 125.0 | 5 | 12.0 | .106 |
| 1N6063 | 81.0 | 90.0 - 110.0 | 1 | 144.0 | 5 | 10.4 | .106 |
| *1N6063A | 82.0 | 95.0 - 105.0 | 1 | 137.0 | 5 | 11.0 | .106 |
| 1N6064 | 90.0 | 99.0 - 121.0 | 1 | 158.0 | 5 | 9.5 | .107 |
| *1N6064A | 94.0 | 105.0 - 116.0 | 1 | 152.0 | 5 | 9.9 | .107 |
| 1N6065 | 95.0 | 108.0 - 132.0 | 1 | 176.0 | 5 | 8.5 | .107 |
| *1N6065A | 100.0 | 114.0 - 126.0 | 1 | 168.0 | 5 | 8.9 | .107 |
| 1N6066 | 105.0 | 117.0 - 143.0 | 1 | 191.0 | 5 | 7.8 | .107 |
| *1N6066A | 110.0 | 124.0 - 137.0 | 1 | 182.0 | 5 | 8.2 | .107 |
| 1N6067 | 121.0 | 135.0 - 165.0 | 1 | 223.0 | 5 | 6.7 | .108 |
| *1N6067A | 128.0 | 143.0 - 158.0 | 1 | 213.0 | 5 | 7.0 | .108 |
| 1N6068 | 137.0 | 153.0 - 187.0 | 1 | 258.0 | 5 | 5.8 | .108 |
| *1N6068A | 145.0 | 162.0 - 179.0 | 1 | 245.0 | 5 | 6.1 | .108 |
| 1N6069 | 145.0 | 162.0 - 198.0 | 1 | 274.0 | 5 | 5.5 | .108 |
| *1N6069A | 150.0 | 171.0 - 189.0 | 1 | 261.0 | 5 | 5.7 | .108 |
| 1N6070 | 155.0 | 171.0 - 210.0 | 1 | 292.0 | 5 | 5.1 | .108 |
| *1N6070A | 160.0 | 181.0 - 200.0 | 1 | 278.0 | 5 | 5.4 | .108 |
| 1N6071 | 165.0 | 180.0 - 220.0 | 1 | 308.0 | 5 | 4.9 | .108 |
| *1N6071A | 170.0 | 190.0 - 210.0 | 1 | 294.0 | 5 | 5.1 | .108 |
| 1N6072 | 175.0 | 198.0 - 242.0 | 1 | 344.0 | 5 | 4.3 | .108 |
| *1N6072A | 185.0 | 209.0 - 231.0 | 1 | 328.0 | 5 | 4.6 | .108 |

*Available in JAN, JANTX, JANTXV

NOTE 1: A TAZ is normally selected according to the rated "Stand Off Voltage" V_{RM} which should be equal to or greater than the DC or continuous peak operating voltage level.

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★ JANS ★

1N6102-1N6137
1N6138-1N6173
1N6102A-1N6137A
1N6138A-1N6173A

FEATURES

- HIGH SURGE CAPACITY PROVIDES TRANSIENT PROTECTION FOR MOST CRITICAL CIRCUITS.
- TRIPLE LAYER PASSIVATION.
- SUBMINIATURE.
- METALLURGICALLY BONDED.
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE
- DYNAMIC IMPEDANCE AND REVERSE LEAKAGE LOWEST AVAILABLE.
- JAN/S/TX/TV TYPES AVAILABLE PER MIL-S-19500/516.

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$.

Storage Temperature: -65°C to $+200^{\circ}\text{C}$.

Surge Power 500W & 1500W

Power @ $T_L = 75^{\circ}\text{C}$ (%) 3.0W 500W Type

Power @ $T_L = 50^{\circ}\text{C}$ (%) 5.0W 1500W Type

ELECTRICAL CHARACTERISTICS

| SERIES TYPE | | BREAKDOWN VOLTAGE V_{BR} MIN. | TEST CURRENT I_T | WORKING PEAK VOLTAGE V_{RWM} | MAX LEAKAGE CURRENT I_D | MAX CLAMPING VOLTAGE V_C (MAX) | MAX PEAK PULSE CURRENT I_P | MAX. TEMP. COEF. OF V_{BR} |
|-------------|---------|---------------------------------|--------------------|--------------------------------|---------------------------------|----------------------------------|------------------------------|------------------------------|
| 500W | 1500W | Vdc | mAdc | Vdc | μAdc μAdc | V(pk) | A(pk) A(pk) | %/ $^{\circ}\text{C}$ |
| 1N6102A | 1N6138A | 6.46 | 175 | 5.2 | 100 500 | 10.5 | 47.6 142.8 | .05 |
| 1N6103A | 1N6139A | 7.13 | 175 | 5.7 | 50 300 | 11.2 | 44.6 133.9 | .06 |
| 1N6104A | 1N6140A | 7.79 | 150 | 6.2 | 10 100 | 12.1 | 41.3 124.0 | .06 |
| 1N6105A | 1N6141A | 8.65 | 150 | 6.9 | 10 100 | 13.4 | 37.3 111.9 | .06 |
| 1N6106A | 1N6142A | 9.50 | 125 | 7.6 | 10 100 | 14.5 | 34.5 103.4 | .07 |
| 1N6107A | 1N6143A | 10.45 | 125 | 8.4 | 1 10 | 15.6 | 32.0 96.2 | .07 |
| 1N6108A | 1N6144A | 11.40 | 100 | 9.1 | 1 10 | 16.9 | 29.6 88.8 | .07 |
| 1N6109A | 1N6145A | 12.35 | 100 | 9.9 | 1 10 | 18.2 | 27.5 82.4 | .08 |
| 1N6110A | 1N6146A | 14.25 | 75 | 11.4 | 1 10 | 21.0 | 23.8 71.4 | .08 |
| 1N6111A | 1N6147A | 15.20 | 75 | 12.2 | 1 10 | 22.3 | 22.4 67.3 | .08 |
| 1N6112A | 1N6148A | 17.10 | 65 | 13.7 | 1 10 | 25.1 | 19.9 59.8 | .085 |
| 1N6113A | 1N6149A | 19.0 | 65 | 15.2 | 1 5 | 27.7 | 18.0 54.2 | .085 |
| 1N6114A | 1N6150A | 20.9 | 50 | 16.7 | 1 5 | 30.5 | 16.4 49.2 | .085 |
| 1N6115A | 1N6151A | 22.8 | 50 | 18.2 | 1 5 | 33.3 | 15.0 45.0 | .09 |
| 1N6116A | 1N6152A | 25.7 | 50 | 20.6 | 1 5 | 37.4 | 13.4 40.1 | .09 |
| 1N6117A | 1N6153A | 28.5 | 40 | 22.8 | 1 5 | 41.6 | 12.0 36.0 | .09 |
| 1N6118A | 1N6154A | 31.4 | 40 | 25.1 | 1 5 | 45.7 | 10.9 32.8 | .095 |
| 1N6119A | 1N6155A | 34.2 | 30 | 27.4 | 1 5 | 49.9 | 10.0 30.1 | .095 |
| 1N6120A | 1N6156A | 37.1 | 30 | 29.7 | 1 5 | 53.6 | 9.3 28.0 | .095 |
| 1N6121A | 1N6157A | 40.9 | 30 | 32.7 | 1 5 | 59.1 | 8.5 25.4 | .095 |
| 1N6122A | 1N6158A | 44.7 | 25 | 35.8 | 1 5 | 64.6 | 7.7 23.2 | .095 |
| 1N6123A | 1N6159A | 48.5 | 25 | 38.8 | 1 5 | 70.1 | 7.1 21.4 | .095 |
| 1N6124A | 1N6160A | 53.2 | 20 | 42.6 | 1 5 | 77.0 | 6.5 19.5 | .095 |
| 1N6125A | 1N6161A | 58.9 | 20 | 47.1 | 1 5 | 85.3 | 5.9 17.6 | .100 |
| 1N6126A | 1N6162A | 64.6 | 20 | 51.7 | 1 5 | 97.1 | 5.1 15.4 | .100 |
| 1N6127A | 1N6163A | 71.3 | 20 | 56.0 | 1 5 | 103.1 | 4.8 14.5 | .100 |
| 1N6128A | 1N6164A | 77.9 | 15 | 62.2 | 1 5 | 112.8 | 4.4 13.3 | .100 |
| 1N6129A | 1N6165A | 86.5 | 15 | 69.2 | 1 5 | 125.1 | 4.0 12.0 | .100 |
| 1N6130A | 1N6166A | 95.0 | 12 | 76.0 | 1 5 | 137.6 | 3.6 10.9 | .100 |
| 1N6131A | 1N6167A | 104.5 | 12 | 86.6 | 1 5 | 151.3 | 3.3 9.9 | .100 |
| 1N6132A | 1N6168A | 114.0 | 10 | 91.2 | 1 5 | 165.1 | 3.0 9.1 | .100 |
| 1N6133A | 1N6169A | 123.5 | 10 | 98.8 | 1 5 | 178.8 | 2.8 8.4 | .105 |
| 1N6134A | 1N6170A | 142.5 | 8 | 114.0 | 1 5 | 206.3 | 2.4 7.3 | .105 |
| 1N6135A | 1N6171A | 152.0 | 8 | 121.6 | 1 5 | 218.4 | 2.3 6.9 | .105 |
| 1N6136A | 1N6172A | 171.0 | 5 | 136.8 | 1 5 | 245.7 | 2.0 6.1 | .110 |
| 1N6137A | 1N6173A | 190.0 | 5 | 152.0 | 1 5 | 273.0 | 1.8 5.5 | .110 |
| Note: 4 | | 1 | 1 | 1 | 2 3 | 1 | 2 3 | 1 |

NOTES: 1. Applies to both 500W and 1500W series. 4. Non --A part has 5% higher max surge voltage, 5% lower V_{BR} min., ISM.
2. Applies to only 500W series.
3. Applies to only 1500W series.

BI-DIRECTIONAL TRANSIENT SUPPRESSORS

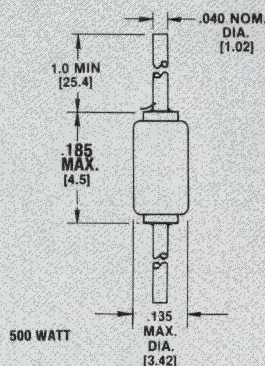


FIGURE 1
(NOTE 3)

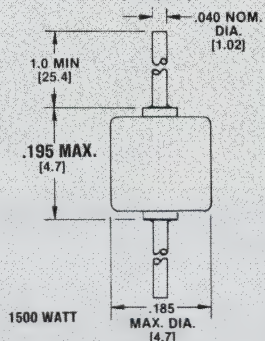


FIGURE 2
(NOTE 2)

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass case.

Lead Material: Tinned copper or silver clad copper.

Marking: Body painted, alpha numeric.

Polarity: No marking with bidirectional devices.

1N6102-1N6137, 1N6138-1N6173 1N6102A-1N6137A, 1N6138A-1N6173A

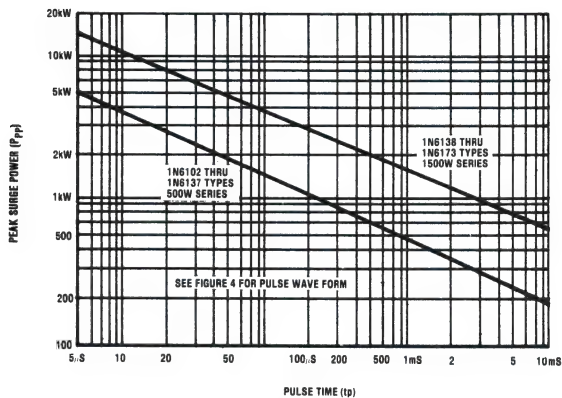


FIGURE 2
PEAK SURGE POWER vs. PULSE TIME

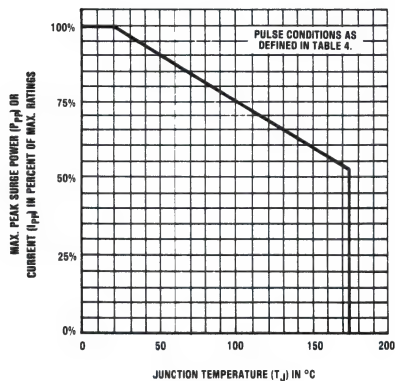


FIGURE 3
PULSE DERATING CURVE

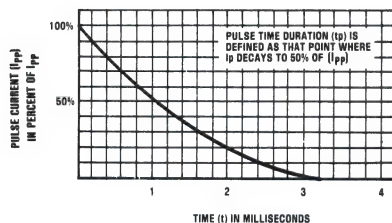


FIGURE 4
PULSE WAVE FORM

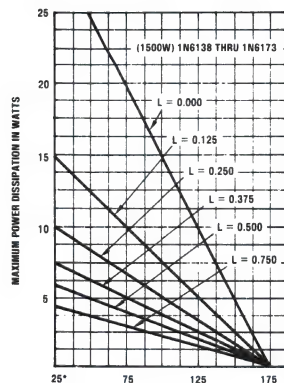
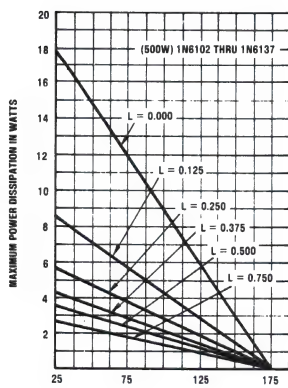


FIGURE 5
MAXIMUM POWER vs. LEAD TEMPERATURE

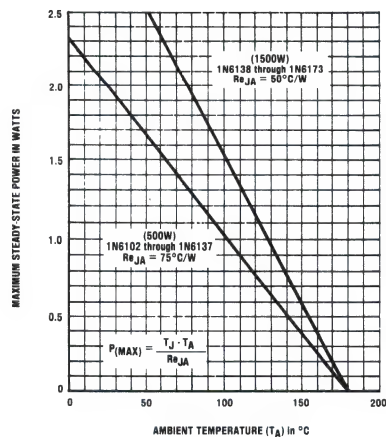


FIGURE 6
STEADY STATE DERATING CURVE
FOR FREE AIR MOUNTING

Maximum lead temperature in °C (T_L) at point "L" from body (for maximum operating junction temperature with equal two-lead conditions).

**1N6267 thru
1N6303A
and 1.5KE6.8 thru
1.5KE200A**

FEATURES

- ECONOMICAL
- 1500 WATTS PEAK PULSE POWER DISSIPATION
- STAND OFF VOLTAGES FROM 5.5V-200V
- UNIPOLAR OR BIPOLAR
- AVAILABLE IN CHIP FORM FOR HYBRID APPLICATION —
- MULTI-CHIP BIDIRECTIONAL CELLS AVAILABLE

DESCRIPTION

This defines a series of silicon Transient Suppressors designed to protect voltage sensitive components from high energy voltage transients. TAZ devices have become very important as a consequence of their high surge capability, extremely fast response time, and low incremental surge resistance (R_s).

To characterize TAZ, a minimum voltage at low current conditions (V_{BR}), and a maximum clamping voltage (V_C), at a maximum peak pulse current are specified. In addition, a maximum clamping ratio is indicated. The maximum leakage current at the rated stand-off voltage is also provided to assure low power consumption under normal conditions.

APPLICATION

This TAZ series has a peak pulse power rating of 1500 watts for one millisecond. It can protect integrated circuits, hybrids, CMOS, MOS, and other voltage sensitive components in a broad range of applications such as telecommunications, power supplies, computers, automotive, industrial, and medical equipment.

MAXIMUM RATINGS

1500 Watts of Peak Pulse Power Dissipation at 25°C.

$t_{clamping}$ (0 Volts to BV Min.):

Unidirectional $< 1 \times 10^{-12}$ Seconds; Bidirectional $< 5 \times 10^{-9}$ Seconds.

Operating and Storage Temperature -65°C to +175°C.

Forward Surge Rating 200 Amps, 1/20 Second at 25°C.

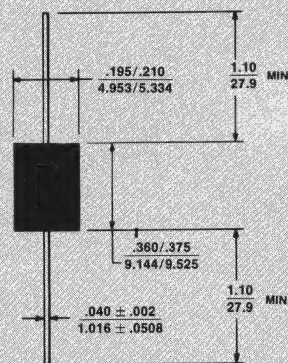
Steady State Power Dissipation 5.0 W @ $T_1 = 25^\circ\text{C}$,
(Not Applicable in Chip Form).

ELECTRICAL CHARACTERISTICS

Clamping Factor: 1.33 @ full rated power
1.20 @ 50% rated power

The Clamping Factor is defined as: The ratio of the actual V_C (Clamping Voltage) to the actual BV (Breakdown Voltage) as measured on a specific device.

TRANSIENT ABSORPTION ZENER UNIDIRECTIONAL AND BIDIRECTIONAL



All dimensions in INCH
m. m.

MECHANICAL CHARACTERISTICS

CASE: Molded

WEIGHT: 1.5 Grams (Approx.)

POLARITY: Positive Terminal
Marked with Band

1N6267 thru 1N6303A and 1.5KE6.8 thru 1.5KE200A ELECTRICAL CHARACTERISTICS @ 25°C

| Industry Type Number | JEDEC Type Number | Rated Stand-off Voltage V _{WM} VOLTS | Breakdown Voltage V _{BR} (MAX) VOLTS | Maximum Clamping Voltage V _C (1 mSEC) VOLTS | Maximum Reverse Leakage I _D @ V _{WM} μA | Maximum Peak Pulse Current I _{PP} MA | Maximum Temperature Coefficient α V _Z %/°C |
|----------------------|-------------------|--|--|---|--|--|--|
| 1.5KE6.8 | 1N6267 | 5.0 | 6.0 | 7.6 | 300 | 30 | .057 |
| 1.5KE6.8A | 1N6267A | 5.50 | 6.12 | 7.48 | 10 | 10.8 | .057 |
| 1.5KE7.5 | 1N6268 | 5.80 | 6.45 | 7.14 | 10 | 10.5 | .057 |
| 1.5KE7.5A | 1N6268A | 6.05 | 6.75 | 8.25 | 10 | 11.7 | .061 |
| 1.5KE8.2 | 1N6269 | 6.40 | 7.13 | 7.88 | 10 | 11.3 | .061 |
| 1.5KE8.2A | 1N6269A | 6.63 | 7.38 | 9.02 | 10 | 12.5 | .065 |
| 1.5KE9.1A | 1N6270 | 7.02 | 7.79 | 13.61 | 10 | 12.1 | .065 |
| 1.5KE9.1A | 1N6270A | 7.27 | 8.19 | 10.00 | 1 | 13.8 | .068 |
| 1.5KE11 | 1N6272 | 7.78 | 8.65 | 9.55 | 1 | 13.4 | .068 |
| 1.5KE12 | 1N6271 | 8.10 | 9.00 | 11.00 | 1 | 15.0 | .073 |
| 1.5KE12A | 1N6271A | 8.55 | 9.50 | 10.50 | 1 | 14.5 | .073 |
| 1.5KE13 | 1N6274 | 8.92 | 9.90 | 12.10 | 1 | 16.2 | .075 |
| 1.5KE13A | 1N6274A | 9.40 | 10.50 | 15.40 | 1 | 15.6 | .075 |
| 1.5KE15 | 1N6273 | 9.72 | 10.80 | 13.20 | 1 | 17.3 | .078 |
| 1.5KE15A | 1N6273A | 10.20 | 11.40 | 12.60 | 1 | 16.7 | .078 |
| 1.5KE16 | 1N6276 | 10.50 | 11.70 | 14.30 | 1 | 19.0 | .081 |
| 1.5KE16A | 1N6276A | 11.10 | 12.40 | 13.70 | 1 | 18.2 | .081 |
| 1.5KE18 | 1N6277 | 12.10 | 13.50 | 16.50 | 1 | 22.0 | .084 |
| 1.5KE18A | 1N6277A | 12.80 | 14.30 | 15.80 | 1 | 21.2 | .084 |
| 1.5KE20 | 1N6278 | 12.90 | 14.40 | 17.60 | 1 | 23.5 | .086 |
| 1.5KE20A | 1N6278A | 13.60 | 15.20 | 16.80 | 1 | 22.5 | .086 |
| 1.5KE22 | 1N6279 | 14.50 | 16.20 | 19.80 | 1 | 26.5 | .088 |
| 1.5KE22A | 1N6279A | 15.30 | 17.10 | 18.90 | 1 | 25.2 | .088 |
| 1.5KE24 | 1N6280 | 15.30 | 18.00 | 21.00 | 1 | 29.1 | .091 |
| 1.5KE24A | 1N6280A | 17.10 | 19.00 | 21.00 | 1 | 27.7 | .090 |
| 1.5KE27 | 1N6281 | 17.80 | 19.80 | 24.20 | 1 | 31.9 | .092 |
| 1.5KE27A | 1N6281A | 18.80 | 20.90 | 23.10 | 1 | 30.6 | .092 |
| 1.5KE30 | 1N6282 | 19.40 | 21.60 | 26.40 | 1 | 34.7 | .094 |
| 1.5KE30A | 1N6282A | 20.50 | 22.80 | 25.20 | 1 | 33.2 | .094 |
| 1.5KE33 | 1N6283 | 21.80 | 24.30 | 29.70 | 1 | 39.1 | .096 |
| 1.5KE33A | 1N6283A | 23.10 | 25.70 | 28.40 | 1 | 37.5 | .096 |
| 1.5KE36 | 1N6284 | 24.30 | 27.00 | 33.00 | 1 | 43.5 | .097 |
| 1.5KE36A | 1N6284A | 25.60 | 28.50 | 31.50 | 1 | 41.4 | .097 |
| 1.5KE39 | 1N6285 | 26.80 | 29.70 | 36.30 | 1 | 47.7 | .098 |
| 1.5KE39A | 1N6285A | 28.20 | 31.40 | 34.70 | 1 | 45.7 | .099 |
| 1.5KE43 | 1N6286 | 29.10 | 32.40 | 38.60 | 1 | 52.0 | .099 |
| 1.5KE43A | 1N6286A | 30.60 | 34.20 | 37.80 | 1 | 49.9 | .099 |
| 1.5KE47 | 1N6287 | 31.60 | 35.10 | 42.90 | 1 | 56.4 | .100 |
| 1.5KE47A | 1N6287A | 33.30 | 37.10 | 41.00 | 1 | 53.9 | .101 |
| 1.5KE51 | 1N6288 | 34.80 | 38.70 | 47.30 | 1 | 61.9 | .101 |
| 1.5KE51A | 1N6288A | 36.80 | 40.90 | 45.20 | 1 | 59.3 | .101 |
| 1.5KE56 | 1N6289 | 38.10 | 42.30 | 51.70 | 1 | 67.8 | .101 |
| 1.5KE56A | 1N6289A | 40.20 | 44.70 | 49.40 | 1 | 64.8 | .101 |
| 1.5KE62 | 1N6290 | 41.30 | 45.90 | 56.10 | 1 | 73.5 | .102 |
| 1.5KE62A | 1N6290A | 43.60 | 48.50 | 53.60 | 1 | 70.1 | .102 |
| 1.5KE68 | 1N6291 | 45.40 | 50.40 | 61.60 | 1 | 80.5 | .103 |
| 1.5KE68A | 1N6291A | 47.80 | 53.20 | 58.80 | 1 | 77.0 | .103 |
| 1.5KE75 | 1N6292 | 50.20 | 55.80 | 69.20 | 1 | 89.0 | .104 |
| 1.5KE75A | 1N6292A | 53.00 | 58.90 | 65.10 | 1 | 85.0 | .104 |
| 1.5KE82 | 1N6293 | 55.10 | 61.20 | 74.80 | 1 | 98.0 | .104 |
| 1.5KE82A | 1N6293A | 58.10 | 64.60 | 71.40 | 1 | 92.0 | .104 |
| 1.5KE91 | 1N6294 | 60.70 | 67.50 | 82.50 | 1 | 108.9 | .105 |
| 1.5KE91A | 1N6294A | 64.10 | 71.30 | 78.80 | 1 | 103.0 | .105 |
| 1.5KE100 | 1N6295 | 66.40 | 73.80 | 90.20 | 1 | 118.0 | .105 |
| 1.5KE100A | 1N6295A | 69.70 | 77.20 | 86.10 | 1 | 113.0 | .105 |
| 1.5KE110 | 1N6296 | 73.70 | 81.90 | 100.00 | 1 | 131.0 | .106 |
| 1.5KE110A | 1N6296A | 77.80 | 86.50 | 95.50 | 1 | 125.0 | .106 |
| 1.5KE120 | 1N6297 | 81.00 | 90.00 | 110.00 | 1 | 144.0 | .106 |
| 1.5KE120A | 1N6297A | 85.50 | 95.00 | 105.00 | 1 | 137.0 | .107 |
| 1.5KE130 | 1N6298 | 89.20 | 99.00 | 121.00 | 1 | 158.0 | .107 |
| 1.5KE130A | 1N6298A | 94.00 | 105.00 | 116.00 | 1 | 152.0 | .107 |
| 1.5KE150 | 1N6299 | 97.20 | 108.00 | 132.00 | 1 | 173.0 | .107 |
| 1.5KE150A | 1N6299A | 102.00 | 114.00 | 126.00 | 1 | 165.0 | .107 |
| 1.5KE160 | 1N6300 | 105.00 | 117.00 | 143.00 | 1 | 187.0 | .107 |
| 1.5KE160A | 1N6300A | 111.00 | 124.00 | 137.00 | 1 | 179.0 | .107 |
| 1.5KE170 | 1N6301 | 121.00 | 135.00 | 165.00 | 1 | 215.0 | .108 |
| 1.5KE170A | 1N6301A | 128.00 | 143.00 | 156.00 | 1 | 207.0 | .108 |
| 1.5KE180 | 1N6302 | 130.00 | 144.00 | 176.00 | 1 | 230.0 | .108 |
| 1.5KE180A | 1N6302A | 136.00 | 152.00 | 168.00 | 1 | 219.0 | .108 |
| 1.5KE200 | 1N6303 | 138.00 | 153.00 | 187.00 | 1 | 244.0 | .108 |
| 1.5KE200A | 1N6303A | 145.00 | 162.00 | 178.00 | 1 | 234.0 | .108 |
| | | 146.00 | 162.00 | 198.00 | 1 | 258.0 | .108 |
| | | 154.00 | 171.00 | 189.00 | 1 | 246.0 | .108 |
| | | 162.00 | 180.00 | 220.00 | 1 | 287.0 | .108 |
| | | 171.00 | 190.00 | 210.00 | 1 | 274.0 | .108 |

V_f at 100 amps peak. mSEC sine wave equals 3.5 volts maximum.
For Bidirectional part number add C or CA as suffix (EG-1.5KE33C or 1.5KE33CA).

SYMBOLS AND ABBREVIATIONS

V_{WM} = RATED STANDOFF VOLTAGE
I_{PP} = PEAK PULSE CURRENT
P_{PP} = PEAK PULSE POWER
V_C (MAX) = MAXIMUM CLAMPING VOLTAGE
V_{BR} = BREAKDOWN VOLTAGE
I_T = TEST CURRENT
I_D = REVERSE LEAKAGE

NOTE 1 Normal selection criteria for TAZ devices is by rated stand-off voltage (V_{WM}) and should be equal or greater than DC or continuous peak operating voltage.

NOTE 2 TAZ devices are tested to maximum peak pulse current (I_{PP}) with clamping voltage monitored. This surge capability is one of the most significant electrical characteristics of the device and should be considered as part of customer quality inspections.

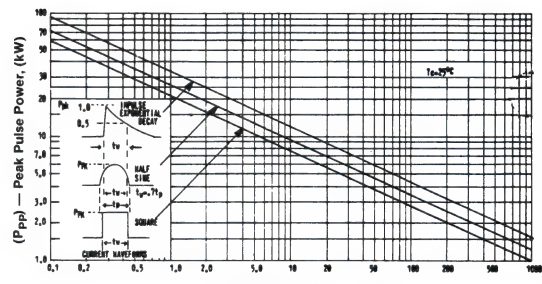


FIGURE 1
PEAK PULSE POWER VS. PULSE TIME

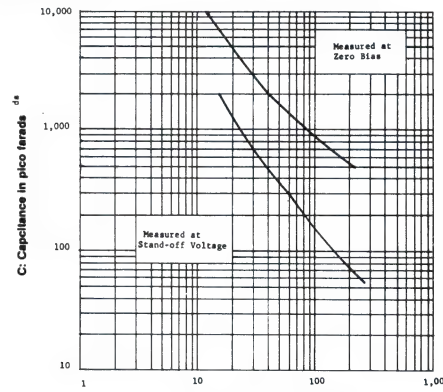


FIGURE 2
TYPICAL CAPACITANCE VS.
BREAKDOWN VOLTAGE

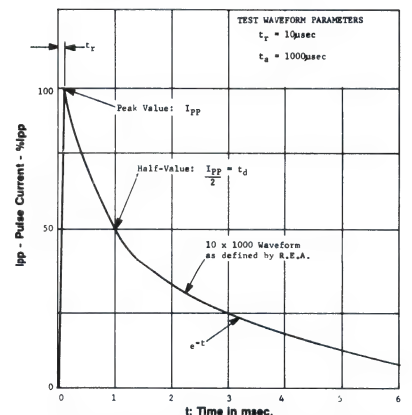


FIGURE 3 PULSE WAVE FORM

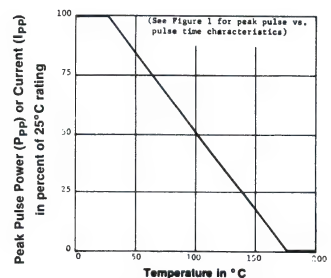


FIGURE 4 DERATING CURVE

micro

Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

**1N6356 thru
1N6372
and
MPT-5 thru
MPT-45C**

FEATURES

- DESIGNED TO PROTECT BIPOLAR AND MOS MICROPROCESSOR BASED SYSTEMS.
- VOLTAGE RANGE OF 5.0 TO 45 VOLTS
- LOW CLAMPING RATIO

MAXIMUM RATINGS

1500 Watts of Peak Pulse Power dissipation at 25°C
 t_{clamping} (0 volts to V_{BR} min): Unidirectional — Less than 1×10^{-12} seconds
 Bidirectional — Less than 5×10^{-9} seconds

Operating and Storage temperatures: -65° to +175°C
 Forward surge rating: 200 amps, 1/120 second at 25°C
 (Applies to Unipolar or single direction only)

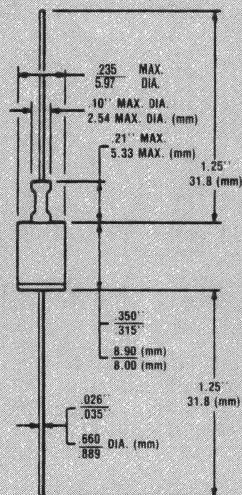
Steady State power dissipation: 1.0 watt
 Repetition rate (duty cycle): .01%

ELECTRICAL CHARACTERISTICS

Clamping Factor: 1.33 @ Full rated power
 1.20 @ 50% rated power

Clamping Factor: The ratio of the actual V_C (Clamping Voltage) to the actual V_{BR} (Breakdown Voltage) as measured on a specific device.

TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: DO-13 welded, hermetically sealed, metal and glass.

FINISH: All external surfaces are corrosion resistant and leads solderable.

POLARITY: Cathode connected to case and marked. Bidirectional not marked.

WEIGHT: 1.4 grams (Appx.)

MOUNTING POSITION: Any.

1N6356 thru 1N6372 and MPT-5 thru MPT-45C

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | STAND-OFF VOLTAGE (NOTE 1) V_{WM} VOLTS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_D μA | MINIMUM* BREAKDOWN VOLTAGE @ mA V_{BR} (min) VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) $I_{PP1} = 1A$ V_C VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ $I_{PP2} = 10A$ V_C VOLTS | MAXIMUM PEAK PULSE CURRENT I_{PP3} A |
|-----------------------------|---|---|---|---|--|--|
| MPT-5 | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| MPT-8 | 8.0 | 25 | 9.4 | 11.3 | 11.5 | 100 |
| MPT-10 | 10.0 | 2 | 11.7 | 13.7 | 14.1 | 90 |
| MPT-12 | 12.0 | 2 | 14.1 | 16.1 | 16.5 | 70 |
| MPT-15 | 15.0 | 2 | 17.6 | 20.1 | 20.6 | 60 |
| MPT-18 | 18.0 | 2 | 21.2 | 24.2 | 25.2 | 50 |
| MPT-22 | 22.0 | 2 | 25.9 | 29.8 | 32.0 | 40 |
| MPT-36 | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| MPT-45 | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

V_f at 100 amps peak, 8.3 msec sine wave equals 3.5 volts maximum

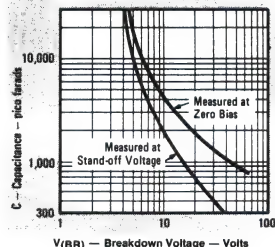
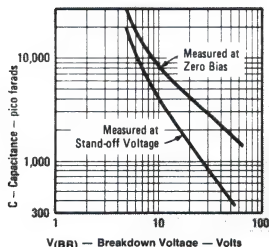
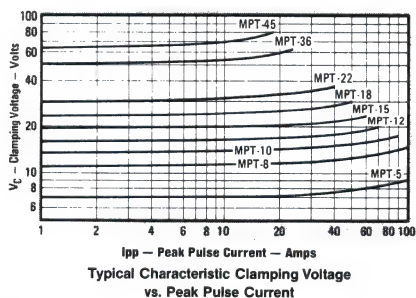
ELECTRICAL CHARACTERISTICS @ 25°C (Test Both Polarities)

| | | | | | | |
|---------|------|-----|------|------|------|-----|
| MPT-5C | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| MPT-8C | 8.0 | 25 | 9.4 | 11.4 | 11.6 | 100 |
| MPT-10C | 10.0 | 2 | 11.7 | 14.1 | 14.5 | 90 |
| MPT-12C | 12.0 | 2 | 14.1 | 16.7 | 17.1 | 70 |
| MPT-15C | 15.0 | 2 | 17.6 | 20.8 | 21.4 | 60 |
| MPT-18C | 18.0 | 2 | 21.2 | 24.8 | 25.5 | 50 |
| MPT-22C | 22.0 | 2 | 25.9 | 30.8 | 32.0 | 40 |
| MPT-36C | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| MPT-45C | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

C Suffix indicates Bidirectional

NOTE 1 TAZ are normally selected according to the reverse "Stand Off Voltage" (V_{WM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

*The minimum breakdown voltage as shown takes into consideration the ± 1 volt tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Similar devices are available with reduced clamping voltages where tighter regulated power supply voltages are employed.





Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300



IN6373 thru IN6389 and MPTE-5 thru MPTE-45C

FEATURES

- DESIGNED TO PROTECT BIPOLAR AND MOS MICROPROCESSOR BASED SYSTEMS FROM ELECTRICAL DISTURBANCES.
- TRANSIENT PROTECTION FOR CMOS, MOS, AND BIPOLAR MICROPROCESSORS
- VOLTAGE RANGE OF 5.0 TO 45 VOLTS
- LOW CLAMPING RATIO

MAXIMUM RATINGS

1500 Watts of Peak Pulse Power dissipation at 25°C

$t_{clamping}$ (0 volts to $V_{(BR)}$ min): Unidirectional—Less than 1×10^{-12} seconds

Bidirectional—Less than 5×10^{-9} seconds

Operating and Storage temperatures: -65° to +175°C

Forward surge rating: 200 amps, 1/120 second at 25°C

(Applies to Unidirectional or single direction only)

Steady State power dissipation: 5.0 watts @ $T_L = 75^\circ\text{C}$, Lead Length = 3/8"

Repetition rate (duty cycle): .05%

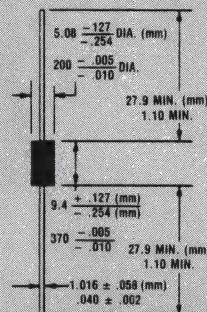
ELECTRICAL CHARACTERISTICS

Clamping Factor: 1.33 @ Full rated power

1.20 @ 50% rated power

Clamping Factor: The ratio of the actual V_C (Clamping Voltage) to the actual BV (Breakdown Voltage) as measured on a specific device.

TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: Void free transfer molded
thermosetting plastic

FINISH: Silver plated copper readily
solderable

POLARITY: Cathode marked with
band. No marking on bidirectional
types.

WEIGHT: 1.5 grams (Appx.)

MOUNTING POSITION: Any

1N6373 -1N6389 and MPTE - 5 thru MPTE -45C

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | STAND-OFF VOLTAGE (Note 1) V_{WM} VOLTS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_{o} μA | MINIMUM* BREAKDOWN VOLTAGE @ 1 mA $V_{(BR)}$ (min.) VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ $I_{PP1} = 1A$ V_C VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ $I_{PP2} = 10A$ V_C VOLTS | MAXIMUM PEAK PULSE CURRENT I_{PP3} A |
|-----------------------------|---|---|--|--|---|--|
| 1N6373 MPTE-5 | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| 1N6374 MPTE-8 | 8.0 | 25 | 9.4 | 11.3 | 11.5 | 100 |
| 1N6375 MPTE-10 | 10.0 | 2 | 11.7 | 13.7 | 14.1 | 90 |
| 1N6376 MPTE-12 | 12.0 | 2 | 14.1 | 16.1 | 16.5 | 70 |
| 1N6377 MPTE-15 | 15.0 | 2 | 17.6 | 20.1 | 20.6 | 60 |
| 1N6378 MPTE-18 | 18.0 | 2 | 21.2 | 24.2 | 25.2 | 50 |
| 1N6379 MPTE-22 | 22.0 | 2 | 25.9 | 29.8 | 32.0 | 40 |
| 1N6380 MPTE-36 | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| 1N6381 MPTE-45 | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

V_f at 100 amps peak, 8.3 msec sine wave equals 3.5 volts maximum

ELECTRICAL CHARACTERISTICS @ 25°C (Test Both Polarities)

| | | | | | | |
|-----------------|------|-----|------|------|------|-----|
| MPTE-5C | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| 1N6382 MPTE-8C | 8.0 | 25 | 9.4 | 11.4 | 11.6 | 100 |
| 1N6383 MPTE-10C | 10.0 | 2 | 11.7 | 14.1 | 14.5 | 90 |
| 1N6384 MPTE-12C | 12.0 | 2 | 14.1 | 16.7 | 17.1 | 70 |
| 1N6385 MPTE-15C | 15.0 | 2 | 17.6 | 20.8 | 21.4 | 60 |
| 1N6386 MPTE-18C | 18.0 | 2 | 21.2 | 24.8 | 25.5 | 50 |
| 1N6387 MPTE-22C | 22.0 | 2 | 25.9 | 30.8 | 32.0 | 40 |
| 1N6388 MPTE-36C | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| 1N6389 MPTE-45C | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

C Suffix indicates Bidirectional

NOTE 1: TAZ are normally selected according to the reverse "Stand Off Voltage" V_{WM} which should be equal to or greater than the DC or continuous peak operating voltage level.

*The minimum breakdown voltage as shown takes into consideration the ± 1 volt tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Similar devices are available with reduced clamping voltages where tighter regulated power supply voltages are employed.

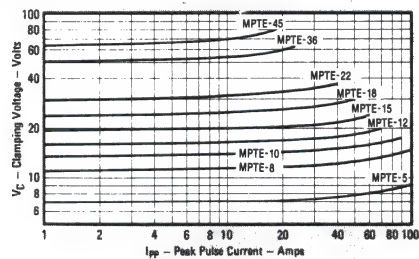


FIGURE 2
TYPICAL CHARACTERISTIC CLAMPING VOLTAGE
VS PEAK PULSE CURRENT

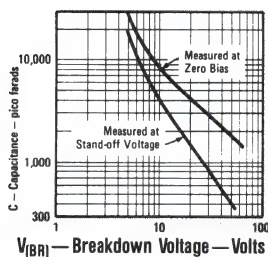


FIGURE 3
TYPICAL CAPACITANCE VS
BREAKDOWN VOLTAGE
(UNIDIRECTIONAL TYPES)

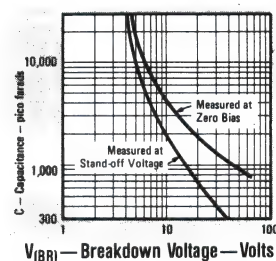


FIGURE 4
TYPICAL CAPACITANCE VS
BREAKDOWN VOLTAGE
(BIDIRECTIONAL TYPES)

IN6461 thru IN6468 and IN6469 thru IN6476

FEATURES

- HIGH SURGE CAPACITY PROVIDES TRANSIENT PROTECTION FOR MOST CRITICAL CIRCUITS.
- TRIPLE LAYER PASSIVATION.
- SUBMINIATURE.
- METALLURGICALLY BONDED.
- VOIDLESS HERMETICALLY SEALED GLASS PACKAGE.
- DYNAMIC IMPEDANCE AND REVERSE LEAKAGE LOWEST AVAILABLE.
- JAN/TX/TXV TYPES AVAILABLE PER MIL-S-19500/551, 552.

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C.

Storage Temperature: -65°C to +200°C.

Surge Power 500W & 1500W

Power @ TA = 25°C (%) 2.5W 500W Type

Power @ TL = 50°C (%) 5.0W 1500W Type

ELECTRICAL CHARACTERISTICS

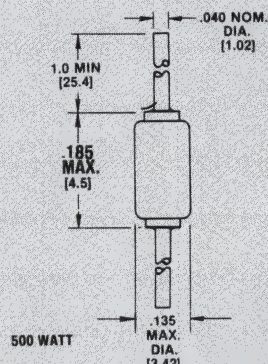
| SERIES TYPE | | BREAK DOWN VOLTAGE V _(BR) MIN. | TEST CURRENT I _T | | WORKING PEAK VOLTAGE V _{WM} | MAX LEAKAGE CURRENT I ₀ | | MAX CLAMPING VOLTAGE V _C | MAX PEAK PULSE CURRENT (I _{PP}) | | MAX. TEMP. COEF. OF V _(BR) |
|-------------|--------|---|-----------------------------|----|--------------------------------------|------------------------------------|------|-------------------------------------|---|-------|---------------------------------------|
| 500W | 1500W | Vdc | mAdc | | Vdc | μAdc | μAdc | V(pk) | A(pk) | A(pk) | %/°C |
| IN6461 | IN6469 | 5.8 | 25 | 50 | 5 | 3000 | 5000 | 9.0 | 56 | 167 | 0.04 |
| IN6462 | IN6470 | 8.5 | 20 | 50 | 6 | 2500 | 5000 | 11.0 | 46 | 137 | 0.04 |
| IN6463 | IN6471 | 13.0 | 5 | 10 | 12 | 500 | 1000 | 22.6 | 22 | 66 | 0.05 |
| IN6464 | IN6472 | 16.4 | 5 | 10 | 15 | 500 | 1000 | 26.5 | 19 | 57 | 0.06 |
| IN6465 | IN6473 | 27.0 | 2 | 5 | 24 | 50 | 100 | 41.4 | 12 | 36.5 | .084 |
| IN6466 | IN6474 | 33.0 | 1 | 1 | 30.5 | 3 | 5 | 47.5 | 11 | 32 | .093 |
| IN6467 | IN6475 | 43.7 | 1 | 1 | 40.3 | 2 | 5 | 63.5 | 8 | 24 | .094 |
| IN6468 | IN6476 | 54.0 | 1 | 1 | 51.6 | 2 | 5 | 78.5 | 6 | 19 | .096 |
| NOTES | | 1 | 2 | 3 | 1 | 2 | 3 | 1 | 2 | 3 | 1 |

NOTE 1: Applies to both 500W and 1500W series.

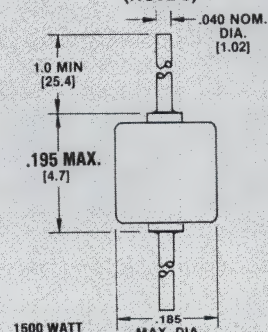
NOTE 2: Applies to only 500W series.

NOTE 3: Applies to only 1500W series.

TRANSIENT SUPPRESSORS



**FIGURE 1
(NOTE 3)**



**FIGURE 1
(NOTE 2)**

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case.

LEAD MATERIAL: Tinned copper or silver clad copper.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.

1N6461 thru 1N6468 & 1N6469 thru 1N6476

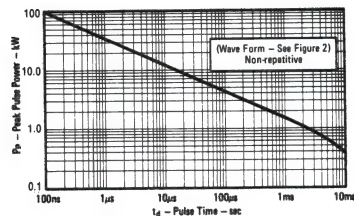


Figure 1. Pulse Time
1N6469 Series

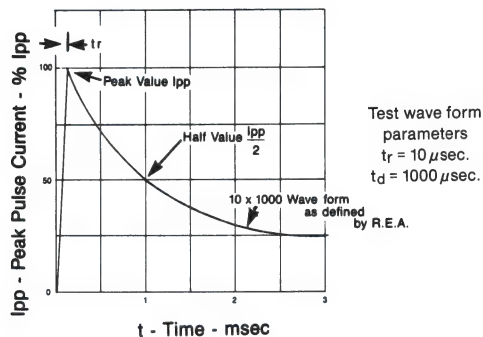


Figure 2. Current Impulse Waveform

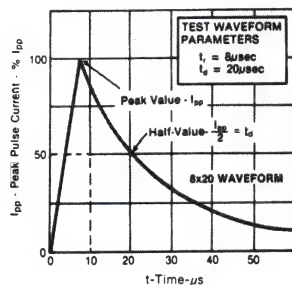


Figure 3. Current Impulse Waveform

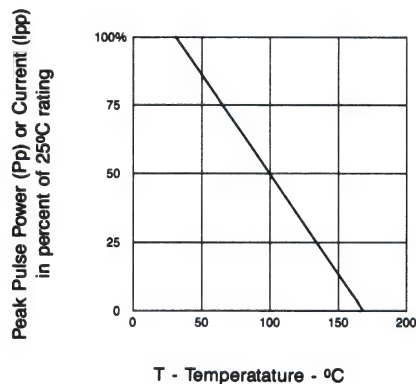


Figure 4. Derating Curve

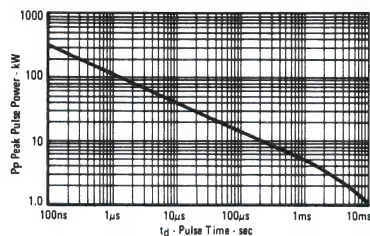


Figure 5. Pulse Waveform
1N6461 Series

FEATURES

- AVAILABLE IN RANGES FROM 5.0 TO 170 VOLTS
- AVAILABLE IN BIDIRECTIONAL FOR AC APPLICATIONS
- LOW CLAMPING RATIO
- SMALL PACKAGE SIZE

As a low cost, 1,000 watt commercial and industrial component, this TAZ series is used in applications where space is a premium and where large voltage transients can permanently damage voltage-sensitive components.

This TAZ has a peak pulse power rating of 1,000 watts for one millisecond. The response time of TAZ clamping action is theoretically instantaneous (1×10^{-12} sec); therefore, they can protect integrated circuits, MOS devices, hybrids, and other voltage-sensitive semiconductors and components. TAZ can also be used in series or parallel to increase the peak power ratings.

MAXIMUM RATINGS

1000 Watts of Peak Pulse Power dissipation at 25°C (see derating curve)
telamping (0 Volts to BV Min.):

Unidirectional $< 1 \times 10^{-12}$ Seconds; Bidirectional $< 5 \times 10^{-9}$ Seconds (theoretical).

Operating and Storage temperatures: -55° to +175°C

Forward surge rating: 133 amps, 8.3 msec at 25°C (except Bidirectional)

Steady State power dissipation: 5.0 watt $T_L = 75^\circ\text{C}$, Lead Length = 3/8"

Repetition rate (duty cycle): .05%

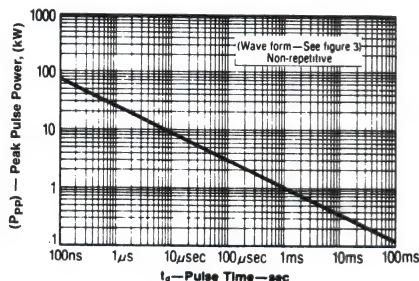


FIGURE 1 PEAK PULSE POWER VS PULSE TIME

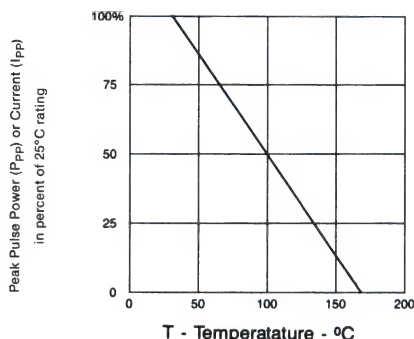
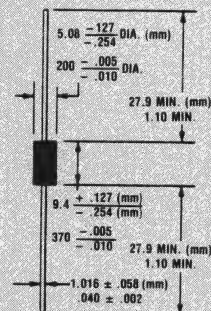


FIGURE 2 DERATING CURVE

TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: Molded case

FINISH: Silver-plated copper,
readily solderable

POLARITY: Cathode terminal
marked with band (except bi-
directional)

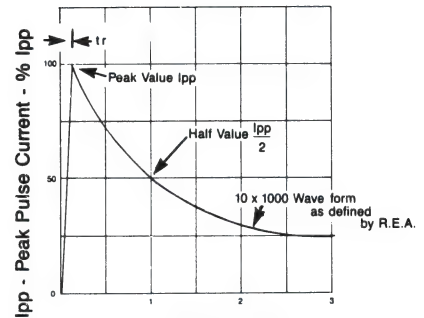
WEIGHT: 1.5 grams (Appx.)

MOUNTING POSITION: Any

1.0KE5 thru 1.0KE170A

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE (NOTE 1) V _{WM} VOLTS | BREAKDOWN VOLTAGE V _{BR} VOLTS @ | | I _B mA | MAXIMUM REVERSE LEAKAGE V _{WM} (NOTE 2) μA | MAXIMUM CLAMPING VOLTAGE V _{CL} (FIG. 3) VOLTS | MAXIMUM PEAK PULSE CURRENT I _{PP} A (FIG. 3) | MAXIMUM VOLTAGE TEMPERATURE VARIATION OF V _{BR} mV/°C |
|-----------------------------|---|--|-------|----------------------|--|--|---|---|
| | | MIN. | MAX. | | | | | |
| 1.0KE5.0 | 5.0 | 6.40 | 7.00 | 10 | 1000 | 9.5 | 104.0 | 5.0 |
| 1.0KE5.0A | 5.0 | 6.40 | 7.00 | 10 | 1000 | 9.2 | 109.0 | 5.0 |
| 1.0KE6.0 | 6.0 | 6.67 | 8.15 | 10 | 1000 | 11.4 | 87.7 | 5.0 |
| 1.0KE6.0A | 6.0 | 6.67 | 8.15 | 10 | 1000 | 10.3 | 97.0 | 5.0 |
| 1.0KE6.5 | 6.5 | 7.22 | 8.82 | 10 | 500 | 12.3 | 81.3 | 5.0 |
| 1.0KE6.5A | 6.5 | 7.22 | 7.96 | 10 | 500 | 11.2 | 88.3 | 5.0 |
| 1.0KE7.0 | 7.0 | 7.78 | 9.51 | 10 | 200 | 13.3 | 73.2 | 5.0 |
| 1.0KE7.0A | 7.0 | 7.78 | 8.90 | 10 | 200 | 12.0 | 83.3 | 5.0 |
| 1.0KE7.5 | 7.5 | 8.33 | 10.2 | 1 | 100 | 14.3 | 69.9 | 7.0 |
| 1.0KE7.5A | 7.5 | 8.33 | 9.21 | 1 | 100 | 12.9 | 77.5 | 7.0 |
| 1.0KE8.0 | 8.0 | 8.89 | 10.9 | 1 | 50 | 15.0 | 66.3 | 7.0 |
| 1.0KE8.0A | 8.0 | 8.89 | 9.83 | 1 | 50 | 13.6 | 73.5 | 7.0 |
| 1.0KE8.5 | 8.5 | 9.44 | 11.5 | 1 | 25 | 15.9 | 62.9 | 8.0 |
| 1.0KE8.5A | 8.5 | 9.44 | 10.4 | 1 | 25 | 14.4 | 68.4 | 8.0 |
| 1.0KE9.0 | 9.0 | 10.0 | 12.2 | 1 | 10 | 16.9 | 59.2 | 9.0 |
| 1.0KE9.0A | 9.0 | 10.0 | 11.1 | 1 | 10 | 15.4 | 64.9 | 9.0 |
| 1.0KE10 | 10 | 11.1 | 13.6 | 1 | 5 | 18.8 | 53.3 | 10 |
| 1.0KE10A | 10 | 11.1 | 12.3 | 1 | 5 | 17.0 | 58.8 | 10 |
| 1.0KE11 | 11 | 12.2 | 14.8 | 1 | 5 | 20.1 | 48.8 | 11 |
| 1.0KE11A | 11 | 12.2 | 13.5 | 1 | 5 | 18.2 | 54.9 | 11 |
| 1.0KE12 | 12 | 13.3 | 16.3 | 1 | 5 | 22.0 | 45.5 | 12 |
| 1.0KE12A | 12 | 13.3 | 14.7 | 1 | 5 | 19.9 | 50.3 | 12 |
| 1.0KE13 | 13 | 14.4 | 17.8 | 1 | 5 | 23.8 | 42.0 | 13 |
| 1.0KE13A | 13 | 14.4 | 15.9 | 1 | 5 | 21.5 | 46.5 | 13 |
| 1.0KE14 | 14 | 15.5 | 19.1 | 1 | 5 | 25.6 | 38.8 | 14 |
| 1.0KE14A | 14 | 15.5 | 17.2 | 1 | 5 | 23.2 | 43.1 | 14 |
| 1.0KE15 | 15 | 16.7 | 20.4 | 1 | 5 | 29.9 | 37.2 | 15 |
| 1.0KE15A | 15 | 16.7 | 18.5 | 1 | 5 | 24.4 | 41.0 | 15 |
| 1.0KE16 | 16 | 17.8 | 21.8 | 1 | 5 | 28.8 | 34.7 | 16 |
| 1.0KE16A | 16 | 17.8 | 19.7 | 1 | 5 | 26.0 | 38.5 | 16 |
| 1.0KE17 | 17 | 18.9 | 23.1 | 1 | 5 | 30.5 | 32.3 | 20 |
| 1.0KE17A | 17 | 18.9 | 20.9 | 1 | 5 | 27.8 | 36.2 | 19 |
| 1.0KE18 | 18 | 20.0 | 24.4 | 1 | 5 | 32.2 | 31.1 | 21 |
| 1.0KE18A | 18 | 20.0 | 22.1 | 1 | 5 | 29.2 | 34.2 | 20 |
| 1.0KE20 | 20 | 22.2 | 27.1 | 1 | 5 | 35.8 | 27.9 | 25 |
| 1.0KE20A | 20 | 22.2 | 24.5 | 1 | 5 | 32.4 | 30.9 | 23 |
| 1.0KE22 | 22 | 24.4 | 29.8 | 1 | 5 | 39.4 | 25.4 | 28 |
| 1.0KE22A | 22 | 24.4 | 26.9 | 1 | 5 | 35.5 | 28.2 | 25 |
| 1.0KE24 | 24 | 26.7 | 32.8 | 1 | 5 | 43.0 | 23.3 | 31 |
| 1.0KE24A | 24 | 26.7 | 29.5 | 1 | 5 | 38.9 | 25.7 | 28 |
| 1.0KE26 | 26 | 28.9 | 35.3 | 1 | 5 | 48.9 | 21.5 | 31 |
| 1.0KE26A | 26 | 28.9 | 31.5 | 1 | 5 | 42.1 | 23.8 | 30 |
| 1.0KE28 | 28 | 31.1 | 38.0 | 1 | 5 | 50.0 | 20.0 | 35 |
| 1.0KE28A | 28 | 31.1 | 34.4 | 1 | 5 | 45.4 | 22.0 | 31 |
| 1.0KE30 | 30 | 33.3 | 40.7 | 1 | 5 | 53.5 | 18.7 | 39 |
| 1.0KE30A | 30 | 33.3 | 36.8 | 1 | 5 | 48.4 | 20.6 | 36 |
| 1.0KE33 | 33 | 36.7 | 44.9 | 1 | 5 | 60.0 | 17.0 | 45 |
| 1.0KE33A | 33 | 36.7 | 40.6 | 1 | 5 | 53.3 | 18.8 | 41 |
| 1.0KE36 | 36 | 40.0 | 48.9 | 1 | 5 | 64.3 | 15.6 | 49 |
| 1.0KE36A | 36 | 40.0 | 44.2 | 1 | 5 | 58.1 | 17.2 | 45 |
| 1.0KE40 | 40 | 44.4 | 54.3 | 1 | 5 | 71.4 | 14.0 | 55 |
| 1.0KE40A | 40 | 44.4 | 48.1 | 1 | 5 | 64.5 | 15.5 | 50 |
| 1.0KE43 | 43 | 47.8 | 58.4 | 1 | 5 | 76.7 | 13.0 | 60 |
| 1.0KE43A | 43 | 47.8 | 52.8 | 1 | 5 | 69.4 | 14.4 | 54 |
| 1.0KE45 | 45 | 50.0 | 61.1 | 1 | 5 | 80.3 | 12.5 | 63 |
| 1.0KE45A | 45 | 50.0 | 55.3 | 1 | 5 | 72.7 | 13.8 | 57 |
| 1.0KE48 | 48 | 53.3 | 65.1 | 1 | 5 | 85.5 | 11.7 | 68 |
| 1.0KE48A | 48 | 53.3 | 58.9 | 1 | 5 | 77.4 | 12.9 | 61 |
| 1.0KE51 | 51 | 56.7 | 69.3 | 1 | 5 | 91.1 | 11.0 | 72 |
| 1.0KE51A | 51 | 56.7 | 62.7 | 1 | 5 | 82.4 | 12.1 | 66 |
| 1.0KE54 | 54 | 60.0 | 73.3 | 1 | 5 | 96.3 | 10.4 | 76 |
| 1.0KE54A | 54 | 60.0 | 66.3 | 1 | 5 | 87.1 | 11.5 | 69 |
| 1.0KE58 | 58 | 64.4 | 78.7 | 1 | 5 | 103.0 | 9.7 | 83 |
| 1.0KE58A | 58 | 64.4 | 71.2 | 1 | 5 | 93.8 | 10.7 | 74 |
| 1.0KE60 | 60 | 66.7 | 81.5 | 1 | 5 | 107.0 | 9.3 | 86 |
| 1.0KE60A | 60 | 66.7 | 73.7 | 1 | 5 | 96.9 | 10.3 | 77 |
| 1.0KE64 | 64 | 71.1 | 86.9 | 1 | 5 | 114.0 | 8.8 | 91 |
| 1.0KE64A | 64 | 71.1 | 78.6 | 1 | 5 | 103.0 | 9.7 | 82 |
| 1.0KE70 | 70 | 77.8 | 95.1 | 1 | 5 | 125 | 8.0 | 100 |
| 1.0KE70A | 70 | 77.8 | 86.0 | 1 | 5 | 113 | 8.8 | 90 |
| 1.0KE75 | 75 | 83.3 | 102.0 | 1 | 5 | 134 | 7.5 | 108 |
| 1.0KE75A | 75 | 83.3 | 92.1 | 1 | 5 | 121 | 8.3 | 97 |
| 1.0KE78 | 78 | 86.7 | 106.0 | 1 | 5 | 139 | 7.2 | 112 |
| 1.0KE78A | 78 | 86.7 | 95.8 | 1 | 5 | 126 | 7.8 | 102 |
| 1.0KE85 | 85 | 94.4 | 115.0 | 1 | 5 | 151 | 6.8 | 123 |
| 1.0KE85A | 85 | 94.4 | 104.0 | 1 | 5 | 137 | 7.3 | 110 |
| 1.0KE90 | 90 | 100 | 122 | 1 | 5 | 160 | 6.3 | 130 |
| 1.0KE90A | 90 | 100 | 111 | 1 | 5 | 146 | 6.8 | 118 |
| 1.0KE100 | 100 | 111 | 136 | 1 | 5 | 179 | 5.8 | 146 |
| 1.0KE100A | 100 | 111 | 123 | 1 | 5 | 162 | 6.2 | 132 |
| 1.0KE110 | 110 | 122 | 149 | 1 | 5 | 196 | 5.1 | 159 |
| 1.0KE110A | 110 | 122 | 135 | 1 | 5 | 177 | 5.7 | 144 |
| 1.0KE120 | 120 | 133 | 163 | 1 | 5 | 214 | 4.7 | 178 |
| 1.0KE120A | 120 | 133 | 147 | 1 | 5 | 193 | 5.2 | 157 |
| 1.0KE130 | 130 | 144 | 175 | 1 | 5 | 231 | 4.3 | 190 |
| 1.0KE130A | 130 | 144 | 159 | 1 | 5 | 209 | 4.8 | 172 |
| 1.0KE150 | 150 | 167 | 204 | 1 | 5 | 268 | 3.7 | 220 |
| 1.0KE150A | 150 | 167 | 185 | 1 | 5 | 243 | 4.1 | 200 |
| 1.0KE160 | 160 | 178 | 218 | 1 | 5 | 287 | 3.5 | 235 |
| 1.0KE160A | 160 | 178 | 197 | 1 | 5 | 259 | 3.9 | 213 |
| 1.0KE170 | 170 | 189 | 231 | 1 | 5 | 304 | 3.3 | 254 |
| 1.0KE170A | 170 | 189 | 209 | 1 | 5 | 275 | 3.6 | 226 |



t - Time - msec
Test wave form
parameters
t_r = 10 μsec
t_d = 1000 μsec

FIGURE 3
PULSE WAVEFORM

V_f at 65 amps peak, 8.5 msec sine wave equals 3.5 volts maximum (except bidirectional).
For Bidirectional Applications — use C or CA suffix for types 1.0KE6.5 through 1.0KE170.

NOTE 1: A TAZ is normally selected according to the reverse "Stand Off Voltage" (V_{WM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

micro

Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

**1.2KE5
thru
1.2KE170A**

TAZ

FEATURES

- AVAILABLE IN RANGES FROM 5.0 TO 170 VOLTS
- AVAILABLE IN BIDIRECTIONAL FOR AC APPLICATIONS
- LOW CLAMPING RATIO
- SMALL PACKAGE SIZE

As a low cost, 1,200 watt commercial and industrial device, this TAZ is used in applications where space is at a premium and where large voltage transients can permanently damage voltage-sensitive components.

This TAZ has a peak pulse power rating of 1,200 watts for one millisecond. The response time of TAZ clamping action is theoretically instantaneous (1×10^{-12} sec); therefore, they can protect integrated circuits, MOS devices, hybrids, and other voltage-sensitive semiconductors and components. TAZ can also be used in series or parallel to increase the peak power ratings.

MAXIMUM RATINGS

1,200 Watts of Peak Pulse Power dissipation at 25°C (see derating curve)

t_{clamping} (0 Volts to BV Min.):

Unidirectional $< 1 \times 10^{-12}$ Seconds; Bidirectional $< 5 \times 10^{-9}$ Seconds.

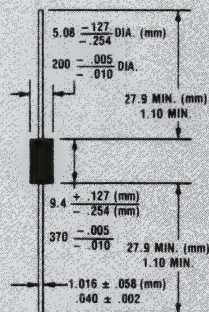
Operating and Storage temperatures: -55° to +175°C

Forward surge rating: 160 amps, 8.3 msec at 25°C (except Bipolar)

Steady State power dissipation: 5.0 watt $T_L = 75^\circ\text{C}$, Lead Length = 3/8"

Repetition rate (duty cycle): .05%

TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: Molded case.

FINISH: Silverplated copper, readily solderable.

POLARITY: Cathode terminal marked with a band (except bidirectional types).

WEIGHT: 1.5 grams (Appx.).

MOUNTING POSITION: Any.

1.2KE5 thru 1.2KE170A

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE (NOTE 1) V _{WM} VOLTS | BREAKDOWN VOLTAGE V _{WM} VOLTS @ | | I ₀ mA | MAXIMUM REVERSE LEAKAGE I _{WM} μA | MAXIMUM CLAMPING VOLTAGE @ I _{PP} (FIG. 3) V _C VOLTS | MAXIMUM PEAK PULSE CURRENT (FIG. 3) I _{PP} A | MAXIMUM VOLTAGE TEMPERATURE VARIATION OF V _{WM} mV/°C |
|-----------------------------|---|--|-------|----------------------|--|--|---|---|
| | | MIN. | MAX. | | | | | |
| 1.2KE5.0 | 5.0 | 6.40 | 7.30 | 10 | 1000 | 9.6 | 125.0 | 5.0 |
| 1.2KE5.0A | 5.0 | 6.40 | 7.00 | 10 | 1000 | 9.2 | 130.0 | 5.0 |
| 1.2KE6.0 | 6.0 | 6.67 | 8.15 | 10 | 1000 | 11.4 | 105.0 | 5.0 |
| 1.2KE6.0A | 6.0 | 6.67 | 7.37 | 10 | 1000 | 10.3 | 117.0 | 5.0 |
| 1.2KE6.5 | 6.5 | 7.22 | 8.82 | 10 | 500 | 12.3 | 97.8 | 5.0 |
| 1.2KE6.5A | 6.5 | 7.22 | 7.96 | 10 | 500 | 11.2 | 107.0 | 5.0 |
| 1.2KE7.0 | 7.0 | 7.78 | 9.51 | 10 | 200 | 13.3 | 90.2 | 6.0 |
| 1.2KE7.0A | 7.0 | 7.78 | 8.60 | 10 | 200 | 12.0 | 100.0 | 6.0 |
| 1.2KE7.5 | 7.5 | 8.33 | 10.2 | 1 | 100 | 14.3 | 83.9 | 7.0 |
| 1.2KE7.5A | 7.5 | 8.33 | 9.21 | 1 | 100 | 12.9 | 93.0 | 7.0 |
| 1.2KE8.0 | 8.0 | 8.89 | 10.9 | 1 | 50 | 15.0 | 80.0 | 7.0 |
| 1.2KE8.0A | 8.0 | 8.89 | 9.83 | 1 | 50 | 13.6 | 88.2 | 7.0 |
| 1.2KE8.5 | 8.5 | 9.44 | 11.5 | 1 | 25 | 15.9 | 75.5 | 8.0 |
| 1.2KE8.5A | 8.5 | 9.44 | 10.4 | 1 | 25 | 14.4 | 83.3 | 8.0 |
| 1.2KE9.0 | 9.0 | 10.0 | 12.2 | 1 | 10 | 16.9 | 71.9 | 9.0 |
| 1.2KE9.0A | 9.0 | 10.0 | 11.1 | 1 | 10 | 15.4 | 78.0 | 9.0 |
| 1.2KE10 | 10 | 11.1 | 13.6 | 1 | 5 | 18.8 | 63.8 | 10 |
| 1.2KE10A | 10 | 11.1 | 12.3 | 1 | 5 | 17.0 | 70.6 | 10 |
| 1.2KE11 | 11 | 12.2 | 14.9 | 1 | 5 | 20.1 | 59.7 | 11 |
| 1.2KE11A | 11 | 12.2 | 13.5 | 1 | 5 | 18.2 | 65.9 | 11 |
| 1.2KE12 | 12 | 13.3 | 16.3 | 1 | 5 | 22.0 | 54.5 | 12 |
| 1.2KE12A | 12 | 13.3 | 14.7 | 1 | 5 | 19.9 | 60.3 | 12 |
| 1.2KE13 | 13 | 14.4 | 17.6 | 1 | 5 | 23.8 | 50.4 | 13 |
| 1.2KE13A | 13 | 14.4 | 15.9 | 1 | 5 | 21.5 | 55.8 | 13 |
| 1.2KE14 | 14 | 15.6 | 19.1 | 1 | 5 | 25.8 | 45.5 | 14 |
| 1.2KE14A | 14 | 15.6 | 17.2 | 1 | 5 | 23.2 | 51.7 | 14 |
| 1.2KE15 | 15 | 16.7 | 20.4 | 1 | 5 | 26.9 | 44.6 | 16 |
| 1.2KE15A | 15 | 16.7 | 18.5 | 1 | 5 | 24.4 | 49.2 | 16 |
| 1.2KE16 | 16 | 17.8 | 21.6 | 1 | 5 | 28.8 | 41.7 | 19 |
| 1.2KE16A | 16 | 17.8 | 19.7 | 1 | 5 | 26.0 | 46.2 | 17 |
| 1.2KE17 | 17 | 18.9 | 23.1 | 1 | 5 | 30.3 | 39.3 | 20 |
| 1.2KE17A | 17 | 18.9 | 20.9 | 1 | 5 | 27.8 | 43.5 | 19 |
| 1.2KE18 | 18 | 20.0 | 24.4 | 1 | 5 | 32.2 | 37.3 | 21 |
| 1.2KE18A | 18 | 20.0 | 22.1 | 1 | 5 | 29.2 | 41.1 | 20 |
| 1.2KE20 | 20 | 22.2 | 27.1 | 1 | 5 | 35.8 | 33.5 | 25 |
| 1.2KE20A | 20 | 22.2 | 24.5 | 1 | 5 | 32.4 | 37.0 | 23 |
| 1.2KE22 | 22 | 24.4 | 29.8 | 1 | 5 | 39.4 | 30.5 | 28 |
| 1.2KE22A | 22 | 24.4 | 26.9 | 1 | 5 | 35.5 | 33.8 | 25 |
| 1.2KE24 | 24 | 26.7 | 32.6 | 1 | 5 | 43.0 | 27.9 | 31 |
| 1.2KE24A | 24 | 26.7 | 29.5 | 1 | 5 | 39.9 | 30.8 | 28 |
| 1.2KE26 | 26 | 28.9 | 35.3 | 1 | 5 | 46.8 | 25.8 | 31 |
| 1.2KE26A | 26 | 28.9 | 31.9 | 1 | 5 | 42.1 | 28.9 | 30 |
| 1.2KE28 | 28 | 31.1 | 36.0 | 1 | 5 | 50.0 | 24.0 | 35 |
| 1.2KE28A | 28 | 31.1 | 34.4 | 1 | 5 | 45.4 | 26.4 | 31 |
| 1.2KE30 | 30 | 33.3 | 40.7 | 1 | 5 | 53.5 | 22.4 | 39 |
| 1.2KE30A | 30 | 33.3 | 36.8 | 1 | 5 | 48.4 | 24.6 | 36 |
| 1.2KE33 | 33 | 36.7 | 44.9 | 1 | 5 | 59.0 | 20.3 | 45 |
| 1.2KE33A | 33 | 36.7 | 40.6 | 1 | 5 | 53.3 | 22.5 | 41 |
| 1.2KE36 | 36 | 40.0 | 48.9 | 1 | 5 | 64.3 | 18.7 | 49 |
| 1.2KE36A | 36 | 40.0 | 44.2 | 1 | 5 | 58.1 | 20.7 | 45 |
| 1.2KE40 | 40 | 44.4 | 54.3 | 1 | 5 | 71.4 | 16.8 | 55 |
| 1.2KE40A | 40 | 44.4 | 49.1 | 1 | 5 | 64.5 | 18.8 | 50 |
| 1.2KE43 | 43 | 47.8 | 58.4 | 1 | 5 | 76.7 | 15.8 | 60 |
| 1.2KE43A | 43 | 47.8 | 52.8 | 1 | 5 | 69.4 | 17.3 | 54 |
| 1.2KE45 | 45 | 50.0 | 61.1 | 1 | 5 | 80.3 | 14.9 | 63 |
| 1.2KE45A | 45 | 50.0 | 55.3 | 1 | 5 | 72.7 | 16.5 | 57 |
| 1.2KE48 | 48 | 53.3 | 65.1 | 1 | 5 | 85.5 | 14.0 | 68 |
| 1.2KE48A | 48 | 53.3 | 58.9 | 1 | 5 | 77.4 | 15.5 | 61 |
| 1.2KE51 | 51 | 56.7 | 69.3 | 1 | 5 | 91.1 | 13.2 | 72 |
| 1.2KE51A | 51 | 56.7 | 62.7 | 1 | 5 | 82.4 | 14.6 | 65 |
| 1.2KE54 | 54 | 60.0 | 73.3 | 1 | 5 | 96.3 | 12.5 | 76 |
| 1.2KE54A | 54 | 60.0 | 66.3 | 1 | 5 | 87.1 | 13.8 | 69 |
| 1.2KE58 | 58 | 64.4 | 78.7 | 1 | 5 | 103.0 | 11.7 | 83 |
| 1.2KE58A | 58 | 64.4 | 71.2 | 1 | 5 | 93.6 | 12.8 | 74 |
| 1.2KE60 | 60 | 66.7 | 81.5 | 1 | 5 | 107.0 | 11.2 | 86 |
| 1.2KE60A | 60 | 66.7 | 73.7 | 1 | 5 | 96.8 | 12.4 | 77 |
| 1.2KE64 | 64 | 71.1 | 86.9 | 1 | 5 | 114.0 | 10.5 | 91 |
| 1.2KE64A | 64 | 71.1 | 78.9 | 1 | 5 | 103.0 | 11.6 | 82 |
| 1.2KE70 | 70 | 77.8 | 95.1 | 1 | 5 | 125 | 9.8 | 100 |
| 1.2KE70A | 70 | 77.8 | 86.0 | 1 | 5 | 113 | 10.6 | 90 |
| 1.2KE75 | 75 | 83.3 | 102.0 | 1 | 5 | 134 | 8.9 | 108 |
| 1.2KE75A | 75 | 83.3 | 92.1 | 1 | 5 | 121 | 9.9 | 97 |
| 1.2KE78 | 78 | 86.7 | 106.0 | 1 | 5 | 139 | 8.5 | 112 |
| 1.2KE78A | 78 | 86.7 | 95.8 | 1 | 5 | 128 | 9.5 | 102 |
| 1.2KE85 | 85 | 94.4 | 115.0 | 1 | 5 | 151 | 7.9 | 123 |
| 1.2KE85A | 85 | 94.4 | 104.0 | 1 | 5 | 137 | 8.8 | 110 |
| 1.2KE90 | 90 | 100 | 122 | 1 | 6 | 160 | 7.5 | 130 |
| 1.2KE90A | 90 | 111 | 111 | 1 | 5 | 146 | 8.2 | 118 |
| 1.2KE100 | 100 | 111 | 136 | 1 | 5 | 179 | 6.7 | 145 |
| 1.2KE100A | 100 | 111 | 123 | 1 | 5 | 162 | 7.4 | 132 |
| 1.2KE110 | 110 | 122 | 148 | 1 | 5 | 196 | 6.1 | 159 |
| 1.2KE110A | 110 | 122 | 135 | 1 | 5 | 177 | 6.8 | 144 |
| 1.2KE120 | 120 | 133 | 163 | 1 | 5 | 214 | 5.6 | 176 |
| 1.2KE120A | 120 | 133 | 147 | 1 | 5 | 193 | 6.2 | 157 |
| 1.2KE130 | 130 | 144 | 176 | 1 | 5 | 231 | 5.2 | 190 |
| 1.2KE130A | 130 | 144 | 159 | 1 | 5 | 209 | 5.7 | 172 |
| 1.2KE150 | 150 | 167 | 204 | 1 | 5 | 286 | 4.3 | 220 |
| 1.2KE150A | 150 | 167 | 185 | 1 | 5 | 243 | 4.95 | 200 |
| 1.2KE160 | 160 | 178 | 218 | 1 | 5 | 287 | 4.2 | 235 |
| 1.2KE160A | 160 | 178 | 197 | 1 | 5 | 259 | 4.6 | 213 |
| 1.2KE170 | 170 | 189 | 231 | 1 | 5 | 304 | 3.9 | 254 |
| 1.2KE170A | 170 | 189 | 208 | 1 | 5 | 275 | 4.4 | 228 |

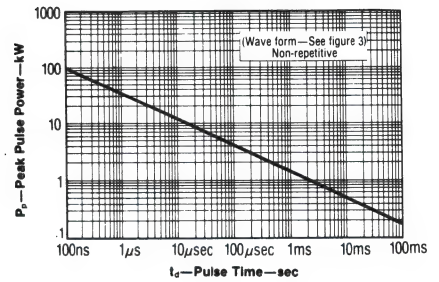


FIGURE 1
Peak Pulse Power vs. Pulse Time

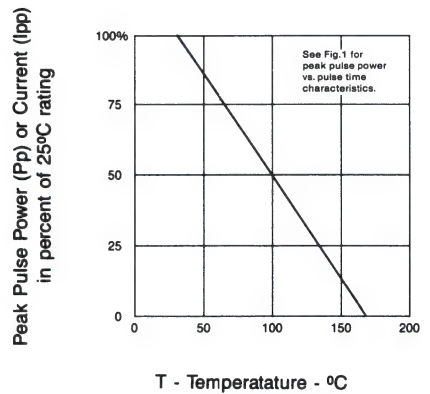


FIGURE 2
Derating Curve

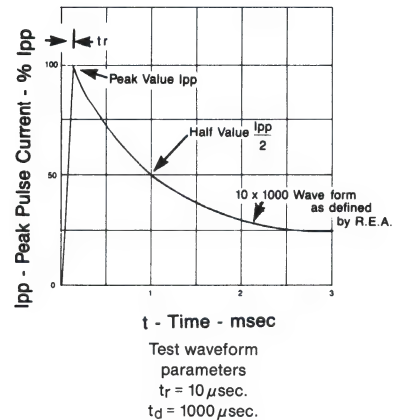


FIGURE 3
PULSE WAVEFORM

V_f at 80 amps peak, 8.3 msec sine wave equals 3.5 volts maximum (except bidirectional).
For Bidirectional Applications—use C or CA suffix for types 1.2KE6.5 through 1.2KE170.

NOTE 1: A TAZ is normally selected according to the reverse "Stand Off Voltage" (V_{WM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

FEATURES

Designed for use on the output of switching power supplies, voltage tolerances are referenced to the power supply output voltage level.

MAXIMUM RATINGS

5000 Watts of Peak Pulse Power dissipation at 25°C
Clamping time (0 volts to $V_{(BR)}$ min): Less than 1×10^{-12} seconds
Operating and Storage temperature: -55° to +150°C
Steady State power dissipation: 5.0 watts @ $T_L = 25^\circ\text{C}$
Repetition rate (duty cycle): .05%

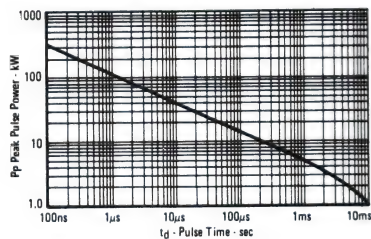


FIGURE 1
PEAK PULSE POWER
VS. PULSE TIME

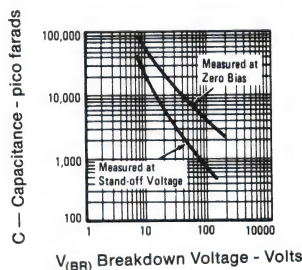
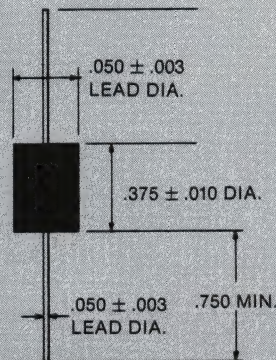
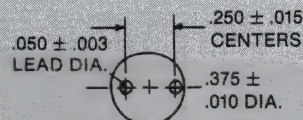
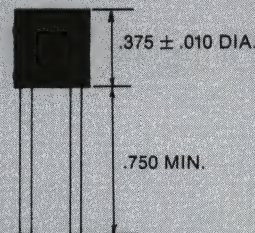


FIGURE 2
TYPICAL CAPACITANCE VS.
BREAKDOWN VOLTAGE

TRANSIENT ABSORPTION ZENER



CASE 5A



CASE 5R

MECHANICAL CHARACTERISTICS

CASE: Void free molded thermo-setting plastic

FINISH: Silver plated copper readily solderable.

POLARITY: Band denotes cathode. Bidirectional not marked.

WEIGHT: 4 grams (Appx.)

MOUNTING POSITION: Any

5KP5.0 thru 5KP110A

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE (Note 1) V _R VOLTS | BREAKDOWN VOLTAGE @ V _{WM} VOLTS | I _T mA | MAXIMUM CLAMPING VOLTAGE @ I _{PP} (1 mSEC) V _{WM} VOLTS | MAXIMUM REVERSE LEAKAGE @ V _{WM} I _A μA | MAXIMUM PEAK PULSE CURRENT (FIG. 3) I _{PP} A | MAXIMUM VOLTAGE TEMPERATURE VARIATION OF V _{WM} mV/°C |
|-----------------------------|--|---|----------------------|---|--|---|---|
| 5KP5.0 | 5.0 | 6.40 - 7.30 | 50 | 9.6 | 2000 | 520 | 4.0 |
| 5KP5.0A | 5.0 | 6.40 - 7.00 | 50 | 9.2 | 2000 | 543 | 4.0 |
| 5KP6.0 | 6.0 | 6.67 - 8.15 | 50 | 11.4 | 5000 | 430 | 4.0 |
| 5KP6.0A | 6.0 | 6.67 - 7.37 | 50 | 10.3 | 5000 | 485 | 4.0 |
| 5KP6.5 | 6.5 | 7.22 - 8.82 | 50 | 12.3 | 2000 | 407 | 4.0 |
| 5KP6.5A | 6.5 | 7.22 - 7.98 | 50 | 11.2 | 2000 | 447 | 4.0 |
| 5KP7.0 | 7.0 | 7.78 - 9.51 | 50 | 13.3 | 1000 | 378 | 5.0 |
| 5KP7.0A | 7.0 | 7.78 - 8.60 | 50 | 12.0 | 1000 | 417 | 5.0 |
| 5KP7.5 | 7.5 | 8.33 - 10.2 | 5 | 14.3 | 250 | 350 | 6.0 |
| 5KP7.5A | 7.5 | 8.33 - 9.21 | 5 | 12.9 | 250 | 388 | 6.0 |
| 5KP8.0 | 8.0 | 8.89 - 10.9 | 5 | 15.0 | 150 | 333 | 6.0 |
| 5KP8.0A | 8.0 | 8.89 - 9.83 | 5 | 13.6 | 150 | 367 | 6.0 |
| 5KP8.5 | 8.5 | 9.44 - 11.5 | 5 | 15.9 | 50 | 314 | 7.0 |
| 5KP8.5A | 8.5 | 9.44 - 10.4 | 5 | 14.4 | 50 | 347 | 7.0 |
| 5KP9.0 | 9.0 | 10.0 - 12.2 | 5 | 16.9 | 20 | 295 | 8.0 |
| 5KP9.0A | 9.0 | 10.0 - 11.1 | 5 | 15.4 | 20 | 325 | 8.0 |
| 5KP10 | 10 | 11.1 - 13.6 | 5 | 18.8 | 15 | 266 | 9.0 |
| 5KP10A | 10 | 11.1 - 12.3 | 5 | 17.0 | 15 | 294 | 9.0 |
| 5KP11 | 11 | 12.2 - 14.9 | 5 | 20.1 | 10 | 249 | 10 |
| 5KP11A | 11 | 12.2 - 13.5 | 5 | 18.2 | 10 | 274 | 10 |
| 5KP12 | 12 | 13.3 - 16.3 | 5 | 22.0 | 10 | 227 | 11 |
| 5KP12A | 12 | 13.3 - 14.7 | 5 | 19.9 | 10 | 251 | 11 |
| 5KP13 | 13 | 14.4 - 17.6 | 5 | 23.8 | 10 | 210 | 12 |
| 5KP13A | 13 | 14.4 - 15.9 | 5 | 21.5 | 10 | 232 | 12 |
| 5KP14 | 14 | 15.6 - 19.1 | 5 | 25.8 | 10 | 194 | 13 |
| 5KP14A | 14 | 15.6 - 17.2 | 5 | 23.2 | 10 | 215 | 13 |
| 5KP15 | 15 | 16.7 - 20.4 | 5 | 26.9 | 10 | 188 | 15 |
| 5KP15A | 15 | 16.7 - 18.5 | 5 | 24.4 | 10 | 206 | 15 |
| 5KP16 | 16 | 17.8 - 21.8 | 5 | 28.8 | 10 | 176 | 18 |
| 5KP16A | 16 | 17.8 - 19.7 | 5 | 26.0 | 10 | 192 | 16 |
| 5KP17 | 17 | 18.9 - 23.1 | 5 | 30.5 | 10 | 164 | 19 |
| 5KP17A | 17 | 18.9 - 20.9 | 5 | 27.6 | 10 | 181 | 18 |
| 5KP18 | 18 | 20.0 - 24.4 | 5 | 32.2 | 10 | 155 | 20 |
| 5KP18A | 18 | 20.0 - 22.1 | 5 | 29.2 | 10 | 172 | 19 |
| 5KP20 | 20 | 22.2 - 27.1 | 5 | 35.8 | 10 | 139 | 24 |
| 5KP20A | 20 | 22.2 - 24.5 | 5 | 32.4 | 10 | 154 | 22 |
| 5KP22 | 22 | 24.4 - 29.8 | 5 | 39.4 | 10 | 127 | 27 |
| 5KP22A | 22 | 24.4 - 26.9 | 5 | 35.5 | 10 | 141 | 24 |
| 5KP24 | 24 | 26.7 - 32.6 | 5 | 43.0 | 10 | 116 | 30 |
| 5KP24A | 24 | 26.7 - 29.5 | 5 | 38.9 | 10 | 128 | 27 |
| 5KP26 | 26 | 28.9 - 35.3 | 5 | 46.6 | 10 | 107 | 33 |
| 5KP26A | 26 | 28.9 - 31.9 | 5 | 42.1 | 10 | 119 | 29 |
| 5KP28 | 28 | 31.1 - 38.0 | 5 | 50.1 | 10 | 99 | 34 |
| 5KP28A | 28 | 31.1 - 34.4 | 5 | 45.5 | 10 | 110 | 30 |
| 5KP30 | 30 | 33.3 - 40.7 | 5 | 53.5 | 10 | 93 | 38 |
| 5KP30A | 30 | 33.3 - 36.8 | 5 | 48.4 | 10 | 103 | 35 |
| 5KP33 | 33 | 36.7 - 44.9 | 5 | 59.0 | 10 | 85 | 41 |
| 5KP33A | 33 | 36.7 - 40.6 | 5 | 53.3 | 10 | 94 | 38 |
| 5KP36 | 36 | 40.0 - 48.9 | 5 | 64.3 | 10 | 78 | 45 |
| 5KP36A | 36 | 40.0 - 44.2 | 5 | 58.1 | 10 | 86 | 40 |
| 5KP40 | 40 | 44.4 - 54.3 | 5 | 71.4 | 10 | 70 | 50 |
| 5KP40A | 40 | 44.4 - 49.1 | 5 | 64.5 | 10 | 78 | 45 |
| 5KP43 | 43 | 47.8 - 58.4 | 5 | 78.7 | 10 | 65 | 54 |
| 5KP43A | 43 | 47.8 - 52.8 | 5 | 69.4 | 10 | 72 | 49 |
| 5KP45 | 45 | 50.0 - 61.1 | 5 | 80.3 | 10 | 62 | 57 |
| 5KP45A | 45 | 50.0 - 55.3 | 5 | 72.7 | 10 | 69 | 51 |
| 5KP48 | 48 | 53.3 - 65.1 | 5 | 85.5 | 10 | 58 | 62 |
| 5KP48A | 48 | 53.3 - 58.9 | 5 | 77.4 | 10 | 65 | 55 |
| 5KP51 | 51 | 56.7 - 69.3 | 5 | 91.1 | 10 | 56 | 65 |
| 5KP51A | 51 | 56.7 - 62.7 | 5 | 82.4 | 10 | 61 | 60 |
| 5KP54 | 54 | 60.0 - 73.3 | 5 | 96.3 | 10 | 52 | 70 |
| 5KP54A | 54 | 60.0 - 66.3 | 5 | 87.1 | 10 | 57 | 64 |
| 5KP58 | 58 | 64.4 - 78.7 | 5 | 103.0 | 10 | 49 | 77 |
| 5KP58A | 58 | 64.4 - 71.2 | 5 | 93.6 | 10 | 53 | 69 |
| 5KP60 | 60 | 66.7 - 81.5 | 5 | 107.0 | 10 | 47 | 79 |
| 5KP60A | 60 | 66.7 - 73.7 | 5 | 96.8 | 10 | 52 | 70 |
| 5KP64 | 64 | 71.1 - 86.9 | 5 | 114.0 | 10 | 44 | 85 |
| 5KP64A | 64 | 71.1 - 78.6 | 5 | 103.0 | 10 | 49 | 75 |
| 5KP70 | 70 | 77.8 - 95.1 | 5 | 125 | 10 | 40 | 93 |
| 5KP70A | 70 | 77.8 - 86.0 | 5 | 113 | 10 | 44 | 84 |
| 5KP75 | 75 | 83.3 - 102.0 | 5 | 134 | 10 | 37 | 100 |
| 5KP75A | 75 | 83.3 - 92.1 | 5 | 121 | 10 | 41 | 90 |
| 5KP78 | 78 | 86.7 - 106.0 | 5 | 139 | 10 | 36 | 104 |
| 5KP78A | 78 | 86.7 - 95.8 | 5 | 126 | 10 | 40 | 94 |
| 5KP85 | 85 | 94.4 - 115.0 | 5 | 151 | 10 | 33 | 113 |
| 5KP85A | 85 | 94.4 - 104.0 | 5 | 137 | 10 | 36 | 102 |
| 5KP90 | 90 | 100 - 122 | 5 | 160 | 10 | 31 | 120 |
| 5KP90A | 90 | 100 - 111 | 5 | 146 | 10 | 34 | 109 |
| 5KP100 | 100 | 111 - 136 | 5 | 179 | 10 | 28 | 134 |
| 5KP100A | 100 | 111 - 123 | 5 | 162 | 10 | 31 | 122 |
| 5KP110 | 110 | 122 - 149 | 5 | 196 | 10 | 26 | 147 |
| 5KP110A | 110 | 122 - 135 | 5 | 177 | 10 | 28 | 132 |

V_f at 100 amps peak, 8.3 msec sine wave equals 3.5 volts maximum.

NOTE 1: TAZ are selected according to the reverse "Stand Off Voltage" V_{WM} which should be equal to or greater than the DC or continuous peak operating voltage level.

FEATURES

These TAZ devices are high power, medium voltage Transient Suppressors designed for protecting precision industrial electronic equipment. They are available from 17 volts through 280 volts. Special voltages are available upon request to the factory.

MAXIMUM RATINGS

15,000 watts of Peak Pulse Power dissipation at 25°C
t_{clamping} (0 volts to V_{BR}) min): Less than 1×10^{-12}
Operating and Storage temperature: -55°C to +150°C
Steady State power dissipation: 7.0 watts @ T_A = 25°C
Repetition rate (duty cycle): .05%

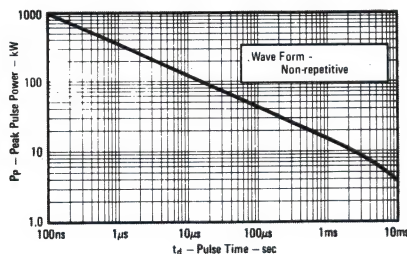
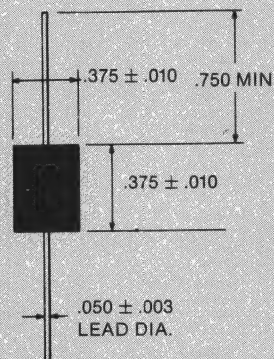
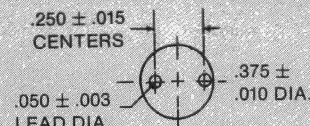
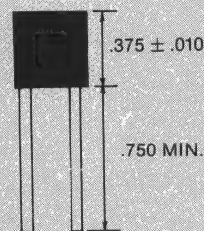


FIGURE 1
PEAK PULSE POWER
VS. PULSE TIME

TRANSIENT ABSORPTION ZENER



CASE 5A



CASE 5R

MECHANICAL CHARACTERISTICS

CASE: Void free molded thermosetting plastic.

FINISH: Silver plated copper
Readily solderable.

POLARITY: Positive terminal
marked with a dot.

WEIGHT: 13 grams (Appx.).

MOUNTING POSITION: Any.

15KP17 thru 15KP280A

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE (Note 1) V _{WM} VOLTS | BREAKDOWN VOLTAGE @ V _(BR) VOLTS | I _T mA | MAXIMUM CLAMPING PULSE VOLTAGE @ I _{PP} (1 mSEC) V _C VOLTS | MAXIMUM REVERSE LEAKAGE @ V _{WM} I ₀ μA | MAXIMUM PEAK PULSE CURRENT (FIG. 2) I _{PP} A | MAXIMUM VOLTAGE TEMPERATURE VARIATION OF V _{BR} mV/°C |
|-----------------------------|---|---|----------------------|---|--|---|---|
| 15KP17 | 17 | 18.9- 23.1 | 50 | 32.3 | 5000 | 464 | 19 |
| 15KP17A | 17 | 18.9- 20.9 | 50 | 29.3 | 5000 | 512 | 17 |
| 15KP18 | 18 | 20.0- 24.4 | 50 | 34.2 | 5000 | 439 | 20 |
| 15KP18A | 18 | 20.0- 22.1 | 50 | 30.9 | 5000 | 485 | 18 |
| 15KP20 | 20 | 22.2- 27.1 | 20 | 37.9 | 1500 | 396 | 24 |
| 15KP20A | 20 | 22.2- 24.5 | 20 | 34.3 | 1500 | 437 | 21 |
| 15KP22 | 22 | 24.4- 29.8 | 10 | 41.1 | 500 | 365 | 27 |
| 15KP22A | 22 | 24.4- 26.9 | 10 | 37.1 | 500 | 404 | 24 |
| 15KP24 | 24 | 26.7- 32.6 | 5 | 45.0 | 150 | 333 | 30 |
| 15KP24A | 24 | 26.7- 29.5 | 5 | 40.7 | 150 | 369 | 27 |
| 15KP26 | 26 | 28.9- 35.3 | 5 | 48.7 | 50 | 308 | 32 |
| 15KP26A | 26 | 28.9- 31.9 | 5 | 44.0 | 50 | 341 | 29 |
| 15KP28 | 28 | 31.1- 38.0 | 5 | 52.4 | 25 | 286 | 35 |
| 15KP28A | 28 | 31.1- 34.4 | 5 | 47.5 | 25 | 316 | 31 |
| 15KP30 | 30 | 33.3- 40.7 | 5 | 56.2 | 15 | 267 | 27 |
| 15KP30A | 30 | 33.3- 36.8 | 5 | 50.7 | 15 | 296 | 34 |
| 15KP33 | 33 | 36.7- 44.9 | 5 | 60.6 | 10 | 248 | 42 |
| 15KP33A | 33 | 36.7- 40.6 | 5 | 54.8 | 10 | 274 | 38 |
| 15KP36 | 36 | 40.0- 48.9 | 5 | 66.0 | 10 | 227 | 46 |
| 15KP36A | 36 | 40.0- 44.2 | 5 | 59.7 | 10 | 251 | 41 |
| 15KP40 | 40 | 44.4- 54.3 | 5 | 72.8 | 10 | 206 | 51 |
| 15KP40A | 40 | 44.4- 49.1 | 5 | 65.8 | 10 | 228 | 46 |
| 15KP43 | 43 | 47.8- 58.4 | 5 | 77.1 | 10 | 195 | 55 |
| 15KP43A | 43 | 47.8- 52.8 | 5 | 69.7 | 10 | 215 | 50 |
| 15KP45 | 45 | 50.0- 61.1 | 5 | 80.7 | 10 | 186 | 57 |
| 15KP45A | 45 | 50.0- 55.3 | 5 | 73.0 | 10 | 205 | 52 |
| 15KP48 | 48 | 53.3- 65.1 | 5 | 85.9 | 10 | 175 | 62 |
| 15KP48A | 48 | 53.3- 58.9 | 5 | 77.7 | 10 | 193 | 56 |
| 15KP51 | 51 | 56.7- 69.3 | 5 | 91.5 | 10 | 164 | 66 |
| 15KP51A | 51 | 56.7- 62.7 | 5 | 82.8 | 10 | 181 | 60 |
| 15KP54 | 54 | 60.0- 73.3 | 5 | 96.8 | 10 | 155 | 70 |
| 15KP54A | 54 | 60.0- 66.3 | 5 | 87.5 | 10 | 171 | 63 |
| 15KP58 | 58 | 64.4- 78.7 | 5 | 104.0 | 10 | 144 | 76 |
| 15KP58A | 58 | 64.4- 71.2 | 5 | 94.0 | 10 | 160 | 68 |
| 15KP60 | 60 | 66.7- 81.5 | 5 | 107.0 | 10 | 140 | 78 |
| 15KP60A | 60 | 66.7- 73.7 | 5 | 97.3 | 10 | 154 | 71 |
| 15KP64 | 64 | 71.1- 86.9 | 5 | 115 | 10 | 130 | 84 |
| 15KP64A | 64 | 71.1- 78.8 | 5 | 104 | 10 | 144 | 76 |
| 15KP70 | 70 | 77.8- 95.1 | 5 | 126 | 10 | 119 | 92 |
| 15KP70A | 70 | 77.8- 86.0 | 5 | 114 | 10 | 132 | 83 |
| 15KP75 | 75 | 83.3-102.0 | 5 | 135 | 10 | 111 | 100 |
| 15KP75A | 75 | 83.3- 92.1 | 5 | 122 | 10 | 123 | 89 |
| 15KP78 | 78 | 86.7-106.0 | 5 | 140 | 10 | 107 | 104 |
| 15KP78A | 78 | 86.7- 95.8 | 5 | 126 | 10 | 119 | 93 |
| 15KP85 | 85 | 94.4-115 | 5 | 152 | 10 | 99 | 113 |
| 15KP85A | 85 | 94.4-104 | 5 | 137 | 10 | 109 | 102 |
| 15KP90 | 90 | 100.0-122 | 5 | 160 | 10 | 94 | 120 |
| 15KP90A | 90 | 100.0-111 | 5 | 146 | 10 | 103 | 109 |
| 15KP100 | 100 | 111- 136 | 5 | 179 | 10 | 84 | 134 |
| 15KP100A | 100 | 111- 123 | 5 | 162 | 10 | 93 | 121 |
| 15KP110 | 110 | 122- 149 | 5 | 196 | 10 | 77 | 147 |
| 15KP110A | 110 | 122- 135 | 5 | 178 | 10 | 84 | 133 |
| 15KP120 | 120 | 133- 163 | 5 | 214 | 10 | 70 | 161 |
| 15KP120A | 120 | 133- 147 | 5 | 193 | 10 | 78 | 145 |
| 15KP130 | 130 | 144- 176 | 5 | 231 | 10 | 65 | 174 |
| 15KP130A | 130 | 144- 159 | 5 | 209 | 10 | 72 | 157 |
| 15KP150 | 150 | 167- 204 | 5 | 268 | 10 | 56 | 202 |
| 15KP150A | 150 | 167- 185 | 5 | 243 | 10 | 62 | 183 |
| 15KP160 | 160 | 178- 218 | 5 | 287 | 10 | 52 | 216 |
| 15KP160A | 160 | 178- 197 | 5 | 259 | 10 | 58 | 195 |
| 15KP170 | 170 | 189- 231 | 5 | 304 | 10 | 49 | 229 |
| 15KP170A | 170 | 189- 209 | 5 | 275 | 10 | 55 | 207 |
| 15KP180 | 180 | 200- 244 | 5 | 321 | 10 | 47 | 242 |
| 15KP180A | 180 | 200- 221 | 5 | 291 | 10 | 52 | 219 |
| 15KP200 | 200 | 222- 271 | 5 | 356 | 10 | 42 | 269 |
| 15KP200A | 200 | 222- 245 | 5 | 322 | 10 | 47 | 243 |
| 15KP220 | 220 | 245- 299 | 5 | 393 | 10 | 38 | 297 |
| 15KP220A | 220 | 245- 271 | 5 | 356 | 10 | 42 | 269 |
| 15KP240 | 240 | 267- 326 | 5 | 428 | 10 | 35 | 324 |
| 15KP240A | 240 | 267- 295 | 5 | 388 | 10 | 39 | 293 |
| 15KP260 | 260 | 289- 353 | 5 | 464 | 10 | 32 | 352 |
| 15KP260A | 260 | 289- 319 | 5 | 419 | 10 | 36 | 317 |
| 15KP280 | 280 | 311- 380 | 5 | 500 | 10 | 30 | 378 |
| 15KP280A | 280 | 311- 344 | 5 | 452 | 10 | 33 | 342 |

V_F = 7.5 V @ 200A, 8.3 msec/½ sine wave.

NOTE 1: TAZ are normally selected according to the reverse "Stand Off Voltage" V_{WM} which should be equal to or greater than the DC or continuous peak operating voltage level.

MICRO

Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

60KS200C BIDIRECTIONAL TRANSIENT VOLTAGE SUPPRESSOR

TRANSIENT
ABSORPTION ZENER

FEATURES

- 200 VOLT BIDIRECTIONAL
- EXCEEDS MIL-STD-1399 REQUIREMENTS
- CAN BE SUPPLIED WITH JAN/JANTX PARTS

This device is a bidirectional Transient Suppressor for shipboard equipment and power servicing equipment where large voltage transients endanger voltage sensitive components. It meets all applicable environmental requirements of MIL-S-19500 and is consistent with MIL-E-16400. Designed with MIL-STD-1399 Section 103 (Interface standard for shipboard systems, Electrical power, Alternating current) as the controlling specification.

MAXIMUM RATINGS

15,000 watts Peak Pulse Power dissipation at 25°C
Steady State power dissipation: 10 watts
Operating and Storage temperatures: -65° to +150°C
 $t_{clamping}$ (0 volts to V_{BR}): Less than 1×10^{-8} seconds

CAPACITANCE

170 pF @ 0 Volts (Typical)

ELECTRICAL CHARACTERISTICS @ 25°C (Test Both Polarities)*

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE (Note 1) V_{WM} VOLTS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_D μA | BREAKDOWN VOLTAGE @ 1 mA $V_{(BR)}$ VOLTS Min. Max. | MAXIMUM CLAMPING VOLTAGE @ I_{PP} V_C VOLTS | MAXIMUM PEAK PULSE CURRENT (Pulse Wave Form) I_{PP} A |
|-----------------------------|--|---|--|--|--|
| 60KS200C | 180 | 10 | 200 225 | 335 | 180 |

*Consult factory for other available voltages.



MECHANICAL CHARACTERISTICS

CASE: Molded case.
TERMINAL: Silver-plated brass.
POLARITY: Bidirectional.
WEIGHT: 50 grams (Appx.).
MOUNTING POSITION: Any.

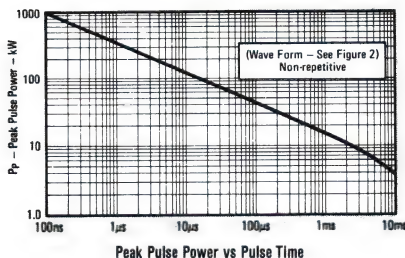


FIGURE 1

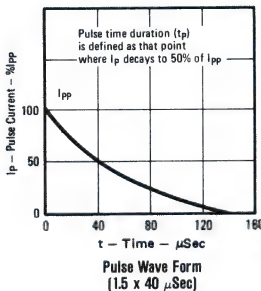
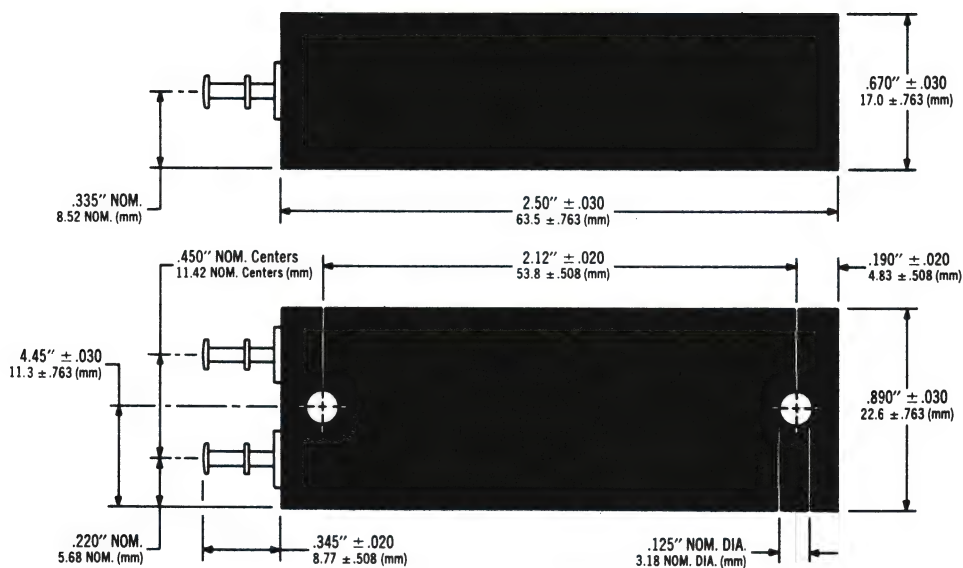


FIGURE 2

60KS200C BIDIRECTIONAL TRANSIENT VOLTAGE SUPPRESSOR



All dimensions in $\frac{\text{INCH}}{\text{m.m.}}$

micro

Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

704-15K36 and 704-15K36T TRANSIENT VOLTAGE SUPPRESSOR

FEATURES

- DESIGNED FOR MIL-STD-704
- 28 VOLT POWER SUPPLY PROTECTION
- CAN BE SUPPLIED WITH JAN/JANTX PARTS

This series is primarily for use in avionics equipment. It meets all applicable environmental requirements of MIL-S-19500. The controlling specification for these devices is MIL-STD-704 (Characteristics and Utilization of Aircraft Electric Power). These 15kW assemblies are designed typically to operate with a minimum source impedance of .25 Ohms for transients.

MAXIMUM RATINGS

Peak Pulse Power dissipation at 25°C: 15,000 watts at 1 msec

Steady State power dissipation: 10 watts

$t_{clamping}$ (0 volts to $V_{(BR)}$ min): Less than 1×10^{-12} seconds

Operating and Storage temperatures: -65° to +150°C

Forward surge rating: 300 amps, 1/120 second at 25°C

Duty cycle: .01%

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE (Note 1) V_{WM} VOLTS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_D μA | MINIMUM BREAKDOWN VOLTAGE @ 10 mA $V_{(BR)}$ VOLTS | MAXIMUM CLAMPING VOLTAGE @ I_{PP} V_C VOLTS | MAXIMUM PEAK PULSE CURRENT (Fig. 2) I_{PP} A | MAXIMUM FORWARD VOLTAGE V_F @ ~ 8.3 msec. 100 A VOLTS DC |
|-----------------------------|--|---|---|--|---|--|
| 704-15K36 | 31.5 | 100 | 36 | 51 | 300 | 3.0 |
| 704-15K36T | 31.5 | 500 | 36 | 51 | 300 | 15.0 |

NOTE 1: TAZ are normally selected according to the reverse "Stand Off Voltage" (V_{WM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

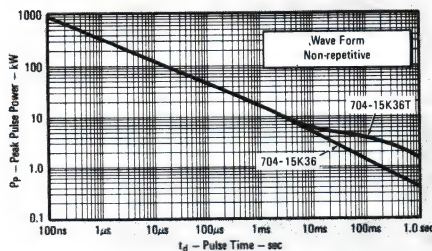


FIGURE 1
PEAK PULSE POWER
VS. PULSE TIME

TRANSIENT ABSORPTION ZENER



704-15K36 Case 8



704-15K36T Case 9

MECHANICAL CHARACTERISTICS

CASE: Molded case.

TERMINAL: Silver Plated Brass

POLARITY: Cathode terminal marked with a dot.

WEIGHT: 704-15K36 = 38 grams

704-15K36T = 65 grams

MOUNTING POSITION: Any.

704-15K36 and 704-15K36T

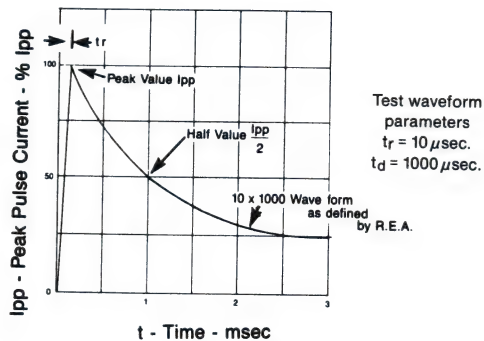
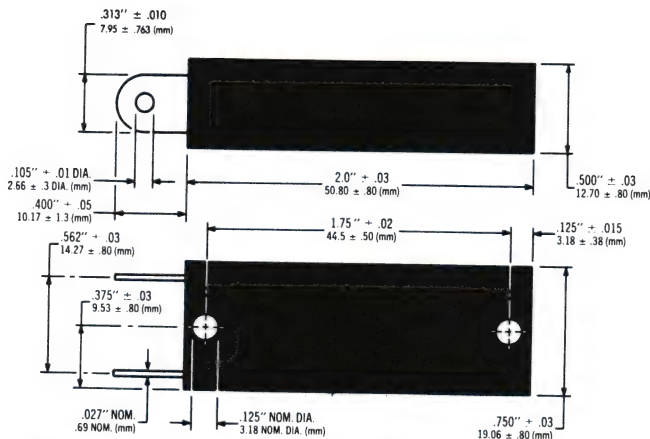


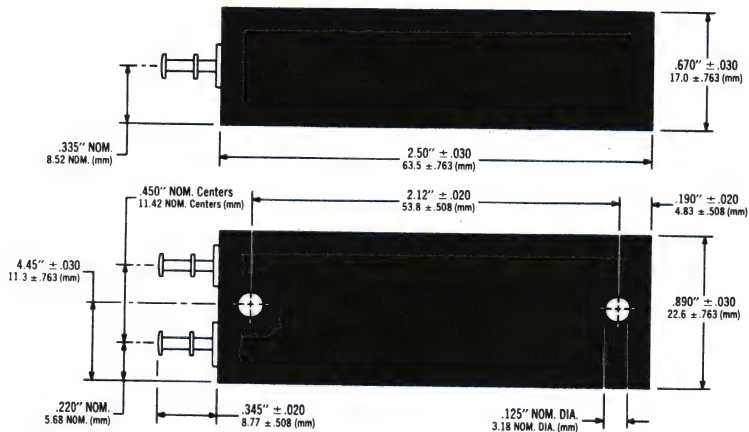
FIGURE 2

PULSE WAVEFORM

PACKAGE DIMENSIONS



CASE 8



CASE 9

micro

Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300**DLTS-5
thru
DLTS-30****FEATURES**

This series of TAZ devices is packaged in a ceramic, dual-in-line, hermetically sealed package. These components offer 15 protective devices; unidirectional or bidirectional, common buss connections, per package. The dual-in-line is designed specifically for data line protection, at the P.C. board level. TTL and MOS voltages are available for protection of input/output data circuits.

- UNIDIRECTIONAL OR BIDIRECTIONAL
- MULTIPLE TAZ ARRAY
- DUAL-IN-LINE, 16 PIN HERMETIC PACKAGE
- LOW CAPACITANCE
- μ P/mP COMPATIBLE PACKAGE
- VOLTAGE RANGE OF 5V TO 100V AVAILABLE
- COMMON BUSS CONFIGURATION
- MILITARY ENVIRONMENT CAPABILITY

MAXIMUM RATINGS

500 Watts Peak Pulse Power/Position (@ 25°C) (8 x 20 μ s)

t_{clamping} (0 volts to BV min.) Less than 1×10^{-12} seconds (theoretical)
(unidirectional) 5×10^{-9} seconds (bidirectional) (theoretical)

Operating and Storage Temperatures: -55°C to +150°C

Forward Surge Rating: 10 Amps, 1/120 sec. @ 25°C (unidirectional)

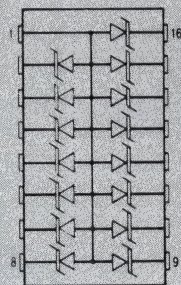
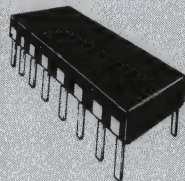
Repetition Rate (duty cycle): .01%

AVAILABLE DEVICE TYPES**UNIDIRECTIONAL**

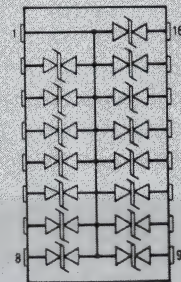
DLTS-5, A
DLTS-12, A
DLTS-17, A
DLTS-24, A
DLTS-30, A

BIDIRECTIONAL

DLTS-8C, CA
DLTS-13C, CA
DLTS-19C, CA
DLTS-30C, CA

**DATA LINE
TRANSIENT SUPPRESSOR**

TYPICAL
UNIDIRECTIONAL
SCHEMATIC



TYPICAL
BIDIRECTIONAL
SCHEMATIC

**MECHANICAL
CHARACTERISTICS**

CASE: Ceramic, 16 pin dual-in-line
(.300" row spacing)

POLARITY: Pin No. 1 marked
with a flag on lead and a dot on
top of package. Body marked
with type number.

WEIGHT: 3.5 grams (Appx.)

DLTS thru DLTS - 30

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE V_{WM} VOLTS | MINIMUM BREAKDOWN VOLTAGE @ 1 mA $V_{(BR)}$ VOLTS | MAXIMUM CLAMPING VOLTAGE @ $I_{PP2} = 1A$ (8 x 20 psec) V_{C1} VOLTS | MAXIMUM CLAMPING VOLTAGE @ $I_{PP2} = 10A$ (8 x 20 psec) V_{C2} VOLTS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_D μA | MAXIMUM CAPACITANCE @ 0V 1MHz C μF | MAXIMUM VOLTAGE TEMPERATURE VARIATION OF $V_{(BR)}$ MV/C |
|-----------------------------|--|--|--|---|---|---|---|
| Unidirectional | | | | | | | |
| DLTS-5 | 5 | 6.0 | 10.2 | 12.5 | 200 | 880 | 5 |
| DLTS-5A | 5 | 6.0 | 9.5 | 10.6 | 200 | 880 | 5 |
| DLTS-12 | 12 | 13.3 | 21.1 | 26.0 | 2 | 440 | 18 |
| DLTS-12A | 12 | 13.3 | 19.1 | 23.5 | 2 | 440 | 18 |
| DLTS-17 | 17 | 19.2 | 30.4 | 37.4 | 2 | 330 | 20 |
| DLTS-17A | 17 | 19.2 | 27.5 | 33.9 | 2 | 330 | 20 |
| DLTS-24 | 24 | 26.7 | 42.3 | 52.1 | 2 | 275 | 31 |
| DLTS-24A | 24 | 26.7 | 38.3 | 47.2 | 2 | 275 | 31 |
| DLTS-30 | 30 | 33.3 | 52.8 | 65.0 | 2 | 220 | 39 |
| DLTS-30A | 30 | 33.3 | 47.8 | 58.8 | 2 | 220 | 39 |
| Bidirectional | | | | | | | |
| DLTS-8C | 8 | 8.5 | 13.4 | 16.6 | 10 | 440 | 9 |
| DLTS-8CA | 8 | 8.5 | 12.2 | 15.0 | 10 | 440 | 9 |
| DLTS-13C | 13 | 14.4 | 22.8 | 28.1 | 4 | 385 | 18 |
| DLTS-13CA | 13 | 14.4 | 20.6 | 25.4 | 4 | 385 | 18 |
| DLTS-19C | 19 | 21.6 | 34.2 | 42.1 | 4 | 275 | 24 |
| DLTS-19CA | 19 | 21.6 | 31.0 | 38.1 | 4 | 275 | 24 |
| DLTS-30C | 30 | 33.3 | 52.8 | 65.0 | 4 | 165 | 39 |
| DLTS-30CA | 30 | 33.3 | 47.8 | 58.8 | 4 | 165 | 39 |

"A", "CA", suffix denotes selected clamping voltage.

NOTE 1: A TAZ is normally selected according to the reverse "Stand Off Voltage" V_{WM} which should be equal to or greater than the DC or continuous peak operating voltage level.

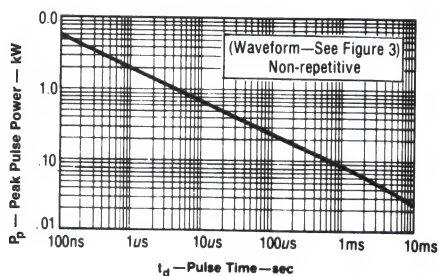


FIGURE 1
PEAK PULSE POWER VS PULSE TIME
(PER POSITION)

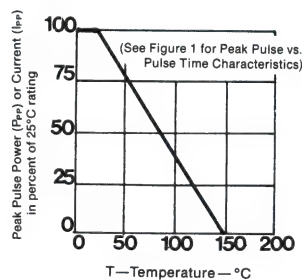


FIGURE 2
DERATING CURVE

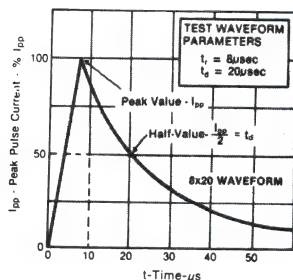
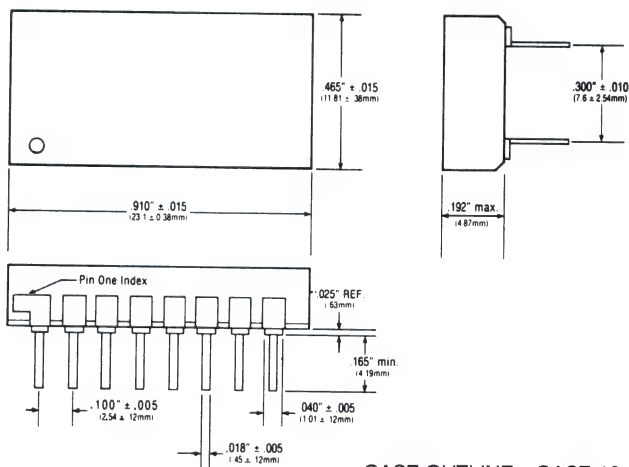


FIGURE 3
PULSE WAVEFORM



CASE OUTLINE—CASE 10

APPLICATION

The GMP-5 is a low voltage transient suppressor designed for the protection of integrated circuits. Characterized by a very low clamping voltage together with a low standoff voltage, GMP-5's afford a high degree of protection to: TTL, ECL, DTL, MOS, CMOS, VMOS, HMOS, NMOS and static memory circuits susceptible to 5-volt line transients.

DESCRIPTION/FEATURES

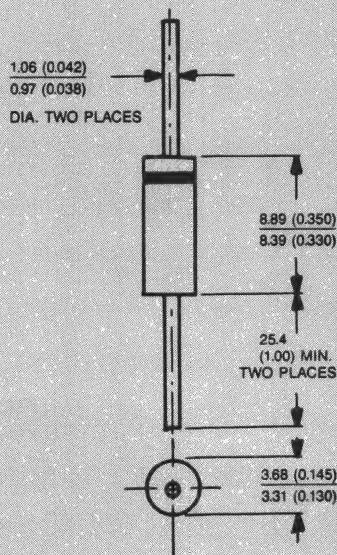
Transient Absorption Zeners (TAZ) are PN silicon junction zeners designed for transient voltage suppression. Due to the TAZ's fast response time, protection level and high discharge capability, they are extremely effective in providing protection against pulses generated by: voltage reversals, capacitive or inductive load switching, electromechanical switching, electrostatic discharge and electromagnetic coupling. Since integrated circuits are more susceptible to damage from these pulses, TAZ devices offer effective protection.

- 500 WATTS PEAK PULSE POWER DISSIPATION
- WORKING VOLTAGE OF 5 VOLTS
- PROTECTS TTL, ECL, DTL, MOS, CMOS, AND MSI INTEGRATED CIRCUITS
- LOW CLAMPING FACTOR

MAXIMUM RATINGS

500 Watts of Peak Pulse Power dissipation at 25°C
t_{clamping} (0 volts to BV min.): Less than 1×10^{-12} seconds (theoretical)
Operating and Storage Temperatures: -65°C to +175°C
Forward surge rating: 50 amps 1/120 second at 25°C
Steady State power dissipation: 5.0 W @ T_L = 75°C, Lead Length = 3/8"
Repetition rate (duty cycle): .05%

TRANSIENT ABSORPTION ZENER



Cathode Indicated by Band
All Dimensions in Millimeters (Inches)

MECHANICAL CHARACTERISTICS

CASE: Void free transfer molded thermosetting plastic

FINISH: Silver plated copper, readily solderable

POLARITY: Band denotes cathode

WEIGHT: 0.7 gram (Appx.)

MOUNTING POSITION: Any

GMP-5

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI CORP. PART NUMBER | STAND OFF VOLTAGE Note 1 V _{WM} Volts | MAXIMUM REVERSE LEAKAGE @ V _{WM} I _D μA | MINIMUM BREAKDOWN VOLTAGE @ 1mA V (min) V (BR) Volts | MAXIMUM CLAMPING VOLTAGE @ I _{pp1} = 1A (Fig 2) V _C Volts | MAXIMUM CLAMPING VOLTAGE @ I _{pp2} = 10A (Fig 2) V _C Volts | MAXIMUM PEAK PULSE CURRENT (Fig 2) I _{pp3} Amps | MAXIMUM PEAK PULSE CURRENT (1.2x50 μsec) Amps |
|-----------------------------------|--|--|---|---|--|--|---|
| GMP — 5 | 5.0 | 300 | 5.3 | 6.7 | 6.9 | 70 | 215 |
| GMP — 5A | 5.0 | 100 | 5.5 | 6.7 | 6.9 | 70 | 215 |
| GMP — 5B | 5.0 | 300 | 5.3 | 6.4 | 6.6 | 70 | 215 |

Note 1: A TAZ is usually selected according to the reverse "Stand Off Voltage" (V_{WM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

V_f at 50 amps peak, 8.3 msec sine wave = 3.5 volts maximum

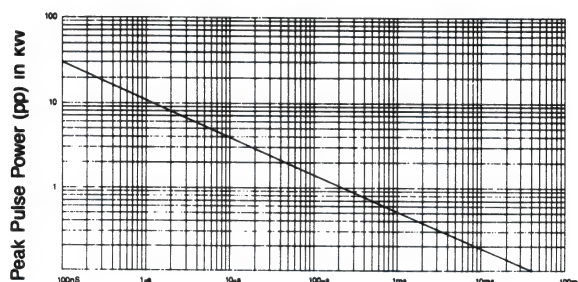


FIGURE 1
PEAK PULSE POWER VS PULSE TIME

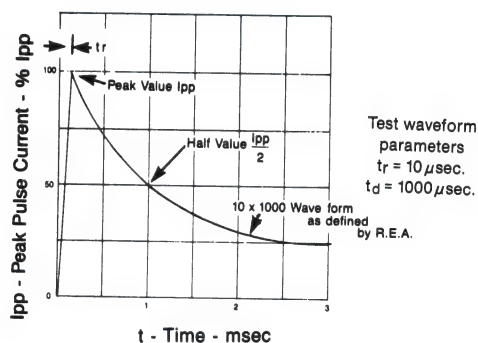


FIGURE 2
PULSE WAVE FORM

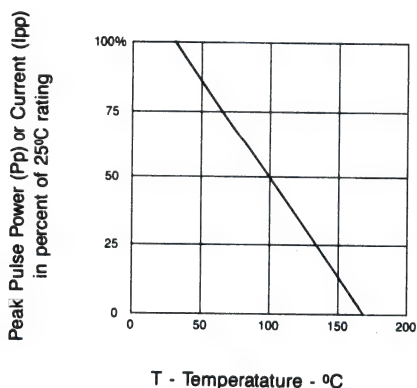


FIGURE 3
DERATING CURVE

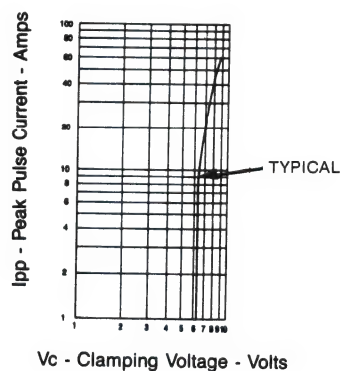


FIGURE 4
TYPICAL CHARACTERISTIC CLAMPING VOLTAGE
(V_C) VS PEAK PULSE CURRENT (I_{pp})

FEATURES

- THIS SERIES OF TAZ DEVICES IS DESIGNED TO PROTECT BIPOLAR, MOS AND SCHOTTKY IMPROVED INTEGRATED CIRCUITS.
- TRANSIENT PROTECTION FOR CMOS, MOS, BIPOLAR, ICS (TTL, ECL, DTL, RTL AND LINEAR FUNCTIONS)
- 5.0 TO 45 VOLTS
- LOW CLAMPING RATIO

MAXIMUM RATINGS

1500 Watts of Peak Pulse Power dissipation at 25°C

t_{clamping} (0 volts to V_{BR} min): Unidirectional—Less than 1×10^{-12} seconds
Bidirectional—Less than 5×10^{-9} seconds

Operating and Storage temperatures: -65° to +175°C

Forward surge rating: 200 amps, 1/120 second at 25°C

(Applies to Unidirectional or single direction only)

Steady State power dissipation: 1.0 watt

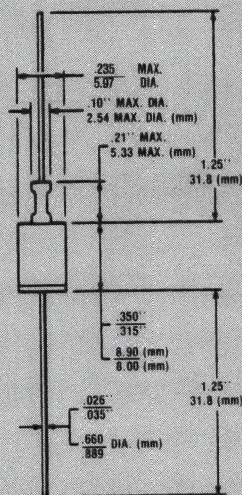
Repetition rate (duty cycle): .01%

ELECTRICAL CHARACTERISTICS

Clamping Factor: 1.33 @ Full rated power
1.20 @ 50% rated power

Clamping Factor: The ratio of the actual V_C (Clamping Voltage) to the actual V_{BR} (Breakdown Voltage) as measured on a specific device.

TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: DO-13 welded, hermetically sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and leads solderable.

POLARITY: Cathode connected to case and marked. Bidirectional not marked.

WEIGHT: 1.4 grams (Appx.)

MOUNTING POSITION: Any

ICT-5 thru ICT-45C

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | STAND-OFF VOLTAGE (NOTE 1) V_{WM} VOLTS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_D μA | MINIMUM* BREAKDOWN VOLTAGE @ 1 mA $B_{(VR)}$ (min.) VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ $I_{PP1} = 1A$ V_C VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ $I_{PP2} = 10A$ V_C VOLTS | MAXIMUM PEAK PULSE CURRENT I_{PP3} A |
|-----------------------------|---|---|--|--|---|--|
| ICT-5 | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| ICT-8 | 8.0 | 25 | 9.4 | 11.3 | 11.5 | 100 |
| ICT-10 | 10.0 | 2 | 11.7 | 13.7 | 14.1 | 90 |
| ICT-12 | 12.0 | 2 | 14.1 | 16.1 | 16.5 | 70 |
| ICT-15 | 15.0 | 2 | 17.6 | 20.1 | 20.6 | 60 |
| ICT-18 | 18.0 | 2 | 21.2 | 24.2 | 25.2 | 50 |
| ICT-22 | 22.0 | 2 | 25.9 | 29.8 | 32.0 | 40 |
| ICT-36 | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| ICT-45 | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

V_f at 100 amps peak, 8.3 msec sine wave equals 3.5 volts maximum

ELECTRICAL CHARACTERISTICS @ 25°C (Test Both Polarities)

| | | | | | | |
|---------|------|-----|------|------|------|-----|
| ICT-5C | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| ICT-8C | 8.0 | 25 | 9.4 | 11.4 | 11.6 | 100 |
| ICT-10C | 10.0 | 2 | 11.7 | 14.1 | 14.5 | 90 |
| ICT-12C | 12.0 | 2 | 14.1 | 16.7 | 17.1 | 70 |
| ICT-15C | 15.0 | 2 | 17.6 | 20.8 | 21.4 | 60 |
| ICT-18C | 18.0 | 2 | 21.2 | 24.8 | 25.5 | 50 |
| ICT-22C | 22.0 | 2 | 25.9 | 30.8 | 32.0 | 40 |
| ICT-36C | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| ICT-45C | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

C Suffix indicates Bidirectional

NOTE 1: TAZ are normally selected according to the reverse "Stand Off Voltage" V_{WM} which should be equal to or greater than the DC or repetitive peak operation voltage level.

*The minimum breakdown voltage as shown takes into consideration the ± 1 volt tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Similar devices are available with reduced clamping voltages where tighter regulated power supply voltages are employed.

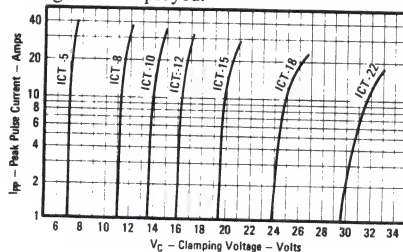


FIGURE 2
TYPICAL CHARACTERISTIC CLAMPING VOLTAGE
VS PEAK PULSE CURRENT

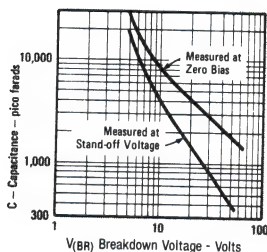


FIGURE 3
TYPICAL CAPACITANCE VS
BREAKDOWN VOLTAGE
(UNIDIRECTIONAL TYPES)

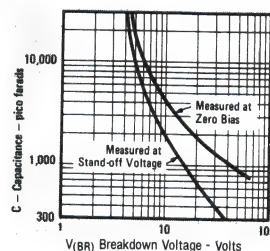


FIGURE 4
TYPICAL CAPACITANCE VS
BREAKDOWN VOLTAGE
(BIDIRECTIONAL TYPES)

FAZ

micro
Microsemi Corp.
The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ
For more information call:
(602) 941-6300

ICTE-5 thru ICTE-45C

FEATURES

- DESIGNED TO PROTECT BIPOLAR, MOS, AND SCHOTTKY IMPROVED INTEGRATED CIRCUITS FROM ELECTRICAL DISTURBANCES.
- TRANSIENT PROTECTION FOR CMOS, MOS, BIPOLAR, ICs, (TTL, ECL, DTL, RTL AND LINEAR FUNCTIONS)
- VOLTAGE RANGE OF 5.0 TO 45 VOLTS
- LOW CLAMPING RATIO

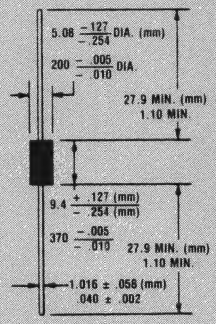
MAXIMUM RATINGS

1500 Watts of Peak Pulse Power dissipation at 25°C
 t_{clamping} (0 volts to V_{BR} min.): Unidirectional—Less than 1×10^{-12} seconds
 Bidirectional—Less than 5×10^{-9} seconds
 Operating and Storage Temperatures: -65° to +175°C
 Forward Surge Rating: 200 amps, 1/120 second at 25°C
 (Applies to Unidirectional or single direction only)
 Steady State power dissipation: 5.0 watts @ $T_L = 75^\circ\text{C}$, Lead Length = 3/8"
 Repetition rate (duty cycle): .05%

ELECTRICAL CHARACTERISTICS

Clamping Factor: 1.33 @ Full rated power
 1.20 @ 50% rated power
 Clamping Factor: The ratio of the actual V_C (Clamping Voltage) to the actual V_{BR} (Breakdown Voltage) as measured on a specific device.

TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: Void free, molded thermal-setting plastic
 FINISH: Silver plated copper readily solderable
 POLARITY: Band denotes cathode
 WEIGHT: 1.5 grams (Appx.)
 MOUNTING POSITION: Any

ICTE - 5 thru ICTE - 45C

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | STAND-OFF VOLTAGE (Note 1) V_{WM} VOLTS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_{0} μA | MINIMUM* BREAKDOWN VOLTAGE @ 1 mA V_{BR} (min.) VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ $I_{PP1} = 1A$ V_C VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ $I_{PP2} = 10A$ V_C VOLTS | MAXIMUM PEAK PULSE CURRENT I_{PP3} A |
|-----------------------------|---|---|--|--|---|--|
| ICTE-5 | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| ICTE-8 | 8.0 | 25 | 9.4 | 11.3 | 11.5 | 100 |
| ICTE-10 | 10.0 | 2 | 11.7 | 13.7 | 14.1 | 90 |
| ICTE-12 | 12.0 | 2 | 14.1 | 16.1 | 16.5 | 70 |
| ICTE-15 | 15.0 | 2 | 17.6 | 20.1 | 20.6 | 60 |
| ICTE-18 | 18.0 | 2 | 21.2 | 24.2 | 25.2 | 50 |
| ICTE-22 | 22.0 | 2 | 25.9 | 29.8 | 32.0 | 40 |
| ICTE-36 | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| ICTE-45 | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

V_f at 100 amps peak, 8.3 msec sine wave equals 3.5 volts maximum

ELECTRICAL CHARACTERISTICS @ 25°C (Test Both Polarities)

| | | | | | | |
|----------|------|-----|------|------|------|-----|
| ICTE-5C | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| ICTE-8C | 8.0 | 25 | 9.4 | 11.4 | 11.6 | 100 |
| ICTE-10C | 10.0 | 2 | 11.7 | 14.1 | 14.5 | 90 |
| ICTE-12C | 12.0 | 2 | 14.1 | 16.7 | 17.1 | 70 |
| ICTE-15C | 15.0 | 2 | 17.6 | 20.8 | 21.4 | 60 |
| ICTE-18C | 18.0 | 2 | 21.2 | 24.8 | 25.5 | 50 |
| ICTE-22C | 22.0 | 2 | 25.9 | 30.8 | 32.0 | 40 |
| ICTE-36C | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| ICTE-45C | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

C Suffix indicates Bidirectional

NOTE 1: TAZ are normally selected according to the reverse "Stand Off Voltage" V_{WM} which should be equal to or greater than the DC or continuous peak operating voltage level.

*The minimum breakdown voltage as shown takes into consideration the ± 1 volt tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Similar devices are available with reduced clamping voltages where tighter regulated power supply voltages are employed.

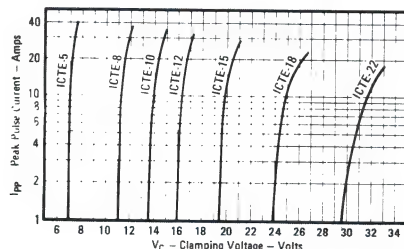


FIGURE 2
TYPICAL CHARACTERISTIC CLAMPING VOLTAGE
VS PEAK PULSE CURRENT

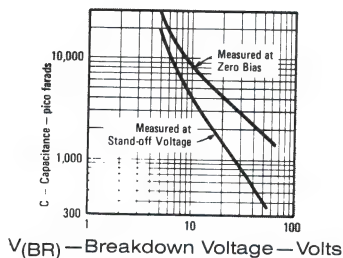


FIGURE 3
TYPICAL CAPACITANCE VS
BREAKDOWN VOLTAGE
(UNIDIRECTIONAL TYPES)

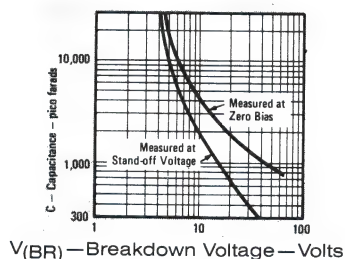


FIGURE 4
TYPICAL CAPACITANCE VS
BREAKDOWN VOLTAGE
(BIDIRECTIONAL TYPES)

micro

Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

TAZ

LC6.5 thru LC170A LOW CAPACITANCE

FEATURES

This series employs a standard TAZ in series with a rectifier with the same transient capabilities as the TAZ. The rectifier is used to reduce the effective capacitance up thru 100 MHz with a minimum amount of signal loss or deformation. The low capacitance TAZ may be applied directly across the signal line to prevent induced transients from lightning, power interruptions, or static discharge. If bipolar transient capability is required, two low-capacitance TAZ must be used in parallel, opposite in polarity for complete AC protection.

- 1500 WATTS OF PEAK PULSE POWER DISSIPATION AT 25°C
- AVAILABLE IN RANGES FROM 6.5-200V
- LOW CAPACITANCE AC SIGNAL PROTECTION

MAXIMUM RATINGS

1500 Watts of Peak Pulse Power dissipation at 25°C
 t_{clamping} (0 volts to V_{BR} min): Less than 5×10^{-9} seconds
 Operating and Storage temperatures: -65° to +175°C
 Steady State power dissipation: 1.0 W
 Repetition Rate (duty cycle): .01%

ELECTRICAL CHARACTERISTICS

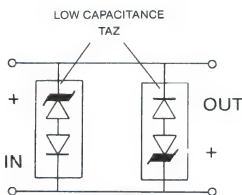
Clamping Factor: 1.4 @ Full Rated power
 1.30 @ 50% Rated power

Clamping Factor: The ratio of the actual V_C (Clamping Voltage) to the actual V_{BR} (Breakdown Voltage) as measured on a specific device.

NOTE: When pulse testing, test in Avalanche direction. DO NOT pulse in forward direction.

APPLICATION

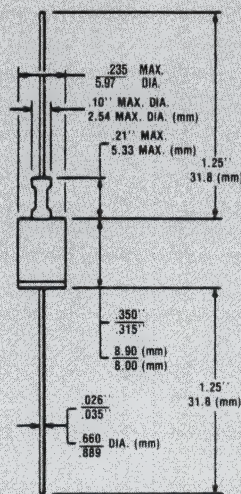
Devices must be used with two units in parallel, opposite in polarity, as shown in circuit for AC Signal Line protection:



SCHEMATIC



TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: DO-13, welded, hermetically sealed metal and glass.

FINISH: All external surfaces are corrosion resistant and leads solderable.

POLARITY: Cathode connected to case and marked.

WEIGHT: 1.4 grams (Appx.)

MOUNTING POSITION: Any

LC6.5 thru LC170A

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE V _{WM} VOLTS | BREAKDOWN VOLTAGE V _{BR} VOLTS | | @ I _r mA | MAXIMUM REVERSE LEAKAGE V _{WM} I _D μA | MAXIMUM CLAMPING VOLTAGE I _{PP} V _C VOLTS | PEAK PULSE CURRENT 10 × 1000 AMPS | CAPAC- TANCE @ 0 VOLTS pF | V _{WM} WORKING INVERSE BLOCKING VOLTAGE VOLTS | I _{IB} INVERSE BLOCKING LEAKAGE CURRENT μA | V _{PIS} PEAK INVERSE BLOCKING VOLTAGE VOLTS |
|-----------------------------|---|--|-------|------------------------|--|--|---|---------------------------------------|---|--|---|
| | | Min. | Max. | | | | | | | | |
| LC6.5 | 6.5 | 7.22 | 8.82 | 10 | 1000 | 12.3 | 100 | 100 | 75 | 1 | 100 |
| LC6.5A | 6.5 | 7.22 | 7.98 | 10 | 1000 | 11.2 | 100 | 100 | 75 | 1 | 100 |
| LC7.0 | 7.0 | 7.78 | 9.51 | 10 | 500 | 13.3 | 100 | 100 | 75 | 1 | 100 |
| LC7.0A | 7.0 | 7.78 | 8.60 | 10 | 500 | 12.0 | 100 | 100 | 75 | 1 | 100 |
| LC7.5 | 7.5 | 8.33 | 10.2 | 10 | 250 | 14.3 | 100 | 100 | 75 | 1 | 100 |
| LC7.5A | 7.5 | 8.33 | 9.21 | 10 | 250 | 12.9 | 100 | 100 | 75 | 1 | 100 |
| LC8.0 | 8.0 | 8.89 | 10.9 | 1 | 100 | 15.0 | 100 | 100 | 75 | 1 | 100 |
| LC8.0A | 8.0 | 8.89 | 9.83 | 1 | 100 | 13.6 | 100 | 100 | 75 | 1 | 100 |
| LC8.5 | 8.5 | 9.44 | 11.5 | 1 | 50 | 15.9 | 94 | 100 | 75 | 1 | 100 |
| LC8.5A | 8.5 | 9.44 | 10.4 | 1 | 50 | 14.4 | 100 | 100 | 75 | 1 | 100 |
| LC9.0 | 9.0 | 10.0 | 12.2 | 1 | 10 | 16.9 | 89 | 100 | 75 | 1 | 100 |
| LC9.0A | 9.0 | 10.0 | 11.1 | 1 | 10 | 15.4 | 97 | 100 | 75 | 1 | 100 |
| LC10 | 10 | 11.1 | 13.6 | 1 | 5 | 18.8 | 80 | 100 | 75 | 1 | 100 |
| LC10A | 10 | 11.1 | 12.3 | 1 | 5 | 17.0 | 88 | 100 | 75 | 1 | 100 |
| LC11 | 11 | 12.2 | 14.9 | 1 | 5 | 20.1 | 74 | 100 | 75 | 1 | 100 |
| LC11A | 11 | 12.2 | 13.5 | 1 | 5 | 18.2 | 82 | 100 | 75 | 1 | 100 |
| LC12 | 12 | 13.3 | 16.3 | 1 | 5 | 22.0 | 68 | 100 | 75 | 1 | 100 |
| LC12A | 12 | 13.3 | 14.7 | 1 | 5 | 19.9 | 75 | 100 | 75 | 1 | 100 |
| LC13 | 13 | 14.4 | 17.6 | 1 | 5 | 23.8 | 63 | 100 | 75 | 1 | 100 |
| LC13A | 13 | 14.4 | 15.9 | 1 | 5 | 21.5 | 70 | 100 | 75 | 1 | 100 |
| LC14 | 14 | 15.6 | 19.1 | 1 | 5 | 25.8 | 58 | 100 | 75 | 1 | 100 |
| LC14A | 14 | 15.6 | 17.2 | 1 | 5 | 23.2 | 65 | 100 | 75 | 1 | 100 |
| LC15 | 15 | 16.7 | 20.4 | 1 | 5 | 26.9 | 56 | 100 | 75 | 1 | 100 |
| LC15A | 15 | 16.7 | 18.5 | 1 | 5 | 24.4 | 61 | 100 | 75 | 1 | 100 |
| LC16 | 16 | 17.8 | 21.8 | 1 | 5 | 28.8 | 52 | 100 | 75 | 1 | 100 |
| LC16A | 16 | 17.8 | 19.7 | 1 | 5 | 26.0 | 57 | 100 | 75 | 1 | 100 |
| LC17 | 17 | 18.9 | 23.1 | 1 | 5 | 30.5 | 49 | 100 | 75 | 1 | 100 |
| LC17A | 17 | 18.9 | 20.9 | 1 | 5 | 27.9 | 54 | 100 | 75 | 1 | 100 |
| LC18 | 18 | 20.0 | 24.4 | 1 | 5 | 32.2 | 46 | 100 | 75 | 1 | 100 |
| LC18A | 18 | 20.0 | 22.1 | 1 | 5 | 29.7 | 51 | 100 | 75 | 1 | 100 |
| LC20 | 20 | 22.2 | 27.1 | 1 | 5 | 35.8 | 42 | 100 | 75 | 1 | 100 |
| LC20A | 20 | 22.2 | 24.5 | 1 | 5 | 32.4 | 46 | 100 | 75 | 1 | 100 |
| LC22 | 22 | 24.4 | 29.8 | 1 | 5 | 39.4 | 38 | 100 | 75 | 1 | 100 |
| LC22A | 22 | 24.4 | 26.9 | 1 | 5 | 35.5 | 42 | 100 | 75 | 1 | 100 |
| LC24 | 24 | 26.7 | 32.5 | 1 | 5 | 43.0 | 35 | 100 | 75 | 1 | 100 |
| LC24A | 24 | 26.7 | 29.5 | 1 | 5 | 38.9 | 39 | 100 | 75 | 1 | 100 |
| LC26 | 26 | 28.9 | 35.3 | 1 | 5 | 46.6 | 32 | 100 | 75 | 1 | 100 |
| LC26A | 26 | 28.9 | 31.9 | 1 | 5 | 42.1 | 36 | 100 | 75 | 1 | 100 |
| LC28 | 28 | 31.1 | 38.0 | 1 | 5 | 50.1 | 30 | 100 | 75 | 1 | 100 |
| LC28A | 28 | 31.1 | 34.4 | 1 | 5 | 45.4 | 33 | 100 | 75 | 1 | 100 |
| LC30 | 30 | 33.3 | 40.7 | 1 | 5 | 53.5 | 28 | 100 | 75 | 1 | 100 |
| LC30A | 30 | 33.3 | 36.6 | 1 | 5 | 48.4 | 31 | 100 | 75 | 1 | 100 |
| LC33 | 33 | 36.7 | 44.9 | 1 | 5 | 58.0 | 25.4 | 100 | 75 | 1 | 100 |
| LC33A | 33 | 36.7 | 40.6 | 1 | 5 | 53.3 | 28.1 | 100 | 75 | 1 | 100 |
| LC36 | 36 | 40.0 | 48.9 | 1 | 5 | 64.3 | 23.3 | 100 | 75 | 1 | 100 |
| LC36A | 36 | 40.0 | 44.2 | 1 | 5 | 58.1 | 25.8 | 100 | 75 | 1 | 100 |
| LC40 | 40 | 44.4 | 54.3 | 1 | 5 | 71.4 | 21.0 | 100 | 75 | 1 | 100 |
| LC40A | 40 | 44.4 | 49.1 | 1 | 5 | 64.5 | 23.3 | 100 | 75 | 1 | 100 |
| LC43 | 43 | 47.8 | 58.4 | 1 | 5 | 78.7 | 19.5 | 100 | 150 | 1 | 200 |
| LC43A | 43 | 47.8 | 52.8 | 1 | 5 | 69.4 | 21.6 | 100 | 150 | 1 | 200 |
| LC45 | 45 | 50.0 | 61.1 | 1 | 5 | 80.3 | 18.7 | 100 | 150 | 1 | 200 |
| LC45A | 45 | 50.0 | 55.3 | 1 | 5 | 72.7 | 20.6 | 100 | 150 | 1 | 200 |
| LC48 | 48 | 53.3 | 65.1 | 1 | 5 | 85.5 | 17.5 | 100 | 150 | 1 | 200 |
| LC48A | 48 | 53.3 | 58.9 | 1 | 5 | 77.4 | 19.4 | 100 | 150 | 1 | 200 |
| LC51 | 51 | 56.7 | 69.3 | 1 | 5 | 91.1 | 16.5 | 100 | 150 | 1 | 200 |
| LC51A | 51 | 56.7 | 62.7 | 1 | 5 | 82.4 | 18.2 | 100 | 150 | 1 | 200 |
| LC54 | 54 | 60.0 | 73.3 | 1 | 5 | 96.3 | 15.6 | 100 | 150 | 1 | 200 |
| LC54A | 54 | 60.0 | 66.3 | 1 | 5 | 87.1 | 17.2 | 100 | 150 | 1 | 200 |
| LC58 | 58 | 64.4 | 78.7 | 1 | 5 | 103.0 | 14.6 | 100 | 150 | 1 | 200 |
| LC58A | 58 | 64.4 | 71.2 | 1 | 5 | 93.8 | 16.0 | 100 | 150 | 1 | 200 |
| LC60 | 60 | 66.7 | 81.5 | 1 | 5 | 107.0 | 14.0 | 90 | 150 | 1 | 200 |
| LC60A | 60 | 66.7 | 73.7 | 1 | 5 | 96.8 | 15.5 | 90 | 150 | 1 | 200 |
| LC64 | 64 | 71.1 | 86.9 | 1 | 5 | 114.0 | 13.2 | 90 | 150 | 1 | 200 |
| LC64A | 64 | 71.1 | 78.6 | 1 | 5 | 103.0 | 14.6 | 90 | 150 | 1 | 200 |
| LC70 | 70 | 77.8 | 95.1 | 1 | 5 | 125 | 12.0 | 90 | 150 | 1 | 200 |
| LC70A | 70 | 77.8 | 86.0 | 1 | 5 | 113 | 13.3 | 90 | 150 | 1 | 200 |
| LC75 | 75 | 83.3 | 102.0 | 1 | 5 | 134 | 11.2 | 90 | 150 | 1 | 200 |
| LC75A | 75 | 83.3 | 92.1 | 1 | 5 | 121 | 12.4 | 90 | 150 | 1 | 200 |
| LC80 | 80 | 88.7 | 108 | 1 | 5 | 142 | 10.6 | 90 | 150 | 1 | 200 |
| LC80A | 80 | 88.7 | 98.0 | 1 | 5 | 129 | 11.6 | 90 | 150 | 1 | 200 |
| LC90 | 90 | 100 | 122 | 1 | 5 | 180 | 9.4 | 90 | 300 | 1 | 200 |
| LC90A | 90 | 100 | 111 | 1 | 5 | 146 | 10.3 | 90 | 300 | 1 | 200 |
| LC100 | 100 | 111 | 136 | 1 | 5 | 179 | 8.4 | 90 | 300 | 1 | 200 |
| LC100A | 100 | 111 | 123 | 1 | 5 | 162 | 9.3 | 90 | 300 | 1 | 200 |
| LC110 | 110 | 122 | 149 | 1 | 5 | 196 | 7.7 | 90 | 300 | 1 | 400 |
| LC110A | 110 | 122 | 135 | 1 | 5 | 178 | 8.4 | 90 | 300 | 1 | 400 |
| LC120 | 120 | 133 | 163 | 1 | 5 | 214 | 7.0 | 90 | 300 | 1 | 400 |
| LC120A | 120 | 133 | 147 | 1 | 5 | 193 | 7.8 | 90 | 300 | 1 | 400 |
| LC130 | 130 | 144 | 176 | 1 | 5 | 231 | 6.5 | 90 | 300 | 1 | 400 |
| LC130A | 130 | 144 | 159 | 1 | 5 | 209 | 7.2 | 90 | 300 | 1 | 400 |
| LC150 | 150 | 167 | 204 | 1 | 5 | 268 | 5.6 | 90 | 300 | 1 | 400 |
| LC150A | 150 | 167 | 185 | 1 | 5 | 243 | 6.2 | 90 | 300 | 1 | 400 |
| LC160 | 160 | 178 | 218 | 1 | 5 | 287 | 5.2 | 90 | 300 | 1 | 400 |
| LC160A | 160 | 178 | 197 | 1 | 5 | 259 | 5.8 | 90 | 300 | 1 | 400 |
| LC170 | 170 | 189 | 231 | 1 | 5 | 304 | 4.9 | 90 | 300 | 1 | 400 |
| LC170A | 170 | 189 | 209 | 1 | 5 | 275 | 5.4 | 90 | 300 | 1 | 400 |

NOTE 1: TAZ are normally selected according to the reverse "Stand Off Voltage (V_{WM})" which should be equal to or greater than the DC or continuous peak operating voltage level.

FEATURES

This series employs a standard TAZ in series with a rectifier with the same transient capabilities as the TAZ. The rectifier is also used to reduce the effective capacitance up thru 100 MHz with a minimum amount of signal loss or deformation. The low-capacitance TAZ may be applied directly across the signal line to prevent induced transients from lightning, power interruptions, or static discharge. If bipolar transient capability is required, two low-capacitance TAZ must be used in parallel, opposite in polarity for complete AC protection.

- 1500 WATTS OF PEAK PULSE POWER DISSIPATION AT 25°C
- AVAILABLE IN RANGES FROM 6.5—200V
- LOW CAPACITANCE AC SIGNAL PROTECTION

MAXIMUM RATINGS

1500 Watts of Peak Pulse Power dissipation at 25°C
t_{clamping} (0 volts to V_{BR}) min): Less than 5×10^{-9} seconds
Operating and Storage temperatures: -65° to +175°C
Steady State power dissipation: 5.0W @ T_L = 75°C
Lead Length = 3/8"

Repetition Rate (duty cycle): .05%

ELECTRICAL CHARACTERISTICS

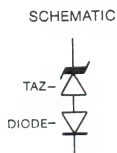
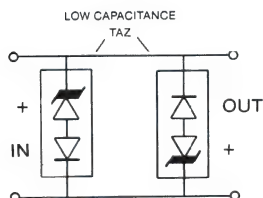
Clamping Factor: 1.4 @ Full Rated power
1.30 @ 50% Rated power

Clamping Factor: The ratio of the actual V_C (Clamping Voltage) to the actual V_{BR} (Breakdown Voltage) as measured on a specific device.

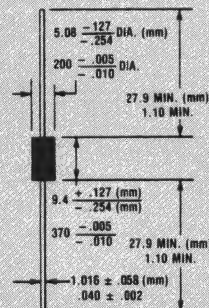
NOTE: When pulse testing, test in TAZ Avalanche direction. DO NOT pulse in forward direction.

APPLICATION

Devices must be used with two units in parallel, opposite in polarity, as shown in circuit for AC Signal Line protection:



TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: Void free transfer molded thermosetting plastic.

FINISH: Silver plated copper readily solderable.

POLARITY: Cathode marked with band.

WEIGHT: 1.5 grams (Appx.).

MOUNTING POSITION: Any.

LCE6.5 thru LCE170A

ELECTRICAL CHARACTERISTICS @ 25°C

| MICRO-SEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE V _{WM} VOLTS | BREAKDOWN VOLTAGE V _{WM} VOLTS | | @ I _T mA | MAXIMUM REVERSE LEAKAGE @ V _{WM} I _S μA | MAXIMUM CLAMPING VOLTAGE I _{sp} = V _C VOLTS | MAXIMUM PEAK PULSE CURRENT 10 x 1000 μA | CAPACITANCE @ 1 VOLTS PF | V _{WM} WORKING INVERSE BLOCKING VOLTAGE VOLTS | I _S INVERSE BLOCKING LEAKAGE CURRENT μA | V _{WM} PEAK INVERSE BLOCKING VOLTAGE VOLTS |
|------------------------|---|---|-------|------------------------|--|--|---|-----------------------------------|---|---|--|
| | | Min. | Max. | | | | | | | | |
| LCE6.5 | 6.5 | 7.22 | 8.82 | 10 | 1000 | 12.3 | 100 | 100 | 75 | 1 | 100 |
| LCE6.5A | 6.5 | 7.22 | 7.98 | 10 | 1000 | 11.2 | 100 | 100 | 75 | 1 | 100 |
| LCE7.0 | 7.0 | 7.78 | 9.51 | 10 | 500 | 13.3 | 100 | 100 | 75 | 1 | 100 |
| LCE7.0A | 7.0 | 7.78 | 8.80 | 10 | 500 | 12.0 | 100 | 100 | 75 | 1 | 100 |
| LCE7.5 | 7.5 | 8.33 | 10.2 | 10 | 250 | 14.3 | 100 | 100 | 75 | 1 | 100 |
| LCE7.5A | 7.5 | 8.33 | 9.21 | 10 | 250 | 12.9 | 100 | 100 | 75 | 1 | 100 |
| LCE8.0 | 8.0 | 8.89 | 10.9 | 1 | 100 | 15.0 | 100 | 100 | 75 | 1 | 100 |
| LCE8.0A | 8.0 | 8.89 | 9.83 | 1 | 100 | 13.6 | 100 | 100 | 75 | 1 | 100 |
| LCE8.5 | 8.5 | 9.44 | 11.5 | 1 | 50 | 15.9 | 94 | 100 | 75 | 1 | 100 |
| LCE8.5A | 8.5 | 9.44 | 10.4 | 1 | 50 | 14.4 | 100 | 100 | 75 | 1 | 100 |
| LCE9.0 | 9.0 | 10.0 | 12.2 | 1 | 10 | 16.9 | 89 | 100 | 75 | 1 | 100 |
| LCE9.0A | 9.0 | 10.0 | 11.1 | 1 | 10 | 15.4 | 97 | 100 | 75 | 1 | 100 |
| LCE10 | 10 | 11.1 | 13.6 | 1 | 5 | 18.8 | 80 | 100 | 75 | 1 | 100 |
| LCE10A | 10 | 11.1 | 12.3 | 1 | 5 | 17.0 | 88 | 100 | 75 | 1 | 100 |
| LCE11 | 11 | 12.2 | 14.9 | 1 | 5 | 20.1 | 74 | 100 | 75 | 1 | 100 |
| LCE11A | 11 | 12.2 | 13.5 | 1 | 5 | 18.2 | 82 | 100 | 75 | 1 | 100 |
| LCE12 | 12 | 13.3 | 16.3 | 1 | 5 | 22.0 | 68 | 100 | 75 | 1 | 100 |
| LCE12A | 12 | 13.3 | 14.7 | 1 | 5 | 19.9 | 75 | 100 | 75 | 1 | 100 |
| LCE13 | 13 | 14.4 | 17.8 | 1 | 5 | 23.8 | 63 | 100 | 75 | 1 | 100 |
| LCE13A | 13 | 14.4 | 15.9 | 1 | 5 | 21.5 | 70 | 100 | 75 | 1 | 100 |
| LCE14 | 14 | 15.6 | 19.1 | 1 | 5 | 25.8 | 58 | 100 | 75 | 1 | 100 |
| LCE14A | 14 | 15.6 | 17.2 | 1 | 5 | 23.2 | 65 | 100 | 75 | 1 | 100 |
| LCE15 | 15 | 16.7 | 20.4 | 1 | 5 | 28.9 | 50 | 100 | 75 | 1 | 100 |
| LCE15A | 15 | 16.7 | 18.5 | 1 | 5 | 24.4 | 61 | 100 | 75 | 1 | 100 |
| LCE16 | 16 | 17.8 | 21.8 | 1 | 5 | 29.8 | 42 | 100 | 75 | 1 | 100 |
| LCE16A | 16 | 17.8 | 19.7 | 1 | 5 | 26.0 | 57 | 100 | 75 | 1 | 100 |
| LCE17 | 17 | 18.9 | 23.1 | 1 | 5 | 30.5 | 40 | 100 | 75 | 1 | 100 |
| LCE17A | 17 | 18.9 | 20.9 | 1 | 5 | 27.6 | 54 | 100 | 75 | 1 | 100 |
| LCE18 | 18 | 20.0 | 24.4 | 1 | 5 | 32.2 | 46 | 100 | 75 | 1 | 100 |
| LCE18A | 18 | 20.0 | 22.1 | 1 | 5 | 29.2 | 51 | 100 | 75 | 1 | 100 |
| LCE20 | 20 | 22.2 | 27.1 | 1 | 5 | 35.8 | 42 | 100 | 75 | 1 | 100 |
| LCE20A | 20 | 22.2 | 24.5 | 1 | 5 | 32.4 | 46 | 100 | 75 | 1 | 100 |
| LCE22 | 22 | 24.4 | 29.8 | 1 | 5 | 39.4 | 38 | 100 | 75 | 1 | 100 |
| LCE22A | 22 | 24.4 | 26.9 | 1 | 5 | 35.5 | 42 | 100 | 75 | 1 | 100 |
| LCE24 | 24 | 26.7 | 32.9 | 1 | 5 | 43.0 | 35 | 100 | 75 | 1 | 100 |
| LCE24A | 24 | 26.7 | 29.5 | 1 | 5 | 38.9 | 39 | 100 | 75 | 1 | 100 |
| LCE26 | 26 | 28.9 | 35.3 | 1 | 5 | 46.6 | 32 | 100 | 75 | 1 | 100 |
| LCE26A | 26 | 28.9 | 31.9 | 1 | 5 | 42.1 | 36 | 100 | 75 | 1 | 100 |
| LCE28 | 28 | 31.1 | 38.0 | 1 | 5 | 50.1 | 30 | 100 | 75 | 1 | 100 |
| LCE28A | 28 | 31.1 | 34.4 | 1 | 5 | 45.5 | 33 | 100 | 75 | 1 | 100 |
| LCE30 | 30 | 33.3 | 40.7 | 1 | 5 | 53.5 | 28 | 100 | 75 | 1 | 100 |
| LCE30A | 30 | 33.3 | 36.8 | 1 | 5 | 48.4 | 31 | 100 | 75 | 1 | 100 |
| LCE33 | 33 | 36.7 | 44.9 | 1 | 5 | 59.0 | 25.4 | 100 | 75 | 1 | 100 |
| LCE33A | 33 | 36.7 | 40.6 | 1 | 5 | 53.3 | 28.1 | 100 | 75 | 1 | 100 |
| LCE36 | 36 | 40.0 | 48.9 | 1 | 5 | 64.3 | 23.3 | 100 | 75 | 1 | 100 |
| LCE36A | 36 | 40.0 | 44.2 | 1 | 5 | 58.1 | 25.8 | 100 | 75 | 1 | 100 |
| LCE40 | 40 | 44.4 | 54.3 | 1 | 5 | 71.4 | 21.0 | 100 | 75 | 1 | 100 |
| LCE40A | 40 | 44.4 | 49.1 | 1 | 5 | 64.5 | 23.3 | 100 | 75 | 1 | 100 |
| LCE43 | 43 | 47.8 | 58.4 | 1 | 5 | 76.7 | 19.5 | 100 | 150 | 1 | 200 |
| LCE43A | 43 | 47.8 | 52.8 | 1 | 5 | 69.4 | 21.6 | 100 | 150 | 1 | 200 |
| LCE45 | 45 | 50.0 | 61.1 | 1 | 5 | 80.3 | 18.7 | 100 | 150 | 1 | 200 |
| LCE45A | 45 | 50.0 | 55.3 | 1 | 5 | 72.7 | 20.6 | 100 | 150 | 1 | 200 |
| LCE48 | 48 | 53.3 | 65.1 | 1 | 5 | 85.5 | 17.5 | 100 | 150 | 1 | 200 |
| LCE48A | 48 | 53.3 | 58.9 | 1 | 5 | 77.4 | 19.4 | 100 | 150 | 1 | 200 |
| LCE51 | 51 | 56.7 | 69.3 | 1 | 5 | 91.1 | 16.5 | 100 | 150 | 1 | 200 |
| LCE51A | 51 | 56.7 | 62.7 | 1 | 5 | 82.4 | 18.2 | 100 | 150 | 1 | 200 |
| LCE54 | 54 | 60.0 | 73.3 | 1 | 5 | 98.3 | 15.6 | 100 | 150 | 1 | 200 |
| LCE54A | 54 | 60.0 | 66.3 | 1 | 5 | 87.1 | 17.2 | 100 | 150 | 1 | 200 |
| LCE56 | 56 | 64.4 | 78.7 | 1 | 5 | 109.0 | 14.6 | 100 | 150 | 1 | 200 |
| LCE58A | 58 | 64.4 | 71.2 | 1 | 5 | 93.6 | 16.0 | 100 | 150 | 1 | 200 |
| LCE60 | 60 | 66.7 | 81.5 | 1 | 5 | 107.0 | 14.0 | 90 | 150 | 1 | 200 |
| LCE60A | 60 | 66.7 | 73.7 | 1 | 5 | 96.8 | 15.5 | 90 | 150 | 1 | 200 |
| LCE64 | 64 | 71.1 | 86.9 | 1 | 5 | 114.0 | 13.2 | 90 | 150 | 1 | 200 |
| LCE64A | 64 | 71.1 | 78.6 | 1 | 5 | 103.0 | 14.6 | 90 | 150 | 1 | 200 |
| LCE70 | 70 | 77.8 | 95.1 | 1 | 5 | 125 | 12.0 | 90 | 150 | 1 | 200 |
| LCE70A | 70 | 77.8 | 86.0 | 1 | 5 | 113 | 13.3 | 90 | 150 | 1 | 200 |
| LCE75 | 75 | 83.3 | 102.0 | 1 | 5 | 134 | 11.2 | 90 | 150 | 1 | 200 |
| LCE75A | 75 | 83.3 | 92.1 | 1 | 5 | 121 | 12.4 | 90 | 150 | 1 | 200 |
| LCE80 | 80 | 88.7 | 108 | 1 | 5 | 142 | 10.6 | 90 | 150 | 1 | 200 |
| LCE80A | 80 | 88.7 | 98.0 | 1 | 5 | 129 | 11.6 | 90 | 150 | 1 | 200 |
| LCE90 | 90 | 100 | 122 | 1 | 5 | 180 | 8.4 | 90 | 300 | 1 | 200 |
| LCE90A | 90 | 100 | 111 | 1 | 5 | 146 | 10.3 | 90 | 300 | 1 | 200 |
| LCE100 | 100 | 111 | 136 | 1 | 5 | 179 | 8.4 | 90 | 300 | 1 | 200 |
| LCE100A | 100 | 111 | 123 | 1 | 5 | 162 | 9.3 | 90 | 300 | 1 | 200 |
| LCE110 | 110 | 122 | 149 | 1 | 5 | 196 | 7.7 | 90 | 300 | 1 | 400 |
| LCE110A | 110 | 122 | 135 | 1 | 5 | 178 | 8.4 | 90 | 300 | 1 | 400 |
| LCE120 | 120 | 133 | 163 | 1 | 5 | 214 | 7.0 | 90 | 300 | 1 | 400 |
| LCE120A | 120 | 133 | 147 | 1 | 5 | 193 | 7.8 | 90 | 300 | 1 | 400 |
| LCE130 | 130 | 144 | 176 | 1 | 5 | 231 | 6.5 | 90 | 300 | 1 | 400 |
| LCE130A | 130 | 144 | 159 | 1 | 5 | 209 | 7.2 | 90 | 300 | 1 | 400 |
| LCE150 | 150 | 167 | 204 | 1 | 5 | 268 | 5.6 | 90 | 300 | 1 | 400 |
| LCE150A | 150 | 167 | 185 | 1 | 5 | 243 | 6.2 | 90 | 300 | 1 | 400 |
| LCE160 | 160 | 178 | 218 | 1 | 5 | 287 | 5.2 | 90 | 300 | 1 | 400 |
| LCE160A | 160 | 178 | 197 | 1 | 5 | 259 | 5.8 | 90 | 300 | 1 | 400 |
| LCE170 | 170 | 189 | 231 | 1 | 5 | 304 | 4.9 | 90 | 300 | 1 | 400 |
| LCE170A | 170 | 189 | 209 | 1 | 5 | 275 | 5.4 | 90 | 300 | 1 | 400 |

NOTE 1: TAZ are normally selected according to the reverse "Stand Off Voltage (V_{WM})" which should be equal to or greater than the DC or continuous peak operating voltage level.

FEATURES

This series is used in automotive and vehicular applications where load-dump and field decay transients occur. The LDTS protects across-the-line dc power systems from Load Dump and Field Decay Voltage Transient Susceptibility on Power Leads.

- DESIGNED FOR DC POWER APPLICATIONS
- LOW CLAMPING RATIO

MAXIMUM RATINGS

3000 Watts of Peak Pulse Power dissipation at 50ms (see Figure 1)
 $t_{clamping}$ (0 volts to V_{BR} min.): Less than 1×10^{-12} seconds (theoretical)
 Storage temperature: -50°C to $+200^{\circ}\text{C}$
 Operating temperature: -50° to $+175^{\circ}\text{C}$ (Figure 3)
 Forward surge rating: 200 amps, 8.3ms at 25°C
 Steady state power dissipation: 50 watts, $T_C = 25^{\circ}\text{C}$
 Repetition Rate (duty cycle): 0.1%

LDTS 14 Series — Designed for a standard 12 volt power system.

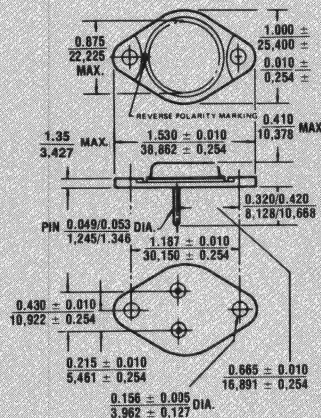
LDTS 24 Series — Designed for a standard 12 volt power system capable of sustaining a 24 volt (double voltage) jump start.

LDTS 30 Series — Designed for a standard 24 volt power system.

ELECTRICAL CHARACTERISTICS

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE (Notes 1 & 2) V_{WM} VOLTS | MINIMUM BREAKDOWN VOLTAGE V_{BR} @ 20 mA VOLTS | MAXIMUM CLAMPING VOLTAGE @ I_{FP} V_C VOLTS | MAXIMUM SURGE CURRENT (Fig. 2) I_S AMPS | MAXIMUM REVERSE LEAKAGE V_{WM} I_R μ AMPS | MAXIMUM VOLTAGE TEMP. Variation V_{BR} mW/C |
|-----------------------------|---|---|--|--|--|--|
| LDTS 14 | 14.0 | 16.0 | 26.0 | 115.5 | 100.0 | 19.0 |
| LDTS 14A | 14.0 | 16.0 | 23.5 | 128.0 | 100.0 | 17.0 |
| LDTS 24 | 24.0 | 26.5 | 43.0 | 70.0 | 100.0 | 31.0 |
| LDTS 24A | 24.0 | 26.5 | 39.0 | 77.0 | 100.0 | 29.0 |
| LDTS 30 | 30.0 | 33.0 | 54.0 | 56.0 | 100.0 | 39.0 |
| LDTS 30A | 30.0 | 33.0 | 48.5 | 62.0 | 100.0 | 36.0 |

TRANSIENT ABSORPTION ZENER



All dimensions in **INCH**
m.m. **FIGURE 1**

MECHANICAL CHARACTERISTICS

CASE: Industry standard TO-3 hermetically sealed, .052 inch diameter pins.

FINISH: All external surfaces are corrosion resistant and terminals solderable.

POLARITY: Standard polarity anode to case.

WEIGHT: 15 grams (Appx.).

MOUNTING HARDWARE: See page 41.

LDS14 thru LDS30A

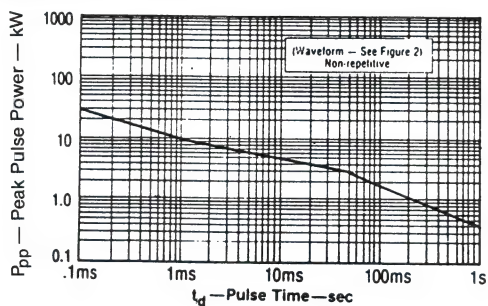
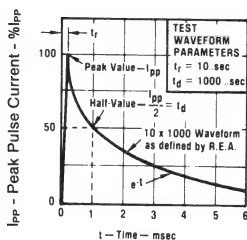
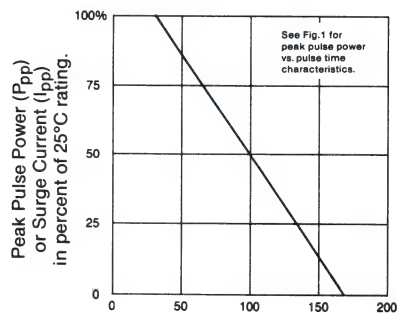


FIGURE 1
PEAK PULSE POWER
VS. PULSE TIME @ 25°C



Pulse Wave Form (10 x 1000)

FIGURE 2
SURGE WAVEFORM



T - Temperature - °C

FIGURE 3
DERATING CURVE

BIDIRECTIONAL VARISTOR MSV SERIES

FEATURES

The MSV series consists of a matched set of silicon junctions configured for bidirectional application. They can be used in telephone equipment, replacing: copper oxide varistors, fractional voltage regulators, negative temperature coefficient resistors, signal limiters and expanders. They are ideally suited for: meter/galvanometer protection, wave shaping, threshold limiters and zener diode compensation. Non-standard voltages are also available.

The MSV varistor is a PN junction device configured with two parallel-connected, matched, bidirectional, highly reliable silicon diodes. It is a two-electrode device with a voltage-dependent nonlinear resistance that drops markedly as the applied voltage is increased.

MSV devices are designed for controlled protection at various current levels and are rated at 70 amps peak pulse current.

These varistors are supplied in Microsemi's exclusive, cost-effective, highly reliable, molded axial leaded package.

MAXIMUM RATINGS

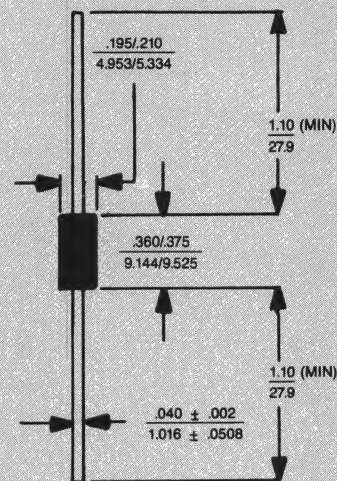
Steady State Power: 1.0 Watt at 50°C

Operating and Storage Temperatures: -65° to +175°C

Surge: 30 Amps, 8.4 msec @ 25°C

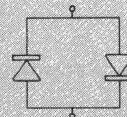
70 Amps, 1.0 msec @ 25°C

$t_{clamping}$ (0 volts to BV min.): less than 1×10^{-8} seconds (theoretical)



dimensions: inches
 mm

SCHEMATIC



MECHANICAL CHARACTERISTICS

CASE: Void free molded thermo-setting plastic.

FINISH: Silver Plated CCFE
 Readily Solderable.

POLARITY: Bidirectional.

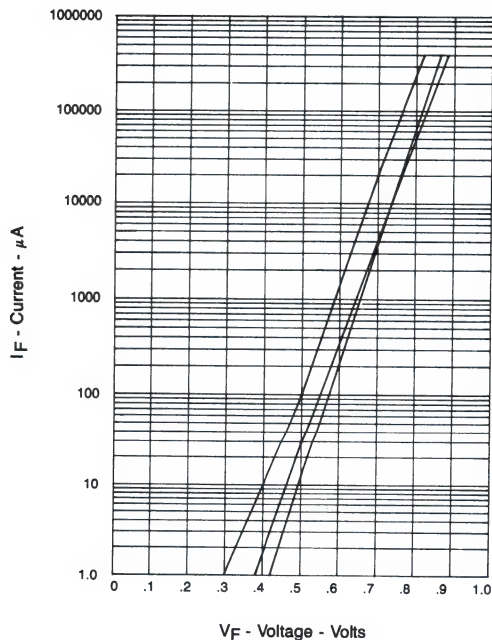
WEIGHT: 1.5 gram (Appx.).

MOUNTING POSITION: Any.

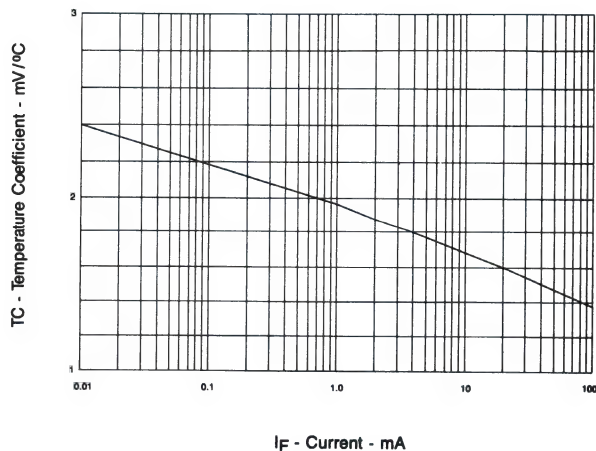
MSV SERIES

ELECTRICAL CHARACTERISTICS at 25°C (Test Both Polarities).

| MICROSEMI PART NUMBER | SYMBOL | CONDITIONS | Minimum | LIMITS | Maximum | UNITS |
|-----------------------|--------|--------------|---------|--------|---------|---------|
| MSV 101 | V_F | $10.0\mu A$ | .35 | | .50 | Vdc |
| | V_F | 100.0mA | .74 | | .85 | Vdc |
| MSV 102 | V_F | 100.0mA | .74 | | .85 | Vdc |
| | I_F | 0.2V | | | .10 | μA |
| MSV 103 | V_F | $1.0\mu A$ | .30 | | .45 | Vdc |
| | V_F | $10.0\mu A$ | .40 | | .50 | Vdc |
| | V_F | $100.0\mu A$ | .48 | | .58 | Vdc |
| | V_F | 1.0mA | .56 | | .66 | Vdc |
| | V_F | 10.0mA | .65 | | .74 | Vdc |
| | V_F | 100.0mA | .75 | | .82 | Vdc |
| MSV 201 | V_F | $20\mu A$ | .70 | | 1.00 | Vdc |
| | V_F | 100.0mA | 1.48 | | 1.70 | Vdc |



Range Curve
Current - Voltage for MSV Varistor
(Typical Curves for the MSV 103)



Ambient Temperature Coefficient
Of Voltage vs. Varistor Current

PHP8.4 thru PHP500 and PIP8.4 thru PIP500

FEATURES

- 7,500 AND 15,000 WATTS PEAK PULSE POWER DISSIPATION
- AVAILABLE IN RANGES FROM 8.4 TO 500 VOLTS
- EACH DEVICE IS 100% TESTED
- DESIGNED FOR MILITARY (PHP SERIES) AND COMMERCIAL (PIP SERIES)

PHP/PIP is designed for applications requiring "across the line" AC power protection. These TAZ modules are used in applications where extreme voltage transients can permanently damage voltage sensitive systems or components. These devices are most often used when discrete TAZ do not have high enough power requirements to suppress large power surges.

TAZ modules can be used to protect equipment from induced lightning, power surges and transients originating from inductive switching or power interrupt. The modules used for both commercial and military applications, including telecommunications, central office switching and PABX, CATV distribution, aircraft, shipboard, computers, distributed data processing and power supplies.

For military applications, the PHP module sub-assemblies are packaged in a hermetically sealed glass-to-metal package. Also available screened in accordance with MIL-S-19500/507. The PHP series modules can have design consistency with the following military requirements as controlling specifications:

- MIL-STD-1399
- MIL-STD-704
- MIL-E-16400
- MIL-S-19500/507

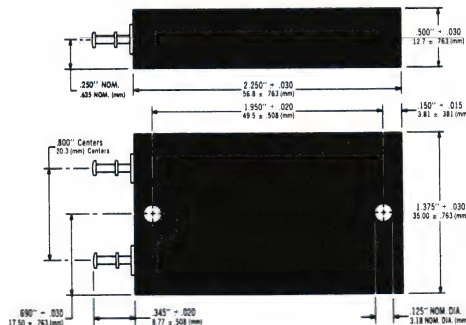
MAXIMUM RATINGS

7,500 and 15,000 watts Peak Pulse power dissipation at the 1 msec pulse and 25°C (see derating curve)

Operating and Storage temperatures: -65° to +150°C

Average Steady State power dissipation at 50°C: 7.5 watts

$t_{clamping}$ (0 volts to BV): Less than 1×10^{-8} seconds



Case 11

MILITARY APPLICATIONS: PHP series sub-assemblies are packaged in a hermetically sealed glass-to-metal package, available with design consistency to MIL-S-19500/507.

COMMERCIAL APPLICATIONS: PIP series sub-assemblies are packaged in a molded epoxy case.

TRANSIENT ABSORPTION ZENER



Case 11

MECHANICAL CHARACTERISTICS

CASE: Molded case.

TERMINAL: Silver plated brass.

POLARITY: Bidirectional.

WEIGHT: 50 grams (Appx.).

MOUNTING POSITION: Any.

PHP8.4 thru PIP500

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | AVERAGE RMS VOLTAGE VOLTS AC | REVERSE STAND-OFF VOLTAGE (NOTE 1) V _{WM} VOLTS DC | MINIMUM BREAKDOWN VOLTAGE V _(BR) @ I _t VOLTS mA | MAXIMUM REVERSE LEAKAGE I ₀ @ V _{WM} MICRO AMPERES | MAXIMUM CLAMPING VOLTAGE V _C @ I _{PP} VOLTS DC | MAXIMUM PEAK PULSE CURRENT (FIG. 3) I _{PP} A | MAXIMUM PEAK PULSE POWER (I MSEC) P _p KILOWATTS |
|-----------------------------|---------------------------------------|--|---|---|--|---|--|
| PHP8.4 | 8.4 | 12.0 | 14 10 | 250 | 22 | 341 | 7.5 |
| PHP24 | 24.0 | 34.0 | 40 10 | 250 | 67 | 112 | 7.5 |
| PHP 30 | 30.0 | 42.5 | 50 1.0 | 250 | 84 | 90 | 7.5 |
| PHP 60 | 60.0 | 85.0 | 100 1.0 | 250 | 167 | 90 | 15.0 |
| PHP 120* | 120.0 | 170.0 | 200 1.0 | 250 | 319 | 47 | 15.0 |
| PHP 208 | 208.0 | 295.0 | 347 1.0 | 250 | 536 | 28 | 15.0 |
| PHP250* | 250.0 | 354.0 | 418 1.0 | 250 | 652 | 23 | 15.0 |
| PHP 440 | 440.0 | 623.0 | 735 1.0 | 250 | 1138 | 13.2 | 15.0 |
| PHP 500* | 500.0 | 708.0 | 835 1.0 | 250 | 1292 | 11.6 | 15.0 |

| | | | | | | | |
|----------|-------|-------|---------|-----|------|------|------|
| PIP 8.4 | 8.4 | 12.0 | 14 10 | 250 | 22 | 341 | 7.5 |
| PIP 24 | 24.0 | 34.0 | 40 10 | 250 | 67 | 112 | 7.5 |
| PIP 30 | 30.0 | 42.5 | 50 1.0 | 250 | 84 | 90 | 7.5 |
| PIP 60 | 60.0 | 85.0 | 100 1.0 | 250 | 167 | 90 | 15.0 |
| PIP 120* | 120.0 | 170.0 | 200 1.0 | 250 | 319 | 47 | 15.0 |
| PIP 208 | 208.0 | 295.0 | 347 1.0 | 250 | 536 | 28 | 15.0 |
| PIP 250* | 250.0 | 354.0 | 418 1.0 | 250 | 652 | 23 | 15.0 |
| PIP 440 | 440.0 | 623.0 | 735 1.0 | 250 | 1138 | 13.2 | 15.0 |
| PIP 500* | 500.0 | 708.0 | 835 1.0 | 250 | 1292 | 11.6 | 15.0 |

Special Voltages available from factory. *Recommended for marine applications.

NOTE 1: A TAZ is normally selected according to the reverse "Stand Off Voltage" (V_R) which should be equal to or greater than the DC or continuous peak operating voltage level.

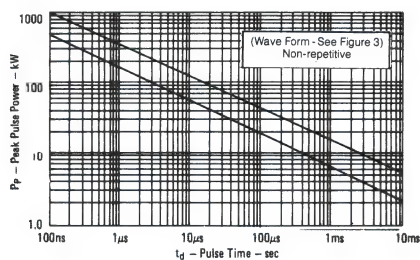


FIGURE 1
PEAK PULSE POWER
VS. PULSE TIME

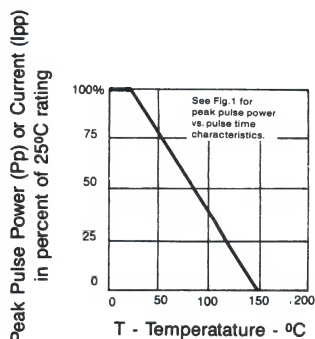


FIGURE 2
PULSE WAVEFORM

DERATING CURVE

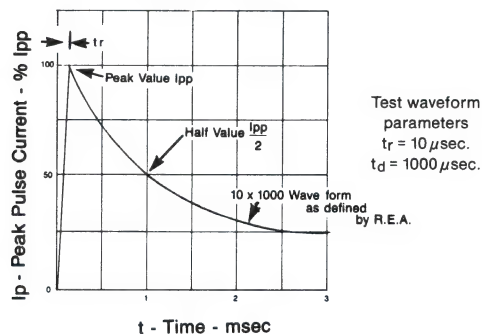


FIGURE 3
PULSE WAVEFORM

FEATURES

- ECONOMICAL SERIES
- AVAILABLE IN BOTH UNIDIRECTIONAL AND BIDIRECTIONAL CONSTRUCTION
- 5.0 TO 170 STAND-OFF VOLTS AVAILABLE
- 500 WATTS PEAK PULSE POWER DISSIPATION
- QUICK RESPONSE

MAXIMUM RATINGS

Peak Pulse Power Dissipation at 25°C: 500 Watts

Steady State Power Dissipation: 2.5 Watts at $T_L = +75^\circ\text{C}$

3/8" Lead Length

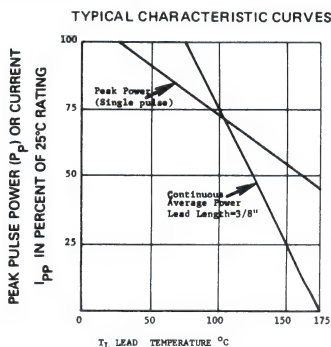
t_{clamping} (0 Volts to BV Min.):

Unidirectional $< 1 \times 10^{-12}$ Seconds; Bidirectional $< 5 \times 10^{-9}$ Seconds.

Operating and Storage Temperature: -65° to $+175^\circ\text{C}$

APPLICATION

TAZ is an economical, molded, commercial product used to protect voltage-sensitive components from destruction or partial degradation. The response time of their clamping action is virtually instantaneous (1×10^{-12} Sec) and they have a peak pulse power rating of 500 watts for 1 msec as depicted in Figure 1 and 2. Microsemi also offers various varieties of TAZ's to meet higher and lower power demands and special applications.



DERATING CURVE

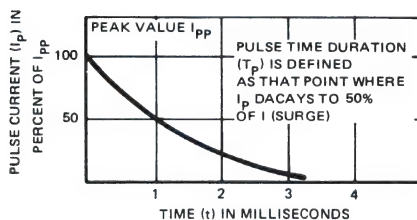
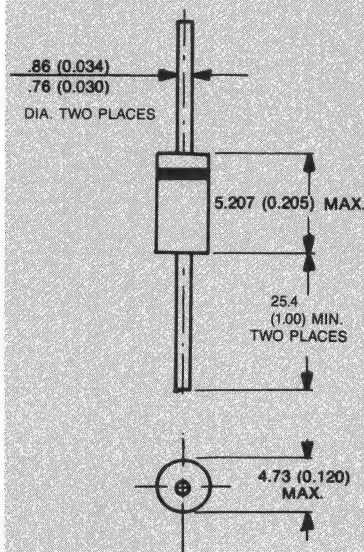


FIGURE 1
PULSE WAVEFORM FOR
EXPONENTIAL SURGE

TRANSIENT ABSORPTION ZENER



Cathode Indicated by Band
All Dimensions in Millimeters (Inches)

MECHANICAL CHARACTERISTICS

CASE: Void free transfer molded thermosetting plastic.

FINISH: Silver plated copper readily solderable.

POLARITY: Band denotes cathode. Bidirectional not marked.

WEIGHT: 0.7 gram (Appx.).

MOUNTING POSITION: Any.

P5KE5.0 thru P5KE170

ELECTRICAL CHARACTERISTICS at 25°C

| PART NUMBER | BREAKDOWN VOLTAGE V _(BR) | | TEST CURRENT I _T | RATED STAND OFF VOLTAGE V _{WM} | REVERSE LEAKAGE CURRENT I _D @ V _{WM} | PULSE REVERSE VOLTAGE V _C MAX @ I _{PP} | PULSE CURRENT I _{PP} | TEMP. COEFFICIENT OF V _(BR) (TA) -55° C TO 100° C %/V _{WM} |
|-------------|--|-----------------|--------------------------------|--|---|---|----------------------------------|---|
| | MIN | MAX. | | | | | | |
| | V _{DC} | V _{DC} | mA | V | μA | V | A | % / °C |
| P5KE5.0 | 6.4 | 7.3 | 10 | 5.0 | 600 | 9.6 | 52 | .057 |
| P5KE5.0A | 6.4 | 7.0 | 10 | 5.0 | 600 | 9.2 | 54.3 | .057 |
| P5KE6.0 | 6.67 | 8.15 | 10 | 6.0 | 600 | 11.4 | 43.9 | .059 |
| P5KE6.0A | 6.67 | 7.37 | 10 | 6.0 | 600 | 10.3 | 48.5 | .059 |
| P5KE6.5 | 7.22 | 8.82 | 10 | 6.5 | 400 | 12.3 | 40.7 | .061 |
| P5KE6.5A | 7.22 | 7.98 | 10 | 6.5 | 400 | 11.2 | 44.7 | .061 |
| P5KE7.0 | 7.78 | 9.51 | 10 | 7.0 | 150 | 13.3 | 37.8 | .065 |
| P5KE7.0A | 7.78 | 8.40 | 10 | 7.0 | 150 | 12.0 | 42.0 | .065 |
| P5KE7.5 | 8.33 | 10.2 | 1 | 7.5 | 50 | 14.3 | 35.0 | .067 |
| P5KE7.5A | 8.33 | 9.21 | 1 | 7.5 | 50 | 12.9 | 38.8 | .067 |
| P5KE8.0 | 8.89 | 10.9 | 1 | 8.0 | 25 | 15.0 | 33.3 | .070 |
| P5KE8.0A | 8.89 | 9.83 | 1 | 8.0 | 25 | 13.6 | 36.7 | .070 |
| P5KE8.5 | 9.44 | 11.5 | 1 | 8.5 | 5 | 15.9 | 31.4 | .073 |
| P5KE8.5A | 9.44 | 10.4 | 1 | 8.5 | 5 | 14.4 | 34.7 | .073 |
| P5KE9.0 | 10.0 | 12.2 | 1 | 9.0 | 1 | 16.9 | 29.5 | .076 |
| P5KE9.0A | 10.0 | 11.1 | 1 | 9.0 | 1 | 15.4 | 32.5 | .076 |
| P5KE10 | 11.1 | 13.6 | 1 | 10 | 1 | 18.8 | 26.6 | .078 |
| P5KE10A | 11.1 | 12.3 | 1 | 10 | 1 | 17.0 | 29.4 | .078 |
| P5KE11 | 12.2 | 14.9 | 1 | 11 | 1 | 20.1 | 24.9 | .081 |
| P5KE11A | 12.2 | 13.5 | 1 | 11 | 1 | 18.2 | 27.4 | .081 |
| P5KE12 | 13.3 | 16.3 | 1 | 12 | 1 | 22.0 | 22.7 | .082 |
| P5KE12A | 13.3 | 14.7 | 1 | 12 | 1 | 19.9 | 25.1 | .082 |
| P5KE13 | 14.4 | 17.6 | 1 | 13 | 1 | 21.0 | 23.8 | .084 |
| P5KE13A | 14.4 | 15.9 | 1 | 13 | 1 | 21.5 | 23.2 | .084 |
| P5KE14 | 15.6 | 19.1 | 1 | 14 | 1 | 25.8 | 19.4 | .086 |
| P5KE14A | 15.6 | 17.2 | 1 | 14 | 1 | 23.2 | 21.5 | .086 |
| P5KE15 | 16.7 | 20.4 | 1 | 15 | 1 | 28.9 | 18.8 | .087 |
| P5KE15A | 16.7 | 18.5 | 1 | 15 | 1 | 24.4 | 20.6 | .087 |
| P5KE16 | 17.8 | 21.8 | 1 | 16 | 1 | 28.8 | 17.6 | .088 |
| P5KE16A | 17.8 | 19.7 | 1 | 16 | 1 | 26.0 | 19.2 | .088 |
| P5KE17 | 18.9 | 23.1 | 1 | 17 | 1 | 30.5 | 16.4 | .090 |
| P5KE17A | 18.9 | 20.9 | 1 | 17 | 1 | 27.6 | 18.1 | .090 |
| P5KE18 | 20.0 | 24.4 | 1 | 18 | 1 | 32.2 | 15.5 | .092 |
| P5KE18A | 20.0 | 22.1 | 1 | 18 | 1 | 29.2 | 17.2 | .092 |
| P5KE20 | 22.2 | 27.1 | 1 | 20 | 1 | 35.8 | 13.9 | .093 |
| P5KE20A | 22.2 | 24.5 | 1 | 20 | 1 | 32.4 | 15.4 | .093 |
| P5KE22 | 24.4 | 29.8 | 1 | 22 | 1 | 39.4 | 12.7 | .094 |
| P5KE22A | 24.4 | 26.9 | 1 | 22 | 1 | 35.5 | 14.1 | .094 |
| P5KE24 | 26.7 | 32.6 | 1 | 24 | 1 | 43.0 | 11.6 | .096 |
| P5KE24A | 26.7 | 29.5 | 1 | 24 | 1 | 38.9 | 12.8 | .096 |
| P5KE26 | 28.9 | 35.3 | 1 | 26 | 1 | 46.6 | 10.7 | .097 |
| P5KE26A | 28.9 | 31.9 | 1 | 26 | 1 | 42.1 | 11.9 | .097 |
| P5KE28 | 31.1 | 38.0 | 1 | 28 | 1 | 50.0 | 9.9 | .098 |
| P5KE28A | 31.1 | 34.4 | 1 | 28 | 1 | 45.4 | 11.0 | .098 |
| P5KE30 | 33.3 | 40.7 | 1 | 30 | 1 | 53.5 | 9.3 | .099 |
| P5KE30A | 33.3 | 36.8 | 1 | 30 | 1 | 48.4 | 10.3 | .099 |
| P5KE33 | 36.7 | 44.9 | 1 | 33 | 1 | 59.0 | 8.0 | .100 |
| P5KE33A | 36.7 | 40.6 | 1 | 33 | 1 | 53.3 | 9.4 | .100 |
| P5KE35 | 40.0 | 48.9 | 1 | 36 | 1 | 64.3 | 7.8 | .101 |
| P5KE36A | 40.0 | 44.2 | 1 | 36 | 1 | 58.1 | 8.6 | .101 |
| P5KE40 | 44.4 | 54.3 | 1 | 40 | 1 | 71.4 | 7.0 | .101 |
| P5KE40A | 44.4 | 49.1 | 1 | 40 | 1 | 64.5 | 7.8 | .101 |
| P5KE43 | 47.8 | 58.4 | 1 | 43 | 1 | 76.7 | 6.5 | .102 |
| P5KE43A | 47.8 | 52.8 | 1 | 43 | 1 | 69.4 | 7.2 | .102 |
| P5KE45 | 50.0 | 61.1 | 1 | 45 | 1 | 80.3 | 6.2 | .102 |
| P5KE45A | 50.0 | 55.3 | 1 | 45 | 1 | 72.7 | 6.9 | .102 |
| P5KE48 | 53.3 | 65.1 | 1 | 48 | 1 | 85.5 | 5.8 | .103 |
| P5KE48A | 53.3 | 58.9 | 1 | 48 | 1 | 77.4 | 6.5 | .103 |
| P5KE51 | 56.7 | 69.3 | 1 | 51 | 1 | 91.1 | 5.5 | .103 |
| P5KE51A | 56.7 | 62.7 | 1 | 51 | 1 | 82.4 | 6.1 | .103 |
| P5KE54 | 60.0 | 73.3 | 1 | 54 | 1 | 96.3 | 5.2 | .104 |
| P5KE54A | 60.0 | 66.3 | 1 | 54 | 1 | 87.1 | 5.7 | .104 |
| P5KE58 | 64.4 | 78.7 | 1 | 58 | 1 | 103.0 | 4.9 | .104 |
| P5KE58A | 64.4 | 71.2 | 1 | 58 | 1 | 93.6 | 5.3 | .104 |
| P5KE60 | 66.7 | 81.5 | 1 | 60 | 1 | 107.0 | 4.7 | .104 |
| P5KE60A | 66.7 | 73.7 | 1 | 60 | 1 | 96.8 | 5.2 | .104 |
| P5KE64 | 71.1 | 86.9 | 1 | 64 | 1 | 114.0 | 4.4 | .103 |
| P5KE64A | 71.1 | 78.6 | 1 | 64 | 1 | 103.0 | 4.9 | .105 |
| P5KE70 | 77.8 | 95.1 | 1 | 70 | 1 | 125.0 | 4.0 | .105 |
| P5KE70A | 77.8 | 86.0 | 1 | 70 | 1 | 113.0 | 4.4 | .105 |
| P5KE75 | 83.3 | 102.0 | 1 | 75 | 1 | 134.0 | 3.7 | .105 |
| P5KE75A | 83.3 | 92.1 | 1 | 75 | 1 | 121.0 | 4.1 | .105 |
| P5KE78 | 86.7 | 106.0 | 1 | 78 | 1 | 139.0 | 3.6 | .106 |
| P5KE78A | 86.7 | 95.8 | 1 | 78 | 1 | 126.0 | 4.0 | .106 |
| P5KE85 | 94.4 | 115.0 | 1 | 85 | 1 | 151.0 | 3.3 | .106 |
| P5KE85A | 94.4 | 104.0 | 1 | 85 | 1 | 137.0 | 3.6 | .106 |
| P5KE90 | 100.0 | 122.0 | 1 | 90 | 1 | 160.0 | 3.1 | .107 |
| P5KE90A | 100.0 | 111.0 | 1 | 90 | 1 | 146.0 | 3.4 | .107 |
| P5KE100 | 111.0 | 136.0 | 1 | 100 | 1 | 179.0 | 2.8 | .107 |
| P5KE100A | 111.0 | 123.0 | 1 | 100 | 1 | 162.0 | 3.1 | .107 |
| P5KE110 | 122.0 | 149.0 | 1 | 110 | 1 | 196.0 | 2.6 | .107 |
| P5KE110A | 122.0 | 135.0 | 1 | 110 | 1 | 177.0 | 2.8 | .107 |
| P5KE120 | 133.0 | 163.0 | 1 | 120 | 1 | 214.0 | 2.3 | .107 |
| P5KE120A | 133.0 | 147.0 | 1 | 120 | 1 | 193.0 | 2.6 | .107 |
| P5KE130 | 144.0 | 176.0 | 1 | 130 | 1 | 231.0 | 2.2 | .108 |
| P5KE130A | 144.0 | 159.0 | 1 | 130 | 1 | 209.0 | 2.4 | .108 |
| P5KE150 | 167.0 | 204.0 | 1 | 150 | 1 | 268.0 | 1.9 | .108 |
| P5KE150A | 167.0 | 185.0 | 1 | 150 | 1 | 243.0 | 2.1 | .108 |
| P5KE160 | 178.0 | 218.0 | 1 | 160 | 1 | 287.0 | 1.7 | .108 |
| P5KE160A | 178.0 | 197.0 | 1 | 160 | 1 | 259.0 | 1.9 | .108 |
| P5KE170 | 189.0 | 231.0 | 1 | 170 | 1 | 304.0 | 1.6 | .108 |
| P5KE170A | 189.0 | 209.0 | 1 | 170 | 1 | 275.0 | 1.8 | .108 |

SYMBOLS AND ABBREVIATIONS

| | |
|----------------------|----------------------------|
| V _{WM} | = Rated Stand-Off Voltage |
| I _{PP} | = Peak Pulse Current |
| P _{PP} | = Peak Pulse Power |
| V _C (MAX) | = Maximum Clamping Voltage |
| V _(BR) | = Breakdown Voltage |
| I _T | = Test Current |
| I _D | = Reverse Leakage |

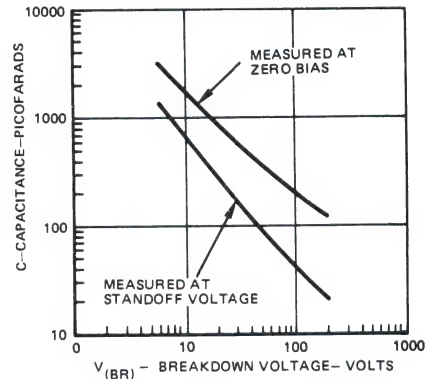


FIGURE 3
P5KE TYPICAL CAPACITANCE VS
BREAKDOWN VOLTAGE

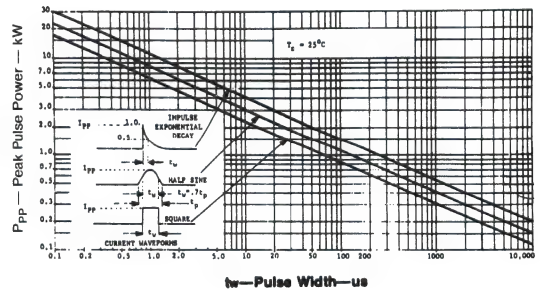


FIGURE 4
PEAK PULSE POWER VS PULSE TIME

Forward Voltage (V_f) @ 35 amps peak, 8.3 msec sine wave equal to 3.5 volts max.
(Excluding Bidirectional)

For Bidirectional Construction, indicate a C or CA suffix after part number i.e.
P5KE170CA.

micro

Microsemi Corp.

The diode experts

SANTA ANA, CA

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

TAZ

**P6KE6.8 thru
P6KE200**

FEATURES

- ECONOMICAL SERIES
- AVAILABLE IN BOTH UNIDIRECTIONAL AND BIDIRECTIONAL CONSTRUCTION
- 6.8 TO 200 VOLTS AVAILABLE
- 600 WATTS PEAK PULSE POWER DISSIPATION

MAXIMUM RATINGS

Peak Pulse Power Dissipation at 25°C: 600 Watts

Steady State Power Dissipation: 5 Watts at $T_L = +75^\circ\text{C}$, 3/8" Lead Length
 t_{clamping} (0 Volts to BV Min.):

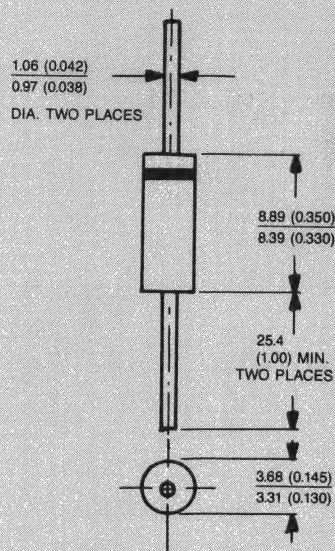
Unidirectional $< 1 \times 10^{-12}$ Seconds; Bidirectional $< 5 \times 10^{-9}$ Seconds.

Operating and Storage Temperature: -65° to 200°C

APPLICATION

TAZ is an economical, molded, commercial product used to protect voltage-sensitive components from destruction or partial degradation. The response time of their clamping action is virtually instantaneous (1×10^{-12} Sec) and they have a peak pulse power rating of 600 watts for 1 msec as depicted in Figure 1 and 2. Microsemi also offers various varieties of TAZ's to meet higher and lower power demands and special applications.

TRANSIENT ABSORPTION ZENER



Cathode Indicated by Band
All Dimensions in Millimeters (Inches)

MECHANICAL CHARACTERISTICS

CASE: Void free transfer molded thermosetting plastic (T-18).

FINISH: Silver plated copper readily solderable.

POLARITY: Band denotes cathode. Bidirectional not marked.

WEIGHT: 0.7 gram (Appx.).

MOUNTING POSITION: Any.

P6KE6.5 thru P6KE200A

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$

| MICROSEMI PART NUMBER | BREAKDOWN VOLTAGE $V_{(BR)}$ NOM. | | | TEST CURRENT I_T | RATED STAND-OFF VOLTAGE V_{WM} | MAX. REVERSE LEAKAGE CURRENT I_R @ V_{WM} | MAX. PEAK REVERSE VOLTAGE V_C MAX @ I_{PP} | MAX. PEAK PULSE CURRENT I_{PP} | MAX. TEMP. COEFFICIENT OF V_{BR} $\propto V_{(BR)}$ (T_A) -55°C To 100°C |
|-----------------------------|--|-----|------|--------------------------|---|--|--|--|--|
| | MIN. | VDC | MAX. | | | | | | |
| P6KE6.8 | 6.12 | 6.8 | 7.48 | 10 | 5.5 | 1000 | 10.8 | 56 | .057 |
| P6KE6.8A | 8.45 | 8.8 | 7.14 | 10 | 5.8 | 1000 | 10.5 | 57 | .057 |
| P6KE7.5 | 6.75 | 7.5 | 8.25 | 10 | 6.05 | 500 | 11.7 | 51 | .061 |
| P6KE7.5A | 7.13 | 7.5 | 7.88 | 10 | 6.4 | 500 | 11.3 | 53 | .061 |
| P6KE8.2 | 7.38 | 8.2 | 9.02 | 10 | 6.63 | 200 | 12.5 | 48 | .065 |
| P6KE8.2A | 7.79 | 8.2 | 8.61 | 10 | 7.02 | 200 | 12.1 | 50 | .065 |
| P6KE9.1 | 8.19 | 9.1 | 10 | 1 | 7.37 | 50 | 13.8 | 44 | .068 |
| P6KE9.1A | 8.65 | 9.1 | 8.55 | 1 | 7.78 | 50 | 13.4 | 45 | .068 |
| P6KE10 | 9.0 | 10 | 11 | 1 | 8.1 | 10 | 15 | 40 | .073 |
| P6KE10A | 9.5 | 10 | 10.5 | 1 | 8.55 | 10 | 14.5 | 41 | .073 |
| P6KE11 | 9.9 | 11 | 12.1 | 1 | 8.92 | 5 | 16.2 | 37 | .075 |
| P6KE11A | 10.5 | 11 | 11.6 | 1 | 9.4 | 5 | 15.8 | 38 | .075 |
| P6KE12 | 10.8 | 12 | 13.2 | 1 | 9.72 | 5 | 17.3 | 35 | .078 |
| P6KE12A | 11.4 | 12 | 12.6 | 1 | 10.2 | 5 | 16.7 | 36 | .078 |
| P6KE13 | 11.7 | 13 | 14.3 | 1 | 10.5 | 5 | 19 | 32 | .081 |
| P6KE13A | 12.4 | 13 | 13.7 | 1 | 11.1 | 5 | 18.2 | 33 | .081 |
| P6KE15 | 13.5 | 15 | 16.5 | 1 | 12.1 | 5 | 22 | 27 | .084 |
| P6KE15A | 14.3 | 15 | 15.8 | 1 | 12.8 | 5 | 21.2 | 28 | .084 |
| P6KE16 | 14.4 | 16 | 17.6 | 1 | 12.9 | 5 | 23.5 | 26 | .086 |
| P6KE16A | 15.2 | 16 | 16.8 | 1 | 13.6 | 5 | 22.5 | 27 | .086 |
| P6KE18 | 16.2 | 18 | 19.8 | 1 | 14.5 | 5 | 26.5 | 23 | .088 |
| P6KE18A | 17.1 | 18 | 18.9 | 1 | 15.3 | 5 | 25.2 | 24 | .088 |
| P6KE20 | 18 | 20 | 22 | 1 | 16.2 | 5 | 28.1 | 21 | .090 |
| P6KE20A | 19 | 20 | 21 | 1 | 17.1 | 5 | 27.7 | 22 | .090 |
| P6KE22 | 19.8 | 22 | 24.2 | 1 | 17.8 | 5 | 31.9 | 19 | .092 |
| P6KE22A | 20.9 | 22 | 23.1 | 1 | 18.8 | 5 | 30.6 | 20 | .092 |
| P6KE24 | 21.8 | 24 | 26.4 | 1 | 19.4 | 5 | 34.7 | 17 | .094 |
| P6KE24A | 22.8 | 24 | 25.2 | 1 | 20.5 | 5 | 33.7 | 18 | .094 |
| P6KE27 | 24.3 | 27 | 29.7 | 1 | 21.8 | 5 | 38.1 | 15 | .096 |
| P6KE27A | 25.7 | 27 | 28.4 | 1 | 23.1 | 5 | 37.5 | 16 | .096 |
| P6KE30 | 27 | 30 | 33 | 1 | 24.3 | 5 | 43.5 | 14 | .097 |
| P6KE30A | 28.5 | 30 | 31.5 | 1 | 25.6 | 5 | 41.4 | 14.4 | .097 |
| P6KE33 | 29.7 | 33 | 36.3 | 1 | 26.8 | 5 | 47.7 | 12.6 | .098 |
| P6KE33A | 31.4 | 33 | 34.7 | 1 | 28.2 | 5 | 45.7 | 13.2 | .098 |
| P6KE36 | 32.4 | 36 | 39.6 | 1 | 29.1 | 5 | 52 | 11.6 | .099 |
| P6KE36A | 34.2 | 36 | 37.8 | 1 | 30.8 | 5 | 49.9 | 12 | .099 |
| P6KE39 | 35.1 | 39 | 42.9 | 1 | 31.6 | 5 | 58.4 | 10.6 | .100 |
| P6KE39A | 37.1 | 39 | 41 | 1 | 33.3 | 5 | 53.9 | 11.2 | .100 |
| P6KE43 | 38.7 | 43 | 47.3 | 1 | 34.8 | 5 | 61.9 | 9.6 | .101 |
| P6KE43A | 40.9 | 43 | 45.2 | 1 | 36.8 | 5 | 59.3 | 10.1 | .101 |
| P6KE47 | 42.3 | 47 | 51.7 | 1 | 38.1 | 5 | 67.8 | 8.8 | .101 |
| P6KE47A | 44.7 | 47 | 49.4 | 1 | 40.2 | 5 | 64.8 | 9.3 | .101 |
| P6KE51 | 45.9 | 51 | 56.1 | 1 | 41.3 | 5 | 73.5 | 8.2 | .102 |
| P6KE51A | 48.5 | 51 | 53.6 | 1 | 43.6 | 5 | 70.1 | 8.6 | .102 |
| P6KE56 | 50.4 | 56 | 61.6 | 1 | 45.4 | 5 | 80.5 | 7.4 | .103 |
| P6KE56A | 53.2 | 56 | 58.8 | 1 | 47.8 | 5 | 77 | 7.8 | .103 |
| P6KE62 | 55.8 | 62 | 68.2 | 1 | 50.2 | 5 | 88 | 6.8 | .104 |
| P6KE62A | 58.9 | 62 | 65.1 | 1 | 53 | 5 | 85 | 7.1 | .104 |
| P6KE68 | 61.2 | 68 | 74.8 | 1 | 55.1 | 5 | 98 | 6.1 | .104 |
| P6KE68A | 64.6 | 68 | 71.4 | 1 | 58.1 | 5 | 92 | 6.5 | .104 |
| P6KE75 | 67.5 | 75 | 82.5 | 1 | 60.7 | 5 | 108 | 5.5 | .105 |
| P6KE75A | 71.3 | 75 | 78.8 | 1 | 64.1 | 5 | 103 | 5.8 | .105 |
| P6KE82 | 73.8 | 82 | 90.2 | 1 | 66.4 | 5 | 118 | 5.1 | .105 |
| P6KE82A | 77.9 | 82 | 86.1 | 1 | 70.1 | 5 | 113 | 5.3 | .105 |
| P6KE91 | 81.9 | 91 | 100 | 1 | 73.7 | 5 | 131 | 4.5 | .106 |
| P6KE91A | 86.5 | 91 | 95.5 | 1 | 77.8 | 5 | 125 | 4.8 | .106 |
| P6KE100 | 90 | 100 | 110 | 1 | 81 | 5 | 144 | 4.2 | .106 |
| P6KE100A | 95 | 100 | 105 | 1 | 85.5 | 5 | 137 | 4.4 | .106 |
| P6KE110 | 99 | 110 | 121 | 1 | 89.2 | 5 | 158 | 3.8 | .107 |
| P6KE110A | 105 | 110 | 116 | 1 | 94 | 5 | 152 | 3.4 | .107 |
| P6KE120 | 108 | 120 | 132 | 1 | 97.2 | 5 | 173 | 3.5 | .107 |
| P6KE120A | 114 | 120 | 126 | 1 | 102 | 5 | 165 | 3.6 | .107 |
| P6KE130 | 117 | 130 | 143 | 1 | 105 | 5 | 187 | 3.2 | .107 |
| P6KE130A | 124 | 130 | 137 | 1 | 111 | 5 | 179 | 3.3 | .107 |
| P6KE150 | 135 | 150 | 165 | 1 | 121 | 5 | 215 | 2.8 | .108 |
| P6KE150A | 143 | 150 | 158 | 1 | 128 | 5 | 207 | 2.9 | .108 |
| P6KE160 | 144 | 160 | 176 | 1 | 130 | 5 | 230 | 2.6 | .108 |
| P6KE160A | 152 | 160 | 168 | 1 | 136 | 5 | 219 | 2.7 | .108 |
| P6KE170 | 153 | 170 | 187 | 1 | 138 | 5 | 244 | 2.5 | .108 |
| P6KE170A | 161 | 170 | 179 | 1 | 145 | 5 | 234 | 2.6 | .108 |
| P6KE180 | 162 | 180 | 198 | 1 | 146 | 5 | 258 | 2.3 | .108 |
| P6KE180A | 171 | 180 | 189 | 1 | 154 | 5 | 248 | 2.4 | .108 |
| P6KE200 | 180 | 200 | 220 | 1 | 162 | 5 | 287 | 2.1 | .108 |
| P6KE200A | 190 | 200 | 210 | 1 | 171 | 5 | 274 | 2.2 | .108 |

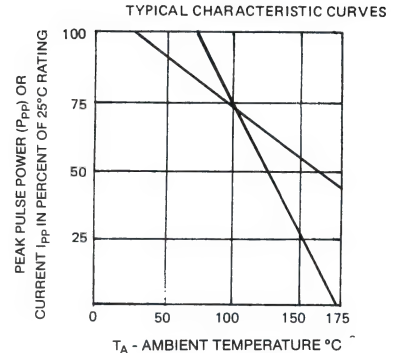


FIGURE 1
DERATING CURVE

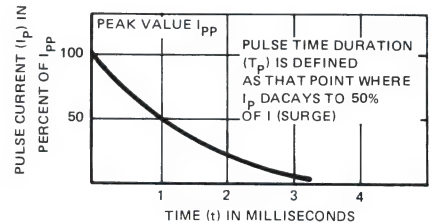


FIGURE 2
PULSE WAVEFORM FOR
EXPONENTIAL SURGE

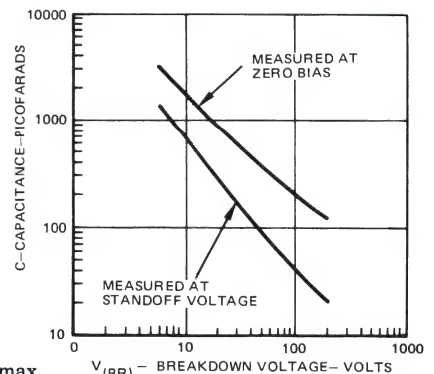


FIGURE 3
P6KE TYPICAL CAPACITANCE
VS BREAKDOWN VOLTAGE

Forward Voltage (V_F) @ 50 amps peak, 8.3 msec sine wave equal to 3.5 volts max.
(Excluding Bidirectional)

For Bidirectional Construction, indicate C or CA suffix after part number i.e.
P6KE200CA.

SYMBOLS AND ABBREVIATIONS

| | |
|------------|---------------------------|
| V_{WM} | = Rated Stand-Off Voltage |
| I_{PP} | = Peak Pulse Current |
| P_P | = Peak Pulse Power |
| V_C | = Clamping Voltage |
| $V_{(BR)}$ | = Breakdown Voltage |
| I_T | = Test Current |
| I_D | = Reverse Leakage |

P7KE10 thru P7KE100C

FEATURES

- VOLTAGES FROM 10.0 TO 100V STAND-OFF (V_{WM})
- UNIDIRECTIONAL OR BIDIRECTIONAL
- LOW COST

The P7KE10 thru P7KE100C TAZ is a low cost silicon transient suppressor series designed to protect applications in telephone switching where large voltage transients can permanently damage voltage-sensitive components. TAZ has a peak pulse power rating of 700 watts for 1 millisecond. The response time of the TAZ clamping action is less than (1×10^{-12}) seconds and therefore can be used in applications where induced lightning on rural or remote transmission lines presents a hazard to electronic circuitry. They can also be used to protect integrated circuits, MOS devices, hybrids and other voltage-sensitive semiconductors and components.

MAXIMUM RATINGS

700 Watts of Peak Pulse Power dissipation at 25°C (see derating curve)
 $t_{clamping}$ (0 volts to BV min): Less than 1×10^{-9} seconds (Bidirectional),
 1×10^{-12} seconds (Unidirectional)

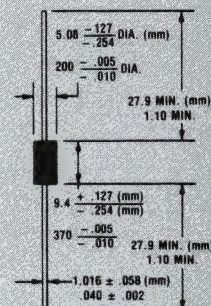
Operating and Storage temperatures: -55° to +175°C

Forward surge rating: 133 amps, (Except Bidirectional)

| MICROSEMI PART NUMBER | | REVERSE STAND-OFF VOLTAGE (NOTE 1) V_{WM} VOLTS | BREAKDOWN VOLTAGE $V_{(BR)}$ @ $I_D = 5mA$ VOLTS | | MAXIMUM CLAMPING VOLTAGE (Fig. 2) V_C @ I_{PP} VOLTS | MAXIMUM REVERSE LEAKAGE CURRENT I_D @ V_{WM} μA | MAXIMUM PEAK PULSE CURRENT (Fig. 2) I_{PP} AMPS | MAXIMUM TEMP. COEFFICIENT $V_{(BR)}$ OF $V_{(BR)}$ %/°C |
|--------------------------|---------------|--|---|-------|---|---|--|--|
| Unidirectional | Bidirectional | | MIN. | MAX. | | | | |
| P7KE10 | P7KE10C | 10 | 13.0 | 20.0 | 25 | 5.0 | 30 | .10 |
| P7KE25 | P7KE25C | 25 | 29.6 | 43.5 | 53 | 5.0 | 13 | .11 |
| P7KE43 | P7KE43C | 43 | 50.0 | 75.0 | 90 | 5.0 | 8 | .12 |
| P7KE100 | P7KE100C | 100 | 130.0 | 200.0 | 235 | 5.0 | 3 | .12 |

NOTE 1: A TAZ is normally selected according to the reverse "Stand-Off Voltage" V_{WM} which should be equal to or greater than the DC or continuous peak operating voltage level.

UNIDIRECTIONAL & BIDIRECTIONAL TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: Molded case.

FINISH: Silver plated copper,
readily solderable.

POLARITY: Cathode terminal
marked (except bidirectional).

WEIGHT: 1.5 grams (Appx.).

MOUNTING POSITION: Any.

P7KE10 thru P7KE100C

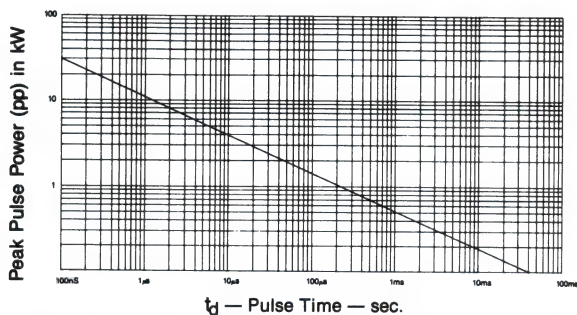


FIGURE 1 PEAK PULSE POWER VS. PULSE TIME

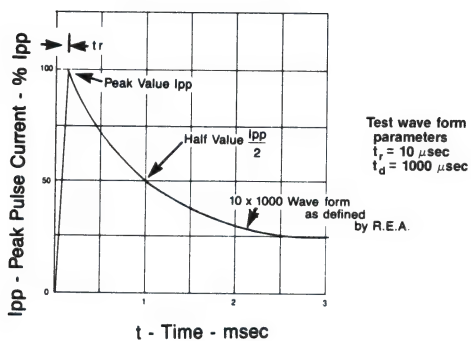


FIGURE 2 DERATING CURVE

FEATURES

- VOLTAGES FROM 5.0 TO 28V STAND-OFF (V_{WM})
- LOW CLAMPING RATIO
- SMALL PACKAGE SIZE

The SOV series is an inexpensive, 500 watt transient absorption zener designed for board level protection of bipolar and MOS memories from ESD (Electrostatic Discharge) and other transient voltages. In addition, TAZ, because of their low clamping factor, provide a high degree of protection to VMOS, HMOS, and CMOS circuits susceptible to line transients.

MAXIMUM RATINGS

500 Watts of Peak Pulse Power dissipation at 25°C (see derating curve)

$t_{clamping}$ (0 volts to BV min): Less than 1×10^{-12} seconds (theoretical)

Operating and Storage temperatures: -65° to +175°C

Forward surge rating: 70 amps, 1/120 second at 25°C

Steady State power dissipation: 1.0 watt $T_L = 75^\circ\text{C}$, Lead Length = 3/8"

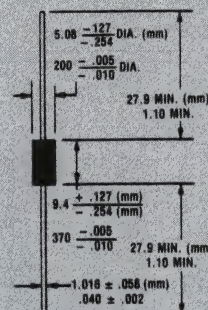
Repetition rate (duty cycle): .01%

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI PART NUMBER | REVERSE STAND-OFF VOLTAGE V_{WM} VOLTS | MAXIMUM REVERSE LEAKAGE CURRENT $I_D @ V_{WM}$ μA | MINIMUM BREAKDOWN VOLTAGE V_{BR} (MIN) @ 1 mA VOLTS | MAXIMUM CLAMPING VOLTAGE (Fig. 2) $V_C @ 1A$ VOLTS | TYPICAL CLAMPING VOLTAGE V_C @ 5A @ 10A VOLTS | | MAXIMUM CLAMPING VOLTAGE (Fig. 2) $V_C @ I_{PP}$ VOLTS | MAXIMUM PEAK PULSE CURRENT (Fig. 2) I_{PP} AMPS |
|-----------------------------|--|---|--|---|--|------|---|--|
| SOV 5.0 | 5.0 | 300 | 6.0 | 7.4 | | 7.9 | 9.3 | 53.7 |
| SOV10 | 10.0 | 2 | 11.1 | 13.2 | | 14.4 | 16.5 | 30.3 |
| SOV12 | 12.0 | 2 | 13.8 | 16.5 | | 18.5 | 21.0 | 23.8 |
| SOV15 | 15.0 | 2 | 16.7 | 19.7 | | 22.2 | 25.2 | 19.8 |
| SOV18 | 18.0 | 2 | 20.4 | 23.8 | 26.0 | | 30.5 | 16.3 |
| SOV24 | 24.0 | 2 | 28.4 | 32.4 | 37.0 | | 42.0 | 11.9 |
| SOV28 | 28.0 | 2 | 30.7 | 35.9 | 41.0 | | 46.5 | 10.7 |

NOTE 1: A TAZ is normally selected according to the reverse "Stand-Off Voltage" V_{WM} which should be equal to or greater than the DC or continuous peak operating voltage level.

TRANSIENT ABSORPTION ZENER



MECHANICAL CHARACTERISTICS

CASE: Molded case.

FINISH: Silver plated copper,
readily solderable.

POLARITY: Band denotes cathode.

WEIGHT: 1 gram (Appx.).

MOUNTING POSITION: Any.

SOV5.0 thru SOV28

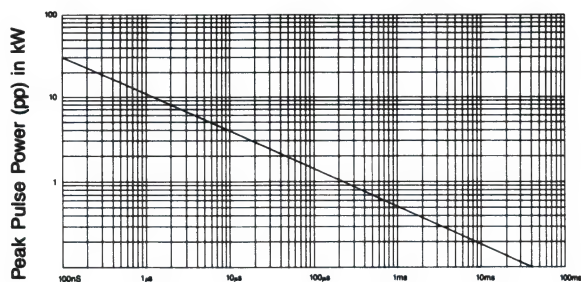


FIGURE 1
PEAK PULSE POWER
VS. PULSE TIME

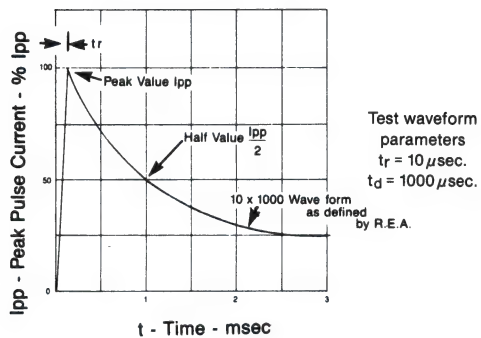


FIGURE 2
PULSE WAVEFORM

FEATURES

- PROTECTS TTL, ECL, DTL, MOS, CMOS AND MSI INTEGRATED CIRCUITS OPERATING ON POWER SUPPLIES OF 5 VOLTS OR LOWER.
- MAXIMUM CLAMPING VOLTAGE OF 7.6 VOLTS AT 30 AMPS (1 MILLISECOND EXPONENTIAL SURGE).
- CLAMPING TIME LESS THAN 1 PICOSECOND.
- ECONOMICAL AXIAL LEADED MOLDED PACKAGE.

DESCRIPTION

The TS-7 low voltage transient suppressor is characterized by very low clamping voltage (V_C), together with low standoff voltage (V_{WM}) which are synonymous with integrated circuit power supply voltage levels. Allowance has been made in establishing the minimum breakdown voltage $V_{(BR)}$ at 25°C to provide safe operation over the full military temperature range.

The Microsemi TS-7 Low Voltage Transient Suppressor is designed for the protection of 5.0 volt circuits. It protects TTL, ECL, DTL, MOS, CMOS and MSI circuits requiring 5.0 volt or lower power supplies. The TS-7 low voltage transient suppressor features outstanding surge handling capabilities and extremely fast response time. Typical applications include computer power supplies, airborne avionics and controls, telephone and mobile communications equipment and numerous applications where transients are present.

ELECTRICAL SPECIFICATIONS @ 25°C

$t_{clamping}$ (0 volts to $V_{(BR)}$ min): 1×10^{-12} seconds (typical)
Steady state power dissipation: 5.0W @ $T_L = 75^\circ\text{C}$, Lead length 3/8"
Reverse standoff voltage V_{WM} : 5.0 volts
Maximum reverse leakage I_D @ V_{WM} : 300 μA
Maximum clamping voltage (V_C) @ I_{PP1} : 7.6 volts
Peak pulse current (I_{PP1}): 30A
Peak pulse power vs pulse time: Refer to Figure 2
Pulse wave form: Refer to Figure 3

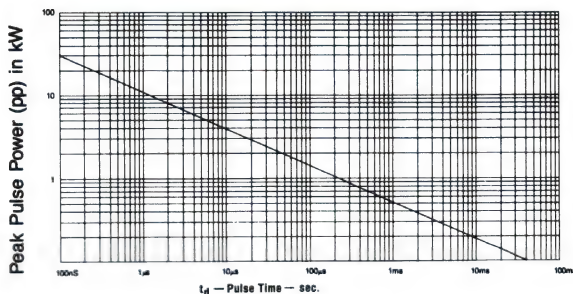


FIGURE 2
Peak Pulse Power vs. Pulse Time

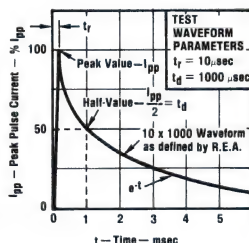


FIGURE 3
Pulse Wave Form

LOW VOLTAGE TRANSIENT SUPPRESSOR

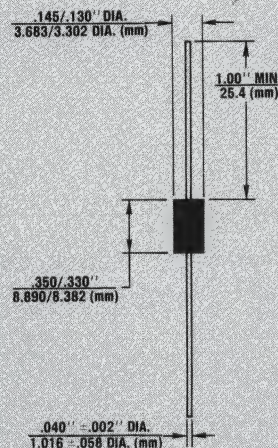


FIGURE 1

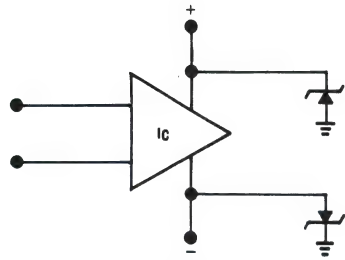
MECHANICAL CHARACTERISTICS

FINISH: Silver plated copper leads.
POLARITY: Positive terminal (cathode) marked with band.
WEIGHT: 1.7 grams (Appx.).
RANGE: Operating and storage temperature range -65°C to 150°C

TS-7 LOW VOLTAGE TRANSIENT SUPPRESSOR

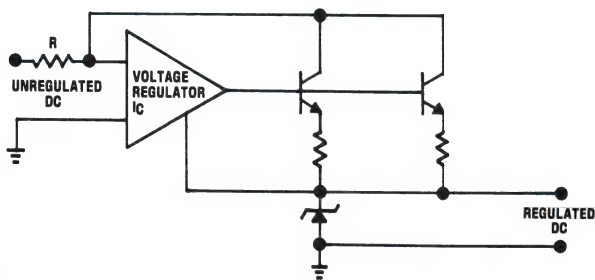
TYPICAL DC POWER LINE APPLICATION

The TS-7 on the power line prevents IC failures during power supply switching, or failures caused by power supply reversals or transients.



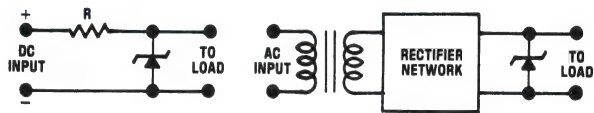
TYPICAL VOLTAGE REGULATOR APPLICATION

A TS-7 on a voltage regulator output eliminates the need for numerous protection circuit components. It will also protect bypass transistors from voltage spikes across the emitter to collector terminals.



TYPICAL POWER SOURCE APPLICATION

The TS-7 has a reverse standoff voltage equal to or greater than the DC output voltage and provides voltage transient protection for power sources. In most industrial applications, an LC filter is required on the line when a transformer is eliminated and the TS-7 is on the power supply input. The addition of a fuse in the line is usually advantageous, and the series resistor can be replaced with an inductor in some applications.



SURFACE MOUNT TECHNOLOGY

Surface Mount Technology is rapidly becoming the state-of-the-art in PC board design and construction.

Insertion technology has imposed restrictions and limitations on PC board technology. With utilization of Surface Mount Technology these restrictions and limitations may be overcome, permitting a continued advance in the state-of-the-art design of PC boards.

Surface Mount Packages offer a much lower profile than conventional packages. This allows for more boards to be utilized in a given amount of space. Surface Mount Packages may be stacked closer together utilizing less total volume than insertion packages.

The reduction of the number of board layers required and the elimination or reduction of the number of plated through holes significantly lowers PC board prices.

Surface Mount components are sent directly to the assembly line, eliminating the intermediate preparation step required for insertion technology components.

Surface Mount Component design and the recent assembly equipment development has provided for the placement of devices at the rate of a five thousand per hour to hundreds of thousands of devices per hour.

Surface Mount Packages with their unique construction allow for superior device performance. With the smaller configuration, the limitations placed on chip performance by internal lead length, parasitic capacitance, and inductance has been greatly reduced.

The cost effectiveness of Surface Mount Technology allows the manufacturer to produce smaller units and offer increased functions with the same size product.

SURFACE MOUNT PACKAGE ADVANTAGES

***Small Size**—The amount of space required for a circuit is reduced by 25% to 50% over conventional diode components.

***Complete Pretest Capability**—Unlike unencapsulated die, which can only be partially tested by probing or sorting, surface mount products are 100% electrically tested after soldering and encapsulation, providing performance equivalent to their larger discrete counterparts.

***Handling and Assembly Ease**—Surface Mount standard package outline permits the placement of components onto the substrates using automated handling equipment.

***Mounting Considerations**—To maintain the inherent reliability of the Microsemi products, proper selection of printed circuit boards and hybrid substrates are important. The axial surface mount equivalents have low expansion coefficients similar to ceramic leadless chip carriers. For military temperature range applications requiring many temperature cycles, an alumina sub-

strate should be considered. For low cost commercial applications subject to reasonable environments with limited temperature ranges, a low expansion PC board material like epoxy glass, can be considered. Since the PC material has inherent higher thermal resistance than alumina substrate, the SMD maximum dissipation will involve the usual design/cost/performance trade off.

***Pre-Formed Leads**—Surface Mount packages are ready for placement onto the substrates, with no intermediate lead forming steps required.

***Reliability**—All chips used in Surface Mount packages are oxide passivated or glassivated, and are epoxy or glass encapsulated for superior mechanical strength and moisture resistance.

***Availability**—A wide variety of discrete diode and rectifier components from Microsemi's repertoire of reliability-proven semiconductor processes and geometries are available in surface mount packages. Please consult the factory for availability of specific devices not listed in the catalog.

Special Packages and Assemblies

Microsemi Corporation offers a multiplicity of packages for many applications. These include: potted modules, flat packs, leadless chip carriers, dual inline, single inline, chip on channel and disc-die-disc assemblies.

Since the aforementioned assemblies can use high reliability die and Microsemi diode construction packaging techniques, they possess all of the axial diode high performance characteristics. For example, almost all Microsemi diode products listed in this data book can be

manufactured in disc-die-disc construction.

Figures 1 through 7 illustrate a small sample of several disc-die-disc special rectifiers, transient suppressors, 3 ϕ rectifiers, and diode arrays suitable for hybrid and other subminiature applications.

Consult the respective Microsemi factory for more information on the company's capabilities to meet customer requirements on special packages and assemblies.

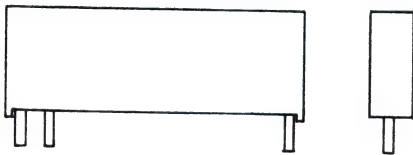


FIGURE 1
DIODE NETWORK



FIGURE 2
DISC-DIE-DISC ASSEMBLY

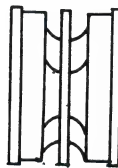


FIGURE 3
PELLET, BIDIRECTIONAL
TRANSIENT SUPPRESSOR

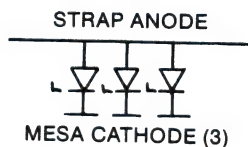


FIGURE 4
DIODE ARRAY (3)



FIGURE 5
DIODE ARRAY (5)

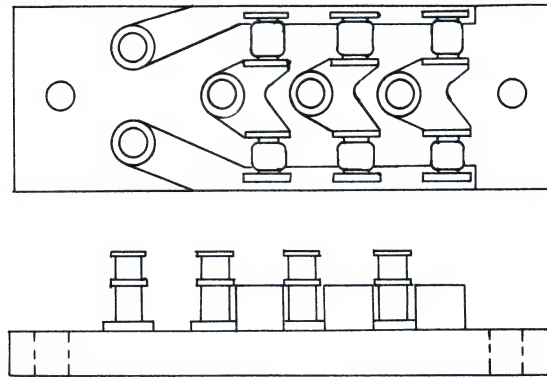


FIGURE 6
3 ϕ F.W. RECTIFIER
ASSEMBLY

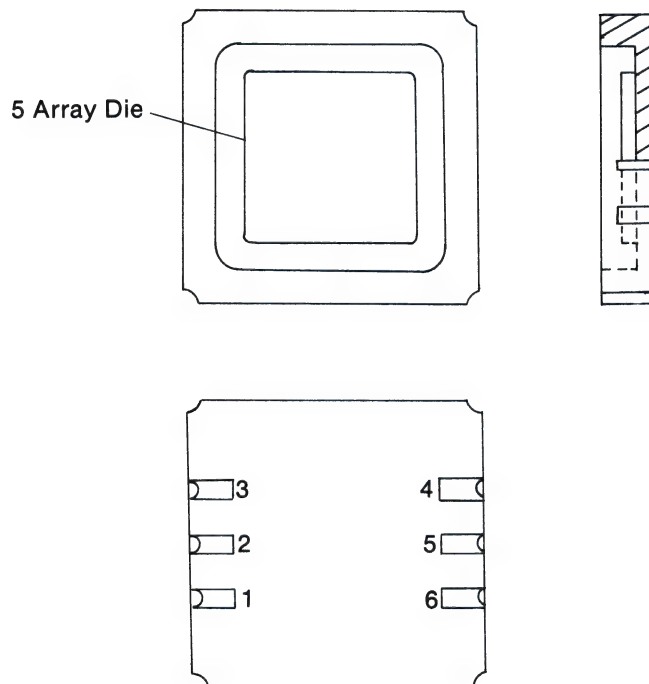


FIGURE 7
LEADLESS CHIP CARRIER

SURFACE MOUNT DEVICES

Offered by Microsemi Corp. — Santa Ana, CA

DESCRIPTION

In addition to being "the Diode Experts," Microsemi Corporation manufactures diodes using Surface Mount Technology (SMT) which provides small size, low cost assemblies for many customer applications, without sacrificing power rating or hi-rel JAN, TX, TXV, and JANS quality. Mesa surface mount diodes can be supplied from the Santa Ana facility using miniature, metallurgically bonded, hard glass to metal, non-cavity,

square end cap packages for high power applications.

Microsemi Santa Ana facility initial offerings include: four basic power ratings of rectifiers, hi-rel rectifier stacks, zener diodes, transient voltage suppressors, and PIN diodes. The capability exists to supply JAN, TX, TXV, and JANS equivalents on all of Santa Ana's products.

FEATURES FOR SURFACE MOUNT DEVICES (SMD)

- VOIDLESS, HERMETICALLY SEALED GLASS PACKAGE
- METALLURGICALLY BONDED
- SQUARE END CAPS
- JAN, TX, TXV, AND JANS EQUIVALENTS AVAILABLE
- CUSTOM TYPES SUPPLIED TO CUSTOMER DRAWINGS

MECHANICAL CHARACTERISTICS

Case: Hermetically sealed glass

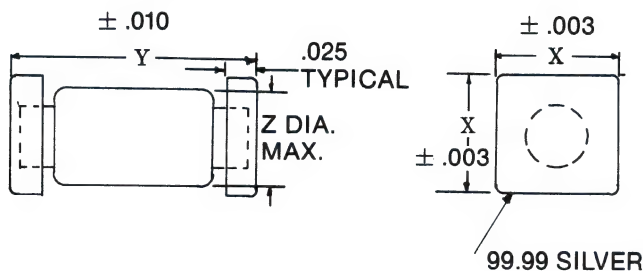
Polarity: Cathode dot

Finish Material: Silver

MAXIMUM RATINGS

Operating Temperature: - 65°C to +200°C

Storage Temperature: - 65°C to +200°C



PACKAGE DIMENSIONS

| PACKAGE TYPE | — DIMENSIONS — | | |
|--------------|----------------|------|------|
| | X | Y | Z |
| B | .073 | .175 | .065 |
| A | .100 | .190 | .085 |
| E | .140 | .215 | .135 |
| G | .190 | .215 | .185 |

CROSS REFERENCE SELECTION GUIDE

Rectifiers and Stacks*

| JEDEC TYPE NUMBER | SMD TYPE NUMBER | PACKAGE TYPE | PEAK REV. VOLTAGE | AVG. DC CURRENT (I _O) in AMPS |
|----------------------|----------------------|-----------------|----------------------|---|
| 1N3595 | 3595 SM | B | 125 | 0.5 |
| 1N4938 | 4938 SM | A | 200 | 0.5 |
| 1N4942 thru 1N4948 | 4942 SM thru 4948 SM | A | 200 thru 1000 | 1.0 |
| 1N5615 thru 1N5623 | 5615 SM thru 5623 SM | A | 200 thru 1000 | 1.0 |
| 1N4148-1 | 4148-1 SM | B | 75 | 0.5 |
| 1N4150-1 | 4150-1 SM | B | 50 | 0.5 |
| 1N5802 thru 1N5806 | 5802 SM thru 5806 SM | A | 50 thru 150 | 2.5 |
| 1N6073 thru 1N6075 | 6073 SM thru 6075 SM | A | 50 thru 150 | 3.0 |
| 1N5415 thru 1N5420 | 5415 SM thru 5420 SM | E | 50 thru 600 | 3.0 |
| 1N5186 thru 1N5190 | 5186 SM thru 5190 SM | E | 100 thru 600 | 3.0 |
| 1N5807 thru 1N5811 | 5807 SM thru 5811 SM | E | 50 thru 150 | 6.0 |
| 1N6079 thru 1N6081 | 6079 SM thru 6081 SM | G | 50 thru 150 | 12.0 |
| **1N3643 thru 1N3647 | 3643 SM thru 3647 SM | D | 1000 thru 3000 | 0.2 |
| **1N4254 thru 1N4257 | 4254 SM thru 4257 SM | D | 1500 thru 3000 | 0.2 |
| **1N5181 thru 1N5184 | 5181 SM thru 5184 SM | D | 4000 thru 10,000 | 0.06 |

Zener Diodes*

(and T.C. Zeners, Unidirectional and Bidirectional Transient Suppressors)

| JEDEC TYPE NUMBER | SMD TYPE NUMBER | PACKAGE TYPE | WATTAGE (mW) | PEAK PULSE POWER (Watts) |
|-----------------------|----------------------|-----------------|-----------------|--------------------------------|
| 1N821 thru 1N829 | 821 SM thru 829 SM | A | 250 | - |
| 1N6309 thru 1N6355 | 6309 SM thru 6355 SM | C | 500 | - |
| 1N6485 thru 1N6491 | 6485 SM thru 6491 SM | A | 1500 | - |
| 1N4460 thru 1N4496 | 4460 SM thru 4496 SM | A | 1500 | - |
| 1N5063 thru 1N5117 | 5063 SM thru 5117 SM | A | 3000 | - |
| 1N4954 thru 1N4986 | 4954 SM thru 4986 SM | E | 5000 | - |
| †1N6102 A thru 1N6137 | 6102 SM thru 6137 SM | E | - | 500 |
| †1N6138 A thru 1N6173 | 6138 SM thru 6173 SM | G | - | 1500 |

*Consult factory for additional types not listed.

**High Voltage Stacks.

†Bidirectional Transient Suppressors.

Note: Unidirectional transient suppressor versions of this SMD package are available at 250 through 1500 watts peak pulse power. Consult factory for the package size applicable for specific applications.

SANTA ANA, CA

For more information call:
(714) 979-8220

DESCRIPTION/FEATURES

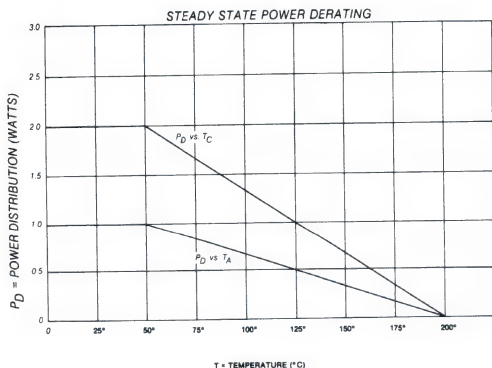
- LEADLESS PACKAGE FOR SURFACE MOUNT TECHNOLOGY
- IDEAL FOR HIGH DENSITY MOUNTING
- VOLTAGE RANGE—3.3 TO 100 VOLTS
- HERMETICALLY SEALED, DOUBLE-SLUG GLASS CONSTRUCTION

MAXIMUM RATINGS

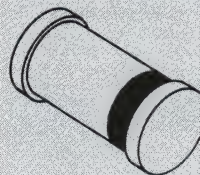
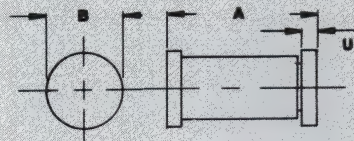
1.00 Watt DC Power Rating (See Power Derating Curve)
 -65°C to +200°C Operating and Storage Junction Temperature
 Power Derating 10.0 mW/°C above 50°C
 Forward Voltage @ 200 mA: 1.2 Volts

APPLICATION

This surface mountable zener diode series is similar to the 1N4728 thru 1N4764 registration in the DO-41 equivalent package except that it meets the new JEDEC surface mount outline DO-213AB. It is an ideal selection for applications of high density and low parasitic requirements. Due to its glass hermetic qualities, it may also be considered for high reliability applications when required by a source control drawing (SCD).



LEADLESS GLASS ZENER DIODES



| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|--------|------|
| | MIN | MAX | MIN | MAX |
| A | 4.80 | 5.20 | 1.89 | 2.05 |
| B | 2.39 | 2.68 | .094 | .102 |
| U | .41 | .55 | .016 | .022 |

DO-213AB

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass with solder contact tabs at each end.

FINISH: All external surfaces are corrosion resistant, readily solderable.

POLARITY: Banded end is cathode.

THERMAL RESISTANCE: 75°C/Watt typical junction to contact (case) tabs. (See Power Derating Curve)

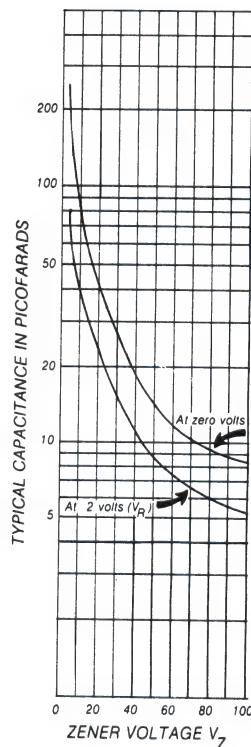
MOUNTING POSITION: Any.

MLL4728 thru MLL4764

ELECTRICAL CHARACTERISTICS @ $T_C = 30^\circ\text{C}$

| TYPE NUMBER (Note 1) | ZENER VOLTAGE (V_Z) (Note 4) | TEST CURRENT (I_{ZT}) | MAXIMUM DYNAMIC IMPEDANCE (Z_{ZT} @ I_{ZT}) (Note 2) | MAXIMUM REVERSE CURRENT (I_R @ V_R) | TEST VOLTAGE (V_R) | MAXIMUM REGULATOR CURRENT (I_{ZM}) $T_A = 50^\circ\text{C}$ | MAXIMUM KNEE IMPEDANCE (Z_{ZK} @ I_{ZK}) (Note 2) | TEST CURRENT (I_{ZK}) | MAXIMUM (SURGE) CURRENT (I_S) (Note 3) |
|----------------------------|---|---------------------------------|--|--|------------------------------|---|---|---------------------------------|--|
| | VOLTS | mA | OHMS | μA | VOLTS | mA | OHMS | mA | mA |
| MLL4728A | 3.3 | 76 | 10 | 100 | 1 | 276 | 400 | 1.0 | 1380 |
| MLL4729A | 3.6 | 69 | 10 | 100 | 1 | 252 | 400 | 1.0 | 1260 |
| MLL4730A | 3.9 | 64 | 9 | 50 | 1 | 234 | 400 | 1.0 | 1190 |
| MLL4731A | 4.3 | 58 | 9 | 10 | 1 | 217 | 400 | 1.0 | 1070 |
| MLL4732A | 4.7 | 53 | 8 | 10 | 1 | 193 | 500 | 1.0 | 970 |
| MLL4733A | 5.1 | 49 | 7 | 10 | 1 | 178 | 550 | 1.0 | 890 |
| MLL4734A | 5.6 | 45 | 5 | 10 | 2 | 162 | 600 | 1.0 | 810 |
| MLL4735A | 6.2 | 41 | 2 | 10 | 3 | 146 | 700 | 1.0 | 730 |
| MLL4736A | 6.8 | 37 | 3.5 | 10 | 4 | 133 | 700 | 1.0 | 660 |
| MLL4737A | 7.5 | 34 | 4.0 | 10 | 5 | 121 | 700 | 0.5 | 605 |
| MLL4738A | 8.2 | 31 | 4.5 | 10 | 6 | 110 | 700 | 0.5 | 550 |
| MLL4739A | 9.1 | 28 | 5.0 | 10 | 7 | 100 | 700 | 0.5 | 500 |
| MLL4740A | 10 | 25 | 7 | 10 | 7.6 | 91 | 700 | 0.25 | 454 |
| MLL4741A | 11 | 23 | 8 | 5 | 8.4 | 83 | 700 | 0.25 | 414 |
| MLL4742A | 12 | 21 | 9 | 5 | 9.1 | 76 | 700 | 0.25 | 380 |
| MLL4743A | 13 | 19 | 10 | 5 | 9.9 | 69 | 700 | 0.25 | 344 |
| MLL4744A | 15 | 17 | 14 | 5 | 11.4 | 61 | 700 | 0.25 | 304 |
| MLL4745A | 16 | 15.5 | 16 | 5 | 12.2 | 57 | 700 | 0.25 | 285 |
| MLL4746A | 18 | 14 | 20 | 5 | 13.7 | 50 | 750 | 0.25 | 250 |
| MLL4747A | 20 | 12.5 | 22 | 5 | 15.2 | 45 | 750 | 0.25 | 225 |
| MLL4748A | 22 | 11.5 | 23 | 5 | 16.7 | 41 | 750 | 0.25 | 205 |
| MLL4749A | 24 | 10.5 | 25 | 5 | 18.2 | 38 | 750 | 0.25 | 190 |
| MLL4750A | 27 | 9.5 | 35 | 5 | 20.6 | 34 | 750 | 0.25 | 170 |
| MLL4751A | 30 | 8.5 | 40 | 5 | 22.8 | 30 | 1000 | 0.25 | 150 |
| MLL4752A | 33 | 7.5 | 45 | 5 | 25.1 | 27 | 1000 | 0.25 | 135 |
| MLL4753A | 36 | 7.0 | 50 | 5 | 27.4 | 25 | 1000 | 0.25 | 125 |
| MLL4754A | 39 | 6.5 | 60 | 5 | 29.7 | 23 | 1000 | 0.25 | 115 |
| MLL4755A | 43 | 6.0 | 70 | 5 | 32.7 | 22 | 1500 | 0.25 | 110 |
| MLL4756A | 47 | 5.5 | 80 | 5 | 35.8 | 19 | 1500 | 0.25 | 95 |
| MLL4757A | 51 | 5.0 | 95 | 5 | 38.8 | 18 | 1500 | 0.25 | 90 |
| MLL4758A | 56 | 4.5 | 110 | 5 | 42.6 | 16 | 2000 | 0.25 | 80 |
| MLL4759A | 62 | 4.0 | 125 | 5 | 47.1 | 14 | 2000 | 0.25 | 70 |
| MLL4760A | 68 | 3.7 | 150 | 5 | 51.7 | 13 | 2000 | 0.25 | 65 |
| MLL4761A | 75 | 3.3 | 175 | 5 | 56.0 | 12 | 2000 | 0.25 | 60 |
| MLL4762A | 82 | 3.0 | 200 | 5 | 62.2 | 11 | 3000 | 0.25 | 55 |
| MLL4763A | 91 | 2.8 | 250 | 5 | 69.2 | 10 | 3000 | 0.25 | 50 |
| MLL4764A | 100 | 2.5 | 350 | 5 | 76.0 | 9 | 3000 | 0.25 | 45 |

CAPACITANCE vs. V_Z CURVE



NOTE 1: The type numbers shown with an "A" suffix have a $\pm 5\%$ tolerance on the nominal Zener voltage. Also available with suffix "C" for $\pm 2\%$, and "D" for $\pm 1\%$, while the absence of a suffix letter denotes $\pm 10\%$ tolerance.

NOTE 2: The Zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the DC Zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at two points to insure a sharp knee on the breakdown curve and eliminate unstable units.

NOTE 3: The reverse surge current is measured at 25°C ambient using a 1/2 square wave or equivalent sine wave pulse 1/120 second duration superimposed on I_{ZT} .

NOTE 4: Voltage measurements to be performed 90 seconds after application of DC current.

MLL5221 thru MLL5281

DESCRIPTION/FEATURES

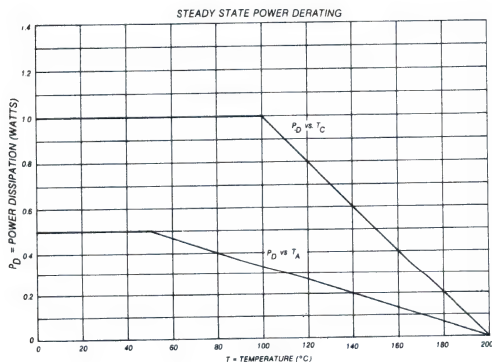
- LEADLESS PACKAGE FOR SURFACE MOUNT TECHNOLOGY
- IDEAL FOR HIGH DENSITY MOUNTING
- VOLTAGE RANGE—2.4 TO 200 VOLTS
- HERMETICALLY SEALED, DOUBLE-SLUG GLASS CONSTRUCTION
- METALLURGICALLY BONDED CONSTRUCTION AVAILABLE AS DASH ONE.

MAXIMUM RATINGS

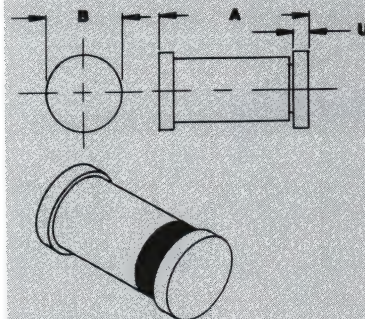
500 mW DC Power Rating (See Power Derating Curve)
-65°C to +200°C Operating and Storage Junction Temperature
Power Derating 3.33 mW/°C above 50°C

APPLICATION

This surface mountable zener diode series is similar to the 1N5221 thru 1N5281 registration in the DO-35 equivalent package except that it meets the new JEDEC surface mount outline DO-213AA. It is an ideal selection for applications of high density and low parasitic requirements. Due to its glass hermetic qualities, it may also be considered for high reliability applications when required by a source control drawing (SCD).



LEADLESS GLASS ZENER DIODES



| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 3.30 | 3.70 | 0.130 | 0.146 |
| B | 1.60 | 1.70 | 0.063 | 0.067 |
| U | .41 | .55 | 0.016 | 0.022 |

DO-213AA

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass with solder contact tabs at each end.

FINISH: All external surfaces are corrosion resistant, readily solderable.

POLARITY: Banded end is cathode.

THERMAL RESISTANCE: 100°C/Watt typical junction to contact (case) tabs.

MOUNTING POSITION: Any.

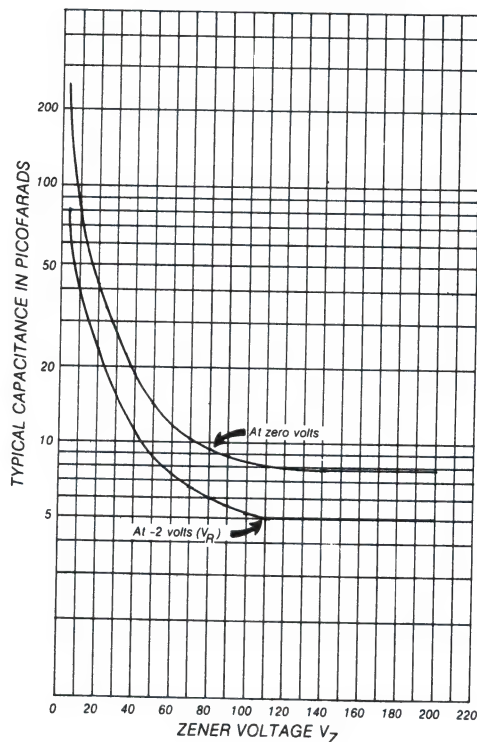
MLL5221 thru MLL 5281

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted. Based on dc measurements at thermal equilibrium; case temperature maintained at $30 \pm 2^\circ\text{C}$. $V_F = 1.1\text{V}$ max @ $I_F = 200\text{ mA}$ for all types.)

| Type No (Note 1) | Nominal Zener Voltage V_Z @ I_{ZT} Volts (Note 2) | Test Current I_{ZT} mA | Max Zener Impedance | | | | Max Reverse Leakage Current | | | | Max Zener Voltage Temperature Coeff. (A and B Suffix only) α_{VZ} (%/°C) (Note 3) |
|---------------------|---|-----------------------------------|-----------------------------|---------------------------------------|--|-----|-----------------------------|----------------|-----|---|--|
| | | | A and B Suffix only | | | | A and B Suffix only | | | | |
| | | | Z_{ZT} @ I_{ZT} Ohms | Z_{ZK} @ $I_{ZK} + 0.25$ mA Ohms | | | I_R μ A | V_R Volts | | I_R @ V_R Used for Suffix A μ A | |
| | | | | | | | | A | B | | |
| MLL5221 | 2.4 | 20 | 30 | 1200 | | 100 | 0.95 | 1.0 | 200 | -0.085 | |
| MLL5222 | 2.5 | 20 | 30 | 1250 | | 100 | 0.95 | 1.0 | 200 | -0.085 | |
| MLL5223 | 2.7 | 20 | 30 | 1300 | | 75 | 0.95 | 1.0 | 150 | -0.080 | |
| MLL5224 | 2.8 | 20 | 30 | 1400 | | 75 | 0.95 | 1.0 | 150 | -0.080 | |
| MLL5225 | 3.0 | 20 | 29 | 1600 | | 50 | 0.95 | 1.0 | 100 | -0.075 | |
| MLL5226 | 3.3 | 20 | 28 | 1600 | | 25 | 0.95 | 1.0 | 100 | -0.070 | |
| MLL5227 | 3.6 | 20 | 24 | 1700 | | 15 | 0.95 | 1.0 | 100 | -0.065 | |
| MLL5228 | 3.9 | 20 | 23 | 1900 | | 10 | 0.95 | 1.0 | 75 | -0.060 | |
| MLL5229 | 4.3 | 20 | 22 | 2000 | | 5.0 | 0.95 | 1.0 | 50 | -0.055 | |
| MLL5230 | 4.7 | 20 | 19 | 1900 | | 5.0 | 1.9 | 2.0 | 50 | -0.050 | |
| MLL5231 | 5.1 | 20 | 17 | 1800 | | 5.0 | 1.9 | 2.0 | 50 | -0.030 | |
| MLL5232 | 5.6 | 20 | 16 | 1600 | | 5.0 | 2.9 | 3.0 | 50 | -0.038 | |
| MLL5233 | 6.0 | 20 | 7.0 | 1600 | | 5.0 | 3.3 | 3.5 | 50 | -0.038 | |
| MLL5234 | 6.2 | 20 | 7.0 | 1500 | | 5.0 | 3.8 | 4.0 | 50 | -0.045 | |
| MLL5235 | 6.8 | 20 | 5.0 | 750 | | 3.0 | 4.8 | 5.0 | 30 | -0.050 | |
| MLL5236 | 7.5 | 20 | 6.0 | 500 | | 3.0 | 5.7 | 6.0 | 30 | -0.058 | |
| MLL5237 | 8.2 | 20 | 8.0 | 500 | | 3.0 | 6.2 | 6.5 | 30 | -0.062 | |
| MLL5238 | 8.7 | 20 | 8.0 | 800 | | 3.0 | 6.7 | 7.0 | 30 | -0.065 | |
| MLL5239 | 9.1 | 20 | 10 | 600 | | 3.0 | 7.6 | 8.0 | 30 | -0.068 | |
| MLL5240 | 10 | 20 | 17 | 600 | | 3.0 | 7.6 | 8.0 | 30 | -0.075 | |
| MLL5241 | 11 | 20 | 22 | 600 | | 2.0 | 8.0 | 8.4 | 30 | -0.076 | |
| MLL5242 | 12 | 20 | 30 | 600 | | 1.0 | 8.7 | 9.1 | 10 | -0.077 | |
| MLL5243 | 13 | 9.5 | 13 | 600 | | 0.5 | 9.4 | 9.9 | 10 | -0.079 | |
| MLL5244 | 14 | 9.0 | 15 | 600 | | 0.1 | 9.5 | 10 | 10 | -0.082 | |
| MLL5245 | 15 | 8.5 | 16 | 600 | | 0.1 | 10.5 | 11 | 10 | -0.082 | |
| MLL5246 | 16 | 7.8 | 17 | 600 | | 0.1 | 11.4 | 12 | 10 | -0.083 | |
| MLL5247 | 17 | 7.4 | 19 | 600 | | 0.1 | 12.4 | 13 | 10 | -0.084 | |
| MLL5248 | 18 | 7.0 | 21 | 600 | | 0.1 | 13.3 | 14 | 10 | -0.085 | |
| MLL5249 | 19 | 6.6 | 23 | 600 | | 0.1 | 13.3 | 14 | 10 | -0.086 | |
| MLL5250 | 20 | 6.2 | 25 | 600 | | 0.1 | 14.3 | 15 | 10 | -0.086 | |
| MLL5251 | 22 | 5.6 | 29 | 600 | | 0.1 | 16.2 | 17 | 10 | -0.087 | |
| MLL5252 | 24 | 5.2 | 33 | 600 | | 0.1 | 17.1 | 18 | 10 | -0.088 | |
| MLL5253 | 25 | 5.0 | 35 | 600 | | 0.1 | 18.1 | 19 | 10 | -0.089 | |
| MLL5254 | 27 | 4.6 | 41 | 600 | | 0.1 | 20 | 21 | 10 | -0.090 | |
| MLL5255 | 28 | 4.5 | 44 | 600 | | 0.1 | 20 | 21 | 10 | -0.091 | |
| MLL5256 | 30 | 4.2 | 49 | 600 | | 0.1 | 22 | 23 | 10 | -0.091 | |
| MLL5257 | 33 | 3.8 | 58 | 700 | | 0.1 | 24 | 25 | 10 | -0.091 | |
| MLL5258 | 36 | 3.4 | 70 | 700 | | 0.1 | 26 | 27 | 10 | -0.092 | |
| MLL5259 | 39 | 3.2 | 80 | 800 | | 0.1 | 29 | 30 | 10 | -0.093 | |
| MLL5260 | 43 | 3.0 | 93 | 900 | | 0.1 | 31 | 33 | 10 | -0.094 | |
| MLL5261 | 47 | 2.7 | 105 | 1000 | | 0.1 | 34 | 36 | 10 | -0.095 | |
| MLL5262 | 51 | 2.5 | 125 | 1100 | | 0.1 | 37 | 39 | 10 | -0.096 | |
| MLL5263 | 56 | 2.2 | 150 | 1300 | | 0.1 | 41 | 43 | 10 | -0.096 | |
| MLL5264 | 60 | 2.1 | 170 | 1400 | | 0.1 | 44 | 46 | 10 | -0.097 | |
| MLL5265 | 62 | 2.0 | 185 | 1400 | | 0.1 | 45 | 47 | 10 | -0.097 | |
| MLL5266 | 68 | 1.8 | 230 | 1600 | | 0.1 | 49 | 52 | 10 | -0.097 | |
| MLL5267 | 75 | 1.7 | 270 | 1700 | | 0.1 | 53 | 56 | 10 | -0.098 | |
| MLL5268 | 82 | 1.5 | 330 | 2000 | | 0.1 | 59 | 62 | 10 | -0.098 | |
| MLL5269 | 87 | 1.4 | 370 | 2200 | | 0.1 | 65 | 68 | 10 | -0.099 | |
| MLL5270 | 91 | 1.4 | 400 | 2300 | | 0.1 | 66 | 69 | 10 | -0.099 | |
| MLL5271 | 100 | 1.3 | 500 | 2600 | | 0.1 | 72 | 76 | 10 | -0.110 | |
| MLL5272 | 110 | 1.1 | 750 | 3000 | | 0.1 | 80 | 84 | 10 | -0.110 | |
| MLL5273 | 120 | 1.0 | 900 | 4000 | | 0.1 | 86 | 91 | 10 | -0.110 | |
| MLL5274 | 130 | 0.95 | 1100 | 4500 | | 0.1 | 94 | 99 | 10 | -0.110 | |
| MLL5275 | 140 | 0.90 | 1300 | 4500 | | 0.1 | 101 | 106 | 10 | -0.110 | |
| MLL5276 | 150 | 0.85 | 1500 | 5000 | | 0.1 | 108 | 114 | 10 | -0.110 | |
| MLL5277 | 160 | 0.80 | 1700 | 5500 | | 0.1 | 116 | 122 | 10 | -0.110 | |
| MLL5278 | 170 | 0.74 | 1900 | 6000 | | 0.1 | 123 | 129 | 10 | -0.110 | |
| MLL5279 | 180 | 0.68 | 2200 | 6500 | | 0.1 | 130 | 137 | 10 | -0.110 | |
| MLL5280 | 190 | 0.66 | 2400 | 6500 | | 0.1 | 137 | 144 | 10 | -0.110 | |
| MLL5281 | 200 | 0.65 | 2500 | 7000 | | 0.1 | 144 | 152 | 10 | -0.110 | |

CAPACITANCE vs. V_Z CURVE



NOTE 1: Table as shown lists type numbers, which indicate a tolerance of $\pm 20\%$ with guaranteed limits on only V_Z , I_R , and V_F . Devices with guaranteed limits on all six parameters are indicated by suffix "A" for $\pm 10\%$, "B" for $\pm 5\%$, "C" for $\pm 2\%$, and "D" for $\pm 1\%$ tolerance.

NOTE 2: The electrical characteristics are measured after allowing the device to stabilize for 20 seconds.

NOTE 3: Temperature coefficient (α_{VZ}). Test conditions for temperature coefficient are as follows:

- $I_{ZT} = 7.5\text{ mA}$, $T_1 = 25^\circ\text{C}$,
 $T_2 = 125^\circ\text{C}$ (MLL5221A, B thru MLL5242A, B.)
- $I_{ZT} = \text{Rated } I_{ZT}$, $T_1 = 25^\circ\text{C}$,
 $T_2 = 125^\circ\text{C}$ (MLL5243A, B thru MLL5281A, B.)

Device to be temperature stabilized with current applied prior to reading breakdown voltage at the specified ambient temperature.

MLL5913 thru MLL5956

DESCRIPTION/FEATURES

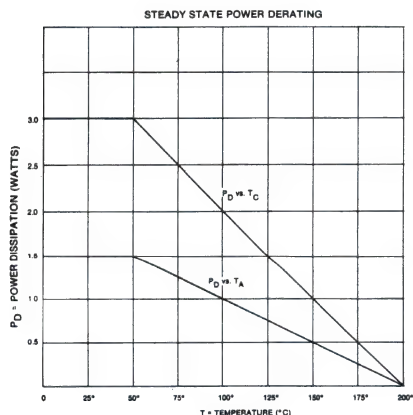
- LEADLESS PACKAGE FOR SURFACE MOUNT TECHNOLOGY
- IDEAL FOR HIGH DENSITY MOUNTING
- VOLTAGE RANGE—3.3 TO 200 VOLTS
- HERMETICALLY SEALED, DOUBLE-SLUG GLASS CONSTRUCTION
- METALLURGICALLY ENHANCED CONTACT CONSTRUCTION

MAXIMUM RATINGS

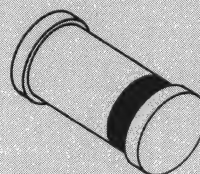
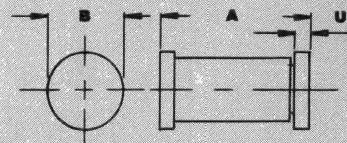
1.50 Watts DC Power Rating (See Power Derating Curve)
-65°C to +200°C Operating and Storage Junction Temperature
Power Derating 10.0 mW/°C above 50°C

APPLICATION

This surface mountable zener diode series is similar to the 1N5913 thru 1N5956 registration in the DO-41 equivalent package except that it meets the new JEDEC surface mount outline DO-213AB. It is an ideal selection for applications of high density and low parasitic requirements. Due to its glass hermetic qualities, it may also be considered for high reliability applications when required by a source control drawing (SCD).



LEADLESS GLASS ZENER DIODES



| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|--------|------|
| | MIN | MAX | MIN | MAX |
| A | 4.80 | 5.20 | .189 | .205 |
| B | 2.39 | 2.66 | .094 | .102 |
| U | .41 | .55 | .016 | .022 |

DO-213AB

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass with solder contact tabs at each end.

FINISH: All external surfaces are corrosion resistant, readily solderable.

POLARITY: Banded end is cathode.

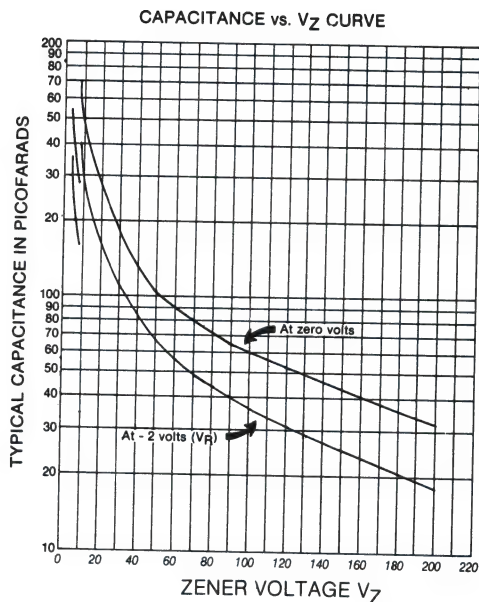
THERMAL RESISTANCE: 50°C/Watt typical junction to contact (case) tabs. (See Power Derating Curve)

MOUNTING POSITION: Any.

MLL5913 thru MLL5956

ELECTRICAL CHARACTERISTICS @ $T_C = 30^\circ\text{C}$

| JEDEC TYPE NUMBER | ZENER VOLTAGE V_Z (Note 2) | TEST CURRENT I_{ZT} | DYNAMIC IMPEDANCE Z_{ZT} (Note 3) | KNEE CURRENT I_{ZK} | KNEE IMPEDANCE Z_{ZK} (Note 3) | REVERSE CURRENT I_R | REVERSE VOLTAGE V_R | MAX. DC CURRENT I_{ZM} |
|-------------------------|---------------------------------------|-----------------------------|--|-----------------------------|---|-----------------------------|-----------------------------|--------------------------------|
| (Note 1) | Volts | mA | Ω | mA | Ω | μA | Volts | mA |
| MLL5913 | 3.3 | 113.6 | 10 | 1.0 | 500 | 100 | 1.0 | 454 |
| MLL5914 | 3.6 | 104.2 | 9.0 | 1.0 | 500 | 75 | 1.0 | 416 |
| MLL5915 | 3.9 | 96.1 | 7.5 | 1.0 | 500 | 25 | 1.0 | 384 |
| MLL5916 | 4.3 | 87.2 | 6.0 | 1.0 | 500 | 5.0 | 1.0 | 348 |
| MLL5917 | 4.7 | 79.8 | 5.0 | 1.0 | 500 | 5.0 | 1.5 | 319 |
| MLL5918 | 5.1 | 73.5 | 4.0 | 1.0 | 350 | 5.0 | 2.0 | 294 |
| MLL5919 | 5.6 | 66.9 | 2.0 | 1.0 | 250 | 5.0 | 3.0 | 267 |
| MLL5920 | 6.2 | 60.5 | 2.0 | 1.0 | 200 | 5.0 | 4.0 | 241 |
| MLL5921 | 6.8 | 55.1 | 2.5 | 1.0 | 200 | 5.0 | 5.2 | 200 |
| MLL5922 | 7.5 | 50 | 3.0 | 0.5 | 400 | 5.0 | 6.0 | 280 |
| MLL5923 | 8.2 | 45.7 | 3.5 | 0.5 | 400 | 5.0 | 6.5 | 182 |
| MLL5924 | 9.1 | 41.2 | 4.0 | 0.5 | 500 | 5.0 | 7.0 | 164 |
| MLL5925 | 10 | 37.5 | 4.5 | 0.25 | 500 | 5.0 | 8.0 | 150 |
| MLL5926 | 11 | 34.1 | 5.5 | 0.25 | 500 | 1.0 | 8.4 | 125 |
| MLL5927 | 12 | 31.2 | 6.5 | 0.25 | 550 | 1.0 | 9.1 | 125 |
| MLL5928 | 13 | 29.8 | 7.0 | 0.25 | 550 | 1.0 | 9.9 | 115 |
| MLL5929 | 15 | 25 | 9.0 | 0.25 | 600 | 1.0 | 11.4 | 100 |
| MLL5930 | 16 | 23.4 | 10 | 0.25 | 600 | 1.0 | 12.2 | 93 |
| MLL5931 | 18 | 20.8 | 12 | 0.25 | 650 | 1.0 | 13.7 | 83 |
| MLL5932 | 20 | 18.7 | 14 | 0.25 | 650 | 1.0 | 15.2 | 75 |
| MLL5933 | 22 | 17 | 17.5 | 0.25 | 650 | 1.0 | 16.7 | 68 |
| MLL5934 | 24 | 15.6 | 19 | 0.25 | 700 | 1.0 | 18.2 | 62 |
| MLL5935 | 27 | 13.9 | 23 | 0.25 | 700 | 1.0 | 20.6 | 55 |
| MLL5936 | 30 | 12.5 | 28 | 0.25 | 750 | 1.0 | 22.8 | 50 |
| MLL5937 | 33 | 11.4 | 33 | 0.25 | 800 | 1.0 | 25.1 | 45 |
| MLL5938 | 36 | 10.4 | 38 | 0.25 | 850 | 1.0 | 27.4 | 41 |
| MLL5939 | 39 | 9.6 | 45 | 0.25 | 900 | 1.0 | 29.7 | 34 |
| MLL5940 | 43 | 8.7 | 53 | 0.25 | 950 | 1.0 | 32.7 | 31 |
| MLL5941 | 47 | 8.0 | 67 | 0.25 | 1000 | 1.0 | 35.8 | 29 |
| MLL5942 | 51 | 7.3 | 70 | 0.25 | 1100 | 1.0 | 38.8 | 26 |
| MLL5943 | 56 | 6.7 | 86 | 0.25 | 1300 | 1.0 | 42.6 | 24 |
| MLL5944 | 62 | 6.0 | 100 | 0.25 | 1500 | 1.0 | 47.1 | 22 |
| MLL5945 | 68 | 5.5 | 120 | 0.25 | 1700 | 1.0 | 51.2 | 20 |
| MLL5946 | 75 | 5.0 | 140 | 0.25 | 2000 | 1.0 | 56 | 18 |
| MLL5947 | 82 | 4.6 | 160 | 0.25 | 2500 | 1.0 | 62.2 | 16 |
| MLL5948 | 91 | 4.1 | 200 | 0.25 | 3000 | 1.0 | 76 | 15 |
| MLL5949 | 100 | 3.7 | 250 | 0.25 | 3100 | 1.0 | 83.6 | 13 |
| MLL5950 | 110 | 3.4 | 300 | 0.25 | 4000 | 1.0 | 91.2 | 12 |
| MLL5951 | 120 | 3.1 | 380 | 0.25 | 4500 | 1.0 | 98.9 | 11 |
| MLL5952 | 130 | 2.9 | 450 | 0.25 | 6000 | 1.0 | 114 | 10 |
| MLL5953 | 150 | 2.5 | 600 | 0.25 | 7000 | 1.0 | 121.6 | 9.0 |
| MLL5954 | 160 | 2.3 | 700 | 0.25 | 8000 | 1.0 | 136.8 | 8.0 |
| MLL5955 | 180 | 2.1 | 900 | 0.25 | | 1.0 | 152 | 7.0 |
| MLL5956 | 200 | 1.9 | 1200 | 0.25 | | 1.0 | | |



T_C Maintained at 30°C , $V_F = 1.2\text{ V}$ max @ $I_F = 200\text{ mA}$ (all types)

NOTE 1: No suffix indicates a $\pm 20\%$ tolerance on nominal V_Z . The suffix A denotes $\pm 10\%$, B denotes $\pm 5\%$, C denotes $\pm 2\%$, and D denotes $\pm 1\%$ tolerance.

NOTE 2: Zener voltage (V_Z) is measured at $T_C = 30^\circ\text{C}$. Voltage measurement to be performed 90 seconds after application of DC current.

NOTE 3: The zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} .

TAZ

SMS SERIES 5.0 thru 170.0 Volts 600 WATTS

FEATURES

- LOW PROFILE PACKAGE FOR SURFACE MOUNTING
- VOLTAGE RANGE: 5.0 TO 170 VOLTS
- 600 WATTS PEAK POWER
- UNIDIRECTIONAL AND BIDIRECTIONAL
- LOW INDUCTANCE

This series of TAZ (transient absorption zeners), available in small outline surface mountable packages, is designed to optimize board space. Packaged for use with surface mount technology automated assembly equipment, these parts can be placed on printed circuit boards and ceramic substrates to protect sensitive components from transient voltage damage.

The SMS series, rated for 600 watts, during a one millisecond pulse, can be used to protect sensitive circuits against transients induced by lightning and inductive load switching. With a response time of 1×10^{-12} seconds (theoretical) they are also effective against electrostatic discharge and NEMP.

MAXIMUM RATINGS

600 watts of Peak Power dissipation ($10 \times 1000\mu s$)

$t_{clamping}$ (0 volts to $V_{(BR)}$ min): less than 1×10^{-12} seconds (theoretical)

Forward surge rating: 50 Amps, 1/120 sec @ 25°C (Excluding Bidirectional)

Operating and Storage Temperature: -65° to +175°C

NOTE: A TAZ is normally selected according to the reverse "Stand Off Voltage" (V_{RM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

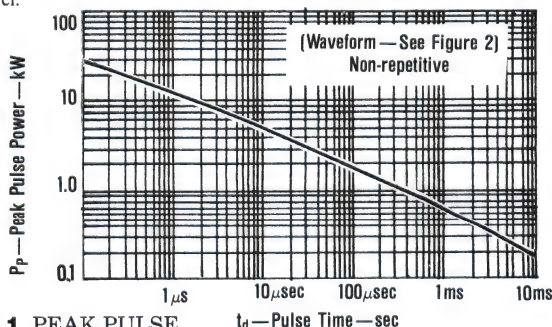


FIGURE 1 PEAK PULSE POWER VS PULSE TIME

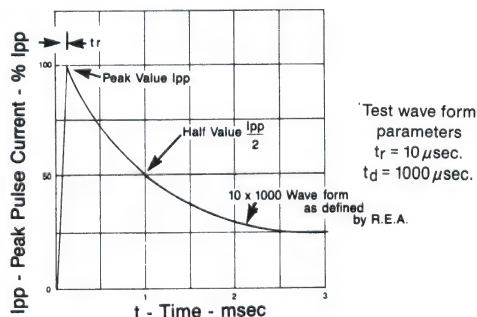
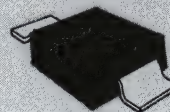


FIGURE 2
PULSE WAVEFORM

UNI- and BI-DIRECTIONAL SURFACE MOUNT



See Page 303 for
Package Dimensions.

MECHANICAL CHARACTERISTICS

CASE: Molded Surface Mountable.

TERMINAL: Gull-wing or Modified J-bend leads, solder dipped.

POLARITY: Cathode indicated by dot. No marking on bidirectional devices.

PACKAGING: Standard 12 mm tape (see EIA Std. RS-481).

SMS 5.0 thru 170.0 Volts

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI CORP. PART NUMBER | | DEVICE MARKING CODE | REVERSE STAND-OFF VOLTAGE (See Note) V _{WM} VOLTS | BREAKDOWN VOLTAGE V _(BR) @ I _T VOLTS | | MAXIMUM CLAMPING VOLTAGE @ I _{PP} VOLTS | PEAK PULSE CURRENT (See Fig. 2) I _{PP} AMPS | MAXIMUM REVERSE LEAKAGE @ V _{WM} I _D μA |
|--------------------------------|---------------------------|---------------------------|---|---|------|--|---|--|
| GULL-WING LEAD | MODIFIED "J" BEND LEAD | | | MIN. | MAX. | | | |
| SMSG5.0 | SMSJ5.0 | KD | 5.0 | 6.40 - 7.30 | 10 | 9.6 | 62.5 | 800 |
| SMSG5.0A | SMSJ5.0A | KE | 5.0 | 6.40 - 7.00 | 10 | 9.2 | 65.2 | 800 |
| SMSG6.0 | SMSJ6.0 | KF | 6.0 | 6.67 - 8.15 | 10 | 11.4 | 52.6 | 800 |
| SMSG6.0A | SMSJ6.0A | KG | 6.0 | 6.67 - 7.37 | 10 | 10.3 | 58.3 | 800 |
| SMSG6.5 | SMSJ6.5 | KH | 6.5 | 7.22 - 8.82 | 10 | 12.3 | 48.7 | 500 |
| SMSG6.5A | SMSJ6.5A | KK | 6.5 | 7.22 - 7.98 | 10 | 11.2 | 53.6 | 500 |
| SMSG7.0 | SMSJ7.0 | KL | 7.0 | 7.78 - 9.51 | 10 | 13.3 | 45.1 | 200 |
| SMSG7.0A | SMSJ7.0A | KM | 7.0 | 7.78 - 8.60 | 10 | 12.0 | 50.0 | 200 |
| SMSG7.5 | SMSJ7.5 | KN | 7.5 | 8.33 - 10.2 | 1 | 14.3 | 42.0 | 100 |
| SMSG7.5A | SMSJ7.5A | KP | 7.5 | 8.33 - 9.21 | 1 | 12.9 | 46.5 | 100 |
| SMSG8.0 | SMSJ8.0 | KQ | 8.0 | 8.89 - 10.9 | 1 | 15.0 | 40.0 | 50 |
| SMSG8.0A | SMSJ8.0A | KR | 8.0 | 8.89 - 9.83 | 1 | 13.6 | 44.1 | 50 |
| SMSG8.5 | SMSJ8.5 | KS | 8.5 | 9.44 - 11.5 | 1 | 15.9 | 37.7 | 10 |
| SMSG8.5A | SMSJ8.5A | KT | 8.5 | 9.44 - 10.4 | 1 | 14.4 | 41.7 | 10 |
| SMSG9.0 | SMSJ9.0 | KU | 9.0 | 10.0 - 12.2 | 1 | 16.9 | 35.5 | 5 |
| SMSG9.0A | SMSJ9.0A | KV | 9.0 | 10.0 - 11.1 | 1 | 15.4 | 39.0 | 5 |
| SMSG10 | SMSJ10 | KW | 10 | 11.1 - 13.6 | 1 | 18.8 | 31.9 | 5 |
| SMSG10A | SMSJ10A | KX | 10 | 11.1 - 12.3 | 1 | 17.0 | 35.3 | 5 |
| SMSG11 | SMSJ11 | KY | 11 | 12.2 - 14.9 | 1 | 20.1 | 29.9 | 5 |
| SMSG11A | SMSJ11A | KZ | 11 | 12.2 - 13.5 | 1 | 18.2 | 33.0 | 5 |
| SMSG12 | SMSJ12 | LD | 12 | 13.3 - 16.3 | 1 | 22.0 | 27.3 | 5 |
| SMSG12A | SMSJ12A | LE | 12 | 13.3 - 14.7 | 1 | 19.9 | 30.2 | 5 |
| SMSG13 | SMSJ13 | LF | 13 | 14.4 - 17.6 | 1 | 23.8 | 25.2 | 5 |
| SMSG13A | SMSJ13A | LG | 13 | 14.4 - 15.9 | 1 | 21.5 | 27.9 | 5 |
| SMSG14 | SMSJ14 | LH | 14 | 15.6 - 19.1 | 1 | 25.8 | 23.3 | 5 |
| SMSG14A | SMSJ14A | LK | 14 | 15.6 - 17.2 | 1 | 23.2 | 25.8 | 5 |
| SMSG15 | SMSJ15 | LL | 15 | 16.7 - 20.4 | 1 | 26.9 | 22.3 | 5 |
| SMSG15A | SMSJ15A | LM | 15 | 16.7 - 18.5 | 1 | 24.4 | 24.0 | 5 |
| SMSG16 | SMSJ16 | LN | 16 | 17.8 - 21.8 | 1 | 28.8 | 20.8 | 5 |
| SMSG16A | SMSJ16A | LP | 16 | 17.8 - 19.7 | 1 | 26.0 | 23.1 | 5 |
| SMSG17 | SMSJ17 | LQ | 17 | 18.9 - 23.1 | 1 | 30.5 | 19.7 | 5 |
| SMSG17A | SMSJ17A | LR | 17 | 18.9 - 20.9 | 1 | 27.6 | 21.7 | 5 |
| SMSG18 | SMSJ18 | LS | 18 | 20.0 - 24.4 | 1 | 32.2 | 18.6 | 5 |
| SMSG18A | SMSJ18A | LT | 18 | 20.0 - 22.1 | 1 | 29.2 | 20.5 | 5 |
| SMSG20 | SMSJ20 | LU | 20 | 22.2 - 27.1 | 1 | 35.8 | 16.7 | 5 |
| SMSG20A | SMSJ20A | LV | 20 | 22.2 - 24.5 | 1 | 32.4 | 18.5 | 5 |
| SMSG22 | SMSJ22 | LW | 22 | 24.4 - 29.8 | 1 | 39.4 | 15.2 | 5 |
| SMSG22A | SMSJ22A | LX | 22 | 24.4 - 26.9 | 1 | 35.5 | 16.9 | 5 |
| SMSG24 | SMSJ24 | LY | 24 | 26.7 - 32.6 | 1 | 43.0 | 14.0 | 5 |
| SMSG24A | SMSJ24A | LZ | 24 | 26.7 - 29.5 | 1 | 38.9 | 15.4 | 5 |
| SMSG26 | SMSJ26 | MD | 26 | 28.9 - 35.3 | 1 | 46.6 | 12.4 | 5 |
| SMSG26A | SMSJ26A | ME | 26 | 28.9 - 31.9 | 1 | 42.1 | 14.2 | 5 |
| SMSG28 | SMSJ28 | MF | 28 | 31.1 - 38.0 | 1 | 50.0 | 12.0 | 5 |
| SMSG28A | SMSJ28A | MG | 28 | 31.1 - 34.4 | 1 | 45.4 | 13.2 | 5 |
| SMSG30 | SMSJ30 | MH | 30 | 33.3 - 40.7 | 1 | 53.5 | 11.2 | 5 |
| SMSG30A | SMSJ30A | MK | 30 | 33.3 - 36.8 | 1 | 48.4 | 12.4 | 5 |
| SMSG33 | SMSJ33 | ML | 33 | 36.7 - 44.9 | 1 | 58.0 | 10.2 | 5 |
| SMSG33A | SMSJ33A | MM | 33 | 36.7 - 40.6 | 1 | 53.3 | 11.3 | 5 |
| SMSG36 | SMSJ36 | MN | 36 | 40.0 - 48.9 | 1 | 64.3 | 9.3 | 5 |
| SMSG36A | SMSJ36A | MP | 36 | 40.0 - 44.2 | 1 | 58.1 | 10.3 | 5 |
| SMSG40 | SMSJ40 | MQ | 40 | 44.4 - 54.3 | 1 | 71.4 | 8.4 | 5 |
| SMSG40A | SMSJ40A | MR | 40 | 44.4 - 49.1 | 1 | 64.5 | 9.3 | 5 |
| SMSG43 | SMSJ43 | MS | 43 | 47.8 - 58.4 | 1 | 76.7 | 7.8 | 5 |
| SMSG43A | SMSJ43A | MT | 43 | 47.8 - 52.8 | 1 | 69.4 | 8.6 | 5 |
| SMSG45 | SMSJ45 | MU | 45 | 50.0 - 61.1 | 1 | 80.3 | 7.5 | 5 |
| SMSG45A | SMSJ45A | MV | 45 | 50.0 - 55.3 | 1 | 72.7 | 8.3 | 5 |
| SMSG48 | SMSJ48 | MW | 48 | 53.3 - 65.1 | 1 | 85.5 | 7.0 | 5 |
| SMSG48A | SMSJ48A | MX | 48 | 53.3 - 58.9 | 1 | 77.4 | 7.7 | 5 |
| SMSG51 | SMSJ51 | MY | 51 | 56.7 - 69.3 | 1 | 91.1 | 6.6 | 5 |
| SMSG51A | SMSJ51A | MZ | 51 | 56.7 - 62.7 | 1 | 82.4 | 7.3 | 5 |
| SMSG54 | SMSJ54 | ND | 54 | 60.0 - 73.3 | 1 | 96.3 | 6.2 | 5 |
| SMSG54A | SMSJ54A | NE | 54 | 60.0 - 66.3 | 1 | 87.1 | 6.9 | 5 |
| SMSG58 | SMSJ58 | NF | 58 | 64.4 - 78.7 | 1 | 103.0 | 5.8 | 5 |
| SMSG58A | SMSJ58A | NG | 58 | 64.4 - 71.2 | 1 | 93.6 | 6.4 | 5 |
| SMSG60 | SMSJ60 | NH | 60 | 66.7 - 81.5 | 1 | 107.0 | 5.6 | 5 |
| SMSG60A | SMSJ60A | NK | 60 | 66.7 - 73.7 | 1 | 96.8 | 6.2 | 5 |
| SMSG64 | SMSJ64 | NL | 64 | 71.1 - 86.9 | 1 | 114.0 | 5.3 | 5 |
| SMSG64A | SMSJ64A | NM | 64 | 71.1 - 78.6 | 1 | 103.0 | 5.8 | 5 |

SMS 5.0 thru 170 Volts

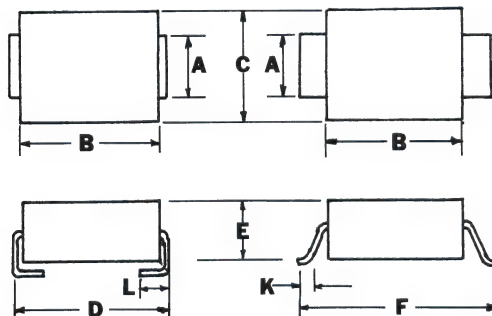
ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI CORP. PART NUMBER | | DEVICE MARKING CODE | REVERSE STAND-OFF VOLTAGE (See Note) V_{WM} VOLTS | BREAKDOWN VOLTAGE V_{BR} @ I_T VOLTS | | MAXIMUM CLAMPING VOLTAGE @ I_{PP} VOLTS | PEAK PULSE CURRENT (See Fig. 2) I_{PP} AMPS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_D μA |
|--------------------------------|---------------------------|---------------------------|--|---|-------|---|--|---|
| GULL-WING LEAD | MODIFIED "J" BEND LEAD | | | MIN. | MAX. | | | |
| SMSG70 | SMSJ70 | NN | 70 | 77.8 | 95.1 | 1 | 125 | 4.8 |
| SMSG70A | SMSJ70A | NP | 70 | 77.8 | 86.0 | 1 | 113 | 5.3 |
| SMSG75 | SMSJ75 | NQ | 75 | 83.3 | 102.0 | 1 | 134 | 4.5 |
| SMSG75A | SMSJ75A | NR | 75 | 83.3 | 92.1 | 1 | 121 | 4.9 |
| SMSG78 | SMSJ78 | NS | 78 | 86.7 | 106.0 | 1 | 139 | 4.3 |
| SMSG78A | SMSJ78A | NT | 78 | 86.7 | 95.8 | 1 | 126 | 4.7 |
| SMSG85 | SMSJ85 | NU | 85 | 94.4 | 115.0 | 1 | 151 | 3.9 |
| SMSG85A | SMSJ85A | NV | 85 | 94.4 | 104.0 | 1 | 137 | 4.4 |
| SMSG90 | SMSJ90 | NW | 90 | 100 | 122 | 1 | 160 | 3.8 |
| SMSG90A | SMSJ90A | NX | 90 | 100 | 111 | 1 | 146 | 4.1 |
| SMSG100 | SMSJ100 | NY | 100 | 111 | 136 | 1 | 179 | 3.4 |
| SMSG100A | SMSJ100A | NZ | 100 | 111 | 123 | 1 | 162 | 3.7 |
| SMSG110 | SMSJ110 | PD | 110 | 122 | 149 | 1 | 196 | 3.0 |
| SMSG110A | SMSJ110A | PE | 110 | 122 | 135 | 1 | 177 | 3.4 |
| SMSG120 | SMSJ120 | PF | 120 | 133 | 163 | 1 | 214 | 2.8 |
| SMSG120A | SMSJ120A | PG | 120 | 133 | 147 | 1 | 193 | 3.1 |
| SMSG130 | SMSJ130 | PH | 130 | 144 | 176 | 1 | 231 | 2.6 |
| SMSG130A | SMSJ130A | PK | 130 | 144 | 159 | 1 | 209 | 2.9 |
| SMSG150 | SMSJ150 | PL | 150 | 167 | 204 | 1 | 268 | 2.2 |
| SMSG150A | SMSJ150A | PM | 150 | 167 | 185 | 1 | 243 | 2.5 |
| SMSG160 | SMSJ160 | PN | 160 | 178 | 218 | 1 | 287 | 2.1 |
| SMSG160A | SMSJ160A | PP | 160 | 178 | 197 | 1 | 259 | 2.3 |
| SMSG170 | SMSJ170 | PQ | 170 | 189 | 231 | 1 | 304 | 2.0 |
| SMSG170A | SMSJ170A | PR | 170 | 189 | 209 | 1 | 275 | 2.2 |

For Bidirectional indicate a C or CA suffix after the part number. (i.e.: SMSG170CA or SMSJ170C)

Microsemi Corp.'s SMS Series (600W) surface mountable packages are designed specifically for transient voltage suppression. The wide leads assure a large surface contact for good heat dissipation, and a low resistance path for surge current flow to ground. These high speed transient voltage suppressors can be used to effectively protect sensitive components such as integrated circuits and MOS devices.

PACKAGE DIMENSIONS



| DIMENSIONS IN INCHES | | | | | | | |
|---------------------------|------|------|------|------|------|------|-------|
| | A | B | C | D | E | F | K |
| MIN. | .077 | .160 | .130 | .200 | .070 | .235 | .015 |
| MAX. | .083 | .180 | .150 | .220 | .085 | .255 | .030 |
| DIMENSIONS IN MILLIMETERS | | | | | | | |
| MIN. | 1.96 | 4.06 | 3.30 | 5.08 | 1.77 | 5.97 | 0.381 |
| MAX. | 2.10 | 4.57 | 3.81 | 5.59 | 2.16 | 6.48 | 0.762 |

Typical Standoff Height: 0.004"-0.008" (0.1mm-0.2mm)

Peak Pulse Power (P_{PP}) or Current (I_{PP})
in percent of 25°C rating

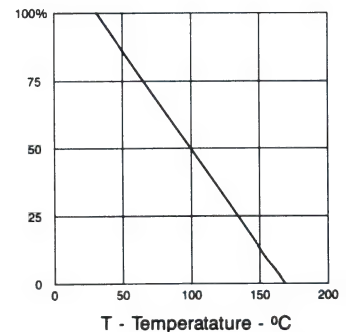


FIGURE 3 DERATING CURVE

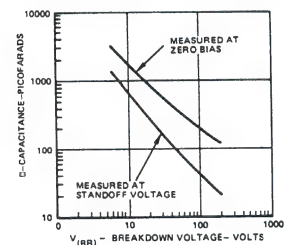


FIGURE 4
TYPICAL CAPACITANCE VS.
BREAKDOWN VOLTAGE

SMM SERIES 5.0 thru 170.0 Volts 1500 WATTS

FEATURES

- UNIDIRECTIONAL AND BIDIRECTIONAL
- 1500 WATTS PEAK POWER
- VOLTAGE RANGE: 5.0 TO 170 VOLTS
- LOW INDUCTANCE
- LOW PROFILE PACKAGE FOR SURFACE MOUNTING

This series of TAZ (transient absorption zeners), available in small outline surface mountable packages, is designed to optimize board space. Packaged for use with surface mount technology automated assembly equipment, these parts can be placed on printed circuit boards and ceramic substrates to protect sensitive components from transient voltage damage.

The SMM series, rated for 1500 watts during a one millisecond pulse, can be used to protect sensitive circuits against transients induced by lightning and inductive load switching. With a response time of 1×10^{-12} seconds (theoretical) they are also effective against electrostatic discharge and NEMP.

MAXIMUM RATINGS

1500 watts of Peak Power dissipation ($10 \times 1000\mu s$)

$t_{clamping}$ (0 volts to V_{BR} min): less than 1×10^{-12} seconds (theoretical)

Forward surge rating: 200 Amps, 1/120 sec @ 25°C (Excluding Bidirectional)

Operating and Storage Temperature: -65° to +175°C

NOTE: TAZ is normally selected according to the reverse "Stand Off Voltage" (V_{RM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

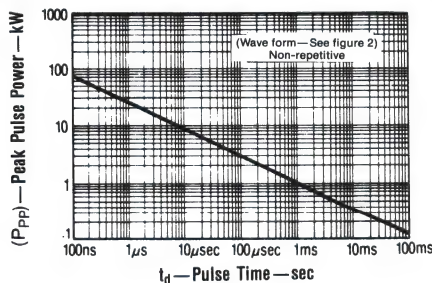


FIGURE 1 PEAK PULSE POWER VS PULSE TIME

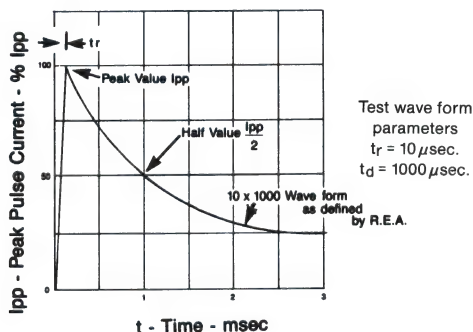


FIGURE 2
PULSE WAVEFORM

UNIDIRECTIONAL AND BIDIRECTIONAL SURFACE MOUNT



MECHANICAL CHARACTERISTICS

CASE: Molded, surface mountable.

TERMINALS: Solder-dipped gull-wing or modified J-bend leads.

POLARITY: Cathode indicated by dot. No marking on bidirectional devices.

PACKAGING: 16mm tape. (See EIA Std. RS-481.)

SMM 5.0 thru 170.0 Volts

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI CORP. PART NUMBER | | DEVICE MARKING CODE | REVERSE STAND-OFF VOLTAGE (See Note) V_{WM} VOLTS | BREAKDOWN VOLTAGE $V_{(BR)}$ @ I_T VOLTS | | MAXIMUM CLAMPING VOLTAGE @ I_{PP} VOLTS | PEAK PULSE CURRENT (See Fig. 2) I_{PP} AMPS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_D μA |
|--------------------------------|---------------------------|---------------------------|--|---|------|---|--|---|
| GULL-WING LEAD | MODIFIED "J" BEND LEAD | | | MIN. | MAX. | | | |
| SMMG5.0 | SMMJ5.0 | GDD | 5.0 | 6.40 - 7.30 | 10 | 9.6 | 156.2 | 1000 |
| SMMG5.0A | SMMJ5.0A | GDE | 5.0 | 6.40 - 7.00 | 10 | 9.2 | 163.0 | 1000 |
| SMMG6.0 | SMMJ6.0 | GDF | 6.0 | 6.67 - 8.15 | 10 | 11.4 | 131.6 | 1000 |
| SMMG6.0A | SMMJ6.0A | GDG | 6.0 | 6.67 - 7.37 | 10 | 10.3 | 145.6 | 1000 |
| SMMG6.5 | SMMJ6.5 | GDH | 6.5 | 7.22 - 8.82 | 10 | 12.3 | 122.0 | 500 |
| SMMG6.5A | SMMJ6.5A | GDK | 6.5 | 7.22 - 7.98 | 10 | 11.2 | 133.9 | 500 |
| SMMG7.0 | SMMJ7.0 | GDL | 7.0 | 7.78 - 9.51 | 10 | 13.3 | 112.8 | 200 |
| SMMG7.0A | SMMJ7.0A | GDM | 7.0 | 7.78 - 8.60 | 10 | 12.0 | 125.0 | 200 |
| SMMG7.5 | SMMJ7.5 | GDN | 7.5 | 8.33 - 10.2 | 1 | 14.3 | 104.9 | 100 |
| SMMG7.5A | SMMJ7.5A | GDP | 7.5 | 8.33 - 9.21 | 1 | 12.9 | 116.3 | 100 |
| SMMG8.0 | SMMJ8.0 | GDO | 8.0 | 8.89 - 10.9 | 1 | 15.0 | 100.0 | 50 |
| SMMG8.0A | SMMJ8.0A | GDR | 8.0 | 8.89 - 9.83 | 1 | 13.6 | 110.3 | 50 |
| SMMG8.5 | SMMJ8.5 | GDS | 8.5 | 9.44 - 11.5 | 1 | 15.9 | 94.3 | 25 |
| SMMG8.5A | SMMJ8.5A | GDT | 8.5 | 9.44 - 10.4 | 1 | 14.4 | 104.2 | 25 |
| SMMG9.0 | SMMJ9.0 | GDU | 9.0 | 10.0 - 12.2 | 1 | 16.9 | 88.7 | 10 |
| SMMG9.0A | SMMJ9.0A | GDV | 9.0 | 10.0 - 11.1 | 1 | 15.4 | 97.4 | 10 |
| SMMG10 | SMMJ10 | GDW | 10 | 11.1 - 13.6 | 1 | 18.8 | 79.8 | 5 |
| SMMG10A | SMMJ10A | GDX | 10 | 11.1 - 12.3 | 1 | 17.0 | 88.2 | 5 |
| SMMG11 | SMMJ11 | GDY | 11 | 12.2 - 14.9 | 1 | 20.1 | 74.6 | 5 |
| SMMG11A | SMMJ11A | GDZ | 11 | 12.2 - 13.5 | 1 | 18.2 | 82.4 | 5 |
| SMMG12 | SMMJ12 | GED | 12 | 13.3 - 16.3 | 1 | 22.0 | 68.2 | 5 |
| SMMG12A | SMMJ12A | GEE | 12 | 13.3 - 14.7 | 1 | 19.9 | 75.3 | 5 |
| SMMG13 | SMMJ13 | GEF | 13 | 14.4 - 17.6 | 1 | 23.8 | 63.0 | 5 |
| SMMG13A | SMMJ13A | GEG | 13 | 14.4 - 15.9 | 1 | 21.5 | 69.7 | 5 |
| SMMG14 | SMMJ14 | GEH | 14 | 15.6 - 19.1 | 1 | 25.8 | 58.1 | 5 |
| SMMG14A | SMMJ14A | G EK | 14 | 15.6 - 17.2 | 1 | 23.2 | 64.7 | 5 |
| SMMG15 | SMMJ15 | GEL | 15 | 16.7 - 20.4 | 1 | 26.9 | 55.8 | 5 |
| SMMG15A | SMMJ15A | GEM | 15 | 16.7 - 18.5 | 1 | 24.4 | 61.5 | 5 |
| SMMG16 | SMMJ16 | GEN | 16 | 17.8 - 21.8 | 1 | 28.8 | 52.1 | 5 |
| SMMG16A | SMMJ16A | GEP | 16 | 17.8 - 19.7 | 1 | 26.0 | 57.7 | 5 |
| SMMG17 | SMMJ17 | GEQ | 17 | 18.9 - 23.1 | 1 | 30.5 | 49.2 | 5 |
| SMMG17A | SMMJ17A | GER | 17 | 18.9 - 20.9 | 1 | 27.6 | 53.3 | 5 |
| SMMG18 | SMMJ18 | GES | 18 | 20.0 - 24.4 | 1 | 32.2 | 46.6 | 5 |
| SMMG18A | SMMJ18A | GET | 18 | 20.0 - 22.1 | 1 | 29.2 | 51.4 | 5 |
| SMMG20 | SMMJ20 | GEU | 20 | 22.2 - 27.1 | 1 | 35.8 | 41.9 | 5 |
| SMMG20A | SMMJ20A | GEV | 20 | 22.2 - 24.5 | 1 | 32.4 | 46.3 | 5 |
| SMMG22 | SMMJ22 | GEW | 22 | 24.4 - 29.8 | 1 | 39.4 | 38.1 | 5 |
| SMMG22A | SMMJ22A | GEX | 22 | 24.4 - 26.9 | 1 | 35.5 | 42.2 | 5 |
| SMMG24 | SMMJ24 | GEY | 24 | 26.7 - 32.6 | 1 | 43.0 | 34.9 | 5 |
| SMMG24A | SMMJ24A | GEZ | 24 | 26.7 - 29.5 | 1 | 38.9 | 38.6 | 5 |
| SMMG26 | SMMJ26 | GFD | 26 | 28.9 - 35.3 | 1 | 46.6 | 32.2 | 5 |
| SMMG26A | SMMJ26A | GFE | 26 | 28.9 - 31.9 | 1 | 42.1 | 35.6 | 5 |
| SMMG28 | SMMJ28 | GFF | 28 | 31.1 - 38.0 | 1 | 50.0 | 30.0 | 5 |
| SMMG28A | SMMJ28A | GFG | 28 | 31.1 - 34.4 | 1 | 45.4 | 33.0 | 5 |
| SMMG30 | SMMJ30 | G FH | 30 | 33.3 - 40.7 | 1 | 53.5 | 28.0 | 5 |
| SMMG30A | SMMJ30A | GFK | 30 | 33.3 - 36.8 | 1 | 48.4 | 31.0 | 5 |
| SMMG33 | SMMJ33 | GFL | 33 | 36.7 - 44.9 | 1 | 59.0 | 25.2 | 5 |
| SMMG33A | SMMJ33A | GFM | 33 | 36.7 - 40.6 | 1 | 53.3 | 28.1 | 5 |
| SMMG36 | SMMJ36 | GFN | 36 | 40.0 - 48.9 | 1 | 64.3 | 23.3 | 5 |
| SMMG36A | SMMJ36A | GFP | 36 | 40.0 - 44.2 | 1 | 58.1 | 25.8 | 5 |
| SMMG40 | SMMJ40 | GFQ | 40 | 44.4 - 54.3 | 1 | 71.4 | 21.0 | 5 |
| SMMG40A | SMMJ40A | GFR | 40 | 44.4 - 49.1 | 1 | 64.5 | 23.2 | 5 |
| SMMG43 | SMMJ43 | GFS | 43 | 47.8 - 58.4 | 1 | 76.7 | 19.6 | 5 |
| SMMG43A | SMMJ43A | GFT | 43 | 47.8 - 52.8 | 1 | 69.4 | 21.6 | 5 |
| SMMG45 | SMMJ45 | GFU | 45 | 50.0 - 61.1 | 1 | 80.3 | 18.7 | 5 |
| SMMG45A | SMMJ45A | GFV | 45 | 50.0 - 55.3 | 1 | 72.7 | 20.6 | 5 |
| SMMG48 | SMMJ48 | GFW | 48 | 53.3 - 65.1 | 1 | 85.5 | 17.5 | 5 |
| SMMG48A | SMMJ48A | GFX | 48 | 53.3 - 58.9 | 1 | 77.4 | 19.4 | 5 |
| SMMG51 | SMMJ51 | GFY | 51 | 56.7 - 69.3 | 1 | 91.1 | 18.5 | 5 |
| SMMG51A | SMMJ51A | GFZ | 51 | 56.7 - 62.7 | 1 | 82.4 | 18.2 | 5 |
| SMMG54 | SMMJ54 | GGD | 54 | 60.0 - 73.3 | 1 | 96.3 | 15.6 | 5 |
| SMMG54A | SMMJ54A | GGE | 54 | 60.0 - 66.3 | 1 | 87.1 | 17.2 | 5 |
| SMMG58 | SMMJ58 | GGF | 58 | 64.4 - 78.7 | 1 | 103.0 | 14.6 | 5 |
| SMMG58A | SMMJ58A | GGG | 58 | 64.4 - 71.2 | 1 | 93.6 | 16.0 | 5 |
| SMMG60 | SMMJ60 | G GH | 60 | 66.7 - 81.5 | 1 | 107.0 | 14.0 | 5 |
| SMMG60A | SMMJ60A | G GK | 60 | 66.7 - 73.7 | 1 | 96.8 | 15.5 | 5 |
| SMMG64 | SMMJ64 | GGL | 64 | 71.1 - 86.9 | 1 | 114.0 | 13.2 | 5 |
| SMMG64A | SMMJ64A | GGM | 64 | 71.1 - 78.6 | 1 | 103.0 | 14.6 | 5 |

SMM 5.0 thru 170 Volts

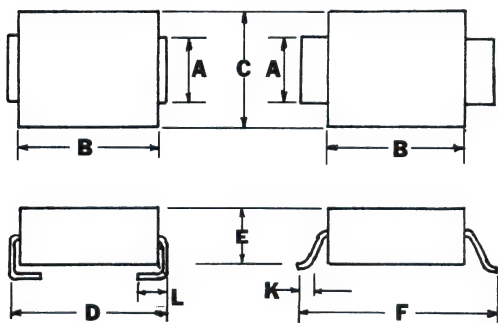
ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI CORP. PART NUMBER | | DEVICE MARKING CODE | REVERSE STAND-OFF VOLTAGE (See Note) V_{WM} VOLTS | BREAKDOWN VOLTAGE V_{BR} @ I_T VOLTS | | MAXIMUM CLAMPING VOLTAGE @ I_{PP} VOLTS | PEAK PULSE CURRENT (See Fig. 2) I_{PP} AMPS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_0 μA |
|--------------------------------|---------------------------|---------------------------|--|---|-------|---|--|---|
| GULL-WING LEAD | MODIFIED "J" BEND LEAD | | | MIN. | MAX. | | | |
| SMMG70 | SMMJ70 | GGN | 70 | 77.8 | 95.1 | 1 | 125 | 5 |
| SMMG70A | SMMJ70A | GGP | 70 | 77.8 | 86.0 | 1 | 113 | 5 |
| SMMG75 | SMMJ75 | GGQ | 75 | 83.3 | 102.0 | 1 | 134 | 5 |
| SMMG75A | SMMJ75A | GGR | 75 | 83.3 | 92.1 | 1 | 121 | 5 |
| SMMG78 | SMMJ78 | GGS | 78 | 86.7 | 106.0 | 1 | 139 | 5 |
| SMMG78A | SMMJ78A | GGT | 78 | 86.7 | 95.8 | 1 | 126 | 5 |
| SMMG85 | SMMJ85 | GGU | 85 | 94.4 | 115.0 | 1 | 151 | 5 |
| SMMG85A | SMMJ85A | GGV | 85 | 94.4 | 104.0 | 1 | 137 | 5 |
| SMMG90 | SMMJ90 | GGW | 90 | 100 | 122 | 1 | 160 | 5 |
| SMMG90A | SMMJ90A | GGX | 90 | 100 | 111 | 1 | 146 | 5 |
| SMMG100 | SMMJ100 | GGY | 100 | 111 | 136 | 1 | 179 | 5 |
| SMMG100A | SMMJ100A | GGZ | 100 | 111 | 123 | 1 | 162 | 5 |
| SMMG110 | SMMJ110 | GHD | 110 | 122 | 149 | 1 | 196 | 5 |
| SMMG110A | SMMJ110A | GHE | 110 | 122 | 135 | 1 | 177 | 5 |
| SMMG120 | SMMJ120 | GHF | 120 | 133 | 163 | 1 | 214 | 5 |
| SMMG120A | SMMJ120A | GHG | 120 | 133 | 147 | 1 | 193 | 5 |
| SMMG130 | SMMJ130 | GHH | 130 | 144 | 176 | 1 | 231 | 5 |
| SMMG130A | SMMJ130A | GHK | 130 | 144 | 159 | 1 | 209 | 5 |
| SMMG150 | SMMJ150 | GHL | 150 | 167 | 204 | 1 | 268 | 5 |
| SMMG150A | SMMJ150A | GHM | 150 | 167 | 185 | 1 | 243 | 5 |
| SMMG160 | SMMJ160 | GHN | 160 | 178 | 218 | 1 | 287 | 5 |
| SMMG160A | SMMJ160A | GHP | 160 | 178 | 197 | 1 | 259 | 5 |
| SMMG170 | SMMJ170 | GHQ | 170 | 189 | 231 | 1 | 304 | 5 |
| SMMG170A | SMMJ170A | GHR | 170 | 189 | 209 | 1 | 275 | 5 |

For Bidirectional indicate a C or CA suffix after the part number. (i.e.: SMMG170CA or SMMJ170C)

Microsemi Corp.'s SMM Series (1500W) surface mountable packages are designed specifically for transient voltage suppression. The wide leads assure a large surface contact for good heat dissipation, and a low resistance path for surge current flow to ground. These high speed transient voltage suppressors can be used to effectively protect sensitive components such as integrated circuits and MOS devices.

PACKAGE DIMENSIONS



DIMENSIONS IN INCHES

| | A | B | C | D | E | F | K | L |
|------|------|------|------|------|------|-------|-------|-------|
| MIN. | .115 | .260 | .220 | .300 | .070 | .375 | .025 | .030 |
| MAX. | .121 | .280 | .240 | .320 | .085 | .395 | .040 | .060 |
| | A | B | C | D | E | F | K | L |
| MIN. | 2.92 | 6.60 | 5.58 | 7.62 | 1.77 | 9.50 | 0.635 | 0.760 |
| MAX. | 3.07 | 7.11 | 6.09 | 8.13 | 2.16 | 10.03 | 1.100 | 1.520 |

Typical Standoff Height: 0.004"-0.008" (0.1mm-0.2mm)

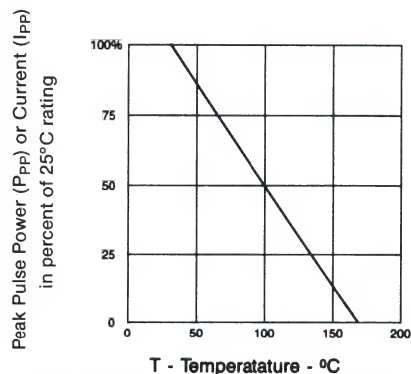


FIGURE 3 DERATING CURVE

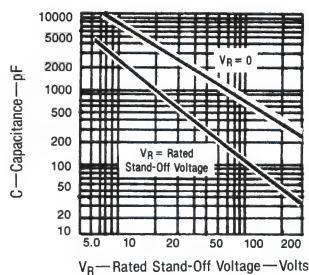


FIGURE 4
TYPICAL CAPACITANCE
VS STAND-OFF VOLTAGE

SML SERIES

5.0 thru 170.0

Volts

3000 WATTS

FEATURES

- UNIDIRECTIONAL AND BIDIRECTIONAL
- 3000 WATTS PEAK POWER
- VOLTAGE RANGE: 5.0 TO 170 VOLTS
- LOW INDUCTANCE
- LOW PROFILE PACKAGE FOR SURFACE MOUNTING

This series of TAZ (transient absorption zeners), available in small outline surface mountable packages, is designed to optimize board space. Packaged for use with surface mount technology automated assembly equipment, these parts can be placed on printed circuit boards and ceramic substrates to protect sensitive components from transient voltage damage.

The SML series, rated for 3000 watts, during a one millisecond pulse, can be used to protect sensitive circuits against transients induced by lightning and inductive load switching. With a response time of 1×10^{-12} seconds (theoretical) they are also effective against electrostatic discharge and NEMP.

MAXIMUM RATINGS

3000 watts of Peak Power dissipation ($10 \times 1000\mu s$)

$t_{clamping}$ (0 volts to V_{BR} min): less than 1×10^{-12} seconds (theoretical)

Forward surge rating: 200 Amps, 1/120 sec @ 25°C (Excluding Bidirectional)

Operating and Storage Temperature: -65° to +175°C

NOTE: TAZ is normally selected according to the reverse "Stand Off Voltage" (V_{RM}) which should be equal to or greater than the DC or continuous peak operating voltage level.

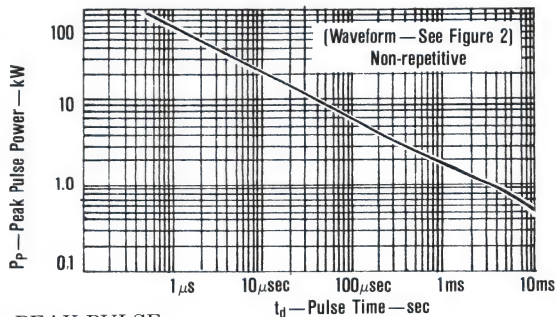


FIGURE 1 PEAK PULSE POWER VS PULSE TIME

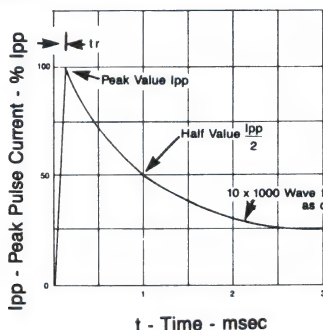


FIGURE 2 PULSE WAVEFORM

UNIDIRECTIONAL AND BIDIRECTIONAL SURFACE MOUNT



MECHANICAL CHARACTERISTICS

CASE: Molded, surface mountable.

TERMINALS: Solder-dipped gull-wing or modified J-bend leads.

POLARITY: Cathode end indicated by dot. No marking on bidirectional devices.

PACKAGING: 16mm tape. (See EIA Std. RS-481.)

Test wave form parameters
 $t_r = 10 \mu sec.$
 $t_d = 1000 \mu sec.$

SML 5.0 thru 170.0 Volts

ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI CORP. PART NUMBER | | DEVICE MARKING CODE | REVERSE STAND-OFF VOLTAGE (See Note) V_{WM} VOLTS | BREAKDOWN VOLTAGE V_{BR} @ I_T VOLTS | | MAXIMUM CLAMPING VOLTAGE @ I_{PP} VOLTS | PEAK PULSE CURRENT (See Fig. 2) I_{PP} AMPS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_R μA |
|--------------------------------|---------------------------|---------------------------|--|---|------|---|--|---|
| GULL-WING LEAD | MODIFIED "J" BEND LEAD | | | MIN. | MAX. | | | |
| SMLG5.0 | SMLJ5.0 | MD | 5.0 | 6.40 - 7.30 | 10 | 9.6 | 312.5 | 1000 |
| SMLG5.0A | SMLJ5.0A | MD | 5.0 | 6.40 - 7.00 | 10 | 9.2 | 326.0 | 1000 |
| SMLG6.0 | SMLJ6.0 | MD | 6.0 | 6.67 - 8.15 | 10 | 11.4 | 263.2 | 1000 |
| SMLG6.0A | SMLJ6.0A | MD | 6.0 | 6.67 - 7.37 | 10 | 10.3 | 291.3 | 1000 |
| SMLG6.5 | SMLJ6.5 | MD | 6.5 | 7.22 - 8.82 | 10 | 12.3 | 243.9 | 500 |
| SMLG6.5A | SMLJ6.5A | MD | 6.5 | 7.22 - 7.98 | 10 | 11.2 | 267.9 | 500 |
| SMLG7.0 | SMLJ7.0 | MD | 7.0 | 7.78 - 9.51 | 10 | 13.3 | 225.6 | 200 |
| SMLG7.0A | SMLJ7.0A | MD | 7.0 | 7.78 - 8.60 | 10 | 12.0 | 250.0 | 200 |
| SMLG7.5 | SMLJ7.5 | MD | 7.5 | 8.33 - 10.2 | 1 | 14.3 | 209.8 | 100 |
| SMLG7.5A | SMLJ7.5A | MD | 7.5 | 8.33 - 9.21 | 1 | 12.9 | 232.6 | 100 |
| SMLG8.0 | SMLJ8.0 | MD | 8.0 | 8.89 - 10.9 | 1 | 15.0 | 200.0 | 50 |
| SMLG8.0A | SMLJ8.0A | MD | 8.0 | 8.89 - 9.83 | 1 | 13.6 | 220.6 | 50 |
| SMLG8.5 | SMLJ8.5 | MD | 8.5 | 9.44 - 11.5 | 1 | 15.9 | 188.6 | 25 |
| SMLG8.5A | SMLJ8.5A | MD | 8.5 | 9.44 - 10.4 | 1 | 14.4 | 208.4 | 25 |
| SMLG9.0 | SMLJ9.0 | MD | 9.0 | 10.0 - 12.2 | 1 | 16.9 | 177.4 | 10 |
| SMLG9.0A | SMLJ9.0A | MD | 9.0 | 10.0 - 11.1 | 1 | 15.4 | 194.8 | 10 |
| SMLG10 | SMLJ10 | MD | 10 | 11.1 - 13.6 | 1 | 18.8 | 159.6 | 5 |
| SMLG10A | SMLJ10A | MD | 10 | 11.1 - 12.3 | 1 | 17.0 | 176.4 | 5 |
| SMLG11 | SMLJ11 | MD | 11 | 12.2 - 14.9 | 1 | 20.1 | 149.2 | 5 |
| SMLG11A | SMLJ11A | MD | 11 | 12.2 - 13.5 | 1 | 18.2 | 164.8 | 5 |
| SMLG12 | SMLJ12 | MD | 12 | 13.3 - 16.3 | 1 | 22.0 | 136.4 | 5 |
| SMLG12A | SMLJ12A | MD | 12 | 13.3 - 14.7 | 1 | 19.9 | 150.6 | 5 |
| SMLG13 | SMLJ13 | MD | 13 | 14.4 - 17.6 | 1 | 23.8 | 126.0 | 5 |
| SMLG13A | SMLJ13A | MD | 13 | 14.4 - 15.9 | 1 | 21.5 | 139.4 | 5 |
| SMLG14 | SMLJ14 | MD | 14 | 15.6 - 19.1 | 1 | 25.8 | 116.2 | 5 |
| SMLG14A | SMLJ14A | MD | 14 | 15.6 - 17.2 | 1 | 23.2 | 129.4 | 5 |
| SMLG15 | SMLJ15 | MD | 15 | 16.7 - 20.4 | 1 | 26.9 | 111.6 | 5 |
| SMLG15A | SMLJ15A | MD | 15 | 16.7 - 18.5 | 1 | 24.4 | 123.0 | 5 |
| SMLG16 | SMLJ16 | MD | 16 | 17.8 - 21.8 | 1 | 28.8 | 104.2 | 5 |
| SMLG16A | SMLJ16A | MD | 16 | 17.8 - 19.7 | 1 | 26.0 | 115.4 | 5 |
| SMLG17 | SMLJ17 | MD | 17 | 18.9 - 23.1 | 1 | 30.5 | 98.4 | 5 |
| SMLG17A | SMLJ17A | MD | 17 | 18.9 - 20.9 | 1 | 27.6 | 106.8 | 5 |
| SMLG18 | SMLJ18 | MD | 18 | 20.0 - 24.4 | 1 | 32.2 | 93.2 | 5 |
| SMLG18A | SMLJ18A | MD | 18 | 20.0 - 22.1 | 1 | 29.2 | 102.8 | 5 |
| SMLG20 | SMLJ20 | MD | 20 | 22.2 - 27.1 | 1 | 35.8 | 83.8 | 5 |
| SMLG20A | SMLJ20A | MD | 20 | 22.2 - 24.5 | 1 | 32.4 | 92.6 | 5 |
| SMLG22 | SMLJ22 | MD | 22 | 24.4 - 29.8 | 1 | 39.4 | 76.2 | 5 |
| SMLG22A | SMLJ22A | MD | 22 | 24.4 - 26.9 | 1 | 35.5 | 84.4 | 5 |
| SMLG24 | SMLJ24 | MD | 24 | 26.7 - 32.6 | 1 | 43.0 | 69.8 | 5 |
| SMLG24A | SMLJ24A | MD | 24 | 26.7 - 29.5 | 1 | 38.9 | 77.2 | 5 |
| SMLG26 | SMLJ26 | MD | 26 | 28.9 - 35.3 | 1 | 46.6 | 64.4 | 5 |
| SMLG26A | SMLJ26A | MD | 26 | 28.9 - 31.9 | 1 | 42.1 | 71.2 | 5 |
| SMLG28 | SMLJ28 | MD | 28 | 31.1 - 38.0 | 1 | 50.0 | 60.0 | 5 |
| SMLG28A | SMLJ28A | MD | 28 | 31.1 - 34.4 | 1 | 45.4 | 66.0 | 5 |
| SMLG30 | SMLJ30 | MD | 30 | 33.3 - 40.7 | 1 | 53.5 | 56.0 | 5 |
| SMLG30A | SMLJ30A | MD | 30 | 33.3 - 36.8 | 1 | 48.4 | 62.0 | 5 |
| SMLG33 | SMLJ33 | MD | 33 | 36.7 - 44.9 | 1 | 59.0 | 50.4 | 5 |
| SMLG33A | SMLJ33A | MD | 33 | 36.7 - 40.6 | 1 | 53.3 | 56.2 | 5 |
| SMLG36 | SMLJ36 | MD | 36 | 40.0 - 48.9 | 1 | 64.3 | 46.6 | 5 |
| SMLG36A | SMLJ36A | MD | 36 | 40.0 - 44.2 | 1 | 58.1 | 51.6 | 5 |
| SMLG40 | SMLJ40 | MD | 40 | 44.4 - 54.3 | 1 | 71.4 | 42.0 | 5 |
| SMLG40A | SMLJ40A | MD | 40 | 44.4 - 49.1 | 1 | 64.5 | 48.4 | 5 |
| SMLG43 | SMLJ43 | MD | 43 | 47.8 - 58.4 | 1 | 76.7 | 39.2 | 5 |
| SMLG43A | SMLJ43A | MD | 43 | 47.8 - 52.8 | 1 | 69.4 | 43.2 | 5 |
| SMLG45 | SMLJ45 | MD | 45 | 50.0 - 61.1 | 1 | 80.3 | 37.4 | 5 |
| SMLG45A | SMLJ45A | MD | 45 | 50.0 - 55.3 | 1 | 72.7 | 41.2 | 5 |
| SMLG48 | SMLJ48 | MD | 48 | 53.3 - 65.1 | 1 | 85.5 | 35.0 | 5 |
| SMLG48A | SMLJ48A | MD | 48 | 53.3 - 58.9 | 1 | 77.4 | 38.8 | 5 |
| SMLG51 | SMLJ51 | MD | 51 | 56.7 - 69.3 | 1 | 91.1 | 37.0 | 5 |
| SMLG51A | SMLJ51A | MD | 51 | 56.7 - 62.7 | 1 | 82.4 | 36.4 | 5 |
| SMLG54 | SMLJ54 | MD | 54 | 60.0 - 73.3 | 1 | 96.3 | 31.2 | 5 |
| SMLG54A | SMLJ54A | MD | 54 | 60.0 - 66.3 | 1 | 87.1 | 34.4 | 5 |
| SMLG58 | SMLJ58 | MD | 58 | 64.4 - 78.7 | 1 | 103.0 | 39.2 | 5 |
| SMLG58A | SMLJ58A | MD | 58 | 64.4 - 71.2 | 1 | 93.6 | 32.0 | 5 |
| SMLG60 | SMLJ60 | MD | 60 | 66.7 - 81.5 | 1 | 107.0 | 28.0 | 5 |
| SMLG60A | SMLJ60A | MD | 60 | 66.7 - 73.7 | 1 | 96.8 | 31.0 | 5 |
| SMLG64 | SMLJ64 | MD | 64 | 71.1 - 86.9 | 1 | 114.0 | 26.4 | 5 |
| SMLG64A | SMLJ64A | MD | 64 | 71.1 - 78.6 | 1 | 103.0 | 29.2 | 5 |

SML 5.0 thru 170 Volts

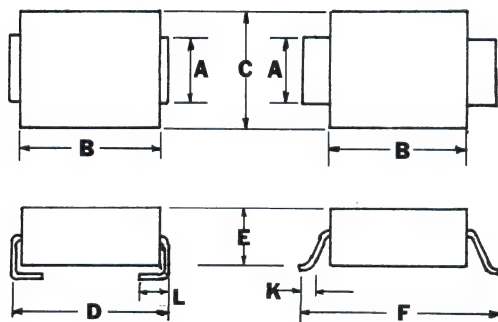
ELECTRICAL CHARACTERISTICS @ 25°C

| MICROSEMI CORP. PART NUMBER | | DEVICE MARKING CODE | REVERSE STAND-OFF VOLTAGE (See Note) V_{WM} VOLTS | BREAKDOWN VOLTAGE $V_{(BR)}$ @ I_T VOLTS | | MAXIMUM CLAMPING VOLTAGE @ I_{PP} VOLTS | PEAK PULSE CURRENT (See Fig. 2) I_{PP} AMPS | MAXIMUM REVERSE LEAKAGE @ V_{WM} I_D μA |
|--------------------------------|---------------------------|---------------------------|--|---|-------|---|--|---|
| GULL-WING LEAD | MODIFIED "J" BEND LEAD | | | MIN. | MAX. | | | |
| SMLG70 | SMLJ70 | MGN | 70 | 77.8 | 95.1 | 1 | 125 | 5 |
| SMLG70A | SMLJ70A | MGF | 70 | 77.8 | 86.0 | 1 | 113 | 5 |
| SMLG75 | SMLJ75 | MGQ | 75 | 83.3 | 102.0 | 1 | 134 | 5 |
| SMLG75A | SMLJ75A | MGR | 75 | 83.3 | 92.1 | 1 | 121 | 5 |
| SMLG78 | SMLJ78 | MGS | 78 | 86.7 | 106.0 | 1 | 139 | 5 |
| SMLG78A | SMLJ78A | MGT | 78 | 86.7 | 95.8 | 1 | 126 | 5 |
| SMLG85 | SMLJ85 | MGU | 85 | 94.4 | 115.0 | 1 | 151 | 5 |
| SMLG85A | SMLJ85A | MGV | 85 | 94.4 | 104.0 | 1 | 137 | 5 |
| SMLG90 | SMLJ90 | MGW | 90 | 100 | -122 | 1 | 160 | 5 |
| SMLG90A | SMLJ90A | MGX | 90 | 100 | -111 | 1 | 146 | 5 |
| SMLG100 | SMLJ100 | MGY | 100 | 111 | -136 | 1 | 179 | 5 |
| SMLG100A | SMLJ100A | MGZ | 100 | 111 | -123 | 1 | 162 | 5 |
| SMLG110 | SMLJ110 | MHD | 110 | 122 | -149 | 1 | 196 | 5 |
| SMLG110A | SMLJ110A | MHE | 110 | 122 | -135 | 1 | 177 | 5 |
| SMLG120 | SMLJ120 | MHF | 120 | 133 | -163 | 1 | 214 | 5 |
| SMLG120A | SMLJ120A | MHG | 120 | 133 | -147 | 1 | 193 | 5 |
| SMLG130 | SMLJ130 | MNH | 130 | 144 | -176 | 1 | 231 | 5 |
| SMLG130A | SMLJ130A | MNH | 130 | 144 | -159 | 1 | 209 | 5 |
| SMLG150 | SMLJ150 | MHL | 150 | 167 | -204 | 1 | 268 | 5 |
| SMLG150A | SMLJ150A | MHM | 150 | 167 | -185 | 1 | 243 | 5 |
| SMLG160 | SMLJ160 | MHN | 160 | 178 | -218 | 1 | 287 | 5 |
| SMLG160A | SMLJ160A | MHP | 160 | 178 | -197 | 1 | 259 | 5 |
| SMLG170 | SMLJ170 | MHQ | 170 | 189 | -231 | 1 | 304 | 5 |
| SMLG170A | SMLJ170A | MHR | 170 | 189 | -209 | 1 | 275 | 5 |

For Bidirectional indicate a C or CA suffix after the part number. (i.e.: SMLG170CA or SMLJ170C)

Microsemi Corp.'s SML Series (3000W) surface mountable packages are designed specifically for transient voltage suppression. The wide leads assure a large surface contact for good heat dissipation, and a low resistance path for surge current flow to ground. These high speed transient voltage suppressors can be used to effectively protect sensitive components such as integrated circuits and MOS devices.

PACKAGE DIMENSIONS



DIMENSIONS IN INCHES

| | A | B | C | D | E | F | K | L |
|---------------------------|------|------|------|------|------|-------|-------|-------|
| MIN. | .142 | .260 | .220 | .300 | .070 | .375 | .025 | .030 |
| MAX. | .148 | .280 | .240 | .320 | .085 | .395 | .040 | .060 |
| DIMENSIONS IN MILLIMETERS | | | | | | | | |
| MIN. | 3.60 | 6.60 | 5.58 | 7.62 | 1.77 | 9.50 | 0.635 | 0.760 |
| MAX. | 3.76 | 7.11 | 6.09 | 8.13 | 2.16 | 10.03 | 1.100 | 1.520 |

Typical Standoff Height: 0.004"-0.008" (0.1mm-0.2mm)

Peak Pulse Power (P_{PP}) or Current (I_{PP})
in percent of 25°C rating

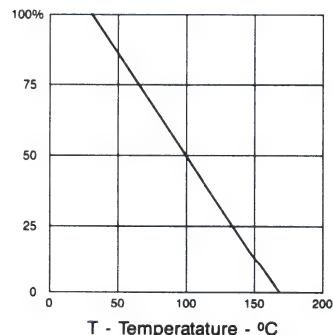


FIGURE 3 DERATING CURVE

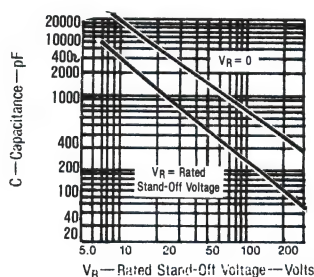


FIGURE 4
TYPICAL CAPACITANCE
VS STAND-OFF VOLTAGE



Power Technology Components
A Microsemi Company
23201 S. Normandie • Torrance, CA 90501 • (213) 534-3737
TLX: 664276 • FAX: (213) 5305609

NPN Darlington Transistors TO-204MA (TO-3)

| Part Number | IC Amps | V _{CE0} (SUS) Volts | V _{CE} (SAT) Volts | hFE (Typical) | Switch Time S | | | P _D Watts | Circuit Diagram | Technical Publication |
|--|---------|------------------------------|-----------------------------|---------------|----------------|----------------|----------------|----------------------|-----------------|-----------------------|
| | | | | | t _r | t _s | t _r | | | |
| PTC 10002 PTC 10003 | 10 | 350 400 | 1.9 | 30-300 | 0.6 | 3.0 | 1.5 | 150 | A | PTC 10002/03 |
| PTC 10006 PTC 10007 | 10 | 350 400 | 1.9 | 30-300 | 0.6 | 1.5 | 0.5 | 150 | B | PTC 10006/07 |
| PTC 6251 PTC 6252 PTC 6253 | 10 | 350 400 450 | 2.0 | 10-120 | 0.4 | 2.5 | 1.0 | 150 | C | Consult Factory |
| PTC 6000 PTC 6001 | 15 | 300 350 | 2.0 | 40-160 | 0.4 | 2.5 | 1.0 | 125 | C | PTC 6000/03 |
| PTC 6002 PTC 6003 | 15 | 400 500 | 2.0 | 40-160 | 0.4 | 2.5 | 1.0 | 125 | C | PTC 6000/03 |
| PTC 10000 PTC 10001 | 20 | 350 400 | 1.9 | 50-600 | 0.6 | 3.5 | 2.4 | 175 | A | PTC 10000/01 |
| PTC 10004 PTC 10005 | 20 | 350 400 | 1.9 | 50-600 | 0.6 | 1.5 | 0.5 | 175 | B | PTC 10004/05 |
| PTC 10008 PTC 10009 | 20 | 450 500 | 2.0 | 40-400 | 1.5 | 2.0 | 0.6 | 175 | B | PTC 10008/09 |
| PTC 6060 PTC 6061 PTC 6062 PTC 6063 | 20 | 300 350 400 500 | 1.5 | 30-120 | 0.4 | 2.5 | 1.0 | 125 | C | PTC 6060/63 |
| PTC 9000 PTC 9001 PTC 9002 | 20 | 750 850 900 | 2.0 | 20 | 3.0 | 6.0 | 3.0 | 125 | C | PTC 9000/02 |
| PTC 6022 PTC 6023 | 30 | 350 400 | 2.0 | 50-750 | 0.4 | 6.5 | 1.0 | 125 | C | PTC 6022/6023 |
| PTC 6072 PTC 6073 | 40 | 350 400 | 2.0 | 50-250 | 0.4 | 6.5 | 1.0 | 125 | B | PTC 6072/6073 |
| PTC 10022 PTC 10023 | 40 | 350 400 | 2.2 | 50-600 | 1.2 | 2.5 | 0.9 | 250 | B | PTC 10022/23 |
| PTC 10015 PTC 10016 | 50 | 400 500 | 2.2 | 25 | 1.0 | 2.5 | 1.0 | 250 | B | PTC 10015/16 |
| PTC 7000 PTC 7001 PTC 7002 PTC 7003 | 50 | 300 350 400 500 | 2.0 | 40-120 | 0.4 | 2.5 | 0.7 | 175 | C | PTC 7000/03 |
| PTC 10020 PTC 10021 | 60 | 200 250 | 2.2 | 75-1000 | 1.0 | 3.5 | 0.5 | 250 | B | PTC 10020/21 |



Power Technology Components

A Microsemi Company

23201 S. Normandie • Torrance, CA 90501 • (213) 534-3737

TLX: 664276 • FAX: (213) 5305609

NPN Transistors TO-204MA (TO-3)

| | | | | | | | | | | |
|----------|-----|-----|-----|--------|------|-----|-----|-----|---|-------------|
| PTC 401 | 2 | 300 | 2.0 | 20-100 | — | — | 0.8 | 75 | — | PTC 401/402 |
| PTC 413 | 2 | 325 | 0.8 | 20-80 | 0.25 | 2.5 | 0.8 | 75 | — | PTC 413/423 |
| PTC 410 | 3.5 | 200 | 0.8 | 30-90 | 0.25 | 2.5 | 0.8 | 100 | — | PTC 410/411 |
| PTC 411 | 3.5 | 300 | 0.8 | 30-90 | 0.25 | 2.5 | 0.8 | 100 | — | PTC 410/411 |
| PTC 402 | 3.5 | 325 | 2.0 | 20-100 | — | — | 0.8 | 100 | — | PTC 401/402 |
| PTC 403 | 3.5 | 325 | 2.0 | 20-100 | — | — | 0.8 | 100 | — | PTC 403/409 |
| PTC 409 | 3.5 | 325 | 2.0 | 20-100 | 0.25 | 2.5 | 0.8 | 100 | — | PTC 403/409 |
| PTC 423 | 3.5 | 325 | 0.8 | 20-80 | 0.25 | 2.5 | 0.8 | 100 | — | PTC 413/423 |
| PTC 424 | 3.5 | 350 | 0.8 | 30-90 | 0.25 | 2.5 | 0.8 | 100 | — | PTC 424/425 |
| PTC 425 | 3.5 | 400 | 0.8 | 30-90 | 0.25 | 2.5 | 0.8 | 100 | — | PTC 424/425 |
| PTC 430 | 7 | 300 | 0.9 | 15-45 | 0.4 | 2.5 | 0.8 | 125 | — | PTC 430/431 |
| PTC 431 | 7 | 325 | 0.7 | 15-35 | 0.4 | 2.5 | 0.8 | 125 | — | PTC 430/431 |
| PTC 484 | 10 | 700 | 2.0 | 7.5 | 2.0 | 4.0 | 2.0 | 175 | — | * |
| PTC 485 | 10 | 800 | 2.0 | 7.5 | 2.0 | 4.0 | 2.0 | 175 | — | * |
| 2N6674 | 10 | 300 | 1.0 | 8-20 | 0.6 | 2.5 | 0.5 | 175 | — | 2N6674/75 |
| 2N6675 | 10 | 400 | 1.0 | 8-20 | 0.6 | 2.5 | 0.5 | 175 | — | 2N6674/75 |
| 2N6676 | 15 | 300 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 175 | — | 2N6676/78 |
| 2N6677 | 15 | 350 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 175 | — | 2N6676/78 |
| 2N6678 | 15 | 400 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 175 | — | 2N6676/78 |
| PTC 6679 | 30 | 300 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 230 | — | PTC6679/81 |
| PTC 6680 | 30 | 350 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 230 | — | PTC6679/81 |
| PTC 6681 | 30 | 400 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 230 | — | PTC6679/81 |
| PTC 6682 | 40 | 300 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 230 | — | PTC6682/83 |
| PTC 6683 | 40 | 350 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 230 | — | PTC6682/83 |

* Consult Factory

NPN Transistors TO-247

| Part Number | Ic Amps | V _{CEO} (SUS) Volts | V _{CE} (SAT) Volts | h _{FE} (Typical) | Switch Time S | | | P _D Watts | Circuit Diagram | Technical Publication |
|-------------|---------|------------------------------|-----------------------------|---------------------------|----------------|----------------|----------------|----------------------|-----------------|-----------------------|
| | | | | | t _r | t _s | t _f | | | |
| PTC 401P | 2 | 300 | 2.0 | 20-100 | — | — | 0.8 | 75 | — | * |
| PTC 413P | 2 | 325 | 0.8 | 20-80 | 0.25 | 2.5 | 0.8 | 75 | — | * |
| PTC 410P | 3.5 | 200 | 0.8 | 30-90 | 0.25 | 2.5 | 0.8 | 100 | — | * |
| PTC 411P | 3.5 | 300 | 0.8 | 30-90 | 0.25 | 2.5 | 0.8 | 100 | — | * |
| PTC 402P | 3.5 | 325 | 2.0 | 20-100 | — | — | 0.8 | 100 | — | * |
| PTC 403P | 3.5 | 325 | 2.0 | 20-100 | — | — | 0.8 | 100 | — | * |
| PTC 409P | 3.5 | 325 | 2.0 | 20-100 | 0.25 | 2.5 | 0.8 | 100 | — | * |
| PTC 423P | 3.5 | 325 | 0.8 | 20-80 | 0.25 | 2.5 | 0.8 | 100 | — | * |
| PTC 424P | 3.5 | 350 | 0.8 | 30-90 | 0.25 | 2.5 | 0.8 | 100 | — | * |
| PTC 425P | 3.5 | 400 | 0.8 | 30-90 | 0.25 | 2.5 | 0.8 | 100 | — | * |
| PTC 430P | 7 | 300 | 0.9 | 15-45 | 0.4 | 2.5 | 0.8 | 125 | — | * |
| PTC 431P | 7 | 325 | 0.7 | 15-35 | 0.4 | 2.5 | 0.8 | 125 | — | * |
| PTC 484P | 10 | 700 | 2.0 | 7.5 | 2.0 | 4.0 | 2.0 | 125 | — | * |
| PTC 485P | 10 | 800 | 2.0 | 7.5 | 2.0 | 4.0 | 2.0 | 125 | — | * |
| PTC 6674P | 10 | 300 | 1.0 | 8-20 | 0.6 | 2.5 | 0.5 | 125 | — | * |
| PTC 6675P | 10 | 400 | 1.0 | 8-20 | 0.6 | 2.5 | 0.5 | 125 | — | * |
| PTC 6676P | 15 | 300 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 125 | — | * |
| PTC 6677P | 15 | 350 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 125 | — | * |
| PTC 6678P | 15 | 400 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 125 | — | * |



Power Technology Components

A Microsemi Company

23201 S. Normandie • Torrance, CA 90501 • (213) 534-3737

TLX: 664276 • FAX: (213) 5305609

NPN Darlington Transistors TO-247

| | | | | | | | | | | |
|--------------------------|----|------------|-----|--------|-----|-----|-----|-----|---|---------------|
| PTC 10000P PTC 10001P | 20 | 350 400 | 1.9 | 50-600 | 0.6 | 3.5 | 2.4 | 125 | A | PTC 10000/01P |
| PTC 10002P PTC 10003P | 10 | 350 400 | 2.0 | 30-300 | 0.6 | 3.0 | 1.5 | 125 | A | PTC 10002/03P |

NPN Powermode Transistors

| | | | | | | | | | | |
|----------------------------------|----|-----|-----|------|-----|-----|-----|-----|-----------------------|---|
| PTC 8003 PTC 8004 PTC 8005 | 50 | 350 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 580 | Isolated Collector | * |
| PTC 8000 PTC 8001 PTC 8002 | 60 | 350 | 1.5 | 8-20 | 0.6 | 2.5 | 0.5 | 580 | Isolated Collector | * |

* Consult Factory

Fast Recovery Rectifiers

| Part Number | I _O Amps | V _R Volts | I _{FSM} Amps | V _F Volts | t _{rr} nS | Case Type | Technical Publication |
|--|------------------------|-----------------------------|--------------------------|-------------------------|-----------------------|--------------|--------------------------|
| PTC 862 PTC 864 PTC 866 | 40 | 200 400 600 | 600 | 1.5 | 500 | DO-5 | PTC 862/66 |
| PTC 872 PTC 874 PTC 876 | 50 | 200 400 600 | 600 | 1.5 | 500 | DO-5 | PTC 872/76 |
| PTC 920 PTC 921 PTC 922 PTC 923 | 50 | 900 1000 1100 1200 | 600 | 1.5 | 500 | DO-5 | PTC 920/23 |
| PTC 940 PTC 941 PTC 942 PTC 943 | 100 | 900 1000 1100 1200 | 2200 | 1.5 | 575 | DO-8 | PTC 940/43 |

For specific test conditions and performance specifications, refer to the Referenced Technical Publication.

Powermode Fast Recovery Rectifiers

| | | | | | | | |
|-------------------------------|-----|----------------------|-----|-----|-----|-------------------|---|
| PTC 700 PTC 701 PTC 702 | 100 | 1000 1100 1200 | 600 | 1.5 | 600 | Isolated Anode | * |
| PTC 710 PTC 711 PTC 712 | 125 | 1000 1100 1200 | 600 | 1.5 | 600 | Isolated Anode | * |

* Consult Factory

Circuit Diagrams

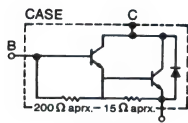


Diagram A

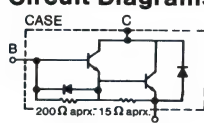


Diagram B



Diagram C



Power Technology Components

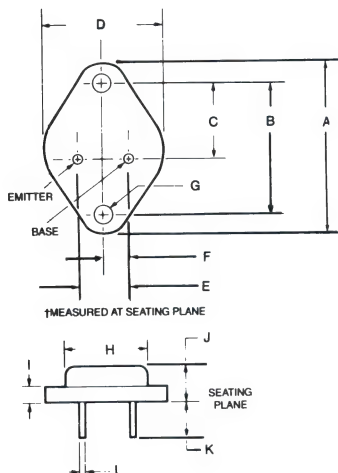
A Microsemi Company

23201 S. Normandie • Torrance, CA 90501 • (213) 534-3737

TLX: 664276 • FAX: (213) 5305609

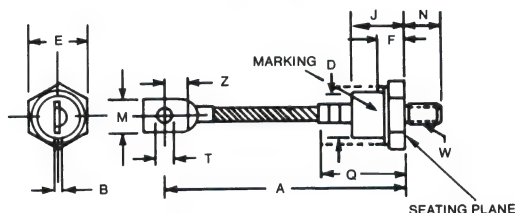
Dimensions

Transistors TO-204MA (Formerly TO-3)



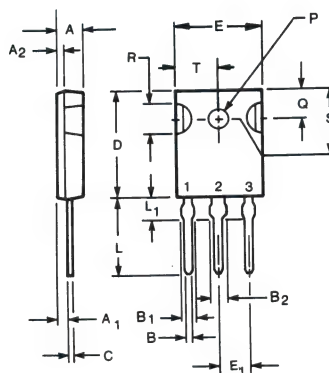
| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | — | 39.95 | — | 1.573 |
| B | 29.90 | 30.40 | 1.177 | 1.197 |
| C | 16.64 | 17.15 | 0.655 | 0.675 |
| D | — | 26.67 | — | 1.050 |
| E | 10.67 | 11.18 | 0.420 | 0.440 |
| F | 5.21 | 5.72 | 0.205 | 0.225 |
| ØG | 3.84 | 4.09 | 0.151 | 0.161 |
| ØH | — | 22.23 | — | 0.875 |
| I | — | 3.43 | — | 0.135 |
| J | 6.35 | 11.43 | 0.250 | 0.450 |
| K | 8.13 | — | 0.32 | — |
| ØL | 0.97 | 1.09 | 0.038 | 0.043 |

Rectifiers DO-8



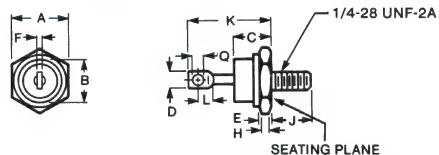
| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|--------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 98.43 | 117.47 | 3.875 | 4.625 |
| B | 2.03 | 3.05 | .080 | .120 |
| ØD | 21.97 | 22.86 | .865 | .900 |
| E | 26.19 | 27.00 | 1.031 | 1.063 |
| F | 7.37 | 7.87 | .290 | .310 |
| J | 22.10 | 23.88 | .870 | .940 |
| M | 11.10 | 16.51 | .437 | .650 |
| N | 15.37 | 16.38 | .605 | .645 |
| Q | — | 42.54 | — | 1.675 |
| ØT | 5.33 | 7.87 | .210 | .310 |
| Z | 7.62 | — | .300 | — |
| ØW | ¾-24 UNF-2A | | | |

Plastic Transistor TO-247



| DIM | MILLIMETERS | | INCHES | |
|----------------|-------------|-------|--------|------|
| | MIN | MAX | MIN | MAX |
| A | 4.70 | 5.31 | .185 | .209 |
| A | 2.21 | 2.59 | .087 | .102 |
| A | 1.50 | 2.49 | .059 | .098 |
| B | 1.02 | 1.40 | .040 | .055 |
| B | 2.01 | 2.39 | .079 | .094 |
| B | 3.00 | 3.38 | .118 | .133 |
| C | 0.41 | 0.79 | .016 | .031 |
| D | 19.71 | 20.29 | .776 | .799 |
| E | 15.29 | 15.88 | .602 | .625 |
| E ₁ | 5.13 | 5.79 | .202 | .228 |
| L | 14.20 | 14.78 | .559 | .582 |
| L ₁ | 3.71 | 4.29 | .146 | .169 |
| ØP | 3.00 | 3.38 | .118 | .133 |
| Q | 5.31 | 5.69 | .209 | .224 |
| ØR | 4.52 | 5.49 | .178 | .216 |
| S | 5.31 | 5.72 | .209 | .225 |
| T | 7.16 | 8.13 | .282 | .320 |

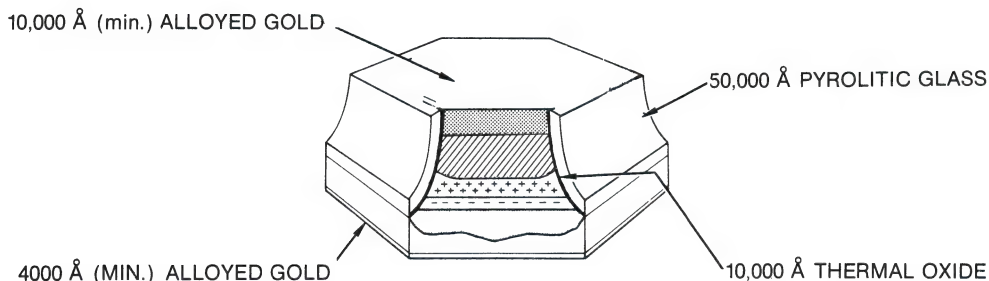
Rectifiers DO-5



| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 16.94 | 17.45 | 0.667 | 0.687 |
| ØB | — | 16.94 | — | 0.667 |
| C | — | 11.43 | — | 0.450 |
| D | — | 9.53 | — | 0.375 |
| E | 2.92 | 5.08 | 0.115 | 0.200 |
| F | — | 2.03 | — | 0.080 |
| H | 1.52 | — | 0.060 | — |
| J | 10.72 | 11.51 | 0.422 | 0.453 |
| K | — | 25.40 | — | 1.000 |
| L | 3.86 | — | .156 | — |
| ØQ | 3.56 | 4.45 | 0.140 | .175 |

MESA CHIPS FOR HYBRID APPLICATIONS

TYPICAL DIE CROSS SECTION FOR MESA DIE



Micro's new families of rectifier, computer diode and zener dice are passivated both with thermal oxide and pyrolytic glass for improved electrical stability after high temperature assembly operations. Rugged mesa construction and controlled junction geometry give high surge capability with minimized surface electric fields.

The rectifier family consists of 0.5A, 1A, 3A and 20A devices, computer and general purpose diodes, range from 250mW to 3A, and zener chips are available in 0.5W, 1.5W and 5W configurations. Micro also has single chip T.C. zeners of Series 1N821-829 and 1N821A-829A.

Devices are available as dice or, for more convenient handling, they may be ordered lid, channel or tab mounted. Specify any variation of gold, silver, aluminum or nickel metallization, as well as moly, tungsten and kovar tabs. Hard or soft solder can be applied to metallization of tabs.

Dice are shipped in Freon to avoid contamination and mechanical shock. For use, the Freon is poured off and the dice are clean and ready for assembly.

FEATURES

- ANY ZENER OR RECTIFIER IN THE MICROSEMI DATA BOOK CAN BE SUPPLIED IN DICE.
- LOT TRACEABILITY.
- ALL DICE ARE VISUALLY INSPECTED.
- HI-REL SCREENING AND PRODUCT ASSURANCE TESTING IS AVAILABLE.
- ALL MESA DICE ARE OXIDE AND GLASS PASSIVATED.
- POLARITY RECTIFIERS; MESA CATHODE. ANODE MESA IS AVAILABLE FOR DICE LESS THAN 200 VOLTS.
- ZENERS, 6.8-39 VOLT, 91-400 VOLT CATHODE MESA, 43-82 VOLT ANODE MESA.
- STANDARD METALLIZATION FOR MESA DICE IS 10,000 Å MINIMUM GOLD ON THE MESA, 4,000 Å GOLD MINIMUM ON THE BASE. SPECIAL METALLIZATION IS AVAILABLE.
- DICE AVAILABLE TO MIL-STD-883C, METHOD 5008. (B LEVEL AND S LEVEL)
- DICE MAY BE PACKAGED IN WAFFLE PACKS, BULK PACKING VIALS OR BULK PACK IN VIALS WITH FREON.

SANTA ANA, CA

For more information call:
(714) 979-8220

GENERAL PARAMETER RESTRICTIONS FOR 100% DICE TEST:

*Unmounted dice do not have the power ratings of packaged devices.

**Test conditions as well as ratings may need to be reduced.

V_F = 200 MA maximum. Accuracy variable above 50 MA, highly contact dependent.

I_R = Normal handling 10 NA minimum. Must be in dark. Special handling 1 NA minimum. In dark and special design cables and contacts.

B_V = Normal care 300 Volts maximum. Special care for dice >600 Volts — Requires hand test, special test box and environment. Dice are to be tested and maintained in an inert atmosphere to insure stability and eliminate arcing.

V_Z = 300 Volts maximum. V_Z tests requiring I_Z of over 200 MA not reliable.

Z_{ZT} = 1 Ohm minimum. V_Z tests requiring I_Z of over 200 MA not reliable.

Z_{ZK} = Not very reliable test due to AC pick up in probe & contact leads.

A.C. TESTS such as t_{rr} , junction capacitance, V_f peak, t_{fr} , r_e , are not performed as 100% tests. (See AC sample testing.)

High Current Tests such as V_f at current levels over 500MA, I_{FSM} , or V_Z Zener voltages at test currents over 500 MA cannot be reliably performed on dice, but must be die attached and bonded or sealed in a proper glass package.

A.C. PARAMETER TESTING:

A.C. parameters are lot guaranteed, not 100% tested. Samples sufficient to guarantee .4% AQL (Acceptable Quality Level) are assembled from the inspection lot and all A.C. parameters tested. The samples must meet the required A.C. test AQL or LTPD (Lot Tolerance Percent Defective) or the entire lot is rejected. Copies of A.C. test data for each dice lot can be provided at nominal cost.

Standard AQL or A.C. Parameters are Listed Below

| | |
|------------------|---------------------|
| t_{rr} = 1.5% | junction cap = 1.5% |
| t_{fr} = 1.0% | I subsurge = 2.5% |
| $V_F(PK)$ = 1.0% | Z_{zt} = 2.5% |
| r_e = 1.0% | Z_{zk} = 5.0% |
| | Noise = 20.0% |

Tighter AQL's are available by special lot selection or special controlled lot processing.

| | INDUSTRY STANDARD PART # | MICROSEMI CHIP PART # | POWER RATING* | DIE SIZE | | DIE THICKNESS | DIE GEOMETRY (FIGURE #) | METALLIZATION | | PACKAGING | | NOTE |
|--------|--------------------------------|-----------------------------|------------------|------------|--------|------------------|-------------------------------|------------------|-----------------|-----------|---------|------|
| | | | | TOP | BASE | | | TOP | BASE | WAFFLE | F. VIAL | |
| ZENERS | 1N957B- 1N992B | MD957B- MD992B | 400 mW | .011" | .022" | .009" | #4 | 10K \bar{A} Au | 4K \bar{A} Au | * | * | 1, 2 |
| | 1N4461- 1N4496 | MD4461- MD4496 | 1.5 Watt | .019" | .033" | .009" | #4 | 10K \bar{A} Au | 4K \bar{A} Au | * | * | 1, 2 |
| | 1N4954- 1N4996 | MD4954- MD4996 | 5 Watt | .049" | .0615" | .009" | #4 | 10K \bar{A} Au | 4K \bar{A} Au | * | * | 1, 2 |
| | 1N5063- 1N5117 | MD5063- MD5117 | 3 Watt | .030" | .048" | .009" | #5 | 10K \bar{A} Au | 4K \bar{A} Au | * | * | 1, 2 |
| | 1N6309- 1N6319 | MD6309- MD6319 | 500 mW | See Note 3 | | .008" | #6 | Al | Au | * | * | 1, 2 |
| | 1N6320- 1N6355 | MD6320- MD6355 | 500 mW | .019" | .024" | .009" | #4 | 10K \bar{A} Au | 4K \bar{A} Au | * | * | 1, 2 |
| | | | | | | | | | | | | |
| | | | | | | | | | | | | |
| | | | | | | | | | | | | |
| | | | | | | | | | | | | |

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For more information call:
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| INDUSTRY STANDARD PART # | MICROSEMI CHIP PART # | DESC. / CURRENT RATING | DIE SIZE | | DIE THICKNESS | DIE GEOMETRY (FIGURE #) | METALLIZATION | | PACKAGING | | NOTE |
|--|--|---|----------|--------|------------------|-------------------------------|---------------|---------|-----------|---------|------|
| | | | TOP | BASE | | | TOP | BASE | WAFFLE | F. VIAL | |
| 1N483B, 1N485B- 1N486B | MD483B, MD485B- MD486B | General Purpose 2 A @ 25°C | .011" | .022" | .009" | #4 | 10K Å Au | 4K Å Au | * | * | 2, 6 |
| 1N645- 1N649 | MD645- MD649 | General Purpose 2 A @ 25°C | .017" | .026" | .009" | #4 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N3595 | MD3595 | Fast Recovery 2 A @ 25°C | .009" | .015" | .008" | #6 | Al | Au | * | * | 5 |
| 1N3600 | MD3600 | Fast Recovery 2A @ 25°C | .007" | .015" | .008" | #6 | Al | Au | * | * | 4 |
| 1N3611, 1N3612, 1N3613, 1N3614, 1N3957 | MD3611, MD3612, MD3613, MD3614, MD3957 | General Purpose 1 Amp @ 100°C | .019" | .033" | .009" | #4 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N4001, 1N4004, 1N4005, 1N4007 | MD4001, MD4004, MD4005, MD4007 | General Purpose 1 Amp (Max.) | .030" | .048" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N4148, 1N4150 | MD4148, MD4150 | Fast Recovery 2 A (Max.) | .030" | .048" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N4245- 1N4246 | MD4245- MD4246 | General Purpose 1 Amp @ 100°C | .035" | .050" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N4247- 1N4249 | MD4247- MD4249 | Fast Recovery 1 Amp @ 55°C | .019" | .033" | .009" | #4 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N4942- 1N4944 1N4946- 1N4948 | MD4942- MD4944 MD4946- MD4948 | General Purpose 5 Amps @ 55°C | .074" | .088" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N5415- 1N5420 | MD5415- MD5420 | Fast Recovery 3 Amp | .049" | .0615" | .009" | #4 | 10K Å Au | 4K Å Au | * | * | 2, 6 |
| 1N5614, 1N5616, 1N5618 1N5620, 1N5622 | MD5614, MD5616, MD5618 MD5620, MD5622 | General Purpose 1 Amp @ 50°C | .035" | .050" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N5550- 1N5553, 1N5554 | MD5550- MD5553, MD5554 | General Purpose 5 Amps @ 55°C | .074" | .088" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N5615, 1N5617, 1N5619 1N5621, 1N5623 | MD5615, MD5617, MD5619 MD5621, MD5623 | General Purpose 1 Amp @ 55°C | .035" | .050" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2 |
| 1N5802- 1N5806 | MD5802- MD5806 | Fast Recovery 1 Amp @ 55°C | .035" | .050" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2, 6 |
| 1N5807- 1N5811 | MD5807- MD5811 | Fast Recovery 3 Amps @ 55°C | .074" | .088" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2, 6 |
| 1N5812, 1N5814, 1N5816 | MD5812, MD5814, MD5816 | General Purpose 20 Amps (Max.) | .144" | .158" | .009" | #5 | 10K Å Au | 4K Å Au | * | * | 2, 6 |

RECTIFIERS

| RECTIFIERS | INDUSTRY STANDARD PART # | MICROSEMI CHIP PART # | DESC./ CURRENT RATING | DIE SIZE | | DIE THICKNESS | DIE GEOMETRY (FIGURE #) | METALLIZATION | | PACKAGING | | NOTE |
|------------|--------------------------------|-----------------------------|--|----------|-------|------------------|-------------------------------|---------------|--------|-----------|---------|------|
| | | | | TOP | BASE | | | TOP | BASE | WAFFLE | F. VIAL | |
| | 1N6073- 1N6075 | MD6073- MD6075 | Fast Recovery 1 Amp (Average) | .030" | .048" | .009" | #5 | 10KÅ Au | 4KÅ Au | * | * | 2. 6 |
| | 1N6076- 1N6078 | MD6076- MD6078 | Fast Recovery 1 Amp (Average) | .074" | .090" | .009" | #5 | 10KÅ Au | 4KÅ Au | * | * | 2. 6 |
| | 1N6079- 1N6081 | MD6079- MD6081 | Fast Recovery 1 Amp (Average) | .115" | .129" | .009" | #5 | 10KÅ Au | 4KÅ Au | * | * | 2. 6 |
| | | | | | | | | | | | | |

NOTE 1: 6.8-39 Volts, 91-200 Volts Cathode Mesa, 43-82 Volts Anode Mesa

NOTE 2: Special metallization is available.

NOTE 3: Planar die .021 square, bonding pad anode up.

NOTE 4: Planar die also available in .021 square.

NOTE 5: Figure #7 when ordering .021 square die.

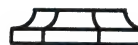
NOTE 6: Anode mesa available less than 200 Volts.

MICROSEMI DIE GEOMETRY

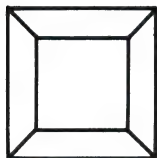
MESA



(Side View)



(Side View)



(Top View)

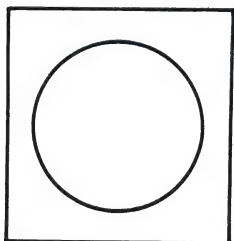
FIGURE 4



(Top View)

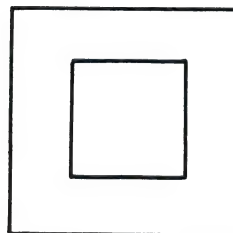
FIGURE 5

PLANAR (Anode Top Contact)



(Top View)

FIGURE 6



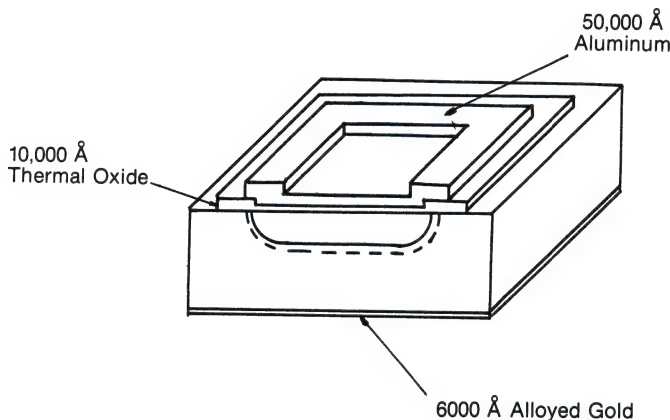
(Top View)

FIGURE 7

SANTA ANA, CA
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PLANAR CHIPS FOR HYBRID APPLICATIONS

TYPICAL PLANAR CHIP FOR HYBRID APPLICATION



Microsemi's family of zener and transient suppressor planar dice are passivated with thermal oxide construction utilizing unique epitaxial techniques to provide both controlled junction geometry with minimized surface electric fields as well as minimal clamping voltages for transient suppressors. Additional geometries are available for single chip zero temperature coefficient reference diodes and bipolar transient suppressors.

Microsemi Corporation offers a complete line of zener, transient suppressor, rectifier and zero temperature compensated reference voltage chips most commonly used in hybrid circuit design. All chips have a high temperature glass SiO_2 passivation protecting the p-n junction regions for subsequent handling. Metallizations available are compatible with ultrasonic and thermocompression scrub and eutectic die bonding and wire bonding techniques. Also, our own special metallization is available for solder bonding techniques if required.

All chips are subjected to visual inspection at Microsemi Corporation which exceed the criteria detailed in MIL-STD-883, Method 2010, Condition B, as well as MIL-STD-750, Method 2073, and are guaranteed to pass an AQL of 2.5%. All chips are also 100% electrically tested to meet the specified parameters and are guaranteed to pass an AQL of 1.0%.

Microsemi hybrid applications requiring zener diodes have historically selected electrical properties identical to earlier identified JEDEC registrations in the "1N" series devices. The majority of these are rated at 500mW or less. However, higher power selections are also available if adequate heat sinking is provided

by the hybrid manufacturers in the mounting techniques.

Microsemi Corporation offers several chip sizes for various applications. A 25 mil square die is primarily for applications up to 500mW. For power levels exceeding this up to 3 watts, we recommend our 37 mil square. Above 3 watts, a 60 mil square die is available. Please specify die size when ordering if requirements deviate from this guideline as determined by customer heat-sinking and mounting conditions.

The popular zero temperature compensated reference voltage chips provided by Microsemi are available in 37 mil or 25 mil double pad square die. On request, Microsemi will provide correlation samples assembled in solderless DO-7 package.

Some of the electrical equivalent types offered by Microsemi are listed in the accompanying pages. As may be seen, the "1N" prefix has been replaced by a "CH" to specify CHip when ordering. Other JEDEC registration chip equivalents may be ordered similarly if not listed herein in "CH" prefix. Consult factory for other special requirements not JEDEC registered.

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

HIGH RELIABILITY FEATURES

- AVAILABLE TO JAN, JANTX, JANTXV AND JANS EQUIVALENT SCREENING
- VISUAL PER MIL-STD-750 METHOD 2073, MIL-STD-883 METHOD 2010 OR CUSTOM SPECIFICATIONS
- MOUNTING IN DEVICE PACKAGES FOR LOT ACCEPTANCE TESTING OR SPECIAL SCREENING AS REQUIRED BY CUSTOMER SPECIFICATIONS

ADDITIONAL FEATURES

- PLANAR CONFIGURATION
- GLASS PASSIVATED
- SAW CUT TO ELIMINATE CRACKS AND CHIPPING
- AVAILABLE FOR HI-REL APPLICATIONS
- NUMEROUS METALLIZATION SCHEMES AVAILABLE
- TRACEABILITY TO STARTING SILICON WAFER LOT AND INDIVIDUAL DIFFUSION RUN
- 100% TESTED
- MANY STANDARD TYPES AVAILABLE OFF THE SHELF

Microsemi's diode chips are available in numerous metallization schemes including aluminum top (anode) and gold back (cathode), chrome-silver-gold or others as specified by customer requirements. Microsemi chips are compatible with all wire bonding and die attach techniques.

Microsemi chips are available in both polarities, Anode-Top and Cathode bottom being standard and Anode-bottom and Cathode-Top optional.

Nearly all encapsulated devices available from Microsemi can be supplied in dice form.

Engineering support is available for any special requirements.

SPECIFICATIONS

Zener Diode Chips.

Zero Temperature Compensated Reference Voltage Chips.

Transient Absorption Zeners (TAZ)

Rectifiers

All Junctions Passivated with Silicon Dioxide.

Electrically Similar to JEDEC Registrations with appropriate Bonding and Heat Sinking.

Compatible with All Wire Bonding and Die Attach Techniques.

Metallization: Anode wire bond pad is aluminum 50KÅ thick. Cathode (backside) is gold 6000 Å thick and alloyed. Other metallizations available for solder bonding such as chrome-silver-gold if specified.

Operation: For zener or reference voltage zero-TC operation, back side cathode must be operated positive with respect to anode.

Shipment: Chips are packaged in "waffle pack" containers or glass vials.

SCOTTSDALE, AZ

For more information call:
(602) 941-6300

| | INDUSTRY STANDARD PART # | MICROSEMI CHIP PART # (Note 1) | POWER RATING* | DIE SIZE (Note 1) | DIE THICKNESS | DIE GEOMETRY (Figure) | BOND PAD SIZE ANODE CATHODE (Note 2) | METALLIZATION FRONT BACK OPTIONS | PACKAGING WAFFLE F. VIAL |
|----------------------------------|---|---|------------------|---|-------------------------|-----------------------------|--|-------------------------------------|-----------------------------|
| ZENERS | 1N746- 1N759 | CH746- CH759 | 400 mW | .020" x .020" .025" x .025" .037" x .037" | .010" .010" .013" | #1 | .013" .020" .020" .025" .029" .037" | Al Au CrAgAu | * * |
| | 1N4370 1N4372 | CH4370 CH4372 | 400 mW | .020" x .020" .025" x .025" .037" x .037" | .010" .010" .013" | #1 | .013" .020" .020" .025" .029" .037" | Al Au CrAgAu | * * |
| | 1N957- 1N992 | CH957- CH992 | 400 mW | .020" x .020" .025" x .025" .037" x .037" | .010" .010" .013" | #1 | .013" .020" .020" .025" .029" .037" | Al Au CrAgAu | * * |
| | 1N2970- 1N3015 | CH2970- CH3015 | 10 Watt | .060" x .060" | .013" | #1 | .052" .060" | Al Au CrAgAu | * * |
| | 1N3993- 1N4000 | CH3993- CH4000 | 10 Watt | .060" x .060" | .013" | #1 | .052" .060" | Al Au CrAgAu | * * |
| | 1N3016- 1N3051 | CH3016- CH3051 | 1 Watt | .037" x .037" | .013" | #1 | .029" .037" | Al Au CrAgAu | * * |
| | 1N3821- 1N3830 | CH3821- CH3830 | 1 Watt | .037" x .037" | .013" | #1 | .029" .037" | Al Au CrAgAu | * * |
| | 1N4099- 1N4135 | CH4099- CH4135 | 400 mW | .020" x .020" .025" x .025" .037" x .037" | .010" .010" .013" | #1 | .013" .020" .020" .025" .029" .037" | Al Au CrAgAu | * * |
| | 1N4614- 1N4627 | CH4614- CH4627 | 400 mW | .020" x .020" .025" x .025" .037" x .037" | .010" .010" .013" | #1 | .013" .020" .020" .025" .029" .037" | Al Au CrAgAu | * * |
| | 1N4678- 1N4717 | CH4678- CH4717 | 250 mW | .020" x .020" .025" x .025" .037" x .037" | .010" .010" .013" | #1 | .013" .020" .020" .025" .029" .037" | Al Au CrAgAu | * * |
| | 1N4728- 1N4764 | CH4728- CH4764 | 1 Watt | .037" x .037" | .013" | #1 | .029" .037" | Al Au CrAgAu | * * |
| | 1N5221- 1N5281 | CH5221- CH5281 | 500 mW | .020" x .020" .025" x .025" .037" x .037" | .010" .010" .013" | #1 | .013" .020" .020" .025" .029" .037" | Al Au CrAgAu | * * |
| | 1N5333- 1N5388 | CH5333- CH5388 | 5 Watt | .060" x .060" | .013" | #1 | .052" .060" | Al Au CrAgAu | * * |
| | 1N5518- 1N5546 | CH5518- CH5546 | 250 mW | .020" x .020" .025" x .025" .037" x .037" | .010" .010" .013" | #1 | .013" .020" .020" .025" .029" .037" | Al Au CrAgAu | * * |
| | 1N5728- 1N5757 | CH5728- CH5757 | 400 mW | .020" x .020" | .013" | #1 | .013" .020" | Al Au CrAgAu | * * |
| | 1N5913- 1N5956 | CH5913- CH5956 | 1.5 Watt | .037" x .037" | .013" | #1 | .029" .037" | Al Au CrAgAu | * * |
| | 1N5985- 1N6031 | CH5985- CH6031 | 500 mW | .020" x .020" | .010" | #1 | .013" .020" | Al Au CrAgAu | * * |
| | 1EZ110D5- 1EZ200D5 | CH1EZ110D5- CH1EZ200D5 | 1 Watt | .037" x .037" | .013" | #1 | .029" .037" | Al Au CrAgAu | * * |
| | 2EZ3.6D5- 2EZ200D5 | CH2EZ3.6D5- CH2EZ200D5 | 2 Watt | .037" x .037" | .013" | #1 | .029" .037" | Al Au CrAgAu | * * |
| | 3EZ3.9D5- 3EZ200D5 | CH3EZ3.9D5- CH3EZ200D5 | 3 Watt | .037" x .037" | .013" | #1 | .029" .037" | Al Au CrAgAu | * * |
| T.C.'s | 1N821, A- 1N829, A | CH821, A- CH829, A | 250 mW | .037" x .037" .025" x .025" | .013" | #1 #2 | .029" .037" (Double Pad) | Al Au CrAgAu | * * |
| | 1N4565, A- 1N4584, A | CH4565, A- CH4584, A | 400 mW | .037" x .037" .025" x .025" | .013" .010" | #1 #2 | .029" .037" (Double Pad) | Al Au CrAgAu | * * |
| | 1N5555- 1N5558 | CH5555- CH5558 | *1500 Watt | .123" x .123" | .013" | #3 | .115" .123" | Al Au CrAgAu | * * |
| Transient Suppressors | 1N5629- 1N5665 | CH5629- CH5665 | *1500 Watt | .123" x .123" | .013" | #3 | .115" .123" | Al Au CrAgAu | * * |
| | 1N5907- 1N5908 | CH5907- CH5908 | *1500 Watt | .123" x .123" | .013" | #3 | .115" .123" | Al Au CrAgAu | * * |
| | 1N6267- 1N6303 (1.5 KE Series) | CH6267- CH6303 | *1500 Watt | .123" x .123" | .013" | #3 | .115" .123" | Al Au CrAgAu | * * |
| | 1N6036- 1N6072 | CH6036- CH6072 | *1500 Watt | .123" x .123" | .020" | #3A | .115" Bipolar (Double Anode) | Al Au CrAgAu | * * |
| | P6KE6.8- P6KE200 | CHP6KE6.8- CHP6KE200 | *600 Watt | .060" x .060" | .013" | #1 | .052" .060" | Al Au CrAgAu | * * |

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| RECTIFIERS | INDUSTRY STANDARD PART # | MICROSEMI CHIP PART # (Note 1) | DESC./ CURRENT RATING | DIE SIZE (Note 1) | DIE THICKNESS | DIE GEOMETRY (Figure) | BOND PAD SIZE | | METALLIZATION | | | PACKAGING | |
|------------|--------------------------------|---|-----------------------------|-------------------------|------------------|-----------------------------|---------------|---------|---------------|------|---------|-----------|---------|
| | | | | | | | ANODE | CATHODE | FRONT | BACK | OPTIONS | WAFFLE | F. VIAL |
| | 1N3879- 1N3883 | CH3879- CH3883 | Fast Recovery 6 Amp | .120" x .120" | .013" | #1 | .112" | .120" | Al | Au | CrAgAu | * | * |
| | 1N3889- 1N3893 | CH3889- CH3893 | Fast Recovery 12 Amp | .120" x .120" | .013" | #1 | .112" | .120" | Al | Au | CrAgAu | * | * |

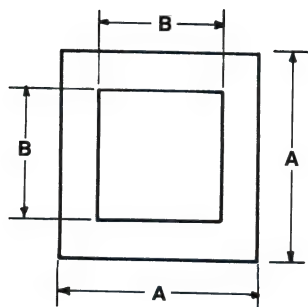
NOTE 1: For ordering 20 mil size die add suffix "-20", for 25 mil die add "-25", or for 37 mil die add "-37" to type number.

NOTE 2: Chips are available in both polarities. Standard is anode-top, cathode-bottom and optional is anode-bottom, cathode-top.

*Power Rating = Peak Pulse Power (TAZ devices)

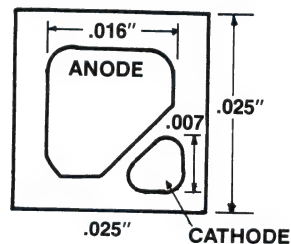
MICROSEMI DIE GEOMETRY

PLANAR

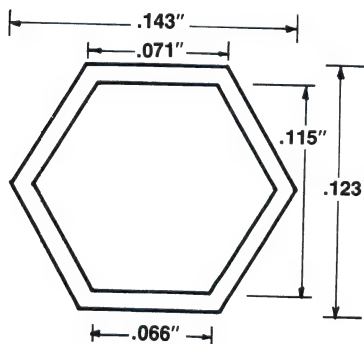


| DIE SIZE | .020 | .025 | .037 | .060 | .120 |
|-----------|-------|-------|-------|-------|-------|
| A | .020" | .025" | .037" | .060" | .120" |
| B | .013" | .020" | .029" | .052" | .112" |
| Thickness | .010" | .010" | .013" | .013" | .013" |

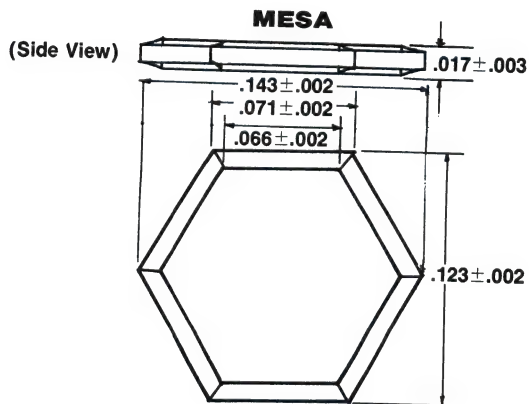
FIGURE 1



(Top View)
FIGURE 2



(Top View)
FIGURE 3



(Top View)
FIGURE 3A

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APPLICATION NOTES

SILICON VOLTAGE REGULATOR DIODES (ZENERS)

INTRODUCTION

The Silicon Voltage Regulator Diode is a two terminal semiconductor, commonly referred to as a "zener diode". It is designed to provide a near constant voltage when operated in the reverse breakdown mode (anode negative). When operated with a forward bias (anode positive) the Regulator Diode behaves similarly to any forward biased rectifier junction.

PARAMETER LETTER SYMBOLS
AND THEIR DEFINITIONS

The Voltage Regulator Diode is defined by a number of static and dynamic parameters. The most important are on the data sheet as shown in the Microsemi catalog. These symbols and definitions have been compiled previously for this catalog. It is suggested that the reader familiarize himself with these definitions before continuing on with the test material.

VOLT-AMPERE CHARACTERISTICS

Figure 1 is a curve illustrating the Volt-Ampere characteristics of the Regulator Diode. The standard circuit symbol is also shown.

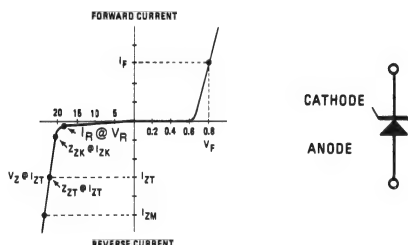


FIGURE 1

The Volt-Ampere characteristics show that the Regulator Diode conducts current in both directions. The reverse breakdown voltage (V_Z) is determined by the manufacturing process, the resistivity of the material used, and the test current. Because of the low dynamic impedance beyond the knee of the curve, the current must be limited by some external means. The steady state DC current is not to exceed I_{ZM} or the device may be destroyed due to internal heating. The forward characteristics, as illustrated in the curve, are similar to those associated with any forward biased silicon junction. There is little change in forward current until V_F exceeds approximately 0.6 volts. As in the case of reverse breakdown or "zener" mode, the forward current must be limited by external

means or the device can be destroyed. The allowable current under forward biased conditions is much greater than under reverse biased conditions. Most data sheets today specify a maximum forward voltage (V_F) at a selected forward current (I_F).

Because the Voltage Regulator Diode's primary function is to provide a constant voltage output, it is important that the dynamic impedance (Z_Z) along the operating portion of the V-I curve be as low as possible. The lower the impedance the less change in zener voltage due to changes in operating current. The dynamic impedance usually is specified at two points on the curve, namely at the manufacturer's specified operating point (Z_{ZT}), and at the "knee" where the device is just starting to regulate (Z_{ZK}). The sharpness of the "knee" is a good indication of the regulation qualities of the device. The dynamic impedance decreases with increasing current up to a point, however good regulation usually can be obtained by operating at any point beyond the "knee".

Ideally there should be no current flow through the regulator until breakdown occurs. However, due to the intrinsic properties of a semiconductor there is a minute current flow prior to breakdown. This reverse leakage current (I_R) is usually specified at 75% to 90% of the nominal zener breakdown voltage (V_Z). I_R will change with temperature and must be considered for high temperature operation. For junction temperature changes of 25°C to +150°C, I_R will increase approximately 100 times.

The Silicon Voltage Regulating Diode is commonly used to clamp or suppress extraneous surge currents within a system. Under surge conditions the Voltage Regulator Diode can withstand currents in excess of the specified steady state maximum current I_{ZM} . The maximum reverse surge current, I_{ZSM} (surge), usually is specified for a pulse duration of 8.3ms (1/2 cycle of 60 Hz). However, due to the increased number of digital applications pulse widths as low as 100μsec are now being specified. These characteristics are further defined under section "Transient Suppression Characteristics."

TEMPERATURE EFFECTS

All semiconductors are susceptible to parameter changes with temperature. Of primary concern with Voltage Regulator Diodes is the change in the reverse breakdown voltage (V_Z). As is commonly known, a forward biased junction exhibits a negative temperature coefficient (TC) between $-1.6\text{mV}/^\circ\text{C}$ and $-2.2\text{mV}/^\circ\text{C}$ depending on the methods and material used in fabrication. The temperature dependency of the Voltage Regulator Diode operated in the reverse breakdown "zener" mode is quite different. Figure 2 is a curve illustrating the change in V_Z with temperature changes.

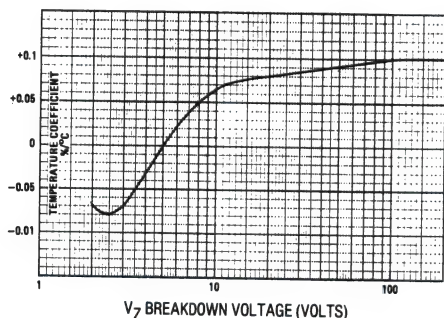


FIGURE 2

Note that for specified breakdown voltages less than 5.1 volts, the TC is negative. For breakdown voltages above approximately 5.1 volts the temperature coefficients become increasingly positive. Beyond 25 or 30 volts the temperature coefficient change is not quite as drastic as at the lower voltages. There is a region of V_Z around 5 to 6 volts where the Voltage Regulator has a theoretical zero TC. The exact voltage where zero TC occurs is greatly dependent on the operating current.

Silicon junctions can withstand junction temperatures in excess of 200°C. Usually the limiting factor for the maximum operating temperature is in the method of construction. Most specifications call for 200°C storage and 175°C maximum operating temperature.

JUNCTION FABRICATION

The initial stage of Voltage Regulator fabrication is commonly referred to as the "crystal growing process". Ultra pure polycrystalline silicon, mixed with a specific amount of impurities is brought to a molten state in an induction furnace. A monocrystalline seed, selected for the desired lattice structure, orientation and impurity concentration, is lowered into a crucible and allowed to come in contact with the molten silicon. As the seed begins to melt it is slowly withdrawn from the crucible. The rate of withdrawal is such that a crystal is grown which exhibits the properties of the seed. The crystal, or ingot as it is sometimes called, is sliced into wafers of approximately 15 mil thickness. The wafers are then lapped and polished to obtain surface uniformity.

The junctions are formed by employing one of two basic techniques while in wafer form — diffused or alloy diffused. The diffused method is accomplished by diffusing N or P type material into P or N type material respectively. Alloy diffused junctions are formed by alloying an aluminum deposition into N type material. The alloy diffused devices exhibit superior breakdown characteristics at the lower voltages (2V-10V). The diffused method is used to manufacture devices with breakdown voltages above 10 volts or so. After diffusion the wafer is metalized and then etched or scribed into individual chips.

Although specific processes vary from one manufacturer to another, basic fabrication techniques are quite similar throughout the industry.

Figure 3 illustrates the chip cross sectional view of the diffused and alloy diffused junctions. Figure 3a shows a simple diffused junction. This method has some serious drawbacks in that the edge of the junction is exposed to contamination by the elements. Figure 3b shows an improved method whereby a silicon dioxide (SiO_2) passivation is used to protect the junction. This method greatly improves the long term performance of the device.

Figures 3c and 3d show the alloy diffused methods. The passivated process has established itself as a reliable method of forming all types of semiconductor junctions.

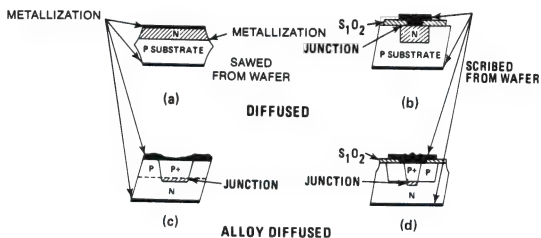


FIGURE 3

CONSTRUCTION METHODS

There are two basic methods for constructing glass diodes. Figure 4a illustrates the use of a "C" bend to make contact with one side of the die. This is used only on stacked die zero TC devices. The opposite side of the die is soldered directly to the die stack first seal post. This method has been used at one time or another by most manufacturers and is still being used by some today.

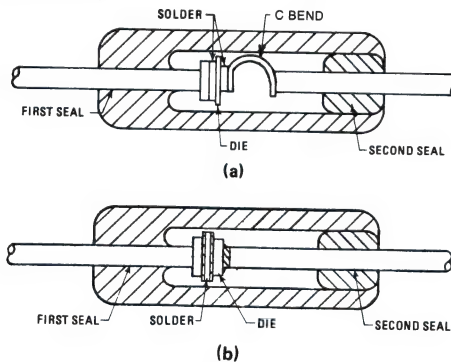


FIGURE 4

The construction as shown in Figure 4b eliminates the "C" bend by using a straight through post. This method has the advantage of simplifying construction techniques and increasing surge and power capabilities and is used on all of our Zener diodes and some TC's.

The epoxy package which utilizes top planar die construction is shown in Figure 5. The leads utilized are of a double nail-head type with a flat to prevent a torque for breaking the solder bond. Each device is conformal coated to protect the die. The double nail-head lead in conjunction with the conformal coating result in a device with excellent moisture resistance.

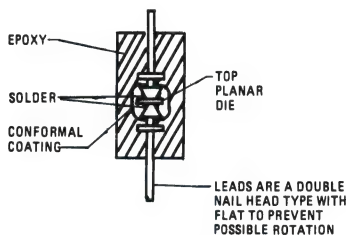


FIGURE 5

Double slug DO-35 diodes are assembled in the manner shown in Figure 6. A diffused and passivated die with an electrolytically deposited silver "bump" for a front contact is sealed between Dumet slugs in a hermetically sealed glass sleeve. A metallurgically bonded version of the DO-35 or DO-41 is also available with an additional high temperature braze pre-form inserted on both sides of the die.

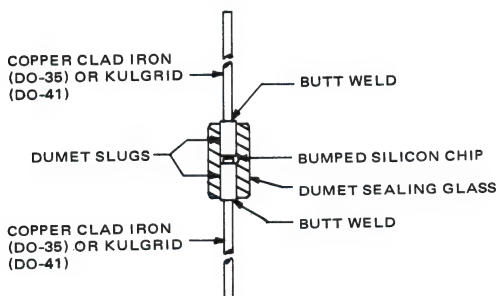


FIGURE 6

THERMAL CHARACTERISTICS

The Silicon Voltage Regulator has inherent thermal properties that must be taken into consideration when operating at elevated temperatures. As mentioned earlier in the text, there is a maximum allowable junction temperature after which reliable operation may be impaired. Figure 7 is a typical power derating curve for a 400mW glass device.

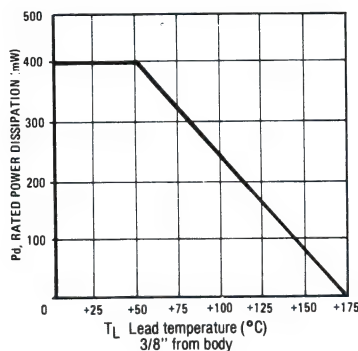


FIGURE 7

Note that the curve decreases linearly to zero power at the maximum specified operating temperature. This curve is only valid under specified conditions, i.e. the leads are clamped to an infinite heat sink 3/8" from the body of the device. An infinite heat sink is defined as a method by which the leads of the device are maintained at the ambient temperature under maximum power conditions. If the lead temperature is allowed to increase above the ambient, the junction temperature also will increase by an equivalent amount. This temperature increase limits the maximum power dissipation. The reciprocal of the power curve's slope approximates the thermal resistance of the device ($R_{\theta JL}$). For the curve in Figure 7 the thermal resistance junction to lead can be calculated to be

$$R_{\theta JL} = \frac{125^{\circ}\text{C}}{400\text{mW}} = 310^{\circ}\text{C/Watt.}$$

For case mounted devices, $R_{\theta JC}$ (thermal resistance junction to case) is given on the data sheet.

In actual applications, an infinite heat sink is not practical such that there is a finite thermal resistance value which exists in series with the device with reference to ambient temperature. For example, printed circuit board mountings for axial leaded devices may easily exceed 30°C/watt which can be significant, particularly for devices which are rated above one watt and exhibit a thermal resistance junction to lead below 100°C/watt . It is therefore important to include these considerations when determining what the junction to ambient thermal resistance is, i.e.

$$R_{\theta JA} = R_{\theta JL} + R_{\theta HS}$$

where $R_{\theta HS}$ is the thermal resistance of the heat sink to ambient provided by the application mounting.

The thermal resistance of the heat sink will dictate the clamp location lead temperature (T_L) rise above ambient illustrated in Fig. 7 by the following relation:

$$T_L = T_A + PR_{\theta HS}$$

where P is the power dissipated by the diode and T_A is the ambient temperature. For case mounted diode, the value of case temperature T_C can be determined by similar means.

TRANSIENT SUPPRESSION CHARACTERISTICS

The relative large p-n junction geometries that are inherently designed into zener diodes provide the silicon voltage regulator with very good transient suppression qualities. The specific extent of energy or power versus time (pulse width) which zener devices can safely absorb is dependent primarily on uniform silicon p-n junction area as well as the internal package heat sinking immediately in contact with this active region.

The transient surge capability of discrete zener diodes is also what inherently classifies zener diodes as being **insensitive** to Electro Static Discharges (ESD) per DOD-HDBK-263, 5.4.2.1.3.

For applications requiring both voltage regulation and transient suppression (including ESD), discrete forms of zener diodes have been used extensively with considerable success. Protection diodes designed into IC chips or as part of MOS chips are generally not suitable for transient protection or prevention

of ESD damage primarily as a consequence of the limited size protection junctions and heat sinking due to cost and performance trade offs of such device designs.

In Figure 8 is a composite illustration of the transient surge capability of the major discrete package configurations of zener diodes provided by Microsemi Corp. This depicts the power capability versus transient square wave pulse width.

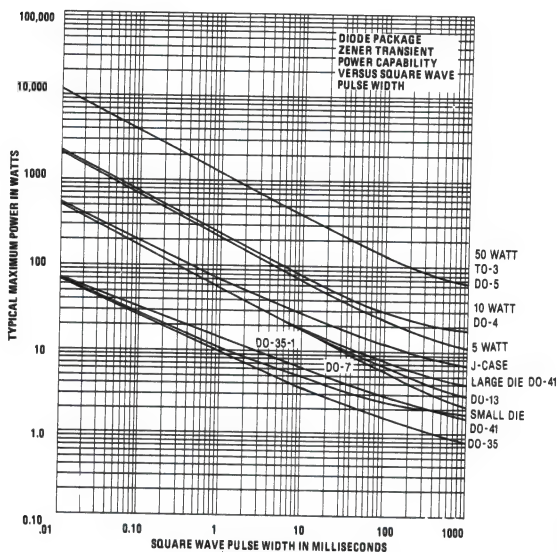


FIGURE 8

USER GUIDE

The Silicon Voltage Regulator Diode can be mounted in any position without affecting operation. However, as mentioned under thermal properties, mounting is important when considering power dissipation.

Regulator Diodes are not often connected in parallel. The only useful application for parallel operation is to clamp the voltage during excessive surge conditions where a single device would not be effective. Usually, the breakdown voltage $V_{(BR)}$ of each device connected in parallel is matched as near as possible otherwise the surge power will not be equally distributed.

Series operation is quite common. In fact, most manufacturers stack die in series of high voltage applications. The breakdown voltage of the stack then becomes the sum of the individual zeners.

There are clipping applications where two regulators are connected in series with their anodes or cathodes common as shown in Figure 9.

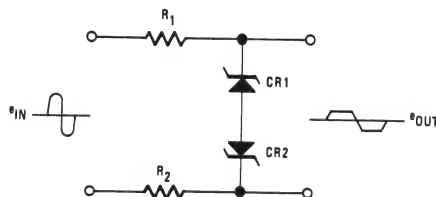


FIGURE 9

In this illustration, when the input signal goes positive CR₁ operates in the normal zener or reverse breakdown mode. CR₂ is forward biased and offers a low impedance, low voltage drop return to the supply. When the signal goes negative the reverse is true, i.e. CR₂ is operated in the reverse breakdown mode and CR₁ is forward biased. The result is the squaring of the input sine wave.

Devices of this type, when manufactured specifically for this application are called "Double Anode" or "Clipper" Diodes. Voltage Regulator Diodes are also used for signal level shifting, threshold or bias control, and limiting.

TEMPERATURE COMPENSATED VOLTAGE REFERENCE DIODES

INTRODUCTION

The Temperature Compensated Voltage Reference Diode is a 2 terminal multi-junction semiconductor commonly referred to as a "TC zener diode". It is designed to provide a constant breakdown voltage with time and temperature. Voltage temperature stability is achieved by matching the equal and opposite temperature coefficients of a Voltage Regulator Diode (zener) and a forward-biased junction.

PARAMETER LETTER SYMBOLS AND THEIR DEFINITIONS

The Temperature Compensated Voltage Reference Diode is defined by a number of static and dynamic parameters which are the same, or similar, to those of a Voltage Regulator Diode.

THEORY OF OPERATION

The TC Voltage Reference Diode (TC zener) is a combination of a Voltage Regulator Diode with one or more rectifying junctions connected in series.¹ The positive temperature coefficient of the Voltage Regulator Diode is equal and opposite to the negative temperature coefficient of the forward-biased junction(s). Figure 1 schematically illustrates how the regulator and forward-biased junction(s) are connected for 2 of the more popular reference voltages.

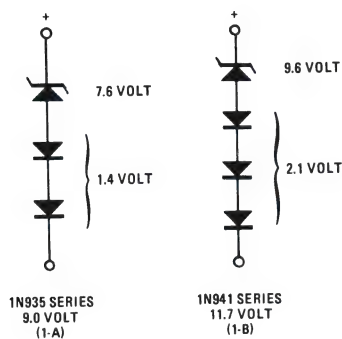


FIGURE 1

The number of forward-biased junctions required per device type is a function of the Voltage Regulator breakdown voltage. As shown in Figure 1, two forward junctions are used for the 9 Volt reference and three forward junctions are used for the 11.7 Volt reference. Multiple "forwards" are required for 9 Volt and 11.7 Volt references because the temperature coefficient of the Voltage Regulator becomes increasingly

NOTE 1:

These compensating junctions are sometimes referred to as stabistors.

positive with breakdown voltage, therefore requires a larger negative coefficient to cancel its effects. Other reference voltages are possible by combining one or more of those shown in Figure 1 or by other combinations of Voltage Regulator Diodes and forward-biased junctions that have compatible coefficients and linearity.

The forward-biased junctions have a voltage drop of approximately 0.7 volts at 7.5 mA and exhibit a negative temperature coefficient between -1.6 and $-2.2\text{mV}/^\circ\text{C}$. The exact coefficient is a function of material and the process used. As mentioned previously, the temperature coefficient of the Voltage Regulator Diode becomes increasingly positive for voltages greater than approximately 5 Volts (see Application Note on Voltage Regulator Diodes). For a 7.8 Volt regulator diode, the temperature coefficient is approximately $+0.05\%/^\circ\text{C}$ or $+4.2\text{mV}/^\circ\text{C}$. By combining this with two forward junctions of $-2.1\text{mV}/^\circ\text{C}$ each, compensation for temperature changes can be achieved. Also, it is important that the temperature coefficients of both the Voltage Regulator Diode and forward biased junctions be as linear as possible so there will be tracking over the complete temperature range. This is not always possible and, consequently, some device types are specified over a limited temperature range.

VOLT-AMPERE CHARACTERISTICS

The volt-ampere characteristics of the temperature compensated reference diodes are similar to the volt-ampere characteristics of Voltage Regulating Diodes (zener) with the exception that they have a very high breakdown voltage in the forward-biased mode. See Figure 2.

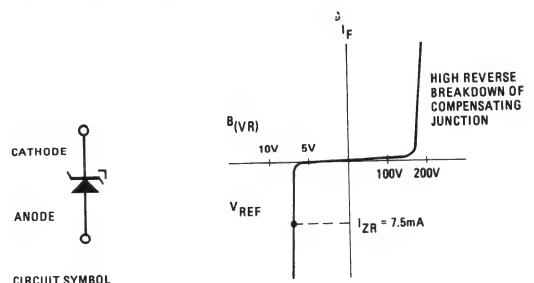


FIGURE 2

This is due to the high reverse breakdown characteristics of the forward compensating junctions. The two parameters that set it apart from a Voltage Regulator Diode are temperature coefficient and time stability. Otherwise, Voltage Reference Diodes can be analyzed as a very low TC Voltage Regulating Diode.

EFFECTS OF VARYING CURRENT

The temperature coefficient of temperature compensated Voltage Reference Diodes is extremely dependent on the operating current. Figure 3 illustrates the effective change in temperature coefficient vs operating current for the device type shown in Figure 1(a).

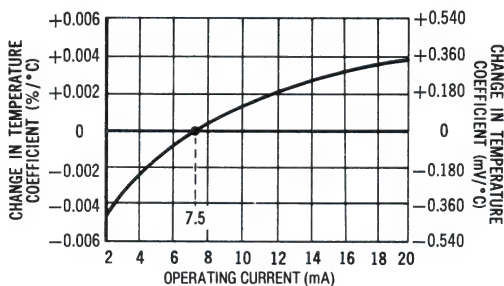


FIGURE 3

It's possible to improve the temperature coefficient of individual devices by slight adjustments of operating current. For example: If the device has an initial positive coefficient at the specified test current; reducing the current slightly will have the effect of making the temperature coefficient less positive.

METHODS OF DEFINING TEMPERATURE COEFFICIENT

Early registrations of Temperature Compensated Voltage Reference diodes defined the temperature coefficient in $\%/^{\circ}\text{C}$ i.e., a maximum % change in reference (or breakdown) voltage with each degree change in ambient temperature. Common values specified are $\pm 0.01\%/^{\circ}\text{C}$, $\pm 0.005\%/^{\circ}\text{C}$, $\pm 0.002\%/^{\circ}\text{C}$, $\pm 0.001\%/^{\circ}\text{C}$, $\pm 0.0005\%/^{\circ}\text{C}$ and $\pm 0.0002\%/^{\circ}\text{C}$. These values also are specified in PPM/ $^{\circ}\text{C}$. For example: A $0.001\%/^{\circ}\text{C}$ device can be identified as a 10 PPM/ $^{\circ}\text{C}$ or $10\mu\text{V}/^{\circ}\text{C}$. This method implies that the TC characteristics are linear and predictable over the temperature extremes. In reality, the combined coefficients of the Voltage Regulator and forward junctions are not always linear, especially for the low values of TC.

This led to the "Hour-glass" measurement technique as illustrated in Figure 4 whereby, while not guaranteeing a linear relationship, it was hoped the TC characteristics would stay within the confines of the shaded area. This approach had the disadvantage in that it required a large number of test points to guarantee operation within the "Hour-glass".

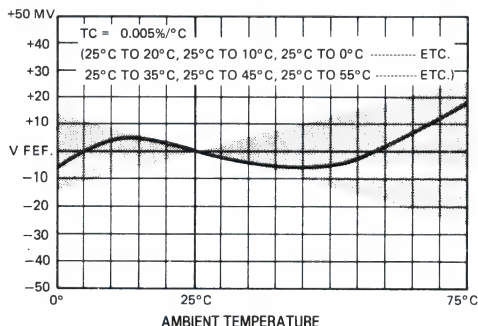


FIGURE 4

A later, and more widely accepted concept was the so-called "Box Method" where a max. mV change over the temperature extremes is specified. See Figure 5.

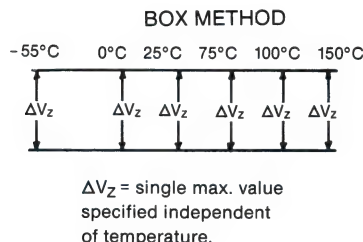


FIGURE 5

This method of defining temperature coefficient is more practical from both the manufacturer's and Design Engineer's point of view. The manufacturer does not have to concern himself so much with linearity so long as he does not exceed the maximum mV deviation between the temperature extremes. The Design Engineer finds this more useful because he does not have to go through computations to find out what his worst case reference change will be. Both the Military and JEDEC format now require that the device be specified by the "Box Method" with a minimum of 5 test points.

Some manufacturers, rather than perform 5 tests at different temperatures, continuously monitor ΔV_Z as the device is subjected to the two temperature extremes. This is still basically a Box Method with the advantage of increased productivity and an infinite number of test points.

TIME STABILITY

Specifying a device with a low TC does not necessarily imply that the reference voltage will remain stable over long periods of time. To control this parameter, manufacturers have established a test procedure and screening process whereby TC devices can be specified with guaranteed stability for 1,000 or more hours of operating life. These Ultra Stable Temperature Compensated Voltage Reference Diodes, as they are sometimes referred to, are manufactured with guaranteed stability as low as 5 PPM/1,000 hours. This guarantee is only valid if the device is operated at a specific temperature and current per the manufacturer's data sheet. Figure 6 is a typical plot of time stability.

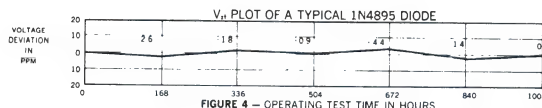


FIGURE 6

JUNCTION FABRICATION

Since the TC Voltage Reference Diode is basically a Voltage Regulator Diode, with forward-biased junctions connected in series, the methods of fabrication are the same, and are covered in the section on "Voltage Regulator Diodes". There is one possible exception, however. The 6.2 Volt references utilize a single chip construction i.e., the Voltage Regulator junction and the forward-biased compensating junction are diffused on a single chip in a single process. Figure 7 illustrates this fabrication technique. This technique also has the advantage of a simplified manufacturing process by elimination of a solder process. NOTE: The regions where the junctions reach the surface (A and B) are fully protected (passivated) from the environment by an oxide layer.

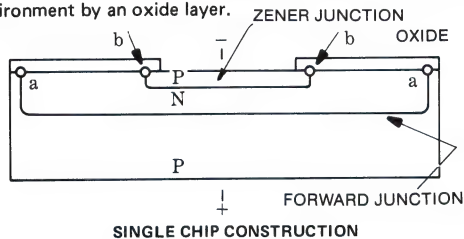


FIGURE 7

CONSTRUCTION METHODS

Voltage Reference Diodes are packaged in glass and epoxy with the 400 mW glass being, by far, the most popular. Figure 8 illustrates typical construction techniques for these type devices.

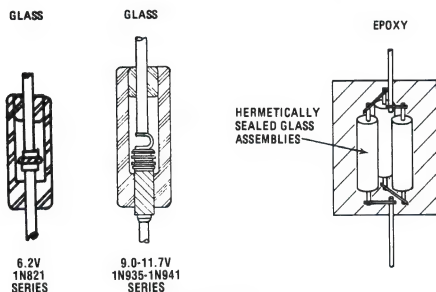


FIGURE 8

USER GUIDE

MOUNTING CONSIDERATIONS

The temperature compensated Voltage Reference Diodes can be mounted in any position without adversely affecting operation.

THERMAL CONSIDERATIONS

The Voltage Reference Diode is designed to operate at the maximum specified operating temperature without derating, providing the test current is as specified. Actually, there is no need for a derating curve because normal operation will insure that the max. junction temperature will not be exceeded. However, for Ultra Stable applications, mounting techniques can affect the absolute value of the reference. The difference between an infinite heat sink and no sink at all could cause a 15°C difference in junction temperature and, therefore, a change in reference voltage depending on the TC of the device. When correlation of readings is required, the method of measurement has to be completely defined.

ELECTRICAL CONSIDERATIONS

There are no useful applications for operating reference devices in parallel, however, series operation is quite common. When operating in series, the user should select device types that have a common test current. Otherwise, the junction operating temperature may be adversely affected. Also, rated parameters at I_{ZT} may be substantially changed.

Reference devices require that the operating current be maintained at a high degree of accuracy to ensure performance as published by the manufacturer. Figure 9 is a schematic representation of two circuits that can provide a constant current. Figure 9a requires an extremely stable power supply to maintain I_{ZT} at its proper current. While the circuit, as shown in Figure 9b, can provide a constant current independent of power supply variations.

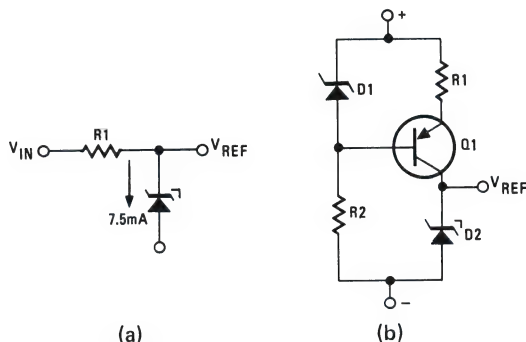


FIGURE 9

APPLICATIONS

Many of the Electronic Systems today require a voltage reference to insure system accuracy. Stability with time and temperature is only as good as the reference selected, therefore careful consideration must be given to the design and choice of reference. The Standard Cell, due to its size, fragility, and susceptibility to environments is not suitable for most applications. Consequently, the Silicon Temperature Compensated Voltage Reference Diode (TC Zener) has found acceptance as a small, reliable, and rugged replacement for Standard Cell applications.

Shown below are a few illustrations where a Reference Diode is used as a stable reference for critical circuit applications. For most optimum performance, a minimal current should be drawn from the device.

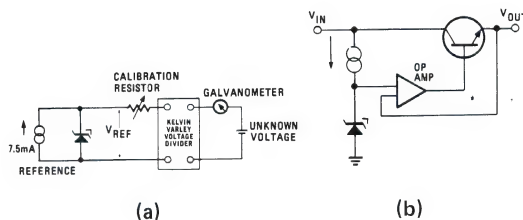


FIGURE 10

PROCESS NORM SCREENING

WHY ARE MICROSEMI DIODES BETTER?

Over the past ten years, Microsemi has been noted for high quality zener diodes. As the semiconductor state-of-art advanced, Microsemi has expanded its technology to offer the highest quality, most reliable, yet reasonably priced zener diodes on the market. This is accomplished by the following methods:

I. DIE

- A. Thermal oxide passivated planar junctions are utilized for sharper breakdown and longer life.
- B. The largest junctions possible were designed for lower operating temperatures and high surge capabilities.
- C. VZ, ZZT, ZZK, and IR are 100% tested on all die. (except DO-35)

II. PACKAGES & ASSEMBLY

- A. All the device packages are designed for the lowest thermal properties and the highest structural stability.

III. TESTING

- A. All devices are 100% tested for VZ, ZZT, ZZK, IR and VF regardless of individual specifications.

- B. All devices are tested to MICROSEMI PROCESS NORM SCREENING.

Microsemi has incorporated many device preconditioning and test methods to insure that the quality of our devices is far superior to the industry standard.

| GLASS PACKAGES (DO-7, DO-35, DO-13 and DO-41) | METAL PACKAGES (DO-4, DO-5 and TO-3) | EPOXY PACKAGES (Case J and T-18) |
|--|--|--|
| <ol style="list-style-type: none"> 1. 48 hours storage at 200°C after final seal. 2. Temperature cycling - 50°C to +150°C, 5 cycles minimum. 3. All electrical parameters tested (VZ, ZZT, ZZK, IR and VF) regardless of individual specifications. 4. Process norm IR. 5. Process norm VF. | <ol style="list-style-type: none"> 1. 48 hours storage at 200°C following final weld. 2. Temperature cycling - 50°C to +150°C, 5 cycles minimum. 3. All electrical parameters tested (VZ, ZZT, ZZK, IR and VF). 4. Power square wave surge (TO-3, DO-5: 100ms; DO-4: 50ms). 5. Thermal response test. 6. Process norm IR. 7. Process norm VF. | <ol style="list-style-type: none"> 1. 30 minute storage at 150°C following encapsulation. 2. Temperature cycling - 50°C to +150°C, 5 cycles minimum. 3. All electrical parameters tested (VZ, ZZT, ZZK, IR and VF) regardless of individual specifications. 4. Process norm IR. 5. Process norm VF. |

CHART 1

PROCESS NORM SCREENING

100% PRECONDITIONING AND TESTS BY PACKAGE TYPE FOR ALL VOLTAGE REGULATOR DIODES.

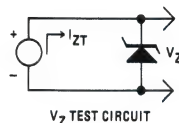
Probably the most important characteristic of a semiconductor device to your customer is its infant mortality rate. This is a term used to describe the devices that fail within the first few hours of operation. Although this is most important, it is very difficult to identify infant mortalities by conventional test methods. One method of eliminating these failures that is expensive but relatively common is to subject a production

lot to environmental and life testing. In an attempt to give the customer a more reliable part without prohibitive costs, Microsemi has devised sophisticated screening procedures to insure a high quality level in our **commercial product**. A summary by package type of these procedures is shown in Chart I.

VOLTAGE REGULATOR and VOLTAGE REFERENCE LETTER SYMBOLS and DEFINITIONS

V_Z Breakdown voltage when the regulator is biased in the reverse direction.

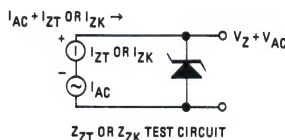
I_{ZT} Test current applied to define V_Z .



Z_{ZT} Voltage regulator impedance with I_{ZT} applied. See Note 3 on the 1N5333B data sheet for complete test conditions.

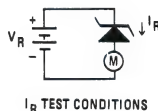
Z_{ZK} Voltage regulator impedance at a test current (I_{ZK}). This defines the "Knee" of the curve or that point where the regulator has just started in the breakdown mode.

I_{ZK} The test current used to define Z_{ZK} . See Note 3 on the 1N5333B data sheet for complete test conditions.



I_R Reverse leakage current. The amount of current flow when a voltage is applied (V_R) such that the diode is biased at some voltage less than that which causes breakdown.

V_R The voltage applied to measure leakage current.

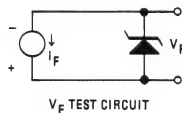


I_{ZM} Maximum current that can be applied to the regulator to maintain operation within its specified power rating. See Note 5 on the 1N5333B data sheet for complete test conditions.

I_{ZSM} Maximum surge current that the devices can withstand for a specified period of time. See Note 6 on the 1N5333B data sheet for complete test conditions. (This is specified as I_{PP} for transient suppressors.)

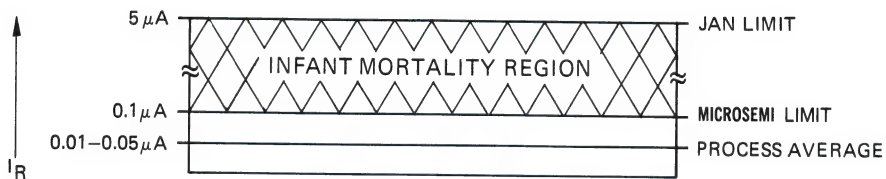
V_F Forward voltage drop of the regulator when biased in the forward direction.

I_F Forward current used to define V_F .

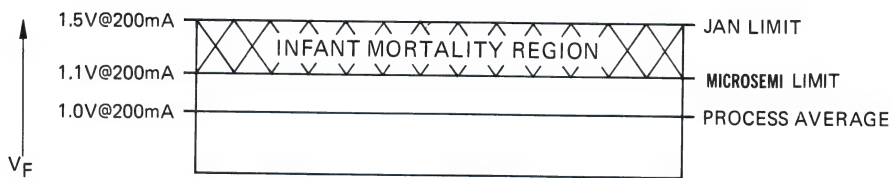


α_{VZ} Temperature coefficient of the breakdown voltage V_Z . The maximum change in V_Z expressed as a percent per degree centigrade change in temperature. This is a method of defining the TC of a Voltage Regulator. For convenience, $\pm mV/^{\circ}C$ is sometimes used. It is not the preferred method of reference voltage TC measurement.

$\Delta V_Z(\text{temp.})$ Voltage temperature stability. This is the change in breakdown voltage (V_Z) for a given set of conditions. This is the MIL and JEDEC preferred definition of Voltage Reference temperature coefficients.



PROCESS NORM I_R LIMITS



PROCESS NORM V_F LIMITS

CHART II
PROCESS NORM LIMITS
EXAMPLE: JAN1N962B SERIES

OUR PROCEDURES ARE AS FOLLOWS:

1. NORM LIMIT TESTING:

Due to Microsemi die processing methods, many of our critical measurement parameters are orders of magnitude tighter than standard JAN or JEDEC requirements. These tighter parameters are utilized to provide a very effective reliability screen. In lieu of the JEDEC or JAN limits, Microsemi utilizes tighter limits that conform to their product norms. An example of this is the IR limit for the JAN1N962B series. The JAN limit is $5\mu\text{A}$ and Microsemi in-house limit is $0.1\mu\text{A}$. It has been found through extensive evaluation that devices with a leakage exceeding $0.1\mu\text{A}$ but less than $5\mu\text{A}$, exhibit a very high failure rate. Chart II depicts norm I_R , norm V_F , and norm transient thermal response limits.

2. SURGE STRESSES:

All our devices are then subjected to a high current surge pulse which is used to detect devices with junction abnormalities (except DO-35).

3. PARAMETERS TESTED FOR:

V_Z , Z_{ZT} , Z_{ZK} , I_R and V_F are all tested on all devices although individual test requirements may not specify all these parameters.

To insure junction cleanliness, Microsemi subjects all devices to an elevated temperature IR with a norm limit (except DO-35).

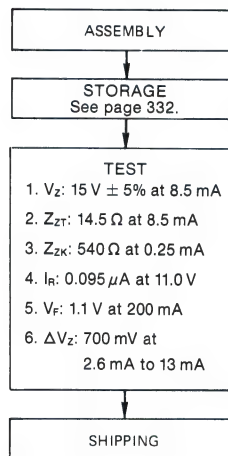
4. NORM LIMIT V_F :

To detect solder and/or die plating deficiencies, we subject all devices to a norm limit V_F test.

5. THERMAL RESPONSE (Thermal impedance per defined unit of time): (DO-7 & DO-13 only)

To assure high quality, high power Microsemi zeners are subjected to thermal response (or thermal impedance) testing on a 100% basis. Thermal response is similar to thermal resistance (0J) in that you measure a junction temperature rise for a predetermined power dissipation. The main difference with thermal response is that you use a very high power pulse for a short time duration (50-100 msec). This increases the sensitivity to solder voids and potential intermittent devices over that of standard thermal resistance tests. This is accomplished by confining the heat dissipation to the die/solder area and disregarding the package thermal properties.

MICROSEMI METHODS



TYPICAL TEST

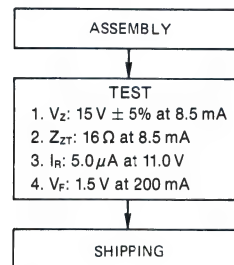


CHART III

COMPARISON OF **MICROSEMI** TEST METHODS TO THOSE OF OTHER MANUFACTURERS FOR A 1N965B UTILIZING STRAIGHT-THRU CONSTRUCTION (DO-7).

Chart III compares test methods with typical methods used by other manufacturers. By employing unique test methods such as these, Microsemi is able to supply commercial products with failure rates well below 1%/1000 hours. Thus, in nearly all instances, potential infant mortality devices are removed before product is shipped.

**WHAT ARE
JAN COMPONENTS?**

JAN components are standard "1N" type devices, MIL qualified and subjected to environmental and life sample tests to assure quality conformance. The JAN devices are 100% tested, lot traceable, and are subjected to other tests as described in the comparison chart. JAN devices are the most economical of the Hi-Rel devices and are often used in commercial applications requiring better potential life cycle performance than can be guaranteed with standard "1N" components.

**WHAT ARE TX AND
TXV COMPONENTS?**

JANTX and JANTXV semiconductors are JAN devices subjected to extra testing as outlined in MIL-S-19500. These screening procedures are designed to eliminate the possibility of infant failures that might occur in the early stages of component system use. The devices are subjected to environmental as well as electrical test.

To assure continuous quality and reliability, PDA (percent defects allowable) requirements are applied to every lot. This effectively restricts the probability of shipping defective lots which are not characteristic of the TX product. The selection of TX and TXV components assures (1) maximum component reliability and (2) standardized reliability testing procedures.

1. Reliability

The Department of Defense has had extremely favorable reliability with electronic systems which have incorporated TX and TXV requirements. These complicated systems include ICBM's, anti missile missiles, and other advanced military defense systems.

2. Standardization

Military specifications, incorporating TX and TXV requirements, cover large families of devices and provide a broad range of specific device types capable of fulfilling the majority of electrical requirements. Quite often special device types can be selected from this group and still meet the basic military specifications by belonging to the generic MIL-spec family.

**WHAT ARE
DO35-1 COMPONENTS?**

The DO35-1 devices represent one of the newest military approved product lines within the zener diode industry. Microsemi has had QPL approval to supply these devices since June 1, 1979.

Basically, the -1 signifies a metallurgically bonded device which provides a substantial reduction of thermal impedance and eliminates any possibility of poor contact due to thermal excursions during subsequent application.

Microsemi approval of the DO35-1 device consists of JAN, JANTX, JANTXV, and JANS.

**WHAT ARE
JAN S COMPONENTS?**

JAN S components meet industry requirements for "Space Reliability Parts". JAN S is the highest reliability level in military specifications and requires additional testing above the levels of JANTX and JANTXV. NASA standard parts are now covered by JAN S military parts.

Microsemi is the first manufacturer to qualify its diodes to JAN S and has a large selection of types under qualification. All JAN S diodes meet these requirements:

- All parts are traceable from starting wafer to shipped product.
- Serialization of individual parts are identified within lots.
- Critical process steps are baselined and change controlled.
- Production and Q.C. operators are qualified and certified.
- Radiographic examination is performed on each device by a certified X-ray facility.
- Lot conformance testing is performed on each device lot.
- All diodes have an additional 144 hours of burn-in beyond the 96 hours required for JANTX and JANTXV.
- Failure analysis is performed on all catastrophic screening failures.
- Construction of all parts is accomplished on certified lines under exacting GSI surveillance from the start of wafer processing through shipment.

**ADVANTAGES OF MICROSEMI
HIGH-REL. COMPONENTS**

Why should you choose Microsemi Hi-Rel diodes? Just look at these facts and the answer will be clear.

■ Proven Reliability

Microsemi diodes are capable of "witnessing" failure* rates as low as 0.067 parts per million hours. Microsemi's Hi-Rel diodes have proven their reliability in virtually every major military contract from the F-4 fighter to the Intelsat Satellite.

**Definition: units which deviate from the initial parameter limits, with the exception of reverse leakage, which normally is allowed to double.*

■ Broad Qualification

Microsemi offers the broadest selection of zener and temperature compensated diodes in the industry, from 1.8 volts to 200 volts, from 250 mw to 50 watts and from metallurgically bonded DO-35 package to TO-3 package. No matter what the numbers, Microsemi has the combination.

■ Weldable leads

Microsemi Hi-Rel diodes (TX and TXV) have leads which are compatible with the majority of weld and solder requirements.

■ Separate packaging and shipping area

As with the Hi-Rel testing area, the packaging and shipping area is segregated from our normal commercial product areas to specially handle virtually any packaging requirement.

■ Constant QC monitor

Specially trained QC personnel are assigned to the Hi-Rel area to constantly monitor processes from Hi-Rel entry to final data preparation and shipment from a common area.

■ Stock availability

Our continuous qualifications and testing procedures allow Microsemi to carry a large factory inventory of JAN and JANTXV devices from the common 400 mw version to the more sophisticated high voltage T.C. devices.

■ Continuous Engineering for Quality

To meet the current and future demands of the industry and production processes, Microsemi has established Engineering departments to improve semiconductor manufacturing.

A. Sustaining Engineering works in the production phase of manufacturing to improve device capabilities of product which is currently being produced.

B. Development Engineering is continually developing new products which can be added to our current product lines enabling Microsemi to meet the product demands of our customers.

HIGH RELIABILITY SCREENING SEQUENCE

Microscopic Inspection — 100% microscopic inspection is performed on all TXV devices.

Serialization — As required, a serial number is used to provide traceability throughout the entire screening process.

Traceability — Traceability is maintained per the applicable specification and MIL-S-19500.

100% Electrical Test — Complete electrical test per applicable specification.

High Temperature Storage (Non-operating). Devices are stored in high temperatures ranging from 150°C to 200°C to screen out failures.

Temperature Cycling — Devices are cycled for temperatures ranging from -65°C to +175°C to weed out structural weakness, i.e. solder joints, welds, glass to metal seals and molecular lattice structure.

100% Electrical Tests — Devices are subjected to electrical tests to the critical functional parameters and delta calculations determined.

Shock — When specified devices are subjected to a mechanical shock test.

Acceleration — When specified devices are subjected to centrifuge.

100% Electrical Test — Devices are subjected to electrical test to the critical parameters and delta calculations determined.

Forward Instability Shock Test — When specified devices receive a monitored shock test in the forward direction.

Backward Instability Vibration — When specified devices are subjected to a monitored vibration test in the reverse direction.

Seal Leak (Fine) — Devices are tested with a helium mass spectrometer to locate any leaks down to 1×10^{-6} CC's per second leak rate.

Seal Leak (Gross). — Devices are checked for leaks too large for detection by tracer gases.

Powerage (Burn-in) — Devices are subjected to up to 240 hours of burn-in to the conditions in the applicable specification.

100% Electrical Test — Devices are subjected to all parameters of the applicable specification and delta calculations are determined and those devices not meeting the requirements are rejected.

HIGH-RELIABILITY COMPARISON CHART

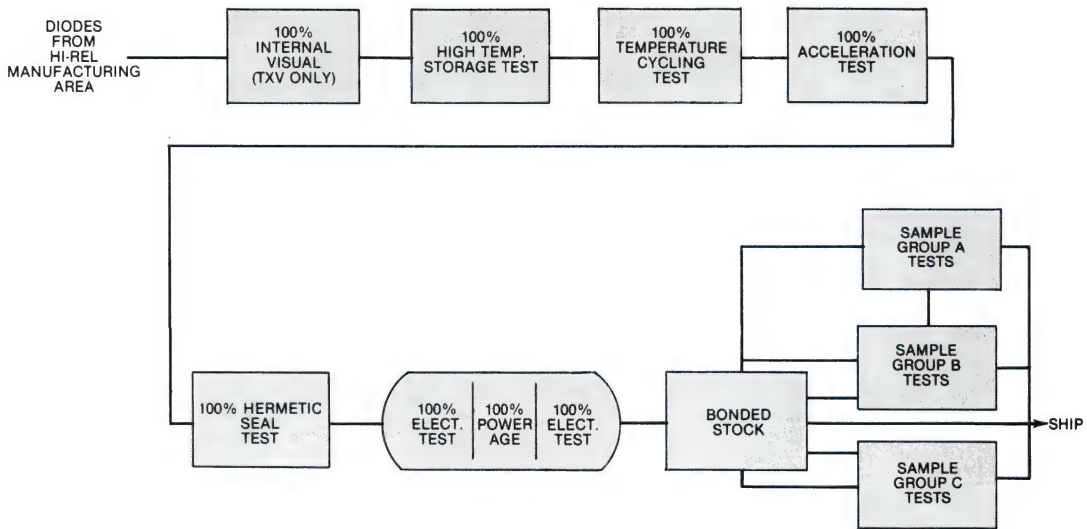
| | JAN | TX | TXV | S |
|---|---------|---------|---------|-----|
| Microscopic Inspection (Internal Visual) | No | No | Yes | Yes |
| Serialization | No | No | No | Yes |
| Traceability (Diffusion) | Yes (1) | Yes (1) | Yes (1) | Yes |
| Traceability (Lot) | Yes (1) | Yes (1) | Yes (1) | Yes |
| 100% Electrical Test | Yes | Yes | Yes | Yes |
| High Temp. Storage (Non-Operating) | Yes | Yes | Yes | Yes |
| Temperature Cycling | No | Yes | Yes | Yes |
| Electrical Test (#1 with Drift Screen Limits) | No | No | No | Yes |
| Monitored Shock | No | No | No | Yes |
| Monitored Vibration | No | No | No | Yes |
| Centrifuge | No | Yes (2) | Yes (2) | Yes |
| Seal Leak (Fine) | No | Yes | Yes | Yes |
| Seal Leak (Gross) | No | Yes | Yes | Yes |
| Electrical Test (#2 with Drift Screen Limits) | No | Yes | Yes | Yes |
| Power Age (Burn-In) | No | Yes | Yes | Yes |
| Electrical Test (#3 with Drift Screen Limits) | No | Yes | Yes | Yes |
| X-Ray | No | No | No | Yes |
| Microscopic (External Visual) | No | No | No | Yes |
| Group A Inspection per MIL-S-19500 | Yes | Yes | Yes | Yes |
| Group B Inspection per MIL-S-19500 | Yes | Yes | Yes | Yes |
| Group C Inspection per MIL-S-19500 | Yes | Yes | Yes | Yes |
| PDA (Max, Pct. Def. Allow. thru Screening) | No | Yes | Yes | Yes |

1. Within lot accumulation rules established in MIL-S-19500.

2. When Required by MIL-S-19500.

Any combination of the above tests and many additional tests will be performed if the customer requires further reliability testing. These would require special Purchase Order requirements which are particularly well handled at Microsemi.

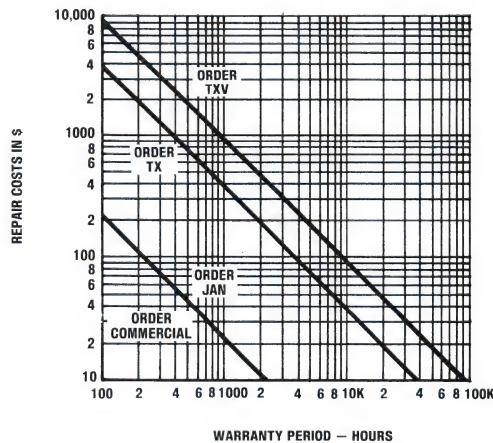
Testing-Sequence



The chart below is designed to help you select the level of reliability that you need. It compares cost of equipment and repair costs during warranty and is offered only as a rule of thumb. Obviously, other factors such as your image in your marketplace, and initial equipment costs, must also be factored

into your component buying decision.

Once you decide on a reliability level for your components then you must select a vendor. Like you, our quality stems from our people and from the materials we use in production.



SELECTING TRANSIENT VOLTAGE SUPPRESSORS

APPLICATION NOTES

5

System voltage and current transients are a major cause of component failure in semiconductors.

These transients may be by either internal system disturbances, such as the normal switching operations of power supplies and electro mechanical devices or from external system disturbances such as electrostatic discharges.

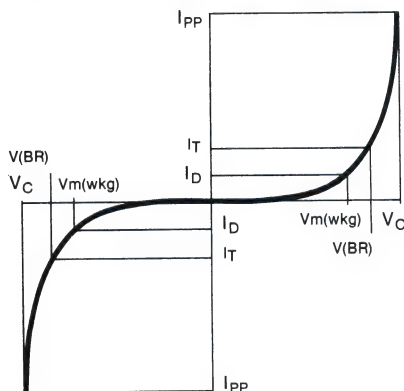
Microsemi Corp's series of transient suppressors provide significant protection against these high voltage spikes and due to their subminiature size can be installed directly onto the p.c. board offering maximum protection to sensitive components.

The following information is offered as a guide for choosing the correct device for your applications:

Certain parameters form the basis for selection: (See Figure 1)

Figure 1

TYPICAL CHARACTERISTIC CURVE FOR BI-DIRECTIONAL TRANSIENT SUPPRESSOR SHOWING ALL THE SIGNIFICANT PARAMETERS.

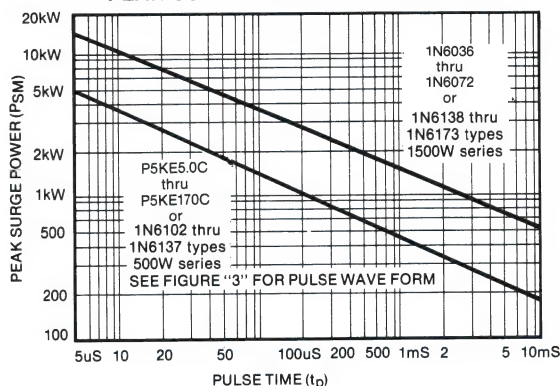


1. Breakdown Voltage $[V(BR)]$ is the nominal zener breakdown voltage, suffix A 5% tolerance, no suffix 10% tolerance.
2. Test current (I_T) is the zener current at which nominal breakdown voltage is measured.
3. Maximum Leakage Current (I_D) is the current leakage measured at the max D.C. working voltage (V_{WM}).
4. Working Peak Voltage (V_{WM}) is the maximum permissible D.C. working voltage.
5. Maximum Peak Surge Voltage (V_C) is the maximum clamping voltage at I_{PP} .

6. Maximum Peak Pulse Current (I_{PP}) is the maximum permissible surge current for waveform of Figure 3. The product of V_C and I_{PP} give the power rating for the device, e.g. for 1N6138A, $I_{PP} \times V_C$ is $142.8 \times 10.5 = 1500$ Watts.

Using the above parameters, first choose which series of suppressors will handle the surge from Figure 2, Peak Surge Power vs. Pulse Time. Examples given in this figure are for bidirectional TAZ; however, unidirectional are also available.

**FIGURE 2
PEAK SURGE POWER VS PULSE TIME**

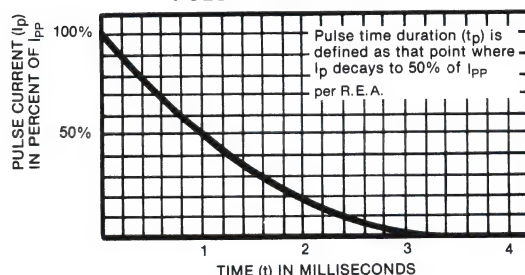


Then from the appropriate data page, determine the device with the standoff voltage equal to or greater than the normal circuit operating voltage. Making sure the clamping voltage from V_C is below the voltage that could cause damage to any component in your circuit.

Should the clamping voltage not be low enough for your application please contact the factory for other specialized devices available.

These devices are also available in encapsulated assemblies of parallel and/or series combinations to provide higher current or higher power capabilities. Please contact the factory for further information.

**FIGURE 3
PULSE WAVE FORM**



TAZ

APPLICATION NOTES

6

TAZ GENERAL DESCRIPTION

TAZ are PN silicon transient voltage suppressors characterized by exceptional surge handling capabilities, extremely fast response time (1 picosecond) and low series resistance. TAZ are designed, manufactured, specified and tested for transient suppression.

TAZ are available in a number of axial leaded package configurations:

- Metal DO-13 package.
- Hard Glass Axial Lead
- Plastic economical commercial package.
- Multiple device assemblies.
- Modules for special applications.
- High reliability and commercial applications.

TAZ are also available in chip form for hybrid applications in ratings from 500 watts to 1500 watts peak pulse power.

Standard geometrics of .060 inches square for up to 600 watts; .142 inch hexagonal for 1500 watt devices. Both .013 inches max thickness.

Standard metallization is chrome/silver/gold.

Aluminum/gold is also available.

Typical general applications for TAZ include protection from:

- Induced lightning effects on transmission lines.
- Inductive and switching transients.
- Protection of IC's and other voltage sensitive circuits.
- EMP suppression.

Microsemi specializes in custom design of devices for special applications.

TRANSIENTS

A voltage transient is generated by a sudden release of stored energy causing an unpredictable change in voltage. This energy can be stored and released from within the circuit by means of inductive switching or arcing, or can be induced from outside the circuit by uncontrollable sources such as switching transients on an AC power line or lightning induced transients.

Transient over-voltages are a major problem in semiconductor circuits. If not suitably protected, discrete components and integrated circuits can be destroyed or damaged by high energy voltage transients.

TAZ

TAZ (Transient Absorption Zeners) offer a low cost and effective solution to this problem. TAZ are bi-axial leaded devices composed of large area, silicon P-N junctions.

TAZ are capable of absorbing the energy present within the transient, thereby maintaining circuit conditions and protecting voltage sensitive components.

Since integrated circuits are becoming smaller and more complex, it has become increasingly more important that transient suppression be implemented in the early design stages. The design of the circuit protection will help prevent costly field failures and future installation or retrofitting.

The major electrical characteristics of TAZ are:

1. Fast response time — theoretically 1×10^{-12} seconds.
2. Wide voltage range: 5.0V-400V available in axial leaded devices. (Higher voltages available in modular devices.)
3. High transient power dissipation:
 - Up to 5000 watts in axial leaded devices.
 - Up to 60,000 watts or more available in modular packages.
4. Available in high reliability metal cases, glass and cost effective plastic.

MODULAR ASSEMBLIES

For applications where an axial leaded TAZ cannot handle the amount of transient energy detected, Microsemi offers custom modules utilizing other component combinations to meet individual requirements. Microsemi offers a complete line of standard commercial and military grade modular assemblies such as the 60KS200C, 704-15K36/704-15K36T, and the PIP/PHP series. For more information or special requirements, consult the factory.

TAZ CHIPS FOR HYBRID APPLICATIONS

TAZ are also offered in chip form for hybrid applications. TAZ chips are available in various geometry and metallizations. Please consult the factory for further information.

TAZ TERMS, DEFINITIONS AND SYMBOLS

This section provides the reader an overview of terminology and its definition as it relates to the device parameters shown on the data sheets and JEDEC Standard No. 77.

| SYMBOL | TERM | DEFINITION |
|--------------|--|--|
| V_{WM} | Rated working peak voltage also (rated stand-off voltage). | The peak voltage excluding all transient voltages. |
| I_D | Standby current. | The DC current through a surge suppressor at rated standoff voltage V_{WM} . |
| I_S | Surge peak transient current. | The peak current for a single pulse. |
| $V_{(BR)}$ | Breakdown voltage. | The value of voltage at which breakdown occurs. |
| V_C | Clamping voltage. | The voltage in a region of low differential resistance that serves to limit the voltage across the device terminals. |
| I_{PP} | Peak impulse current. | The peak current for a series of essentially identical pulses. |
| I_{PPM} | Rated peak impulse current. | |
| V_W | Working peak voltage. Note: This term is also called "standoff voltage." | The peak voltage excluding all transient voltages. |
| I_{SM} | Rated surge peak transient current. | |
| P_{PP} | Repetitive peak pulse power dissipation. | The peak power dissipation resulting from the peak impulse current I_{PP} . |
| P_{PPM} | Rated repetitive peak pulse power dissipation. | |
| CF | Clamping factor. | The ratio of clamping voltage to breakdown voltage. |
| V_C/V_{WM} | Voltage clamping ratio. | The ratio of clamping voltage to rated working peak voltage. |

HOW TO SELECT TAZ

In selecting the right TAZ for an application, there are four key parameters to consider:

1. V_{WM} Rated working peak voltage or reverse stand-off voltage.
 2. P_{PPM} Rated peak pulse power dissipation.
 3. I_{PPM} Rated peak pulse current.
 4. V_C Clamping voltage.
1. V_{WM} Select a TAZ with a V_{WM} equal to or greater than the peak operating voltage at the point of protection. It is important that the voltage does not exceed this parameter in normal operating conditions or the device could go into the avalanche or breakdown mode which may disrupt normal operations or dissipate power needlessly across the TAZ.
 2. P_{PPM} To select TAZ for the correct peak pulse power capability, one must first define the transient conditions. This can be determined by the placement or location of the device within the system.

There are basically three categories or levels of protection. These are primary, secondary and board level.

The primary level of protection is the most severe transient environment. This level usually has a very low source impedance as well as a low series resistance; e.g., transmission lines which are exposed to the highest degree of voltage transients such as power switching or lightning strikes. Due to the intensity and magnitude of these transients, a single TAZ may not provide adequate protection. For applications of this nature, Microsemi offers a series of custom modules to fit individual needs. For more information, consult the factory.

The secondary protection level would normally be preceded by a transformer or a circuit with a given series resistance and inductance. Higher source impedance can result in a higher voltage transient, but may not contain the energy level generated on low impedance

Board level protection has higher impedance and may result in higher voltage spikes, but usually is lower in transient energy due to the greater current limiting factor. Applications at this level will generally require a lower power TAZ such as a 500 watt (P5KE) or 600 watt (P6KE). Since there are no set industry standards on source impedance at various levels, it is suggested that discretion be used when selecting for a specific application.

In order to select for the peak pulse current capability of a TAZ, the transient voltage and circuit impedance must be determined. The peak current can be calculated by dividing the peak transient voltage by the series impedance. A TAZ is then selected with a greater I_{PP} than that expected in a transient condition.

In selecting TAZ it is important that the clamping voltage rating does not exceed the instantaneous voltage level acceptable to maintain safe operating conditions for the components being protected. Board level applications are usually more sensitive in this respect than primary or secondary applications. The clamping is the maximum allowable voltage at the output of the device when subjected to its peak pulse current.

This parameter is determined using a specified pulse waveform. The waveform most widely recognized is a 10 x 1000 mS impulse Figure 1.

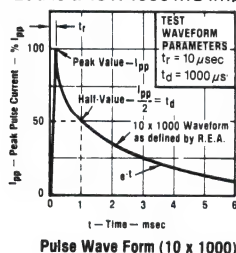


FIGURE 1

Other waveforms are used for some devices geared for specific applications or environments such as the LDTs series for load dump. Here a 50 mS pulse is used to simulate the conditions found in an automotive application.

Although the 10 x 1000 mS waveform is used as a reference for the majority of TAZ available, they can also be upgraded for higher transient levels for shorter duration pulses. Also different transient waveforms may be used as shown in Figure 2 as exemplified for the TAZ devices rated for 1500 watts peak pulse power for the waveform in Figure 1.

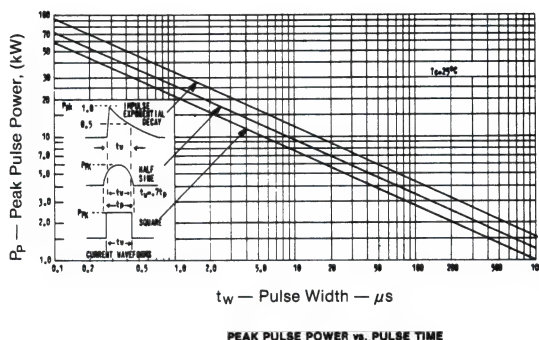


FIGURE 2

AC AND DC APPLICATIONS

TAZ are typically used in parallel to the load or circuit being protected. When the transient voltage exceeds the rated stand-off voltage, the TAZ will go into the avalanche or breakdown mode. It will then act as a shunt so that the destructive energy within the transient bypasses the load as shown in Figure 3.

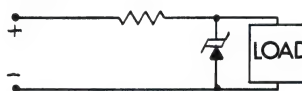


FIGURE 3
DC POWER

Bidirectional TAZ is also available for AC applications as shown in Figure 4.



FIGURE 4

TAZ is used to protect sensitive components in a DC power supply from AC line transients. Figure 5 shows the TAZ placed across the rectifier bridge. With this method a unipolar TAZ can be used, but the surge capability of the rectifier diodes must be compatible with that of the TAZ.

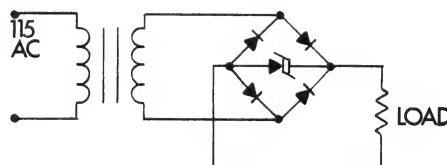


FIGURE 5
AC LINE PROTECTION USING UNIPOLAR TAZ

Figure 6 shows how a bipolar TAZ can be used for the same application, but to protect against line transients that can overstress the rectified diodes used in the bridge.

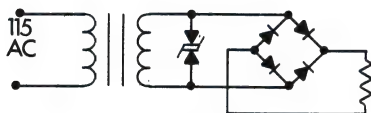


FIGURE 6
AC LINE PROTECTION USING BIDIRECTIONAL TAZ

TRANSIENT SUPPRESSION FOR ENERGIZING AND DE-ENERGIZING OF TRANSFER PRIMARY

Figure 7 shows how bipolar or double anode TAZ can be used to suppress transients caused by the energizing and de-energizing of a transformer primary. When energized, transients can occur when the peak voltage couples the stray capacitance and inductance of the secondary winding causing an oscillating voltage transient.

When de-energizing, large voltage transients occur when the primary circuit is opened while the transformer is driving a high impedance load. Transients can be coupled into the secondary winding when this interruption occurs. TAZ provides a low impedance discharge path to protect sensitive components.

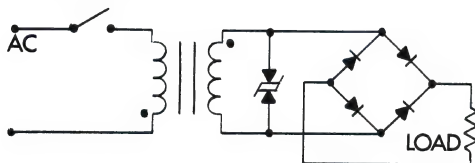


FIGURE 7

TRANSISTOR PROTECTION FOR INDUCTIVE LOAD SWITCHING

TAZ can be used to protect transistors against damaging transients generated by an inductive load when disconnected. Figure 8 shows a TAZ connected collector to emitter to absorb the stored energy released from the load when the transistor turns off. This will reduce the demands upon the safe operating area of the transistor.

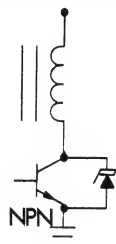


FIGURE 8

MICROPROCESSOR AND MEMORY PROTECTION

Memories and microprocessors along with logic and linear integrated circuits are extremely susceptible to voltage transients. It is very important that protection is provided to prevent costly field failures and down time.

MOS memory protection.

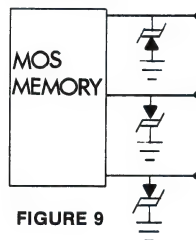


FIGURE 9

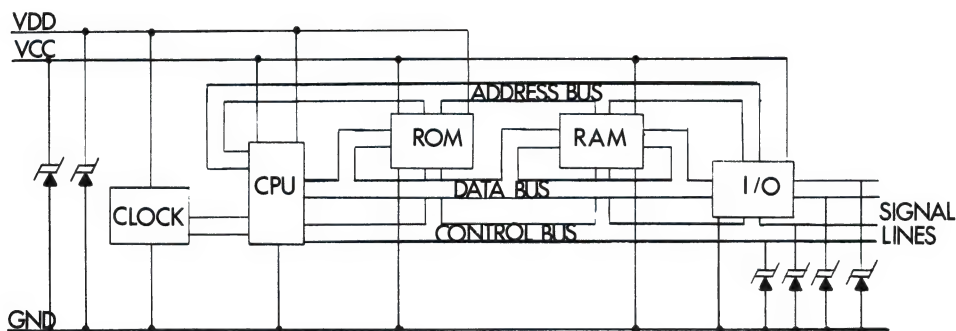


FIGURE 10

TAZ are used on each voltage supply line to the integrated circuit to protect against transients induced on to the power supply line. Placing the TAZ from line to ground will optimize the TAZ peak power dissipation capability.

MICROPROCESSOR SYSTEM PROTECTION

Figure 10 shows TAZ used to protect microprocessor systems from AC line transients and switching transients from the power supply. Also shown are TAZ used to prevent transients induced on to the signal lines from entering the data and control buses. If the microprocessor is operating in a hazardous environment, such as controlling operating functions of machine tools, protection should be provided on both the power supply lines and signal lines.

HIGH VOLTAGE OR CURRENT APPLICATIONS

TAZ can be used in parallel or in series to accommodate applications requiring a higher voltage or surge current rating than offered in single axial leaded device. For higher voltage applications, TAZ can be used in series as shown in Figure 11.

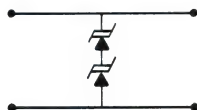


FIGURE 11

When used in this configuration, the total voltage capability equals the sum of the voltages of each additional TAZ in series. The surge current capability remains the same as that of the TAZ with the lowest surge current rating. This, in turn will increase the total peak pulse power dissipation rating.

For higher surge current capabilities, TAZ can be used in parallel as shown in Figure 12.

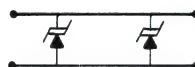


FIGURE 12

When used in parallel, it is very important that the TAZ be closely matched by voltage to assure that one of the devices does not go into the breakdown mode absorbing all of the current. In parallel, the voltage will remain the same as one TAZ, but the current is increased by the surge current rating of each additional TAZ used. This also increases the peak pulse power dissipation rating. Due to the critical aspect of the screening required for parallel combinations, it is recommended that this be handled by the manufacturer.

TAZ CAPACITANCE

For many applications, the TAZ is viewed as a device that does not introduce extraneous noise into the system. It is assumed to react instantaneously and does not create an insertion loss. The low leakage currents do give a low insertion loss, but in fast switching circuits or RF applications the TAZ capacitance becomes an important factor.

Due to the peak pulse power dissipation level required of the TAZ, it is constructed using a large P-N junction which in turn means a higher capacitance. Capacitance is also affected by the avalanche voltage of the device. The greater the breakdown voltage, the lower the capacitance. The lower the breakdown voltage, the greater the capacitance as depicted in the curve for the 1.5KW TAZ series in Figure 13. Note that the capacitance is reduced as the reverse bias voltage is applied.

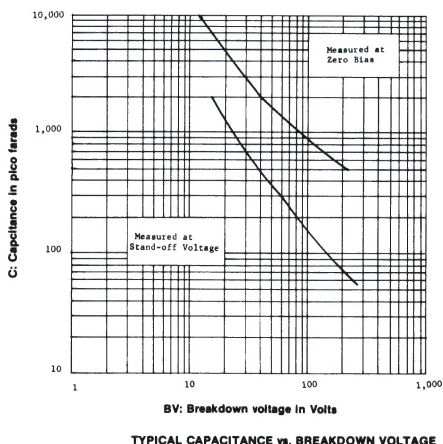


FIGURE 13

When the capacitance level of the device is too high for a particular application, it may be reduced by one of the methods shown in Figures 14 and 15.

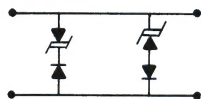


FIGURE 14

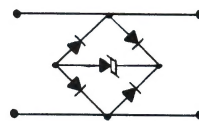


FIGURE 15

In order to reduce the effective capacitance, low capacitance diodes may be used in series. Both methods shown are bi-directional and will require proper selection of the low capacitance diodes used for a particular application. There are four major requirements that are of concern when making this selection:

1. The reverse breakdown of the diode must exceed the TAZ maximum clamping voltage.
2. The forward surge current rating must exceed the expected current level that the TAZ is exposed to under transient conditions.
3. The forward voltage at expected pulse levels must not exceed the allowable voltage level of the protected circuit when added to the other TAZ clamping voltage and other voltage drops in series.
4. The capacitance of the diode must be compatible with the operating frequency of the circuit.

Microsemi offers a line of low capacitance TAZ, the LCE series (epoxy package) for commercial applications and the LC series (DO-13 package) which is hermetically sealed and can be screened to military specifications. For applications requiring a lower capacitance or special assemblies, consult the factory.

Notes

MICROSEMI CORPORATION

Military Qualified Products List

MIL-S-19500 JAN 'S' LEVEL

| | |
|---|------|
| *1N645-1, 1N647-1 | /240 |
| *1N754A-1 thru 1N759A-1 | /127 |
| *1N962B-1 thru 1N973B-1 | /117 |
| *1N4148-1 | /116 |
| *1N4150-1 | /231 |
| *1N5415 thru 1N5420 | /411 |
| *1N5615, 1N5617, 1N5619, 1N5621, 1N5623 | /429 |
| *1N6103 & A thru 1N6112 & A | /516 |

MIL-S-19500 JAN, JANTX, JANTXV LEVELS

| | |
|--|------|
| *1N483B thru 1N485B | /118 |
| *1N645-1, 1N647-1, 1N649-1 | /240 |
| 1N746A thru 1N759A | /127 |
| 1N746A-1 thru 1N759A-1 | /127 |
| 1N821, 1N823, 1N825, 1N827, 1N829 | /159 |
| 1N821-1, 1N823-1, 1N825-1, 1N827-1, 1N829-1 | /159 |
| 1N914 | /116 |
| 1N936B, 1N937B, 1N938B, 1N939B, 1N940B | /156 |
| 1N936B-1, 1N937B-1, 1N938B-1, 1N939B-1, 1N940B-1 | /156 |
| 1N941B, 1N943B, 1N944B, 1N945B | /157 |
| 1N941B-1, 1N943B-1, 1N944B-1, 1N945B-1 | /157 |
| 1N962B thru 1N992B | /117 |
| 1N962B-1 thru 1N992B-1 | /117 |
| 1N1742A | /298 |
| 1N2804B & RB thru 1N2846B & RB | /114 |
| 1N2970B & RB thru 1N3015B & RB | /124 |
| 1N3016B thru 1N3051B | /115 |
| 1N3154 thru 1N3157 | /158 |
| 1N3154-1 thru 1N3157-1 | /158 |
| *1N3206 | /195 |
| *1N3207 | /230 |
| 1N3305B & RB thru 1N3350B & RB | /358 |
| *1N3595 | /241 |
| *1N3611 thru 1N3614 | /228 |
| *1N3644 thru 1N3647 | /279 |
| 1N3821A thru 1N3828A | /115 |
| 1N3890 & R, 1N3891 & R, 1N3893 & R | /304 |
| *1N3957 | /228 |
| 1N3993A & RA thru 1N4000A & RA | /272 |
| 1N4099 thru 1N4135 | /435 |
| 1N4099-1 thru 1N4135-1 | /435 |
| 1N4148, 1N4148-1 | /116 |
| *1N4150-1 | /231 |
| 1N4153, 1N4153-1 | /337 |
| *1N4245 thru 1N4249 | /286 |
| 1N4370A thru 1N4372A | /127 |
| 1N4370A-1 thru 1N4372A-1 | /127 |
| 1N4454, 1N4454-1 | /144 |
| *1N4460 thru 1N4496 | /406 |
| 1N4549B & RB thru 1N4554B & RB | /358 |
| 1N4557B & RB thru 1N4562B & RB | /114 |
| 1N4565A thru 1N4574A | /452 |
| 1N4565A-1 thru 1N4569A-1 | /452 |
| 1N4570A-1 thru 1N4574A-1 | /452 |
| 1N4614 thru 1N4627 | /435 |
| 1N4614-1 thru 1N4627-1 | /435 |

| | |
|---|------|
| *1N4938, 1N4938-1 | /169 |
| *1N4942 thru 1N4948 | /359 |
| *1N4954 thru 1N4996 | /356 |
| *1N5194 thru 1N5196 | /118 |
| *1N5415 thru 1N5420 | /411 |
| 1N5518B thru 1N5546B | /437 |
| 1N5518B-1 thru 1N5546B-1 | /437 |
| *1N5550 thru 1N5552 | /420 |
| *1N5614, 1N5616, 1N5618, 1N5620, 1N5622 | /427 |
| *1N5615, 1N5617, 1N5619, 1N5621, 1N5623 | /429 |
| 1N5629A thru 1N5665A | /500 |
| *1N5802, 1N5804, 1N5806 | |
| 1N5807, 1N5809, 1N5811 | /477 |
| 1N5907 | /500 |
| *1N5968 and 1N5969 | /356 |
| 1N6036A thru 1N6072A | /507 |
| *1N6074 thru 1N6075 | /503 |
| *1N6103 & A thru 1N6137 & A | /516 |
| *1N6139 & A thru 1N6173 & A | /516 |
| *1N6309 thru 1N6336 | /533 |
| *1N6485 thru 1N6491 | /406 |

*Products qualified at MICROSEMI Santa Ana, others at Scottsdale or both

Qualifications Pending

MIL-S-19500 JAN 'S' LEVEL

| | |
|---|------|
| 1N649-1 | /240 |
| 1N821-1, 1N823-1, 1N825-1, 1N827-1, 1N829-1 | /159 |
| 1N974B-1 thru 1N992B-1 | /117 |
| 1N4454-1 | /144 |
| 1N4460 thru 1N4496 | /406 |
| 1N4938-1 | /169 |
| 1N4954 thru 1N4996 | /356 |
| 1N5194 thru 1N5196 | /118 |
| 1N5550 thru 1N5554 | /420 |
| 1N5614, 1N5616, 1N5618, 1N5620, 1N5622 | /427 |
| 1N5802, 1N5804, 1N5806 | |
| 1N5807, 1N5809, 1N5811 | /477 |

MIL-S-19500 JAN, JANTX, JANTXV LEVELS

| | |
|----------------------------------|------|
| 1N457 thru 1N459 | /193 |
| 1N643, 1N662 and 1N663 | /256 |
| 1N3064 | /144 |
| 1N3070, 1N3070-1 | /169 |
| 1N3600 | /231 |
| 1N4150 | /231 |
| 1N4531 | /116 |
| 1N4532 | /144 |
| 1N4534 | /337 |
| 1N5186 thru 1N5190 | /424 |
| 1N5553 and 1N5554 | /420 |
| 1N6337 thru 1N6355 | /533 |
| 1N6461 thru 1N6468 | /551 |
| 1N6469 thru 1N6476 | /552 |
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| M19500/483-01 thru M19500/483-04 | /483 |



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